## LSI Logic Data Book 1986

## Bipolar and CMOS LSI/VLSI

Texas


## Application Reports

## LSI Logic Data Book

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## INTRODUCTION

The LSI Logic Data Book presents pertinent technical information on Texas Instruments complex bipolar, and CMOS LSI logic'integrated circuits. The bipolar LSI products described in this volume include:
o The fastest TTL-compatible 8-bit processor slice chip set available. The chip set includes an 8-bit registered ALU, a 14-bit microsequencer, a 16- and 32-bit expandable barrel shifter, and a 16 -word by 4-bit register file.

- The fastest stand-alone 32-bit error detection and correction circuit (EDAC)
- High-performance $16 \times 4$ and $16 \times 5$ "zero-fall-through" FIFOs (first in, first out) memory devices with 24-nanosecond fall-through times
- A high-speed "flash" 32-bit barrel shifter (SN74AS8838). The SN74AS8838 is the first member of the Texas Instruments 32-bit processor chip set.

Specifications on CMOS LSI products included in this volume describe the following:

- The THCT1010, which is the lowest power 16-×16-bit multiplier and accumulator (MAC) available.
- Two 64 K and 256 K DRAM controllers with inputs that are TTL- and CMOS-voltage compatible.
- Two high-speed CMOS múltilevel pipeline registers, which offer a reduction in power over previously available devices.

To assist you in the selection of complex MSI logic components to complement a system design, the LSI Logic Data Book contains specifications on high-performance bus transceivers, readback latches, comparators, and controllers.

Many Texas Instruments leadership bipolar LSI functions use our new advanced bipolar technology, IMPACTTM (IMPlanted Advanced Composed Technology). This unique innovation offers performance advantages in speed, power, and circuit density over preceding bipolar technologies. The process offers such features as:

- 2- $\mu \mathrm{m}$ feature size
- 7- $\mu \mathrm{m}$ metal pitch
- Walled emitters
- Ion implantation
- Oxide isolation
- Composed masks

This data book provides a functional index to all bipolar digital device types available or under development. Packaging dimensions given in the Mechanical Data section of this book are in metric measurement land parenthetically in inches), which should simplify board layout for designers involved in metric conversion and new designs. The general information section includes an explanation of the function tables, parameter measurement information, and typical characteristics related to the products listed in this volume.

Complete technical data for any Texas Instruments semiconductor/component product is available from your nearest TI field sales office, local authorized TI distributor, or by writing direct to:

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Dallas, Texas 75265
We sincerely believe that you will find the new LSI Logic Data Book a meaningful addition to your technical library.

## General Information

Numerical Index
Glossary
Explanation of Function Tables
Parameter Measurement Information
Functional Index

LSI Devices

## Application Reports

Advanced Schottky Family<br>Error Detection and Correction<br>Memory Mapping<br>Bit-Slice Processor 8-Bit Family<br>Excerpt - SN74AS888, SN74AS890<br>Bit-Slice Processor User's Guide

Mechanical Data

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|  |  | NUMERIC |
| :---: | :---: | :---: |
| SN54AS181A | SN74AS181A | 2-3 |
| SN54LS222 | SN74LS222 | 2-13 |
| SN54LS224 | SN74LS224 | 2-13 |
|  | SN74S225 | 2-21 |
| SN54LS227 | SN74LS227 | 2-13 |
| SN54LS228 | SN74LS228 | 2-13 |
| SN54ALS229A | SN74ALS229A | 2-27 |
| SN54ALS232A | SN74ALS232A | 2-33 |
| SN54ALS233A | SN74ALS233A | 2-37 |
|  | SN74AS250 | 2-43 |
| SN54ALS280 | SN74ALS280. | 2-47 |
| SN54AS280 | SN74AS280 | 2-47 |
| SN54AS286 | SN74AS286 | 2-53 |
| SN54LS610 | SN74LS610 | 2-59 |
| SN54LS611 | SN74LS611 | 2-59 |
| SN54LS612 | SN74LS612 | 2-59 |
| SN54LS613 | SN74LS613 | 2-59 |
| SN54ALS 616 | SN74ALS616 | 2-69 |
| SN54ALS617 | SN74ALS617 | 2-69 |
| SN54ALS632A | SN74ALS632A | 2-81 |
| SN54AS632 | SN74AS632 | 2-97 |
| SN54ALS633 | SN74ALS633 | 2.81 |
| SN54ALS634 | SN74ALS634 | 2-81 |
| SN54AS634 | SN74AS634 | 2-97 |
| SN54ALS635 | SN74ALS635 | 2-81 |
| SN54ALS646 | SN74ALS646 | 2-111 |
| SN54AS646 | SN74AS646 | 2-111 |
| SN54ALS647 | SN74ALS647 | 2-111 |
| SN54ALS648 | SN74ALS648 | 2-111 |
| SN54AS648 | SN74AS648 | 2-111 |
| SN54ALS 649 | SN74ALS649 | 2-111 |
| SN54ALS651 | SN74ALS651 | 2-125 |
| SN54AS651 | SN74AS651 | 2-125 |
| SN54ALS652 | SN74ALS652 | 2-125 |
| SN54AS652 | SN74AS652 | 2-125 |
| SN54ALS653 | SN74ALS653 | 2-125 |
| SN54ALS654 | SN74ALS654 | 2-125 |
| SN54ALS666 | SN74ALS666 | 2-137 |
| SN54ALS667 | SN74ALS667 | 2-137 |
| SN54AS821 | SN74AS821 | 2-145 |
| SN54AS822 | SN74AS822 | 2-145 |
| SN54AS823 | SN74AS823 | 2-151 |
| SN54AS824 | SN74AS824 | 2-151 |
| SN54AS825 | SN74AS825 | 2-157 |
| SN54AS826 | SN74AS826 | 2-157 |
| SN54ALS841 | SN74ALS841 | 2-163 |
| SN54AS841 | SN74AS841 | 2-163 |
| SN54ALS842 | SN74ALS842 | 2-163 |
| SN54AS842 | SN74AS842 | 2-163 |
| SN54ALS843 | SN74ALS843 | 2-173 |
| SN54AS843 | SN74AS843 | 2-173 |
| SN54ALS844 | SN74ALS844 | 2-173 |
| SN54AS844 | SN74AS844 | 2-173 |
| SN54ALS845 | SN74ALS845 | 2-181 |
| SN54AS845 | SN74AS845 | 2-181 |
| SN54ALS846 | SN74ALS846 | 2-181 |
| SN54AS846 | SN74AS846 | 2-181 |
|  | SN74AS850 | 2-191 |
|  | SN74AS851 | 2-191 |


| L INDEX |  |  |
| :---: | :---: | :---: |
| SN54AS852 | SN74AS852 | 2-201 |
| SN54AS856 | SN74AS856 | 2-207 |
| SN54AS867 | SN74AS867 | 2-213 |
| SN54AS869 | SN74AS869 | 2-213 |
| SN54AS870 | SN74AS870 | 2-219 |
| SN54AS871 | SN74AS871 | 2-219 |
| SN54AS877 | SN74AS877 | 2-225 |
| SN54AS881A | SN74AS881A | 2-3 |
| SN54AS882A | SN74AS882A | 2-231 |
| SN54AS885 | SN74AS885 | 2-239 |
| SN54AS887 | SN74AS887 | 2-245 |
| SN54AS888 | SN74AS888 | 2-293 |
| SN54AS890 | SN74AS890 | 2-343 |
| SN54AS895 | SN74AS895 | 2-361 |
| SN54AS897A | SN74AS897A | 2-411 |
| SN54ALS963 | SN74ALS963 | 2-429 |
| SN54ALS964 | SN74ALS964 | 2-429 |
|  | SN74ALS990 | 2.441 |
|  | SN74ALS991 | 2-441 |
|  | SN74ALS992 | 2.449 |
|  | SN74ALS993 | 2-449 |
|  | SN74ALS994 | 2-457 |
|  | SN74ALS995 | 2-457 |
|  | SN74ALS996 | 2-465 |
| SN54AS1181 | SN74AS1181 | 2-471 |
| SN54ALS2967 | SN74ALS2967 | 2-483 |
| SN54ALS2968 | SN74ALS2968 | 2-483 |
| SN54ALS6301 | SN74ALS6301. | 2-503 |
| SN54ALS6302 | SN74ALS6302 | 2-503 |
|  | SN74ALS8400 | 2.509 |
| SN54AS8834 | SN74AS8834 | 2-513 |
| SN54AS8838 | SN74AS8838 | 2-523 |
| SN54ALS29818 | SN74ALS29818. | 2-533 |
| SN54ALS29819 | SN74ALS29819. | 2.533 |
| SN54ALS29821 | SN74ALS29821. | 2-545 |
| SN54ALS29822 | SN74ALS29822. | 2-545 |
| SN54ALS29823 | SN74ALS29823. | 2-551 |
| SN54ALS29824 | SN74ALS29824. | 2-551 |
| SN54ALS29825 | SN74ALS29825. | 2-559 |
| SN54ALS29826 | SN74ALS29826. | 2-559 |
| SN54ALS29827 | SN74ALS29827. | 2-565 |
| SN54ALS29828 | SN74ALS29828. | 2.565 |
| SN54ALS29861 | SN74ALS29861. | 2-571 |
| SN54ALS29862 | SN74ALS29862. | 2.571 |
| SN54ALS29863 | SN74ALS29863. | 2-577 |
| SN54ALS29864 | SN74ALS29864 | 2-577 |
| THC ${ }^{\text {1010-160M }}$ |  | 2.583 |
|  | THCT1010-100. | 2-583 |
|  | THCT 1010-140E | 2-583 |
| THCT2000M | THCT2000E | 2-593 |
|  | THCT4502. | 2.597 |
|  | THCT29520E | 2-613 |
|  | THCT29520 | 2-613 |
|  | THCT 29521 E | 2-613 |
|  | THCT29521. | 2-613 |
|  | TMS2150 | 2-619 |
|  | TMS4500A | 2-627 |

## INTRODUCTION

These symbols, terms, and definitions are in accordance with those currently agreed upon by the JEDEC Council of the Electronic Industries Association (EIA) for use in the USA and by the International Electrotechnical Commission (IEC) for international use.


[^0]$V_{I H} \quad$ High-level input voltage
An input voltage within the more positive (less negative) of the two ranges of values used to represent the binary variables.
NOTE: A minimum is specified that is the least-positive value of high-level input voltage for which operation of the logic element within specification limits is guaranteed.
$\mathrm{V}_{\mathrm{IK}}$ Input clamp voltage
An input voltage in a region of relatively low differential resistance that serves to limit the input voltage swing.
VIL Low-level input voltage
An input voltage level within the less positive (more negative) of the two ranges of values used to represent the binary variables.
NOTE: A maximum is specified that is the most-positive value of low-level input voltage for which operation of the logic element within specification limits is guaranteed.
$\mathbf{V}_{\mathbf{O H}} \quad$ High-level output voltage
The voltage at an output terminal with input conditions applied that, according to the product specification, will establish a high level at the output.

VOL Low-level output voltage
The voltage at an output terminal with input conditions applied that, according to the product specification, will establish a low level at the output.
$t_{a}$

## Access time

The time interval between the application of a specified input pulse and the availability of valid signals at an output.
${ }^{\mathrm{t}}$ dis $\quad$ Disable time (of a three-state or open-collector output)
The propagation time between the specified reference points on the input and output voltage waveforms with the output changing from either of the defined active levels (high or low) to a high-impedance (off) state. NOTE: For 3 -state outputs, $t_{\text {dis }}=t_{\text {pHZ }}$ or tpLZ. Open-collector outputs will change only if they are low at the time of disabling so $t_{\text {dis }}=t_{\text {PLH }}$.
ten Enable time (of a three-state or open-collector output)
The propagation time between the specified reference points on the input and output voltage waveforms with the output changing from a high-impedance (off) state to either of the defined active levels (high or low). NOTE: In the case of memories, this is the access time from an enable input (e.g., $\overline{\mathrm{G}}$ ). For 3 -state outputs, $t_{e n}=t_{P Z H}$ or tPZL. Open-collector outputs will change only if they are responding to data that would cause the output to go low so $\mathrm{t}_{\mathrm{en}}=\mathrm{t}_{\mathrm{pHL}}$.
*Current out of a terminal is given as a negative value.

## glossary <br> TTL SYMBOLS, TERMS, AND DEFINITIONS

| $t^{\text {h }}$ | Hold time |
| :---: | :---: |
|  | The time interval during which a signal is retained at a specified input terminal after an active transition occurs at another specified input terminal. |
|  | NOTES: 1 . The hold time is the actual time interval between two signal events and is determined by the system in which the digital circuit operates. A minimum value is specified that is the shortest interval for which correct operation of the digital circuit is guaranteed. |
|  | 2. The hold time may have a negative value in which case the minimum limit defines the longest interval (between the release of the signal and the active transition) for which correct operation of the digital circuit is guaranteed. |
| $t_{\text {pd }}$ | Propagation delay time |
|  | The time between the specified reference points on the input and output voltage waveforms with the output changing from one defined level (high or low) to the other defined level. ( $\mathrm{t}_{\mathrm{Dd}}=\mathrm{t}_{\mathrm{PHL}}$ or $\left.\mathrm{t}_{\mathrm{PLH}}\right)$. |
| ${ }^{\text {tPHL }}$ | Propagation delay time, high-to-low-level output |
|  | The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined high level to the defined low level. |
| ${ }^{\text {t PHZ }}$ | Disable time (of a three-state output) from high level |
|  | The time interval between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined high level to a high-impedance (off) state. |
| tPLH | Propagation delay time, low-to-high-level output |
|  | The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined low level to the defined high level. |
| tPLZ | Disable time (of a three-state output) from low level |
|  | The time interval between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined low level to a high-impedance (off) state. |
| ${ }^{\text {tPZH }}$ | Enable time (of a three-state output) to high level |
|  | The time interval between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined high level. |
| ${ }^{\text {tPZL }}$ | Enable time (of a three-state output) to low level |
|  | The time interval between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined low level. |
| $\mathbf{t s r}_{\mathbf{s r}}$ | Sense recovery time |
|  | The time interval needed to switch a memory from a write mode to a read mode and to obtain valid data signals at the output. |
| $\mathrm{t}_{\mathbf{s u}}$ | Setup time |
|  | The time interval between the application of a signal at a specified input terminal and a subsequent active transition at another specified input terminal. |
|  | NOTES: 1 . The setup time is the actual time interval between two signal events and is determined by the system in which the digital circuit operates. A minimum value is specified that is the shortest interval for which correct operation of the digital circuit is guaranteed. |
|  | 2. The setup time may have a negative value in which case the minimum limit defines the longest interval (between the active transition and the application of the other signal) for which correct operation of the digital circuit is guaranteed. |
| $t_{w}$ | Pulse duration (width) |
|  | The time interval between specified reference points on the leading and trailing edges of the pulse waveform. |

## GLOSSARY <br> TTL SYMBOLS, TERMS, AND DEFINITIONS

## PART II - CLASSIFICATION OF CIRCUIT COMPLEXITY

## Gate Equivalent Circuit

A basic unit-of-measure of relative digital-circuit complexity. The number of gate equivalent circuits is that number of individual logic gates that would have to be interconnected to perform the same function.

Large-Scale Integration, LSI
A concept whereby a complete major subsystem or system function is fabricated as a single microcircuit. In this context a major subsystem or system, whether digital or linear, is considered to be one that contains 100 or more equivalent gates or circuitry of similar complexity.

## Medium-Scale Integration, MSI

A concept whereby a complete subsystem or system function is fabricated as a single microcircuit. The subsystem or system is smaller than for LSI, but whether digital or linear, is considered to be one that contains 12 or more equivalent gates or circuitry of similar complexity.

Small-Scale Integration, SSI
Integrated circuits of less complexity than medium-scale integration (MSI).

## Very-Large-Scale Integration, VLSI

The description of any IC technology that is much more complex than large-scale integration (LSI), and involves a much higher equivalent gate count. At this time an exact definition including a minimum gate count has not been standardized by JEDEC or the IEEE.

The following symbols are used in function tables on TI data sheets:

| H | $=$ | high level (steady state) |
| :---: | :---: | :---: |
| L | = | low level (steady state) |
| $\uparrow$ | $=$ | transition from low to high level |
| $\downarrow$ | = | transition from high to low level |
| $\rightarrow$ | $=$ | value/level or resulting value/level is routed to indicated destination |
| $\cap$ | = | value/level is re-entered |
| $x$ | $=$ | irrelevant (any input, including transitions) |
| Z | $=$ | off (high-impedance) state of a 3-state-output |
| a...h | $=$ | the level of steady-state inputs at inputs $A$ through $H$ respectively |
| $\mathrm{O}_{0}$ | $=$ | level of $Q$ before the indicated steady-state input conditions were established |
| $\overline{\mathrm{O}}_{0}$ | = | complement of $Q_{0}$ or level of $\bar{\chi}$ before the indicated steady-state input conditions were established |
| $\mathrm{O}_{\mathrm{n}}$ | = | level of Q before the most recent active transition indicated by $\downarrow$ or $\uparrow$ |
| $\sqrt{\square}$ | $=$ | one high-level pulse |
| [ | $=$ | one low-level pulse |
| TOGGLE | = | each output changes to the complement of its previous level on each active transition indicated by $\downarrow$ or $\uparrow$. |

If, in the input columns, a row contains only the symbols $\mathrm{H}, \mathrm{L}$, and/or X , this means the indicated output is valid whenever the input configuration is achieved and regardless of the sequence in which it is achieved. The output persists so long as the input configuration is maintained.

If, in the input columns, a row contains $H, L$, and/or $X$ together with $\uparrow$ and/or $\downarrow$, this means the output is valid whenever the input configuration is achieved but the transition(s) must occur following the achievement of the steady-state levels. If the output is shown as a level ( $H, L, Q_{0}$, or $\left.\overline{\mathrm{O}}_{0}\right)$, it persists so long as the steady-state input levels and the levels that terminate indicated transitions are maintained. Unless otherwise indicated, input transitions in the opposite direction to those shown have no effect at the output. (If the output is shown as a pulse, $\sqrt{L}$ or $\boldsymbol{\square}$, the pulse follows the indicated input transition and persists for an interval dependent on the circuit.)

Among the most complex function tables in this book are those of the shift registers. These embody most of the symbols used in any of the function tables, plus more. Below is the function table of a 4 -bit bidirectional universal shift register, e.g., type SN74194.

| FUNCTION TABLE |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUTS |  |  |  |  |  |  |  |  |  | OUTPUTS |  |  |  |
| CLEAR | MODE |  | ClOCK | SERIAL |  | PARALLEL |  |  |  | $\mathrm{O}_{\mathbf{A}}$ | $\mathbf{O}_{\mathbf{B}}$ | ${ }^{0} \mathbf{C}$ | $Q_{D}$ |
|  | S1 | S0 |  | LEFT | RIGHT | A | B | C | D |  |  |  |  |
| L | X | X | X | $x$ | X | X | X | X | X | L | L | L | $L$ |
| H | X | $x$ | L | $x$ | $x$ | X | $x$ | x | X | $\mathrm{O}_{\text {AO }}$ | $\mathrm{O}_{\mathrm{BO}}$ | $\mathrm{O}_{\mathrm{CO}}$ | $\mathrm{O}_{\text {DO }}$ |
| H | H | H | $\dagger$ | $x$ | X | a | $b$ | c | d | a | b | c | d |
| H | L. | H | $\uparrow$ | $x$ | H | $x$ | $x$ | X | $x$ | H | $\mathrm{Q}_{\text {An }}$ | $\mathrm{O}_{\mathrm{Bn}}$ | $\mathrm{Q}_{\mathrm{Cn}}$ |
| H | L | H | $\uparrow$ | X | L | $x$ | $x$ | x | X | L. | $\mathrm{Q}_{\text {An }}$ | $\mathrm{O}_{\mathrm{Bn}}$ | $\mathrm{Q}_{\mathrm{Cn}}$ |
| H | H | L | $\dagger$ | H | $x$ | $x$ | $x$ | X | $x$ | $\mathrm{O}_{8 n}$ | $\mathrm{O}_{\mathrm{Cn}}$ | Q ${ }_{\text {D }}$ | H |
| H | H | $L$ | $\uparrow$ | L | $x$ | X | $x$ | X | X | $\mathrm{O}_{\mathrm{Bn}}$ | $\mathrm{O}_{\mathrm{Cn}}$ | QDn | L |
| H | L | L | X | X | X | X | X | X | X | $\mathrm{O}_{\mathrm{AO}}$ | $\mathrm{O}_{\mathrm{BO}}$ | $\mathrm{O}_{\mathrm{CO}}$ | $\mathrm{Q}_{\mathrm{DO}}$ |

The first line of the table represents a synchronous clearing of the register and says that if clear is low, all four outputs will be reset low regardless of the other inputs. In the following lines, clear is inactive (high) and so has no effect.

The second line shows that so long as the clock input remains low (while clear is high), no other input has any effect and the outputs maintain the levels they assumed before the steady-state combination of clear high and clock low was established. Since on other lines of the table only the rising transition of the clock is shown to be active, the second line implicitly shows that no further change in the outputs will occur while the clock remains high or on the high-to-low transition of the clock.

The third line of the table represents synchronous parallel loading of the register and says that if S1 and S0 are both high then, without regard to the serial input, the data entered at $A$ will be at output $Q_{A}$, data entered at $B$ will be at $\mathrm{Q}_{\mathrm{B}}$, and so forth, following a low-to-high clock transition.

The fourth and fifth lines represent the loading of high- and low-level data, respectively, from the shift-right serial input and the shifting of previously entered data one bit; data previously at $Q_{A}$ is now at $Q_{B}$, the previous levels of $Q_{B}$ and $Q_{C}$ are now at $Q_{C}$ and $Q_{D}$ respectively, and the data previously at $Q_{D}$ is no longer in the register. This entry of serial data and shift takes place on the low-to-high transition of the clock when S1 is low and SO is high and the levels at inputs $A$ through $D$ have no effect.

The sixth and seventh lines represent the loading of high- and low-level data, respectively, from the shift-left serial input and the shifting of previously entered data one bit; data previously at $Q_{B}$ is now at $Q_{A}$, the previous levels of $Q_{C}$ and $\mathrm{Q}_{\mathrm{D}}$ are now at $\mathrm{Q}_{\mathrm{B}}$ and $\mathrm{Q}_{\mathrm{C}}$, respectively, and the data previousty at $\mathrm{Q}_{\mathrm{A}}$ is no longer in the register. This entry of serial data and shift takes place on the low-to-high transition of the clock when S1 is high and SO is low and the levels at inputs $A$ through $D$ have no effect.

The last line shows that as long as both mode inputs are low, no other input has any effect and, as in the second line, the outputs maintain the levels they assumed before the steady-state combination of clear high and both mode inputs low was established.

## PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT FOR
BI-STATE
TOTEM-POLE OUTPUTS


HIGH-LEVEL
PULSE


VOLTAGE WAVEFORMS PULSE WIDTHS


NOTES: B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses have the following characteristics: PRR $\leq 1 \mathrm{MHz}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=2 \mathrm{~ns}$, duty cycle $=50 \%$.
D. When measuring propagation delay times of 3 -state outputs, switch S 1 is closed.

## GATES AND INVERTERS



POSITIVE-NAND GATES AND INVERTERS WITH OPEN-COLLECTOR OUTPUTS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { THL } \end{aligned}$ | ALS | AS | H | L | LS | S |  |
| Hex Inverters | '05 | - |  |  | - |  | - | - | 2 |
|  |  |  | A |  |  |  |  |  | 3 |
|  | - 1005 |  | - |  |  |  |  |  |  |
| Quadruple 2-Input Gates | $\cdot 01$ | - |  |  | - |  | $\bullet$ |  | 2 |
|  |  |  | $\bullet$ |  |  |  |  |  | 3 |
|  | '03 | - |  |  |  | $\bullet$ | - | - | 2 |
|  |  |  | B |  |  |  |  |  | 3 |
|  | '1003 |  | A |  |  |  |  |  |  |
| Triple 3-Input Gates | '12 | - |  |  |  |  | - |  | 2 |
|  |  |  | A |  |  |  |  |  | 3 |
| Dual 4-Input Gates | '22 | - |  |  | $\bullet$ |  | - | $\bullet$ | 2 |
|  |  |  | B |  |  |  |  |  | 3 |


| POSITIVE-AND GATES |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | H | LS | S |  |
| Hex 2-Input Gates | '808 |  | A | B |  |  |  | 3 |
| Quadruple 2-Input Gates | '08 | - |  |  |  | - | - | 2 |
|  |  |  | - | $\bullet$ |  |  |  | 3 |
|  | $\cdot 1008$ |  | A | $\bullet$ |  |  |  |  |
| Triple 3-Input Gates | '11 |  |  |  | $\bullet$ | $\bullet$ | $\bullet$ | 2 |
|  |  |  | A | $\bullet$ |  |  |  | 3 |
|  | '1011 |  | A |  |  |  |  | 3 |
| Dual 4-Input Gates | '21 |  |  |  | $\bullet$ | - |  | 2 |
|  |  |  | - | $\bullet$ |  |  |  | 3 |
| Triple 4-Input AND/NAND | 800 |  |  | 4 |  |  |  |  |

- Denotes available technology.

A Denotes planned new products.
A Denotes " $A$ " suffix version available in the technology indicated.
$B$ Denotes " $B$ " suffix version available in the technology indicated.

GATES, EXPANDERS, BUFFERS, DRIVERS, AND TRANSCEIVERS


EXPANDABLE GATES

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | STD | ALS | AS | H | L | LS |  |
| $\begin{array}{l}\text { Dual 4-Input Positive-NOR } \\ \text { with Strobe }\end{array}$ | $\cdot 23$ | - |  |  |  |  |  | 2 |
| 4-Wide AND-OR | 52 |  |  |  | $\bullet$ |  |  |  |
| 4-Wide AND-OR-INVERT | '53 | - |  |  | $\bullet$ |  |  |  |
| 2-Wide AND-OR-INVERT | 55 |  |  |  | - | $\bullet$ | $\bullet$ |  |
| Dual 2-Wide AND-OR-INVERT | 50 | - |  |  | $\bullet$ |  |  |  |

EXPANDERS

| DESCRIPTION |  | TECHNOLOGY |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | STD <br> TTL | ALS | AS | H | VOLUME |
| Dual 4-Input |  | $\bullet$ |  |  | $\bullet$ |  |
| Triple 3-Input | '61 |  |  |  | $\bullet$ | 2 |
| 3-2-2-3 Input AND-OR | $' 62$ |  |  |  | $\bullet$ |  |

BUFFER AND INTERFACE GATES WITH OPEN-COLLECTOR OUTPUTS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | S |  |
| Hex | '07 | $\bullet$ |  |  |  |  | 2 |
|  | 17 | - |  |  |  |  |  |
|  | . 35 |  | $\bullet$ |  |  |  | 3 |
|  | '1035 |  | $\bullet$ |  |  |  | 3 |
| Hex Inverter | '06 | $\bullet$ |  |  |  |  | 2 |
|  | '16 | $\bullet$ |  |  |  |  |  |
|  | '1005 |  | - |  |  |  | 3 |
| Quad 2-input Positive-NAND | . 26 | - |  |  | $\bullet$ |  | 2 |
|  | '38 | - |  |  | $\bullet$ | $\bullet$ |  |
|  |  |  | A |  |  |  | 3 |
|  | '39 | - |  |  |  |  | 2 |
|  | '1003 |  | A |  |  |  | 3 |
| Quad 2-Input Positive-NOR | '33 | $\bullet$ |  |  | $\bullet$ |  | 2 |
|  |  |  | A |  |  |  | 3 |

BUFFERS. DRIVERS. AND BUS TRANSCEIVERS WITH OPEN-COLLECTOR OUTPUTS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | S |  |
| Noninverting Octal Buffers/Drivers | $\cdot 743$ |  | 4 |  |  |  | 3 |
|  | '757 |  | - | - |  |  |  |
|  | '760 |  |  | - |  |  |  |
| Inverting Octal Buffers/Drivers | '742 |  | 4 |  |  |  |  |
|  | '756 |  |  | $\bullet$ |  |  |  |
|  | '763 |  | - | - |  |  |  |
| Inverting and Noninverting Octal Buffers/Drivers | '762 |  | - | - |  |  |  |
| Noninverting Quad Transceivers | '759 |  |  | - |  |  |  |
| Inverting Quad Transceivers | '758 |  |  | $\bullet$ |  |  |  |

- Denotes available technology.

ADenotes planned new products.
A Denotes " $A$ " suffix version available in the technology indicated.

## GATES, EXPANDERS, BUFFERS, DRIVERS, AND TRANSCEIVERS

| description | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|l} \hline \text { STD } \\ \mathrm{TTL} \end{array}$ | ALS | AS | LS | s |  |
| Noninverting 10-Bit Buffers/Drivers | '29827 |  | 4 |  |  |  | LSI |
| Inverting 10-Bit Buffers/Drivers | '29828 |  | A |  |  |  |  |
| Noninverting 10-8it Transceivers | 29861 |  | $\triangle$ |  |  |  |  |
| Inverting 10-Bit Transceivers | '29862 |  | $\Delta$ |  |  |  |  |
| Noninverting 9-8it Transceivers | 29863 |  | - |  |  |  |  |
| Inverting 9-Bit Transceivers | 29864 |  | $\pm$ |  |  |  |  |
| Noninverting Octal Buffers/Drivers | '241 |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  |  |  | A | $\bullet$ |  |  | 3 |
|  | '244 |  |  |  | - | $\bullet$ | 2 |
|  |  |  | A | $\bullet$ |  |  | 3 |
|  | '465 |  |  |  | - |  | 2 |
|  |  |  | A |  |  |  | 3 |
|  | '467 |  |  |  | - |  | 2 |
|  |  |  | A |  |  |  | 3 |
|  | '541 |  |  |  | - |  | 2 |
|  |  |  | $\bullet$ |  |  |  | 3 |
|  | $\cdot 1241$ ! |  | 4 |  |  |  |  |
|  | '1244 |  | A |  |  |  |  |
| Inverting Octal Buffers/Drivers | '231 |  | - | $\cdot$ |  |  |  |
|  | '240 |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  |  |  | A | $\bullet$ |  |  | 3 |
|  | '466 |  |  |  | - |  | 2 |
|  |  |  | A |  |  |  | 3 |
|  | '468 |  |  |  | - |  | 2 |
|  |  |  | A |  |  |  | 3 |
|  | '540 |  |  |  | - |  | 2 |
|  |  |  | - |  |  |  | 3 |
|  | $\cdot 12409$ |  | - |  |  |  |  |
| Inverting and Noninverting Octal Buffers/Drivers | '230 |  |  | - |  |  | 3 |
| Octal Transceivers | 245 |  |  |  | $\bullet$ |  | 2 |
|  |  |  | A | $\bullet$ |  |  | 3 |
|  | '1245 |  | A |  |  |  |  |
| Noninverting Hex Buffers/Drivers | '365 | A |  |  | A |  | 2 |
|  |  |  | - |  |  |  | 3 |
|  | '367 | A |  |  | A |  | 2 |
|  |  |  | - |  |  |  | 3 |
| Inverting Hex Buffers/Drivers | 366 | A |  |  | A |  | 2 |
|  |  |  | - |  |  |  | 3 |
|  | 368 | A |  |  | A |  | 2 |
|  |  |  | $\triangle$ |  |  |  | 3 |
| Quad Buffers/Drivers with Independent Output Controls | '125 | $\bullet$ |  |  | A |  | 2 |
|  | 126 | - |  |  | A |  |  |
|  | '425 | $\bullet$ |  |  |  |  |  |
|  | '426 | $\bullet$ |  |  |  |  |  |
| Noninverting Quad Transceivers | 243 |  |  |  | - |  | 3 |
|  |  |  | A | - |  |  |  |
|  | -12439 |  | - |  |  |  |  |
| Inverting Quad Transceivers | '242 |  |  |  | $\bullet$ |  | 2 |
|  |  |  | A | - |  |  | 3 |
|  | $\cdot 12421$ |  | - |  |  |  |  |
| Quad Transceivers with Storage | 226 |  |  |  |  | $\bullet$ | 2 |
| 12-Input NAND Gate | . 134 |  |  |  |  | $\bullet$ |  |


| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | s |  |
| Hex 2-Input Positive-NAND | '804 |  | A | B |  | 3 |
| Hex 2-Input Positive-NOR | '805 |  | A | B |  |  |
| Hex 2 -Input Positive-AND | '808 |  | A | B |  |  |
| Hex 2 -Input Positive-OR | '832 |  | A | B |  |  |
| Quad 2-Input Positive-NOR | '128 | - |  |  |  | 2 |
| Dual 4-Input Positive-NAND | '140 |  |  |  | $\bullet$ |  |

[^1]- Denotes planned new products.
- Denotes very low power.

A Denotes " $A$ " suffix version available in the technology indicated.
$B$ Denotes " $B$ " suffix version available in the technology indicated.

## BUFFERS, DRIVERS, TRANSCEIVERS, AND CLOCK GENERATORS

BUFFERS, CLOCK/MEMORY DRIVERS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | H | LS | s |  |
| Hex 2-Input Positive-NAND | '804 |  | A | B |  |  |  | 3 |
| Hex 2-Input Positive-NOR | 805 |  | A | B |  |  |  |  |
| Hex 2-Input Positive-AND | '808 |  | A | B |  |  |  |  |
| Hex 2-Input Positive-OR | 832 |  | A | B |  |  |  |  |
| Hex Inverter | '1004 |  | $\bullet$ | - |  |  |  |  |
| Hex Buffer | '34 |  | $\bullet$ | $\bullet$ |  |  |  |  |
|  | '1034 |  | $\bullet$ | A |  |  |  |  |
| Quad 2-Input Positive-NAND | '37 | $\bullet$ |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  |  |  | A |  |  |  |  | 3 |
|  | $\cdot 1000$ |  | A | - |  |  |  |  |
| Quad 2 -input Positive-NOR |  | $\bullet$ |  |  |  | $\bullet$ |  | 2 |
|  | '28 |  | A |  |  |  |  | 3 |
|  | ${ }^{1} 1002$ |  | A |  |  |  |  |  |
|  | $\cdot 1036$ |  |  | A |  |  |  |  |
| Ouad 2-Input Positive-AND | '1008 |  | A | - |  |  |  |  |
| Quad 2-Input Positive-OR | '1032 |  | A | - |  |  |  |  |
| Triple 3-Input Positive-NAND | - 1010 |  | A |  |  |  |  |  |
| Triple 3-Input Positive-AND | $\cdot 1011$ |  | A |  |  |  |  |  |
| Triple 4-Input AND-NAND | '800 |  |  | ム |  |  |  |  |
| Triple 4-Input OR-NOR | '802 |  |  | $\triangle$ |  |  |  |  |
| Dual 4-Input Positive-NAND | '40 | $\bullet$ |  |  | $\bullet$ | $\bullet$ | $\bullet$ | 2 |
|  |  |  | A |  |  |  |  | 3 |
|  | . 1020 |  | A |  |  |  |  |  |
| Line Driver/Memory Driver with Series Damping Resistor | '436 |  |  |  |  |  | $\bullet$ | 2 |
| Line Driver/Memory Oriver | $\cdot 437$ |  |  |  |  |  | $\bullet$ |  |

BI-/TRI-DIRECTIONAL BUS TRANSCEIVERS AND DRIVERS

| DESCRIPTION |  | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ALS | AS | LS | s |  |
| Quad with Bit Direction | 3.State | ${ }^{\prime} 446$ |  |  | - |  | 2 |
| Controls | 3-State | 449 |  |  | - |  |  |
| Quad Tridirection | OC | ${ }^{4} 440$ |  |  | $\bullet$ |  |  |
|  | OC | 441 |  |  | $\bullet$ |  |  |
|  | 3-State | ${ }^{4} 42$ |  |  | - |  |  |
|  | 3-State | 443 |  |  | - |  |  |
|  | 3-State | 444 |  |  | - |  |  |
|  | OC | '448 |  |  | $\bullet$ |  |  |
| 4-Bit with Storage | 3-State | '226 |  |  |  | $\bullet$ |  |

octal bus transceivers/mos drivers

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | sto TTL | ALS | AS | LS | s |  |
| Inverting Outputs. 3-State | $\cdot 2620$ |  |  | $\bigcirc$ |  |  | 3 |
|  | $\cdot 2640$ |  |  | $\bullet$ |  |  |  |
| True Outputs, 3-State | $\cdot 2623$ |  |  | $\bullet$ |  |  |  |
|  | $\cdot 2645$ |  |  | , |  |  |  |

octal buffers and line drivers with input/output resistors

| DESCRIPTION |  | TYPE | TECHNOLOGY |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | $s$ |  |
| Input Resistors | Inverting Outputs |  | 746 |  | - |  |  |  | 3 |
|  | Noninverting Outputs | '747 |  | - |  |  |  |  |  |
| Output Resistors | Inverting Outputs | '2540 |  | $\bullet$ |  |  |  |  |  |
|  | Noninverting Outputs | '2541 |  | - |  |  |  |  |  |

octal bi-fri-directional bus transceivers

| DESCRIPTION |  | TYPE OF OUTPUT | TYPE | technology |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | ALS |  | AS | LS |  |
| $12 \mathrm{~mA} / 24 \mathrm{~mA} .48 \mathrm{~mA} / 64 \mathrm{~mA}$ Sink. True Outputs | Low <br> Power |  | 3-State | $\cdot 245$ | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | OC | '621 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | 3-State | '623 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | OC. 3 State | '639 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | 3 State | '652 | - | - |  | 3 \& LSI |
|  |  |  |  |  |  | - | 2 |
|  |  | OC. 3-State | '654 | 4 |  |  | 3 |
|  |  |  |  |  |  | $\bullet$ | 2 |
|  | Very Low Power | OC | 1621 | 4 |  |  | 3 |
|  |  | 3 State | 1623 | A |  |  |  |
|  |  | Oc, 3 State | . 1639 | $\Delta$ |  |  |  |
| $12 \mathrm{~mA} / 24 \mathrm{~mA} / 48 \mathrm{~mA} 64 \mathrm{~mA}$ Sink, Inverting Outputs | $\begin{aligned} & \text { Low } \\ & \text { Power } \end{aligned}$ | 3. State | '620 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | OC | 622 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  |  | OC. 3-State | '638 | A | - |  | 3 |
|  |  |  |  |  |  | $\bullet$ | 2 |
|  |  | 3 State | '651 | - | - |  | 3 \& LSI |
|  |  |  |  |  |  | - | 2 |
|  |  | OC. 3-State | '653 | $\triangle$ |  |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  | Very Low Power | 3 State | $\cdot 1620$ | $\triangle$ |  |  | 3 |
|  |  | OC | ${ }^{1} 1622$ | $\wedge$ |  |  |  |
|  |  | OC, 3 State | '1638 | 4 |  |  |  |
| $12 \mathrm{~mA} .24 \mathrm{~mA} / 48 \mathrm{~mA} 64 \mathrm{~mA}$ Sink. True Outputs | Low <br> Power | OC | '641 | A | - |  |  |
|  |  |  |  |  |  | - | 2 |
|  |  | 3-State | '645 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  | Very Low Power | OC | $\cdot 1641$ | $\Delta$ |  |  | 3 |
|  |  | 3.State | . 1645 | A |  |  |  |
| $12 \mathrm{~mA}: 24 \mathrm{~mA} .48 \mathrm{~mA}: 64 \mathrm{~mA}$ Sink, Inverting Ouiputs | Low <br> Power | 3 State | 640 | A | $\bullet$ |  |  |
|  |  |  |  |  |  | - | 2 |
|  |  | OC | '642 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  | Very Low <br> Power | 3 Siate | $\cdot 1640$ | A |  |  | 3 |
|  |  | OC | $\cdot 1642$ | 4 |  |  |  |
| $12 \mathrm{~mA} / 24 \mathrm{~mA} / 48 \mathrm{~mA} 64 \mathrm{~mA}$ <br> Sink. True and <br> Inverting Outputs | Low <br> Power | 3-State | '643 | A | - |  |  |
|  |  |  |  |  |  | - | 2 |
|  |  | OC | '644 | A | - |  | 3 |
|  |  |  |  |  |  | - | 2 |
|  | Very Low Power | 3-State | . 1643 | A |  |  | 3 |
|  |  | OC | 1644 | $\pm$ |  |  |  |
| Registered with Multiplex <br> $12 \mathrm{~mA} / 24 \mathrm{~mA} / 48 \mathrm{~mA} 64 \mathrm{~mA}$ <br> True Outputs |  | 3-State | 646 | - | - |  | $3 \&$ LSI |
|  |  |  |  |  | - | 2 |  |
|  |  | OC | 647 | $\bullet$ |  |  | 3 |
|  |  |  |  |  | - | 2 |  |
| Registered with Multiplexed $12 \mathrm{~mA} / 24 \mathrm{~mA} / 48 \mathrm{~mA} / 64 \mathrm{~mA}$ Inverting Outputs |  |  | 3.Stare | '648 | - | $\bullet$ |  | 3 \& LSt |
|  |  |  |  |  |  | - | 2 |
|  |  | OC | -649 | - |  |  | 3 \& LSI |
|  |  |  |  |  |  | $\bullet$ | 2 |
| Universal Transceiveri Port Controllers |  | 3-State | '877 |  | $\bullet$ |  | 3 \& LSI |
|  |  | 852 |  | $\bullet$ |  |  |
|  |  | '856 |  | - |  |  |

- Denotes available technology.
- Denotes planned new products.

A Denotes " $A$ " suffix version available in the technology indicated.
$B$ Denotes " $B$ " suffix version available in the technology indicated.

FLIP-FLOPS

DUAL AND SINGLE FLIP-FLOPS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STO } \\ & \text { TTL } \end{aligned}$ | ALS | AS | H | L | LS | S |  |
| Dual J-K Edge-Triggered | '73 | - |  |  | $\bullet$ | $\bullet$ | A |  | 2 |
|  | '76 |  |  |  |  |  | A |  |  |
|  | '78 |  |  |  | $\bullet$ | - | A |  |  |
|  | '103 |  |  |  | - |  |  |  |  |
|  | '106 |  |  |  | $\bullet$ |  |  |  |  |
|  | $\cdot 107$ | - |  |  |  |  | A |  |  |
|  | +108 |  |  |  | $\bullet$ |  |  |  |  |
|  | $\cdot 109$ | - |  |  |  |  | A |  |  |
|  |  |  | A | - |  |  |  |  | 3 |
|  | 112 |  |  |  |  |  | A | $\bullet$ | 2 |
|  |  |  | A | 4 |  |  |  |  | 3 |
|  | - 113 |  |  |  |  |  | A | $\bullet$ | 2 |
|  |  |  | A | 4 |  |  |  |  | 3 |
|  | $\cdot 114$ |  |  |  |  |  | A | - | 2 |
|  |  |  | A | $\Delta$ |  |  |  |  | 3 |
| Single J-K Edge-Triggered | '70 | $\bullet$ |  |  |  |  |  |  | 2 |
|  | '101 |  |  |  | $\bullet$ |  |  |  |  |
|  | 102 |  |  | , | - |  |  |  |  |
| Dual Pulse-Triggered | '73 | $\bullet$ |  |  | $\bullet$ | $\bullet$ |  |  |  |
|  | '76 | $\bullet$ |  |  | $\bullet$ |  |  |  |  |
|  | '78 |  |  |  | $\bullet$ | $\bullet$ |  |  |  |
|  | '107 | $\bullet$ |  | $\pm$ |  |  |  |  |  |
| Single Puise-Triggered | '71 |  |  |  | $\bullet$ | - |  |  |  |
|  | '72 | - |  |  | $\bullet$ | $\bullet$ |  |  |  |
|  | . 104 | $\bullet$ |  |  |  |  |  |  |  |
|  | '105 | $\cdots$ |  |  |  |  |  |  |  |
| Dual J-K with Data Lockout | $\cdot 111$ | - |  |  |  |  |  |  |  |
| Single J.K with Data Lockout | - 110 | - |  |  |  |  |  |  |  |
| Dual D.Type | '74 | - |  |  | $\bullet$ | $\bullet$ | A | - |  |
|  |  |  | A | - |  |  |  |  | 3 |

QUAD AND MEX FLIP-FLOPS

| DESCRIPTION | No. OF FFs | OUTPUTS | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | S |  |
| D Type | 6 | Q | $\cdot 174$ | - |  |  | - | $\bullet$ | 2 |
|  |  |  |  |  | - | $\bullet$ |  |  | 3 |
|  |  |  | . 378 |  |  |  | - |  | 2 |
|  | 4 | Q, $\overline{0}$ | '171 |  |  |  | - |  |  |
|  |  |  | $\cdot 175$ | $\bullet$ |  |  | $\cdots$ | $\bullet$ |  |
|  |  |  |  |  | $\bullet$ | $\bullet$ |  |  | 3 |
|  |  |  | 379 |  |  |  | - |  | 2 |
| J.K | 4 | 0 | '276 | - |  |  |  |  |  |
|  |  |  | '376 | - |  |  |  |  |  |

OCTAL, 9-BIT, AND 10-BIT D-TYPE FLIP-FLOPS

| DESCRIPTION | NO. OF BITS | OUTPUT | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \hline \text { STD } \\ & T T L \end{aligned}$ | ALS | AS | LS | S |  |
| True Data | Octal | 3-State | '374 |  | - | - |  |  | 3 |
|  |  |  |  |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  |  | 3-State | . 574 |  | B | $\bullet$ |  |  | 3 |
| True Dato with Clear | Octal | 2-State | $\cdot 273$ |  | $\bullet$ |  |  |  |  |
|  |  |  |  | - |  |  | - |  | 2 |
|  |  | 3-State | '575 |  | - | - |  |  | 3 |
|  |  | 3-State | '874 |  | $\bullet$ | - |  |  |  |
|  |  | 3-State | '878 |  | - | $\bullet$ |  |  |  |
| True with Enable | Octal | 2-State | 377 |  |  |  | - |  | 2 |
| Inverting | Octal | 3-State | '534 |  | - | $\bullet$ |  |  | 3 |
|  |  | 3-State | '564 |  | A |  |  |  |  |
|  |  | 3-State | '576 |  | A | $\bullet$ |  |  |  |
| Inverting with Clear | Octal | 3-State | 577 |  | A | $\bullet$ |  |  |  |
|  |  | 3-State | 879 |  | A | - |  |  |  |
| Inverting with Preset | Octal | 3-State | '876 |  | A | - |  |  |  |
| True | Octal | 3-State | '825 |  |  | - |  |  | $3 \& \mathrm{LSI}$ |
| Inverting | Octal | 3.State | '826 |  |  | $\bullet$ |  |  |  |
| True | 9 - Bit | 3-State | '823 |  |  | - |  |  |  |
| Inverting | 9-Bit | 3-State | '824 |  |  | - |  |  |  |
| True | 10-Bit | 3-State | '821 |  |  | - |  |  |  |
| Inverting | 10-8it | 3-State | 822 |  |  | - |  |  |  |
| True | Octal | 3-State | '29825 |  | 4 |  |  |  |  |
| Inverting | Octal | 3-State | . 29826 |  | 4 |  |  |  |  |
| True | 9-Bit | 3-State | 29823 |  | 4 |  |  |  |  |
| Inverting | 9-Bit | 3-State | '29824 |  | A |  |  |  |  |
| True | 10-Bit | 3-State | '29821 |  | 4 |  |  |  |  |
| Inverting | 10-Bit | 3-State | '29822 |  | 4 |  |  |  |  |

[^2]
## FUNCTIONAL INDEX

## LATCHES AND MULTIVIBRATORS



D-TYPE
OCTAL, 9-BIT, AND 10-BIT READ-BACK LATCHES

| DESCRIPTION | $\begin{gathered} \text { NO. OF } \\ \text { BITS } \end{gathered}$ | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{array}{\|l\|} \hline \text { STD } \\ \text { TTL } \\ \hline \end{array}$ | ALS | AS | LS | S |  |
| Edge-Triggered Inverting and Noninverting | Octal | '996 |  | $\Delta$ |  |  |  | 3 \& LSI |
| Transparent True | Octal | '990 |  | - |  |  |  |  |
|  | 9-Bit | '992 |  | - |  |  |  |  |
|  | 10-Bit | '994 |  | - |  |  |  |  |
| Transparent Noninverting | Octal | '991 |  | - |  |  |  |  |
|  | 9-Bit | '992 |  | $\bullet$ |  |  |  |  |
|  | 10-Bit | '994 |  | $\bullet$ |  |  |  |  |
| Transparent with Clear True Outputs | Octal | '666 |  | - |  |  |  |  |
| Transparent with Clear Inverting Outputs | Octal | '667 |  | - |  |  |  |  |

OCTAL, 9-BIT, AND 10-BIT LATCHES

| DESCRIPTION | $\begin{gathered} \text { NO. OF } \\ \text { BITS } \end{gathered}$ | OUTPUT | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{array}{\|l\|} \hline \text { STD } \\ \mathrm{TTL} \end{array}$ | ALS | AS | LS | S |  |
| Transparent | Octal | 3-State | $\cdot 268$ |  |  |  |  | $\bullet$ | 2 |
|  |  |  | '373 |  |  |  | $\bullet$ | $\bullet$ |  |
|  |  |  |  |  | - | $\bullet$ |  |  | 3 |
|  |  | 3-State | $\cdot 573$ |  | - | $\bullet$ |  |  |  |
| Dual 4-Bit <br> Transparent | Octal | 2-State | ' 100 | - |  |  |  |  | 2 |
|  |  | 2-State | . 116 | $\bullet$ |  |  |  |  |  |
|  |  | 3-State | '873 |  | B | $\bullet$ |  |  | 3 |
| Inverting Transparent | Octal | 3-State | '533 |  | $\bullet$ | - |  |  |  |
|  |  | 3-State | '563 |  | A |  |  |  |  |
|  |  | 3-State | '580 |  | A | $\bullet$ |  |  |  |
| Dual 4-Bit <br> Inverting Transparent | Octal | 3-State | '880 |  | A | - |  |  |  |
| 2-Input Multiplexed | Octal | 3-State | '604 |  |  |  | $\bullet$ |  | 2 |
|  |  | OC | '605 |  |  |  | $\bullet$ |  |  |
|  |  | 3-State | '606 |  |  |  | $\bullet$ |  |  |
|  |  | OC | '607 |  |  |  | $\bullet$ |  |  |
| Addressable | Octal | 2.State | '259 | - |  |  | $\bullet$ |  |  |
|  |  |  |  |  | - |  |  |  | 3 |
| Multi-Mode Buffered | Octal | 3-State | '412 |  |  |  |  | - | 2 |
| True | Octal | 3-State | '845 |  | $\bullet$ | - |  |  | 3 \& LSI |
| Inverting | Octal | 3-State | '846 |  | 4 | - |  |  |  |
| True | 9-Bit | 3-State | '843 |  | $\bullet$ | $\bullet$ |  |  |  |
| Inverting | 9-Bit | 3-State | '844 |  | $\bullet$ | $\bullet$ |  |  |  |
| True | 10-Bit | 3-State | '841 |  | $\bullet$ | $\bullet$ |  |  |  |
| Inverting | 10-Bit | 3-State | '842 |  | - | $\bullet$ |  |  |  |

MONOSTABLE MULTIVIBRATORS WITH SCHMITT-TRIGGER INPUTS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \\ & \hline \end{aligned}$ | ALS | AS | LS | S | 1 |  |
| Single | '121 | - |  |  |  |  | $\bullet$ | 2 |
| Dual | $\cdot 221$ | $\bullet$ |  |  | $\bullet$ |  |  | 2 |

## - Denotes available technology.

A Denotes planned new products.
A Denotes " $A$ " suffix version available in the technology indicated.
B Denotes " $B$ " suffix version available in the technology indicated.

REGISTERS

Shift registers

| DESCRIPTION | NO. <br> OF <br> BITS | MODES |  |  |  |  | TYPE | TECHNOLOGY |  |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \dot{\alpha} \\ & \dot{s} \end{aligned}$ | $\|\vec{\omega}\|$ | $\begin{aligned} & 9 \\ & 8 \\ & 0 \end{aligned}$ |  |  |  | $\begin{aligned} & \hline \text { STo } \\ & \mathrm{THL} \end{aligned}$ | ALS | AS | L | LS | S |  |
| Sign-Protected |  | $x$ |  | $x$ | $x$ |  | 322 |  |  |  |  | A |  |  |
| Parallel-In, <br> Parallel-Out, <br> Bidirectional | 8 | $\underline{x}$ | $x$ | x | x |  | $\cdot 198$ | - |  |  |  |  |  | 2 |
|  |  | $x$ | $\times$ | $x$ | x |  | '299 |  |  |  |  | - | - |  |
|  |  |  |  |  |  |  |  | - | 4 |  |  |  | 3 |  |
|  |  | $x$ | x | $x$ | x |  |  | '323 |  |  |  |  | - |  | 2 |
|  |  |  |  |  |  |  |  |  | - | 4 |  |  |  | 3 |
|  | 4 | $x$ | x | X | X |  | '194 | - |  |  |  | A | - | 2 |
|  |  |  |  |  |  |  |  |  | 4 |  |  |  | 3 |  |
| Parallel-in, <br> Parallel-Out, <br> Registered <br> Outputs | 4 | x | x | x | x |  |  | '671 |  |  |  |  | - |  | 2 |
|  |  | $x$ | $x$ | $x$ | x |  | '672 |  |  |  |  | - |  |  |  |
| Paraliel-In, <br> Parallel-Out | 8 | x |  | x | x |  | $\cdot 199$ | - |  |  |  |  |  |  |  |
|  | 5 | x |  | x |  |  | $\cdot 96$ | - |  |  | - | - |  |  |  |
|  | 4 | x |  |  | $x$ | '95 |  | A |  |  | - | B |  | 2 |  |
|  |  |  |  |  |  |  |  |  | - |  |  |  | 3 |  |  |
|  |  | $x$ |  | $x$ |  |  |  | '99 |  |  |  | - |  |  | 2 |
|  |  | $\times$ |  | $x$ | x |  | $\cdot 178$ | - |  |  |  |  |  |  |  |
|  |  | x |  | $x$ | x |  | . 179 | - |  |  |  |  |  |  |  |
|  |  | x | $x$ |  | '195 |  |  | - |  |  |  | A | - | 2 |  |
|  |  |  |  |  |  |  | 4 |  |  |  | 3 |  |  |
|  |  | x |  | x |  |  |  |  |  | '295 |  |  |  |  | B |  | 2 |
|  |  | x | x |  |  |  | '395 |  |  |  |  | A |  | 2 |  |
|  |  |  |  |  |  |  |  | 4 |  |  |  | 3 |  |  |
| Serial-in <br> Parallel-Out | 16 | x |  | x |  |  | x |  | '673 |  |  |  |  | - |  | 2 |
|  | 8 | x |  |  |  |  | $\cdot 164$ | - |  |  | - | - |  |  |  |  |
|  |  |  |  |  |  |  |  |  | 4 |  |  |  |  | 3 |  |  |
| Parallel-In, <br> Serial-Out | 16 | x |  | x | x |  | 674 |  |  |  |  | - |  | 2 |  |  |
|  | 8 | X |  | x | x |  | '165 | - |  |  |  | A |  |  |  |  |
|  |  |  |  |  |  |  |  | 4 |  |  |  |  | 3 |  |  |  |
|  |  | x | x |  | x |  |  | '166 | $\bullet$ |  |  |  | A |  | 2 |  |
|  |  |  |  |  |  | 4 |  |  |  |  |  | 3 |  |  |  |
| Serial-In, <br> Serial-Out | 8 | x |  |  |  |  |  |  | '91 | A |  |  | - | - |  | 2 |
|  | 4 | x |  | x |  |  | '94 | - |  |  |  |  |  |  |  |  |

Shift Registers with latches

| DESCRIPTION | $\begin{gathered} \hline \text { NO. } \\ \text { OF } \\ \text { BITS } \\ \hline \end{gathered}$ | OUTPUTS | TYPE | TECHNOLOGY |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | ALS | AS | LS |  |
| Parallel-In, Parallel-Out with Output Latches | 4 | 3-State | 671 |  |  | $\bullet$ | 2 |
|  |  | 3-State | . 672 |  |  | $\bullet$ |  |
| Serial-In, Parallel-Out with Output Latches | 16 | 2-State | '673 |  |  | $\cdots$ |  |
|  | 8 | Buffered | ${ }^{5} 594$ |  |  | $\bullet$ |  |
|  |  | 3-State | '595 |  |  | $\bullet$ |  |
|  |  | OC | 596 |  |  | $\bullet$ |  |
|  |  | OC | '599 |  |  | $\bullet$ |  |
| Parallel-In, Serial-Out, with Input Latches | 8 | 2-State | '597 |  |  | $\bullet$ |  |
|  |  | 3-State | '589 |  |  | - |  |
| Parallel I/O Ports with input Latches, Multiplexed Serial Inputs | 8 | 3-State | '598 |  |  | - |  |


| SIGN-PROTECTED REGISTERS |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DESCRIPTION | NO. <br> OF <br> BITS | MODES |  |  |  | TYPE | TECHNOLOGY |  |  | VOLUME |
|  |  | $\left\|\begin{array}{l} \underset{n}{n} \\ \dot{n} \end{array}\right\|$ | $\vec{\omega}$ | ¢ | 읒 |  | ALS | AS | LS |  |
| Sign-Protected Register | 8 | $\times$ |  | $\times$ | X | '322 |  |  | A | 2 |

REGISTER FILES

| DESCRIPTION | OUTPUT | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS |  |
| 8 Words $\times 2$ Bits | 3-State | $\cdot 172$ | - |  |  |  | 2 |
| 4 Words $\times 4$ Bits | OC | . 170 | - |  |  | $\bullet$ |  |
|  | 3.State | . 670 |  |  |  | $\bullet$ |  |
| Dual 16 Words $\times 4$ Bits | 3-State | '870 |  |  | $\bullet$ |  | 3 \& LSI |
|  | 3-State | '871 |  |  | - |  |  |
| 64 Words $\times 40$ Bits | 3-State | '8834 |  |  | $\wedge$ |  | LSI |

OTHER REGISTERS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \\ & \hline \end{aligned}$ | ALS | AS | L | LS | S |  |
| Quadruple Multiplexers with Storage | '98 |  |  |  | - |  |  | 2 |
|  | '298 | - |  |  |  | - |  |  |
|  |  |  |  | $\bullet$ |  |  |  | 3 |
|  | '398 |  |  |  | - |  |  | 2 |
|  | '399 |  |  |  | - |  |  |  |
| 8-Bit Universal Shift | '299 |  |  |  |  | - | $\bullet$ |  |
| Registers |  |  | - | 4 |  |  |  | 3 |
| Quadruple Bus-Buffer Registers | '173 | - |  |  |  | A |  | 2 |
| Octal Storage Register | '396 |  |  |  |  | $\bullet$ |  |  |
| Dual-Rank 8-Bit Shift Registers | '963 |  | 4 |  |  |  |  | 3 \& LSI |
|  | '964 |  | $\triangle$ |  |  |  |  |  |
| 8-Bit Diagnostics/ Pipeline Registers | '29818 |  | 4 |  |  |  |  |  |
|  | '29819 |  | 4 |  |  |  |  |  |

## - Denotes available technology.

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## COUNTERS

1


| DESCRIPTION | PARALLEL LOAD | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \hline \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | 1 | LS | S |  |
| Decade | Set-to-9 | '90 | A |  |  | - | - |  | 2 |
|  |  | '68 |  |  |  |  | $\bullet$ |  |  |
|  | Yes | '176 | - |  |  |  |  |  |  |
|  | Yes | '196 | - |  |  |  | - | $\bullet$ |  |
|  | Set-to-9 | '290 | - |  |  |  | - |  |  |
| 4-Bit Binary | None | '93 | A |  |  | $\bullet$ | - |  |  |
|  |  | '69 |  |  |  |  | - |  |  |
|  | Yes | '177 | - |  |  |  |  |  |  |
|  | Yes | '197 | $\bullet$ |  |  |  | - | $\bullet$ |  |
|  | None | '293 | $\bullet$ |  |  |  | $\bullet$ |  |  |
| Divide by-12 | None | '92 | A |  |  |  | $\bullet$ |  |  |
| Dual Decade | None | '390 | - |  |  |  | - |  |  |
|  | Set-to-9 | ${ }^{4} 490$ | - |  |  |  | $\bullet$ |  |  |
| Dual 4-Bit Binary | None | '393 | - |  |  |  | - |  |  |

8-BIT BINARY COUNTERS WITH REGISTERS

| DESCRIPTION | TYPE OF OUTPUT | TYPE | TECHNOLOGY |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ALS | AS | LS |  |
| Parallel Register | 3-State | '590 |  |  | - | 2 |
| Outputs | OC | '591 |  |  | - |  |
| Parallel Register inputs | 2-State | 592 |  |  | $\bullet$ |  |
| Parallel I/O | 3-State | '593 |  |  | - |  |

FREQUENCY DIVIDERS, RATE MULTIPLIERS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STO } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS |  |
| 50-to. 1 Frequency Divider | '56 |  |  |  | $\bullet$ | 2 |
| 60-to-1 Frequency Divider | '57 |  |  |  | $\cdots$ |  |
| 60-Bit Binary Rate Multiplier | '97 | - |  |  |  |  |
| Decade Rate Multiplier | $\cdot 167$ | $\bullet$ |  |  |  |  |

- Denotes available technology.

A Denotes " $A$ " suffix version available in the technology indicated.
$B$ Denotes " $B$ " suffix version available in the technology indicated.

## DECODERS, ENCODERS, DATA SELECTORS/MULTIPLEXERS AND SHIFTERS

data selectors/multiplexers

| DESCRIPTION | $\square$ | TYPE | TECHNOLOGY |  |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \mathrm{STD} \\ & \mathrm{TTL} \end{aligned}$ | ALS | AS | L | LS | s |  |
| 16.to-1 | 2-State | 150 | $\bullet$ |  |  |  |  |  | 2 |
|  | 3-State | '250 |  |  | $\bullet$ |  |  |  | 3 \& LSI |
|  | 3.State | '850 |  |  | $\bullet$ |  |  |  |  |
|  | 3-State | '851 |  |  | $\bullet$ |  |  |  |  |
| Dual 8 -to. 1 | 3-State | '351 | $\bullet$ |  |  |  |  |  | 2 |
| 8-to- 1 | 2-State | '151 | A |  |  |  | $\bullet$ | $\bullet$ |  |
|  |  |  |  | - | $\bullet$ |  |  |  | 3 |
|  | 2-State | $\cdot 152$ | A |  |  |  | $\bullet$ |  | 2 |
|  | 3. State | '251 | - |  |  |  | $\bullet$ | $\bullet$ |  |
|  |  |  |  | - | 4 |  |  |  | 3 |
|  | 3-State | '354 |  |  |  |  | - |  | 2 |
|  | 2.State | '355 |  |  |  |  | - |  |  |
|  | 3-State | '356 |  |  |  |  | $\bullet$ |  |  |
|  | OC | '357 |  |  |  |  | $\bullet$ |  |  |
| Dual 4-to-1 | 2-State | '153 | $\bullet$ |  |  | - | $\bullet$ | $\bullet$ |  |
|  |  |  |  | - | $\bullet$ |  |  |  | 3 |
|  | 3-State | '253 |  |  |  |  | - | $\bullet$ | 2 |
|  |  |  |  | - | - |  |  |  | 3 |
|  | 2. State | '352 |  |  |  |  | $\bullet$ |  | 2 |
|  |  |  |  | - | - |  |  |  | 3 |
|  | 3-State | '353 |  |  |  |  | $\bullet$ |  | 2 |
|  |  |  |  | $\bullet$ | $\bullet$ |  |  |  | 3 |
| Octal 2 to- 1 with Storage | 3.State | ${ }^{6} 604$ |  |  |  |  | $\bullet$ |  | 2 |
|  | OC | '605 |  |  |  |  | $\bullet$ |  |  |
|  | 3.State | '606 |  |  |  |  | $\bullet$ |  |  |
|  | OC | 607 |  |  |  |  | $\bullet$ |  |  |
| Quad 2-to-1 with Storage | 2. State | '98 |  |  |  | $\bullet$ |  |  |  |
|  | 2-State | - 298 | - |  |  |  | $\bullet$ |  | 2 |
|  |  |  |  |  | $\bullet$ |  |  |  | 3 |
|  | 2. State | . 398 |  |  |  |  | $\bullet$ |  | 2 |
|  | 2. State | '399 |  |  |  |  | $\bullet$ |  |  |
| Quad 2-to-1 | 2-State | '157 | $\bullet$ |  |  | $\bigcirc$ | - | $\bullet$ |  |
|  |  |  |  | - | $\bullet$ |  |  |  | 3 |
|  | 2.State | '158 |  |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  |  |  |  | $\bullet$ | - |  |  |  | 3 |
|  | 3-State | '257 |  |  |  |  | B | - | 2 |
|  |  |  |  | A | - |  |  |  | 3 |
|  | 3-State | '258 |  |  |  |  | B | $\bullet$ | 2 |
|  |  |  |  | A | - |  |  |  | 3 |
| 6-to-1 Universal Multiplexer | 3-State | '857 |  | $\bullet$ | $\bullet$ |  |  |  | 3 |

DECODERS/DEMULTIPLEXERS

| DESCRIPTION | TYPE OF OUTPUT | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | L | LS | S |  |
| 4-to-16 | 3-State | '154 | $\bullet$ |  |  | - |  |  | 2 |
|  | OC | . 159 | $\bullet$ |  |  |  |  |  |  |
| 4-to-10 BCD-to-Decimal | 2-State | '42 | A |  |  | - | - |  |  |
| $\begin{aligned} & \text { 4-to-10 Excess } 3 \text {-to- } \\ & \text { Decimal } \end{aligned}$ | 2-State | '43 | A |  |  | - |  |  |  |
| $\begin{aligned} & \text { 4-to-10 Excess 3-Gray- } \\ & \text { to-Decimal } \end{aligned}$ | 2-State | '44 | A |  |  | - |  |  |  |
| 3-to-8 with Address Latches | 2-State | '131 |  | - | 4 |  |  |  | 3 |
|  |  | $\cdot 137$ |  | $\bullet$ | A |  |  |  |  |
|  |  |  |  |  |  |  | - |  | 2 |
| 3-to-8 | 2-State | '138 |  | - | $\triangle$ |  |  |  | 3 |
|  |  |  |  |  |  |  | $\bullet$ | $\bullet$ | 2 |
|  | 3-State | '538 |  | A |  |  |  |  | 3 |
| Dual 2-to-4 | 2-State | '139 |  | 4 | $\bullet$ |  |  |  |  |
|  |  |  |  |  |  |  | A | $\bullet$ | 2 |
|  | 2-State | 155 | - |  |  |  | A |  |  |
|  | OC | '156 | - |  |  |  | - |  |  |
| Dual 1-to-4 Decoders | 3-State | '539 |  | 4 |  |  |  |  | 3 |

CODE CONVERTERS

| DESCRIPTION | TYPE | TECHNOLOGY | TELUME <br> STD <br> TTL | S |
| :--- | :---: | :---: | :---: | :---: |

PRIORITY ENCODERS/REGISTERS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \\ & \hline \end{aligned}$ | ALS | AS | LS |  |
| Full BCD | 147 | - |  |  | - | 2 |
| Cascadable Octal | '148 | - |  |  | $\bullet$ |  |
| Cascadable Octal with 3-State Outputs | 348 |  |  |  | $\bullet$ |  |
| 4-Bit Cascadable with Registers | '278 | - |  |  |  |  |

SHIFTERS

| DESCRIPTION | OUTPUT | TYPE | TECHNOLOGY |  |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | L | LS | S |  |
| 4 - Bit Shifter | 3. State | '350 |  |  |  |  |  | - | 2 |
| Parallel 16-Bit Multi-Mode Barrel Shifter | 3-State | '897 |  |  | - |  |  |  | LSı |
| 32-Bit Barrel Shifter | 3-State | '8838 |  |  | $\triangle$ |  |  |  |  |

- Denotes available technology.

A Denotes planned new products.
A Denotes "A" suffix version available in the technology indicated.
$B$ Denotes " $B$ " suffix version available in the technology indicated.

## DISPLAY DECODERS/DRIVERS, MEMORY/MICROPROCESSOR CONTROLLERS, AND VOLTAGE-CONTROLLED OSCILLATORS

OPEN-COLLECTOR DISPLAY DECODERS/DRIVERS
ио!ңешлодиן ןesәuәэ >

| DESCRIPTION | OFF-STATE OUTPUT VOLTAGE | TYPE | TECHNOLOGY |  |  |  |  | VOLume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{array}{\|l} \hline \text { STD } \\ \mathrm{TIL} \end{array}$ | ALS | AS | L | Ls |  |
| BCD-to-Decimal | 30 V | 45 | $\bullet$ |  |  |  |  | 2 |
|  | 60 V | 141 | - |  |  |  |  |  |
|  | 15 V | 145 | $\bullet$ |  |  |  | - |  |
|  | 7 V | $\cdot 445$ |  |  |  |  | $\bullet$ |  |
| BCD-to-Seven-Segment | 30 V | '46 | A |  |  | - |  |  |
|  | 15 V | 47 | A |  |  | $\bullet$ | $\bullet$ |  |
|  | 5.5 V | '48 | - |  |  |  | - |  |
|  | 5.5 V | '49 | - |  |  |  | $\bullet$ |  |
|  | 30 V | '246 | $\bullet$ |  |  |  |  |  |
|  | 15 V | '247 | $\bullet$ |  |  |  | $\bullet$ |  |
|  | 7 V | '347 |  |  |  |  | $\bullet$ |  |
|  | 7 V | ${ }^{4} 47$ |  |  |  |  | - |  |
|  | 5.5 V | . 248 | $\bullet$ |  |  |  | $\bullet$ |  |
|  | 5.5 V | 249 | - |  |  |  | $\bullet$ |  |

OPEN COLLECTOR DISPLAY DECODERS/DRIVERS WITH COUNTERS/LATCH

| DESCRIPTION | TYPE | TECHNOLOGY |  | STD <br> TTL | ALS |
| :--- | :---: | :---: | :---: | :---: | :---: | AS | VOLUME |
| :---: |
| BCD Counter/4-Bit Latch/BCD-to-Decimal <br> Decoder/Driver |
| BCD Counter/4-Bit <br> Latch/BCD-to-Seven-Segment <br> Decoder/LED Driver |
| BCD Counter/4-Bit <br> Latch/BCD-to-Seven-Segment <br> Decoder/Lamp Driver |

VOLTAGE-CONTROLLED OSCILLATORS

| DESCRIPTION |  |  |  |  |  | TYPE | TECHNOLOGY |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| No. VCOs | $\begin{gathered} \text { COMP'L } \\ Z_{\text {OUT }} \\ \hline \end{gathered}$ | ENABLE | RANGE INPUT | $R_{\text {ext }}$ | $\begin{aligned} & f_{\text {max }} \\ & M H z \end{aligned}$ |  | LS | S |  |
| Single | Yes | Yes | Yes | No | 20 | '624 | - |  | 2 |
| Single | Yes | Yes | Yes | Yes | 20 | '628 | - |  |  |
| Dual | No | Yes | . Yes | No | 60 | '124 |  | - |  |
| Dual | Yes | Yes | No | No | 20 | '626 | - |  |  |
| Dual | No | No | No | No | 20 | '627 | $\bullet$ |  |  |
| Dual | No | Yes | Yes | No | 20 | 629 | - |  |  |

MEMORY/MICROPROCESSOR CONTROLLERS

| DESCRIPTION |  |  | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ALS | AS | LS | 5 |  |
| System Controllers IUniversal or for '8881 |  |  |  | '890 |  | $\bullet$ |  |  | LSI |
| Memory <br> Refresh <br> Controllers | Transparent, | 4K. 16 K | 600 |  |  | A |  | 2 |
|  | Burst Modes | 64 K | '601 |  |  | A |  |  |
|  | Cycle Steal, | 4K, 16K | '602 |  |  | A |  |  |
|  | Burst Modes | 64 K | 603 |  |  | A |  |  |
| Memory Cycle Controller |  |  | 608 |  |  | $\bullet$ |  |  |
| Memory Mappers |  | 3-State | 612 |  |  | - |  | LSI |
|  |  | OC | 613 |  |  | $\bullet$ |  |  |
| Memory Mappers with Output Latches |  | 3-State | 610 |  |  | $\bullet$ |  |  |
|  |  | OC | 611 |  |  | $\bullet$ |  |  |
| Multi-Mode Latches (8080 A Applications) |  |  | 412 |  |  |  | $\bullet$ | 2 |
| Dynamic Memory Controllers |  | 16K. 64 K. | 2967 | 4 |  |  |  | LSI |
|  |  | 256K | 2968 | 4 |  |  |  |  |
|  |  | $\begin{aligned} & 16 \mathrm{~K}, 64 \mathrm{~K} \\ & 256 \mathrm{~K}, 1 \mathrm{MEG} \end{aligned}$ | 6301 | $\triangle$ |  |  |  |  |
|  |  | '6302 | A |  |  |  |  |

CLOCK GENERATOR CIRCUITS

| DESCRIPTION | TYPE | technology |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \\ & \hline \end{aligned}$ | ALS | AS | LS | s |  |
| Quadruple Complementary-Output Logic Elements | '265 | - |  |  |  |  | 2 |
| Dual Pulse Synchronizers/Drivers | 120 | $\bullet$ |  |  |  |  |  |
| Crystal Controlled Oscillators | 320 |  |  |  | $\bullet$ |  |  |
|  | 321 |  |  |  | - |  |  |
| Digital Phase-Lock Loop | 297 |  |  |  | - |  |  |
| Programmable Frequency | 292 |  |  |  | - |  |  |
| Dividers/Digital Timers | 294 |  |  |  | $\bullet$ |  |  |
| Triple 4-Input AND/NAND Drivers | '800 |  |  | 4 |  |  | 3 |
| Triple 4-Input OR/NOR Drivers | 802 |  |  | 4 |  |  |  |
| Dual VCO | $\cdot 124$ |  |  |  |  | $\bullet$ | 2 |

RESULTANT DISPLAYS USING ‘46A, '47A, '48, '49, 'L46, 'L47, 'LS47, 'LS48, 'LS49, 'LS347


RESULTANT DISPLAYS USING '246, '247, '248, '249, 'LS247, 'LS248, 'LS249, 'LS447


- Denotes available technology.

ADenotes planned new products
A Denotes " $A$ " suffix version available in the technology indicated.

## COMPARATORS AND ERROR DETECTION CIRCUITS

4-BIT COMPARATORS

| DESCRIPTION |  |  |  |  | TYPE | TECHNOLOGY |  |  |  |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| P-O | P>0 | $p<0$ | output | output enable |  | $\begin{aligned} & \hline \text { STO } \\ & \mathrm{TIL} \end{aligned}$ | ALS | AS | L | LS | $s$ |  |
| Yes | Yes | No | 2.State | No | '85 | - |  |  | - | - | - | 2 |

8-BIT COMPARATORS

| DESCRIPTION |  |  |  |  |  |  |  | TYPE | TECHNOLOGY |  |  | volume |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUTS | P=O | $\overline{\mathrm{P}=0}$ | $P>0$ | $\overline{P>0}$ | P<0 | OUTPUT | OUTPUT <br> ENABLE |  | ALS | AS | LS |  |
| $\begin{aligned} & 20 \mathrm{k} \Omega \\ & \text { Pull Up } \end{aligned}$ | Yes | No | No | No | No | OC | Yes | 518 | - |  |  | 3 |
|  | No | Yes | No | No | No | 2-S | Yes | . 520 | - |  |  |  |
|  | No | Yes | No | No | No | OC | Yes | 522 | $\bullet$ |  |  |  |
|  | No | Yes | No | Yes | No | 2-S | No | 682 |  |  | - | 2 |
|  | No | Yes | No | Yes | No | OC | No | 683 |  |  | $\bullet$ |  |
| Standard | Yes | No | No | No | No | OC | Yes | '519 | - |  |  | 3 |
|  | No | Yes | No | No | No | 2-S | Yes | '521 | - |  |  |  |
|  | No | Yes | No | Yes | No | 2.5 | No | '684 |  |  | $\bullet$ | 2 |
|  | No | Yes | No | Yes | No | OC | No | 685 |  |  | $\bullet$ |  |
|  | No | Yes | No | Yes | No | 2-S | Yes | ${ }^{686}$ |  |  | $\bullet$ |  |
|  | No | Yes | No | Yes | No | OC | Yes | '687 |  |  | $\bullet$ |  |
|  | No | Yes | No | No | No | 2.5 | Yes | '688 | $\bullet$ |  |  | 3 |
|  | No | Yes | No | No | No | $2 \cdot 5$ | Yes | 688 |  |  | - | 2 |
|  |  |  |  |  |  |  |  |  | - |  |  | 3 |
|  | No | Yes | No | No | No | OC | Yes | '689 |  |  | - | 2 |
| Latched P Logic \& Arith | No | No | Yes | No | Yes | 2.S | Yes | 885 |  | $\bullet$ |  | 3 \& LSI |
| Latched P\&O Logic \& Arith | Yes | No | Yes | No | Yes | Latched | Yes | '866 |  | $\bullet$ |  | 3 |

address comparators

| DESCRIPTION | OUTPUT ENABLE | LATCHED OUTPUT | TYPE | TECHNOLOGY |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | ALS | AS |  |
| 16-Bit to 4-Bit | Yes |  | $\cdot 677$ | $\bullet$ |  | 3 |
|  |  | Yes | '678 | - |  |  |
| 12-Bit to 4-Bit | Yes |  | ${ }^{6} 679$ | $\bullet$ |  |  |
|  |  | Yes | '680 | - |  |  |

PARITY GENERATORS/CHECKERS, ERROR DETECTION AND CORRECTION CIRCUITS

| DESCRIPTION |  | NO. OF BITS | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|l\|} \hline \text { STD } \\ \hline \text { TTL } \\ \hline \end{array}$ |  | ALS | AS | ts | S |  |
| Odd/Even Parity Generators/Checkers |  |  | 8 | '180 | $\bullet$ |  |  |  |  | 2 |
|  |  | 9 | '280 |  |  |  | $\cdots$ | $\bullet$ |  |  |
|  |  |  |  | $\bullet$ | $\bullet$ |  |  | $3 \& 4 \mathrm{LI}$ |  |  |
|  |  | 9 | '286 |  |  | - |  |  |  |  |
|  | 3-State |  | 8 | '636 |  |  |  | $\bullet$ |  | 2 |
|  | OC | 8 | '637 |  |  |  | $\bullet$. |  |  |  |
|  | 3-State | 16 | '616 |  | - |  |  |  | 3 \& LSI |  |
|  | OC | 16 | '617 |  | A |  |  |  |  |  |
| Paraliel Error <br> Detection/Correction Circuits | 3-State | 16 | '630 |  |  |  | $\bullet$ |  | 2 |  |
|  | OC | 16 | '631 |  |  |  | $\bullet$ |  |  |  |
|  | 3-State | 16 | '8400 |  | 4 |  |  |  | LSI |  |
|  | 3-State | 32 | '632 |  | A | A |  |  | 3 \& LSI |  |
|  | OC | 32 | '633 |  | - | $\Delta$ |  |  |  |  |
|  | 3-State | 32 | '634 |  | $\Delta$ | A |  |  |  |  |
|  | OC | 32 | 635 |  | 4 | 4 |  |  |  |  |

FUSE-PROGRAMMABLE COMPARATORS

| DESCRIPTION | VOLUME | TECHNOLOGY |  |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | STD <br> TTL | ALS | AS | LS | S |  |
| 16-Bit Identity Comparator |  |  | $\bullet$ |  |  |  |  |
| 12-Bit identity Comparator |  |  | $\bullet$ |  |  |  | 3 |
| 8-Bit Identity Comparator <br> and 4-Bit Comparator | 527 |  | $\bullet$ |  |  |  |  |

- Denotes available technology.

ADenotes planned new products.
A Denotes " $A$ " suffix version available in the technology indicated.

## ARITHMETIC CIRCUITS AND PROCESSOR ELEMENTS

## 1.

parallel binary adders

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { STD } \\ & \mathrm{TIL} \end{aligned}$ | ALS | AS | H | LS | S |  |
| 1-Bit Gated | '80 | - |  |  |  |  |  | 2 |
| 2.Bit | '82 | - |  |  |  |  |  |  |
| 4-Bit | '83 | A |  |  |  | A |  |  |
|  | '283 | - |  |  |  | - | $\bullet$ |  |
| Dual 1-Bit Carry-Save | 183 |  |  |  | - | $\bullet$ |  |  |

ACCUMULATORS. ARITHMETIC LOGIC UNITS, LOOK-AHEAD CARRY GENERATORS

| DESCRIPTION |  | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \hline \text { STO } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | S |  |
| 4.Bit Parallel Binary Accumulators |  |  | 281 |  |  |  |  | - | 2 |
|  |  | 681 |  |  |  | - |  |  |  |
| 4 Bit Arithmetic Logic Units Function Generators |  | 181 | - |  |  | $\bullet$ | $\bullet$ |  |  |
|  |  | 181 |  |  | A |  |  |  |  |
|  |  | '1181 |  |  | - |  |  | 3 \& LSt |  |
|  |  | 381 |  |  |  | A |  | 2 |  |
|  |  |  |  |  |  |  | $\bullet$ | 2 |  |
|  |  | '881 |  |  | A |  |  | 3 \& LSI |  |
| 4 Bit Arithmetic Logic Unit <br> with Ripple Carry |  | 382 |  |  |  | - |  | 2 |  |
| Look. Ahead Carry <br> Generators | 16 BIt | 182 | $\bullet$ |  |  |  | - | 2 |  |
|  |  |  |  |  | $\Delta$ |  |  | 3 |  |
|  |  | 282 |  |  | 4 |  |  |  |  |
|  | 32 Bit | 882 |  |  | A |  |  | $3 \& \mathrm{LSI}$ |  |
| Quad Serial Adder'Subtractor |  | 385 |  |  |  | $\bullet$ |  | 2 |  |

MULTIPLIERS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|l} \hline \text { STD } \\ \text { TTL } \\ \hline \end{array}$ | ALS | AS | LS | S |  |
| 2-Bit-by-4-Bit Parallel Binary Muttipliers | '261 |  |  |  | - |  | 2 |
| 4-Bit-by-4-Bit Parallel Binary Multipliers | '284 | - |  |  |  |  |  |
|  | '285 | - |  |  |  |  |  |
| 25-MHz 6. Bit Binary Rate Multipliers | '97 | $\bullet$ |  |  |  |  |  |
| $25-\mathrm{MHz}$ Decade Rate Multipliers | '167 | $\bullet$ |  |  |  |  |  |
| 8 -Bit $\times 1$ - - ${ }^{\text {a }}$ 2's Complement Multipliers | '384 |  |  |  | - |  |  |

OTHER ARITHMETIC OPERATORS

| DESCRIPTION | TYPE | TECHNOLOGY |  |  |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \mathrm{STD} \\ & \mathrm{TTL} \end{aligned}$ | ALS | AS | H | L | LS | S |  |
| Quad 2 Input Exclusive OR | '86 | - |  |  |  | - | A | - | 2 |
| Gates with Totem-Pole |  |  | $\bullet$ |  |  |  |  |  | 3 |
| Outputs | $\cdot 386$ |  |  |  |  |  | A |  | 2 |
| Quad 2-Input Exclusive-OR Gates with Open Collector | '136 | - |  |  |  |  |  | $\bullet$ |  |
| Outputs |  |  | - |  |  |  |  |  | 3 |
| Quad 2.Input ExclusiveNOR Gates | '266 |  |  |  |  |  | - |  | 2 |
|  | '810 |  | - | A |  |  |  |  | 3 |
| Quad 2-Input Exclusive NOR Gates with Open Collector Outputs | '811 |  | - | 4 |  |  |  |  | 3 |
| Quad Exclusive OR'NOR Gates | '135 |  |  |  |  |  |  | - | 2 |
| 4 Bit True/Complement Element | '87 |  |  |  | $\bullet$ |  |  |  |  |

BIPOLAR BIT-SLICE PROCESSOR ELEMENTS

| DESCRIPTION | $\begin{gathered} \text { CASCADABLE } \\ \text { TO } \\ \text { N-BITS } \end{gathered}$ | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ALS | AS | LS | S |  |
| 8-Bit Slice | No | 887 |  | - |  |  | LSI |
|  | Yes | '888 |  | - |  |  |  |
|  | Yes | '895 |  | 4 |  |  |  |

[^3]ADenotes planned new products.
A Denotes " $A$ " suffix version available in the technology indicated.

## MEMORIES

| STANDARD PROMs |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DESCRIPTION | TYPE | ORGANIZATION ${ }^{+}$ | TYPE OUTPUT | S | VOLUME |
| 16K-Bit Arrays | TBP28S 166 <br> TBP38S165 <br> TBP38S166 <br> TBP38SA165 <br> TBP38SA166 <br> TBP34S162 <br> TBP34SA162 | $\begin{aligned} & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 2048 \mathrm{~W} \times 8 B \\ & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 4096 \mathrm{~W} \times 4 \mathrm{~B} \\ & 4096 \mathrm{~W} \times 4 \mathrm{~B} \end{aligned}$ | 3-State <br> 3-State <br> 3.State <br> OC <br> OC <br> 3.State <br> OC |  |  |
| 8K-Bit Arrays | TBP24S81 <br> TBP24SA81 <br> TBP28S85A <br> TBP28S86A <br> TBP28SA86A <br> TBP38S85 <br> TBP38S86 <br> TBP38SA85 <br> TBP38SA86 | $\begin{aligned} & 2048 \mathrm{~W} \times 4 \mathrm{~B} \\ & 2048 \mathrm{~W} \times 4 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 88 \\ & 1024 \mathrm{~W} \times 8 B \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \end{aligned}$ | 3-State <br> OC <br> 3-State <br> 3-State <br> OC <br> 3-State <br> 3.State <br> OC <br> OC |  | 4 |
| 4K-Bit Arrays | TBP24S41 <br> TBP24SA41 <br> TBP28S42 <br> TBP28SA42 <br> TBP28S46 <br> TBP28SA46 | $\begin{array}{r} 1024 \mathrm{~W} \times 4 \mathrm{~B} \\ 1024 \mathrm{~W} \times 4 \mathrm{~B} \\ 512 \mathrm{~W} \times 8 \mathrm{~B} \\ 512 \mathrm{~W} \times 8 \mathrm{~B} \\ 512 \mathrm{~W} \times 8 \mathrm{~B} \\ 512 \mathrm{~W} \times 8 \mathrm{~B} \\ \hline \end{array}$ | 3-State OC 3.State OC 3-State OC |  |  |
| 2K-Bit Arrays | $\begin{aligned} & \text { TBP38S22 } \\ & \text { TBP38SA22 } \end{aligned}$ | $\begin{array}{r} 256 \mathrm{~W} \times 8 \mathrm{~B} \\ 256 \mathrm{~W} \times 8 \mathrm{~B} \\ \hline \end{array}$ | 3.State <br> OC | $\bullet$ |  |
| 1K-Bit Arrays | TBP24S10 <br> TBP24SA10 <br> TEP34S10 <br> TBP34SA10 | $\begin{aligned} & 256 \mathrm{~W} \times 4 \mathrm{~B} \\ & 256 \mathrm{~W} \times 4 \mathrm{~B} \\ & 256 \mathrm{~W} \times 4 \mathrm{~B} \\ & 256 \mathrm{~W} \times 4 \mathrm{~B} \end{aligned}$ | 3-State <br> OC 3.State OC |  |  |
| 256-Bit Arrays | TBP18S030 <br> TBP18SA030 <br> TBP38S030 <br> TBP38SA030 | $\begin{aligned} & \hline 32 W \times 8 B \\ & 32 W \times 8 B \\ & 32 W \times 8 B \\ & 32 W \times 8 B \end{aligned}$ | 3-State <br> OC <br> 3.State OC |  |  |
| LOW-POWER PROMs |  |  |  |  |  |
| DESCRIPTION | TYPE | ORGANIZATION | TYPE OUTPUT | S | VOLUME |
| 16K-Bit Arrays | TBP28L166 <br> TBP38L165 <br> TBP38L 166 <br> TBP34L162 | $\begin{aligned} & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 2048 \mathrm{~W} \times 88 \\ & 2048 \mathrm{~W} \times 8 \mathrm{~B} \\ & 4096 \mathrm{~W} \times 4 \mathrm{~B} \end{aligned}$ | 3-State <br> 3-State <br> 3-State <br> 3-State |  | 4 |
| 8K-Bit Arrays | TBP28L85A <br> TBP28L86A <br> TBP38L85 <br> TBP38L86 | $\begin{aligned} & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \\ & 1024 \mathrm{~W} \times 8 \mathrm{~B} \end{aligned}$ | 3-State <br> 3-State <br> 3-State <br> 3-State | $\begin{aligned} & \mathbf{4} \\ & \mathbf{4} \\ & \mathbf{4} \\ & \hline \end{aligned}$ |  |
| 4K-Bit Arrays | TBP28L42 <br> TBP28L46 | $\begin{aligned} & 512 \mathrm{~W} \times 8 \mathrm{~B} \\ & 512 \mathrm{~W} \times 8 \mathrm{~B} \end{aligned}$ | 3.State <br> 3-State | $\bullet$ |  |
| 2K-Bit Arrays | TBP28L22 <br> TBP28LA22 <br> TBP38L22 | $\begin{aligned} & 256 \mathrm{~W} \times 8 \mathrm{~B} \\ & 256 \mathrm{~W} \times 8 \mathrm{~B} \\ & 256 \mathrm{~W} \times 8 \mathrm{~B} \end{aligned}$ | 3-State OC 3-State |  |  |
| 1K-Bit Arrays | TBP34L10 | $256 \mathrm{~W} \times 4 \mathrm{~B}$ | 3-State | $\bullet$ |  |
| 256-Bit Arrays | TBP38L030 | $32 \mathrm{~W} \times 88$ | 3-State | $\pm$ |  |


| DESCRIPTION | TYPE | ORGANIZATION | TYPE <br> OUTPUT | $\mathbf{S}$ | VOLUME |
| :--- | :--- | :---: | :---: | :---: | :---: |
| 16K-BIt Arrays | TBP34R162 | $4096 \mathrm{~W} \times 4 \mathrm{~B}$ | 3 State | $\bullet$ |  |
|  | TBP34SR165 | $4096 \mathrm{~W} \times 4 \mathrm{~B}$ | 3 State | $\Delta$ | 4 |
|  | TBP38R165 | $2048 \mathrm{~W} \times 8 \mathrm{~B}$ | 3 State | $\bullet$ |  |

RANDOM-ACCESS READ-WRITE MEMORIES (RAMS)

| DESCRIPTION | Organization |  | TYPE | TECHNOLOGY |  |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \text { STD } \\ & \text { TTL } \end{aligned}$ | ALS | AS | LS | S |  |
| 256-Bit Arrays | $256 \times 1$ | 3-State | 201 |  |  |  |  | - | 4 |
|  |  | OC | '301 |  |  |  |  | $\bullet$ |  |
| 64-Bit Arrays | $16 \times 4$ | OC | 89 | - |  |  |  |  |  |
|  |  | 3-State | '189 |  |  |  | A | B |  |
|  |  | 3-State | '219 |  |  |  | A |  |  |
|  |  | OC | 289 |  |  |  | A | 8 |  |
|  |  | OC | '319 |  |  |  | A |  |  |
| 16-Bit Multiple-Port <br> Register File | $8 \times 2$ | 3-State | 172 | - |  |  |  |  | 2 |
| 16-Bit Register Fite | $4 \times 4$ | OC | 170 | - |  |  | $\bullet$ |  |  |
|  |  | 3 State | 670 |  |  |  | - |  |  |
| Dual 64-Bit <br> Register Files | $16 \times 4$ | 3-State | 870 |  |  | - |  |  | 3 |
|  |  |  | 871 |  |  | - |  |  |  |

FIRST-IN FIRST-OUT MEMORIES (FIFOS)

| description | $\begin{gathered} \text { TYPE } \\ \text { OF } \\ \text { OUYPUT } \end{gathered}$ | TYPE | TECHNOLOGY |  |  |  | VOLUME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ALS | AS | is | s |  |
| $16 \times 4$ | 3 State | 222 |  |  | - |  | LSI |
|  | 3.State | 224 |  |  | - |  |  |
|  | 3-State | 227 |  |  | - |  |  |
|  | 3 State | 228 |  |  | - |  |  |
|  | 3-State | 232 | A |  |  |  | 3 \& LSI |
| $16 \times 5$ | 3 State | 225 |  |  | $\bullet$ | - | LSt |
|  | 3 State | 229. | A |  |  |  | $3 \& \mathrm{LSI}$ |
|  | 3 State | 233 | A |  |  |  |  |



- PAL is a registered trademark of Monolithic Memories Incorporated.
- Denotes available. technology.

ADenotes planned new products.

## General Information

Numerical Index
Glossary
Explanation of Function Tables
Parameter Measurement Information
Functional Index

## LSI Devices

## Application Reports

Advanced Schottky Family
Error Detection and Correction
Memory Mapping
Bit-Slice Processor 8-Bit Family Excerpt - SN74AS888, SN74AS890 Bit-Slice Processor User's Guide

Mechanical Data

| $\Gamma$ |
| :--- |
| $\bullet$ |
| 0 |
| 0 |
| 0 |
| $\vdots$ |
| 0 |
| 0 |

- Package Options Include the 'AS181A in Compact 300 -mil or Standard 600-mil DIPs. The 'AS881A is Offered in 300-mil DIPS. Both Devices are Available in Both Plastic and Ceramic Chip Carriers
- Full Look-Ahead for High-Speed Operations on Long Words
- Arithmetic Operating Modes:

Addition
Subtraction
Shift Operand A One Position
Magnitude Comparison
Plus Twelve Other Arithmetic Operations

- Logic Function Modes

Exclusive-OR
Comparator
AND, NAND, OR, NOR
'AS881A Provides Status Register Checks Plus Ten Other Logic Operations

- Dependable Texas Instruments Quality and Reliability
logic symbol


Pin numbers shown are JT, JW, NT, and NW packages.

SN54AS181A . . . JT OR JW PACKAGE SN54AS881A . . . JT PACKAGE
SN74AS181A . . . NT OR NW PACKAGE SN74AS881A . . . NT PACKAGE (TOP VIEW)

| B 01 | $1 \bigcup_{24}$ | $]^{1} \mathrm{VCC}$ |
| :---: | :---: | :---: |
| $\overline{\mathrm{A}} \bigcirc \square 2$ | 233 | $\square \bar{A} 1$ |
| S3 $\square 3$ | 322 | B 1 |
| S2 $\square 4$ | 21 | $\overline{\mathrm{A}} 2$ |
| S $1 \square 5$ | 20 | $\overline{\mathrm{B}} 2$ |
| So $\square 6$ | 19 | Ā3 |
| $\mathrm{C}_{\mathrm{n}}-7$ | 18 | B3 |
| M - 8 | 17 | $\overline{\mathrm{G}}$ |
| $\vec{F} 0 \square 9$ | 16 | $\square c_{n+4}$ |
| F1 10 | 015 | $\bar{P}$ |
| $\overline{\mathrm{F}} 2 \square 11$ | 14 | $A=B$ |
| GND 12 | 213 | F3 |

SN54AS181A, SN54AS881A . . . FK PACKAGE SN74AS181A, SN74AS881A . . . FN PACKAGE (TOP VIEW)


NC-No internal connection

TYPICAL ADDITION TIMES ( $C_{L}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=280 \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| NUMBER OF BITS | ADDITION TIMES |  |  | PACKAGE COUNT |  | CARRY METHOD BETWEEN ALUs |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | USING 'AS881A AND'AS882 | $\begin{gathered} \text { USING 'AS181A } \\ \text { AND 'AS882 } \end{gathered}$ | USING 'S181 AND 'S182 | ARITHMETIC LOGIC UNITS | LOOK-AHEAD CARRY GENERATORS |  |
| 1 to 4 | 5 ns | 5 ns | 11 ns | 1 |  | NONE |
| 5 to 8 | 10 ns | 10 ns | 18 ns | 2 |  | RIPPLE |
| 9 to 16 | 14 ns | 14 ns | 19 ns | 3 or 4 | 1 | FULL LOOK-AHEAD |
| 17 to 64 | 19 ns | 19 ns | 28 ns | 5 to 16 | 2 to 5 | FULL LOOK-AHEAD |

## SN54AS181A, SN54AS881A, SN74AS181A, SN74AS881A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

## description

The 'AS181A and 'AS881A are arithmetic logic units (ALU)/function generators that have a complexity of 75 and 77 equivalent gates, respectively, on a monolithic chip. These circuits perform 16 binary arithmetic operations on two 4-bit words as shown in Tables 1 and 2. These operations are selected by the four function-select lines (S0, S1, S2, S3) and include addition, subtraction, decrement, and straight transfer. When performing arithmetic manipulations, the internal carries must be enabled by applying a low-level voltage to the mode control input (M). A full carry look-ahead scheme is made available in these devices for fast, simultaneous carry generation by means of two cascade-outputs (pins 15 and 17) for the four bits in the package. When used in conjunction with the SN54AS882 or SN74AS882 full carry look-ahead circuits, high-speed arithmetic operations can be performed. The typical addition times shown previously illustrate the little additional time required for addition of longer words when full carry look-ahead is employed. The method of cascading 'AS882 circuits with these ALUs to provide multilevel full carry lookahead is illustrated under signal designations.

If high speed is not of importance, a ripple-carry input ( $C_{n}$ ) and a ripple-carry output ( $C_{n}+4$ ) are available. However, the ripple-carry delay has also been minimized so that arithmetic manipulations for small word lengths can be performed without external circuitry.

The 'AS181A and 'AS881A will accommodate active-high or active-low data if the pin designations are interpreted as follows:

| PIN NUMBER | $\mathbf{2}$ | $\mathbf{1}$ | $\mathbf{2 3}$ | $\mathbf{2 2}$ | $\mathbf{2 1}$ | $\mathbf{2 0}$ | $\mathbf{1 9}$ | $\mathbf{1 8}$ | $\mathbf{9}$ | $\mathbf{1 0}$ | $\mathbf{1 1}$ | $\mathbf{1 3}$ | $\mathbf{7}$ | $\mathbf{1 6}$ | $\mathbf{1 5}$ | $\mathbf{1 7}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Active-low data (Table 1) | $\overline{\mathrm{A} O}$ | $\overline{\mathrm{~B}} 0$ | $\overline{\mathrm{~A}} 1$ | $\overline{\mathrm{~B}} 1$ | $\overline{\mathrm{~A}} 2$ | $\overline{\mathrm{~B}} 2$ | $\overline{\mathrm{~A}} 3$ | $\overline{\mathrm{~B}} 3$ | $\overline{\mathrm{~F}} 0$ | $\overline{\mathrm{~F}} 1$ | $\overline{\mathrm{~F} 2}$ | $\overline{\mathrm{~F}} 3$ | $\mathrm{C}_{\mathrm{n}}$ | $\mathrm{C}_{\mathrm{n}}+4$ | $\overline{\mathrm{P}}$ | $\overline{\mathrm{G}}$ |
| Active-high data (Table 2) | AO | BO | A 1 | B 1 | A 2 | B 2 | A 3 | B 3 | FO | F 1 | F 2 | F 3 | $\overline{\mathrm{C}}_{n}$ | $\overline{\mathrm{C}}_{\mathrm{n}}+4$ | X | Y |

Subtraction is accomplished by 1 's complement addition where the 1 's complement of the subtrahend is generated internally. The resultant output is $A-B-1$, which requires an end-around or forced carry to provide $A-B$.

The 'AS181A and 'AS881A can also be utilized as a comparator. The $A=B$ output is internally decoded from the function outputs (F0, F1, F2, F3) so that when two words of equal magnitude are applied at the $A$ and $B$ inputs, it will assume a high level to indicate equality $(A=B)$. The $A L U$ must be in the subtract mode with $C_{n}=H$ when performing this comparison. The $A=B$ output is open-collector so that it can be wire-AND connected to give a comparison for more than four bits. The carry output ( $C_{n}+4$ ) can also be used to supply relative magnitude information. Again, the ALU must be placed in the subtract mode by placing the function select input S3, S2, S1, S0 at L, H, H, L, respectively.

| INPUT $C_{n}$ | OUTPUT $C_{n+4}$ | ACTIVE-LOW DATA <br> (FIGURE 1) | ACTIVE-HIGH DATA <br> (FIGURE 2) |
| :---: | :---: | :---: | :---: |
| $H$ | $H$ | $\mathrm{~A} \geqslant \mathrm{~B}$ | $\mathrm{~A} \leqslant \mathrm{~B}$ |
| H | L | $\mathrm{A}<\mathrm{B}$ | $\mathrm{A}>\mathrm{B}$ |
| L | H | $\mathrm{A}>\mathrm{B}$ | $\mathrm{A}<\mathrm{B}$ |
| L | L | $\mathrm{A} \leqslant \mathrm{B}$ | $\mathrm{A} \geqslant \mathrm{B}$ |

These circuits have been designed to not only incorporate all of the designer's requirements for arithmetic operations, but also to provide 16 possible functions of two Boolean variables without the use of external circuitry. These logic functions are selected by use of the four function-select inputs (S0, S1, S2, S3) with the mode-control input (M) at a high level to disable the internal carry. The 16 logic functions are detailed in Tables 1 and 2 and include exclusive-OR, NAND, AND, NOR, and OR functions.

## description (continued)

The 'AS881A has the same pinout and same functionality as the 'AS181A except for the $\bar{P}, \bar{G}$, and $C_{n}+4$ outputs when the device is in the logic mode $(M=H)$.

In the logic mode the 'AS881A provides the user with a status check on the input words A and B, and the ouput word $F$. While in the logic mode the $\bar{P}, \bar{G}$, and $C_{n}+4$ outputs supply status information based upon the following logical combinations:
$\overline{\mathrm{P}}=\mathrm{F} 0+\mathrm{F} 1+\mathrm{F} 2+\mathrm{F} 3$
$\bar{G}=H$
$C_{n+4}=P C_{n}$

FUNCTION TABLE FOR INPUT BITS EQUAL/NOT EQUAL
SO-S3-H. S1-S2-L, and M-H

| $\mathrm{C}_{\mathrm{n}}$ | DATA INPUTS |  |  |  | OUTPUTS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | $\overline{\mathrm{G}}$ | $\overline{\mathrm{P}}$ | $\mathrm{c}_{\mathrm{n}+4}$ |
| H | $\overline{\mathrm{A}} 0=\overline{\mathrm{B}} 0$ | $\overline{\mathrm{A}} 1=\overline{\mathrm{B}} 1$ | $\overline{\mathrm{A}} 2=\overline{\mathrm{B}} 2$ | $\overline{\mathrm{A}} 3=\overline{\mathrm{B}} 3$ | H | L | H |
| L | $\overline{\mathrm{A}} 0=\overline{\mathrm{B}} 0$ | $\overline{\mathrm{A}} 1=\overline{\mathrm{B}} 1$ | $\overline{\mathrm{A}} 2=\overline{\mathrm{B}} 2$ | $\overline{\mathrm{A}} 3=\overline{\mathrm{B}} 3$ | H | L | L |
| X | $\overline{\mathrm{A}} 0 \neq \overline{\mathrm{B}} 0$ | x | $x$ | X | H | H | L |
| $x$ | x | $\overline{\mathrm{A}} 1 \neq \overline{\mathrm{B}} 1$ | x | $x$ | H | H | $L$ |
| x | $x$ | x | $\overline{\mathrm{A}} 2 \neq \overline{\mathrm{B}} 2$ | $\times$ | H | H | L |
| x | x | X | X | $\overline{\mathrm{A}} 3 \neq \overline{\mathrm{B}} 3$ | H | H | L |

FUNCTION TABLE FOR INPUT PAIRS HIGH/NOT HIGH

| $\mathrm{c}_{\mathrm{n}}$ | DATA INPUTS |  |  |  | OUTPUTS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | $\overline{\text { G }}$ | $\stackrel{\bar{p}}{ }$ | $\mathrm{C}_{\mathrm{n}+4}$ |
| H | $\overline{\mathrm{A}} \mathrm{O}$ or $\overline{\mathrm{B}} \mathrm{O}=\mathrm{L}$ | $\overline{\mathrm{A}} 1$ or $\overline{\mathrm{B}} 1=\mathrm{L}$ | $\overline{\mathrm{A}} 2$ or $\overline{\mathrm{B}} 2=\mathrm{L}$ | $\overline{\mathrm{A}} 3$ or $\overline{\mathrm{B}} 3=\mathrm{L}$ | H | L | H |
| L | $\overline{\mathrm{A}} \mathrm{O}$ or $\overline{\mathrm{B}} \mathrm{O}=\mathrm{L}$ | $\overrightarrow{\mathrm{A}} 1$ or $\overline{\mathrm{B}} 1=\mathrm{L}$ | $\overline{\mathrm{A}} 2$ or $\overline{\mathrm{B}} 2=\mathrm{L}$ | $\overline{\mathrm{A}} 3$ or $\overline{\mathrm{B}} 3=\mathrm{L}$ | H | L | L |
| x | $\overline{\mathrm{A}} \mathrm{O}=\overline{\mathrm{B}} \mathrm{O}=\mathrm{H}$ | x | $X$ | X | H | H | L |
| x | $x$ | $\bar{A} 1=\bar{B} 1=H$ | x | $x$ | H | H | L |
| x | x | $x$ | $\overline{\mathrm{A}} 2=\overline{\mathrm{B}} 2=\mathrm{H}$ | X | H | H | L |
| x | X | $\times$ | X | $\overline{\mathrm{A}} 3=\overline{\mathrm{B}} 3=\mathrm{H}$ | H | H | L |

The combination of signals on the S3 through S0 control lines determine the operation performed on the data words to generate the output bits $\overline{\mathrm{Fi}}$. By monitoring the $\overline{\mathrm{P}}$ and $\mathrm{C}_{\mathrm{n}}+4$ outputs, the user can determine if all pairs of input bits are equal (see table above) or if any pair of inputs are both high (see table above). The 'AS881A has the unique feature of providing an $A=B$ status while the exclusive-OR( $\oplus$ ) function is being utilized. When the control inputs (S3, S2, S1, SO) equal H,L,L, H; a status check is generated to determine whether all pairs ( $\overline{\mathrm{A}} i, \overline{\mathrm{~B}} \mathrm{i}$ ) are equal in the following manner: $\bar{P}=(A 0 \oplus B 0)+(A 1 \oplus B 1)+(A 2 \oplus B 2)+(A 3 \oplus B 3)$. This unique bit-by-bit comparison of the data words, which is available on the totem-pole $\bar{P}$ output, is particularly useful when cascading 'AS881s. As the $A=B$ condition is sensed in the first stage, the signal is propagated through the same ports used for carry generation in the arithmetic mode ( $\bar{P}$ and $\bar{G}$ ). Thus the $A=B$ status is transmitted to the second stage more quickly without the need for external multiplexing logic. The $A=B$ open-collector output allows the user to check the validity of the bit-by-bit result by comparing the two signals for parity.

If the user wishes to check for any pair of data inputs ( $\bar{A} i, \bar{B} i$ ) being high, it is necessary to set the control lines (S3,S2,S1,SO) to L, H, L, L. The data pairs will then be ANDed together and the results ORed in the following manner: $\bar{P}=\bar{A} O \bar{B} O+\bar{A} 1 \bar{B} 1+\bar{A} 2 \bar{B} 2+\bar{A} 3 \bar{B} 3$.

| S3 | $S 2$ | $S 1$ | $S 0$ | $M$ | $\bar{P}=F 0+F 1+F 2+F 3$ |  |
| :---: | :---: | :---: | :---: | :---: | :--- | :--- | :--- |
| $L$ | $H$ | $L$ | $L$ | $H$ | $\bar{A} 0 \bar{B} 0+\bar{A} 1 \bar{B} 1+\bar{A} 2 \bar{B} 2+\bar{A} 3 \bar{B} 3$ |  |
| $H$ | $L$ | $L$ | $H$ | $H$ | $(A O \oplus B O)+(A 1 \oplus B 1)+(A 2 \oplus B 2)+(A 3 \Theta B 3)$ |  |

## signal designations

In both Figures 1 and 2, the polarity indicators ( $\Delta$ ) indicate that the associated input or output is activelow with respect to the function shown inside the symbol and the symbols are the same in both figures. The signal designations in Figure 1 agree with the indicated internal functions based on active-low data, and are for use with the logic functions and arithmetic operations shown in Table 1. The signal designations have been changed in Figure 2 to accommodate the logic functions and arithmetic operations for the activehigh data given in Table 2. The 'AS181A and 'AS881A together with 'AS882 and 'S182 can be used with the signal designation of either Figure 1 or Figure 2.


TABLE 1

| SELECTION | ACTIVE-LOW DATA |  |  |
| :---: | :---: | :---: | :---: |
|  | $\mathrm{M}=\mathrm{H}$ | $\mathrm{M}=\mathrm{L}$; ARITHM | TIC OPERATIONS |
| S3 S2 S1 ${ }^{\text {S0 }}$ | LOGIC FUNCTIONS | $\begin{gathered} C_{n}=L \\ \text { (no carry) } \end{gathered}$ | $C_{n}=H$ <br> (with carry) |
| L L L L | $\mathrm{F}=\overrightarrow{\mathrm{A}}$ | $F=A$ MINUS 1 | $F=A$ |
| $L L L H$ | $F=\overline{A B}$ | $F=A B M I N U S 1$ | $F=A B$ |
| L L $\quad \mathrm{H}$ | $F=\bar{A}+B$ | $F=A \bar{B}$ MINUS 1 | $F=A \bar{B}$ |
| L L H H | $F=1$ | $F=$ MINUS 1 (2's COMP) | $F=Z E R O$ |
| L | $F=\overline{A+B}$ | $F=A \operatorname{PLUS}(\mathrm{~A}+\overline{\mathrm{B}})$ | $F=A$ PLUS $\|A+\bar{B}\|$ PLUS 1 |
| L H L H | $F=\bar{B}$ | $F=A B P L U S ~(A+\bar{B}\rangle$ | $F=A B P L U S(A+\bar{B})$ PLUS 1 |
| L H H H L | $F=\overline{A \oplus B}$ | $F=A$ MINUS B MINUS 1 | $F=A$ MINUS $B$ |
| L H H H | $F=A+\bar{B}$ | $F=A+\bar{B}$ | $F=\{A+\bar{B}\rangle$ PLUS 1 |
| H L L L | $F=\bar{A} B$ | $F=A P L U S\{A+B\rangle$ | $F=A$ PLUS $(A+B) P$ PLUS ; |
| $H$ L L H | $F=A \oplus B$ | $F=A$ PLUS $B$ | $F=A$ PLUS B PLUS 1 |
| H L H L | $F=B$ | $F=A \bar{B} P L U S(A+B)$ | $F=A \bar{B} P \operatorname{CLUS}(A+B) P L U S ~ 1$ |
| H L H H | $F=A+B$ | $F=(A+B)$ | $F=\{A+B)$ PLUS 1 |
| $\mathrm{H} \quad \mathrm{H} \quad \mathrm{L}$ L | $F=0$ | $F=A P L U S A^{\dagger}$ | $F=A$ PLUS A PLUS 1 |
| H H L H | $F=A \bar{B}$ | $F=A B P L U S A$ | $F=A B$ PLUS A PLUS 1 |
| $\mathrm{H} \quad \mathrm{H} \quad \mathrm{H} \quad \mathrm{L}$ | $F=A B$ | $F=A \bar{B} P$ LUS $A$ | $F=A \bar{B} P$ LUS $A$ PLUS 1 |
| H H H H | $F=A$ | F-A | $F=A P L U S 1$ |



TABLE 2

${ }^{\dagger}$ Each bit is shifted to the next more significant position.
logic diagram (positive logic)


## SN54AS881A, SN74AS881A

ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS
logic diagram (positive logic)
'AS881A

2



## SN54AS181A, SN54AS881A, SN74AS181A, SN74AS881A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |  |
| :---: | :---: | :---: |
| Input voltage ..................................................................... 7 V |  |  |
| Off-state output voltage ( $\mathrm{A}=\mathrm{B}$ output only) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |  |
| Operating free-air temperature range: | SN54AS181A, SN54AS881A | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74AS181A, SN74AS881A | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions


## SN54AS181A, SN54AS881A, SN74AS181A, SN74AS881A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

electrical characteristics over recommended operating free-air temperature range funless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS' |  |  | SN74AS' |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 /=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Any output except $A=B$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{l}^{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | V |
|  | $\stackrel{\text { G }}{ }$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-3 \mathrm{~mA}$ | 2.4 | 3.4 |  | 2.4 | 3.4 |  | $\checkmark$ |
| ${ }^{1} \mathrm{OH}$ | $\mathrm{A}=\mathrm{B}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\text {OL }}$ | Any output except $\overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{LL}=20 \mathrm{~mA}$ |  | 0.3 | 0.5 |  | 0.3 | 0.5 | V |
|  | $\overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=48 \mathrm{~mA}$ |  | 0.4 | 0.5 |  | 0.4 | 0.5 | V |
| 1 | M input | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $V_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | Any A or B input |  |  |  |  | 0.3 |  |  | 0.3 |  |
|  | Any S input |  |  |  |  | 0.4 |  |  | 0.4 |  |
|  | Carry input |  |  |  |  | 0.6 |  |  | 0.6 |  |
| Ith | M input | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | Any A or B input |  |  |  |  | 60 |  |  | 60 |  |
|  | Any S input |  |  |  |  | 80 |  |  | 80 |  |
|  | Carry input |  |  |  |  | 120 |  |  | 120 |  |
| IIL | $M$ input | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $V_{1}=0.4 \mathrm{~V}$ |  |  | -2 |  |  | -2 | mA |
|  | Any A or B input |  |  |  |  | -6 |  |  | -6 |  |
|  | Any S input |  |  |  |  | -8 |  |  | -8 |  |
|  | Carry input |  |  |  |  | -12 |  |  | -12 |  |
| $10^{\ddagger}$ | All outputs except $\mathrm{A}=\mathrm{B} \text { and } \overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -45 | - 112 | -30 | -45 | -112 | mA |
|  | $\overline{\mathrm{G}}$ |  |  | -165 |  |  | -165 |  |  |  |
| ${ }^{\text {I C C }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | 'AS181A |  | 135 | 200 |  | 135 | 200 | mA |
|  |  | 'AS881A |  | 135 | 210 |  | 135 | 210 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit current, IOS

## SN54AS181A, SN54AS881A, SN74AS181A, SN74AS881A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | $\left\lvert\, \begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}\right.$ | TEST CONDITIONS | $\begin{aligned} & \hline V_{C C}=5 \mathrm{~V}, \\ & C_{L}=15 \mathrm{pF}, \\ & R_{L}=500 \Omega \\ & (280 \Omega \text { for } A=B) . \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline \text { AS181A } \\ & \text { 'AS881A } \\ & \hline \end{aligned}$ | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & C_{\mathrm{L}}=50 \mathrm{pF}(15 \mathrm{pF} \text { for } \mathrm{A}=\mathrm{B}), \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega(280 \Omega \text { for } A=B), \\ & \mathrm{T}_{A}=\text { MIN to MAX } \end{aligned}$ |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | SN54AS181A SN54AS881A |  | $\begin{aligned} & \text { SN74AS181A } \\ & \text { SN74AS881A } \end{aligned}$ |  |  |  |
|  |  |  |  | MIN TYP ${ }^{\dagger}$ MAX | MIN TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| ${ }^{1} \mathrm{pd}$ | $\mathrm{C}_{n}$ | $\mathrm{C}_{n+4}$ |  | 5 | 27 | 11 | 2 | 7 | 9 | ns |
| ${ }^{\text {p }}$ d | Any $\overline{\mathrm{A}}$ or $\overline{\mathrm{B}}$ | $C_{n+4}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V} \\ & \mathrm{SO}=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 6 | 28 | 14 | 2 | 8 | 12 | ns |
| ${ }^{\text {tpd }}$ | Any $\bar{A}$ or $\bar{B}$ | $C_{n+4}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 0=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V} \text { (DIFF mode) } \end{aligned}$ | 7 | 28 | 20 | 2 | 8 | 16 | ns |
| ${ }^{\text {p }}$ d | $\mathrm{C}_{\mathrm{n}}$. | Any F | $\mathrm{M}=0 \mathrm{~V}$ ( $\overline{\mathrm{SUM}}$ or $\overline{\mathrm{DIFF}}$ mode) | 5 | 36 | 11 | 3 | 6 | 9 | ns |
| ${ }^{t} \mathrm{pd}$ | $\begin{gathered} \text { Any } \\ \bar{A} \text { or } \bar{B} \end{gathered}$ | $\overrightarrow{\mathrm{G}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V} \\ & \mathrm{SO}=\mathrm{S} 3=4.5 \vee(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 4 | 25 | 9 | 2 | 5 | 7 | ns |
| ${ }^{t} \mathrm{pd}$ | Any $\overline{\mathrm{A}}$ or $\overline{\mathrm{B}}$ | $\overline{\mathrm{G}}$ | $\begin{aligned} & M=0 V, S 0=S 3=0 \vee \\ & S 1=S 2=4.5 \vee(\overline{D I F F} \text { mode }) \end{aligned}$ | 5 | 26 | 12 | 2 | 6 | 9 | ns |
| ${ }^{t} \mathrm{pd}$ | $\overline{A n y}, \bar{A} \text { or } \bar{B}$ | $\bar{p}$ | $\begin{aligned} & M=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & S O=S 3=4.5 \vee(\overline{\mathrm{SUM} \text { mode })} \end{aligned}$ | 5 | 26 | 11 | 2 | 6 | 8 | ns |
| ${ }^{t} \mathrm{pd}$ | $\begin{gathered} \text { Any } \\ \overline{\mathrm{A}} \text { or } \bar{B} \end{gathered}$ | $\stackrel{\text { ¢ }}{ }$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 0=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V}(\overline{\mathrm{DIFF}} \text { mode }) \end{aligned}$ | 5 | 26 | 13 | 2 | 6 | 10 | ns |
| ${ }^{\text {p }}$ pd | $\overline{\mathrm{A} i}$ or $\bar{B} i$ | $\overline{\mathrm{Fi}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & \mathrm{SO}=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 5 | 25 | 11 | 2 | 5 | 8 | ns |
| ${ }^{\text {t }} \mathrm{pd}$ | $\bar{A} i$ or $\bar{B} i$ | $\bar{F} i$ | $\begin{aligned} & M=0 \mathrm{~V}, \mathrm{~S} 0=\mathrm{S} 1=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V}(\mathrm{DIFF} \text { mode }) \end{aligned}$ | 5 | 26 | 12 | 2 | 6 | 10 | ns |
| ${ }^{\text {tp }}$ p | $\bar{A} i$ or $\overline{B i}_{i}$ | $\bar{F} \mathrm{i}$ | $\mathrm{M}=4.5 \mathrm{~V}$ (LOGIC mode) | 6 | 26 | 16 | 2 | 6 | 11 | ns |
| ${ }^{\text {t }}$ pd | $\begin{aligned} & \text { Any } \bar{A} \\ & \text { or } \bar{B} \end{aligned}$ | $A=B$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 0=\mathrm{S} 3=0 \mathrm{~V} . \\ & \mathrm{S} 1=\mathrm{S} 2=4.5 \mathrm{~V}(\overline{\mathrm{DIFF}} \text { mode }) \end{aligned}$ | 12 | $4 \quad 14$ | 26 | 4 | 14 | 21 | ns |

additional 'AS881A switching characteristics involving status checks (see Note 1)

$\mathrm{t}_{\mathrm{pd}}=\mathrm{t}_{\mathrm{PHL}}$ or $\mathrm{t}_{\mathrm{PLH}}$
${ }^{\top}$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## PARAMETER MEASUREMENT INFORMATION

SUM MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{SO}=\mathrm{S3}=4.5 \mathrm{~V}, \mathrm{S1}=\mathrm{S2}=\mathrm{M}=0 \mathrm{~V}$

| PARAMETER | INPUT UNDER TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | output UNDER TEST | output <br> WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { APPLY } \\ & 4.5 \mathrm{~V} \end{aligned}$ | APPLY GND | $\begin{aligned} & \text { APPLY } \\ & 4.5 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \text { APPLY } \\ & \text { GND } \end{aligned}$ |  |  |
| tPLH | $\bar{A} i$ | Bi | None | Remaining $\bar{A}$ and $\bar{B}$ | $\mathrm{C}_{n}$ | Fi | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\overline{B r}_{i}$ | $\bar{A} i$ | None | Remaining $\bar{A}$ and $\bar{B}$ | $\mathrm{C}_{\mathrm{n}}$ | Fi | In-Phase |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{B}}$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{P}}$ | In-Phase |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  |  |  |
| tPLH | $\overline{\mathrm{B}} \mathrm{i}$ | $\bar{A} i$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\text { p }}$ | In-Phase |
| tpHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{A} i$ | None | Bi | $\begin{aligned} & \hline \text { Remaining } \\ & \bar{B} \end{aligned}$ | $\begin{aligned} & \text { Remaining } \\ & \bar{A}, C_{n} \\ & \hline \end{aligned}$ | $\overline{\text { G }}$ | In-Phase |
| ${ }_{\text {tPHL }}$ |  |  |  |  |  |  |  |
| tPLH | $\overline{\mathrm{B}}$ | None | $\bar{A}{ }_{i}$ | $\begin{gathered} \hline \text { Remaining } \\ \bar{B} \\ \hline \end{gathered}$ | Remaining <br> $\bar{A}, C_{n}$ | $\overline{\mathrm{G}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\mathrm{C}_{\mathrm{n}}$ | None | None | $\overline{A l l}$ | $\begin{gathered} \hline \text { All } \\ \bar{B} \end{gathered}$ | $\begin{gathered} \text { Any } \bar{F} \\ \text { or } C_{n+4} \\ \hline \end{gathered}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{A}{ }^{i}$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | $\begin{gathered} \text { Remaining } \\ \bar{B} \\ \hline \end{gathered}$ | $\begin{aligned} & \text { Remaining } \\ & \bar{A}, c_{n} \\ & \hline \end{aligned}$ | $\mathrm{C}_{\mathrm{n}+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{B}} \mathrm{i}$ | None | $\bar{A} i$ | $\begin{gathered} \text { Remaining } \\ \bar{B} \end{gathered}$ | Remaining <br> $\bar{A}, C_{n}$ | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |

DIFF MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{S} 1=\mathrm{S} 2=4.5 \mathrm{~V}, \mathrm{SO}=\mathrm{S3}=\mathrm{M}=0 \mathrm{~V}$

| PARAMETER | INPUT under TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT UNDER TEST | output WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY <br> 4.5 V | APPLY GND | $\begin{aligned} & \text { APPLY } \\ & 4.5 \mathrm{~V} \end{aligned}$ | APPLY GND |  |  |
| tPLH | $\bar{A} i$ | None | $\overline{\mathrm{B}} \mathrm{i}^{\text {i }}$ | Remaining | Remaining | Fi | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tpLH | $\overline{\mathrm{B}} \mathrm{i}$ | $\bar{A}_{i}$ | None | Remaining | Remaining | Fi | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{A}{ }_{i}$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | None | - Remaining | $\overline{\text { P }}$ | In-Phase |
| tPHL |  |  |  |  | $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ |  | In |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{Bi}}$ | $\bar{A} i$ | None | None | Remaining | $\overline{\text { p }}$ | Out-of-Phase |
| tPHL |  |  |  |  | $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ |  | Outor Pras |
| ${ }^{\text {tPLH }}$ | $\bar{A} i$ | $\overline{\mathrm{Bi}}$ | None | None | Remaining | $\overline{\mathrm{G}}$ | In. Phase |
| tpHL |  |  |  |  | $\overline{\mathrm{A}} \text { and } \overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ |  | n. Phase |
| tPLH | $\overline{\mathrm{Bi}}$ | None | $\bar{A} i$ | None | Remaining | $\overline{\mathrm{G}}$ | Out-of-Phase |
| tPHL |  |  |  |  | $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ |  |  |
| tPLH | $\overline{A_{i}}$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | Remaining | remaining | $A=B$ | In-Phase |
| tpHL |  |  |  |  | $\bar{B}, C_{n}$ |  | In-Rase |
| tPLH | $\overline{\mathrm{B}} \mathrm{i}$ | $\bar{A} i$ | None | ${ }_{\text {Remaining }}$ | Remaining | $A=B$ | Out-of-Phase |
| tPHL |  |  |  |  | $\bar{B}, \mathrm{C}_{n}$ |  |  |
| tPLH | $\mathrm{C}_{\mathrm{n}}$ | None | None | - ${ }^{\text {All }}$ | None | $C_{n+4}=$ | In-Phase |
| tPHL |  |  |  | $\bar{A}$ and $\bar{B}$ |  | or any $\bar{F}$ |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{Bi}}$ | None | None | Remaining | $\mathrm{C}_{\mathrm{n}+4}$ | Out-of-Phase |
| tPHL |  |  |  |  | $\bar{A}, \bar{B}, C_{n}$ |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\text { B }}$ | None | $\bar{A} i$ | None | Remaining | $\mathrm{C}_{\mathrm{n}+4}$ | In-Phase |
| tPHL |  |  |  |  | $\bar{A}, \bar{B}, C_{n}$ |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

# SN54LS222, SN54LS224, SN54LS227, SN54LS228 <br> SN74LS222, SN74LS224, SN74LS227, SN74LS228 <br> 16 X 4 SYNCHRONOUS FIRST-IN FIRST.OUT MEMORIES <br> JANUARY 1981 - REVISED MARCH 1985 

- Independent Synchonous Inputs and Outputs
- 16 Words of 4 Bits Each
- 3-State Outputs Drive Bus Lines Directly
- Data Rates from 0 to 10 MHz
- Fall-Through Time . . . 50 ns Typ
- Data Terminals Arranged for Optimum PC Board Layout
- Expandable Using External Gating


## description

These 64-bit memories are Low-Power Schottky memory arrays organized as 16 words of 4 bits each. They can be expanded in multiples of $15 m+1$ words or $4 n$ bits, or both, (where $n$ is the number of packages in the vertical array and $m$ is the number of packages in the horizontal array) however some external gating is required (see Figure 1). For longer words using the 'LS224 or 'LS228, the IR signals of the first-rank packages and OR signals of the last-rank packages must be ANDed for proper synchronization.

| TYPE | INPUT-READY ENABLE AND <br> OUTPUT-READY ENABLE | OUTPUT |
| :---: | :---: | :--- |
| 'LS222 | Yes | 3-State |
| 'LS224 | No | 3-State |
| 'LS227 | Yes | Open-collector |
| 'LS228 | No | Open-collector |

```
    SN54LS222, SN54LS227 . . . J PACKAGE
SN74LS222, SN74LS227 . . . J OR N PACKAGE
```

(TOP VIEW)

| OE $\square^{1}$ | $\mathrm{U}_{20}$ | VCC |
| :---: | :---: | :---: |
| IRE 2 | 19 | UNCK |
| IR $\square^{3}$ | 18 | ORE |
| LDCK [4 | 17 | IOR |
| DO 5 | 16 | 00 |
| NC $\square^{6}$ | 15 | NC |
| D1 -7 | 14 | Q1 |
| D2 $\square^{8}$ | 13 | -2 |
| D3 9 | 12 | -03 |
| GND 10 | 1 | $\overline{C L R}$ |

[^4] SN74LS224, SN74LS228 . . . J OR N PACKAGE
(TOP VIEW)

| OE 1 | $\bigcup_{16}$ | $\square V_{C C}$ |
| :---: | :---: | :---: |
| IR 2 | 15 | U UNCK |
| LDCK ${ }^{\text {a }}$ | 14 | OR |
| DO $\square^{4}$ | 13 | 00 |
| D1 5 | 12 | 口Q1 |
| D2 6 | 11 | Q2 |
| D3 $\square_{7}$ | 10 | $\bigcirc 03$ |
| GND 8 | 9 | $\square \overline{C L R}$ |

NC - No internal connection
For chip carrier information contact the factory.

## operation

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. These FIFOs are designed to process data at rates from 0 to 10 MHz in a bit-parallel format, word by word. Data is written into the memory on a high-to-low transition at the load clock input (LDCK) and read out on a low-to-high transition at the unload clock input (UNCK).

The memory is full when the number of words clocked in exceeds the number of words clocked out by 16. When the memory is full, LDCK signals have no effect. When the memory is empty, UNCK signals have no effect.

Status of the FIFO memory (see timing diagram) is monitored by the input ready (IR) and output ready (OR) flags that indicate "not full' and "not empty" conditions. The IR output will be high only when the memory is not full and the LDCK input is low. The OR output will be high only when the memory is not empty and UNCK is high.
A low level at the clear ( $\overline{\mathrm{CLR}}$ ) input resets the internal stack control counters and also sets IR high and OR low to indicate that old data remaining at the data outputs is invalid. Data outputs are noninverting with respect to the data inputs and are at high impedance when output enable (OE) is low. OE does not affect the IR and OR outputs.

## 16 X 4 SYNCHRONOUS FIRST.IN FIRST.OUT MEMORIES

## functional block diagram (positive logic)


*'LS222 and 'LS224 have 3-state ( $\nabla$ loutputs. 'LS227 and 'LS228 have open collector ( $\mathbf{\Omega}$ ) outputs.
('LS222 and 'LS227 pin numbers)
['LS224 and 'LS228 pin numbers]
timing diagram


## logic symbols ${ }^{\dagger}$


$\dagger$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
These symbols are functionally accurate but do not show the details of implementation; for these, see the functional block diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at that time. Output data is invalid when the counter content is 0 .
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

```
Supply voltage, VCC (See Note 1)....................................................... . . . 7 V
```



```
Off-state output voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range:
    SN54LS222, SN54LS224, SN54LS227, SN54LS228 . . . . . . . . . . . . . . . . . . - 55 % C to 125 %
    SN74LS222, SN74LS224, SN74LS227, SN74LS228 . . . . . . . . . . . . . . . . . . . . . 0 0 % C to 70 % C
```



NOTE 1: Voltage values are with respect to network ground terminal.

## SN54LS222, SN54LS224, SN74LS222, SN74LS224 16 X 4 SYNCHRONOUS FIRST-IN FIRST-OUT MEMORIES WITH 3-STATE OUTPUTS

## recommended operating conditions

| . |  |  | SN54LS' |  | SN74LS' |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM MAX | MIN | NOM MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 4.5 | $5 \quad 5.5$ | 4.75 | $5 \quad 5.25$ | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  | 2 |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.7 |  | 0.8 | V |
| I | High-level output current | Q |  | -1 |  | $-2.6$ | mA |
| I | High-level output current | IR, OR |  | -0.4 |  | -0.4 | , |
|  |  | Q |  | 12 |  | 24 |  |
| O | Low-level output current | IR, OR |  | 4 |  | 8 | A |
|  |  | LDCK high | 60 |  | 60 |  |  |
|  |  | LDCK low | 15 |  | 15 |  |  |
| $t_{w}$ | Pulse duration | UNCK low | 30 |  | 30 |  | ns |
|  |  | UNCK high | 30 |  | 30 |  |  |
|  |  | $\overline{C L R}$ low | 20 |  | 20 |  |  |
|  |  | D to LDCK $\downarrow$ | 50 |  | 50 |  |  |
| $\mathrm{t}_{\mathrm{su}}$ | Setup time | LDCK $\downarrow$ before UNCK $\downarrow$ | 50 |  | 50 |  | ns |
|  |  | UNCK $\uparrow$ before LDCK $\uparrow$ | 50 |  | 50 |  |  |
| $t_{\text {h }}$ | Hold time | D from LDCK $\downarrow$ | 0 |  | 0 |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  | -55 | 125 | 0 | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  | SN54LS' |  |  | SN74LS ${ }^{\prime}$ |  |  | ŨNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | 0 | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{I}^{\mathrm{OH}}=\mathrm{MAX}$ | 2.4 | 3.3 |  | 2.4 | 3.4 |  | V |
| , | IR, OR | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.5 | 3.4 |  | 2.7 | 3.4 |  | $v$ |
|  | Q | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | ${ }^{1} \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
| V OL |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 | v |
|  | IR, OR | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}^{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| ${ }^{\text {I OZH }}$ | 0 | $V_{C C}=$ MAX, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL | Q | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\text {CC }}=$ MAX, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $V_{C C}=$ MAX, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $V_{C C}=$ MAX . | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
| $\mathrm{los}^{\S}$ | Q | $V_{C C}=$ MAX , |  | -30 |  | -130 | -30 |  | -130 | mA |
|  | IR, OR |  |  | -20 |  | -100 | -20 |  | -100 |  |
| ${ }^{\text {I C C }}$ |  | $V_{C C}=$ MAX, | Outputs high |  | 84 | 135 |  | 84 | 135 | mA |
|  |  | Outputs low |  | 87 | 155 |  | 87 | 155 |  |
|  |  | Outputs disabled |  | 89 | 155 |  | 89 | 155 |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
$\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.


SN54LS222, SN54LS224, SN74LS222, SN74LS224 16 X 4 SYNCHRONOUS FIRST-IN FIRST-OUT MEMORIES WITH 3-STATE OUTPUTS
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER | FROM | TO | TEST CONDITIONS | 'LS222 |  |  | 'LS224 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| ${ }^{\text {tPLH }}$ | IRE $\uparrow$ | IR | $\begin{aligned} & R_{\mathrm{L}}=2 \mathrm{k} \Omega, \\ & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \\ & \text { See Note } 2 \end{aligned}$ |  | 23 | 35 |  |  |  | ns |
| ${ }_{\text {t }}$ | IRE! | IR |  |  | 9 | 15 |  |  |  | ns |
| ${ }^{\text {t PLH }}$ | ORE $\uparrow$ | OR |  |  | 22 | 35 |  |  |  | ns |
| tPHL | ORE $\downarrow$ | OR |  |  | 9 | 15 |  |  |  | ns |
| ${ }^{\text {t PLH }}$ | LDCK $\downarrow$ | IR |  |  | 25 | 40 |  | 25 | 40 | ns |
| ${ }_{\text {tPHL }}$ | LDCK $\uparrow$ | IR |  |  | 36 | 50 |  | 36 | 50 | ns |
| tPLH | LDCK | OR |  |  | 48 | 70 |  | 48 | 70 | ns |
| tPLH | UNCK $\uparrow$ | OR |  |  | 29 | 45 |  | 29 | 45 | ns |
| ${ }_{\text {t PHL }}$ | UNCK! | OR |  |  | 28 | 45 |  | 28 | 45 | ns |
| ${ }_{\text {tPLH }}$ | UNCK $\uparrow$ | IR |  |  | 49 | 70 |  | 49 | 70 | ns |
| ${ }_{\text {tPLH }}$ | $\overline{C L R} \downarrow$ | IR |  |  | 36 | 55 |  | 36 | 55 | ns |
| tPHL | $\overline{\text { CLR }} \downarrow$ | OR |  |  | 25 | 40 |  | 25 | 40 | ns |
| ${ }_{\text {tPHL }}$ | LDCK | Q | $\begin{aligned} & R_{L}=667 \Omega, \\ & C_{L}=45 \mathrm{pF}, \end{aligned}$ <br> See Note 2 |  | 34 | 50 |  | 34 | 50 | ns |
| ${ }^{\text {P PLH }}$ | UNCK $\uparrow$ | Q |  |  | 54 | 80 |  | 54 | 80 | ns |
| tPHL | UNCK $\uparrow$ | Q |  |  | 45 | 70 |  | 45 | 70 | ns |
| ${ }_{\text {tPZL }}$ | OE $\uparrow$ | Q |  |  | 22 | 35 |  | 22 | 35 | ns |
| ${ }^{\text {tPZ }}$ ( ${ }^{\text {P }}$ | OE 1 | Q |  |  | 21 | 35 |  | 21 | 35 | ns |
| tPLZ | OE $\downarrow$ | Q | $\mathrm{R}_{\mathrm{L}}=667 \Omega, \quad C_{\mathrm{L}}=5 \mathrm{pF},$ <br> See Note 2 |  | 16 | 30 |  | 16 | 30 | ns |
| tPHZ | OE $\downarrow$ | Q |  |  | 18 | 30 |  | 18 | 30 | ns |

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.
schematics of inputs and outputs
EQUIVALENT OF CLEAR AND
OUTPUT READY ENABLE INPUTS

VCCO | EQUIVALENT OF |
| :---: |
| OTHER INPUTS |

SN54LS227, SN54LS228, SN74LS227, SN74LS228
16 X 4 SYNCHRONOUS FIRST-IN FIRST.OUT MEMORIES
WITH OPEN-COLLECTOR OUTPUTS
recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  | SN54LS' |  |  | SN74LS' |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {F }}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\\|_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| ${ }^{\mathrm{I} \mathrm{OH}}$ | Q | $\mathrm{V}_{\text {CC }}=$ MIN, | $\mathrm{VOH}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| VOH | IR, OR | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | 2.5 | 3.4 |  | 2.7 | 3.4 |  | V |
|  | 0 | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
| VOL |  | $\mathrm{V}_{\text {CC }}=$ MIN, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 | v |
| OL | IR, OR | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OL}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | $v$ |
|  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| IOZH | Q | $\mathrm{V}_{\text {CC }}=\mathrm{MAX}$. | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| 'OZL | 0 | $V_{C C}=$ MAX, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 |  | $V_{C C}=M A X$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $V_{C C}=M A X$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ILL |  | $V_{C C}=$ MAX | $\mathrm{V}_{\mathrm{I}}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
| Ios ${ }^{8}$ | IR, OR | $V_{C C}=$ MAX |  | -20 |  | -100 | -20 |  | -100 | mA |
| ICC |  | $V_{C C}=M A X$ | Outputs high |  | 84 | 135 |  | 84 | 135 | mA |
|  |  | Outputs low |  | 87 | 155 |  | 87 | 155 |  |
|  |  | Outputs disabled |  | 89 | 155 |  | 89 | 155 |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\S_{\text {Not }}$ more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second

## SN54LS227, SN54LS228, SN74LS227, SN74LS228 16 X 4 SYNCHRONOUS FIRST-IN FIRST.OUT MEMORIES WITH OPEN-COLLECTOR OUTPUTS

switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER | FROM | TO | TEST CONDITIONS | 'LS227 |  |  | 'LS228 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| ${ }^{\text {tPLH }}$ | IRE $\uparrow$ | IR | $\begin{aligned} & R_{\mathrm{L}}=2 \mathrm{k} \Omega \\ & C_{\mathrm{L}}=15 \mathrm{pF}, \\ & \text { See Note } 2 \end{aligned}$ |  | 23 | 35 |  |  |  | ns |
| ${ }^{\text {t PHL }}$ | IRE! | IR |  |  | 9 | 15 |  |  |  | ns |
| ${ }^{\text {tPLH }}$ | ORET | OR |  |  | 22 | 35 |  |  |  | ns |
| ${ }^{\text {tPHL }}$ | ORE | OR |  |  | 9 | 15 |  |  |  | ns |
| ${ }^{\text {P PLH }}$ | LDCK ! | IR |  |  | 25 | 40 |  | 25 | 40 | ns |
| ${ }^{\text {t PHL }}$ | LDCK $\uparrow$ | IR |  |  | 36 | 50 |  | 36 | 50 | ns |
| tPLH | LDCK $\downarrow$ | OR |  |  | 48 | 70 |  | 48 | 70 | ns |
| ${ }^{\text {tPLH }}$ | UNCK $\dagger$ | OR |  |  | 29 | 45 |  | 29 | 45 | ns |
| TPHL | UNCK! | OR |  |  | 28 | 45 |  | 28 | 45 | ns |
| ${ }^{\text {tPLH }}$ | UNCK ${ }^{\text {¢ }}$ | IR |  |  | 49 | 70 |  | 49 | 70 | ns |
| tPLH | CLR! | IR |  |  | 36 | 55 |  | 36 | 55 | ns |
| ${ }^{\text {tPHL }}$ | CLR | OR |  |  | 25 | 40 |  | 25 | 40 | ns |
| ${ }^{\text {t }} \mathrm{PHL}$ | LDCK. | Q | $\begin{aligned} & R_{L}=667 \Omega, \\ & C_{L}=45 \mathrm{pF}, \end{aligned}$ <br> See Note 2 |  | 34 | 50 |  | 34 | 50 | ns |
| tPLH | UNCK $\dagger$ | Q |  |  | 54 | 80 |  | 54 | 80 | ns |
| ${ }_{\text {t PHL }}$ | UNCK $\uparrow$ | Q |  | , | 45 | 70 |  | 45 | 70 | ns |
| ${ }^{\text {tPLH }}$ | OE | Q |  |  | 21 | 30 |  | 21 | 30 | ns |
| tPHL | OE $\uparrow$ | Q |  |  | 20 | 35 |  | 20 | 35 | ns |

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.
schematics of inputs and outputs



FIGURE 1. 46-WORD BY 16-BIT EXPANSION USING 'LS222

[^5]- Independent Asynchronous Inputs and Outputs
- Organized as 16 -Words of 5 Bits
- DC to $10-\mathrm{MHz}$ Data Rate
- 3-State Data Outputs
- 20-Pin, 300-mil, High-Density Package


## description

This 80-bit active-element memory is a monolithic Schottky-clamped transistortransistor logic (STTL) array organized as 16 words of five-bits each. A memory system using the SN74S225 can easily be expanded in multiples of 16 words or of 5 bits as shown in Figure 2. The three-state outputs controlled by a single enable, $\overline{O E}$, makes bus connection and multiplexing easy.

## operation

A FIFO is a memory storage device that allows data to be written into and/or read from its array at independent data rates. The 'S225 FIFO will process data at any desired clock rate from DC to 10 MHz . The data is processed in a parallel format, word by word.

Reading or writing is done independently utilizing separate asynchronous data clocks. Data may be written into the array on the low-to-high transition of either load clock input. Data may be read out of the array on the low-to-high transition of the unload clock input (normally high). Writing data into the FIFO may be accomplished in one of two manners: 1) In applications not requiring a gated clock control, best results will be achieved by applying the clock input to one of the clocks while tying the other clock input high. 2) In applications needing a gated clock, the load clock (gate control) must be high in order for the FIFO to load on the next clock pulse. The clock $A$ and $B$ inputs can be used interchangeably for either clock gate control or clock input.

Status of the 'S225 is provided by three outputs. Input ready monitors the status of the last word location and signifies when the memory is full. This output is high whenever the memory is available to accept any data. The unload clock output also monitors the last word location. This output generates a low-logiclevel pulse (synchronized to the internal clock pulse) when the location is vacant. The third status output, output ready, is high when the first word location contains valid data and unload clock input is high. When unload clock input goes low, output ready will go low and stay low until new valid data is in the first word position. The first word location is defined as the location from which data is provided to the outputs.

The data outputs are noninverted with respect to the data inputs and are three-state with a common control input, output enable. When output enable is low, the data outputs are enabled to function as totem-pole outputs. A high-logic-level forces each data output to a high-impedance state while all other inputs and outputs remain active.

The clear input invalidates all data stored in the memory array by clearing the control logic and setting output ready to a low-logic-level on the high-to-low transition of a low-active pulse.

## FUNCTION TABLES

TABLE 1 INPUT FUNCTIONS

| Input | Pin | Description |
| :--- | ---: | :--- |
| CLK A | 1 | Load Clock A |
| $\overline{D O-D 4}$ | $4-8$ | Data Inputs |
| $\overline{\mathrm{OE}}$ | 9 | Output Enable |
| UNCK IN | 16 | Unload Clock |
| $\overline{\mathrm{CLR}}$ | 18 | Clear |
| CLK B | 19 | Load Clock B |
| GND | 10 | Ground pin |
| $V_{C C}$ | 20 | Supply Voltage |

TABLE 2 OUTPUT FUNCTIONS

| Output | Pin | Description |
| :--- | :---: | :--- |
| IR | 2 | Input Ready |
| UNCK OUT | 3 | Unload Clock |
| Q4-DO | $11-15$ | Data Outputs |
| OR | 17 | Output Ready |


logic symbol ${ }^{\dagger}$


[^6]
## functional block diagram



2

## SN74S225

## $16 \times 5$ ASYNCHRONOUS FIRST.IN FIRST.OUT MEMORY

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)


NOTE 1: All voltage values are with respect to network ground terminal.
recommended operating conditions

|  |  | . | MIN | NOM MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 4.75 | $5 \quad 5.25$ | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 | V |
| ${ }^{\prime} \mathrm{OH}$ | High-level output current | Q outputs |  | -6.5 | mA |
|  |  | All other outputs |  | -3.2 |  |
| ${ }^{1} \mathrm{OL}$ | Low-level output current | Q outputs |  | 16 | mA |
|  |  | All other outputs |  | 8 |  |
| ${ }^{\text {w }}$ W | Pulse duration | CLK A or CLK B (high) | 25 |  | ns |
|  |  | UNCK IN (low) | 7 |  |  |
|  |  | $\overline{\text { CLR (low) }}$ | 40 |  |  |
| ${ }^{\text {t }} \mathrm{su}$ | Setup time before CLK $\mathrm{A} \uparrow$ or CLK $\mathrm{B} \uparrow$ | Data (See Note 2) | -20 |  | ns |
|  |  | $\overline{\text { CLR }}$ inactive | 25 |  |  |
| $t_{\text {h }}$ | Hold time after CLK A $\uparrow$ or CLK B $\uparrow$ |  | 70 |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  | 0 | 70 | ${ }^{\circ} \mathrm{C}$ |

NOTE 2: Data must be setup within 20 ns after the load clock positive transition.
electrical characteristics over recommended operating free-air temperature range
(unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | MIN | TYPT | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IK }}$ |  | $\mathrm{V}_{\text {CC }}=4.75 \mathrm{~V}, \mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Q | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{l}_{\mathrm{OH}}=-6.5 \mathrm{~mA}$ | 2.4 | 2.9 |  | V |
|  | All others | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-3.2 \mathrm{~mA}$ | 2.4 | 2.9 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | Q | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{I}_{\mathrm{OL}}=16 \mathrm{~mA}$ |  | 0.35 | 0.5 | $\checkmark$ |
|  | All others | $\mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \mathrm{IOL}=8 \mathrm{~mA}$ |  | 0.35 | 0.5 |  |
| IOZH |  | $\mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.4 \mathrm{~V}$ |  |  | 50 | $\mu \mathrm{A}$ |
| 'OZL |  | $\mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V}$ |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{1}=5.5 \mathrm{~V}$ |  |  | 1 | mA |
| I'H | Data | $\mathrm{V}_{C C}=5.25 \mathrm{~V}, \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  |  | 40 | $\mu \mathrm{A}$ |
|  | All others |  |  |  | 25 |  |
| IL | Data | $\mathrm{V}_{C C}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=0.5 \mathrm{~V}$ |  |  | -1 | mA |
|  | All others |  |  |  | -0.25 |  |
| los ${ }^{\text { }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V}$ | -30 |  | -100 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}$, (See Note 3) |  | 80 | 120 | mA |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ Duration of the short circuit should not exceed one second.
NOTE 3: ICC is measured with all inputs grounded and the output open.
switching characteristics over recommended operating ranges of $T_{A}$ and $V_{C C}$ (unless otherwise noted)

| PARAMETERS ${ }^{\dagger}$ | FROM | TO | TEST CONDITIONS | MIN TYP ${ }^{\ddagger}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $f_{\text {max }}$ | CLK A |  | $C_{L}=30 \mathrm{pF}$$\text { See Note } 4$ | $10 \quad 20$ |  | MHZ |
| ${ }^{\text {f max }}$ | CLK B |  |  | 1020 |  | MHz |
| $f_{\text {max }}$ | UNCK IN |  |  | $10 \quad 20$ |  | MHz |
| $t_{\text {w }}$ | UNCK OUT |  |  | $7 \quad 14$ |  | ns |
| $t_{\text {dis }}$ | $\overline{O E}$ | Any Q | $C_{L}=5 \mathrm{pF}$ | 10 | 25 | ns |
| $\mathrm{t}_{\mathrm{e}}$ |  |  |  | 25 | 40 |  |
| ${ }^{\text {tPLH }}$ | UNCK IN | Any 0 |  | 50 | 75 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 50 | 75 |  |
| tPLH | $\begin{gathered} \text { CLK A } \\ \text { or } \\ \text { CLK B } \end{gathered}$ | OR |  | 190 | 300 | ns |
| ${ }^{\text {tPLH }}$ | UNCK IN | OR |  | 40 | 60 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 30 | 45 |  |
| ${ }^{\text {tPHL }}$ | $\overline{C L R}$ | OR | $\begin{gathered} C_{L}=30 \mathrm{pF} \\ \text { See Note } 4 \end{gathered}$ | 35 | 60 | ns |
| tPHL | $\begin{gathered} \hline \text { CLK A } \\ \text { or } \\ \text { CLK B } \end{gathered}$ | UNCK OUT |  | 25 | 45 | ns |
| tPHL | UNCK IN | UNCK OUT |  | 270 | 400 | ns |
| tPHL | $\begin{aligned} & \text { CLK A } \\ & \text { or } \\ & \text { CLK B } \end{aligned}$ | IR |  | 55 | 75 | ns |
| tPLH | UNCK IN | IR |  | 255 | 400 | ns |
| tPLH | $\overline{\text { CLR }}$ | IR |  | 16 | 35 | ns |
| ${ }_{\text {tPLH }}$ | ORT | Any Q |  | 10 | 20 | ns |

${ }^{\dagger} f_{\text {max }} \equiv$ maximum clock frequency
$\mathrm{t}_{\mathrm{w}} \equiv$ pulse width (output)
$11 \equiv$ The arrow indicates that the low-to-high ( 1 ) or high-to-low ( 1 ) transition of the output ready (OR) output is used for reference.
${ }^{\text {tpLH }} \equiv$ propagation delay time, low-to-high-level output.
$t_{\text {PHL }} \equiv$ propagation delay time, high-to-low-level output.
${ }^{\ddagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
NOTE 4: Load circuit and voltage waveforms are shown in Section 1.

TYPICAL WAVEFORMS FOR A 16-WORD FIFO


FIGURE 1. TYPICAL WAVEFORMS FOR A 16-WORD FIFO


FIGURE 2. EXPANDING THE 'S225 FIFO (48 WORDS OF 10 BITS SHOWN)

## SN54ALS229A, SN74ALS229A $16 \times 5$ ASYNCHRONOUS FIRST.IN FIRST-OUT MEMORIES

D2876, MARCH 1986-REVISED APRIL 1986

- Independent Asychronous Inputs and Outputs
- 16 Words by 5 Bits Each
- Data Rates from 0 to $\mathbf{3 0} \mathbf{~ M H z}$
- Fall-Through Time . . . 24 ns Typ
- 3-State Outputs


## description

These 80-bit memories utilize Advanced LowPower Schottky technology and feature high speed and fast fall-through times. They are organized as 16 words by 5 bits each.

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. These FIFOs are designed to process data at rates from 0 to 25 megahertz in a bit-parallel format, word by word.

Data is written into memory on a low-to-high transition at the load clock input (LDCK) and is read out on a low-to-high transition at the unload clock input (UNCK). The memory is full when the number of words clocked in exceeds by 16 the number of words clocked out. When the memory is full, LDCK signals will have no effect. When the memory is empty, UNCK signals have no effect.

Status of the FIFO memory is monitored by the FULL, EMPTY, FULL - 2, and EMPTY + 2 output flags. The $\overline{\text { FULL }}$ output will be low whenever the memory is full, and high whenever not full. The $\overline{\text { FULL-2 }}$ output will be low whenever the memory contains 14 data words. The EMPTY output will be low whenever the memory is empty, and high whenever it is not empty. The EMPTY +2 output will be low whenever 2 words remain in memory.

SN54ALS229A . . . J PACKAGE
SN74ALS229A... DW OR N PACKAGE
(TOP VIEW)

| OE $\square^{1}$ | $\cup_{20}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| FULL-2 $\square^{2}$ | 19 | $\overline{\mathrm{EMPTY}+2}$ |
| FULL ${ }^{3}$ | 18 | U UNCLK |
| LDCK $\square^{4}$ | 17 | EMPTY |
| DO 5 | 16 | $\square 0$ |
| D1 6 | 15 | Q1 |
| D2 0 | 14 | ¢2 |
| D3 8 | 13 | Q3 |
| D4 9 | 12 | ¢ 04 |
| GND 10 | 11 | $\overline{\mathrm{RST}}$ |

SN54ALS229A . . . FK PACKAGE SN74ALS229A . . . FN PACKAGE (TOP VIEW)


A low level on the reset input ( $\overline{\mathrm{RST}}$ ) resets the internal stack control pointers and also sets EMPTY low and sets FULL, $\overline{\text { FULL }-2}$, and EMPTY +2 high. The Q outputs are not reset to any specific logic level. The first low-to-high transition on LDCK, after either a $\overline{\text { RST }}$ pulse or from an empty condition, will cause EMPTY to go high and the data to appear on the $Q$ outputs. It is important to note that the first word does not have to be unloaded. Data outputs are noninverting with respect to the data inputs and are at high impedance when the output enable input (OE) is low. OE does not affect the output flags. Cascading is easily accomplished in the word-width direction, but is not possible in the word-depth direction.
logic symbol ${ }^{\dagger}$

t This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12. The symbol is functionally accurate but does not show the details of implementation; for these, see the logic diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at the time. Output data is invalid when the counter content (CT) is 0 .
logic diagram (positive logic)


## timing diagram


absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC ..... 7 V
Input voltage ..... 7 V
Voltage applied to a disabled 3 -state output ..... 5.5 V
Operating free-air temperature range: SN54ALS229A ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$SN74ALS229A

$$
0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}
$$

$$
\text { Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . }-65^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}
$$

recommended operating conditions


## SN54ALS229A, SN74ALS229A $16 \times 5$ ASYNCHRONOUS FIRST.IN FIRST-OUT MEMORIES

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS229A |  |  | SN74ALS229A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYp ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $I_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{VOH}^{\text {OH}}$ | Status flags | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | Q outputs | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  | 2.432 |  |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | Q outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | Status flags | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| lozH |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ${ }^{\text {I OZL }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 |  | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IH |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.2 |  |  | -0.2 | mA |
| $10^{\ddagger}$ |  | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | $-30$ |  | -112 | $-30$ |  | -112 | mA |
| ${ }^{\text {I CC }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  |  | 95 | 150 |  | 95 | 140 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS229A} \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS229A |  | SN74ALS229A |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\prime}$ max | LDCK |  |  |  |  | 25 |  | 30 |  | MHz |
|  | UNCK |  |  |  |  | 25 |  | 30 |  |  |
| ${ }_{\text {t }}{ }_{\text {d }}$ | LDCK $\uparrow$ | Any Q |  | 24 | 47 | 7 | 54 | 7 | 50 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | UNCK $\dagger$ | Any Q |  | 19 | 29 | 9 | 35 | 9 | 33 | ns |
| tPLH | LDCK $\dagger$ | EMPTY |  | 18 | 26 | 9 | 32 | 9 | 30 | ns |
| tPHL | UNCK $\dagger$ | EMPTY |  | 18 | 25 | 9 | 32 | 9 | 29 | ns |
| ${ }^{\text {tPHL }}$ | RST」 | EMPTY. |  | 15 | 21 | 6 | 26 | 6 | 24 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | LDCK $\dagger$ | EMPTY + 2 |  | 23 | 33 | 10 | 40 | 10 | 38 | ns |
| ${ }^{\text {p }}$ d | UNCK $\uparrow$ | EMPTY +2 |  | 20 | 29 | 9 | 38 | 9 | 35 | ns |
| ${ }^{\text {tPLH }}$ | RST! | EMPTY + 2 |  | 20 | 28 | 9 | 35 | 9 | 33 | ns |
| ${ }^{\text {p }}$ d | LDCK $\uparrow$ | FULL-2 |  | 23 | 33 | 10 | 40 | 10 | 38 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | UNCK $\dagger$ | FÜLL-2 |  | 20 | 29 | 9 | 38 | 9 | 35 | ns |
| ${ }_{\text {t PLH }}$ | $\overline{\text { RST }} \downarrow$ | FULL-2 |  | 20 | 28 | 9 | 35 | 9 | 33 | ns |
| tPHL | LDCK $\uparrow$ | FULL |  | 21 | 28 | 10 | 35 | 10 | 33 | ns |
| tPLH | UNCK $\dagger$ | FULL |  | 17 | 23 | 8 | 29 | 8 | 27 | ns |
| tpLH | $\overline{\text { RST }} \downarrow$ | FULL |  | 18 | 27 | 8 | 33 | 8 | 31 | ns |
| $\mathrm{t}_{\text {en }}$ | OE $\uparrow$ | Q |  | 8 | 13 | 1 | 16 | 2 | 15 | ns |
| ${ }^{\text {dis }}$ | OE $\downarrow$ | 0 |  | 8 | 14 | 2 | 20 | 2 | 17 | ns |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Independent Asynchronous Inputs and Outputs
- 16 Words by 4 Bits Each
- Data Rates From 0 to 30 MHz
- Fall-Through Time . . . 24 ns Typ
- 3-State Outputs


## description

These 64-bit memories use Advanced LowPower Schottky technology and feature high speed and fast fall-through times. They are organized as 16 words by 4 bits each.

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. These FIFOs are designed to process data at rates from 0 to 25 megahertz in a bit-parallel format, word by word.

Data is written into memory on a low-to-high transition at the load clock input (LDCK) and is read out on a low-to-high transition at the unload clock input (UNCK). The memory is full when the number of words clocked in exceeds by 16 the number of words clocked out. When the memory is full, LDCK signals have no effect on the data residing in memory. When the memory is empty, UNCK signals have no effect.

SN54ALS232A . . . J PACKAGE
SN74ALS232A . . . D OR N PACKAGE
(TOP VIEW)

| OE $\square_{1}$ | $\bigcup_{16}$ | $1 \mathrm{~V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| FULL-2 | 15 | $\square$ UNCK |
| LDCK ${ }^{3}$ | 14 | EMPTY |
| DO $\square_{4}$ | 13 | 口Q0 |
| D1 5 | 12 | ¢Q1 |
| D2 6 | 11 | ค02 |
| D3 $\square^{7}$ | 10 | $\square 03$ |
| GND 8 | 9 | $\overline{\text { RST }}$ |

SN54ALS232A . . . FK PACKAGE SN74ALS232A . . . FN PACKAGE (TOP VIEW)


NC -- No internal connection.

Status of the FIFO memory is monitored by the $\overline{\text { FULL }}$ and $\overline{\text { EMPTY }}$ output flags. The FULL output will be low when the memory is full, and high when the memory is not full. The EMPTY output will be low when the memory is empty, and high when it is not empty.

A low level on the reset input ( $\overline{\mathrm{RST}}$ ) resets the internal stack control pointers and also sets EMPTY low and sets $\overline{F U L L}$ high. The outputs are not reset to any specific logic levels. The first low-to-high transition on LDCK, either after a $\overline{\operatorname{RST}}$ pulse or from an empty condition, will cause EMPTY to go high and the data to appear on the Q outputs. It is important to note that the first word does not have to be unloaded. Data outputs are noninverting with respect to the data inputs and are at high impedance when the output-enable input (OE) is low. OE does not affect either the $\overline{\text { FULL }}$ or EMPTY output flags. Cascading is easily accomplished in the word-width direction, but is not possible in the word-depth direction.
logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12. The symbol is functionally accurate but does not show the details of implementation; for these, see the logic diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at the time. Output data is invalid when the counter content (CT) is 0 .
logic diagram (positive logic)


Pin numbers shown are for $D, J$, and $N$ packages.
timing diagram


## absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage .................................................................................. 7 V
Voltage applied to a disabled 3 -state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54ALS232A .......................... . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS232A . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  |  | 54ALS | 32A |  | 4ALS | 32A |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX | UNIT |
| $V_{C C}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
|  | High-level output current | Q outputs |  |  | -1 |  |  | -1.6 | mA |
| IOH | High-level output current | FULL, EMPTY |  |  | -0.4 |  |  | -0.4 |  |
|  | Low-level output current | Q outputs |  |  | 12 |  |  | 24 |  |
|  | W-level output carrent | FULL, EMPTY |  |  | 4 |  |  | 8 | mA |
|  |  | LDCK | 0 |  | 25 | 0 |  | 30 | MHz |
| ${ }^{\text {f clock }}$ | Clock frequency | UNCK | 0 |  | 25 | 0 |  | 30 | MHz |
|  |  | RST low | 20 |  |  | 15 |  |  |  |
|  |  | LDCK low | 15 |  |  | 10 |  |  |  |
| $t_{w}$ | Pulse duration | LDCK high | 25 |  |  | 20 |  |  | ns |
|  |  | UNCK low | 15 |  |  | 10 |  |  |  |
|  |  | UNCK high | 25 |  |  | 20 |  |  |  |
|  | Setup time | Data before LDCK $\dagger$ | 10 |  |  | 10 |  |  | ns |
|  | Setup time | $\overline{\mathrm{RST}}$ (inactive) before LDCK $\uparrow$ | 5 |  |  | 5 |  |  | ns |
| th | Hold time | Data after LDCK $\dagger$ | 5 |  |  | 5 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS232A |  |  | SN74ALS232A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| VOH | FULL, EMPTY | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}-2}$ |  |  | V |
|  | Q outputs | $\mathrm{VCC}^{\text {c }}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-2.6 \mathrm{~mA}$ |  |  |  |  |  |  |  |
| VOL | Q outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\prime}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | FULL, EMPTY | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| ${ }^{\text {IOZH }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ${ }_{\text {IOZL }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| ${ }_{1}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.2 |  |  | -0.2 | mA |
| $10^{\ddagger}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$ |  |  | 75 | 125 |  | 75 | 125 | mA |

${ }^{t}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS232A} \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega . \\ & \mathrm{T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS232A |  | SN74ALS232A |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ | LDCK |  | 40 |  |  | 25 |  | 30 |  | MHz |
|  | UNCK |  | 40 |  |  | 25 |  | 30 |  |  |
| ${ }^{\text {tpd }}$ | LDCK $\uparrow$ | Any 0 |  | 30 | 40 | 4 | 50 | 4 | 46 | ns |
| ${ }^{\text {t }}$ d | UNCK $\uparrow$ | Any Q |  | 20 | 27 | 7 | 35 | 7 | 31 | ns |
| tpLH | LDCK $\uparrow$ | EMPTY |  | 17 | 23 | 8 | 29 | 8 | 26 | ns |
| tPHL | UNCK $\uparrow$ | EMPTY |  | 19 | 24 | 10 | 36 | 10 | 29 | ns |
| tphL | $\overline{\text { RST }} \downarrow$ | EMPTY |  | 13 | 18 | 5 | 23 | 5 | 20 | ns |
| tPHL | LDCK $\uparrow$ | FULL |  | 21 | 26 | 10 | 35 | 10 | 31 | ns |
| tPLH | UNCK $\uparrow$ | FULL |  | 17 | 23 | 8 | 28 | 8 | 25 | ns |
| tPLH | $\overline{\text { RST }} \downarrow$ | FULL |  | 18 | 24 | 8 | 31 | 8 | 28 | ns |
| ${ }_{\text {ten }}$ | OET | Q |  | 7 | 12 | 1 | 16 | 1 | 14 | ns |
| $\mathrm{t}_{\text {dis }}$ | OE」 | Q |  | 10 | 16 | 2 | 23 | 2 | 21 | ns |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Independent Asychronous Inputs and Outputs
- 16 Words by 5 Bits Each
- Data Rates from 0 to 30 MHz
- Fall-Through Time . . . 24 ns Typ
- 3-State Outputs


## description

These 80-bit memories utilize Advanced LowPower Schottky technology and feature high speed and fast fall-through times. They are organized as 16 words by 5 bits each.

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. These FIFOs are designed to process data at rates from 0 to 25 megahertz in a bit-parallel format, word by word.

Data is written into memory on a low-to-high transition at the load clock input (LDCK) and is read out on a low-to-high transition at the unload clock input (UNCK). The memory is full when the number of words clocked in exceeds by 16 the number of words clocked out. When the memory is full, LDCK signals will have no effect. When the memory is empty, UNCK signals have no effect.

Status of the FIFO memory is monitored by the FULL, EMPTY, $\overline{\text { FULL }-1}$, and EMPTY +1 output flags. The FULL output will be low whenever the memory is full, and high whenever not full. The $\overline{F U L L-1}$ output will be low whenever the memory contains 15 data words. The EMPTY output will be low whenever the memory is empty, and high whenever it is not empty. The EMPTY +1 output will be low whenever one word remains in memory.


SN54ALS233A . . . FK PACKAGE SN74ALS233A . . . FN PACKAGE (TOP VIEW)


A low level on the reset input ( $\overline{\mathrm{RST}}$ ) resets the internal stack control pointers and also sets EMPTY low and sets $\overline{\text { FULL }}, \overline{\mathrm{FULL}-1}$, and $\overline{\mathrm{EMPTY}+1}$ high. The Q outputs are not reset to any specific logic level. The first low-to-high transition on LDCK, after either a $\overline{R S T}$ pulse or from an empty condition, will cause EMPTY to go high and the data to appear on the $Q$ outputs. It is important to note that the first word does not have to be unloaded. Data outputs are noninverting with respect to the data inputs and are at high impedance when the output enable input ( $O E$ ) is low. OE does not affect the output flags. Cascading is easily accomplished in the word-width direction, but is not possible in the word-depth direction.

## logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12. The symbol is functionally accurate but does not show the details of implementation; for these, see the logic diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at the time. Output data is invalid when the counter content (CT) is 0 .
logic diagram (positive logic)


absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Voltage applied to a disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54ALS233A . . . . . . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS233A . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | SN54ALS233A |  |  | SN74ALS233A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
|  | h-level output current | Q outputs |  |  | -1 |  |  | -1.6 | mA |
| OH | gh-level output current | Status flags |  |  | -0.4 |  |  | -0.4 |  |
| ${ }^{\text {IOL }}$ | Low-level output current | Q outputs |  |  | 12 |  |  | 24 | mA |
|  |  | Status flags |  |  | 4 |  |  | 8 |  |
| ${ }^{\text {f clock }}$ | Clock frequency | LDCK | 0 |  | 25 | 0 |  | 30 | MHz |
|  |  | UNCK | 0 |  | 25 | 0 |  | 30 |  |
| $t_{w}$ | Pulse duration | RST low | 20 |  |  | 15 |  |  | ns |
|  |  | LDCK low | 15 |  |  | 10 |  |  |  |
|  |  | LDCK high | 25 |  |  | 20 |  |  |  |
|  |  | UNCK low | 15 |  |  | 10 |  |  |  |
|  |  | UNCK high | 25 |  |  | 20 |  |  |  |
| $\mathrm{t}_{\text {su }}$ | Setup time | Data before LDCK $\uparrow$ | 10 |  |  | 10 |  |  | ns |
|  |  | $\overline{\text { RST }}$ inactive before LDCK $\uparrow$ | 5 |  |  | 5 |  |  |  |
| $\mathrm{t}_{\mathrm{h}}$ | Hold time | Data after LDCK $\uparrow$ | 5 |  |  | 5 |  |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS233A |  |  | SN74ALS233A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Status flags | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, 1 \mathrm{l} \mathrm{OH}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\text {CC }}-2$ |  |  | $\mathrm{V}_{\text {CC }}-2$ |  |  |  |
|  | Q outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, $\mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ <br> $\mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, $\mathrm{I}_{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  | 2.43 .3 |  |  |  |  |  |  |
|  |  |  |  |  |  |  | 2.43 .2 |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ | Q outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{I}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | Status flags | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| Iozh |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.2 |  |  | -0.2 | mA |
| $10^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  | $88 \quad 143$ |  |  | 88 |  | 133 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

## SN54ALS233A, SN74ALS233A

$16 \times 5$ ASYNCHRONOUS FIRST.IN FIRST-OUT MEMORIES
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS} 233 \mathrm{~A} \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=-\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS233A |  | SN74ALS233A |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{f}$ max | LDCK |  |  | 40 |  | 25 |  | 30 |  | MHz |
|  | UNCK |  |  | 40 |  | 25 |  | 30 |  |  |
| $t_{\text {pd }}$ | LDCK $\uparrow$ | Any Q |  | 24 | 44 | 7 | 52 | 7 | 48 | ns |
| ${ }^{\text {tpd }}$ | UNCK $\uparrow$ | Any Q |  | 19 | 29 | 9 | 35 | 9 | 33 | ns |
| tPLH | LDCK $\uparrow$ | EMPTY |  | 18 | 25 | 9 | 30 | 9 | 28 | ns |
| tPHL | UNCK $\uparrow$ | EMPTY |  | 18 | 25 | 9 | 33 | 10 | 30 | ns |
| tphL | RST ! | EMPTY |  | 13 | 19 | 6 | 24 | 6 | 22 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | LDCK $\uparrow$ | EMPTY + 1 |  | 22 | 31 | 10 | 40 | 10 | 37 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | UNCK $\uparrow$ | EMPTY + 1 |  | 22 | 31 | 9 | 40 | 10 | 37 | ns |
| tPLH | $\overline{\mathrm{RST}} \downarrow$ | EMPTY +1 |  | 19 | 27 | 8 | 32 | 8 | 31 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | LDCK $\uparrow$ | FULL-1 |  | 23 | 32 | 11 | 38 | 12 | 36 | ns |
| ${ }_{\text {tpd }}$ | UNCK $\uparrow$ | FULL-1 |  | 23 | 32 | 11 | 39 | 12 | 36 | ns |
| tPLH | $\overline{\mathrm{RST}} \downarrow$ | FULL-1 |  | 20 | 28 | 10 | 34 | 11 | 32 | ns |
| ${ }_{\text {tPHL }}$ | LDCK $\uparrow$ | FULL |  | 21 | 28 | 10 | 35 | 12 | 33 | ns |
| ${ }_{\text {tPLH }}$ | UNCK $\uparrow$ | FULL |  | 17 | 24 | 8 | 29 | 9 | 27 | ns |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{RST}} \downarrow$ | FULL |  | 18 | 27 | 8 | 32 | 9 | 30 | ns |
| ${ }_{\text {ten }}$ | OE¢ | 0 |  | 8 | 13 | 1 | 16 | 2 | 15 | ns |
| ${ }^{\text {dis }}$ | OE $\downarrow$ | 0 |  | 8 | 12 | 2 | 20 | 2 | 17 | ns |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- 4-Line to 1-Line Multiplexer that can Select 1 and 16 Data Inputs
- Applications:

Boolean Function Generator
Parallel-to-Serial Converter
Data Source Selector

- Buffered 3-State Bus Driver Inputs Permit Multiplexing from N Lines to One Line
- Dependable Texas Instruments Quality and Reliability


## description

The 'AS250 provides full binary decoding to select one of sixteen data sources with an inverting $\bar{W}$ output. The selected sources are buffered with symmetrical propagation delay times. This reduces the possibility of transients occurring at the output.

A buffered enable output ( $\bar{G}$ ) may be used for $n$-line-to-one-line cascading. Taking the $\bar{G}$ high will place the output in a high-impedance state. In the high-impedance state, the output neither loads nor drives the bus lines significantly.

The enable ( $\overline{\mathrm{G}}$ ) does not affect the internal operations of the data selector/multiplexer. New data can be set up while the outputs are disabled.

The SN74AS250 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN74AS250 . . . DW OR NT PACKAGE
(TOP VIEW)

| E7 1 | $\cup_{24}$ | $\square V_{C C}$ |
| :---: | :---: | :---: |
| E6 2 | 23 | ] E 8 |
| E5 $\square^{3}$ | 22 | E9 |
| E4 4 | 21 | E10 |
| E3 5 | 20 | E11 |
| E2 6 | 19 | E12 |
| E1 $\square^{7}$ | 18 | E13 |
| EO-8 | 17 | E14 |
| $\overline{\mathrm{G}} \mathrm{C}_{9}$ | 16 | DE15 |
| W 10 | 15 | A |
| D $\square_{1}$ | 14 | В |
| GND 12 | 13 | C |

SN74AS250 . . . FN PACKAGE (TOP VIEW)


NC-No internal connection

## SN74AS250

### 1.0F-16 DATA GENERATORS/MULTIPLEXERS <br> WITH 3-STATE OUTPUTS

logic symbol ${ }^{\dagger}$

2
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publicatin 617-12.
Pin numbers shown are for DW or NT packages.
logic diagram (positive logic)


## FUNCTION TABLE

| INPUT |  |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { G }}$ | A | B | C | D | Ei | W |
| L | L | L | L | L | E0 | E0 |
| L | H | L | L | L | E1 | E1 |
| L | L | H | L | L | E2 | E2 |
| L | H | H | L | L | E3 | E3 |
| L | L | L | H | L | E4 | E4 |
| L | H | L | H | L | E5 | E5 |
| L | L | H | H | L | E6 | E6 |
| L | H | H | H | L | E7 | E7 |
| L | L | L | L | H | E8 | E8 |
| L | H | L | L | H | E9 | E9 |
| L | L | H | L | H | E10 | E10 |
| L | H | H | L | H | E11 | E11 |
| L | L | L | H | H | E12 | E12 |
| L | H | L | H | H | E13 | E13 |
| L | L | H | H | H | E14 | E14 |
| L | H | H | H | H | E15 | E15 |
| H | X | X | X | X | X | Z |

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC
Operating free-air temperature range
Storage temperature range $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  | MIN | NOM MAX | UNIT |
| :---: | :---: | :---: | :---: |
| VCC Supply voltage | 4.5 | $5 \quad 5.5$ | V |
| $\mathrm{V}_{\text {IH }} \quad$ High-level input voltage | 2 |  | V |
| $\mathrm{V}_{\text {IL }}$ Low-level input voltage |  | 0.8 | V |
| $\mathrm{I}_{\text {OH }} \quad$ High-level output current |  | -15 | mA |
| IOL Low-level output current |  | 48 | mA |
| $\mathrm{T}_{\mathrm{A}}$ Operating free-air temperature | 0 | 70 | ${ }^{\circ} \mathrm{C}$ |

1.0F-16 DATA GENERATORS/MULTIPLEXERS WITH 3-STATE OUTPUTS
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | MIN | TYP ${ }^{\dagger}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IK}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| VOH | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\checkmark$ |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-15 \mathrm{~mA}$ | 2.4 | 3.3 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=48 \mathrm{~mA}$ |  | 0.35 | 0.5 | V |
| ${ }^{\text {ORH }}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 | $\mu \mathrm{A}$ |
| Iozl | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -50 | $\mu \mathrm{A}$ |
| 1 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 | mA |
| 1 IH | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{A}$ |
| ILL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 | mA |
| $10^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | mA |
| ${ }^{\text {I CC }}$ | $V_{C C}=5.5 \mathrm{~V}$ | Outputs high |  | 26 | 42 | mA |
|  |  | Outputs low |  | 31 | 50 |  |
|  |  | Outputs disabled |  | 30 | 48 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN TYP $^{\dagger}$ MAX |  |
| ${ }^{\text {tPLH }}$ | DATA | $\bar{W}$ | 3 | ns |
| ${ }_{\text {tPHL }}$ |  |  | $2-6$ |  |
| tPLH | SELECT | $\bar{W}$ | 4 - 13 | ns |
| ${ }_{\text {tPHL }}$ |  |  | $4-10$ |  |
| tPZH | $\overline{\mathrm{G}}$ | $\bar{W}$ | $2 \quad 7$ | ns |
| tpZL |  |  | 420 |  |
| ${ }^{\text {tPHZ }}$ | $\overline{\mathrm{G}}$ | $\bar{W}$ | $2 \quad 6$ | ns |
| tPLZ |  |  | 2 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Generates Either Odd or Even Parity for Nine Data Lines
- Cascadable for n-Bits Parity
- Can Be Used to Upgrade Existing Systems Using MSI Parity Circuits
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These universal, monolithic, nine-bit parity generators/checkers utilize Advanced Schottky high-performance circuitry and feature odd and even outputs to facilitate operation of either odd or even parity application. The word-length capability is easily expanded by cascading.

These devices can be used to upgrade the performance of most systems utilizing the ' 180 parity generator/checker. Although the 'ALS280 and 'AS280 are implemented without expander inputs, the corresponding function is provided by the availability of an input at pin 4 and the absence of any internal connection at pin 3 . This permits the 'ALS280 and 'AS280 to be substituted for the '180 in existing designs to produce an identical function even if the devices are mixed with existing '180's.
All 'AS280 inputs are buffered to lower the drive requirements.

The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


NC-No internal connection

FUNCTION TABLE

| NUMBER OF INPUTS A | OUTPUTS |  |
| :---: | :---: | :---: |
|  | $\Sigma$ EVEN | $\Sigma$ ODD |
| $0,2,4,6,8$ | H | L |
| $1,3,5,7,9$ | L | H |

logic symbol ${ }^{\dagger}$


[^7]
## SN54ALS280, SN74ALS280

## 9-BIT PARITY GENERATORS/CHECKERS

logic diagram

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

$$
\text { Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V }
$$

Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V

| Operating free-air temperature range: |  |  |  |
| :---: | :---: | :---: | :---: |
|  |  |  |  |

Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  | SN54ALS280 |  |  | SN74ALS280 |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{I}^{\text {OH }}$ High-level output current |  |  | -1 |  |  | -2.6 | mA |
| $\mathrm{I}_{\text {OL }}$ Low-level output current |  |  | 12 |  |  | 24 | mA |
| $\mathrm{T}_{\text {A }}$ Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | SN54ALS280 |  |  | SN74ALS280 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {¢ }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, $\quad \mathrm{I}^{\prime}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, 1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{v}_{\mathrm{CC}}-2$ |  |  | $\mathrm{v}_{\mathrm{CC}}-2$ |  |  | V |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\text {OH }}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  |  |  |  |  |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\text {OH }}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad 1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | $\checkmark$ |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{IOL}^{2}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 1 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| ${ }_{1 / \mathrm{H}}$ | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| 1 L | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, $\quad \mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{\ddagger}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | 10 |  | 16 |  | 10 | 16 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \text { ALS280 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | 280 |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | Any | $\Sigma$ Even |  | 12 | 16 | 3 | 24 | 3 | 20 | ns |
| tPHL |  |  |  | 12 | 17 | 3 | 24 | 3 | 20 |  |
| tpLH | Any | $\Sigma$ Odd |  | 12 | 16 | 3 | 24 | 3 | 20 | ns |
| tPHL |  |  |  | 13 | 18 | 4 | 26 | 4 | 22 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## 9 -BIT PARITY GENERATORS/CHECKERS

## logic diagram


absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Operating free-air temperature range: SN54AS280 ........................... . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74AS280 . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  | SN54AS280 |  |  | SN74AS280 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{\text {CC }}$ Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ High-level input voltage | 2 |  |  | 2 |  |  | V |
| $V_{\text {IL }}$ Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| IOH High-level output current |  |  | -2 |  |  | -2 | mA |
| IOL Low-level output current |  |  | 20 |  |  | 20 | mA |
| $\mathrm{T}_{\mathrm{A}}$ Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

SN54AS280, SN74AS280 9-BIT PARITY GENERATORS/CHECKERS
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | SN54AS280 |  |  | SN74AS280 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| $V_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\prime} \mathrm{OL}=20 \mathrm{~mA}$ |  | 0.35 | 0.5 |  | 0.35 | 0.5 | V |
| I | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{\ddagger}$ | $V_{C C}=5.5 \mathrm{~V}, \quad V_{O}=2.25 \mathrm{~V}$ | $-30$ |  | -112 | -30 |  | -112 | mA |
| ${ }^{1} \mathrm{CC}$ | $V_{\text {CC }}=5.5 \mathrm{~V}$ |  | 25 | 40 |  | 25 | 35 | mA |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS280 |  | SN74AS280 |  |  |
|  |  |  | MiN | MAX | MIN | MAX |  |
| tpLH | Any | $\Sigma$ Even | 3 | 13 | 3 | 12 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 3 | 12.5 | 3 | 11 |  |
| tPLH | Any | £ Odd | 3 | 13 | 3 | 12 | ns |
| ${ }_{\text {tP }}$ |  |  | 3 | 12.5 | 3 | 11.5 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## TXPICAL APPLICATION DATA

25-LINE PARITY/GENERATOR CHECKER


Three 'ALS280/'AS280 can be used to implement a 25 -line parity generator/checker.

As an alternative, the $\Sigma$ ODD outputs of two or three parity generators/checkers can be decoded with a 2 -input ('S86 or 'LS86) or 3 -input ('S135) exclusive-OR gate for 18 - or 27 -line parity applications.

81-LINE PARITY/GENERATOR CHECKER


Longer word lengths can be implemented by cascading 'ALS280/'AS280. As shown here, parity can be generated for word lengths up to 81 bits.

- Generates Either Odd or Even Parity for Nine Data Lines
- Cascadable for n-Bits Parity
- Direct Bus Connection for Parity Generation or for Checking by Using the Parity I/O Port
- Glitch-Free Bus During Power Up/Down
- Package. Options Include both Plastic and Ceramic Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

The SN54AS286, and SN74AS286 universal nine-bit parity generators/checkers feature a local output for parity checking and a 48-milliampere bus-driving parity I/O port for parity generation/checking. The word-length capability is easily expanded by cascading.
The $\overline{\text { XMIT }}$ control input is implemented specifically to accommodate cascading. When $\overline{\text { XMIT }}$ is low the parity tree is disabled and PE will remain at a high logic level regardless of the input levels. When XMIT is high the parity tree is enabled. The Parity Error output will indicate a parity error when either an even number of inputs (A through I) are high and Parity I/O is forced to a low logic level, or when an odd number of inputs are high and Parity $1 / O$ is forced to a high logic level.

The I/O control circuitry was designed so that the I/O port will remain in the high-impedance state during power-up or power-down to prevent bus glitches.

The SN54AS286 is characterized for operation over the full military range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS286 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


NC - No internal connection



FUNCTION TABLE

| NUMBER OF INPUTS <br> (A THRU I) THAT ARE HIGH | $\overline{\text { XMIT }}$ | PARITY I/O | PARITY ERROR |
| :---: | :---: | :---: | :---: |
| 0, 2, 4, 6, 8 | I | H | H |
| 1, 3, 5, 7, 9 | 1 | L | H |
| 0,2,4,6,8 | h | h | H |
| , | h | 1 | L |
| 1,3,5,7,9 | h | h | L |
| 1,3, 5, 7, 9 | h | 1 | H |
| h - high input level <br> H - high output level | 1- low input level <br> L - low output level |  |  |

logic symbol ${ }^{\dagger}$
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for $\mathrm{D}, \mathrm{J}$, and N packages.
absolute maximum ratings over operating free-air temperature range

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |
| :---: | :---: |
| Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |
| Voltage applied to a disabled 3-state output | 5.5 V |
| Operating free-air temperature range: SN54AS286 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74AS286 | . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature | $-65^{\circ} \mathrm{C}$ to $140^{\circ} \mathrm{C}$ |

recommended operating conditions

|  |  |  | SN54AS286 |  |  | SN74AS286 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| IOH | High-level output current | Parity error |  |  | -2 |  |  | -2 | mA |
| Or | High-level output current | Parity 1/O |  |  | -12 |  |  | -15 |  |
| IOL | Low-level output current | Parity error |  |  | 20 |  |  | 20 | mA |
|  |  | Parity I/O |  |  | 32 |  |  | 48 |  |
| TA | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended free-air temperature range
(unless otherwise noted)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $1 / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS286 |  | SN74AS286 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | Any A thru I | Parity 1/O | 3 | 17 | 3 | 15 |  |
| tPHL |  |  | 3 | 15 | 3 | 14 | ns |
| tPLH | Any A thru I | Parity error | 3 | 20 | 3 | 16.5 | ns |
| tPHL |  |  | 3 | 18 | 3 | 16.5 | ns |
| tPLH | Parity I/O | Parity error | 3 | 10 | 3 | 9 | ns |
| tPHL |  |  | 3 | 10 | 3 | 9 |  |
| tPZ | $\overline{\text { XMIT }}$ | Parity 1/O | 3 | 14 | 3 | 13 | ns |
| tPZL |  |  | 3 | 17 | 3 | 16 |  |
| tPHZ |  |  | 3 | 13 | 3 | 11.5 |  |
| tPLZ |  |  | 3 | 11 | 3 | 10 |  |

NOTE 1: Load circuit and voltage waveforms ar shown in Section 1.

TYPICAL APPLICATION DATA


FIGURE 1. 32-BIT PARITY GENERATOR/CHECKER

Figure 1 shows a 32-bit parity generator/checker with output polarity-switching, parity error detection, and parity on every byte.

TYPICAL APPLICATION DATA


FIGURE 2. 90-BIT PARITY GENERATOR/CHECKER WITH PARITY ERROR DETECTION

In Figure 2, a 90-bit parity generator/checker with the XMIT on the last stage is available for use with parity detection.

- Expands 4 Address Lines to 12 Address Lines
- Designed for Paged Memory Mapping
- Output Latches Provided on 'LS610 and 'LS611
- Choice of 3-State or Open-Collector Map Outputs
- Compatible with TMS9900 and Other Microprocessors

| DEVICE | OUTPUTS <br> LATCHED | MAP <br> OUTPUT TYPE |
| :---: | :---: | :---: |
| 'LS610 | Yes | 3-State |
| 'LS611 | Yes | Open-Collector |
| 'LS612 | No | 3-State |
| 'LS613 | No | Open-Collector |

## description

Each 'LS610 through 'LS613 memory-mapper integrated circuit contains a 4 -line to 16 -line decoder, a 16 -word by 12 -bit RAM, 16 channels of 2 -line to 1 -line multiplexers, and other miscellaneous circuitry on a monolithic chip. Each 'LS610 and 'LS611 also contains 12 latches with an enable control.

The memory mappers are designed to expand a microprocessor's memory address capability by eight bits. Four bits of the memory address bus (see System Block Diagram) can be used to select one of 16 map registers that contain 12 bits each. These 12 bits are presented to the system memory address bus through the map output buffers along with the unused memory address bits from the CPU. However, addressable memory space without reloading the map registers is the same as would be available with the memory mapper left out. The addressable memory space is increased only by periodically reloading the map registers from the data bus. This configuration lends itself to memory utilization of 16 pages of $2^{(n-4)}$ registers each without reloading ( $\mathrm{n}=$ number of address bits available from CPU).


## SN54LS610 THRU SN54LS613, SN74LS610 THRU SN74LS613 MEMORY MAPPERS



## SYSTEM BLOCK DIAGRAM

These devices have four modes of operation: read, write, map, and pass. Data may be read from or loaded into the map register selected by the register select inputs (RSO thru RS3) under control of R/W whenever chip select ( $\overline{\mathrm{CS}}$ ) is low. The data I/O takes place on the data bus DO thru D7. The map operation will output the contents of the map register selected by the map address inputs (MAO thru MA3) when $\overline{\mathrm{CS}}$ is high and $\overline{M M}$ (map mode control) is low. The 'LS612 and 'LS613 output stages are transparent in this mode, while the 'LS610 and 'LS611 outputs may be transparent or latched. When $\overline{\mathrm{CS}}$ and $\overline{\mathrm{MM}}$ are both high (pass mode), the address bits on MAO thru MA3 appear at M08-M011, respectively, (assuming appropriate latch control) with low levels in the other bit positions on the map outputs.
logic diagram (positive logic)


[^8]| PIN |  | DESCRIPTION |
| :---: | :---: | :---: |
| NO. | NAME |  |
| $\begin{gathered} 7-12 \\ 29-34 \end{gathered}$ | D0 thru D11 | I/O connections to data and control bus used for reading from and writing to the map register selected by RSO-RS3 when $\overline{\mathrm{CS}}$ is low. Mode controlled by R/ $\overline{\mathrm{W}}$. |
| 36, 38, 1, 3 | RSO thru RS3 | Register select inputs for I/O operations. |
| 6 | R/W | Read or write control used in I/O operations to select the condition of the data bus. When high, the data bus outputs are active for reading the map register. When low, the data bus is used to write into the register. |
| 5 | STROBE | Strobe input used to enter data into the selected map register during I/O operations. |
| 4 | $\overline{\text { CS }}$ | Chip select input. A low input level selects the memory mapper (assuming more than one used) for an 1/O operation. |
| 35, 37, 39, 2 | MAO thru MA3 | Map address inputs to select one of 16 map registers when in map mode ( $\overline{\mathrm{MM}}$ low and $\overline{\mathrm{CS}}$ high). |
| $\begin{aligned} & \hline 14-19, \\ & 22-27 \end{aligned}$ | M00 thru MO11 | Map outputs. Present the map register contents to the system memory address bus in the map mode. In the pass mode, these outputs provide the map address data on MO8-MO11 and low levels on MOO-MO7. |
| 13 | $\overline{\mathrm{MM}}$ | Map mode input. When low, 12 bits of data are transferred from the selected map register to the map outputs. When high (pass mode), the 4 bits present on the map address inputs MAO-MA3 are passed to the map outputs MO8-MO11, respectively, while MOO-MO7 are set low. |
| 21 | $\overline{M E}$ | Map enable for the map outputs. A low level allows the outputs to be active while a high input level puts the outputs at high impedance. |
| 28 | C | Latch enable input for the 'LS610 and 'LS611 (no internal connection for 'LS612 and 'LS613). A high level will transparently pass data to the map outputs. A low level will latch the outputs. |
| 40, 20 | VCC, GND | 5 V power supply and network ground (substrate) pins. |

## SN54LS610 THRU SN54LS613, SN74LS610 THRU SN74LS613 MEMORY MAPPERS

## schematics of inputs and outputs

(NSUT/OUTPUT PORTS, DO-D11

## absolute maximum ratings over operating free-air temperature (unless otherwise noted)

| Supply voltage, VCC (see Note |  | 7 V |
| :---: | :---: | :---: |
| Input voltage: Data Bus I/O .......................................................... . 5.5 C |  |  |
| All other inputs |  | 7 |
| Operating free-air temperature range: SN54LS610 through SN54LS613 . . . . . . - $55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  |  |
|  | SN74LS610 through SN74LS613 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| rage temperature range |  |  |

NOTE 1: Voltage values are with respect to network ground terminal.

## recommended operating conditions

|  |  |  | SN54LS610 SN54LS612 |  |  | SN74LS610 <br> SN74LS612 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $V_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.7 |  |  | 0.8 | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High-level output current | MO |  |  | -12 |  |  | -15 | mA |
|  |  | D |  |  | -1 |  |  | -2.6 |  |
| ${ }^{\prime} \mathrm{OL}$ | Low-level output current | MO |  |  | 12 |  |  | 24 | mA |
|  |  | D |  |  | 4 |  |  | 8 |  |
| ${ }^{\text {t }}$ AVCL | Address setup time <br> (AV before $C$ low) 'LS610 only | See Figure 2 | 30 |  |  | 30 |  |  | ns |
| ${ }^{\text {t SLSH}}$ | Duration of strobe input pulse |  | 75 |  |  | 75 |  |  | ns |
| ${ }^{\text {t CSLSL }}$ | $\overline{\mathrm{CS}}$ setup time ( $\overline{\mathrm{CS}}$ low to strobe low) |  | 20 |  |  | 20 |  |  | ns |
| tWLSL | $\mathrm{R} / \overline{\mathrm{W}}$ setup time (R/ $/ \bar{W}$ low to strobe low) |  | 20 |  |  | 20 |  |  | ns |
| ${ }^{\text {t RVSL }}$ | RS setup time (RS valid to strobe low) |  | 20 |  |  | 20 |  |  | ns |
| ${ }^{\text {t DVSH }}$ | Data setup time (D0-D11 valid to strobe high) | See Figure 1 | 75 |  |  | 75 |  |  | ns |
| ${ }^{\text {t }}$ SHCSH | $\overline{\mathrm{CS}}$ hold time (Strobe high to $\overline{\mathrm{CS}}$ high) |  | 20 |  |  | 20 |  |  | ns |
| ${ }^{\text {t }}$ SHWH | $\bar{R} / \bar{W}$ hold time (Strobe high to $\mathrm{R} / \overline{\mathrm{W}}$ high) |  | 20 |  |  | 20 |  |  | ns |
| tSHRX | RS hold time (Strobe high to RS invalid) |  | 20 |  |  | 20 |  |  | ns |
| ${ }^{\text {t }}$ SHDX | Data hold time (Strobe high to DO-D11 invalid) |  | 20 |  |  | 20 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  |  | SN54LS610 <br> SN54LS612 |  |  | SN74LS610 <br> SN74LS612 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}, \quad \mathrm{I}=-18 \mathrm{~mA}$ |  |  |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | MO | $\begin{aligned} & V_{C C}=M I N, \\ & V_{I L}=M A X \end{aligned}$ | $V_{\mathrm{IH}}=2 \mathrm{~V},$ | $\mathrm{IOH}=-3 \mathrm{~mA}$ | 2.4 |  |  | 2.4 |  |  | v |
|  |  |  |  | $\mathrm{IOH}^{\prime}=$ MAX | 2 |  |  | 2 |  |  |  |
|  | D |  |  | $\mathrm{IOH}^{\text {O }}$ = MAX | 2.4 |  |  | 2.4 |  |  |  |
| $\mathrm{VOL}_{\mathrm{OL}}$ | MO | $\begin{aligned} & V_{C C}=M I N, \quad V_{I H}=2 V \\ & V_{I L}=M A X \end{aligned}$ |  | $\mathrm{I}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  |  |  | $\mathrm{I}^{\mathrm{OL}}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | D |  |  | $\mathrm{I}^{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  |  |  | $\mathrm{IOL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| Iozh |  | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, & \mathrm{~V}_{\mathrm{IH}}=2 \mathrm{~V}, \\ \mathrm{~V}_{\mathrm{IL}}=\mathrm{MAX}, & \mathrm{~V}_{\mathrm{O}}=2.7 \mathrm{~V} \\ \hline \end{array}$ |  |  |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| 'OZL | MO | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, & \mathrm{~V}_{\mathrm{IH}}=2 \mathrm{~V}, \\ \mathrm{~V}_{\mathrm{IL}}=\mathrm{MAX}, & \mathrm{~V}_{\mathrm{O}}=0.4 \mathrm{~V} \\ \hline \end{array}$ |  |  |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
|  | D |  |  |  |  |  | -400 |  |  | -400 |  |
| 11 | D | $V_{C C}=$ MAX |  | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | All others |  |  | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| Ith |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ILL |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=0.4 \mathrm{~V}$ |  |  |  |  | -0.4 |  |  | -0.4 | mA |
| '0s§ | MO | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}$ |  |  | -40 |  | -225 | -40 |  | -225 | mA |
|  | D |  |  | -30 |  | -130 | -30 |  | -130 |  |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}$ | Outputs high |  |  |  | 112 | 180 |  | 112 | 180 | mA |
|  |  | Outputs low |  | 112 | 180 |  | 112 | 180 |  |  |
|  |  | Outputs disabled |  | 150 | 230 |  | 180 | 230 |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=45 \mathrm{pF}$ to GND

|  | PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEST CONDITIONS | 'LS610 |  |  | 'LS612 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| tCSLDV | Access (enable) time | $\overline{\mathrm{CS}} \downarrow$ | D0.11 | $R_{L}=2 \mathrm{k} \Omega,$ <br> See Figure 1, <br> See Notes 2 and 3 |  | 28 | 50 |  | 26 | 50 | ns |
| tWHDV | Access (enable) time | $\mathrm{R} / \overline{\mathrm{W}} \uparrow$ | D0.11 |  |  | 20 | 35 |  | 20 | 35 | ns |
| trvov | Access time | RS | D0-11 |  |  | 49 | 75 |  | 39 | 75 | ns |
| tWLDZ | Disable time | R/W $\downarrow$ | D0-11 |  |  | 32 | 50 |  | 30 | 50 | ns |
| ${ }^{\text {t }}$ CSHDZ | Disable time | $\overline{\mathrm{CS}} \uparrow$ | D0-11 |  |  | 42 | 65 |  | 38 | 65 | ns |
| tELQV | Access (enable) time | $\overline{\mathrm{ME}} \downarrow$ | MOO-11 | $R_{L}=667 \Omega$ <br> See Figure 2, <br> See Notes 2 and 3 |  | 19 | 30 |  | 17 | 30 | ns |
| ${ }^{\text {t CSHOV }}$ | Access time | $\overline{\overline{C S}} \uparrow$ | MOO-11 |  |  | 56 | 85 |  | 48 | 85 | ns |
| tMLQV | Access time | $\overline{\mathrm{MM}} \downarrow$ | MO0-11 |  |  | 25 | 40 |  | 22 | 40 | ns |
| ${ }^{\text {t }} \mathrm{CHQV}$ | Access time | $\mathrm{C} \uparrow$ | MOO-11 |  |  | 24 | 40 |  |  |  | ns |
| tavQV1 | Access time ( $\overline{\mathrm{MM}}$ low) | MA | MOO-11 |  |  | 46 | 70 |  | 39 | 70 | ns |
| $\mathrm{t}_{\mathrm{MHQV}}$ | Access time | $\overline{\mathrm{MM}} \uparrow$ | MOO-11 |  |  | 24 | 40 |  | 22 | 40 | ns |
| t AVQV2 | Propagation time ( $\overline{\mathrm{MM}}$ high) | MA | MO8-11 |  |  | 19 | 30 |  | 13 | 30 | ns |
| tEHOZ | Disable time | $\overline{\mathrm{ME}} \uparrow$ | MOO-11 |  |  | 14 | 25 |  | 14 | 25 | ns |

NOTES: 2. Access times are tested as $t_{P L H}$ and $t_{P H L}$ or $t_{P Z H}$ or $t_{P Z L}$. Disable times are tested as $t_{P H Z}$ and $t_{P L Z}$.
3. Load circuits and voltage waveforms are shown in Section 1.

SN54LS611, SN54LS613, SN74LS611, SN74LS613 MEMORY MAPPERS WITH OPEN-COLLECTOR MAP OUTPUTS
recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=45 \mathrm{pF}$ to GND

|  | PARAMETER | $\begin{gathered} \text { FROM } \\ \text { INPUT) } \end{gathered}$ | TO (OUTPUT) | TEST CONDITIONS | 'LS611 |  |  | 'LS613 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| tcSLDV | Access (enable) time | $\overline{\mathrm{CS}} \downarrow$ | D0-11 | $R_{L}=2 \mathrm{k} \Omega$, See Figure 1 , See Notes 2 and 3 |  | 31 | 50 |  | 28 | 50 | ns |
| twhDV | Access (enable) 'time | $\mathrm{R} / \overline{\mathrm{W}} \uparrow$ | D0-11 |  |  | 23 | 35 |  | 21 | 35 | ns |
| trVDV | Access time | RS | D0-11 |  |  | 51 | 75 |  | 47 | 75 | ns |
| tWLDZ | Disable time | $\mathrm{R} / \overline{\mathrm{W}} \downarrow$ | D0-11 |  |  | 32 | 50 |  | 31 | 50 | ns |
| ${ }^{\text {t CSHDZ }}$ | Disable time | $\overline{\mathrm{CS}} \uparrow$ | D0-11 |  |  | 41 | 65 |  | 40 | 65 | ns |
| telov | Access (enable) time | $\overline{\text { ME }} \downarrow$ | MOO-11 | $R_{\mathrm{L}}=667 \Omega .$ <br> See Figure 2, <br> See Notes 2 and 3 |  | 21 | 30 |  | 19 | 30 | ns |
| ${ }^{\text {t CSHCOV }}$ | Access time | $\overline{\mathrm{CS}} \uparrow$ | MOO-11 |  |  | 57 | 90 |  | 53 | 90 | ns |
| ${ }^{\text {t MLQV }}$ | Access time | MM $\downarrow$ | MOO-11 |  |  | 25 | 40 |  | 25 | 40 | ns |
| ${ }^{\text {t }}$ CHOV | Access time | C $\uparrow$ | MOO-11 |  |  | 30 | 45 |  |  |  | ns |
| tavov1 | Access time (MM low) | MA | MOO-11 |  |  | 47 | 70 |  | 44 | 70 | ns |
| ${ }_{\text {m }}$ MHQV | Access time | MM ${ }^{+}$ | MOO-11 |  |  | 31 | 50 |  | 31 | 50 | ns |
| ${ }^{\text {t }} \mathrm{AVQV} 2$ | Propagation time ( $\overline{\mathrm{MM}}$ high) | MA | MO8-11 |  |  | 21 | 30 |  | 20 | 30 | ns |
| $\mathrm{t}_{\mathrm{EHO}}$ | Disable time | MET | MOO-11 |  |  | 15 | 25 |  | 15 | 25 | ns |


3. Load circuits and voltage waveforms are shown in Section 1.

## explanation of letter symbols

This data sheet uses a new type of letter symbol based on JEDEC Standard 100 to describe time intervals. The format is:

## ${ }^{t} A B-C D$

where: subscripts $A$ and $C$ indicate the names of the signals for which changes of state or level or establishment of state or level constitute signal events assumed to occur first and last, respectively, that is, at the beginning and end of the time interval.

Subscripts $B$ and $D$ indicate the direction of the transitions and/or the final states or levels of the signals represented by $A$ and $C$, respectively. One or two of the following is used:
$H=$ high or transition to high
$\mathrm{L}=$ low or transition to low
$V=$ a valid steady-state level
$X=$ unknown, changing, or "don't care" level
$Z=$ high-impedance (off) state.
The hyphen between the $B$ and $C$ subscripts is omitted when no confusion is likely to occur. For these letter symbols on this data sheet, the signal names are further abbreviated as follows:

| SIGNAL NAME | A AND C SUBSCRIPT | SIGNAL NAME | A AND C SUBSCRIPT |
| :---: | :---: | :---: | :---: |
| C | C | $\overline{\mathrm{ME}}$ | E |
| $\overline{\mathrm{CS}}$ | CS | $\overline{\mathrm{MM}}$ | M |
| DO-11 | D | R/W | W |
| MAO-MA3 | A | RSO-RS3 | R |
| MOO-MO11 | Q | STROBE | S |



## SN54LS610 THRU SN54LS613, SN74LS610 THRU SN74LS613 MEMORY MAPPERS

TIMING DIAGRAMS


FIGURE 2. MAP AND PASS MODES

- Detects and Corrects Single-Bit Errors
- Detects and Flags Dual-Bit Errors
- Built-In Diagnostic Capability
- Fast Write and Read Cycle Processing Times
- Byte-Write Capability
- Dependable Texas Instruments Quality and Reliability

| DEVICE | OUTPUT |
| :---: | :---: |
| 'ALS616 | 3-State |
| 'ALS617 | Open-Collector |

## description

The 'ALS616 and 'ALS617 are 16 -bit parallel error detection and correction circuits in 40-pin, $600-\mathrm{mil}$ packages. The EDACs use a modified Hamming code to generate a 6-bit check word from a 16 -bit data word. This check word is stored along with the data word during the memory write cycle. During memory read cycles, the 22-bit words from memory are processed by the EDACs to determine if errors have occurred in memory.

Single-bit errors in the 16 -bit data word are flagged and corrected. Single-bit errors in the 6 -bit check word are flagged, but the data word will remain unaltered. The 6-bit error syndrome code will pinpoint the error-generating location.

Dual-bit errors are flagged but not corrected. These errors may occur in any two bits of the 22 -bit word from memory. The gross-error condition of all lows or all highs from memory will be detected. Otherwise, errors in three or more bits of the 22-bit word are beyond the capabilities of these devices to detect.

Read-modify-write (byte-control) operations can be performed with the 'ALS616 and 'ALS617 EDACs by using output latch enable, LEDBO, and individual $\overline{\mathrm{OE}} \mathrm{B} 0$ and $\overline{\mathrm{OEB}} 1$ byte control pins.
. Diagnostics are performed on the EDACs by controls and internal paths that allow the user to read the contents of the DB and CB input latches. These will determine if the failure occurred in memory or in the EDAC.

SN54ALS616, SN54ALS617 . . . JD PACKAGE SN74ALS616, SN74ALS617 . . . JD OR N PACKAGE (TOP VIEW)


SN74ALS616, SN74ALS617 . . . FN PACKAGE (TOP VIEW)


NC - No internal connection

The SN54ALS616 and SN54ALS617 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS616 and SN74ALS617 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## SN54ALS616, SN54ALS617, SN74ALS616, SN74ALS617 <br> 16-bIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

TABLE 1. WRITE CONTROL FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | $\begin{array}{\|c} \|c\| c N T R O L \\ \text { S1 So } \end{array}$ | DATA I/O | DB CONTROL <br> $\overline{\mathrm{OEB}} 0$ \& $\overline{\mathrm{OEB}} 1$ | DB OUTPUT LATCH LEDBO | CHECK 1/O | $\begin{gathered} \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \end{gathered}$ | ERROR FLAGS $\overline{E R R} \overline{M E R R}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Write | Generate check word | L L | Input | H | X | Output check bits ${ }^{\dagger}$ | L | $\mathrm{H} \quad \mathrm{H}$ |

tsee Table 2 for details on check bit generation.

## memory write cycle details

During a memory write cycle, the check bits (CBO thru CB5) are generated internally in the EDAC by six 8 -input parity generators using the 16 -bit data word as defined in Table 2. These six check bits are stored in memory along with the original 16 -bit data word. This 22 -bit word will later be used in the memory read cycle for error detection and correction.

TABLE 2. PARITY ALGORITHM

| CHECK WORD BIT | 16-BIT DATA WORD |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| CBO |  |  | X |  | X | X | X |  |  | X |  |  | X |  | X | X |
| CB1 |  | X |  | X |  | X | X | X |  |  |  | X |  | X |  | x |
| CB2 | X |  |  | X | $x$ |  |  | X | $x$ |  | $x$ |  |  | X | x |  |
| CB3 | X | x | $x$ |  |  |  | x | X |  |  | x | x | $x$ |  |  |  |
| CB4 | x | x | x | $x$ | x | x |  |  | $x$ | $x$ |  |  |  |  |  |  |
| CB5 |  |  |  |  |  |  |  |  | x | x | x | x | x | x | x | x |

The six check bits are parity bits derived from the matrix of data bits as indicated by " $X$ " for each bit.

## error detection and correction details

During a memory read cycle, the 6 -bit check word is retrieved along with the actual data. In order to be able to determine whether the data from memory is acceptable to use as presented to the bus, the error flags must be tested to determine if they are at the high level.

The first case in Table 3 represents the normal, no-error conditions. The EDAC presents highs on both flags. The next two cases of single-bit errors give a high on MERR and a low on ERR, which is the signal for a correctable error, and the EDAC should be sent through the correction cycle. The last three cases of double-bit errors will cause the EDAC to signal lows on both $\overline{\text { ERR }}$ and $\overline{\text { MERR }}$, which is the interrupt indication for the CPU.

TABLE 3. ERROR FUNCTION

| TOTAL NUMBER OF ERRORS |  | ERROR FLAGS |  | DATA CORRECTION |
| :---: | :---: | :---: | :---: | :---: |
| 16-BIT DATA WORD | 6-BIT CHECK WORD | ERR | $\overline{\text { MERR }}$ |  |
| 0 | 0 | H | H | Not applicable |
| 1 | 0 | L | H | Correction |
| 0 | 1 | L | H | Correction |
| 1 | 1 | L | L | Interrupt |
| 2 | 0 | L | L | Interrupt |
| 0 | 2 | L | L | Interrupt |

## SN54ALS616, SN54ALS617, SN74ALS616, SN74ALS617 16-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

| MEMORY CYCLE | EDAC FUNCTION | $\begin{gathered} \text { CON } \\ \text { S1 } \end{gathered}$ |  | DATA I/O | DB CONTROL <br> $\overline{\mathrm{OEBO}}$ \& $\overline{\mathrm{OEB}} 1$ | DB OUTPUT LATCH LEDBO | CHECK 1/O | $\begin{gathered} \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \\ \hline \end{gathered}$ | ERROR FLAGS ERR MERR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& flag | H | L | Input | H | X | Input | H | Enabled ${ }^{\dagger}$ |
| Read | Latch input data \& check bits | H | H | Latched input data | H | L | Latched input check word | H | Enabled ${ }^{\dagger}$ |
| Read | Output corrected data and syndrome bits | H | H | Output corrected data word | L | X | Output syndrome bits ${ }^{\ddagger}$ | L | Enabled ${ }^{\dagger}$ |

${ }^{\dagger}$ See Table 3 for error description.
$\ddagger$ See Table 5 for error location.
Error detection is accomplished as the 6-bit check word and the 16 -bit data word from memory are applied to the internal parity generators/checkers. If the parity of all six groupings of data and check bits are correct, it is assumed that no error has occurred and both error flags will be high.

If the parity of one or more of the check groups is incorrect, an error has occurred and the proper error flag or flags will be set low. The two-bit error is not correctable since the parity tree can only identify single-bit errors. Both error flags are set low when any two-bit error is detected.

Three or more simultaneous bit errors can cause the EDAC to believe that no error, a correctable error, or an uncorrectable error has occurred and will produce erroneous results in all three cases. It should be noted that the gross-error conditions of all highs will be detected.

As the corrected word is made available on the data I/O port (DBO thru DB15), the check word I/O port (CB0 thru CB5) presents a 6-bit syndrome error code. This syndrome code can be used to locate the bad memory chip. See Table 5 for syndrome decoding.

TABLE 5. SYNDROME DECODING

| SYNDROME BITS |  | ERROR |
| :---: | :---: | :---: |
|  | $\begin{array}{lllllll}5 & 4 & 3 & 2 & 1 & 0\end{array}$ |  |
|  | L L L L L L | 2-bit |
|  | L L L. L L H | unc |
|  | L L L L H L | unc |
|  | L L L L H H | 2-bit |
|  | L L L H L L | unc |
|  | L L L H L H | 2-bit |
|  | L L L H H L | 2-bit |
|  | L L L H H H | unc |
|  | $L$ L H L L L | unc |
|  | L L H L L | 2-bit |
|  | L L H L H L | 2-bit |
|  | L L H L H H | D87 |
|  | L L H H L L | 2-bit |
|  | L L H H L H | unc |
|  | L L H H H L | DB6 |
|  | L L H H H H | 2-bit |


| SYNDROME BITS | ERROR |
| :---: | :---: |
| $\begin{array}{llllllll}5 & 4 & 3 & 2 & 1 & 0\end{array}$ |  |
| L H L L L L | unc |
| L H L L L H | 2-bit |
| L H L L H L | 2-bit |
| L H L L H H | DB5 |
| L H L H L.L | 2-bit |
| L H L H L H | DB4 |
| L H L H H L | DB3 |
| L H L H H H | 2-bit |
| L H H L L L | 2-bit |
| L H H L L H | DB2 |
| L H H L H L | DB1 |
| L H H L H H | 2-bit |
| L H H H L L | DBO |
| L H H H L H | 2-bit |
| L H H H H L | 2-bit |
|  | CB5 |



| SYNDORME BITS |  |  |  |  |  |  | ERROR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 5 | 4 | 3 | 32 | 2 | 1 | 0 |  |
| H | H | L | L | L | L | L | 2-bit |
| H | H | L | L L | L | L | H | D88 |
| H | H | L | L | $L$ | H | L | unc |
| H | H | L | L | L | H | H | 2-bit |
| H | H | H | L | H | $L$ |  | DB9 |
| H | H | L | L | H | L |  | 2-bit |
| H | H | H | L | H | H | L | 2-bit |
| H | H | H | L | H | H |  | CB3 |
| H | H | H | H | L | L | L | unc |
| H | H | H | H | L | L |  | 2-bit |
| H | H | H | H | L | H |  | 2-bit |
| H | H | H | H | L | H |  | CB2 |
| H | H | H | H | H | L |  | 2-bit |
| H | H | H | H | H | L |  | CB1 |
| H | H | H |  | H | H |  | CBO |
| H | H | 4 H | H | H | H |  | none |

CB $X=$ error in check bit $X$
DB $Y=$ error in data bit $Y$
2-bit $=$ double-bit error
unc $=$ uncorrectable multibit error

## read-modify-write (byte control) operations

The 'ALS616 and 'ALS617 devices are capable of byte-write operations. The 22-bit word from memory must first be latched into the DB and CB input latches. This is easily accomplished by switching from the read and flag mode ( $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}$ ) to the latch input mode ( $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{H}$ ). The EDAC will then make any corrections, if necessary, to the data word and place it at the input of the output data latch. This data word must then be latched into the output data latch by taking $\overline{\mathrm{LEDBO}}$ from a low to a high.
Byte control can now be employed on the data word through the $\overline{\mathrm{OEB}} 0$ or $\overline{\mathrm{OEB}} 1$ controls. $\overline{\mathrm{OEB}} 0$ controls DBO-DB7 (byte 0), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (byte 1).

Placing a high on the byte control will disable the output and the user can modify the byte. If a low is placed on the byte control, then the original byte is allowed to pass onto the data bus unchanged. If the original data word is altered through byte control, a new check word must be generated before it is written back into memory. This is easily accomplished by taking control S1 and SO low. Table 6 lists the read-modify-write functions.

# SN54ALS616, SN54ALS617, SN74ALS616, SN74ALS617 16-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS 

TABLE 6. READ-MODIFY-WRITE FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | $\begin{gathered} \text { CONTROL } \\ \text { S1 So } \end{gathered}$ |  | BYTEn ${ }^{\dagger}$ | $\overline{\mathrm{OEB}} \mathrm{n}^{\dagger}$ | DB OUTPUT <br> LATCH <br> LEDBO | CHECK 1/0 | CB CONTROL | ERROR FLAG <br> $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& Flag | H | L | Input | H | X | Input | H | Enabled |
| Read | Latch input data <br> \& check bits | H | H | Latched Input data | H | L | Latched input check word | H | Enabled |
| Read | Latch corrected data word into output latch | H | H | Latched <br> output <br> data <br> word | H | H | $\begin{gathered} -\frac{\mathrm{Hi}-\mathrm{Z}}{\mathrm{Out}}-1 \\ \text { Syndrome } \\ \text { bits } \end{gathered}$ | $-\frac{\mathrm{H}}{\mathrm{~L}}-$ | Enabled |
| Modifyl write | Modify appropriate byte or bytes \& generate new check word | L | L | Input <br> modified <br> $-\frac{\text { BYTEO }}{}$ <br> Output <br> unchanged <br> BYTEO |  | H | Output check word | L | H H |

$\dagger$ $\dagger \overline{\mathrm{EBB}} 0$ controls DB0-DB7 (BYTEO), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (BYTE1)

| EDAC FUNCTION | $\begin{gathered} \text { CONTROL } \\ \text { S1 S0 } \end{gathered}$ | DATA I/O | $\begin{gathered} \hline \text { DB BYTE } \\ \text { CONTROL } \\ \overline{\text { OEBn }} \end{gathered}$ | DB OUTPUT <br> LATCH <br> LEDBO | CHECK I/O | CB CONTROL $\overline{\text { OECB }}$ | ERROR FLAGS  <br> ERR $\overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read \& flag | H L | Input correct data word | H | X | Input correct check bits | H | H H |
| Latch input check word while data input latch remains transparent | L H | Input <br> diagnostic data word ${ }^{\dagger}$ | H | L | Latched input check bits | H | Enabled |
| Latch diagnostic data word into output latch | L H | Input diagnostic data word ${ }^{\dagger}$ | H | H | Output latched check bits $-\mathrm{Hi} \overline{\mathrm{Z}}$ | $-\frac{\mathrm{L}}{\mathrm{H}}$ | Enabled |
| Latch diagnostic data word into input latch | H H | Latched input diagnostic data word | H | H | Output syndrome bits - - | $\begin{array}{r} L \\ - \\ \hline \end{array}$ | Enabled |
| Output diagnostic data word \& syndrome bits | H H | Output diagnostic data word | L | H | Output syndrome $-\quad \text { bits }$ | $\begin{array}{r} \mathrm{L} \\ - \\ \hline \end{array}$ | Enabled |
| Output corrected diagnostic data word \& output syndrome bits | H H | Output corrected diagnostic data word | L | L | Output syndrome $\frac{\text { bits }}{\text { Hi-Z }}-\text {. }$ | $\begin{gathered} \mathrm{L} \\ \mathrm{H}_{\mathrm{H}}- \end{gathered}$ | Enabled |

${ }^{\dagger}$ Diagnostic data is a data word with an error in one bit location except when testing the $\overline{\mathrm{MERR}}$ error flag. In this case, the diagnostic data word will contain errors in two bit locations.
logic diagram (positive logic)


[^9]
## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, $V_{C C}$ (see Note 1) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage: CB and DB . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
All others. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Operating case temperature range SN54ALS616, SN54ALS617, ......... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Operating free-air temperature range, SN74ALS616, SN74ALS617 . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

these times ensure that corrected data is saved in the output data latch.
$\ddagger$ These times ensure that the diagnostic data word is saved in the output data latch. 16-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS
'ALS616 electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS616 |  |  | SN74ALS616 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{VOH}^{\text {O }}$ | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V} .1 \mathrm{l} \mathrm{IOH}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\text {CC }}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | DB or CB | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\text {OL }}$ | $\overline{\text { ERR }}$ or $\overline{M E R R}$ | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 4 | S0 or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | DB or CB | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| ${ }^{1 / H}$ | S0 or S1 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | DB or $\mathrm{CB}^{\ddagger}$ |  |  |  |  | 20 |  |  | 20 |  |
| IIL | S0 or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
|  | DB or $\mathrm{CB}^{\ddagger}$ |  |  |  |  | -0.1 |  |  | -0.1 |  |
| 10§ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | See Note 1 |  | 110 | 190 |  | 110 | 170 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, Ios. NOTE 1: ICC is measured with SO and S1 at 4.5 V and all CB and DB pins grounded.
${ }^{\prime}$ ALS616 switching characteristics, $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T} \mathrm{C}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS616, $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS616

| PARAMETER | FROM IINPUT) | то (OUTPUT) | TEST CONDITIONS | SN54ALS616 |  | SN74ALS616 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | ERR | $\mathrm{S} 1=\mathrm{H}, \mathrm{S} 0=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 | ns |
|  | DB | ERR | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { MERR }}$ | S $1=H, S 0=L, R_{L}=500 \Omega$ | 15 | 65 | 15 | 55 | ns |
|  | DB | $\overline{\mathrm{MERR}}$ | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 65 | 15 | 55 |  |
| ${ }^{\text {t }}$ d | SO $\downarrow$ and S1 $\downarrow$ | CB | $\mathrm{R} 1=\mathrm{R} 2=500 \mathrm{R}$. | 10 | 60 | 10 | 49 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{L}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 60 | 10 | 49 | ns |
| ${ }^{\text {tpd }}$ | LEDBŌ। | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{S} 0=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 7 | 35 | 7 | 30 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | S1ヶ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 50 | 10 | 50 | ns |
| ten | $\overline{\text { OECB }} \downarrow$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 27 | ns |
| $\mathrm{t}_{\text {dis }}$ | $\overline{\text { OECB }} \uparrow$ | CB | SO $=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 27 | ns |
| ten | $\overline{\mathrm{OEB}} 0$ and $\overline{\mathrm{OEB}} 1 \downarrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 27 | ns |
| $t_{\text {dis }}$ | $\overline{\mathrm{OEB}} 0$ and $\overline{\mathrm{OEB}} 1 \uparrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 27 | ns |

## SN54ALS617, SN74ALS617 <br> 16-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

'ALS617 electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS617 |  |  | SN74ALS617 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $V_{\text {IK }}$ |  |  |  | $V_{C C}=4.5 \mathrm{~V}$, | $1 / 18 \mathrm{~mA}$ |  |  | - 1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\overline{\text { ERR }}$ or $\overline{\text { MERR }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $V_{C C}-2$ |  |  | $V_{C C}-2$ |  |  | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | DB or CB | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\mathrm{OL}}$ | $\overline{\text { ERR }}$ or $\overline{M E R R}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | ${ }^{\mathrm{I}} \mathrm{OH}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| I | S0 or S1 | $V_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| I | DB or CB | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
|  | S0 or S1 | $V_{C C}=5.5 \mathrm{~V}$, | $V_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ${ }_{1 / \mathrm{H}}$ | DB or $\mathrm{CB}^{\ddagger}$ |  |  |  |  | 20 |  |  | 20 |  |
| IIL | S0 or S1 | $V_{C C}=5.5 \mathrm{~V}, \quad V_{1}=0.4 \mathrm{~V}$ |  |  |  | -0.4 |  |  | -0.4 | mA |
|  | DB or $\mathrm{CB}^{\ddagger}$ |  |  |  |  | -0.1 |  |  | -0.1 |  |
| $1 \mathrm{O}^{\text {§ }}$ | $\overline{\text { ERR }}$ or $\overline{\text { MERR }}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | $-30$ |  | - 112 | -30 |  | -112 | mA |
| ${ }^{\text {ICC }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | See Note 1 | 110 |  |  | 110 |  |  | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ For $1 / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
$\S$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS. NOTE 1: ICC is measured with SO and S1 at 4.5 V and all CB and DB pins grounded.
'ALS617 switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS617, $\mathrm{TA}_{A}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS617

| PARAMETER | FROM <br> (INPUT) | TO (OUTPUT) | TEST CONDITIONS | SN54ALS617 |  |  | SN74ALS617 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| ${ }^{\text {p }}$ d | DB and CB | ERR | $S 1=H, S 0=L, R_{L}=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
|  | DB | ERR | $S 1=L, S 0=H, R_{L}=500 \Omega$ |  | 26 |  |  | 26 |  |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { MERR }}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 40 |  |  | 40 |  | ns |
|  |  |  | S1 = L, $\mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 40 |  |  | 40 |  |  |
| ${ }^{\text {t }}$ pd | S0 $\downarrow$ and S1 $\downarrow$ | CB | $\mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| ${ }_{\text {t }}{ }^{\text {d }}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| ${ }^{\text {p }}$ d | $\overline{\text { LEDBO }} \downarrow$ | DB | $S 1=X, S 0=H, R_{L}=680 \Omega$ |  | 26 |  |  | 26 |  | ns |
| ${ }^{\text {tpd }}$ | S11 | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| tPLH | $\overline{\mathrm{OECB}} \uparrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| tPHL | $\overline{\mathrm{OECB}} \downarrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{S0}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| tPLH , | $\overline{\mathrm{OEBO}}$ and $\overline{\mathrm{OEB}} 1 \uparrow$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{S} 0=H, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| ${ }^{\text {t PHL }}$ | $\overline{\mathrm{OEBO}}$ and $\overline{\mathrm{OEB}} 1 \downarrow$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
Additional information on these products can be obtained from the factory as it becomes available.


FIGURE 1. READ, FLAG, AND CORRECT MODE SWITCHING WAVEFORMS


FIGURE 2. READ, CORRECT, MODIFY MODE SWITCHING WAVEFORMS


FIGURE 3. DIAGNOSTIC MODE SWITCHING WAVEFORM

## SN54ALS632A, SN54ALS633 THRU SN54ALS635 <br> SN74ALS632A, SN74ALS633 THRU SN74ALS635 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

D2661, DECEMBER 1982-REVISED DECEMBER 1985

- Detects and Corrects Single-Bit Errors
- Detects and Flags Dual-Bit Errors
- Built-In Diagnostic Capability
- Fast Write and Read Cycle Processing Times
- Byte-Write Capability . . . 'ALS632A and 'ALS633
- Dependable Texas Instruments Quality and Reliability

| DEVICE | PACKAGE | BYTE-WRITE | OUTPUT |
| :--- | :---: | :---: | :---: |
| ALS632A | 52 -pin | yes | 3-State |
| 'ALS633 | 52 -pin | yes | Open-Collector |
| 'ALS634 | 48 -pin | no | 3-State |
| 'ALS635 | $48-$ pin | no | Open-Collector |

## description

The 'ALS632A and 'ALS633 through 'ALS635 devices are 32-bit parallel error detection and correction circuits (EDACs) in 52-pin ('ALS632A and 'ALS633) or 48-pin ('ALS634 and 'ALS635) 600-mil packages. The EDACs use a modified Hamming code to generate a 7 -bit check word from a 32-bit data word. This check word is stored along with the data word during the memory write cycle. During the memory read cycle, the 39-bit words from memory are processed by the EDACs to determine if errors have occurred in memory.

Single-bit errors in the 32 -bit data word are flagged and corrected.
Single-bit errors in the 7-bit check word are flagged, and the CPU sends the EDAC through the correction cycle even though the 32-bit data word is not in error. The correction cycle will simply pass along the original 32 -bit data word in this case and produce error syndrome bits to pinpoint the error-generating location.

Dual-bit errors are flagged but not corrected. These errors may occur in any two bits of the 39-bit data word from memory (two errors in the 32-bit data word, two errors in the 7-bit check word, or one error in each word). The gross-error condition of all lows or all highs from memory will be detected. Otherwise, errors in three or more bits of the 39-bit word are beyond the capabilities of these devices to detect.
'ALS632A. 'ALS633 . . . JD PACKAGE
(TOP VIEW)

| LEDBO | 1 | 52 | $\square^{\prime} \mathrm{Cc}$ |
| :---: | :---: | :---: | :---: |
| MERR | 2 | 51 | ]s1 |
| ERR | 3 | 50 | 7So |
| DBO | 4 | 49 | 万0B31 |
| DB1 | 5 | 48 | 7DB30 |
| DB2 | 6 | 47 | - ${ }^{\text {¢ }}$ 29 |
| DB3 | 7 | 46 | ]DB28 |
| DB4 | 8 | 45 | -DB27 |
| DB5 | 9 | 44 | Поb26 |
| OEB0 | 10 | 43 | - $\overline{O E B} 3$ |
| DB6 | 11 | 42 | ДDB25 |
| DB7 | 12 | 41 | ]DB24 |
| GND | 13 | 40 | ]GND |
| DB8 | 14 | 39 | -DB23 |
| D89 | 15 | 38 | ПDB22 |
| ОEB1 | 16 | 37 | $\square \overline{O E B} 2$ |
| DB10 | 17 | 36 | -DB21 |
| DB11 | 18 | 35 | 70B20 |
| DB12 | 19 | 34 | ]DB19 |
| DB13 | 20 | 33 | -DB18 |
| DB14 | 21 | 32 | ПDB17 |
| DB15 | 22 | 31 | Дов16 |
| CB6 | 23 | 30 | $\square$ ¢во |
| CB5 | 24 | 29 | -CB1 |
| CB4 | 25 | 28 | -cb2 |
| $\overline{O E C B}$ | 26 | 27 | Псв3 |

'ALS632A, 'ALS633 . . . FN PACKAGE (TOP VIEW)


NC - No internal connection

Read-modify-write (byte-control) operations can be performed with the 'ALS632A and 'ALS633 EDACs by using output latch enable, $\overline{\mathrm{LEDBO}}$, and the individual $\overline{\mathrm{OEB} O}$ thru $\overline{\mathrm{OEB}} 3$ byte control pins.

Diagnostics are performed on the EDACs by controls and internal paths that allow the user to read the contents of the DB and CB input latches. These will determine if the failure occurred in memory or in the EDAC.
'ALS634, 'ALS635 . . . JD PACKAGE
(TOP VIEW)

| MERR 1 | $1 \mathrm{O}_{48}$ | $V_{C C}$ |
| :---: | :---: | :---: |
| ERR [2 | 247 | S1 |
| DBO $\square^{3}$ | $3 \quad 46$ | So |
| DB1 $4_{4}^{4}$ | $4 \quad 45$ | -DB31 |
| DB2 5 | 544 | - di30 $^{\text {a }}$ |
| D83 6 | 643 | Прв29 |
| DB4 7 | $7 \quad 42$ | D828 |
| DB5 8 | $8 \quad 41$ | ]B27 |
| $\overline{\text { OEDB } 9}$ | $9 \quad 40$ | DB26 |
| DB6 10 | $10 \quad 39$ | - ${ }^{\text {d } 25}$ |
| DB7 ${ }^{11}$ | 1138 | $7 \mathrm{DB24}$ |
| GND 12 | $12 \quad 37$ | GND |
| DB8 13 | $13 \quad 36$ | -dB23 |
| DB9 14 | $14 \quad 35$ | - ${ }^{\text {d }} 22$ |
| DB10 15 | $15 \quad 34$ | ]D821 |
| DB11 16 | $16 \quad 33$ | DB20 |
| DB12 17 | $17 \quad 32$ | DB19 |
| DB13 18 | $18 \quad 31$ | -DB18 |
| DB14 19 | 1930 | D DB17 |
| DB15 20 | $20 \quad 29$ | DB16 |
| CB6 21 | $21 \cdot 28$ | $\square$ сво |
| CB5 22 | $22 \quad 27$ | - CB 1 |
| CB4 23 | $23 \quad 26$ | - CB 2 |
| ОЕСВ 24 | $24 \quad 25$ | -cb3 |

'ALS634, 'ALS635 . . . FN PACKAGE
(TOP VIEW)


NC-No internal connection

TABLE 1. WRITE CONTROL FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | CONTROL S1 S0 | DATA I/O | $\begin{gathered} \text { DB CONTROL } \\ \overline{\text { OEBn OR }} \\ \overline{\text { OEDB }} \end{gathered}$ | $\begin{gathered} \text { DB OUTPUT LATCH } \\ \text { ('ALS632A, 'ALS633) } \\ \overline{\text { LEDBO }} \end{gathered}$ | CHECK I/O | $\begin{array}{\|c\|} \hline \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \\ \hline \end{array}$ | ERROR FLAGS <br> $\overline{\text { ERR }}$ <br> MERR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Write | Generate check word | L L | Input | H | X | Output check bits $\dagger$ | L | H H |

${ }^{\dagger}$ See Table 2 for details on check bit generation.

## memory write cycle details

During a memory write cycle, the check bits (CBO thru CB6) are generated internally in the EDAC by seven 16 -input parity generators using the 32 -bit data word as defined in Table 2. These seven check bits are stored in memory along with the original 32-bit data word. This 32-bit word will later be used in the memory read cycle for error detection and correction.

## SN54ALS632A, SN54ALS633 THRU SN54ALS635 <br> SN74ALS632A, SN74ALS633 THRU SN74ALS635 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS



The seven check bits are parity bits derived from the matrix of data bits as indicated by " X " for each bit.

## error detection and correction details

During a memory read cycle, the 7 -bit check word is retrieved along with the actual data. In order to be able to determine whether the data from memory is acceptable to use as presented to the bus, the error flags must be tested to determine if they are at the high level.

The first case in Table 3 represents the normal, no-error conditions. The EDAC presents highs on both flags. The next two cases of single-bit errors give a high on $\overline{M E R R}$ and a low on ERR, which is the signal for a correctable error, and the EDAC should be sent through the correction cycle. The last three cases of double-bit errors will cause the EDAC to signal lows on both $\overline{\operatorname{ERR}}$ and $\overline{\mathrm{MERR}}$, which is the interrupt indication for the CPU.

TABLE 3. ERROR FUNCTION

| TOTAL NUMBER OF ERRORS |  | ERROR FLAGS |  | (ATA CORRECTION |
| :---: | :---: | :---: | :---: | :---: |
| 32-BIT DATA WORD | 7-BIT CHECK WORD | ERR | $\overline{\text { MERR }}$ |  |
| 0 | 0 | HAT | H | Not applicable |
| 1 | 0 | L | H | Correction |
| 0 | 1 | L | H | Correction |
| 1 | 1 | L | L | Interrupt |
| 2 | 0 | L | L | Interrupt |
| 0 | 2 | L | L | Interrupt |

Error detection is accomplished as the 7-bit. check word and the 32-bit data word from memory are applied to internal parity generators/checkers. If the parity of all seven groupings of data and check bits are correct, it is assumed that no error has occurred and both error flags will be high.

If the parity of one or more of the check groups is incorrect, an error has occurred and the proper error flag or flags will be set low. Any single error in the 32-bit data word will change the state of either three or five bits of the 7-bit check word. Any single error in the 7-bit check word changes the state of only that one bit. In either case, the single error flag ( $\overline{\mathrm{ERR}})$ will be set low while the dual error flag ( $\overline{\mathrm{MERR}}$ ) will remain high.

Any two-bit error will change the state of an even number of check bits. The two-bit error is not correctable since the parity tree can only identify single-bit errors. Both error flags are set low when any two-bit error is detected.

Three or more simultaneous bit errors can cause the EDAC to believe that no error, a correctable error, or an uncorrectable error has occurred and will produce erroneous results in all three cases. It should be noted that the gross-error conditions of all lows and all highs will be detected.

## SN54ALS632A, SN54ALS633 THRU SN54ALS635

## SN74ALS632A, SN74ALS633 THRU SN74ALS635

 32-bit Parallel error detection and correction circuitsTABLE 4. READ, FLAG, AND CORRECT FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | $\begin{array}{\|c} \mid C O N \\ \text { S1 } \end{array}$ |  | DATA I/O | $\begin{array}{\|c\|} \hline \text { DB CONTROL } \\ \overline{\text { OEBn OR }} \\ \overline{\text { OEDB }} \\ \hline \end{array}$ | $\begin{gathered} \text { DB OUTPUT LATCH } \\ \text { ('ALS632A, 'ALS633) } \\ \overline{\text { LEDBO }} \end{gathered}$ | CHECK I/O | $\begin{array}{\|c\|} \hline \text { CB } \\ \text { CONTROL } \\ \hline \overline{\mathrm{OECB}} \\ \hline \end{array}$ | ERROR FLAGS $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& flag | H | L | Input | H | X | Input | H | Enabledt |
| Read | Latch input data \& check bits | H | H | Latched input data | H | L | Latched input check word | H | Enabled $\dagger$ |
| Read | Output corrected data \& syndrome bits | H | H | Output corrected data word | L | X | Output syndrome bits $\ddagger$ | L | Enabled $\dagger$ |

$\dagger$ See Table 3 for error description.
$\ddagger$ See Table 5 for error location.

As the corrected word is made available on the data I/O port (DBO thru DB31), the check word I/O port (CBO thru CB6) presents a 7-bit syndrome error code. This syndrome error code can be used to locate the bad memory chip. See Table 5 for syndrome decoding.

> SN54ALS632A, SN54ALS633 THRU SN54ALS635 SN74ALS632A, SN74ALS633 THRU SN74ALS635 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS


CB $X=$ error in check bit $X$
DB $Y=$ error in data bit $Y$
2-bit $=$ double-bit error
unc $=$ uncorrectable multibit error

## read-modify-write (byte control) operations

The 'ALS632A and 'ALS633 devices are capable of byte-write operations. The 39-bit word from memory must first be latched into the DB and CB input latches. This is easily accomplished by switching from the read and flag mode ( $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}$ ) to the latch input mode $(\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{H})$. The EDAC will then make any corrections, if necessary, to the data word and place it at the input of the output data latch: This data word must then be latched into the output data latch by taking $\overline{\text { LEDBO }}$ from a low to a high.
Byte control can now be employed on the data word through the $\overline{\mathrm{OEBO}}$ through $\overline{\mathrm{OEB}} 3$ controls. $\overline{\mathrm{OEBO}}$ controls DBO-DB7 (byte 0), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (byte 1), $\overline{\mathrm{OEB}} 2$ controls DB16-DB23 (byte 2), and $\overline{\mathrm{OEB}} 3$ controls DB24-DB31 (byte 3). Placing a high on the byte control will disable the output and the user can modify the byte. If a low is placed on the byte control, then the original byte is allowed to pass onto the data bus unchanged. If the original data word is altered through byte control, a new check word must be generated before it is written back into memory. This is easily accomplished by taking control S1 and SO low. Table 6 lists the read-modify-write functions.

TABLE 6. READ-MODIFY-WRITE FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | $\begin{gathered} \text { CONT } \\ \text { S1 } \end{gathered}$ |  | BYTEn $\dagger$ | $\overline{\text { OEB }} \boldsymbol{\square} \dagger$ | $\begin{gathered} \hline \text { DB OUTPUT } \\ \text { LATCH } \\ \overline{\text { LEDBO }} \\ \hline \end{gathered}$ | CHECK I/O | CB CONTROL | ERROR FLAG <br> $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& Flag | H | L | Input | H | $\times$ | Input | H | Enabled |
| Read | Latch input data <br> \& check bits | H | H | Latched Input data | H | L | Latched input check word | H | Enabled |
| Read | Latch corrected data word into output latch | H | H | Latched <br> output <br> data <br> word | H | H | $\mathrm{Hi}-2$ <br> Output <br> Syndrome <br> bits | H L | Enabled |
| Modify /write | Modify appropriate byte or bytes \& generate new check word | L | L | Input <br> modified <br> BYTEO <br> Output <br> unchanged <br> BYTEO | $\begin{gathered} \mathrm{H} \\ \hline \end{gathered}$ | H | Output check word | L | H H |

$\dagger \overline{\mathrm{OEB}}$ controls DBO-DB7 (BYTEO), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (BYTE1), $\overline{\mathrm{OEB}} 3$ controls DB16-DB23 (BYTE2), $\overline{\mathrm{OEB}} 3$ controls DB24-DB31 (BYTE3).

## diagnostic operations

The 'ALS632A and 'ALS633 thru 'ALS635 are capable of diagnostics that allow the user to determine whether the EDAC or the memory is failing. The diagnostic function tables will help the user to see the possibilities for diagnostic control.

In the diagnostic mode ( $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}$ ), the checkword is latched into the input latch while the data input latch remains transparent. This lets the user apply various data words against a fixed known checkword. If the user applies a diagnostic data word with an error in any bit location, the $\overline{E R R}$ flag should be low. If a diagnostic data word with two errors in any bit location is applied, the $\overline{M E R R}$ flag should be low. After the checkword is latched into the input latch, it can be verified by taking $\overline{\mathrm{OECB}}$ low. This outputs the latched checkword. With the 'ALS632A and 'ALS633, the diagnostic data word can be latched into the output data latch and verified. It should be noted that the 'ALS634 and 'ALS635 do not have this pass-through capability because they do not contain an output data latch. By changing from the diagnostic mode $(S 1=L, S 0=H)$ to the correction mode $(S 1=H, S 0=H)$, the user can verify that the EDAC will correct the diagnostic data word. Also, the syndrome bits can be produced to verify that the EDAC pinpoints the error location. Table 7 ('ALS632A and 'ALS633) and Table 8 ('ALS634 and 'ALS635) list the diagnostic functions.

# SN54ALS632A, SN54ALS633 THRU SN54ALS635 <br> SN74ALS632A, SN74ALS633 THRU SN74ALS635 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS 

TABLE 7. 'ALS632A, 'ALS633 DIAGNOSTIC FUNCTION

| EDAC FUNCTION | $\begin{gathered} \text { CONTROL } \\ \text { S1 s0 } \end{gathered}$ | DATA I/O | $\begin{gathered} \hline \text { DB BYTE } \\ \text { CONTROL } \\ \overline{\mathrm{OEB}} \mathrm{n} \\ \hline \end{gathered}$ | $\begin{gathered} \hline \text { DB OUTPUT } \\ \text { LATCH } \\ \overline{\text { LEDBO }} \end{gathered}$ | CHECK I/O | $\begin{gathered} \mathrm{CB} \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \\ \hline \end{gathered}$ | ERROR FLAGS $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read \& flag | H L | Input correct data word | H | X | Input correct check bits | H | $\mathrm{H} \quad \mathrm{H}$ |
| Latch input check word while data input latch remains transparent | L H | Input diagnostic data word ${ }^{\dagger}$ | H | L | Latched input check bits | H | Enabled |
| Latch diagnostic data word into output latch | L H | Input diagnostic data word ${ }^{\dagger}$ | H | H | $\begin{aligned} & \text { Output latched } \\ & \text { check bits } \\ & \hline \mathrm{Hi} \mathrm{Z} \end{aligned}$ | $-\frac{\mathrm{L}}{\mathrm{H}}--$ | Enabled |
| Latch diagnostic data word into input latch | H H | Latched input diagnostic data word | H | H | Output syndrome bits $\mathrm{Hi}-\mathrm{Z}$ | $\begin{array}{r} \mathrm{L} \\ -\overline{\mathrm{H}} \\ \hline \end{array}$ | Enabled |
| Output diagnostic data word \& syndrome bits | H H | Output diagnostic data word | L | H | Output syndrome bits $-\frac{\mathrm{Ni}}{\mathrm{Hi}-\mathrm{Z}}$ | L H | Enabled |
| Output corrected diagnostic data word \& output syndrome bits | H H | Output corrected diagnostic data word | L | L | Output syndrome $-\frac{\text { bits }}{\mathrm{Hi}} \mathrm{Z}$ |  | Enabled |

${ }^{\dagger}$ Diagnostic data is a data word with an error in one bit location except when testing the $\overline{M E R R}$ error flag. In this case, the diagnostic data word will contain errors in two bit locations.

TABLE 8. 'ALS634, 'ALS635 DIAGNOSTIC FUNCTION

| EDAC FUNCTION | $\begin{aligned} & \mathrm{CON} \\ & \mathrm{~s} 1 \end{aligned}$ | ROL | DATA I/O | DB CONTROL | CHECK 1/O | $\begin{gathered} \text { DB CONTROL } \\ \overline{O E C B} \end{gathered}$ | ERROR FLAGS $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read \& flag | H | L | Input correct data word | H | Input correct check bits | H | $\mathrm{H} \quad \mathrm{H}$ |
| Latch input check bits while data input latch remains transparent | L | H | Input <br> diagnostic data word ${ }^{\dagger}$ | H | Latched input check bits | H | Enabled |
| Output input check bits | L | H | Input diagnostic data word ${ }^{\dagger}$ | H | Output input check bits | L | Enabled |
| Latch diagnostic data into input latch | H | H | Latched input diagnostic data word | H | Output syndrome bits Hi-Z | $-\frac{\mathrm{L}}{-1}$ | Enabled |
| Output corrected diagnostic data word |  | H | Output corrected diagnostic data word | L | Output syndrome bits $\overline{\mathrm{Hi}}-\bar{Z}$ | $-\frac{\mathrm{L}}{\mathrm{H}^{-}}$ | Enabled |

[^10]SN54ALS632A, SN54ALS633, SN74ALS632A, SN74ALS633

## 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

'ALS632A, 'ALS633 logic diagram (positive logic)

*'ALS632A has 3-state ( $\nabla$ ) check-bit and data outputs.
'ALS633 has open-collector ( $\theta$ ) check-bit and data outputs.
'ALS634, 'ALS635 logic diagram (positive logic)

*'ALS634 has 3-state ( $\nabla$ ) check-bit and data outputs.
'ALS635 has open-collector ( $\theta$ ) check-bit and data outputs.

## SN54ALS632A, SN54ALS633 THRU SN54ALS635 <br> SN74ALS632A, SN74ALS633 THRU SN74ALS635 <br> 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC (see Note 1) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage: CB and DB . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
All others. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Operating free-air temperature range:
SN74ALS632A, SN74ALS633 thru SN74ALS635 . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Operating case temperature range:
SN54ALS632A, SN54ALS633 thru SN54ALS635 . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

tThese times ensure that corrected data is saved in the output data latch.
$\ddagger$ These times ensure that the diagnostic data word is saved in the output data latch.

## SN54ALS632A，SN54ALS634，SN74ALS632A，SN74ALS634 32－BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS WITH 3－STATE OUTPUTS

＇ALS632A，＇ALS634 electrical characteristics over recommended operating temperature range（unless otherwise noted）

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS632A SN54ALS634 |  |  | SN74ALS632A SN74ALS634 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | TYP ${ }^{\text {T}}$ | MAX |  | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $1=-18 \mathrm{~mA}$ |  |  | －1．5 |  | －1．5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{v}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}-2}$ |  |  | V |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $\mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.4 | 3.3 |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $\mathrm{IOH}^{\prime}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
|  | $\overline{\text { ERR }}$ or MERR | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ ， | $\mathrm{l}_{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
| VOL |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $1 \mathrm{OL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 | V |
| OL | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $\mathrm{IOL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ ， | $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | SO or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ ， | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| 1 | All others | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ ， | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
|  | S0 or S1 | $V_{C C}=5.5 \mathrm{~V}$ ， | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | ${ }^{\text {A }}$ |
| ${ }_{1}$ | All others ${ }^{\ddagger}$ | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$ ， | $V_{1}=2.7 v$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | S0 or S1 |  |  |  |  | －0．4 |  |  | －0．4 | mA |
| IL | All others ${ }^{\ddagger}$ | $V_{\text {CC }}=5.5 \mathrm{~V}$ ， | $V_{1}=0.4 V$ |  |  | －0．1 |  |  | －0．1 | mA |
| $10^{5}$ |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$ ， | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | －30 |  | －112 | －30 |  | －112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ ， | See Note 1 |  | 150 | 250 |  | 150 | 250 | niA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ．
$\ddagger$ For $1 / O$ ports，the parameters $I_{I H}$ and $I_{I L}$ include the off－state output current．
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short－circuit output current，IOS． NOTE 1：${ }^{I} C C$ is measured with SO and S 1 at 4.5 V and all CB and DB pins grounded．
＇ALS632A switching characteristics， $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T} \mathrm{C}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS632A， $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS632A

| PARAMETER | $\begin{aligned} & \hline \text { FROM } \\ & \text { (INPUT) } \end{aligned}$ | TO （OUTPUT） | TEST CONDITIONS | SN54ALS632A |  | SN74ALS632A |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tpd }}$ | DB and CB | ERR | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 | ns |
|  | DB | $\overline{\text { ERR }}$ | $S 1=L, S 0=H, R_{L}=500 \Omega$ | 10 | 43 | 10 | 40 |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\mathrm{MERR}}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 67 | 15 | 55 | ns |
|  | DB | $\overline{\text { MERR }}$ | $S 1=L, S 0=H, R_{L}=500 \Omega$ | 15 | 67 | 15 | 55 |  |
| ${ }^{\text {t }} \mathrm{pd}$ | S0」 and S1 $\downarrow$ | CB | $\mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 60 | 10 | 48 | ns |
| tPLH | SO $\downarrow$ and S $1 \downarrow$ | ERR | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ | 5 | 30 | 5 | 25 | ns |
| ${ }^{\text {t }}$ d | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{L}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 60 | 10 | 48 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | $\overline{\text { LEDBO }}$ ！ | DB | S1 $=$ X，SO $=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 7 | 35 | 7 | 30 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | S1ヶ | CB | S0 $=$ H，R1 $=$ R2 $=500 \Omega$ | 10 | 60 | 10 | 50 | ns |
| ten | $\overline{\text { OECB }} \downarrow$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |
| ${ }^{\text {d }}$ dis | $\overline{\mathrm{OECB}} \uparrow$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |
| $\mathrm{t}_{\mathrm{e}}$ | OEBO thru $\overline{O E B} 3 \downarrow$ | DB | SO $=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |
| ${ }^{\text {dis }}$ | $\overline{\mathrm{OEB}} 0$ thru $\overline{\mathrm{OEB}} 3 \uparrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |

## SN54ALS634, SN74ALS634

32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS WITH 3-STATE OUTPUTS
'ALS634 switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS634, $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS634

| PARAMETER | $\begin{gathered} \hline \text { FROM } \\ \text { (INPUT) } \end{gathered}$ | $\begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}$ | TEST CONDITIONS | SN54ALS634 |  | SN74ALS634 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { ERR }}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 | ns |
|  |  |  | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { MERR }}$ | S1 $=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 67 | 15 | 55 | ns |
|  |  |  | S1 $=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 67 | 15 | 55 |  |
| $\mathrm{t}_{\mathrm{pd}}$ | SO $\downarrow$ and S $1 \downarrow$ | CB | $\mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 60 | 10 | 48 | ns |
| tPLH | SO $\downarrow$ and S $1 \downarrow$ | ERR | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ | 5 | 30 | 5 | 25 | ns |
| ${ }^{\text {tpd }}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{L}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 10 | 60 | 10 | 48 | ns |
| $t_{\text {pd }}$ | S1ヶ | CB | S0 = H, R1 = R2 $=500 \Omega$ | 7 | 35 | 7 | 30 | ns |
| $t_{\text {en }}$ | $\overline{\text { OECB }}$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |
| $\mathrm{t}_{\text {dis }}$ | $\overline{\mathrm{OECB}} \uparrow$ | CB | S1 $=\mathrm{X}, \mathrm{S} 0=H, R 1=R 2=500 \Omega$ | 2 | 30 | 2 | 25 | n S |
| $\mathrm{t}_{\text {en }}$ | $\overline{\text { OEDB }} \downarrow$ | DB | S1 $=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 30 | ns |
| $\mathrm{t}_{\text {dis }}$ | $\overline{\text { OEDB } \uparrow}$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ | 2 | 30 | 2 | 25 | ns |

'ALS633 electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS633 |  |  |  | 4ALS |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $I_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\overline{\text { ERR }}$ or $\overline{\mathrm{MERR}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
| ${ }^{1} \mathrm{OH}$ | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\text {OL }}$ | $\overline{\text { ERR }}$ or $\overline{M E R R}$ | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{IOL}^{\text {a }}$ ( 12 mA |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 4 | S0 or S1 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| 1 | All others | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| $\mathrm{IIH}^{\text {H }}$ | SO or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | All others ${ }^{\ddagger}$ |  |  |  |  | 20 |  |  | 20 |  |
| IL | So or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
|  | All others ${ }^{\ddagger}$ |  |  |  |  | -0.1 |  |  | -0.1 |  |
| 105 | ERR or MERR | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{1} \mathrm{CC}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | See Note 1 |  | 150 | 250 |  | 150 | 250 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
${ }^{\ddagger}$ For $\mathrm{I} / \mathrm{O}$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS. NOTE 1: ICC is measured with SO and S1 at 4.5 V and all CB and DB pins grounded.
'ALS633 switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{CL}=50 \mathrm{pF}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS633, $\mathrm{TA}_{A}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS633

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS | SN54ALS633 |  | SN74ALS633 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | MAX | MIN | MAX |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { ERR }}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 | ns |
|  | DB | ERR | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 10 | 43 | 10 | 40 |  |
| ${ }^{\text {tpd }}$ | DB and CB | $\overline{\text { MERR }}$ | S1 $=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 67 | 15 | 55 | ns |
|  |  |  | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ | 15 | 67 | 15 | 55 |  |
| ${ }^{\text {t }}$ d | SO $\downarrow$ and S1 $\downarrow$ | CB | $\mathrm{R}_{\mathrm{L}}=680 \Omega$ | 10 | 75 | 10 | 60 | ns |
| ${ }_{\text {tPLH }}$ | SO $\downarrow$ and S1 $\downarrow$ | $\overline{\text { ERR }}$ | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ | 5 | 30 | 5 | 25 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ | 10 | 70 | 10 | 60 | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | LEDBO $\downarrow$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ | 15 | 70 | 15 | 50 | ns |
| ${ }_{\text {tpd }}$ | S1T | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \mathrm{~S}$ | 10 | 60 | 10 | 45 | ns |
| tPLH | $\overline{\text { OECB }} \uparrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ | 2 | 35 | 2 | 30 | ns |
| tPHL | $\overline{\text { OECB }} \downarrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ | 2 | 35 | 2 | 30 | ns |
| tPLH | OEBO thru $\overline{O E B} 3 \uparrow$ | DB | S1 $=\mathrm{X}, \mathrm{S} 0=H, \mathrm{R}_{L}=680 \Omega$ | 2 | 35 | 2 | 30 | ns |
| ${ }^{\text {tPHL }}$ | OEBO thru $\overline{\text { OEB }} 3$. | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{S} 0=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ | 2 | 35 | 2 | 30 | ns |

'ALS635 electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS635 |  |  | SN74ALS635 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYp ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | ERR or MERR | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, 1 \mathrm{OH}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{Cc}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
| ${ }^{\mathrm{I} \mathrm{OH}}$ | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| VOL | $\overline{\text { ERR }}$ or $\overline{\text { MERR }}$ | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | DB or CB | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 1 | S0 or S1 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  |  |  |  |  | mA |
| I | All others | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  |  |  |  |  |  |
| Ith | S0 or S1 | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  |  |  |  |  | $\mu \mathrm{A}$ |
|  | All others ${ }^{\ddagger}$ |  |  |  |  |  |  |  |  |  |
| IIL | S0 or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  |  |  |  |  |  | mA |
|  | All others ${ }^{\ddagger}$ |  |  |  |  |  |  |  |  |  |
| ${ }^{1} 0^{5}$ | ERR or MERR | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | $-30$ |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | See Note 1 | 150 |  |  | 150 |  |  | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $1 / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS. NOTE 1: ICC is measured with SO and S1 at 4.5 V and all CB and DB pins grounded.
${ }^{\prime}$ ALS635 switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{CL}=50 \mathrm{pF}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54ALS635, TA $=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74ALS635

| PARAMETER | FROM <br> (INPUT) | TO (OUTPUT) | TEST CONDITIONS | SN54ALS635 |  |  | SN74ALS635 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| ${ }^{\text {t }}$ pd | DB and CB | $\overline{\text { ERR }}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
|  | DB | $\overline{\text { ERR }}$ | $S 1=L, S 0=H, R_{L}=500 \Omega$ |  | 26 |  |  | 26 |  |  |
| ${ }^{t} \mathrm{pd}$ | DB and CB | $\overline{\text { MERR }}$ | $S 1=H, S O=L, R_{L}=500 \Omega$ |  | 40 |  |  | 40 |  | ns |
|  |  |  | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 40 |  |  | 40 |  |  |
| ${ }^{\text {tpd }}$ | SO $\downarrow$ and S $1 \downarrow$ | CB | $\mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| ${ }^{\text {t PLH }}$ | $\mathrm{SO} \downarrow$ and $\mathrm{S} 1 \downarrow$ | ERR | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 14 |  |  | 14 |  | ns |
| ${ }^{\text {t }} \mathrm{pd}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| ${ }^{t} \mathrm{pd}$ | S1 $\uparrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 40 |  |  | 40 |  | ns |
| $\mathrm{t}_{\mathrm{PLH}}$ | $\overline{\mathrm{OECB}} \uparrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| ${ }^{\text {t PHL }}$ | OECB $\downarrow$ | CB | $S 1=X, S 0=H, R_{L}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| $\mathrm{tPLH}^{\text {P }}$ | $\overline{\text { OEDB } \uparrow ~}$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |
| tPHL | $\overline{\mathrm{OEDB}} \downarrow$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=680 \Omega$ |  | 24 |  |  | 24 |  | ns |

${ }^{+}$All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.


FIGURE 1. READ, FLAG, AND CORRECT MODE SWITCHING WAVEFORMS


FIGURE 2. READ, CORRECT, MODIFY MODE SWITCHING WAVEFORMS

## 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS



FIGURE 3. DIAGNOSTIC MODE SWITCHING WAVEFORM

## - Detects and Corrects Single-Bit Errors

- Detects and Flags Dual-Bit Errors
- Built-In Diagnostic Capability
- Fast Write and Read Cycle Processing Times
- Byte-Write Capability . . . 'AS632
- Dependable Texas Instruments Quality and Reliability

| DEVICE | PACKAGE | BYTE-WRITE | OUTPUT |
| :---: | :---: | :---: | :---: |
| 'AS632 | 52-pin | yes | 3-State |
| 'AS634 | 48 -pin | no | 3-State |

## description

The 'AS632 and 'AS634 devices are 32-bit parallel error detection and correction circuits (EDACs) in 52-pin ('AS632) or 48-pin ('AS634) 600-mil packages. The EDACs use a modified Hamming code to generate a 7-bit check word from a 32-bit data word. This check word is stored along with the data word during the memory write cycle. During the memory read cycle, the 39 -bit words from memory are processed by the EDACs to determine if errors have occurred in memory.

Single-bit errors in the 32 -bit data word are flagged and corrected.
Single-bit errors in the 7-bit check word are flagged, and the CPU sends the EDAC through the correction cycle even though the 32-bit data word is not in error. The correction cycle will simply pass along the original 32-bit data word in this case and produce error syndrome bits to pinpoint the error-generating location.
Dual-bit errors are flagged but not corrected. These errors may occur in any two bits of the 39-bit data word from memory (two errors in the 32 -bit data word, two errors in the 7-bit check word, or one error in each word). The gross-error condition of all lows or all highs from memory will be detected. Otherwise, errors in three or more bits of the 39-bit word are beyond the capabilities of these devices to detect.


NC - No internal connection

## 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

Read-modify-write (byte-control) operations can be performed with the 'AS632 EDAC by using output latch enable, $\overline{L E D B O}$, and the individual $\overline{O E B O}$ thru $\overline{O E B} 3$ byte control pins.

Diagnostics are performed on the EDACs by controls and internal paths that allow the user to read the contents of the DB and CB input latches. These will determine if the failure occurred in memory or in the EDAC.

| 'AS634. | (TOP VIEW) |  |
| :---: | :---: | :---: |
| $\overline{M E R R} 1$ | 48 | $\mathrm{V}_{\mathrm{cc}}$ |
| $\overline{\text { ERR }}{ }^{2}$ | 47 | ]si |
| DBO 3 | 46 | So |
| DB1 4 | 45 | -0831 |
| DB2 5 | 44 | - ${ }^{\text {d }}$ 30 |
| D83 6 | 43 | -0829 |
| D84 7 | 42 | ]0b28 |
| D85 8 | 41 | - ${ }^{\text {d }}$ 27 |
| $\overline{\text { OEDB } 9}$ | 40 | DB26 |
| D66 10 | 39 | ПDB25 |
| DB7 11 | 38 | $\square \mathrm{DB24}$ |
| GND 12 | 37 | $\square \mathrm{GND}$ |
| DB8 13 | 36 | DB23 |
| D89 14 | 35 | DB22 |
| DB10 15 | 34 | - ${ }^{\text {d }} 11$ |
| DB11 16 | 33 | 70B20 |
| DB12 17 | 32 | -DB19 |
| DB13 18 | 31 | -DB18 |
| DB14 19 | 30 | ]DB17 |
| DB15 20 | 29 | DDB16 |
| CB6 21 | 28 | $\square$ сво |
| CB5 22 | 27 | 7 CB 1 |
| CB4 23 | 26 | CB2 |
| $\overline{O E C B}-24$ | 25 | CB3 |



NC - No internal connection

TABLE 1. WRITE CONTROL FUNCTION

| $\begin{gathered} \text { MEMORY } \\ \text { CYCLE } \end{gathered}$ | EDAC FUNCTION | CONTROL S1 SO | DATA 1/O | $\begin{gathered} \text { DB CONTROL } \\ \overline{\text { OEBn OR }} \\ \overline{\text { OEDB }} \end{gathered}$ | $\begin{aligned} & \text { DB OUTPUT LATCH } \\ & \text { ('AS632) } \\ & \overline{\text { LEDBO }} \end{aligned}$ | CHECK I/O | $\begin{array}{\|c} \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \end{array}$ | ERROR FLAGS <br> $\overline{\text { ERR }}$ <br> MERR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Write | Generate check word | L. L. | Input | H | X | Output check bits $\dagger$ | L | H H |

${ }^{\dagger}$ See Table 2 for details on check bit generation.

## memory write cycle details

During a memory write cycle, the check bits (CBO thru CB6) are generated internally in the EDAC by seven 16 -input parity generators using the 32 -bit data word as defined in Table 2. These seven check bits are stored in memory along with the original 32 -bit data word. This 32 -bit word will later be used in the memory read cycle for error detection and correction.

TABLE 2. PARITY ALGORITHM

| CHECK WORD BIT | 3 | 32-BIT DATA WORD |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | 30 | 29 | 28 | 27 | 26 | 25 | 24 | 23 | 22 | 21 | 20 | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| CBO | X |  | X | X |  | X |  |  |  |  | X |  | X | X | X |  |  | X |  |  | X |  | X | X | X | X |  | X |  |  |  | $X$ |
| CB1 |  |  |  | X |  | X |  | X |  | X |  | $X$ |  | X | X | X |  |  |  | X |  | X |  | $X$ |  | $X$ |  |  |  | X | $X$ | $x$ |
| CB2 | $x$ |  | X |  |  | X | X |  | X |  |  | X | X |  |  | X | X |  | X |  |  | X | X |  | $X$ |  |  | X | $x$ |  |  | $x$ |
| СВ3 |  |  | $x$ | X | X |  |  |  | X | X | X |  |  |  | X | X |  |  | ' X | X | X |  |  |  | X | X | $x$ |  |  |  | X | X |
| CB4 | $X$ | $x$ |  |  |  |  |  |  | $X$ | X | X | $x$ | X | X |  |  | X | X |  |  |  |  |  |  | X | X | X | $x$ | $x$ | X |  |  |
| C85 | X | $x$ | $x$ | X | $X$ | $X$ | X | X |  |  |  |  |  |  |  |  | X | X | X | $x$ | X | X | X | $x$ |  |  |  |  |  |  |  |  |
| CB6 | X | X | X | X | X | X | X | X |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | X | X | X | X | X | X | X | X |

The seven check bits are parity bits derived from the matrix of data bits as indicated by " X " for each bit.

## error detection and correction details

During a memory read cycle, the 7 -bit check word is retrieved along with the actual data. In order to be able to determine whether the data from memory is acceptable to use as presented to the bus, the error flags must be tested to determine if they are at the high level.
The first case in Table 3 represents the normal, no-error conditions. The EDAC presents highs on both flags. The next two cases of single-bit errors give a high on $\overline{M E R R}$ and a low on ERR, which is the signal for a correctable error, and the EDAC should be sent through the correction cycle. The last three cases of double-bit errors will cause the EDAC to signal lows on both ERR and $\overline{\text { MERR }}$, which is the interrupt indication for the CPU.

TABLE 3. ERROR FUNCTION

| TOTAL NUMBER OF ERRORS |  | ERROR FLAGS | DATA CORRECTION |  |
| :---: | :---: | :---: | :---: | :---: |
| 32-BIT DATA WORD | 7-BIT CHECK WORD | ERR |  | DATA |
| 0 | 0 | H | H | Not applicable |
| 1 | 0 | L | H | Correction |
| 0 | 1 | L | H | Correction |
| 1 | 1 | L | L | Interrupt |
| 2 | 0 | L | L | Interrupt |
| 0 | 2 | L | L | Interrupt |

Error detection is accomplished as the 7 -bit check word and the 32 -bit data word from memory are applied to internal parity generators/checkers. If the parity of all seven groupings of data and check bits are correct, it is assumed that no error has occurred and both error flags will be high.

If the parity of one or more of the check groups is incorrect, an error has occurred and the proper error flag or flags will be set low. Any single error in the 32-bit data word will change the state of either three or five bits of the 7 -bit check word. Any single error in the 7 -bit check word changes the state of only that one bit. In either case, the single error flag ( $\overline{\mathrm{ERR})}$ will be set low while the dual error flag ( $\overline{\mathrm{MERR}}$ ) will remain high.
Any two-bit error will change the state of an even number of check bits. The two-bit error is not correctable since the parity tree can only identify single-bit errors. Both error flags are set low when any two-bit error is detected.

Three or more simultaneous bit errors can cause the EDAC to believe that no error, a correctable error, or an uncorrectable error has occurred and will produce erroneous results in all three cases. It should be noted that the gross-error conditions of all lows and all highs will be detected.

## 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

TABLE 4. READ, FLAG, AND CORRECT FUNCTION

| MEMORY CYCLE | EDAC <br> FUNCTION | $\begin{gathered} \mathrm{CON} \\ \mathrm{~S} 1 \end{gathered}$ |  | DATA I/O | $\left\lvert\, \begin{gathered} \text { DB CONTROL } \\ \overline{\text { OEBn OR }} \\ \overline{O E D B} \end{gathered}\right.$ | $\begin{gathered} \text { DB OUTPUT LATCH } \\ \text { ('AS632) } \\ \hline \text { LEDBO } \\ \hline \end{gathered}$ | CHECK I/O | $\begin{gathered} \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \end{gathered}$ | $\frac{\text { ERROR FLAGS }}{\overline{E R R}} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& flag | H | 1 | Input | H | X | Input | H | Enabled $\dagger$ |
| Read | Latch input data \& check bits | H | H | Latched input data | H | L | Latched input check word | H | Enabled $\dagger$ |
| Read | Output corrected data \& syndrome bits | H | H | Output corrected data word | L | X | Output syndrome bits $\ddagger$ | L | Enabled $\dagger$ |

${ }^{\dagger}$ See Table 3 for error description.
$\ddagger$ See Table 5 for error location.
As the corrected word is made available on the data I/O port (DBO thru DB31), the check word I/O port (CBO thru CB6) presents a 7-bit syndrome error code. This syndrome error code can be used to locate the bad memory chip. See Table 5 for syndrome decoding.

# SN54AS632, SN54AS634 <br> SN74AS632, SN74AS634 32-bit PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS 




|  |  | SYN | NDR | RO | ME | B | TS |  | ERROR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6 |  | 5 | 4 | 3 | 2 | 1 | 1 | 0 |  |
| H |  | L | L | L | L | L |  | L | 2-bit |
| H |  | L | L | L | L | L | L | H | unc |
| H |  | L | L | L | L | H | H | L | unc |
| H |  | L | L | L | L |  |  |  | 2-bit |
| H |  | L | L | L | H |  |  | $\bar{L}$ | unc |
| H |  | L | L | L | H | L | L |  | 2-bit |
| H |  | L | L | L | H | H | H | L | 2-bit |
| H |  | L | L | L | H |  |  |  | unc |
|  |  | L | L |  |  |  |  | $\bar{L}$ | unc |
| H |  | L | L | H | L | 1 | L |  | 2-bit |
| H |  | L | L | H | L | H | H | L | 2-bit |
| H |  | L | L | H | L |  | H |  | DB15 |
|  |  | L | L | H | H |  | L |  | 2-bit |
|  |  | L | L | H | H | L | L |  | unc |
| H |  | L | L | H | H | H | H | L | DB14 |
| H |  | L | L | H | H |  | H |  | 2-bit |
|  |  | L | H | L |  |  | L | L | unc |
| H |  | $\llcorner$ | H | L | L |  |  |  | 2-bit |
| H |  | L | H | L | L | H | H | L | 2-bit |
| H |  | L | H | L | L | H |  | H | DB13 |
| H |  | L | H |  | H |  | L | L | 2-bit |
| H |  | L | H | L | H | L | H |  | DB12 |
| H |  | L | H | L | H | H | H | L | DB11 |
| H |  | L | H | L | H | H | H |  | 2-bit |
| H |  | L | H | H | L |  | L | L | 2-bit |
| H |  | L | H | H | L | L | L |  | DB10 |
| H |  | L | H | H | L | H | H |  | DB9 |
| H |  | L | H | H | L | H | H |  | 2-bit |
|  |  | L | H | H | H | L | L |  | DB8 |
| H |  | L | H | H | H | L | L |  | 2-bit |
| H |  | L | H | H | H | H | H | L | 2-bit |
| H |  | L | H | H | H | H | H |  | CB5 |


|  |  | ND | DR | OM | HE | BI |  |  | ERROR |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 5 | 4 | 4 | 3 | 2 | 1 |  |  |  |
|  | H | L | L | L | L | L |  |  | unc |
| H | H H | L | L | L | L | L |  |  | 2-bit |
| H | H H | L | L | L | L | H |  |  | 2-bit |
| H | H H | L | L | L | L | H |  |  | DB23 |
| H | H | L | L | L | H |  |  |  | 2-bit |
| H | H | L | L | L | H | 1 |  |  | DB22 |
| H | H H | L | L | L | H | H |  |  | DB21 |
| H | H H | L | L | L | H | H |  |  | 2-bit |
| H | H. H | L | L | H | L |  |  |  | 2-bit |
| H | H | L | L | H | L | L |  |  | DB20 |
| H | H | L | L | H | L | H |  |  | DB19 |
| H | H H | L | L | H | L | H |  |  | 2-bit |
| H | H | L | L | H | H | L |  |  | DB18 |
| H | H H | L | L | H | H | L |  |  | 2-bit |
| H | H H | L | L | H | H | H |  |  | 2-bit |
| H | H H | H | L | H | H | H |  |  | CB4 |
| H | H | H | H | L | L |  |  |  | 2-bit |
| H | H H | H | H | L | L | L |  |  | DB16 |
| H | H H | H H | H | L | L | H |  |  | unc |
| H | H H | H H | H | L | L | H |  |  | 2-bit |
| H | H | H | H | L | H |  |  |  | DB17 |
| H | H | H | H | L | H | L |  |  | 2-bit |
| H | H H | H | H | L | H | H |  |  | 2-bit |
| H | H H | H | H | L | H | H |  |  | CB3 |
| H | H | H | H | H | L |  |  |  | unc |
| H | H H | H | H | H | L | L |  |  | 2-bit |
| H | H H | H | H | H | L | H |  |  | 2 -bit |
| H | H H | H H | H | H | L | H |  |  | CB2 |
|  | H | H | H | H | H | L |  |  | 2-bit |
| H | H | 1 | H | H | H | L |  |  | CB1 |
| H | H H | H | H | H | H | H |  |  | CBO |
| H | H H | H H | H | H | H | H |  |  | none |

CB $X=$ error in check bit $X$
DB $Y=$ error in data bit $Y$
2-bit $=$ double-bit error
unc $=$ uncorrectable multibit error

## read-modify-write (byte control) operations

The 'AS632 is capable of byte-write operations. The 39-bit word from memory must first be latched into the DB and CB input latches. This is easily accomplished by switching from the read and flag mode ( $\mathrm{S} 1=\mathrm{H}$, $S 0=\mathrm{L}$ ) to the latch input mode ( $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{H}$ ). The EDAC will then make any corrections, if necessary, to the data word and place it at the input of the output data latch. This data word must then be latched into the output data latch by taking LEDBO from a low to a high.
Byte control can now be employed on the data word through the $\overline{\mathrm{OEB}} 0$ through $\overline{\mathrm{OEB}} 3$ controls. $\overline{\mathrm{OEB}} \mathrm{O}$ controls DBO-DB7 (byte 0), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (byte 1), $\overline{\mathrm{OEB}} 2$ controls DB16-DB23 (byte 2), and $\overline{\mathrm{OEB}} 3$ controls DB24-DB31 (byte 3). Placing a high on the byte control will disable the output and the user can modify the byte. If a low is placed on the byte control, then the original byte is allowed to pass onto the data bus unchanged. If the original data word is altered through byte control, a new check word must be generated before it is written back into memory. This is easily accomplished by taking control S1 and SO low. Table 6 lists the read-modify-write functions.

32-bit Parallel error detection and correction circuits

TABLE 6. READ-MODIFY-WRITE FUNCTION

| MEMORY CYCLE | EDAC FUNCTION | $\begin{aligned} & \text { CONTROL } \\ & \text { S1 so } \end{aligned}$ | BYTEn $\dagger$ | $\overline{\text { OEB }} \mathrm{n} \dagger$ | $\begin{gathered} \text { DB OUTPUT } \\ \text { LATCH } \\ \text { LEDBO } \\ \hline \end{gathered}$ | CHECK I/O | CB CONTROL | ERROR FLAG <br> $\overline{\text { ERR }} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | Read \& Flag | H L | Input | H | X | Input | H | Enabled |
| Read | Latch input data \& check bits | H H | Latched Input data | H | L | Latched input check word | H | Enabled |
| Read | Latch corrected data word into output latch | H H | Latched output data word | H | H | $-\frac{\mathrm{Hi}-\mathrm{Z}}{\text { Output }}$ <br> Syndrome bits |  <br> L | Enabled |
| Modify /write | Modify appropriate byte or bytes \& generate new check word | L L | Input <br> modified <br> BYTEO <br> Output <br> unchanged <br> BYTEO | H <br> L | H | Output check word | L | H H |

${ }^{\dagger} \overline{\mathrm{OEB}} 0$ controls DBO-DB7 (BYTEO), $\overline{\mathrm{OEB}} 1$ controls DB8-DB15 (BYTE1), $\overline{\mathrm{OEB}} 3$ controls DB16-DB23 (BYTE2), $\overline{\mathrm{OEB}} 3$ controls DB24-DB31 (BYTE3).

## diagnostic operations

The 'AS632 and 'AS634 are capable of diagnostics that allow the user to determine whether the EDAC or the memory is failing. The diagnostic function tables will help the user to see the possibilities for diagnostic control.

In the diagnostic mode ( $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}$ ), the checkword is latched into the input latch while the data input latch remains transparent. This lets the user apply various data words against a fixed known checkword. If the user applies a diagnostic data word with an error in any bit location, the ERR flag should be low. If a diagnostic data word with two errors in any bit location is applied, the MERR flag should be low. After the checkword is latched into the input latch, it can be verified by taking $\overline{\mathrm{OECB}}$ low. This outputs the latched checkword. With the 'AS632, the diagnostic data word can be latched into the output data latch and verified. It should be noted that the 'AS634 does not have this pass-through capability because they do not contain an output data latch. By changing from the diagnostic mode ( $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}$ ) to the correction mode ( $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{H}$ ), the user can verify that the EDAC will correct the diagnostic data word. Also, the syndrome bits can be produced to verify that the EDAC pinpoints the error location. Table 7 ('AS632) and Table 8 ('AS634) list the diagnostic functions.

TABLE 7. 'AS632 DIAGNOSTIC FUNCTION

| EDAC FUNCTION | CONTROL S1 So | DATA I/O | $\begin{gathered} \text { DB BYTE } \\ \text { CONTROL } \\ \overline{\mathrm{OEB}} \mathrm{C} \end{gathered}$ | $\begin{gathered} \text { DB OUTPUT } \\ \text { LATCH } \\ \text { LEDBO } \\ \hline \end{gathered}$ | CHECK I/O | $\begin{gathered} \text { CB } \\ \text { CONTROL } \\ \overline{\mathrm{OECB}} \end{gathered}$ | ERROR FLAGS $\overline{E R R} \overline{\text { MERR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read \& flag | H L | Input correct data word | H | X | Input correct check bits | H | H H |
| Latch input check word while data input latch remains transparent | L H | Input diagnostic data word ${ }^{\dagger}$ | H | L | Latched input check bits | H | Enabled |
| Latch diagnostic data word into output latch | L H | Input <br> diagnostic data word ${ }^{\dagger}$ | H | H | Output latched check bits $\mathrm{Hi}-\mathrm{Z}$ | $-\frac{L}{H}--$ | Enabled |
| Latch diagnostic data word into input latch | H H | Latched input diagnostic data word | H | H | Output syndrome $-\frac{\text { bits }}{\mathrm{Hi}-\mathrm{Z}}---$ | $\begin{gathered} L \\ --\frac{1}{H}-- \end{gathered}$ | Enabled |
| Output diagnostic data word \& syndrome bits | H H | Output diagnostic data word | L | H | Output syndrome $-\frac{\text { bits }}{\mathrm{Hi}-\mathrm{Z}}-----$ | $\begin{gathered} L \\ ----- \end{gathered}$ | Enabled |
| Output corrected diagnostic data word \& output syndrome bits | H H | Output corrected diagnostic data word | L | L | Output syndrome $-\frac{\text { bits }}{\mathrm{Hi}} \mathrm{-Z}-ー-ー-$ | $\begin{gathered} L \\ -\frac{1}{H}-- \end{gathered}$ | Enabled |

TABLE 8. 'AS634 DIAGNOSTIC FUNCTION

| EDAC FUNCTION | $\begin{aligned} & \text { CON } \\ & \text { S1 } \end{aligned}$ |  | DATA I/O | $\begin{aligned} & \text { DB CONTROL } \\ & \overline{\text { OEDB }} \end{aligned}$ | CHECK I/O | DB CONTROL. | $\overline{\text { ERROR FLAGS }} \overline{\overline{\text { ERR }}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read \& flag | H | L | Input correct data word | H | Input correct check bits | H | H H |
| Latch input check bits while data input latch remains transparent | L | H | Input diagnostic data word ${ }^{\dagger}$ | H | Latched input check bits | H | Enabled |
| Output input check bits | L | H | Input diagnostic data word ${ }^{\dagger}$ | H | Output input check bits | L | Enabled |
| Latch diagnostic data into input latch | H | H | Latched input diagnostic data word | H | Output $-\frac{\text { syndrome bits }}{\mathrm{Hi}-\mathrm{Z}}$ | $-\frac{\mathrm{L}}{\mathrm{H}}--$ | Enabled |
| Output corrected diagnostic data word | H | H | Output corrected diagnostic data word | L | Output syndrome bits $-\frac{\overline{H i}-\bar{Z}}{}----$ | $-\frac{L}{H}--$ | Enabled |

${ }^{\dagger}$ Diagnostic data is a data word with an error in one bit location except when testing the $\bar{M} \bar{R} R \bar{R}$ error flag. In this case, the diagnostic data word will contain errors in two bit locations.
'AS632 logic diagram (positive logic)

'AS634 logic diagram (positive logic)


## SN54AS632, SN54AS634 <br> SN74AS632, SN74AS634 <br> 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC (see Note 1) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage: CB and DB ..................................................................... . . . 5.5 V
All others. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Operating free-air temperature range:
SN74AS632, SN74AS634 . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Operating case temperature range:
SN54AS632, SN54AS634 . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## recommended operating conditions



[^11]'AS632, 'AS634 electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS632 <br> SN54AS634 |  |  | SN74AS632 <br> SN74AS634 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\operatorname{MIN}$ | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  | $V_{C C}=4.5 \mathrm{~V}, \quad \quad \mathrm{I}^{\prime}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.4 | 3.3 |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\text {OH }}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\overline{\text { ERR }}$ or $\overline{\text { MERR }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad 1 \mathrm{OH}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  | DB or CB | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\text {OL }}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 1 | S0 or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | All others | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| ${ }^{1} \mathrm{H}$ | DB or $\mathrm{CB}^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | All others ${ }^{\ddagger}$ |  |  |  | 20 |  |  | 20 |  |
| I/L | S0 or S1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
|  | All others ${ }^{\ddagger}$ |  |  |  | -0.1 |  |  | -0.1 |  |
| 105 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, See Note 1 |  | 150 |  |  | 150 |  | mA |

NOTE 1: ICC is measured with S0 and S1 at 4.5 V and all CB and DB pins grounded.
'AS632 switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T} \mathrm{C}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54AS632, $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74AS632

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS | SN54AS632 |  |  | SN74AS632 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| ${ }^{\text {t }} \mathrm{pd}$ | DB and CB | ERR | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 17 |  |  | 17 |  | ns |
|  | DB | ERR | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 17 |  |  | 17 |  |  |
| ${ }^{\text {tpd }}$ | DB and CB | $\overline{\text { MERR }}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
|  | DB | $\overline{M E R R}$ | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 26 |  |  | 26 |  |  |
| $\mathrm{t}_{\mathrm{pd}}$ | SO\ and S1 $\downarrow$ | CB | $\mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
| ${ }_{\text {tPLH }}$ | SO! and S1 $\downarrow$ | ERR | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 9 |  |  | 9 |  | ns |
| ${ }_{\text {t }}{ }^{\text {d }}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{L}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | $\overline{\text { LEDBO }} \downarrow$ | DB | S1 $=$ X, S $0=H, R 1=R 2=500 \Omega$ |  | 17 |  |  | 17 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}$ | S1 $\dagger$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 26 |  |  | 26 |  | ns |
| $\mathrm{t}_{\mathrm{e}}$ | $\overline{\text { OECB }} \downarrow$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |
| $\mathrm{t}_{\text {dis }}$ | $\overline{\mathrm{OECB}} \uparrow$ | CB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |
| ten | $\overline{O E B} 0$ thru $\overline{O E B} 3 \downarrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |
| ${ }^{\text {d }}$ dis | $\overline{\text { OEBO }}$ thru $\overline{\text { OEB }} 3 \uparrow$ | DB | $\mathrm{SO}=\mathrm{H}, \mathrm{S} 1=\mathrm{X}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $1 / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
$\S$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
${ }^{\prime}$ AS634 switching characteristics, $\mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ for SN54AS634, $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for SN74AS634

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS | SN54AS634 |  |  | SN74AS634 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {¢ }}$ | MAX |  |
| ${ }^{\text {tpd }}$ | DB and CB | ERR | $\mathrm{S} .1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 17 |  |  | 17 |  | ns |
|  |  |  | $\mathrm{S} 1=\mathrm{L}, \mathrm{SO}=\mathrm{H}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 17 |  |  | 17 |  |  |
| ${ }^{\text {tpd }}$ | DB and CB | $\overline{M E R R}$ | $\mathrm{S} 1=\mathrm{H}, \mathrm{SO}=\mathrm{L}, \mathrm{R}_{\mathrm{L}}=5 \mathrm{CO} \Omega$ |  | 26 |  |  | 26 |  | ns |
|  |  |  | S1 = L, S $0=H, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 26 |  |  | 26 |  |  |
| ${ }^{\text {p }}$ d | SO $\downarrow$ and S $1 \downarrow$ | CB | $\mathrm{R} 1=\mathrm{R} 2=500 \mathrm{R}$ |  | 23 |  |  | 23 |  | ns |
| tPLH | SOL and S $1 \downarrow$ | ERR | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 9 |  |  | 9 |  | ns |
| ${ }_{\text {tpd }}$ | DB | CB | $\mathrm{S} 1=\mathrm{L}, \mathrm{S} 0=\mathrm{L}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 23 |  |  | 23 |  | ns |
| ${ }^{\text {t }}$ d | S1t | CB | SO $=$ H, R1 $=$ R2 $=500 \Omega$ |  | 23 |  |  | 23 |  | ns |
| $\mathrm{t}_{\text {en }}$ | $\overline{\text { OECB } \downarrow ~}$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |
| $t_{\text {dis }}$ | $\overline{\text { OECB }} \uparrow$ | CB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |
| $t_{\text {en }}$ | $\overline{\text { OEDB } \downarrow}$ | DB | S1 = X, S0 = H, R1 = R2 = 500 $\Omega$ |  | 12 |  |  | 12 |  | ns |
| $t_{\text {dis }}$ | $\overline{\mathrm{OEDB}} \uparrow$ | DB | $\mathrm{S} 1=\mathrm{X}, \mathrm{SO}=\mathrm{H}, \mathrm{R} 1=\mathrm{R} 2=500 \Omega$ |  | 12 |  |  | 12 |  | ns |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.


FIGURE 1. READ, FLAG, AND CORRECT MODE SWITCHING WAVEFORMS


FIGURE 2. READ, CORRECT, MODIFY MODE SWITCHING WAVEFORMS

## 32-BIT PARALLEL ERROR DETECTION AND CORRECTION CIRCUITS



FIGURE 3. DIAGNOSTIC MODE SWITCHING WAVEFORM

- Independent Registers for A and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of True or Inverting Data Paths
- Choice of 3-State or Open-Collector Outputs
- Included Among the Package Options Are Compact 24-pin 300-mil Wide DIPs and Both 28-pin Plastic and Ceramic Chip Carriers
- Dependable Texas Instruments Quality and Reliability

| DEVICE | OUTPUT | LOGIC |
| :---: | :---: | :---: |
| 'ALS646, 'AS646 | 3-State | True |
| 'ALS647 | Open-Collector | True |
| 'AL.S648, 'AS648 | 3-State | Inverting |
| 'ALS649 | Open-Collector | Inverting |

## description

These devices consist of bus transceiver circuits, with 3-state or open-collector outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Data on the A or B bus will be clocked into the registers on the low-to-high transition of the appropriate clock pin (CAB or CBA). The following examples demonstrate the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.
Enable ( $\bar{G}$ ) and direction (DIR) pins are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either register or in both. The select controls (SAB and SBA) can multiplex stored and real-time (transparent mode) data. The circuitry used for select control will eliminate the typical decoding glitch which occurs in a multiplexer during the transition between stored and real-time data. The direction control determines which bus will receive data when enable $\overline{\mathrm{G}}$ is active (low). In the isolation mode (control $\overline{\mathrm{G}}$ high), A data may be stored in one register and/or $B$ data may be stored in the other register.

When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time.

The -1 versions of the SN74ALS' parts are identical to the standard versions except that the recommended maximum IOL is increased to 48 milliamperes. There are no -1 versions of the SN54ALS' parts.
The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$.
The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


FUNCTION TABLE

| INPUTS |  |  |  |  |  | DATA I/O |  | OPERATION OR FUNCTION |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| G | DIR | CAB | CBA | SAB | SBA | A1 THRU A8 | B1 THRU B8 | 'ALS646, 'ALS647 'AS646 | 'ALS648, 'ALS649 'AS648 |
| X <br>  | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & \uparrow \\ & x \end{aligned}$ | $\begin{aligned} & x \\ & \uparrow \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | $X$ X | Input <br> Unspecified ${ }^{\dagger}$ | Unspecified ${ }^{\dagger}$ Input | Store A, B unspecified ${ }^{\dagger}$ Store B, A unspecified ${ }^{\dagger}$ | Store A, B unspecified ${ }^{\dagger}$ <br> Store B, A unspecified ${ }^{\dagger}$ |
| H H | $\begin{aligned} & \mathrm{X} \\ & \mathrm{x} \end{aligned}$ |  | Hor L | $\begin{aligned} & \mathrm{X} \\ & \mathrm{X} \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | Input | Input | Store A and B Data Isolation, hold storage | Store A and B Data Isolation, hold storage |
| L $L$ | $L$ | $\begin{aligned} & x \\ & x \end{aligned}$ |  | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ | Output | Input | Real-Time B Data to A Bus Stored B Data to A Bus | Real-Time $\vec{B}$ Data to A Bus Stored $\bar{B}$ Data to A Bus |
| L L | H H |  | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | Input | Output | Real-Time A Data to B Bus Stored A Data to B Bus | Real-Time $\bar{A}$ Data to B Bus Store $\bar{A}$ Data to B Bus |

${ }^{\dagger}$ The data output functions may be enabled or disabled by various signals at the $\bar{G}$ and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.
functional block diagrams (positive logic)
'ALS646, 'AS646, 'ALS647


Pin numbers shown are for DW, JT, and NT packages.


## logic symbols ${ }^{\dagger}$

'ALS646, 'AS646

'ALS648, 'AS648

'ALS647

'ALS649

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 9i-1984 and IEC Publication 617-12. Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS646, SN74ALS646 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

```
Supply voltage, VCC7 V
```

Input voltage: Control inputs ..... 7 V
I/O ports ..... 5.5 V
Operating free-air temperature range: SN54ALS646 ..... $55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS646 .....  $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | 54ALS | 446 |  | 74ALS | 446 | NIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX | UNIT |
| $V_{C C}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| VIL | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current |  |  | -12 |  |  | -15 | mA |
|  | Low-level output current |  |  | 12 |  |  | 24 | mA |
| , OL | Low-tevel output current |  |  |  |  |  | $48^{\dagger}$ | mA |
| $f_{\text {clock }}$ | Clock frequency | 0 |  | 35 | 0 |  | 40 | MHz |
| $\mathrm{t}_{\text {w }}$ | Pulse duration, clocks high or low | 14.5 |  |  | 12.5 |  |  | ns |
| $\mathrm{t}_{\text {su }}$ - | Setup time, A before CAB $\uparrow$ or B before CBA $\uparrow$ | 15 |  |  | 10 |  |  | ns |
| $\mathrm{t}_{\mathrm{h}}$ | Hold time, A after $\mathrm{CAB} \uparrow$ or B after CBA $\uparrow$ | 0 |  |  | 0 |  |  | ns |
| TA | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The extended condition applies if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V .
The 48 -mA limit applies for the SN74ALS646-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS646 |  |  | SN74ALS646 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$. | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\text {CC }}$ - 2 |  |  | $\mathrm{V}_{\mathrm{Cc}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-3 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.4 | 3.2 |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-12 \mathrm{~mA}$ | 2 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\mathrm{OH}}=-15 \mathrm{~mA}$ |  |  |  | 2 |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \\ & \mathrm{l}_{\mathrm{OL}}=48 \mathrm{~mA} \end{aligned}$ | $\mathrm{IOL}=24 \mathrm{~mA}$ <br> version) |  |  |  |  | 0.35 | 0.5 |  |
| 1 | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| 1 | A or B ports | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| $\mathrm{I}_{\mathrm{H}}$ | Control inputs | $V_{C C}=5.5 \mathrm{~V}$, | $V_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | A or B ports§ |  |  |  |  | 20 |  |  | 20 |  |
|  | Control inputs | $v_{C C}=5.5 \mathrm{~V}, \quad V_{1}=0.4 \mathrm{~V}$ |  |  |  | -0.2 |  |  | -0.2 | mA |
| IL | A or B ports ${ }^{\text {S }}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |
| 101 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | $-30$ |  | -112 | -30 |  | -112 | mA |
| ${ }^{\text {I CC }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 47 | 76 |  | 47 | 76 | mA |
|  |  | Outputs low | $\cdot$ | 55 | 88 |  | 55 | 88 |  |
|  |  | Outputs disabled |  | 55 | 88 |  | 55 | 88 |  |

[^12]IThe output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS

## SN54ALS646, SN74ALS646 <br> OCTAL BUS TRANSCEIVERS AND REGISTERS <br> WITH 3-STATE OUTPUTS

'ALS646 switching characteristics (see Note 1)

${ }^{\dagger}$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

$\qquad$
Supply voltage, VCC ........ . . . . . ...................................................... 7 . 7
Input voltage ..................................................................................... 7 V
Operating free-air temperature range: SN54ALS647........................... . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ SN74ALS647 . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  | SN54ALS647 |  |  | SN74ALS647 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High-level output voltage |  |  | 5.5 |  |  | 5.5 | V |
| ${ }^{\text {I OL }}$ | Low-level output current |  |  | 12 |  |  | 24 | mA |
|  |  |  |  |  |  |  | $48^{\dagger}$ |  |
| $\mathrm{f}_{\text {clock }}$ | Clock frequency | 0 |  | 25 | 0 |  | 30 | MHz |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, clocks high or low | 20 |  |  | 16.5 |  |  | ns |
| $\mathrm{t}_{\text {su }}$ | Setup time, A before CAB $\uparrow$ or B before CBA $\uparrow$ | 15 |  |  | 10 |  |  | ns |
| $t_{\text {th }}$ | Hold time, A after CABT or B after CBAT | 0 |  |  | 0 |  |  | ns |
| TA | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The extended condition applies if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V .
The 48 -mA limit applies for the SN74ALS647-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS647 |  |  | SN74ALS647 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYpt | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V . |
| ${ }^{1} \mathrm{OH}$ |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{l}_{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  |  |  | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA} \end{aligned}$ | $\mathrm{IOL}=24 \mathrm{~mA}$ <br> versions) |  |  |  |  | 0.35 | 0.5 |  |
| 1 | A or B ports | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
|  | A or ports ${ }^{\text {¢ }}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ${ }_{1} \mathrm{H}$ | Control inputs |  |  |  |  | 20 |  |  | 20 |  |
|  | Control inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.2 |  |  | -0.2 | mA |
| IIL | A or B ports ${ }^{\text {¢ }}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |
| ${ }^{\text {I CC }}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$ | Outputs high |  | 35 | 60 |  | 35 | 60 | mA |
|  |  | Outputs low |  | 40 | 65 |  | 40 | 65 |  |

[^13]
## SN54ALS647, SN74ALS647 <br> OCTAL BUS TRANSCEIVERS AND REGISTERS WITH OPEN-COLLECTOR OUTPUTS

'ALS647 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=680 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime}{ }^{\text {ALS } 647} \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=680 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS647 |  | SN74ALS647 |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 40 |  | 25 |  | 30 |  | MHz |
| tPLH | CBA or CAB | $A$ or B |  | 38 | 50 | 19 | 72 | 19 | 58 |  |
| tPHL |  |  |  | 12 | 20 | 6 | 24 | 6 | 22 | ns |
| tPLH | A or B | B or A |  | 35 | 39 | 17 | 70 | 17 | 54 | ns |
| tPHL |  |  |  | 10 | 13 | 4 | 19 | 4 | 16 | ns |
| tPLH | SBA or SAB ${ }^{\dagger}$ (with $A$ or $B$ high) | $A$ or B |  | 40 | 51 | 20 | 72 | 20 | 60 | ns |
| tPHL |  |  |  | 12 | 17 | 6 | 26 | 6 | 22 | ns |
| ${ }_{\text {tPLH }}$ | SBA or SAB ${ }^{\dagger}$ (with A or B low) | $A$ or $B$ |  | 40 | 51 | 20 | 72 | 20 | 60 |  |
| tPHL |  |  |  | 12 | 17 | 6 | 26 | 6 | 22 | ns |
| tPLH | $\overline{\mathrm{G}}$ | $A$ or $B$ |  | 20 | 27 | 10 | 37 | 10 | 31 | ns |
| ${ }^{\text {tPHL}}$ |  |  |  | 10 | 15 | 2 | 20 | 2 | 17 |  |
| tPLH | DIR | $A$ or $B$ |  | 20 | 25 | 9 | 34 | 9 | 29 | ns |
| tPHL |  |  |  | 13 | 17 | 2 | 22 | 2 | 19 |  |

${ }^{\dagger}$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: For load circuit and voltage waveforms, see page 1-12 of The TTL Data Book, Volume 3, 1984.

## SN54ALS648, SN74ALS648 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC | 7 V |
| :---: | :---: |
| Input voltage: Control inputs | 7 V |
| I/O ports | 5.5 V |
| Operating free-air temperature range: SN54ALS648. | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74ALS648 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

|  |  | SN54ALS648 |  |  | SN74ALS648 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{IOH}}$ | High-level output current |  |  | -12 |  |  | -15 | mA |
| $\mathrm{IOL}^{\text {l }}$ | Low-level output current |  |  | 12 |  |  | 24 | mA |
|  |  |  |  |  |  |  | $48^{\dagger}$ |  |
| $\mathrm{f}_{\text {clock }}$ | Clock frequency. | 0 |  | 35 | 0 |  | 40 | MHz |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, clocks high or low | 14.5 |  |  | 12.5 |  |  | ns |
| $\mathrm{t}_{\text {su }}$ | Setup time, $A$ before CAB $\uparrow$ or B before CBA $\uparrow$ | 15 |  |  | 10 |  |  | ns |
| $t_{n}$ | Hold time, A after CAB $\uparrow$ or B after CBA $\uparrow$ | 0 |  |  | 0 |  | , | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The extended conditon applies if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V .
The $48-\mathrm{mA}$ limit applies for the SN74ALS648-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS648 |  |  | SN74ALS648 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, 1 \mathrm{OH}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{v}_{\mathrm{CC}}{ }^{-2}$ |  |  | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OH}}=-3 \mathrm{~mA}$ |  | 2.430 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad 1 \mathrm{I}^{\text {OH }}=-12 \mathrm{~mA}$ |  | 2 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad 1 \mathrm{OH}=-15 \mathrm{~mA}$ |  |  |  |  | 2 |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $V_{C C}=4.5 \mathrm{~V}$, $\mathrm{I}_{\mathrm{OL}}=12 \mathrm{~mA}$ <br> $\mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ <br> $\left(\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}\right.$ for -1 version $)$  |  |  | 0.25 | 0.4 | -0.35 0.5 |  |  | v |
|  |  |  |  |  |  |  |
| 1 | Control inputs |  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  |  | 0.1 |  |  | 0.1 | mA |
|  | A or B ports | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |  |
| Ith | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $V_{1}=2.7 \mathrm{~V}$ | 20 |  |  |  |  | 20 | $\mu \mathrm{A}$ |  |
|  | A or B ports ${ }^{\text {S }}$ |  |  |  |  | 20 |  |  | 20 |  |  |
| ILI | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | $V_{1}=0.4 \mathrm{~V}$ | -0.2 |  |  |  |  | -0.2 | mA |  |
|  | A or B ports ${ }^{\text {s }}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |  |
| 101 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  |  | -30 | -112 |  | mA |  |
| ${ }^{\text {I C C }}$ |  | $V_{C C}=5.5 \mathrm{~V}$ | Outputs high |  | 47 | 76 |  | 47 | 76 | mA |  |
|  |  | Outputs low |  | 57 | 88 |  | 57 | 88 |  |  |
|  |  | Outputs disabled |  | 57 | 88 |  | 57 | 88 |  |  |

[^14]'ALS648 switching characteristics (see Note 1)

| PARAMETER | $\begin{aligned} & \text { FROM } \\ & \text { (INPUT) } \end{aligned}$ | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R}_{2}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS} 648 \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 50 |  | 35 |  | 40 |  | MHz |
| ${ }^{\text {t PLH }}$ | CBA or CAB | $A$ or B |  | 21 | 29 | 8 | 39 | 8 | 33 | ns |
| ${ }_{\text {tPHL }}$ |  |  |  | 13 | 18 | 5 | 23 | 5 | 20 |  |
| tPLH | $A$ or B | $B$ or A |  | 10 | 15 | 3 | 20 | 3 | 17 | ns |
| tPHL |  |  |  | 6 | 8 | 2 | 12 | 2 | 10 |  |
| ${ }_{\text {tPLH }}$ | $\begin{aligned} & \text { SBA or SAB }{ }^{\dagger} \\ & \text { (with } A \text { or } B \text { high) } \end{aligned}$ | $A$ or B |  | 24 | 32 | 5 | 44 | 5 | 39 | ns |
| ${ }_{\text {tPHL }}$ |  |  |  | 15 | 21 | 4 | 26 | 4 | 22 |  |
| tPLH | SBA or SAB ${ }^{\dagger}$ (with A or B low) | $A$ or $B$ |  | 16 | 22 | 6 | 30 | 6 | 25 | ns |
| tPHL |  |  |  | 14 | 19 | 6 | 25 | 6 | 21 |  |
| tPLH | $\overline{\mathrm{G}}$ | $A$ or B |  | 12 | 18 | 4 | 25 | 4 | 22 | ns |
| tPHL |  |  |  | 12 | 18 | 4 | 25 | 4 | 22 |  |
| tPLH | $\overline{\mathrm{G}}$ | $A$ or $B$ |  | 5. | 8 | 1 | 12 | 1 | 10 | ns |
| tpHL |  |  |  | 7 | 12 | 2 | 21 | 2 | 15 |  |
| tPZH | DIR | $A$ or $B$ |  | 14 | 22 | 4 | 35 | 4 | 27 | ns |
| ${ }^{\text {t P Z }}$ |  |  |  | 10 | 17 | 3 | 25 | 3 | 19 |  |
| tPHz | DIR | A or B |  | 7 | 12 | 1 | 17 | 1 | 14 | ns |
| tPLZ |  |  |  | 7 | 13 | 2 | 22 | 2 | 15 |  |

${ }^{\dagger}$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC ..... 7 V
Input voltage ..... 7 V
Operating free-air temperature range: SN54ALS649 ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$SN74ALS649

$$
0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}
$$

Storage temperature range $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## recommended operating conditions


$\dagger$ The extended condition applies if $V_{C C}$ is maintained between 4.75 V and 5.25 V .
The 48-mA limit applies for the SN74ALS649-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS649 |  |  | SN74ALS649 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $1 \mathrm{l}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| ${ }^{1} \mathrm{OH}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\prime}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  |  |  | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{IOL}=24 \mathrm{~mA} \\ & \left(\mathrm{IOL}_{\mathrm{OL}}=48 \mathrm{~mA} \text { for }-1 \text { versions }\right) \end{aligned}$ |  |  |  |  |  | 0.35 | 0.5 |  |
|  | A or B ports | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}_{\text {, }}$ | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| 1 | Control inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| I | A or ports ${ }^{\text {¢ }}$ |  | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ${ }_{1} \mathrm{H}$ | Control inputs | $V_{C C}=5.5 \mathrm{~V}$, |  |  |  | 20 |  |  | 20 |  |
| IL | Control inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  |  | -0.2 |  |  | -0.2 | mA |
|  | A or B ports ${ }^{\text {8 }}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 40 | 60 |  | 40 | 60 | mA |
|  |  | Outputs low |  | 45 | 70 |  | 45 | 70 |  |

[^15]'ALS649 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=680 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS} 49 \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R_{L}=680 \Omega . \\ & T_{A}=\operatorname{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS649 |  | SN74ALS649 |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 40 |  | 25 |  | 30 |  | MHz |
| ${ }^{\text {tPLH }}$ | CBA or CAB | A or B |  | 40 | 52 | 19 | 77 | 19 | 62 |  |
| tpHL |  |  |  | 12 | 18 | 6 | 22 | 6 | 20 | ns |
| tpLH | A or B | B or A |  | 30 | 41 | 13 | 65 | 13 | 50 | n |
| ${ }^{\text {tPHL }}$ |  |  |  | 6 | 9 | 2 | 11 | 2 | 10 | ns |
| tple | SBA or $S A B^{\dagger}$(with $A$ or $B$ high) | A or B |  | 35 | 46 | 20 | 72 | 20 | 55 | ns |
| tPHL |  |  |  | 15 | 21 | 6 | 26 | 6 | 22 |  |
| ${ }^{\text {tPLH }}$ | SBA or $S A B^{\dagger}$(with $A$ or $B$ low) | $A$ or B |  | 35 | 46 | 20 | 72 | 20 | 55 | ns |
| tPHL |  |  |  | 15 | 21 | 6 | 26 | 6 | 22 |  |
| tPLH | $\overline{\mathrm{G}}$ | $A$ or $B$ |  | 16 | 22 | 8 | 28 | 8 | 25 | ns |
| tPHL |  |  |  | 13 | 18 | 2 | 23 | 2 | 20 | n |
| ${ }_{\text {tPLH }}$ | DIR | $A$ or $B$ |  | 16 | 22 | 8 | 28 | 8 | 25 | ns |
| tpHL |  |  |  | 13 | 17 | 2 | 23 | 2 | 20 |  |

$\dagger$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54AS646, SN54AS648, SN74AS646, SN74AS648 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V

Input voltage: Control inputs . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54AS646, SN54AS648 . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ SN74AS646, SN74AS648 $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^16]
## SN54AS646, SN54AS648, SN74AS646, SN74AS648 <br> OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

'AS646 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R} 1=500 \Omega \\ & \mathrm{R} 2=500 \Omega \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS646 |  | SN74AS646 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 75 |  | 90 |  | MHz |
| tPLH | CBA or CAB | $A$ or $B$ | 2 | 9.5 | 2 | 8.5 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 |  |
| tPLH | $A$ or $B$ | $B$ or $A$ | 2 | 11 | 2 | 9 | ns |
| ${ }^{\text {t PHL }}$ |  |  | 1 | 8 | 1 | 7 |  |
| tPLH | SBA or SAB ${ }^{\dagger}$ | $A$ or $B$ | 2 | 12 | 2 | 11 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 |  |
| tPZH | $\overline{\mathrm{G}}$ | $A$ or $B$ | 2 | 10 | 2 | 9 | ns |
| tPZL |  |  | 3 | 15 | 3 | 14 |  |
| tPHZ | $\overline{\mathrm{G}}$ | A or B | 2 | 11 | 2 | 9 | ns |
| tPLZ |  |  | 2 | 11 | 2 | 9 |  |
| ${ }^{\text {tPZH }}$ | DIR | A or B | 3 | 19 | 3 | 16 | ns |
| tPZL |  |  | 3 | 21 | 3 | 18 |  |
| tPHZ | DIR | A or B | 2 | 12 | 2 | 10 | ns |
| ${ }_{\text {t PLZ }}$ |  |  | 2 | 12 | 2 | 10 |  |

'AS648 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то IOUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS648 |  | SN74AS648 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 75 |  | 90 |  | MHz |
| tPLH | CBA or CAB | $A$ or $B$ | 2 | 9.5 | 2 | 8.5 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 |  |
| tPLH | $A$ or $B$ | $B$ or A | 2 | 9 | 2 | 8 | ns |
| tPHL |  |  | 1 | 8 | 1 | 7 |  |
| tPLH | SBA or SAB ${ }^{\dagger}$ | $A$ or B | 2. | 12 | 2 | 11 | ns |
| tpHL |  |  | 2 | 10 | 2 | 9 |  |
| tPZH | $\overline{\mathrm{G}}$ | $A$ or $B$ | 2 | 10 | 2 | 9 | ns |
| tPZL |  |  | 3 | 18 | 3 | 15 |  |
| tPHZ | $\overline{\mathrm{G}}$ | $A$ or B | 2 | 11 | 2 | 9 | ns |
| tPLZ |  |  | 2 | 11 | 2 | 9 |  |
| tPZH | DIR | $A$ or $B$ | 3 | 19 | 3 | 16 | ns |
| tPZL |  |  | 3 | 21 | 3 | 18 |  |
| tPHz | DIR | $A$ or $B$ | 2 | 12 | 2 | 10 | ns |
| tPLZ |  |  | 2 | 12 | 2 | 10 |  |

$\dagger$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Bus Transceivers/Registers
- Independent Registers and Enables for $A$ and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of True and Inverting Data Paths
- Choice of 3-State or Open-Collector Outputs to A Bus
- Included Among the Package Options Are Compact 24-Pin 300-mil-Wide DIPs and Both 28-Pin Plastic and Ceramic Chip Carriers
- Dependable Texas Instruments Quality and Reliability

| DEVICE | A OUTPUT | B OUTPUT | LOGIC |
| :---: | :---: | :---: | :---: |
| 'ALS651,'AS651 | 3-State | 3-State | Inverting |
| 'ALS652,'AS652 | 3-State | 3-State | True |
| 'ALS653 | Open-Collector | 3-State | Inverting |
| 'ALS654 | Open-Collector | 3-State | True |

## description

These devices consist of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Enable $G A B$ and $\bar{G} B A$ are provided to control the transceiver functions. SAB and SBA control pins are provided to select whether realtime or stored data is transferred. The circuitry used for select control will eliminate the typical decoding glitch which occurs in a multiplexer during the transition between stored and realtime data. A low input level selects real-time data, and a high selects stored data. The following examples demonstrate the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.
Data on the $A$ or $B$ data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins ( $C A B$ or CBA) regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling $G A B$ and $\bar{G} B A$. In this configuration each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

The -1 versions of the SN74ALS651 through SN74ALS654 are identical to the standard versions except that the recommended maximum IOL is increased to 48 milliamperes. There are no -1 versions of the SN54ALS651 through SN54ALS654.
The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


SN54ALS651 THRU SN54ALS654, SN54AS651, SN54AS652 SN74ALS651 THRU SN74ALS654, SN74AS651, SN74AS652 OCTAL BUS TRANSCEIVERS AND REGISTERS

| FUNCTION TABLE |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUTS |  |  |  |  |  | DATA I/O |  | OPERATION OR FUNCTION |  |
| GAB | GBA | CAB | CBA | SAB | SBA | A1 THRU A8 | B1 THRU 88 | 'ALS651, 'ALS653 'AS651 | 'ALS652, 'ALS654 'AS652 |
| $\begin{aligned} & \mathrm{L} \\ & \mathrm{~L} \end{aligned}$ | $\begin{aligned} & \mathrm{H} \\ & \mathrm{H} \end{aligned}$ | $\mathrm{H} \text { or } \mathrm{L}$ | $\mathrm{H} \text { or } \mathrm{L}$ |  | $\begin{array}{r} \hline x \\ x \\ \hline \end{array}$ | Input | Input | Isolation <br> Store A and B Data | Isolation <br> Store A and B Data |
| $\begin{aligned} & X \\ & X \\ & H \end{aligned}$ | $\begin{aligned} & \mathrm{H} \\ & \mathrm{H} \\ & \hline \end{aligned}$ |  | H or L | $\begin{aligned} & x \\ & x^{\ddagger} \end{aligned}$ | $\begin{aligned} & \hline x \\ & x \\ & \hline \end{aligned}$ | Input <br> Input | Unspecified ${ }^{\dagger}$ Output | Store A, Hold B <br> Store $A$ in both registers | Store A, Hold B <br> Store $A$ in both registers |
| $\begin{aligned} & \mathrm{L} \\ & \mathrm{~L} \end{aligned}$ | $x$ | $\mathrm{H} \text { or } \mathrm{L}$ |  | $x$ | $\begin{aligned} & x \\ & x^{\ddagger} \end{aligned}$ | Unspecified ${ }^{\dagger}$ Output | Input <br> Input | Hold A, Store B <br> Store $B$ in both registers | Hold A, Store B <br> Store $B$ in both registers |
| L | L | $\begin{aligned} & \hline x \\ & x \end{aligned}$ | $\begin{gathered} \mathrm{X} \\ \mathrm{H} \text { or } \mathrm{L} \end{gathered}$ | $x$ | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ | Output | Input | Real-Time $\bar{B}$ Data to A Bus Stored $\bar{B}$ Data to $A$ Bus | Real-Time B Data to A Bus Stored B Data to A Bus |
| H H | H H | $\begin{gathered} x \\ H \text { or } L \end{gathered}$ |  | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ | $\begin{aligned} & x \\ & x \\ & \hline \end{aligned}$ | Input | Output | Real-Time $\bar{A}$ Data to $B$ Bus Stored $\bar{A}$ Data to B Bus | Real-Time A Data to B Bus Stored A Data to B Bus |
| H | L | Hor L | H or L | H | H | Output | Output | Stored $\bar{A}$ Data to $B$ Bus and Stored $\bar{B}$ Data to $A$ Bus | Stored A Data to B Bus and Stored B Data to A Bus |

${ }^{1}$ The data output functions may be enabled or disabled by various signals at the GAB or $\bar{G} B A$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.
${ }^{\ddagger}$ Select control $=$ L: clocks can occur simultaneously.
Select control $=\mathrm{H}$ : clocks must be staggered in order to load both registers.
logic diagrams (positive logic)
'ALS651, 'AS651, 'ALS653
'ALS652, 'AS652, 'ALS654


Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS651 THRU SN54ALS654, SN54AS651, SN54AS652 <br> SN74ALS651 THRU SN74ALS654, SN74AS651, SN74AS652 OCTAL BUS TRANSCEIVERS AND REGISTERS

logic symbols ${ }^{\dagger}$

'ALS653


'ALS654

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 6.17-12.
Pin numbers shown are for DW. JT, and NT packages.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC | 7 V |
| :---: | :---: |
| Input voltage: Control inputs | 7 V |
| I/O ports | 5.5 V |
| Operating free-air temperature range: SN54ALS651, SN54ALS652 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74ALS651, SN74ALS652 | ..$^{\circ}{ }^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

${ }^{\dagger}$ The extended condition applies if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V . The $48-\mathrm{mA}$ limit applies for the SN74ALS651-1 and SN74ALS652-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^17]$\$$ For $/ / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
TThe output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

SN54ALS651, SN54ALS652, SN74ALS651, SN74ALS652
OCTAL BUS TRANSCEIVERS AND REGISTERS
'ALS651 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline A L S 651 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega \\ & \mathrm{R} 2=500 \Omega \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN | 51 |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 50 |  | 35 |  | 40 |  | MHz |
| tPLH | CBA or CAB | A or B |  | 20 | 27 | 10 | 38 | 10 | 32 | ns |
| ${ }^{\text {t }} \mathrm{PHL}$ |  |  |  | 11 | 15 | 5 | 21 | 5 | 17 |  |
| tPLH | A or B | $B$ or $A$ |  | 9 | 13 | 4 | 20 | 4 | 18 | ns |
| tPHL |  |  |  | 5 | 8 | 2 | 12 | 2 | 10 |  |
| tPLH | SBA or SAB ${ }^{\dagger}$ (with $A$ or $B$ high) | A or B |  | 24 | 31 | 13 | 45 | 13 | 38 | ns |
| tPHL |  |  |  | 13 | 18 | 7 | 25 | 7 | 21 |  |
| ${ }^{\text {PLLH }}$ | SBA or SAB ${ }^{\dagger}$ <br> (with A or B low) | A or B |  | 15 | 20 | 8 | 30 | 8 | 25 | ns |
| ${ }_{\text {t }}^{\text {PHL }}$ |  |  |  | 13 | 18 | 7 | 25 | 7 | 21 |  |
| tPZH | $\overline{\mathrm{G}} \mathrm{BA}$ | A |  | 12 | 16 | 5 | 22 | 5 | 20 | ns |
| tPZL |  |  |  | 11 | 15 | 5 | 21 | 5 | 18 |  |
| tPHZ | ḠBA | A |  | 4 | 7 | 2 | 10 | 2 | 9 | ns |
| ${ }^{\text {tPLZ }}$ |  |  |  | 7 | 10 | 3 | 16 | 3 | 12 |  |
| ${ }^{\text {tPZH }}$ | GAB | B |  | 14 | 19 | 7 | 25 | 7 | 22 | ns |
| $t_{P Z L}$ |  |  |  | 13 | 18 | 7 | 25 | 7 | 21 |  |
| tpHz | GAB | B |  | 5 | 10 | 2 | 14 | 2 | 12 | ns |
| tPLZ |  |  |  | 7 | 10 | 2 | 20 | 2 | 14 |  |

'ALS652 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R^{\prime}=500 \Omega . \\ & R_{2}=500 \Omega, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline \text { ALS } 652 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{A}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MLN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 50 |  | 35 |  | 40 |  | MHz |
| tPLH | CBA or CAB | $A$ or B |  | 20 | 25 | 10 | 35 | 10 | 30 | ns |
| tPHL |  |  |  | 11 | 15 | 5 | 20 | 5 | 17 |  |
| ${ }^{\text {t PLH }}$ | $A$ or B | $B$ or A |  | 11 | 15 | 5 | 20 | 5 | 18 | ns |
| ${ }^{\text {tPHL}}$ |  |  |  | 8 | 10 | 3 | 15 | 3 | 12 |  |
| ${ }_{\text {tPLH }}$ | SBA or SAB ${ }^{\dagger}$ (with $A$ or $B$ high) | A or B |  | 24 | 32 | 15 | 40 | 15 | 35 | ns |
| tPHL |  |  |  | 13 | 17 | 6 | 23 | 6 | 20 |  |
| tPLH | SBA or SAB ${ }^{\dagger}$ (with A or B low) | $A$ or B |  | 17 | 22 | 8 | 30 | 8 | 25 | ns |
| tPHL |  |  |  | 13 | 17 | 5 | 24 | 5 | 20 |  |
| ${ }_{\text {tPZH }}$ | $\overline{\mathrm{G}} \mathrm{BA}$ | A |  | 10 | 15 | 3 | 20 | 3 | 17 | ns |
| ${ }_{\text {t PRL }}$ |  |  |  | 10 | 14 | 5 | 22 | 5 | 18 |  |
| tPHZ | $\overline{\mathrm{G}} \mathrm{BA}$ | A |  | 6 | 8 | 1 | 12 | 1 | 10 | ns |
| ${ }^{\text {tPLZ }}$ |  |  |  | 10 | 13 | 2 | 20 | 2 | 16 |  |
| ${ }_{\text {PZ }}$ | GAB | B |  | 15 | 20 | 8 | 25 | 8 | 22 | -ns ${ }^{-}$ |
| tPZL |  |  |  | 12 | 16 | 6 | 21 | 6 | 18 |  |
| ${ }^{\text {P PHZ }}$ | GAB | B |  | 6 | 8 | 1 | 12 | 1 | 10 | ns |
| ${ }^{\text {tPLZ }}$ |  |  |  | 10 | 13 | 2 | 21 | 2 | 16 |  |

[^18]absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
\[

$$
\begin{aligned}
& \text { Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V } \\
& \text { Input voltage: All inputs and A I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V } \\
& \text { B I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 5.5 \mathrm{~V} \\
& \text { Operating free-air temperature range: SN54ALS653, SN54ALS654 . . . . . . . . . . . . . . . . . . . . }-55^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \\
& \text { SN74ALS653, SN74ALS654 } \\
& .0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \\
& \text { Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . }-65^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}
\end{aligned}
$$
\]

recommended operating conditions

${ }^{\dagger}$ The extended condition applies if $V_{C C}$ is maintained between 4.75 V and 5.25 V . The $48-\mathrm{mA}$ limit applies for the SN74ALS653-1 and SN74ALS654-1 only.
electrical characteristics over recommended operating free-air temparature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS653 <br> SN54ALS654 |  |  | SN74ALS653 SN74ALS654 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| VOH | B ports | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , | $\mathrm{IOH}^{\prime}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-3 \mathrm{~mA}$ | 2.43 .2 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-12 \mathrm{~mA}$ | 2 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-15 \mathrm{~mA}$ |  |  |  | 2 |  |  |  |
| ${ }^{\mathrm{IOH}}$ | A ports | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{VOL}_{\text {OL }}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | v |
|  |  | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{CC}}=4.75 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA} \\ & \text { ( } \mathrm{OL}=48 \mathrm{~mA} \text { for }-1 \text { versions) } \end{aligned}$ |  |  |  |  |  | 0.35 | 0.5 |  |
| 1 | Control inputs | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | A or B ports | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| IIH | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | A or B ports ${ }^{\ddagger}$ |  |  |  |  | 20 |  |  | 20 |  |
| ILL | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
|  | A or B ports ${ }^{\ddagger}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |
| $10{ }^{\prime}$ | B ports | $\mathrm{v}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{\text {I C C }}$ | 'ALS653 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high | 52 |  |  | 52 |  |  | mA |
|  |  |  | Outputs low | 57 |  |  | 57 |  |  |  |
|  |  |  | Outputs disabled | 58 |  |  | 58 |  |  |  |
|  | 'ALS654 |  | Outputs high | 60 |  |  | 60 |  |  |  |
|  |  |  | Outputs low | 68 |  |  | 68 |  |  |  |
|  |  |  | Outputs disabled | 68 |  |  | 68 |  |  |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For I/P ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{IIL}^{2}$ include the off-state output current.
$\S$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

## 'ALS653 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{\mathrm{L}}=50 \mathrm{pF}, \\ & R_{\mathrm{L}}=680 \Omega,(\mathrm{~A} \text { outputs) } \\ & \mathrm{R}_{1}=\mathrm{R} 2=500 \Omega, \text { (B outputs) } \\ & \mathrm{T}_{\mathrm{A}}=\text { MIN to } \mathrm{MAX} \end{aligned}$ |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54ALS653 |  | SN74ALS653 |  |  |  |
|  |  |  | MIN TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{+}$ | MAX |  |
| $f_{\text {max }}$ |  |  |  |  |  |  |  | MHz |
| tPLH | CBA | A | 24 |  |  | 24 |  | ns |
| tPHL |  |  | 15 |  |  | 15 |  |  |
| tplH | CAB | B | 11 |  |  | 11 |  | ns |
| tPHL |  |  | 13 |  |  | 13 |  |  |
| tPLH | A | B | 10 |  |  | 10 |  | ns |
| tPHL |  |  | 12 |  |  | 12 |  |  |
| tPLH | B | A | 24 |  |  | 24 |  | ns |
| tPHL |  |  | 10 |  |  | 10 |  |  |
| ${ }^{\text {tPLH }}$ | SBA ${ }^{\ddagger}$ | A | 26 |  |  | 26 |  | ns |
| tPHL | (with B high) |  | 15 |  |  | 15 |  |  |
| tPLH | SBA ${ }^{\ddagger}$ | A | 26 |  |  | 26 |  | ns |
| tPHL | (with B low) |  | 15 |  |  | 15 |  |  |
| tPLH | SAB ${ }^{\ddagger}$ | B | 16 |  |  | 16 |  | ns |
| tPHL | (with A high) |  | 16 |  |  | 16 |  |  |
| tPLH | SAB ${ }^{\ddagger}$ | B | 15 |  |  | 15 |  | ns |
| ${ }^{\text {PPHL }}$ | (with A low) |  | 15 |  |  | 15 |  |  |
| tpLH | GBA | A | 24 |  |  | 24 |  | ns |
| ${ }_{\text {tPHL }}$ |  |  | 17 |  |  | 17 |  |  |
| tPZH | GAB | B | 19 |  |  | 19 |  | ns |
| tPZL |  |  | 22 | , |  | 22 |  |  |
| tpHZ | GAB | 8 | 12 |  |  | 12 |  | ns |
| tPLZ |  |  | 14 |  |  | 14 |  |  |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

Additional information on these products can be obtained from the factory as it becomes available.
'ALS654 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=680 \Omega,(A \text { outputs }) \\ & \mathrm{R}_{1}=\mathrm{R} 2=500 \Omega,(B \text { outputs }) \\ & \mathrm{T}_{\mathrm{A}}=\text { MIN to } \mathrm{MAX} \end{aligned}$ |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54ALS |  | SN | 74ALS 6 |  |  |
|  |  |  | MIN TYP ${ }^{\dagger}$ | MAX | MIN | TYp ${ }^{\text {t }}$ | MAX |  |
| $f_{\text {max }}$ |  |  |  |  |  |  |  | MHz |
| ${ }_{\text {tPLH }}$ | CBA | A | 24 |  |  | 24 |  | ns |
| tPHL |  |  | 15 |  |  | 15 |  |  |
| tPLH | CAB | B | 11 |  |  | 11 |  | ns |
| tpHL |  |  | 13 |  |  | 13 |  |  |
| tPLH | A | B | 8 |  |  | 8 |  | ns |
| tPHL |  |  | 8 |  |  | 8 |  |  |
| tPLH | B | A | 24 |  |  | 24 |  | ns |
| tPHL |  |  | 10 |  |  | 10 |  |  |
| ${ }^{\text {tPLH }}$ | $\begin{gathered} \text { SBA }^{\ddagger} \\ \text { (with B high) } \end{gathered}$ | A | 26 |  |  | 26 |  | ns |
| tPHL |  |  | 15 |  |  | 15 |  |  |
| tPLH | SBA $^{\ddagger}$(with B low) | A | 26 |  |  | 26 |  | ns |
| tPHL |  |  | 15 |  |  | 15 |  |  |
| tPLH | $\mathrm{SBA}^{\ddagger}$(with A high) | B | 16 |  |  | 16 |  | ns |
| tPHL |  |  | 16 |  |  | 16 |  |  |
| tpLH | $\mathrm{SAB}^{\ddagger}$(with A low) | B | 15 |  |  | 15 |  | ns |
| tPHL |  |  | 12 |  |  | 12 |  |  |
| tpLH | ḠBA | A | 24 |  |  | 24 |  | ns |
| tpHL |  |  | 17 |  |  | 17 |  |  |
| tPZH | GAB | B | 19 |  |  | 19 |  | ns |
| tPZL |  |  | 22 |  |  | 22 |  |  |
| tPHZ | GAB | B | 12 |  |  | 12 |  | ns |
| tPLZ |  |  | 14 |  |  | 14 |  |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

Additional information on these products can be obtained from the factory as it becomes available.

## SN54AS651, SN54AS652, SN74AS651, SN74AS652 oCTAL buS transceivers and registers

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

$$
\begin{aligned}
& \text { Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V } \\
& \text { Input voltage: Control inputs . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V } \\
& \text { I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 5.5 \mathrm{~V} \\
& \text { Operating free-air temperature range: SN54AS651, SN54AS652 . . . . . . . . . . . . . . . . . . . . . }-55^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \\
& \text { SN74AS651, SN74AS652 . . . . . . . . . . . . . . . . . . . . . . . . . . . } 0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \\
& \text { Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . - } 65^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}
\end{aligned}
$$

recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS651 <br> SN54AS652 |  |  | SN74AS651 <br> SN74AS652 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| VOH |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , | $\mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$. | $\mathrm{IOH}^{\mathrm{OH}}=-3 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.4 | 3.2 |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\mathrm{O}}=-12 \mathrm{~mA}$ | 2 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-15 \mathrm{~mA}$ |  |  |  | 2 |  |  |  |
| VOL |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=32 \mathrm{~mA}$ |  | 0.25 | 0.50 |  |  |  | V |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\mathrm{OL}}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.50 |  |
| 1 | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | A or B ports | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| IH | Control inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | A or B ports ${ }^{\ddagger}$ |  |  |  |  | 70 |  |  | 70 |  |
| IIL | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
|  | A or B ports ${ }^{\ddagger}$ |  |  |  |  | -0.75 |  |  | -0.75 |  |
| $10^{8}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | $-30$ |  | -112 | -30 |  | -112 | mA |
| ${ }^{\text {I C C }}$ | 'AS651 | $V_{C C}=5.5 \mathrm{~V}$ | Outputs high |  | 110 | 185 |  | 110 | 185 | mA |
|  |  |  | Outputs low |  | 120 | 195 |  | 120 | 195 |  |
|  |  |  | Outputs disabled |  | 130 | 195 |  | 130 | 195 |  |
|  | 'AS652 |  | Outputs high |  | 120 | 195 |  | 120 | 195 |  |
|  |  |  | Outputs low |  | 130 | 211 |  | 130 | 211 |  |
|  |  |  | Outputs disabled |  | 130 | 211 |  | 130 | 211 |  |

[^19]
## 'AS651 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=\operatorname{MIN} \text { to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS651 |  | SN74AS651 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 75 |  | 90 |  | MHz |
| ${ }^{\text {tPLH }}$ | CBA or CAB | A or B | 2 | 9.5 | 2 | 8.5 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 | ns |
| tPLH | A or B | $B$ or $A$ | 2 | 9 | 2 | 8 |  |
| tPHL |  |  | 1 | 8 | 1 | 7 | ns |
| tPLH | SBA or SAB ${ }^{\dagger}$ | A or.B | 2 | 12 | 2 | 11 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 | ns |
| tPZH | $\overline{\mathrm{G}} \mathrm{BA}$ | A | 2 | 11 | 2 | 10 | ns |
| tPZL |  |  | 3 | 18 | 3 | 16 | ns |
| tPHZ | $\overline{\mathrm{G}} \mathrm{BA}$ | A | 2 | 10 | 2 | 9 | ns |
| tPLZ |  |  | 2 | 10 | 2 | 9 |  |
| tPZH | GAB | B | 3 | 12 | 3 | 11 | s |
| tpZL |  |  | 3 | 20 | 3 | 16 | ns |
| tPHZ | GAB | B | 2 | 11 | 2 | 10 | ns |
| tPLZ |  |  | 2 | 12 | 2 | 11 |  |

'AS652 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} . \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R2}=500 \Omega, \\ & T_{A}=\text { MIN to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS652 |  | SN74AS652 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 75 |  | 90 |  | MHz |
| tPLH | CBA or CAB | A or B | 2 | 9.5 | 2 | 8.5 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 | ns |
| tPLH | $A$ or B | $B$ or A | 2 | 11 | 2 | 9 |  |
| tPHL |  |  | 1 | 8 | 1 | 7 | ns |
| tPLH | SBA or SAB ${ }^{\dagger}$ | $A^{\prime}$ or B | 2 | 12 | 2 | 11 | ns |
| tPHL. |  |  | 2 | 10 | 2 | 9 | ns |
| tPZH | $\overline{\mathrm{G}} \mathrm{BA}$ | A | 2 | 11 | 2 | 10 | ns |
| tpZL |  |  | 3 | 18 | 3 | 16 | ns |
| tPHZ | $\overline{\mathrm{G}} \mathrm{BA}$ | A | 2 | 10 | 2 | 9 | ns |
| tPLZ |  |  | 2 | 10 | 2 | 9 |  |
| tPZH | GAB | B | 3 | 12 | 3 | 11 | ns |
| tPZL |  |  | 3 | 20 | 3 | 16 |  |
| tPHZ | GAB | B | 2 | 11 | 2 | 10 | ns |
| tPLZ |  |  | 2 | 12 | 2 | 11 | ns |

$\dagger$ These parameters are measured with the internal output state of the storage register opposite to that of the bus input. NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- 3-State I/O-Type Read-Back Inputs

Bus-Structured Pinout

- Choice of True or Inverting Logic
'ALS666 . . . True Outputs
'ALS667 . . . Inverting Outputs
- Preset and Clear Inputs
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramics DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 8-bit latches are designed specifically for storing the contents of the input data bus plus providing the capability of reading-back the stored data onto the input data bus. In addition, they provide a 3-state buffer type output and are easily utilized in bus-structured applications.
The eight latches of the 'ALS666 and 'ALS667 are transparent D-type. While the enable ( $C$ ) is high, the Q outputs of the 'ALS666 will follow the data ( $D$ ) inputs. On the 'ALS667, the $\overline{\mathrm{Q}}$ outputs will provide the inverse of what is applied to its data ( $D$ ) inputs. On both devices, the Q or $\overline{\mathrm{Q}}$ output will be in the high-impedance state if either output control, $\overline{\mathrm{OE}} 1$ or $\overline{\mathrm{OE}} 2$, is at a high logic level.

Read-back is provided thru the read-back control input ( $\overline{O E R B}$ ). When $\overline{\text { OERB }}$ is taken low, the data present at the output of the data latches will be allowed to pass back onto the input data bus. When it is taken high, the output of the data latches will be isolated from the data (D) inputs. The read-back control does not affect the internal operation of the latches; however, caution should be exercised not to create a busconflict situation.

The SN54ALS666 and SN54ALS667 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS666 and SN75ALS667 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN54ALS667 . . JT PACKAGE
SN74ALS667 . . DW OR NT PACKAGE
(TOP VIEW)


NC-No internal connection.
logic symbols ${ }^{\dagger}$
'ALS666

'ALS667

$\dagger_{\text {These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12 }}$
Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS666, SN54ALS667, SN74ALS666, SN74ALS667 8-BIT D-TYPE TRANSPARENT READ-BACK LATCHES WITH 3-STATE OUTPUTS

logic diagrams (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS666, SN54ALS667, SN74ALS666, SN74ALS667 <br> 8-BIT D-TYPE TRANSPARENT READ-BACK LATCHES <br> WITH 3-STATE OUTPUTS

timing diagram

$\overline{\mathrm{CLR}}=H, \overline{\mathrm{PRE}}=H, \overline{\mathrm{OE}} 1=L, \overline{\mathrm{OE} 2}=L$
*This setup time ensures the readback circuit will not create a conflict on the input data bus.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
$\qquad$
CC
Input voltage (all inputs except D input)

Storage temperature range
$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | SN54ALS666 <br> SN54ALS667 |  |  | SN74ALS666 SN74ALS667 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High-level output current | Q |  |  | -1 |  |  | -2.6 | mA |
|  |  | D |  |  | -0.4 |  |  | -0.4 |  |
|  | Load-level output current | Q |  |  | 12 |  |  | 24 | mA |
| ${ }^{1} \mathrm{OL}$ |  | D |  |  | 4 |  |  | 8 |  |
|  |  | Enable C high | 15 |  |  | 10 |  |  | ns |
| ${ }^{\text {w }}$ | Pulse duration | CLR low | 10 |  |  | 10 |  |  |  |
|  |  | $\overline{\text { PRE }}$ low | 10 |  |  | 10 |  |  |  |
| ${ }^{\text {t }}$ su | Setup time | Data before C $\downarrow$ | 15 |  |  | 10 |  |  | ns |
|  |  | Data before $\overline{\text { OERB }} \downarrow$ | 15 |  |  | 10 |  |  |  |
| $t_{\text {h }}$ | Hold time | Data after Cl | 10 |  |  | 5 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

## SN54ALS666, SN54ALS667, SN74ALS666, SN74ALS667 8-BIT D.TYPE TRANSPARENT READ-BACK LATCHES WITH 3-STATE OUTPUTS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For I/O ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ inctude the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half the true short-circuit output currents, IOS.

SN54ALS666, SN54ALS667, SN74ALS666, SN74ALS667

## 8-BIT D-TYPE TRANSPARENT READ-BACK LATCHES

WITH 3-STATE OUTPUTS
'ALS666 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ { }^{\prime} \mathrm{ALS} 666 \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | D | Q |  | 7 | 10 | 3 | 18 | 3 | 14 | ns |
| tPHL |  |  |  | 11 | 15 | 4 | 22 | 4 | 18 |  |
| tPLH | C | 0 |  | 12 | 16 | 6 | 25 | 6 | 21 | ns |
| tPHL |  |  |  | 16 | 21 | 8 | 32 | 8 | 27 |  |
| tPHL | $\overline{C L R}$ | Q |  | 17 | 22 | 9 | 32 | 9 | 29 | ns |
| tPHL |  | D |  | 17 | 24 | 11 | 36 | 11 | 32 |  |
| tPLH | $\overline{\text { PRE }}$ | 0 |  | 13 | 18 | 7 | 28 | 7 | 22 | ns |
| tpHL |  | D |  | 17 | 22 | 9 | 35 | 9 | 28 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{\text { OERB }}$ | D |  | 11 | 17 | 4 | 25 | 4 | 21 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 6 | 11 | 1 | 18 | 1 | 14 |  |
| ${ }_{\text {t }}{ }^{\text {d }}$ | $\overline{\mathrm{OE}} 1, \overline{\mathrm{OE}} 2$ | 0 |  | 11 | 17 | 4 | 25 | 4 | 21 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 6 | 11 | 1 | 18 | 1 | 14 |  |

'ALS667 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ \hline \text { ALS667 } \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} . \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  | SN |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }_{\text {tPLH }}$ | D | $\overline{\mathrm{o}}$ |  | 13 | 17 | 6 | 24 | 6 | 20 | ns |
| tPHL |  |  |  | 9 | 13 | 4 | 18 | 4 | 15 |  |
| ${ }^{\text {tPLH }}$ | C | $\overline{\mathrm{O}}$ |  | 18 | 23 | 9 | 35 | 9 | 28 | ns |
| tPHL |  |  |  | 14 | 19 | 7 | 27 | 7 | 22 |  |
| tPLH | $\overline{C L R}$ | $\overline{\mathrm{a}}$ |  | 14 | 19 | 7 | 28 | 7 | 24 | ns |
| tPHL |  | D |  | 17 | 23 | 8 | 30 | 8 | 26 |  |
| tPHL | $\overline{\text { PRE }}$ | $\overline{\mathrm{O}}$ |  | 17 | 23 | 8 | 30 | 8 | 25 | ns |
| tPLH |  | D |  | 18 | 25 | 9 | 35 | 9 | 28 |  |
| $\mathrm{t}_{\mathrm{e}}$ | $\overline{\text { OERB }}$ | D |  | 11 | 17 | 4 | 25 | 4 | 21 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 6 | 11 | 1 | 20 | 1 | 14 |  |
| $\mathrm{t}_{\mathrm{e}}$ | $\overline{\mathrm{OE}} 1, \overline{\mathrm{OE}} 2$ | $\overline{\mathrm{O}}$ |  | 11 | 17 | 4 | 25 | 4 | 21 | ns |
| ${ }_{\text {d }{ }_{\text {dis }} \text { }}$ |  |  |  | 6 | 11 | 1 | 20 | 1 | 14 |  |

$t_{\text {en }}=$ tPZH $^{\text {or tPZL }}$
$t_{\text {dis }}=$ tpHZ or tPLZ

# SN54ALS666, SN54ALS667, SN74ALS666, SN74ALS667 8-BIT D-TYPE TRANSPARENT READ-BACK LATCHES WITH 3-STATE OUTPUTS 

## PARAMETER MEASUREMENT INFORMATION



FIGURE 1


## SN54AS821, SN54AS822, SN74AS821, SN74AS822 10-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

- Functionally Equivalent to AMD's AM29821 and AM29822
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Outputs Have Undershoot Protection Circuitry
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Carriers in Addition to Plastic and Ceramic DIPs
- Buffered Control Inputs to Reduce DC Loading Effects
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit flip-flops feature three-state outputs designed specifically for driving highlycapacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, $1 / O$ ports, bidirectional bus drivers with parity, and working registers.

The ten flip-flops are edge-triggered D-type flipflops. On the positive transition of the clock the Q outputs on the 'AS821 will be true, and on the 'AS822 will be complementary to the data input.

A buffered output-control input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. In the high-impedance state the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control ( $\overline{\mathrm{OC}}$ ) does not affect the internal operation of the flipflops. Old data can be retained or new data can be entered while the outputs are in the highimpedance state.

The SN54AS' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN54AS821 . . . JT PACKAGE SN74AS821 . . . DW OR NT PACKAGE (TOP VIEW)

| OC口 | $\left.\mathrm{J}_{24}\right] \mathrm{VCC}$ |
| :---: | :---: |
| $10{ }_{2}$ | ${ }_{23}{ }^{2} 10$ |
| $2 \mathrm{C} \mathrm{C}_{3}$ | 22.20 |
| $3 \mathrm{C} \square^{4}$ | 21.30 |
| $4 \mathrm{DC5}$ | 20740 |
| 50.6 | 1950 |
| 60 ¢ | 18.60 |
| $70{ }^{8}$ | $17{ }^{170}$ |
| 8 C 9 | 16.80 |
| 90.10 | ${ }^{15}{ }^{1} 90$ |
| 100 ${ }^{11}$ | 14.100 |
| GND ${ }_{1}$ | ${ }_{13}$ CLK |

SN54AS821 . . . FK PACKAGE SN74AS821 . . . FN PACKAGE (TOP VIEW)


SN54AS822 . . . JT PACKAGE SN74AS822 . . . DW OR NT PACKAGE (TOP VIEW)

| OCD | $\cup_{24} \square \mathrm{~V}_{\mathrm{CC}}$ |
| :---: | :---: |
| 1吅 2 | 23 110 |
| $2 \overline{\text { D }}$ | $22-20$ |
| 30.04 | 21.30 |
| $4 \overline{\mathrm{D}} \mathrm{C}^{5}$ | $20 \bigcirc 40$ |
| 50. 6 | 1950 |
| 6 - 7 | 18 -60 |
| 7D-18 | 1770 |
| 8 믕 | $16] 80$ |
| 90. 10 | 15.90 |
| 10D ${ }^{11}$ | 14100 |
| GND 12 | 13 ] CLK |

SN54AS822 . . . FK PACKAGE SN74AS822 . . . FN PACKAGE (TOP VIEW)


NC-No internal connection

SN54AS821, SN74AS821
10-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTS
'AS821 FUNCTION TABLE (EACH FLIP-FLOP)

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\overline{O C}$ | CLK | D | Q |
| L | $\uparrow$ | $H$ | $H$ |
| $L$ | $\uparrow$ | $L$ | $L$ |
| $L$ | $L$ | $X$ | $Q_{O}$ |
| $H$ | $X$ | $X$ | $Z$ |

## 'AS821 logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
'AS821 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.
'AS822 FUNCTION TABLE (EACH FLIP-FLOP)

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\overline{O C}$ | CLK | D | Q |
| L | $\uparrow$ | $H$ | $H$ |
| L | $\uparrow$ | L | L |
| L | L | X | $\mathrm{Q}_{0}$ |
| H | X | X | Z |

'AS822 logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
'AS822 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54AS821, SN54AS822, SN74AS821, SN74AS822

10-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTS
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

recommended operating conditions

|  |  | SN54AS821 <br> SN54AS822 |  |  | SN74AS821 <br> SN74AS822 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{IOH}^{\text {I }}$ | High-level output current |  |  | -24 |  |  | -24 | mA |
| IOL | Low-level output current |  |  | 32 |  |  | 48 | mA |
| $t_{\text {w }}$ | Pulse duration, CLK high or low | 9 |  |  | 8 |  |  | ns |
| $t_{\text {su }}$ | Setup time, data before CLK $\uparrow$ | 7 |  |  | 6 |  |  | ns |
| $t_{\text {th }}$ | Hold time, data after CLK $\uparrow$ | 0 |  |  | 0 |  |  | ns |
| TA | Operating free-air temperature | -55 |  | 125 - | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS821 <br> SN54AS822 |  |  | SN74AS821 <br> SN74AS822 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to | $\mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}$ |  |  | $\mathrm{v}_{\mathrm{CC}}$ |  |  |  |
| VOH |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-15 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.4 | 3.2 |  | v |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-24 \mathrm{~mA}$ | 2 |  |  | 2 |  |  |  |
| VOL |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=32 \mathrm{~mA}$ |  | 0.25 | 0.5 |  |  |  | V |
| OL |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| ${ }^{\text {IOZH }}$ |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| ${ }_{10}{ }^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{\prime} \mathrm{CC}$ | 'AS821 | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$ | Outputs high |  | 55 | 88 |  | 55 | 88 | mA |
|  |  |  | Outputs low |  | 68 | 109 |  | 68 | 109 |  |
|  |  |  | Outputs disabled |  | 70 | 113 |  | 70 | 113 |  |
|  | 'AS822 |  | Outputs high |  | 55 | 88 |  | 55 | 88 |  |
|  |  |  | Outputs low |  | 68 | 109 |  | 68 | 109 |  |
|  |  |  | Outputs disabled |  | 70 | 113 |  | 70 | 113 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS821 <br> SN54AS822 |  | SN74AS821 <br> SN74AS822 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | CLK | Any Q | 3.5 | 9 | 3.5 | 7.5 | ns |
| tPHL |  |  | 3.5 | 11.5 | 3.5 | 10.5 |  |
| tPZH | $\overline{\mathrm{OC}}$ | Any 0 | 4 | 12 | 4 | 11 | ns |
| tPZL |  |  | 4 | 13 | 4 | 12 |  |
| tphz | $\overline{O C}$ | Any 0 | 2 | 10 | 2 | 8 | ns |
| tPZL |  |  | 2 | 10 | 2 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

| 5 |
| :--- |
| 6 |
| 0 |
| 0 |
| $\vdots$ |
|  |

## SN54AS823，SN54AS824 <br> SN74AS823，SN74AS824 <br> 9－BIT BUS INTERFACE FLIP－FLOPS WITH 3－STATE OUTPUTS <br> D2825，JUNE 1984－REVISED JANUARY 1986

－Functionally Equivalent to AMD＇s AM29823 and AM29824
－Provides Extra Data Width Necessary for Wider Address／Data Paths or Buses with Parity
－Outputs Have Undershoot Protection Circuitry
－Power－Up High－Impedance State
－Buffered Control Inputs to Reduce DC Loading Effects
－Package Options Include both Plastic and Ceramic Carriers in Addition to Plastic and Ceramic DIPs
－Dependable Texas Instruments Quality and Reliability

## description

These 9－bit flip－flops feature three－state outputs designed specifically for driving highly capacitive or relatively low－impedance loads．They are particularly suitable for implementing wider buffer registers，I／O ports，bidirectional bus drivers，parity bus interfacing and working registers．
With the clock enable（ $\overline{\text { CLKEN }}$ ）low，the nine $D$－ type edge－triggered flip－flops enter data on the low－to－high transitions of the clock．Taking CLKEN high will disable the clock buffer，thus latching the outputs．The＇AS823 has noninverting $D$ inputs and the＇AS824 has inverting $D$ inputs．Taking the $\overline{C L R}$ input low causes the nine Q outputs to go low independently of the clock．
A buffered output－control input（ $\overline{\mathrm{OC})}$ can be used to place the nine outputs in either normal logic state（high or low level）or a high－impedance state．In the high－impedance state the outputs neither load nor drive the bus lines significantly． The high－impedance state and increased drive provide the capability to drive the bus lines in a bus－organized system without need for interface or pull－up components．The output control does not affect the internal operation of the flip－flops． Old data can be retained or new data can be entered while the outputs are in the high－ impedance state．

```
SN54AS823 ．．．JT PACKAGE
SN74AS823 ．．．DW OR NT PACKAGE （TOP VIEW）
```



## SN54AS823 ．．．FK PACKAGE

 SN74AS823 ．．．FN PACKAGE （TOP VIEW）

SN54AS824 ．．．JT PACKAGE SN74AS824 ．．．DW OR NT PACKAGE （TOP VIEW）

| $\overline{\mathrm{OC}} \square^{1}$ | $\mathrm{U}_{24}$ | $V_{C C}$ |
| :---: | :---: | :---: |
| 1可 ${ }^{2}$ | 23 | 10 |
| $2 \overline{\mathrm{D}} \mathrm{C}^{3}$ | 22 | 20 |
| $3 \overline{\mathrm{D}} \mathrm{C}_{4}$ | 21 | 130 |
| 4 $\overline{\mathrm{D}}$－5 | 20 | 10 |
| 5可－ 6 | 19 | 150 |
| $6 \overline{\mathrm{D}} \mathrm{Cl}^{7}$ | 18 | 60 |
| $7 \overline{\text { D }}$ | 17 | 70 |
| 8 －${ }^{\text {－}}$ | 16 | 180 |
| $9 \overline{\mathrm{D}} \mathrm{C}_{10}$ | 15 | 190 |
| $\overline{C L R}$－11 | 14 | $\square$ CLKEN |
| GND 12 | 213 | ］CLK |

SN54AS824 ．．．FK PACKAGE SN74AS824 ．．．FN PACKAGE （TOP VIEW）


## 9-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTS

The SN54AS' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

|  |  |  |  |  | INPUTS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OUTPUT |  |  |  |  |  |
| OC | $\overline{\text { CLR }}$ | $\overline{\text { CLKEN }}$ | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | $\uparrow$ | H | H |
| L | H | L | $\uparrow$ | L | L |
| L | H | H | X | X | Q $_{0}$ |
| H | X | X | X | X | Z |

## 'AS823 logic symbol ${ }^{\dagger}$

| $\overline{O C} \frac{(1)}{\overline{C L R}}$ | EN |  |
| :---: | :---: | :---: |
| CLKEN (14) | G1 |  |
| CKEN (13) |  |  |
| CLK |  |  |
| $10^{(2)}$ | 2D | (23) 1 |
| 10 (3) | 2 D - | (22) |
| 20 (4) |  | (21) 30 |
| (5) |  | (20) |
| 4 D (6) |  | (19) |
| 5 D (7) |  | (18) |
| 6 b (8) |  | (17) 70 |
| 70 (9) |  | (16) |
| 80 (10) |  | (15) |

$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12
'AS823 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

| 'AS824 FUNCTION TABLE |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| InPUTS |  |  |  |  | $\begin{array}{\|c\|} \hline \text { OUTPUT } \\ 0 \end{array}$ |
| $\overline{\mathrm{OC}}$ | $\overline{\text { CLR }}$ | CLKEN | CLK | $\overline{\mathrm{D}}$ |  |
| L | L | X | X | X | L |
| L | H | L | $\dagger$ | H | L |
| L | H | L | $\uparrow$ | L | H |
| L | H | H | X | X | $0_{0}$ |
| H | X | X | X | X | z |

## 'AS824 logic symbol ${ }^{\dagger}$



[^20]'AS824 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54AS823, SN54AS824, SN74AS823, SN74AS824

9-BIT BUS INTERFACE FLIP-FLOPS WITH 3.STATE OUTPUTS

```
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V V
Input voltage .................................................................................. 7 V
Voltage applied to a disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 5 V
Operating free-air temperature range: SN54AS823, SN54AS824 .............. - 55 % C Co 125 %
SN74AS823, SN74AS824 . . . .............. . 0 }\mp@subsup{0}{}{\circ}\textrm{C}\mathrm{ to }7\mp@subsup{0}{}{\circ}\textrm{C
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . - 65 % C to 150 % C
```

recommended operating conditions

|  |  |  |  | $\begin{aligned} & \text { 54AS8 } \\ & 54 \mathrm{AS8} \end{aligned}$ |  |  | $\begin{aligned} & \text { 174AS8 } \\ & \hline 174 \mathrm{ASB} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{Cc}}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level outpu |  |  |  | -24 |  |  | -24 | mA |
| ${ }_{\text {IOL }}$ | Low-level outpu |  |  |  | 32 |  |  | 48 | mA |
|  | Pulse duration | CLR low | 5 |  |  | 4 |  |  | ns |
| $t_{\text {w }}$ | Pulse duration | CLK high or low | 9 |  |  | 8 |  |  | ns |
| ${ }_{\text {tsu }}$ | Setup time before CLK $\dagger$ | $\overline{\text { CLR }}$ inactive | 8 |  |  | 8 |  |  | ns |
|  |  | Data | 7 |  |  | 6 |  |  |  |
|  |  | $\overline{\text { CLKEN }}$ high or low | 7 |  |  | 6 |  |  |  |
| $t_{\text {h }}$ | Hold time, CLKEN or data after CLK $\dagger$ |  | 0 |  |  | 0 |  |  | ${ }^{\circ} \mathrm{ns}$ |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 |  |

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS823 <br> SN54AS824 |  |  | SN74AS823 <br> SN74AS824 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| VOH |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , $\mathrm{l}^{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | $\mathrm{V}_{\text {CC }}-2$ |  |  | $\checkmark$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad 1 \mathrm{OH}=-15 \mathrm{~mA}$ |  | 2.43 .2 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-24 \mathrm{~mA}$ | 2 |  |  | 2 |  |  |  |
| $\mathrm{V}_{\text {OL }}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=32 \mathrm{~mA}$ |  | 0.3 | 0.5 |  |  |  | V |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| lozi |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | $\begin{aligned} & \mathrm{mA} \\ & \mu \mathrm{~A} \\ & \hline \end{aligned}$ |
| $\mathrm{I}_{\text {IH }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 |  |
| IIL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{\ddagger}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC | 'AS823 |  | Outputs high |  | 49 | 80 |  | 49 | 80 | mA |
|  |  | $V_{C C}=5.5 \mathrm{~V}$ | Outputs low |  | 61 | 100 |  | 61 | 100 |  |
|  |  |  | Outputs disabled |  | 64 | 103 |  | 64 | 103 |  |
|  | 'AS824 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 49 | 80 |  | 49 | 80 | mA |
|  |  |  | Outputs low |  | 61 | 100 |  | 61 | 100 |  |
|  |  |  | Outputs disabled |  | 64 | 103 |  | 64 | 103 |  |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }_{\text {tpLH }}$ | CLK | Any 0 | 3.5 | 9 | 3.5 | 7.5 | ns |
| ${ }_{\text {t }}$ |  |  | 3.5 | 12 | 3.5 | 11 |  |
| ${ }^{\text {tPHL }}$ | $\overline{\text { CLR }}$ | Any 0 | 3.5 | 14 | 3.5 | 13 | ns |
| tPZH | $\overline{\mathrm{OC}}$ | Any 0 | 4 | 12 | 4 | 11 | ns |
| tPZL |  |  | 4 | 13 | 4 | 12 |  |
| tPHZ | $\overline{O C}$ | Any Q | 2 | 10 | 2 | 8 | ns |
| tPLZ |  |  | 2 | 10 | 2 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## D flip-flop signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type flip-flop and to draw its logic symbol based on the assumption of true data (D) inputs. Then outputs that produce data in phase with the data inputs are called Q and those producing complementary data are called Q . An input that causes a Q output to go high or a Q output to go low is called Preset; an input that causes a Q output to go high or a Q output to go low is called Clear. Bars are used over these pin names (PRE and CLR) if they are active-low.

The devices on this data sheet are second-source designs and the pin-name convention used by the original manufacturer has been retained. That makes it necessary to designate the inputs and outputs of the inverting circuit $D$ and $Q$. In some applications it may be advantageous to redesignate the inputs and outputs as $D$ and $Q$. In that case, outputs should be renamed as shown below. Also shown are corresponding changes in the graphical symbol. Arbitrary pin numbers are shown in parentheses.
Notice that Q and Q exchange names, which causes Preset and Clear to do likewise. Also notice that the polarity indicators ( $\triangle$ ) on PRE and CLR remain since these inputs are still active-low, but that the presence or absence of the polarity changes at $D, Q$, and $Q$. Of course pin $5(Q)$ is still in phase with the data input $D$, but now both are considered active high.


- Functionally Equivalent to AMD's AM29825 and AM29826
- Improved IOH Specifications
- Multiple Output Enables Allow Multiuser Control of the Interface
- Outputs Have Undershoot Protection Circuitry
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Buffered Control Inputs to Reduce DC Loading Effect
- Dependable Texas Instruments Quality and Reliability


## description

These 8-bit flip-flops feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing multiuser registers, I/O ports, bidirectional bus drivers, and working registers.
With the clock enable ( $\overline{\mathrm{CLKEN}}$ ) low, the eight D type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking $\overline{\text { CLKEN }}$ high will disable the clock buffer, thus latching the outputs. The 'AS825 has noninverting D inputs and the 'AS826 has inverting $\overline{\mathrm{D}}$ inputs. Taking the $\overline{\mathrm{CLR}}$ input low causes the eight Q outputs to go low independently of the clock.

Multiuser buffered output-control inputs ( $\overline{O C} 1$, $\overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ ) can be used to place the eight outputs in either a normal logic state (high or low level) or a high-impedance state. In the highimpedance state the outputs neither load nor drive the bus lines significantly. The highimpedance state and increased drive provide the capability to drive the bus lines in a busorganized system without need for interface or pull-up components. The output controls do not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

```
    SN54AS825 . . . JT PACKAGE
SN74AS825 . . DW OR NT PACKAGE
(TOP VIEW)
```

| OC1 ${ }^{\circ}$ | $\mathrm{U}_{24}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| $\overline{\mathrm{OC}} 2 \mathrm{~L}^{2}$ | 23 | OC3 |
| 10 ${ }^{3}$ | 22 | 10 |
| $2 \mathrm{D} \mathrm{H}^{4}$ | 21 | 20 |
| $30-5$ | 20 | 30 |
| 40 $\square^{6}$ | 19 | - 40 |
| 50-7 | 18 | 50 |
| $60{ }^{8}$ | 17 | 60 |
| 70 9 | 16 | 70 |
| 8 D 10 | 15 | 80 |
| $\overline{\text { CLR }} 11$ | 14 | $\overline{\text { CLKEN }}$ |
| GND 12 | 13 | CLK |

SN54AS825 . . . FK PACKAGE SN74AS825 . . . FN PACKAGE (TOP VIEW)


SN54AS826 . . . JT PACKAGE SN74AS826 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{\mathrm{OC}} 1{ }^{1}$ | $\mathrm{U}_{24}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| $\overline{\mathrm{OC}} 2$ | 23 | OC3 |
| 10 ${ }^{3}$ | 22 | 10 |
| $2 \overline{\mathrm{D}} \square^{4}$ | 21 | 120 |
| 3D - 5 | 20 | 30 |
| 4 $\overline{\text { - }} 6$ | 19 | 40 |
|  | 18 | 50 |
| $6 \bar{\square}$ | 17 | 60 |
|  | 16 | ] 70 |
| 80̄ 10 | 15 | 80 |
| $\overline{\text { CLR }} 11$ | 14 | CLKEN |
| GND 12 | 13 | $\square \mathrm{CLK}$ |

SN54AS826 . . . FK PACKAGE SN74AS826 . . . FN PACKAGE (TOP VIEW)


NC - No internal connection

The SN54AS' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
'AS825 FUNCTION TABLE

| INPUTS |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathbf{O C}$ | CLR | $\overline{\text { CLKMEN }}$ | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | $\uparrow$ | H | H |
| L | H | L | $\uparrow$ | L | L |
| L | H | H | X | X | $Q_{0}$ |
| H | X | X | X | X | Z |

$\overline{\mathrm{OC}} *=H$ if any of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, or $\overline{\mathrm{OC}} 3$ are high.
$\overline{\mathrm{OC}}^{*}=\mathrm{L}$ if all of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ are low.

## 'AS825 logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
'AS825 logic diagram (positive logic)


| 'AS826 FUNCTION TABLE |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| INPUTS |  |  |  |  | OUTPUT |
| $\overline{\mathrm{O}}{ }^{*}$ | $\overline{\text { CLR }}$ | CLKEN | CLK | D | 0 |
| L | L | X | X | X | L. |
| L | H | L | $\dagger$ | H | L |
| L | H | L | $\dagger$ | L | H |
| L | H | H | $x$ | x | $0_{0}$ |
| H | X | X | X | X | z |

$\overline{\mathrm{OC}} *=\mathrm{H}$ if any of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, or $\overline{\mathrm{OC}} 3$ are high.
$\overline{\mathrm{OC}}^{*}=\mathrm{L}$ if all of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ are low.

## 'AS826 logic symbol ${ }^{\dagger}$


$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12
'AS826 logic diagram (positive logic)


## SN54AS825, SN54AS826, SN74AS825, SN74AS826 8-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage | 7 V |
| :---: | :---: |
| Input voltage | 7 V |
| Voltage applied to a disabled 3 -state output | 5.5 V |
| Operating free-air temperature range: |  |
| SN54AS825, SN54AS826 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74AS825, SN74AS826 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | -65 to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

| : |  |  | SN54AS825 <br> SN54AS826 |  |  | SN74AS825 SN74AS826 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\text {I }} \mathrm{OH}$ | High-level output current |  |  |  | -24 |  |  | -24 | mA |
| ${ }^{\text {OL }}$ |  |  |  |  | 32 |  |  | 48 | mA |
| $t_{w}$ | Pulse duration | $\overline{\text { CLR }}$ low | 5 |  |  | 4 |  |  | ns |
|  |  | CLK high or low | 9 |  |  | 8 |  |  |  |
| $\mathrm{t}_{\text {su }}$ | Setup time before CLK $\uparrow$ | CLR inactive | 8 |  |  | 8 |  |  | ns |
|  |  | Data | 7 |  |  | 6 |  |  |  |
|  |  | $\overline{\text { CLKEN }}$ high or low | 7 |  |  | 6 |  |  |  |
| $\mathrm{t}_{\mathrm{h}}$ | Hold time, $\overline{\text { CLKEN }}$ or data after CLK $\uparrow$ <br> Operating free-air temperature |  | 0 |  |  | 0 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ |  |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS825 <br> SN54AS826 |  |  | SN74AS825 <br> SN74AS826 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{l}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ t | $\mathrm{I}^{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}-2}$ |  |  | V |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-15 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.4 | 3.2 |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-24 \mathrm{~mA}$ | 2 |  |  | 2 |  |  |  |
| $\mathrm{V}_{\text {OL }}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=32 \mathrm{~mA}$ |  | 0.3 | 0.5 |  |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| Iozh |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| Iozl |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ILL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{ \pm}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 | -112 |  | mA |
| ICC | 'AS825 | $V_{C C}=5.5 \mathrm{~V}$ | Outputs high |  | 45 | 73 |  | 45 | 73 | mA |
|  |  |  | Outputs low |  | 56 | 90 |  | 56 | 90 |  |
|  |  |  | Outputs disabled |  | 59 | 95 |  | 59 | 95 |  |
|  | 'AS826 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 45 | 73 |  | 45 | 73 | mA |
|  |  |  | Outputs low |  | 56 | 90 |  | 56 | 90 |  |
|  |  |  | Outputs disabled |  | 59 | 95 |  | 59 | 95 |  |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

## SN54AS825, SN54AS826, SN74AS825, SN74AS826 8-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | CLK | Any 0 | 3.5 | 9 | 3.5 | 7.5 | ns |
| ${ }_{\text {tPHL }}$ |  |  | 3.5 | 11.5 | 3.5 | 11 |  |
| ${ }^{\text {tPHL }}$ | $\overline{\text { CLR }}$ | Any 0 | 3.5 | 14 | 3.5 | 13 | ns |
| tPZH | $\overline{O C}$ | Any 0 | 4 | 12 | 4 | 11 | ns |
| tPZL |  |  | 4 | 13 | 4 | 12 |  |
| ${ }^{\text {tPHZ }}$ | $\overline{\mathrm{OC}}$ | Any 0 | 2 | 10 | 2 | 8 | ns |
| tplz |  |  | 2 | 10 | 2 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## D flip-flop signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type flip-flop and to draw its logic symbol based on the assumption of true data (D) inputs. Then outputs that produce data in phase with the data inputs are called Q and those producing complementary data are called $\overline{\mathrm{Q}}$. An input that causes a Q output to go high or a $\overline{\mathrm{Q}}$ output to go low is called Preset; an input that causes a $\overline{\mathrm{Z}}$ output to go high or a Q output to go low is called Clear. Bars are used over these pin names ( $\overline{\mathrm{PRE}}$ and $\overline{\mathrm{CLR}}$ ) if they are active-low.
The devices on this data sheet are second-source designs and the pin-name convention used by the original manufacturer has been retained. That makes it necessary to designate the inputs and outputs of the inverting circuit $\overline{\mathrm{D}}$ and Q . In some applications it may be advantageous to redesignate the inputs and outputs as D and $\overline{\mathrm{O}}$. In that case, outputs should be renamed as shown below. Also shown are corresponding changes in the graphical symbol. Arbitrary pin numbers are shown in parentheses.
Notice that Q and $\overline{\mathrm{Q}}$ exchange names, which causes Preset and Clear to do likewise. Also notice that the polarity indicators ( $\Delta$ ) on PRE and CLR remain since these inputs are still active-low, but that the presence or absence of the polarity indicator changes at $\overline{\mathrm{D}}, \mathrm{Q}$, and $\overline{\mathrm{Q}}$. Of course $\operatorname{pin} 5(Q)$ is still in phase with the data input $D$, but now both are considered active high.


## SN54ALS841, SN54AS841, SN54ALS842, SN54AS842 <br> SN74ALS841, SN74AS841, SN74ALS842, SN74AS842 <br> 10-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

O2910, DECEMBER 1983-REVISED OCTOBER 1985

- 3-State Buffer-Type Outputs Drive Bus-Lines Directly
- Bus-Structured Pinout
- Provide Extra Bus Driving Latches Necessary for Wider Address/Data Paths or Buses with Parity
- Buffered Control Inputs to Reduce DC Loading
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit latches feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The ten latches are transparent D-type. The 'ALS841 and 'AS841 have noninverting data (D) inputs. The 'ALS842 and 'AS842 have inverting $\overline{\mathrm{D}}$ inputs.

A buffered output control $(\overline{O C})$ input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components.
The output control does not affect the internal operation of the latches. Old data can be retained or new data can be entered while the outputs are off.

The -1 versions of the SN74ALS841 and SN74ALS842 parts are identical to the standard versions except that the recommended maximum loL is increased to 48 milliamperes. There are no -1 versions of the SN54ALS841 and SN54ALS842.


SN54ALS842, SN54AS842 . . . JT PACKAGE SN74ALS842, SN74AS842 . . . DW OR NT PACKAGE (TOP VIEW)


SN54ALS842, SN54AS842 . . . FK PACKAGE SN74ALS842, SN74AS842 . . . FN PACKAGE (TOP VIEW)



NC-No internal connection

## SN54ALS841, SN54AS841, SN54ALS842, SN54AS842 <br> SN74ALS841, SN74AS841, SN74ALS842, SN74AS842 <br> 10-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

The SN54ALS841, SN54AS841, SN54ALS842, and SN54AS842 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS841, SN74AS841, SN74ALS842, and SN74AS842 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

FUNCTION TABLES
'ALS841, 'AS841

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\mathbf{O C}$ | C | D | Q |
| L | $H$ | $H$ | $H$ |
| L | $H$ | L | L |
| L | L | X | Q $_{0}$ |
| $H$ | $X$ | $X$ | $Z$ |

'ALS841, 'AS841 logic symbol ${ }^{\dagger}$

'ALS842, 'AS842

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\overline{\mathbf{O C}}$ | $\mathbf{C}$ | $\overline{\mathbf{D}}$ | $\mathbf{Q}$ |
| $\mathbf{L}$ | H | H | L |
| L | H | L | H |
| L | L | X | $\mathrm{Q}_{0}$ |
| H | X | X | Z |

'ALS841, 'AS841 logic diagram (positive logic)

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS842, 'AS842 logic symbol ${ }^{\dagger}$

$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS842, 'AS842 logic diagram (positive logic)

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
$\qquad$Supply voltage, VCC7 V
Input voltage ..... 7 V
Voltage applied to a disabled 3 -state output ..... 5.5 V
Operating free-air temperature range:
SN54ALS841, SN54AS841, SN54ALS842, SN54AS842 ............ . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$

$$
\text { SN74ALS841, SN74AS841, SN74ALS842, SN74AS842 . . . . . . . . . . . . . . } 0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}
$$

Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## recommended operating conditions


${ }^{\dagger}$ The extended limit applies only if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V . The 48 mA limit applies for SN74ALS841-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54ALS841 |  |  | SN74ALS841 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{VOH}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, 1 \mathrm{OH}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  |  |  |  |  |
|  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| VoL | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\text {a }}$, 12 mA |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA} \\ & \left(\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA} \text { for }-1\right. \text { versions) } \end{aligned}$ |  |  |  |  | 0.35 |  | 0.5 |  |
| IOZH | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IL | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{\S}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 | -112 |  | mA |
| ICC |  | Outputs high |  | 19 | 30 |  | 19 | 30 | mA |
|  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs low |  | 38 | 62 |  | 38 | 62 |  |
|  |  | Outputs disabled |  | 23 | 40 |  | 23 | 40 |  |

$\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
'ALS841 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=25^{\circ} \mathrm{C} \end{aligned}$SN54/74ALS841 |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \\ & \hline \end{aligned}$ |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | 4ALS | 341 |  | 4ALS |  |  |
|  |  |  | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX |  |
| ${ }^{\text {tPLH }}$ | D | 0 |  | 8.5 | 11 | 2 |  | 15 | 2 |  | 13 | ns |
| tPHL |  |  |  | 8.5 | 11 | 2 |  | 15 | 2 |  | 13 |  |
| ${ }_{\text {tPLH }}$ | C | 10 |  | 14 | 18 | 7 |  | 25 | 7 |  | 21 | ns |
| tPHL |  |  |  | 17 | 23 | 8 |  | 30 | 8 |  | 26 |  |
| tPZH | $\overline{\mathrm{OC}}$ | 0 |  | 7.5 | 10 | 2 |  | 14 | 2 |  | 12 | ns |
| tPZL |  |  |  | 7.5 | 10 | 2 |  | 14 | 2 |  | 12 |  |
| tPHZ | $\overline{\mathrm{OC}}$ | 0 |  | 6 | 8 | 2 |  | 12 | 2 |  | 10 | ns |
| tplz |  |  |  | 7 | 9 | 2 |  | 14 | 2 |  | 12 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54ALS842, SN74ALS842 <br> 10-BIT BUS INTERFACE D.TYPE LATCHES WITH 3-STATE OUTPUTS

recommended operating conditions

|  |  | SN54ALS842 |  |  | SN74ALS842 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{C C}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{I} \mathrm{OH}}$ | High-level output current |  |  | -1 |  |  | -2.6 | mA |
|  | Low-level output current |  |  | 12 |  |  | 24 | mA |
|  |  |  |  |  |  |  | $48^{\dagger}$ |  |
|  | Pulse duration, enable C high | 25 |  |  | 20 |  |  | ns |
| ${ }^{\text {tsu }}$ | Setup time, data before enable C $\downarrow$ | 16 |  |  | 10 |  |  | ns |
| $t_{\text {h }}$ | Hold time, data after enable C $\downarrow$ | 7 |  |  | 5 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The extended limit applies only if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V . The 48 mA limit applies for SN74ALS841-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54ALS842 |  |  | SN74ALS842 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MI | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ | -1.2 |  |  | -1.2 |  |  | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ t | $\mathrm{IOH}^{\prime}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  |  |  |  |  |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\text {OL }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA} \\ & (\mathrm{IOL}=48 \mathrm{~mA} \text { for }-1 \text { versions }) \end{aligned}$ |  |  |  |  | 0.35 |  | 0.5 |  |
| IOZH | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IozL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=0.4$ |  |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, $\quad \mathrm{V}_{1}=7 \mathrm{~V}$ |  |  |  | 0.1 |  |  | 0.1 | mA |
| IIH | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| ILL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{\S}$ | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | - 30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{1} \mathrm{CC}$ |  | Outputs high |  | 20 | 35 |  | 20 | 35 | mA |
|  | $V_{C C}=5.5 \mathrm{~V}$ | Outputs low |  | 48 | . 74 |  | 48 | 74 |  |
|  |  | Outputs disabled |  | 27 | 44 |  | 27 | 44 |  |

${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
'ALS842 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \text { ALS842 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\operatorname{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | SN54ALS842 |  | SN74ALS842 |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | $\overline{\text { D }}$ | 0 |  | 11 | 15 | 4 | 22 | 4 | 18 | ns |
| tPHL |  |  |  | 8 | 11 | 3 | 17 | 3 | 13 |  |
| tPLH | C | 0 |  | 17 | 23 | 8 | 31 | 8 | 27 | ns |
| tPHL |  |  |  | 13 | 18 | 6 | 24 | 6 | 20 |  |
| tPZH | $\overline{\mathrm{OC}}$ | 0 |  | 8 | 10 | 2 | 14 | 2 | 12 | ns |
| tPZL |  |  |  | 8 | 11 | 2 | 14 | 2 | 12 |  |
| tPHZ | $\overline{\mathrm{OC}}$ | Q |  | 6 | 8 | 1 | 12 | 1 | 10 | ns |
| tPLZ |  |  |  | 7 | 9 | 2 | 14 | 2 | 12 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54AS841, SN54AS842 <br> SN74AS841, SN74AS842 <br> 10-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

recommended operating conditions

|  |  | SN54AS841 SN54AS842 |  |  | $\begin{aligned} & \text { SN74AS841 } \\ & \text { SN74AS842 } \end{aligned}$ |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | $\checkmark$ |
| $\mathrm{IOH}^{1}$ | High-level output current |  |  | -24 |  |  | -24 | mA |
| IOL | Low-level output current |  |  | 32 |  |  | 48 | mA |
| $t_{\text {w }}$ | Pulse duration, enable C high | 5 |  |  | 4 |  |  | ns |
| ${ }_{\text {t }}{ }_{\text {du }}$ | Setup time, data before enable $\mathrm{C} \downarrow$ | 3.5 |  |  | 2.5 |  |  | ns |
| $\mathrm{t}_{\mathrm{h}}$ | Hold time, data after enable C $\downarrow$ | 3.5 |  |  | 2.5 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS841 SN54AS842 |  |  | SN74AS841 <br> SN74AS842 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{VOH}^{\text {O }}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{cc}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-15 \mathrm{~mA}$ | 2.43 .2 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-24 \mathrm{~mA}$ | $2$ |  |  | 2 |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=32 \mathrm{~mA}$ |  | 0.25 | 0.5 |  |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| IOZH |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{IIH}^{\text {H }}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IL |  | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{\ddagger}$ |  | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | $-30$ |  | -112 | mA |
| Icc | 'AS841 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 36 | 60 |  | 36 | 60 | mA. |
|  |  |  | Outputs low |  | 58 | 94 |  | 58 | 94 |  |
|  |  |  | Outputs disabled |  | 56 | 92 |  | 56 | 92 |  |
|  | 'AS842 |  | Outputs high |  | 38 | 62 |  | 38 | 62 |  |
|  |  |  | Outputs low |  | 60 | 97 |  | 60 | 97 |  |
|  |  |  | Outputs disabled |  | 58 | 95 |  | 58 | 95 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
-AS841 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS841 |  | SN74AS841 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }_{\text {tPLH }}$ | D | 0 | 1 | 8.5 | 1 | 6.5 | ns |
| ${ }_{\text {t }}$ PHL |  |  | ก 1 | 10 | 1 | 9 |  |
| tPLH | C | 0 | 2 | 13 | 2 | 12 | ns |
| ${ }^{\text {t PHL }}$ |  |  | 2 | 13 | 2 | 12 |  |
| tPZH | $\overline{O C}$ | 0 | 2 | 13.5 | 2 | 10.5 | ns |
| tPZL |  |  | 2 | 15 | 2 | 13.5 |  |
| tPHZ | $\overline{O C}$ | 0 | 1 | 10 | 1 | 8 | ns |
| ${ }_{\text {t PLZ }}$ |  |  | 1 | 10 | 1 | 8 |  |

'AS842 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS842 |  | SN74AS842 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | $\overline{\text { D }}$ | 0 | 1 | 11 | 1 | 8.5 | ns |
| tPHL |  |  | 1 | 10 | 1 | 9 |  |
| tPLH | C | 0 | 2 | 13 | 2 | 12 | ns |
| tPHL |  |  | 2 | 13 | 2 | 12 |  |
| tPZH | $\overline{\mathrm{OC}}$ | 0 | 2 | 14.5 | 2 | 12 | ns |
| tpZL |  |  | 2 | 15 | 2 | 12.5 |  |
| tPHZ | $\overline{\mathrm{OC}}$ | 0 | 1 | 10 | 1 | 8 | ns |
| tPLZ |  |  | 1 | 10 | 1 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

# SN54ALS843，SN54AS843，SN54ALS844，SN54AS844 <br> SN74ALS843，SN74AS843，SN74ALS844，SN74AS844 <br> 9－BIT BUS INTERFACE D－TYPE LATCHES WITH 3－STATE OUTPUTS 

D2910，DECEMBER 1983－REVISED DECEMBER 1985
－3－State Buffer－Type Outputs Drive Bus－Lines Directly
－Bus－Structured Pinout
－Provide Extra Bus Driving Latches
Necessary for Wider Address／Data Paths or Buses with Parity
－Buffered Control Inputs to Reduce DC Loading
－Power－Up High Impedance
－Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
－Dependable Texas Instruments Quality and Reliability

## description

These 9－bit latches feature three－state outputs designed specifically for driving highly capacitive or relatively low－impedance loads．They are particularly suitable for implementing buffer registers，I／O ports，bidirectional bus drivers，and working registers．

The nine latches are transparent D－type．The ＇ALS843 and＇AS843 have noninverting data（D） inputs．The＇ALS844 and＇AS844 have inverting $D$ inputs．

A buffered output control（ $\overline{(O C}$ ）input can be used to place the nine outputs in either a normal logic state（high or low levels）or a high－impedance state．In the high－impedance state，the outputs neither load nor drive the bus lines significantly． The high－impedance state and increased drive provide the capability to drive the bus lines in a bus－organized system without need for interface or pull－up components．

The output control（ $\overline{\mathrm{OC}}$ ）does not affect the internal operation of the flip－flops．Old data can be retained or new data can be entered while the outputs are off．
The -1 versions of the SN74ALS843 and SN74ALS844 parts are identical to the standard versions except that the recommended maximum IOL is increased to 48 milliamperes． There are no -1 versions of the SN54ALS843 and SN54ALS844．
SN54ALS843，SN54AS843 ．．．JT PACKAGE SN74ALS843，SN74AS843 ．．DW OR NT PACKAGE （TOP VIEW）

| $\overline{O C} \square^{1}$ | $\mathrm{U}_{24} \square \mathrm{~V}_{\text {CC }}$ |
| :---: | :---: |
| 10 2 | $23] 10$ |
| 20 3 | 22.20 |
| 3D ${ }^{4}$ | $21] 30$ |
| $4 \mathrm{D} \square^{5}$ | $20] 40$ |
| 50 ${ }^{6}$ | 19 －50 |
| 60 7 | 18 －60 |
| 70 8 | 17 70 |
| 8 C | $16 \bigcirc 80$ |
| 9D 10 | 1590 |
| CLR 11 | 14.7 PRE |
| GND 12 | $13 \bigcirc \mathrm{C}$ |

SN54ALS843，SN54AS843．．．FK PACKAGE SN74ALS843，SN74AS843 ．．．FN PACKAGE （TOP VIEW）

SN54ALS844，SN54AS844 ．．．JT PACKAGE SN74ALS844，SN74AS844 ．．DW OR NT PACKAGE （TOP VIEW）

SN54ALS844，SN54AS844 ．．．FK PACKAGE SN74ALS844，SN74AS844 ．．．FN PACKAGE
（TOP VIEW）
只保将 Z Y＞무

NC－No internal connection

SN54ALS843, SN54ASB43, SN54ALS844, SN54AS844 SN74ALS843, SN74AS843, SN74ALS844, SN74AS844 9-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

The SN54ALS843, SN54AS843, SN54ALS844, and SN54AS844 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS843, SN74AS843, SN74ALS844, and SN74AS844 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
'ALS843. 'AS843 FUNCTION TABLE

| INPUTS |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { PRE }}$ | $\overline{\text { CLR }}$ | $\overline{\text { OC }}$ | C | D | O |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | L |
| H | H | L | H | H | H |
| H | H | L | L | X | QO |
| X | X | H | X | X | Z |

'ALS843, 'AS843 logic symbol ${ }^{\dagger}$

$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS843, 'AS843 logic diagram (positive logic)


## SN54ALS843, SN54AS843, SN54ALS844, SN54AS844 <br> SN74ALS843, SN74AS843, SN74ALS844, SN74AS844 9-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

'ALS844, 'AS844 FUNCTION TABLE

| INPUTS |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { PRE }}$ | $\overline{\text { CLR }}$ | $\overline{\text { OC }}$ | C | $\overline{\text { D }}$ | Q |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | H |
| H | H | L | H | H | L |
| H | H | L | L | X | Q O $^{\text {O }}$ |
| X | X | H | X | X | $Z$ |

'ALS844, 'AS844 logic symbol ${ }^{\dagger}$

† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS844, 'AS844 logic diagram (positive logic)

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ ..... 7 V
Input voltage ..... 7 V
Voltage applied to a disabled 3 -state output ..... 5.5 V
Operating free-air temperature range: SN54ALS', SN54AS' ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$SN74ALS', SN74AS' . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$Storage temperature range$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

SN54ALS843, SN54ALS844
SN74ALS843, SN74ALS844
9-bIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

## recommended operating conditions


${ }^{\dagger}$ The 48-mA limit applies for SN74ALS843-1 and SN74ALS844-1 only and only if $\mathrm{V}_{\mathrm{C}}$ is maintained between 4.75 V and 5.25 V .
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, ios.
'ALS843 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF} \\ & R 1=500 \Omega \\ & R 2=500 \Omega \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \mathrm{C}^{\prime} \text { ALS843 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R1}=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {t PLH }}$ | D | Q |  | 7 | 11 | 2 | 15 | 2 | 13 | ns |
| ${ }_{\text {tPHL }}$ |  |  |  | 11 | 15 | 4 | 20 | 4 | 18 |  |
| tPLH | C | Q |  | 12 | 18 | 5 | 25 | 5 | 21 | ns |
| tPHL |  |  |  | 16 | 23 | 8 | 30 | 8 | 26 |  |
| tPLH | $\overline{\text { PRE }}$ | Q |  | 13 | 19 | 5 | 25 | 5 | 22 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 19 | 26 | 4 | 35 | 6 | 30 |  |
| ${ }^{\text {tPLH }}$ | $\overline{C L R}$ | Q |  | 19 | 26 | 4 | 35 | 6 | 30 | ns |
| tPHL |  |  |  | 14 | 21 | 6 | 27 | 6 | 23 |  |
| ${ }_{\text {tPZH }}$ | $\overline{O C}$ | Q |  | 7 | 10 | 2 | 14 | 2 | 12 | ns |
| tPZL |  |  |  | 9 | 12 | 4 | 16 | 4 | 14 |  |
| tPHZ | $\overline{O C}$ | Q |  | 6 | 9 | 2 | 12 | 2 | 10 | ns |
| tPLZ |  |  |  | 7 | 10 | 2 | 14 | 2 | 12 |  |

'ALS844 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega . \\ & \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \text { ALS844 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | $\overline{\text { D }}$ | 0 |  | 11 | 16 | 4 | 22 | 4 | 20 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 9 | 13 | 3 | 17 | 3 | 15 |  |
| tPLH | C | 0 |  | 17 | 24 | 8 | 32 | 8 | 29 | ns |
| tPHL |  |  |  | 14 | 19 | 6 | 26 | 6 | 22 |  |
| tPLH | $\overline{\text { PRE }}$ | Q |  | 13 | 19 | 5 | 25 | 5 | 22 | ns |
| tPHL |  |  |  | 19 | 26 | 4 | 35 | 6 | 30 |  |
| tPLH | $\overline{C L R}$ | 0 |  | 19 | 26 | 4 | 35 | 6 | 30 | ns |
| tPHL |  |  |  | 16 | 23 | 8 | 29 | 8 | 25 |  |
| tPZH | $\overline{\mathrm{OC}}$ | 0 |  | 10 | 15 | 2 | 19 | 4 | 17 | ns |
| tPZL |  |  |  | 12 | 18 | 3 | 22 | 5 | 20 |  |
| tPHZ | $\overline{\mathrm{OC}}$ | 0 |  | 7 | 10 | 1 | 12 | 1 | 11 | ns |
| tplZ |  |  |  | 5 | 9 | 1 | 14 | $!$ | 12 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

SN54AS843, SN54AS844
SN74AS843, SN74AS844
9-bIT BUS INTERFACE D-TYPE LATCHES WITH 3.STATE OUTPUTS
recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS843 SN54AS844 |  |  | SN74AS843 SN74AS844 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1{ }_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 |  |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{cc}}-2$ |  |  | $\mathrm{V}_{\mathrm{cc}}-2$ |  |  | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-15 \mathrm{~mA}$ | 2.43 .2 |  |  | 2.43 .2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-24 \mathrm{~mA}$ | 2 |  |  | 2 |  |  |  |
| $\mathrm{VOL}_{\text {O }}$ |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{OLL}=32 \mathrm{~mA}$ |  | 0.25 | 0.5 |  |  |  | $v$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| Iozh |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| 1 IL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $V_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{\ddagger}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| Icc | 'AS843 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | Outputs high |  | 37 | 62 |  | 37 | 62 | $\mathrm{mA}$ |
|  |  |  | Outputs low |  | 56 | 92 |  | 56 | 92 |  |
|  |  |  | Outputs disabled |  | 56 | 92 |  | 56 | 92 |  |
|  | 'AS844 |  | Outputs high |  | 39 | 64 |  | 39 | 64 |  |
|  |  |  | Outputs low |  | 58 | 95 |  | 58 | 95 |  |
|  |  |  | Outputs disabled |  | 58 | 95 |  | 58 | 95 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

SN54AS843, SN54AS844
SN74AS843, SN74AS844

## 9-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

'AS843 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathbf{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\operatorname{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS843 |  | SN74AS843 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | D | 0 | 1 | 8.5 | 1 | 6.5 | ns |
| tPHL |  |  | 1 | 10 | 1 | 9 |  |
| tPLH | C | 0 | 2 | 13 | 2 | 12 | ns |
| tphi |  |  | 2 | 13 | 2 | 12 |  |
| tPLH | $\overline{\text { PRE }}$ | 0 | 2 | 12 | 2 | 10 | ns |
| tpHL | $\overline{C L R}$ | 0 | 2 | 14 | 2 | 13 | ns |
| tPZH | $\overline{O C}$ | Q | 2 | 13.5 | 2 | 10.5 | ns |
| tPZL |  |  | 2 | 15 | 2 | 13.5 |  |
| tPHZ | $\overline{O C}$ | 0 | 1 | 10 | 1 | '8 | ns |
| ${ }^{\text {tPLZ }}$ |  |  | 1 | 10 | 1 | 8 |  |

'AS844 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \mathrm{\Omega}, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS844 |  | SN74AS844 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | D | 0 | 1 | 11 | 1 | 8.5 | ns |
| tPHL |  |  | 1 | 11 | 1 | 10 |  |
| ${ }^{\text {t PLH }}$ | C | 0 | 2 | 14 | 2 | 12.5 | ns |
| tPHL |  |  | 2 | 14 | 2 | 13 |  |
| ${ }^{\text {tPLH }}$ | $\overline{\text { PRE }}$ | 0 | 2 | 12 | 2 | 10 | ns |
| ${ }^{\text {tPHL }}$ | $\overline{\mathrm{CLR}}$ | Q | 2 | 14.5 | 2 | 13.5 | ns |
| tPZH | $\overline{O C}$ | Q | 2 | 14.5 | 2 | 12 | ns |
| tPZL |  |  | 2 | 15 | 2 | 13.5 |  |
| tPHZ | $\overline{O C}$ | 0 | 1 | 10 | 1 | 8 | ns |
| tplZ |  |  | 1 | 10 | 1 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## D latch signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type latch and to draw its logic symbol based on the assumption of true data (D) inputs. Then outputs that produce data in phase with the data inputs are called $\bar{Q}$ and those producing complementary data are called $\bar{Q}$. An input that causes a $Q$ output to go high or a $\overline{\mathrm{Q}}$ output to go low is called Preset; an input that causes a $\overline{\mathrm{Q}}$ output to go high or a Q output to go low is called Clear. Bars are used over these pin names ( $\overline{\operatorname{PRE}}$ and $\overline{\mathrm{CLR}}$ ) if they are active low. The devices on this data sheet are second-source designs and the pin-name conventions used by the original manufacturer have been retained. That makes it necessary to designate the data inputs and outputs of the inverting circuit $\overline{\mathrm{D}}$ and Q .
In some applications it may be advantageous to redesignate the inputs and outputs $\overline{\mathrm{D}}$ and $\overline{\mathrm{Q}}$ for the noninverting circuits or D and $\overline{\mathrm{Q}}$ for the inverting circuits. In that case signal names should change as shown below. Also shown are corresponding changes in the logic symbols.
Notice that Q becoming $\overline{\mathrm{Q}}$ causes $\overline{\mathrm{PRE}}$ and $\overline{\mathrm{CLR}}$ to exchange their names and their S and R function labels. The presence or absense of polarity indicators $(\triangle)$ changes at the data inputs and outputs, but not at $\overline{\mathrm{PRE}}, \overline{\mathrm{CLR}}$, and $\overline{\mathrm{OC}}$ since these inputs are still active-low.
'ALS843. 'AS843

'ALS844, 'AS844
(

# SN54ALS845，SN54AS845，SN54ALS846，SN54AS846 <br> SN74ALS845，SN74AS845，SN74ALS846，SN74AS846 <br> 8－BIT BUS INTERFACE D－TYPE LATCHES WITH 3－STATE OUTPUTS <br> D2825，DECEMBER 1983－REVISED JANUARY 1986 

－3－State Buffer－Type Outputs Drive Bus－Lines Directly
－Bus－Structured Pinout
－Provides Extra Bus Driving Latches Necessary for Wider Address／Data Paths or Buses with Parity
－Buffered Control Inputs to Reduce DC Loading
－Power－Up High－Impedance State
－Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
－Dependable Texas Instruments Quality and Reliability

## description

These 8－bit latches feature three－state outputs designed specifically for driving highly capacitive or relatively low－impedance loads．They are particularly suitable for implementing buffer registers，I／O ports，bidirectional bus drivers，and working registers．

The eight latches are transparent D－type．The ＇ALS845 and＇AS845 have noninverting data（D） inputs．The＇ALS846 and＇AS846 have inverting $\overline{\mathrm{D}}$ inputs．Since $\overline{\mathrm{CLR}}$ and $\overline{\mathrm{PRE}}$ are independent of the clock，taking the $\overline{C L R}$ input low will cause the eight Q outputs to go low．Taking the $\overline{\mathrm{PRE}}$ input low will cause the eight $Q$ outputs to go high．When both $\overline{P R E}$ and $\overline{C L R}$ are taken low，the outputs will follow the preset condition．
The buffered output control inputs（ $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$ ， and $\overline{\mathrm{OC}} 3$ ）can be used to place the eight outputs in either a normal logic state（high or low levels） or a high－impedance state．In the high－ impedance state，the outputs neither load nor drive the bus lines significantly．The high－ impedance state and increased drive provide the capability to drive the bus lines in a bus－ organized system without need for interface or pull－up components．The output controls do not affect the internal operation of the latches．Old data can be retained or new data can be entered while the outputs are in the high－impedance state．

SN54ALS845，SN54AS845 ．．．JT PACKAGE SN74ALS845，SN74AS845 ．．DW OR NT PACKAGE （TOP VIEW）

| C1 | $\cup_{24} \mathrm{~V}_{\mathrm{CC}}$ |
| :---: | :---: |
| $\overline{\mathrm{OC}} 2 \mathrm{Cl}^{2}$ | $23 \bigcirc \overline{\mathrm{OC}} 3$ |
| 10 3 | $22 \rightarrow 10$ |
| 20 4 | $21 \square 20$ |
| 3D 5 | 20.30 |
| 40 6 | 19 － 40 |
| $50 \square$ | 18.50 |
| 60 8 | 17 －60 |
| 70［9 | $16 \square 70$ |
| 80 10 | 1580 |
| CLR 11 | 14 PRE |
| GND 12 | $13 . \mathrm{C}$ |

SN54ALS845，SN54AS845 ．．．FK PACKAGE
SN74ALS845，SN74AS845 ．．．FN PACKAGE
（TOP VIEW）


SN54ALS846，SN54AS846 ．．．JT PACKAGE SN74ALS846，SN74AS846 ．．．DW OR NT PACKAGE （TOP VIEW）

| $\overline{\mathrm{OC}} 1{ }^{1}$ | $\mathrm{U}_{24}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| $\overline{\mathrm{OC}} \mathrm{Cl}_{2}$ | 23 | OC3 |
| $1 \overline{\mathrm{D}}{ }^{3}$ | 22 | 10 |
| 2 $\mathrm{D}^{4}$ | 21 | 20 |
| 3D ${ }^{\text {d }}$ | 20 | 30 |
| 4可 6 | 19 | 40 |
| 5D ${ }^{\text {D }}$ | 18 | 50 |
| 6 D | 17 | 60 |
| 7或 ${ }^{\text {cos }}$ | 16 | 70 |
| 8 － 10 | 15 | 80 |
| CLR［11 | 14 | PRE |
| GND 12 | 13 | C |

SN54ALS846，SN54AS846 ．．．FK PACKAGE SN74ALS846，SN74AS846 ．．．FN PACKAGE
（TOP VIEW）


|  |  |  |
| :---: | :---: | :---: |
| $2 \bar{D}$ | 75 |  |
| $3 \bar{D}$ | 76 |  |
| 4D | 7 |  |
| NC | $7^{8}$ |  |
| $5 \overline{\mathrm{D}}$ | $\square^{9}$ |  |
| 6 D̈ | 10 |  |
| 7D | $\mathrm{j}^{11}$ |  |
|  |  |  |
|  |  |  |

NC－No internal connection

The -1 versions of the SN74ALS845 and SN74ALS846 parts are identical to the standard versions except that the recommended maximum IOL is increased to 48 milliamperes. There are no -1 versions of the SN54ALS845 and SN54ALS846.

The SN54ALS845, SN54AS845, SN54ALS846, and SN54AS846 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS845, SN74AS845, SN74ALS846, and SN74AS846 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

FUNCTION TABLES
'ALS845, 'AS845

| INPUTS |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { PRE }}$ | $\overline{\text { CLR }}$ | $\overline{\text { OC1 }}$ | $\overline{\text { OC2 }}$ | $\overline{\text { OC3 }}$ | C | D | OUTPUT |
| L | H | L | L | L | X | X | H |
| H | L | L | L | L | X | X | L |
| L | L | L | L | L | X | X | H |
| H | H | L | L | L | H | L | L |
| H | H | L | L | L | H | H | H |
| H | H | L | L | L | L | X | $Q_{O}$ |
| X | X | X | X | H | X | X | Z |
| X | X | X | H | X | X | X | Z |
| X | X | H | X | X | X | X | Z |

'ALS846, 'AS846

| INPUTS |  |  |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { PRE }}$ | $\overline{\text { CLR }}$ | $\overline{\text { OC1 }}$ | $\overline{\text { OC2 }}$ | $\overline{\text { OC3 }}$ | C | $\overline{\mathrm{D}}$ | Q |
| L | H | L | L | L | X | X | H |
| H | L | L | L | L | X | X | L |
| L | L | L | L | L | X | X | H |
| H | H | L | L | L | H | L | H |
| H | H | L | L | L | H | H | L |
| H | H | L | L | L | L | X | Q O |
| X | X | X | X | H | X | X | Z |
| X | X | X | H | X | X | X | Z |
| X | X | H | X | X | X | X | Z |

$\Gamma_{\mathcal{O}}$ logic symbols ${ }^{\dagger}$
'ALS845, 'AS845

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
logic diagrams (positive logic)
'ALS845, 'AS845

'ALS846, 'AS846


Pin numbers shown are for DW, JT, and NT packages.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC ..... 7 V
Input voltage ..... 7 V
Voltage applied to a disabled 3 -state output ..... 5.5 V
Operating free-air temperature range:
SN54ALS845, SN54AS845, SN54ALS846, SN54AS846 $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS845, SN74AS845, SN74ALS846, SN74AS846 ..... $-0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## SN54ALS845, SN74ALS845

8-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS
recommended operating conditions

${ }^{\dagger}$ The extended limit applies only if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V . The 48 mA limit applies for SN74ALS845-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

[^21]switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ \mathrm{R} 1=500 \Omega, \\ \mathrm{R} 2=500 \Omega, \\ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ \hline \text { ALS845 } \\ \hline \end{gathered}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | 0 |  | 7 | 11 | 2 | 15 | 2 | 13 | ns |
| tPHL |  |  |  | 11 | 15 | 4 | 20 | 4 | 18 |  |
| tPLH | C | 0 |  | 12 | 18 | 5 | 25 | 5 | 21 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 16 | 23 | 8 | 30 | 8 | 26 |  |
| tPLH | $\overline{\text { PRE }}$ | 0 |  | 13 | 19 | 5 | 25 | 6 | 22 | ns |
| tPHL |  |  |  | 19 | 26 | 4 | 35 | 6 | 30 | ns |
| tPLH | $\overline{C L R}$ | 0 |  | 19 | 26 | 4 | 35 | 6 | 30 | ns |
| tPHL |  |  |  | 16 | 22 | 6 | 28 | 6 | 24 | ns |
| tPZH | $\overline{\mathrm{OC}}$ | 0 |  | 9 | 14 | 2 | 18 | 3 | 16 | ns |
| tpZL |  |  |  | 12 | 17 | 4. | 20 | 5 | 18 |  |
| tPHZ | $\overline{\mathrm{OC}}$ | Q |  | 4 | 9 | 1 | 12 | 1 | 11 | ns |
| tplz |  |  |  | 6 | 11 | 2 | 14 | 2 | 12 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
recommended operating conditions

|  |  |  |  | 54ALS |  |  | 74ALS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| $\underline{\mathrm{OH}}$ | High-level output current |  |  |  | -1 |  |  | -2.6 | mA |
| ${ }^{\text {l OL }}$ | Low-level output current |  |  |  | 12 |  |  | 24 | mA |
|  |  |  |  |  |  |  |  | $48^{\dagger}$ |  |
|  | Pulse duration | $\overline{\mathrm{CLR}}$ or PRE low |  |  |  |  |  |  | ns |
| tw | Pulse duration | C high |  |  |  |  |  |  |  |
| $\mathrm{t}_{\text {su }}$ | Setup time, data before enable C $\downarrow$ |  |  |  |  |  |  |  | ns |
| th | Hold time, data after enable Cl |  |  |  |  |  |  |  | ns |
| TA | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The extended limit applies only if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V . The 48 mA limit applies for SN74ALS846-1 only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54ALS846 |  |  | SN74ALS846 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\mathrm{iK}}$ | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ | -1.2 |  |  |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}{ }^{-2}$ |  |  | $\mathrm{v}_{\mathrm{CC}}{ }^{-2}$ |  |  | V |
|  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$. | $1 \mathrm{OH}=-1 \mathrm{~mA}$ | 2.43 .3 |  |  |  |  |  |  |
|  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OH}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3,2 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{IOL}^{\text {a }}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  |  |  | V |
|  | $\begin{aligned} & V_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA} \text { for }-1 \text { versions) } \end{aligned}$ |  |  |  |  | 0.35 |  | 0.5 |  |
| IOZH | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 | $V_{C C}=5.5 \mathrm{~V}$, | $V_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IL | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{5}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  |  | -30 |  | -112 | mA |
| I'c | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  |  |  |  |  |  | mA |
|  |  | Outputs low |  |  |  |  |  |  |  |
|  |  | Outputs disabled |  |  |  |  |  |  |  |

${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\S$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
Additional information on these products can be obtained from the factory as it becomes available.

## switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS846} \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=\mathrm{MIN} \text { to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | 0 |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  |  |
| tPLH | C | 0 |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  |  |
| tPLH | $\overline{\text { PRE }}$ | Q |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  | ns |
| tPLH | $\overline{\mathrm{CLR}}$ | 0 |  |  |  |  |  |  |  | ns |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  |  |  |  |  | ns |
| tPZH | $\overline{\mathrm{OC}}$ | 0 |  |  |  |  |  |  |  | ns |
| tPZL |  |  |  |  |  |  |  |  |  |  |
| tpHz | $\overline{O C}$ | 0 |  |  |  |  |  |  |  | ns |
| tplZ |  |  |  |  |  |  |  |  |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
Additional information on these products can be obtained from the factory as it becomes available.

## SN54AS845, SN54AS846 <br> SN74AS845, SN74AS846 <br> 8-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

## recommended operating conditions


electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS845 <br> SN54AS846 |  |  | SN74AS845 <br> SN74AS846 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | Min | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}$ |  |  | $\mathrm{V}_{\mathrm{CC}}$ |  |  |  |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-15 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.4 | 3.2 |  | $\checkmark$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-24 \mathrm{~mA}$ | 2 |  |  | 2 |  |  |  |
| V |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OL}=32 \mathrm{~mA}$ |  | 0.25 | 0.5 |  |  |  | $\checkmark$ |
| OL |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| ${ }^{1} \mathrm{OZH}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  | 50 |  |  | 50 | $\mu \mathrm{A}$ |
| ${ }^{\text {I OZL }}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -50 |  |  | -50 | $\mu \mathrm{A}$ |
| I |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| I/L |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.5 |  |  | -0.5 | mA |
| $10^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| Icc | 'AS845 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  | 35 | 58 |  | 35 | 58 | mA |
|  |  |  | Outputs low |  | 52 | 85 |  | 52 | 85 |  |
|  |  |  | Outputs disabled |  | 52 | 85 |  | 52 | 85 |  |
|  | 'AS846 |  | Outputs high |  | 36 | 59 |  | 36 | 59 |  |
|  |  |  | Outputs low |  | 53 | 87 |  | 53 | 87 |  |
|  |  |  | Outputs disabled |  | 53 | 87 |  | 53 | 87 |  |

[^22]
## SN54AS845, SN54AS846 <br> SN74AS845, SN74AS846 8-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

'AS845 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R} 1=500 \Omega \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS845 |  | SN74AS845 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | Q | 1 | 8.5 | 1 | 6.5 | ns |
| ${ }^{\text {t PHL }}$ |  |  | 1 | 10 | 1 | 9 |  |
| ${ }^{\text {P PLH }}$ | C | Q | 2 | 13 | 2 | 12 | ns |
| ${ }^{\text {tPHL}}$ |  |  | 2 | 13 | 2 | 12 |  |
| ${ }^{\text {tPLH }}$ | $\overline{\text { PRE }}$ | Q | 2 | 12 | 2 | 10 | ns |
| ${ }^{\text {tPHL}}$ | $\overline{\mathrm{CLR}}$ | Q | 2 | 14 | 2 | 13 | ns |
| ${ }^{\text {tPHL }}$ | $\overline{O C}$ | 0 | 2 | 13.5 | 2 | 10.5 | ns |
| tPZL |  |  | 2 | 15 | 2 | 13.5 |  |
| tPHZ | $\overline{O C}$ | Q | 1 | 10 | 1 | 8 | ns |
| tPLZ |  |  | 1 | 10 | 1 | 8 |  |

'AS846 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS846 |  | SN74AS846 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | 0 | 1 | 11 | 1 | 8.5 | ns |
| ${ }^{\text {t PHL }}$ |  |  | 1 | 11 | 1 | 10 |  |
| tPLH | C | 0 | 2 | 14 | 2 | 12.5 | ns |
| tPHL |  |  | 2 | 14 | 2 | 13 |  |
| tpLH | $\overline{\text { PRE }}$ | 0 | 2 | 12 | 2 | 10 | ns |
| tphL | $\overline{\text { CLR }}$ | 0 | 2 | 14.5 | 2 | 13.5 | ns |
| tPHL | $\overline{\mathrm{OC}}$ | 0 | 2 | 14.5 | 2 | 12 | ns |
| tPZL |  |  | 2 | 15 | 2 | 13.5 |  |
| tphz | $\overline{\mathrm{OC}}$ | 0 | 1 | 10 | 1 | 8 | ns |
| ${ }^{\text {t PLZ }}$ |  |  | 1 | 10 | 1 | 8 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54ALS845, SN54AS845, SN54ALS846, SN54AS846 SN74ALS845, SN74AS845, SN74ALS846, SN74AS846 8-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

## D latch signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type latch and to draw its logic symbol based on the assumption of true data (D) inputs. Then outputs that produce data in phase with the data inputs are called Q and those producing complementary data are called $\overline{\mathrm{Q}}$. An input that causes a Q output to go high or a $\overline{\mathrm{Q}}$ output to go low is called Preset; and input that causes a $\overline{\mathrm{Q}}$ output to go high or a Q output to go low is called Clear. Bars are used over these pin names ( $\overline{\operatorname{PRE}}$ and $\overline{C L R}$ ) if they are active low. The devices on this data sheet are second-source designs and the pin-name conventions used by the original manufacturer have been retained. That makes it necessary to designate the data inputs and outputs of the inverting circuit $\overline{\mathrm{D}}$ and Q .
In some applications it may be advantageous to redesignate the inputs and outputs $\overline{\mathrm{D}}$ and $\overline{\mathrm{Q}}$ for the noninverting circuits or $\bar{D}$ and $\overline{\mathrm{Q}}$ for the inverting circuits. In that case signal names should change as shown below. Also shown are corresponding changes in the logic symbols.
Notice that Q becoming $\overline{\mathrm{Q}}$ causes $\overline{\mathrm{PRE}}$ and $\overline{\mathrm{CLR}}$ to exchange their names and their S and R function labels. The presence or absence of polarity indicators ( $\Delta$ ) changes at the data inputs and outputs, but not at $\overline{\mathrm{CLR}} / \overline{\mathrm{PRE}}, \overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ since these inputs are still active-low.
'ALS845, 'AS845

'ALS846, 'AS846

'ALSB46, AS846


- 4-Line to 1-Line Data Selectors/Multiplexers

That Can Select 1 of 16 Data Inputs.
Typical Applications:
Boolean Function Generators
Parallel-to-Serial Converters
Data Source Selectors

- Cascadable to $n$-Bits
- 3-State Bus Driver Outputs
- 'AS850 Offers Clocked Selects; 'AS851 Offers Enable-Controlled Selects
- Has a Master Output Control ( $\overline{\mathbf{G}})$ for Cascading and Individual Output Controls ( $\overline{G Y}, \mathrm{GW}$ ) for Each Output
- Package Options Include both Plastic and
- Ceramic Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These four-line to one-line data selectors/multiplexers provide full binary decoding to select one-of-sixteen data sources with complementary $Y$ and $W$ outputs. The 'AS850 has a clock-controlled select register allowing for a symmetrical presentation of the select inputs to the decoder while the 'AS851 has an enable-controlled select register allowing the user to select and hold one particular data line.
A buffered group of output controls ( $\overline{\mathrm{G}}, \overline{\mathrm{GY}}, \mathrm{GW}$ ) can be used to place the two-outputs in either a normal logic (high or low logic level) or a highimpedance state. In the high-impedance state the outputs neither load nor drive the bus lines significantly. The high-impedance third state and increased drive provide the capability to drive the bus lines in a bus-organized system without the need for interface or pull-up components.
The output controls do not affect the internal operations of the data selector/multiplexer. New data can be setup while the outputs are in the high-impedance state.

The SN74AS850 and SN74AS851 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## SN74AS850, SN74AS851

## 1 OF 16 DATA SELECTORS/MULTIPLEXERS <br> WITH 3.STATE OUTPUTS

| INPUT SELECTION TABLE |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SELECT |  |  | INPUTS | 'AS850 | 'AS851 | INPUT |
| S3 | S2 | S1 | S0 | CLK | SC | SELECTED |
| L | L | L | L | $\uparrow$ | L | D0 |
| L | L | L | H | $\uparrow$ | L | D1 |
| L | L | H | L | $\uparrow$ | L | D2 |
| L | L | H | H | $\uparrow$ | L | D3 |
| L | H | L | L | $\uparrow$ | L | D4 |
| L | H | L | H | $\uparrow$ | L | D5 |
| L | H | H | L | $\uparrow$ | L | D6 |
| L | H | H | H | $\uparrow$ | L | D7 |
| H | L | L | L | $\uparrow$ | L | D8 |
| H | L | L | H | $\uparrow$ | L | D9 |
| H | L | H | L | $\uparrow$ | L | D10 |
| H | L | H | H | $\uparrow$ | L | D11 |
| H | H | L | L | $\uparrow$ | L | D12 |
| H | H | L | H | $\uparrow$ | L | D13 |
| H | H | H | L | $\uparrow$ | L | D14 |
| H | H | H | H | $\uparrow$ | L | D15 |
| X | X | X | X | H or L | H | Dn |

Dn = the input selected before the most-recent low-to-high transition of CLK or $\overline{\mathrm{SC}}$.

## logic symbols ${ }^{\dagger}$



OUTPUT FUNCTION TABLE

| $\overline{\mathbf{G}}$ | $\overline{\mathbf{G Y}}$ | GW | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathbf{W}$ |  |
| H | X | X | Z | Z |
| L | H | L | Z | Z |
| L | L | L | D | Z |
| L | H | H | Z | $\bar{D}$ |
| L | L | H | D | $\bar{D}$ |

$D=$ level of selected input DO-D15

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## 'AS850 logic diagrams (positive logic) (see inset for 'AS851)



## SN74AS850, SN74AS851 1 OF 16 DATA SELECTORS/MULTIPLEXERS WITH 3-STATE OUTPUTS

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)



## SN74AS850 recommended operating conditions



SN74AS850 electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYp ${ }^{\text { }}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IK }}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| VOH |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , $\quad \mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{IOH}=-15 \mathrm{~mA}$ |  | 2 | 3.3 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$. | $\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  | 0.35 | - 0.5 | V |
| IOZH |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 50 | $\mu \mathrm{A}$ |
| lozl |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 | mA |
| IIH |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{A}$ |
| IIL | D, $\overline{\mathrm{G}}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -1 | mA |
|  | All others |  |  |  |  | -0.5 |  |
| $10^{ \pm}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs active |  | 50 | 81 | mA |
|  |  | Outputs disabled |  | 52 | 85 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit current, IOS.

SN74AS850 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 60 |  | MHz |
| tPLH | Any D | Y | 3 | 10.5 | ns |
| tPHL |  |  | 3 | 11 |  |
| tPLH | Any D | W | 3 | 8 | ns |
| tPHL |  |  | 1 | 6 |  |
| ${ }^{\text {tPLH }}$ | CLK | Y | 3 | 14.5 | ns |
| tPHL |  |  | 3 | 17.5 |  |
| tPLH | CLK | W | 3 | 15 | ns |
| tPHL |  |  | 3.5 | 13 |  |
| tPZH | $\overline{\mathrm{G}}$ | Y | 2 | 8 | ns |
| tPZL |  |  | 3 | 11 |  |
| tPHZ | $\overline{\mathrm{G}}$ | Y | 1 | 6 | ns |
| tPLZ |  |  | 2 | 8 |  |
| tPZH | $\overline{\mathrm{G}}$ | W | 2 | 8 | ns |
| tPZL |  |  | 3 | 21 |  |
| tPHZ | $\overline{\mathrm{G}}$ | W | 1 | 6 | ns |
| tplz |  |  | 2 | 8 |  |
| tPZH | $\overline{\mathrm{GY}}$ | Y | 2 | 8 | ns |
| tPZL |  |  | 3 | 11 |  |
| tpHz | $\overline{\mathrm{GY}}$ | Y | 1 | 6 | ns |
| tplz |  |  | 2 | 8 |  |
| tPZH | GW | W | 2 | 10 | ns |
| tPZL |  |  | 3 | 25 |  |
| tphz | GW | W | 1 | 6 | ns |
| tPLZ |  |  | 2 | 11 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN74AS851

## 1 OF 16 DATA SELECTORS/MULTIPLEXERS <br> WITH 3-STATE OUTPUTS

## SN74AS851 recommended operating conditions

|  | MIN | NOM | MAX |
| :--- | ---: | ---: | :---: |
| $V_{\text {CC }}$ | Supply voltage | 4.5 | 5 |
| $\mathrm{~V}_{\text {IH }}$ | High-level input voltage | 5.5 | V |
| $\mathrm{~V}_{\mathrm{IL}}$ | Low-level input voltage | 2 |  |
| $\mathrm{IOH}_{\mathrm{OH}}$ | High-level output current |  | V |
| $\mathrm{I}_{\mathrm{OL}}$ | Low-level output current |  | 0.8 |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, $\overline{\mathrm{SC}}$ low | V |  |
| $\mathrm{t}_{\mathrm{su}}$ | Setup time, select inputs before $\overline{\mathrm{SC} ~} \uparrow$ | 15 | mA |
| $\mathrm{t}_{\mathrm{h}}$ | Hold time, select inputs after $\overline{\mathrm{SC}} \uparrow$ | 10 | 48 |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating free-air temperature | 4.5 | mA |

SN74AS851 electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYP ${ }^{\text {t }}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IK }}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1=-18 \mathrm{~mA}$ |  |  | -1.2 | C |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \quad \mathrm{IOH}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OH}}=-15 \mathrm{~mA}$ |  | 2 | 3.3 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=48 \mathrm{~mA}$ |  | 0.35 | 0.5 | V |
| Iozi |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  | 50 | $\mu \mathrm{A}$ |
| IozL |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=0.4 \mathrm{~V}$ |  |  | -50 | $\mu \mathrm{A}$ |
| 1 |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 | mA |
| $\mathrm{IIH}^{\prime}$ |  | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ | 20 |  |  | $\mu \mathrm{A}$ |
| IIL | D, $\overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ | -0.5 |  |  | mA |
|  | All others |  |  |  |  |  |  |
| $10^{\ddagger}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs active |  | 50 | 81 | mA |
|  |  | Outputs disabled |  | 52 | 85 |  |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit current, IOS.

SN74AS851 switching characteristics (see Note 1)

| . PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN MAX |  |
| ${ }^{\text {tPLH }}$ | Any D | Y | 3 10.5 | ns |
| ${ }_{\text {t }}$ PHL |  |  | $3 \quad 11$ |  |
| tPLH | Any D | W | 3 - 8 | ns |
| ${ }_{\text {t PHL }}$ |  |  | 1 - 6 |  |
| tpLH | S0, S1, S2, S3 | Y | $3 \quad 18$ | ns |
| tpHL |  |  | 3 19 |  |
| ${ }^{\text {P PLH }}$ | S0, S1, S2, S3 | W | 3 16 | ns |
| ${ }^{\text {t PHL }}$ |  |  | $3 \quad 15$ |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{SC}}$ | Y | $3 \quad 18$ | ns |
| ${ }^{\text {tPHL }}$ |  |  | 3 20 |  |
| tPLH | $\overline{\mathrm{SC}}$ | W | 3 16 | ns |
| ${ }^{\text {P PHL }}$ |  |  | 3 15 |  |
| ${ }^{\text {tPZH }}$ | $\overline{\mathrm{G}}$ | Y | 28 | ns |
| ${ }^{\text {t PR2L }}$ |  |  | $3 \quad 11$ |  |
| tPHZ | $\overline{\mathrm{G}}$ | Y | 16 | ns |
| ${ }^{\text {t PLZ }}$ |  |  | 2 |  |
| tPZH | $\overline{\mathrm{G}}$ | W | 2 | ns |
| tPZL |  |  | $3 \quad 21$ |  |
| tPHZ | $\overline{\mathrm{G}}$ | W | 1 - 6 | ns |
| tplz |  |  | 28 |  |
| tPZH | $\overline{\mathrm{GY}}$ | Y | 28 | ns |
| tPZL |  |  | $3 \sim 11$ |  |
| tPHZ | $\overline{\mathrm{GY}}$ | Y | 1 6 | ns |
| ${ }_{\text {t PLL }}$ |  |  | 2 - 8 |  |
| tPZH | GW | W | 2 10 | ns |
| tPZL |  |  | $3 \quad 25$ |  |
| ${ }^{\text {t P H }}$ | GW | W | 1 6 | ns |
| tplZ |  |  | 211 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## TYPICAL APPLICATION DATA

The 'AS850 or 'AS851 can be used as a 1 -of-16 Boolean function generator. Figure 1 shows the 'AS850 in one example.


FIGURE 1. 1-of-16 BOOLEAN FUNCTION GENERATOR

TYPICAL APPLICATION DATA


FIGURE 2. 1-of-32 DATA SELECTOR/MULTIPLEXER

## 1 OF 16 DATA SELECTORS/MULTIPLEXERS <br> WITH 3.STATE OUTPUTS

TYPICAL APPLICATION DATA


FIGURE 3. 1-of-64 DATA SELECTOR/MULTIPLEXER

- Included among the Package Options are Compact, 24-Pin, 300-mil-Wide DIPs and Both 28-Pin Plastic and Ceramic Chip Carriers
- Buffered 3-State Outputs Drive Bus Lines Directly
- Cascadable to n-Bits
- Eight Selectable Transceiver/Port Functions:

A to $B$ or $B$ to $A$
Register to $A$ or $B$
Shifted to A from B or Shifted to B from A
Off-Line Shifts (A and B Ports Transceiving or in High-Impedance State)
Register Clear

- Particularly Suitable for Use in Diagnostics Circuitry
- Serial Register Provides:
- Parallel Storage of Either A or B Input Data
- Serial Transmission of Data from Either A or B Port
- Dependable Texas Instruments Quality and Reliability


## description

The 'AS852 features two 8-bit l/O ports (A1-A8 and $\mathrm{B} 1-\mathrm{B} 8$ ), and 8 -bit parallel-load, serial-in, parallel-out shift register, and control logic. With these features, this device is capable of performing eight selectable transceiver or port functions, depending on the state of the three select lines S0, S1, and S2. These functions include: transferring data from port $A$ to port $B$ or vice versa (i.e., the transceiver function), transferring data from the register to either port, serial shifting data to either port from the opposite port, performing off-line shifts (with $A$ and $B$ ports in high-impedance state), and clearing the register. The 'AS852 can simultaneously transfer data from $A$ to $B$ or $B$ to $A$ and perform an off-line serial shift of data in the register. Synchronous parallel loading of the internal register can be accomplished from either port on the positive transition of the clock while serially shifting data in via the SERIN input. The 'AS852 is ideally suited for applications implementing diagnostic circuitry to enhance system verification and/or fault analysis. All serial data is shifted right. All outputs are buffer-type outputs designed specifically to drive bus lines directly and all are 3 -state except for 08 , which is a totem-pole output.

The SN54AS852 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS852 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## logic diagram (positive logic)



FOUR IDENTICAL CHANNELS NOT SHOWN INPUTS/OUTPUTS NOT SHOWN:
(6) A3 (19) B3
(7) A4 (18) B4
(8) A5 (17) B5
(9) A6
(16) B6


Pin numbers shown are for DW, JT, and NT packages.

## FUNCTION TABLE

| $\begin{aligned} & \text { MODE } \\ & \text { S2 S1 So } \end{aligned}$ | CLOCK | SERIN | A1 01 B1 | A2 02 B2 | A3 $03 \mathrm{B3}$ | A4 04 B4 | A5 05 B5 | A6 06 B6 | A7 07 B7 | A8 08 B8 | PORT FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{array}{lll} \hline \mathrm{L} & \mathrm{~L} & \mathrm{~L} \\ \mathrm{~L} & \mathrm{~L} & \mathrm{~L} \end{array}$ | $\begin{gathered} \mathrm{H} \text { or } \mathrm{L} \\ \uparrow \end{gathered}$ | X $\times$ | $\begin{array}{ll} Z & Q_{n} A 1 \\ Z & A 1 \end{array}$ | $\begin{array}{lll} Z & O_{n} & A 2 \\ Z & A 2 & A 2 \end{array}$ | $\begin{array}{lll} \hline Z & Q_{n} & A 3 \\ A & A 3 & A 3 \end{array}$ | $\begin{array}{lll} Z & O_{n} A 4 \\ Z & A 4 & A 4 \end{array}$ | $\begin{aligned} & Z Q_{n} A 5 \\ & Z A 5 A 5 \end{aligned}$ | $\begin{array}{lll} \hline z & Q_{n} & A 6 \\ z & A 6 & A 6 \end{array}$ | $\begin{array}{lll} Z & O_{n} A 7 \\ Z & A 7 & A 7 \end{array}$ | $\begin{array}{lll} Z & Q_{n} A 8 \\ Z & A B & A 8 \end{array}$ | A TO B |
| $\begin{array}{lll} L & L & H \\ L & L & H \end{array}$ | $\mathrm{H} \text { or } \mathrm{L}$ | X $\times$ | $\begin{aligned} & \mathrm{B} 1 \mathrm{Q}_{\mathrm{n}} \mathrm{Z} \\ & \mathrm{~B} 1 \mathrm{~B} 1 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \text { B2 } \mathrm{O}_{\mathrm{n}} \mathrm{Z} \\ & \text { B2 } 22 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \text { B3 } Q_{n} z \\ & \text { B3 B3 } z \end{aligned}$ | $\begin{aligned} & \text { B4 } O_{n} Z \\ & \text { B4 B4 } Z \end{aligned}$ | $\begin{array}{lll} \text { B5 } a_{n} & Z \\ \text { B5 B5 } \end{array}$ | $\begin{array}{lll} B 6 & a_{n} & Z \\ B 6 & B 6 & Z \end{array}$ | $\begin{aligned} & B 7 Q_{n} Z \\ & B 7 B 7 Z \end{aligned}$ | $\begin{array}{lll} B 8 & a_{n} & Z \\ B 8 & \text { B8 } & Z \end{array}$ | B TO A |
| $\begin{array}{lll} L & H & L \\ L & H & L \end{array}$ |  | X <br>  | $\begin{array}{lll} X & O_{n} & Q 1 \\ Z & A 1 & A 1 \end{array}$ | $\begin{array}{lll} X & a_{n} & 02 \\ z & A 2 & A 2 \end{array}$ | $\begin{array}{lll} x & a_{n} & 03 \\ z & A 3 & A 3 \end{array}$ | $\begin{array}{lll} \mathrm{X} & \mathrm{O}_{n} \mathrm{Q4} \\ \mathrm{Z} & \mathrm{~A} 4 & \mathrm{~A} 4 \end{array}$ | $\begin{aligned} & x a_{n} Q 5 \\ & z ~ A 5 A 5 \end{aligned}$ | $\begin{array}{lll} x & a_{n} & 06 \\ z & A 6 & A 6 \end{array}$ | $\begin{array}{lll} X & Q_{n} & Q 7 \\ Z & A 7 & A 7 \end{array}$ | $\begin{array}{ll} X & \mathrm{Q}_{n} \mathrm{Q8} \\ \mathrm{Z} & \mathrm{AB} \end{array}$ | $\mathrm{O}_{\mathrm{N}} \mathrm{TO}^{\text {B }} \mathrm{N}$ |
| $\begin{array}{lll} \mathrm{L} & \mathrm{H} & \mathrm{H} \\ \mathrm{~L} & \mathrm{H} & \mathrm{H} \end{array}$ | $\begin{gathered} \mathrm{H} \text { or } \mathrm{L} \\ \uparrow \end{gathered}$ |  | $\begin{aligned} & \mathrm{O} 1 \mathrm{o}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{~B} 1 \mathrm{~B} 1 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \mathrm{O} 2 \mathrm{O}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{~B} 2 \mathrm{~B} 2 \mathrm{Z} \end{aligned}$ | $\begin{array}{lll} \text { O3 } Q_{n} & X \\ \text { B3 B3 } & z \end{array}$ | $\begin{aligned} & \mathrm{O} 4 \mathrm{O}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{~B} 4 \mathrm{~B} 4 \\ & \mathrm{Z} \end{aligned}$ | $\begin{aligned} & 05 Q_{n} X \\ & B 5 \mathrm{~B} \quad \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \mathrm{Q} 6 \mathrm{a}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{~B} 6 \mathrm{~B} 6 \end{aligned}$ | $\begin{aligned} & 07 a_{n} x \\ & B 7 B 7 \end{aligned}$ | $\begin{aligned} & 08 a_{n} x \\ & \text { B8 B8 } \quad Z \end{aligned}$ | $Q_{N}$ TO $A_{N}$ |
| $\begin{array}{lll} H & L & L \\ H & L & L \\ H & L & L \end{array}$ | $\begin{gathered} \text { H or L } \\ \uparrow \\ \uparrow \end{gathered}$ | $x$ | $\begin{array}{lll} Z & Q_{n} & A 1 \\ Z & H & A 1 \\ Z & L & A 1 \end{array}$ | $\begin{array}{lll} z & O_{n} & A 2 \\ z & Q_{1} & A 2 \\ z & Q_{1} & A 2 \end{array}$ | $\begin{array}{lll} \hline z & O_{n} & A 3 \\ z & O 2 & A 3 \\ z & 02 & A 3 \end{array}$ | $\begin{array}{lll} z & a_{n} & A 4 \\ z & \text { O3 } & A 4 \\ z & \text { Q3 } & A 4 \end{array}$ | $\begin{array}{lll} z & Q_{n} A 5 \\ z & Q 4 A 5 \\ z & Q_{4} A 5 \end{array}$ | $\begin{array}{lll} z & Q_{n} & A 6 \\ z & Q_{5} & A 6 \\ z & 05 & A 6 \end{array}$ | $\begin{array}{ll} z & Q_{n} A 7 \\ z & Q 6 A 7 \\ z & Q_{1} A 7 \end{array}$ | $\begin{array}{lll} z & Q_{n} & A 8 \\ z & 07 A 8 \\ z & 07 A 8 \end{array}$ | SHIFT <br> AND <br> A TO B |
| $\begin{array}{lll} H & L & H \\ H & L & H \\ H & L & H \end{array}$ | $\begin{gathered} \mathrm{H} \text { or } \mathrm{L} \\ \uparrow \\ \uparrow \\ \uparrow \end{gathered}$ | $x$ | $\begin{array}{ccc} B 1 & Q_{n} & Z \\ \text { B1 } & \text { H } & Z \\ \text { B1 } & \text { L } & Z \end{array}$ | $\begin{array}{lll} B 2 & Q_{n} & Z \\ \text { B2 Q1 } & z \\ \text { B2 Q1 } & z \end{array}$ |  | $\begin{array}{lll} \text { B4 } \mathrm{Q}_{n} & \mathrm{Z} \\ \text { B4 O3 } & \text { Z } \\ \text { B4 O3 } & \text { Z } \end{array}$ | $\begin{array}{\|lll} \text { B5 } \mathrm{Q}_{n} & Z \\ \text { B5 Q4 } & \text { Z } \\ \text { B5 Q4 } \end{array}$ | $\begin{array}{\|lll} B 6 & Q_{n} & Z \\ \text { B6 } 65 & Z \\ \text { B6 } 65 & Z \end{array}$ | $B 7 Q_{n} Z$ <br> B7 06 Z <br> B7 06 Z | $\begin{array}{lll} \text { B8 } a_{n} & Z \\ \text { B8 } & \text { Q7 } & Z \\ \text { B8 } & \text { a7 } & Z \end{array}$ | SHIFT <br> AND <br> B TO A |
| H H L <br> H H L <br> H H L | $\begin{gathered} \hline \text { H or } L \\ \uparrow \\ \uparrow \end{gathered}$ | X H L | $\begin{array}{lll} \hline Z & Q_{n} & Z \\ Z & H & Z \\ Z & L & Z \end{array}$ | $\begin{array}{lll} \hline z & a_{n} & z \\ z & a_{1} & z \\ z & a_{1} & z \end{array}$ | $\begin{array}{lll} \hline z & Q_{n} & Z \\ z & Q 2 & z \\ z & Q 2 & z \end{array}$ | $\begin{array}{lll} z & a_{n} & z \\ z & Q_{3} & z \\ z & \text { Q3 } & z \end{array}$ | $\begin{array}{lll} z & a_{n} & z \\ z & Q_{4} & z \\ z & Q_{4} & z \end{array}$ | $\begin{array}{lll} z & a_{n} & z \\ z & 05 & z \\ z & a_{5} & z \end{array}$ | $\begin{array}{lll} z & Q_{n} & z \\ z & Q_{6} & z \\ z & Q_{6} & z \end{array}$ | $\begin{array}{lll} z & a_{n} & z \\ z & \text { a7 } & z \\ z & 07 & z \end{array}$ | SHIFT |
| $\begin{array}{lll}\mathrm{H} & \mathrm{H} & \mathrm{H} \\ \mathrm{H} & \mathrm{H} & \mathrm{H}\end{array}$ | $\begin{gathered} \mathrm{H} \text { or } \mathrm{L} \\ \uparrow \end{gathered}$ | $x$ | $\begin{array}{ccc}z & a_{n} & z \\ z & L & z\end{array}$ | $\begin{array}{llll}z & Q_{n} & \\ z & L & z\end{array}$ | $\begin{array}{llll}z & Q_{n} & z \\ z & L & z & \\ \end{array}$ | $\begin{array}{cccc}z & a_{n} & z \\ z & L & z\end{array}$ | $\begin{array}{llll}z & a_{n} & z \\ z & L & z\end{array}$ | $\begin{array}{llll}z & Q_{n} & z \\ z & L & z\end{array}$ | $\begin{array}{llll}z & a_{n} & z \\ z & L & z\end{array}$ | $\begin{array}{llll}z & a_{n} & z \\ z & L & z\end{array}$ | CLEAR |

$n=$ level of $Q_{n}(n=1,2, \ldots 8)$ established on the most recent $\uparrow$ transition of CLK. Q1 through Q8 are the shift register outputs; only Q8 is available externally. The double inversions that take place as data travels from port to port are ignored in this table.
logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.

## absolute maximum ratings over free-air temperature range



## recommended operating conditions



## electrical characteristics over recommended operating free-air temperature range

 (unless otherwise noted)
${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the output currents $I_{O Z H}$ and $I^{\circ} \mathrm{OZL}^{\prime}$, respectively.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, 'OS.

## switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS852 |  | SN74AS852 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 45 |  | 50 |  | MHz |
| tPLH | Any A port | Any B port | 2 | 9 | 2 | 7.5 | ns |
| tPHL |  |  | 3 | 12.5 | 3 | 11 |  |
| ${ }^{\text {tPLH }}$ | Any B port | Any A port | 2 | 9 | 2 | 7.5 | ns |
| tPHL |  |  | 3 | 12.5 | 3 | 11 |  |
| tPLH | so, s1, s2 ${ }^{\text {¢ }}$ | Any A or B port | 3 | 11.5 | 3 | 10 | ns |
| tPHL |  |  | 3 | 12 | 3 | 10.5 |  |
| tPLH | CLK | Any A or B port | 2 | 11 | 2 | 9 | ns |
| tPHL |  |  | 3 | 14 | 3 | 12.5 |  |
| tPLH | CLK | Q8 | 2 | 10.5 | 2 | 8 | ns |
| tPHL |  |  | 3 | 11.5 | 3 | 10 |  |
| tPHZ | So, S1, S2 | Any A or B port | 2 | 9 | 2 | 7 | ns |
| tPLZ |  |  | 3 | 13 | 3 | 10.5 |  |
| tPZH |  |  | 2 | 9 | 2 | 7 | ns |
| tPZL |  |  | 3 | 13 | 3 | 10.5 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
§ The positive transition of S 1 control pin will cause low-level data on the A or B bus to be invalid for 17.5 ns .

## TYPICAL APPLICATION DATA



- Included Among the Package Options are Compact, 24-Pin, 300-mil-Wide DIPs and Both 28-Pin Plastic and Ceramic Chip Carriers
- Buffered 3-State Outputs Drive Bus Lines Directly
- Cascadable to $n$-Bits
- Eight Selectable Transceiver/Port Functions:
- B to A
- Register to A and/or B
- Off-Line Shifts (A and B Ports in HighImpedance State)
- Shifted to A and/or B
- Particularly Suitable for Use in Diagnostics Analysis Circuitry
- Serial Register Provides:
- Parallel Storage of Either A or B Input Data
- Serial Transmission of Data from Either A or B Port
- Readback Mode B to A
- Dependable Texas Instruments Quality and Reliability


SN54AS856 . . . FK PACKAGE
SN74AS856 . . . FN PACKAGE (TOP VIEW)


NC-No internal connection

## description

The 'AS856 features two 8-bit I/O ports (A1-A8 and B1-B8), an 8-bit parallel-load, serial-in, parallel-out shift register, and control logic. With these features, this device is capable of performing eight selectable transceiver or port functions, depending on the state of the three control lines $\overline{\mathrm{OEA}}, \overline{\mathrm{OEB}}$, and MODE. These functions include: transferring data from port $A$ to port $B$ or vice versa (i.e., the transceiver function), serial shifting data to either or both ports, and performing off-line shifts (with $A$ and $B$ ports active as transceivers in a high-impedance state). Synchronous parallel loading of the internal register can be accomplished from either port on the positive transition of the clock while serially shifting data in via the SERIN input. The 'AS856 is ideally suited for applications needing signature-analysis circuitry to enhance system verification and/or fault analysis. All serial data is shifted right. All outputs are buffer-type outputs designed specifically to drive bus lines directly and all are 3-state except for 08, which is a totem-pole output.

The SN54AS856 is characterized for operation over the full military temperaure range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS856 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## logic diagram (positive logic)



FUNCTION TABLE

| MODE | $\begin{aligned} & \overline{M O D E} \\ & \overline{O E A A} \end{aligned}$ | $\overline{O E B}$ | ClOCK | SERIN | A1 01 B1 | A2 $02 \mathrm{B2}$ | A3 $03 \mathrm{B3}$ | A4 04 B4 | A5 05 B5 | A6 26 B6 | A7 07 B7 | A8 08 B8 | FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| L | L | L | H or L | X | Q1 0101 | Q2 2202 | 030303 | 040404 | Q5 Q5 Q5 | 060606 | 070707 | 080808 |  |
| $L$ | L | L | $\uparrow$ | X | Q1 01 Q1 | Q2 0202 | 030303 | O4 04 04 | 050505 | 060606 | 070707 | 080808 | FEEDBACK |
| $L$ | L | H | H or L | X | B1 Q1 Z | B2 Q2 Z | B3 03 Z | B4 O4 Z | B5 O5 Z | B6 O6 2 | B7 072 | B8 082 | $B$ to $A$ |
| $L$ | L | H | $\dagger$ | X | B1 B1 Z | B2 B2 Z | B3 B3 Z | B4 B4 Z | B5 B5 2 | B6 B6 $Z$ | B7 B7 Z | B8 B8 2 | $A$ to Q |
| L | H | L | H or L | X | Z Q1 Q1 | 2 O 2 Q 2 | Z Q3 Q3 | Z 0404 | 20505 | Z 0606 | 20707 | Z 0808 | $A$ to Q |
| L | H | L | $\uparrow$ | X | Z A1 A1 | $Z \mathrm{~A} 2 \mathrm{~A} 2$ | Z A3 A3 | Z A4 A4 | Z A5 A5 | Z A6 A6 | 2 A 7 A 7 | $Z$ A8 A8 | Q to B |
| L | H | H | H or L | X | Z Q1 Z | Z 02 Z | Z 03 Z | Z O4 Z | Z 05 Z | z 06 z | 2 Q7 $Z$ | Z 08 Z |  |
| L | H | H | $\uparrow$ | x | Z A1 z | Z A2 Z | Z A3 Z | Z A4 Z | Z A5 Z | Z A6 Z | Z A7 2 | Z A8 $Z$ |  |
| H | 1 | L | H or L | X | Q1 $\mathrm{O}_{\mathrm{n}} \mathrm{Q} 1$ | $\mathrm{O}^{\text {a }} \mathrm{n}_{\mathrm{n}} \mathrm{O} 2$ | $03 \mathrm{O}_{\mathrm{n}} 03$ | Q4 $\mathrm{O}_{\mathrm{n}}$ Q4 | $05 \mathrm{O}_{\mathrm{n}} 05$ | $06 \mathrm{a}_{\mathrm{n}} 06$ | $07 \mathrm{a}_{\mathrm{n}}$ Q7 | Q8 $\mathrm{Q}_{\mathrm{n}}$ Q8 | SHIFT |
| H | L | L | $\uparrow$ | H | H H H | Q1 Q 1 Q 1 | Q2 0202 | Q3 0303 | O4 O4 04 | Q5 0505 | 06 0606 | 070707 | TO |
| H | L | L | $\uparrow$ | L | L L L | Q101 Q1 | 020202 | 030303 | O4 Q4 04 | 05 Q5 05 | 060606 | 070707 | A and B |
| H | L | H | H or L | X | Q1 $\mathrm{O}_{\mathrm{n}} \mathrm{Z}$ | $02 \mathrm{a}_{\mathrm{n}} \mathrm{z}$ | Q3 $\mathrm{O}_{\mathrm{n}} \mathrm{z}$ | Q4 $\mathrm{a}_{\mathrm{n}} \mathrm{z}$ | $05 \mathrm{a}_{\mathrm{n}} \mathrm{z}$ | $06 \mathrm{O}_{\mathrm{n}} \mathrm{z}$ | $07 a_{n} z$ | $08 \mathrm{a}_{\mathrm{n}} \mathrm{z}$ | SHIFT |
| H | L | H | $\dagger$ | H | H H Z | 01012 | Q2 02 z | 03 03 z | 0404 Z | 0505 z | 0606 z | 0707 z | то |
| H | L | H | $\uparrow$ | L | L L Z | Q101 z | 0202 2 | 0303 Z | 0404 Z | 0505 z | 06 06 z | 0707 Z | A |
| H | H | L | H or L | X | $z \mathrm{O}_{\mathrm{n}} \mathrm{Ql}_{1}$ | $z \mathrm{Q}_{\mathrm{n}} \mathrm{Q} 2$ | $z \mathrm{Q}_{\mathrm{n}} \mathrm{Q} 3$ | $z \mathrm{O}_{\mathrm{n}}$ Q4 | $z \mathrm{a}_{\mathrm{n}}$ Q5 | $z \mathrm{a}_{\mathrm{n}} \mathrm{Q} 6$ | $z \mathrm{O}_{\mathrm{n}} 07$ | $z \mathrm{a}_{\mathrm{n}} \mathrm{Q} 8$ | SHIFT |
| H | H | L | $\uparrow$ | H | Z H H | z Q1 01 | $z{ }^{2} 020$ | $z{ }^{2} 0303$ | z 04 Q4 | z 0505 | 20606 | $z \quad 0707$ | то |
| H | H | L. | $\uparrow$ | L | Z L L | Z Q1 Q1 | z Q2 02 | z 03 03 | Z Q4 04 | z 0505 | z 0606 | z 0707 | 8 |
| H | H | H | H or L | X | $z a_{n} z$ | $z \mathrm{O}_{\mathrm{n}} \mathrm{z}^{\prime}$ | $z a_{n} z$ | $z a_{n} z$ | $z Q_{n} z$ | $z a_{n} z$ | $z a_{n} z$ | $z a_{n} z$ | SHIFT |
| H | H | H | $\uparrow$ | H | Z H Z | z 012 | z 02 z | z 03 z | Z Q4 Z | z 05 z | z Q6 z | $z 07 \mathrm{z}$ | SHIFT |
| H | H | H | $\uparrow$ | L | Z L H | z 012 | z 02 z | z 03 z | Z Q4 Z | Z 05 z | z 06 z | z 07 z |  |

$\mathrm{n}=$ level of $\mathrm{Q}_{\mathrm{n}}(\mathrm{n}=1,2 \ldots 8)$ established on most recent $\uparrow$ transition of CLK. Q 1 through Q 8 are the shift register outputs; only Q 8 is available externally. The double inversions that take place as data travels from port to port are ignored in this table.

## logic symbol ${ }^{\dagger}$



Pin numbers shown are for DW, JT, and NT packages.
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## absolute maximum ratings over free-air temperature range

$$
\text { Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 7 \text { V }
$$

Input voltage: All inputs ..... 7 V
I/O ports ..... 5.5 V
Voltage applied to a disabled 3 -state output ..... 5.5 V
Operating free-air temperature range: SN54AS856 $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74AS856 ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions


SN54AS856, SN74AS856 8-BIT UNIVERSAL TRANSCEIVER PORT CONTROLLERS
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For I/O ports, the parameters $I_{I H}$ and $I_{I L}$ include the output currents $I_{O Z H}$ and $I_{O Z L}$, respectively.
${ }^{5}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, iOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS856 |  | SN74AS856 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 45 |  | 50 |  | MHz |
| tPLH | Any B port | Any A port | 2 | 8 | 2 | 7 | s |
| tpHL |  |  | 2 | 10.5 | 2 | 9.5 | ns |
| tPLH | ¢MODE $¢$ | Any A or B port | 2 | 8.5 | 2 | 7.5 | ns |
| tPHL |  |  | 5 | 20 | 5 | 19 |  |
| tPLH | $\downarrow$ MODE | Any A or B port | 2 | 8.5 | 2 | 7.5 | ns |
| tPHL |  |  | 2 | 9.5 | 2 | 8 | ns |
| ${ }_{\text {tPLH }}$ | CLK | Any A or B port | 3 | 12 | 3 | 9 | ns |
| tPHL |  |  | 3 | 12 | 3 | 11 | ns |
| ${ }_{\text {tPLH }}$ | CLK | Q8 | 2 | 9 | 2 | 7.5 | ns |
| tPHL |  |  | 2 | 10 | 2 | 9 |  |
| tpHz | $\overline{O E A}$ or $\overline{O E B}$ | Any A or B port | 2 | 9 | 2 | 7 | ns |
| ${ }^{\text {t PLZ }}$ |  |  | 2 | 12 | 2 | 9.5 |  |
| tPZH |  |  | 2 | 8 | 2 | 7 | ns |
| tPZL |  |  | 2 | 11 | 2 | 10 |  |

[^23]səo!nəa IS7

- Included among the Package Options are Compact, 24-Pin, 300-mil-Wide DIPs and 28-Pin Ceramic Chip Carriers
- Fully Programmable with Synchronous Counting and Loading
- 'AS867 Has Asynchronous Clear, 'AS869 Has Synchronous Clear
- Fully Independent Clock Circuit Simplifies Use
- Ripple Carry Output for n-Bit Cascading
- Improved Performance Compared to Schottky TTL:
- Typical Power Reduced by 38\%
- Maximum Count Frequency is $25 \%$ Higher
- Dependable Texas Instruments Quality and Reliability


## description



SN54AS867, SN54AS869 . . . . FK PACKAGE
(TOP VIEW)


NC - No internal connection

These synchronous presettable counters feature an internal carry look-ahead for cascading in high-speed counting applications. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincident with each other when so instructed by the count-enable inputs and internal gating. This mode of operation helps eliminate the output counting spikes that are normally associated with asynchronous (ripple-clock) counters. A buffered clock input triggers the eight flip-flops on the rising (positive-going) edge of the clock waveform.
These counters are fully programmable; that is, the outputs may each be preset to either level. The load mode circuitry allows parallel loading of the cascaded counters. As loading is synchronous, selecting the load mode disables the counter and causes the outputs to agree with the data inputs after the next clock pulse.

The carry look-ahead circuitry provides for cascading counters for $n$-bit synchronous applications without additional gating. Instrumental in accomplishing this function are two count-enable inputs and a carry output. Both count enable inputs ( $\overline{\mathrm{ENP}}$ and $\overline{\mathrm{ENT}}$ ) must be low to count. The direction of the count is determined by the levels of the select inputs (see Function Table). Input $\overline{\text { ENT }}$ is fed forward to enable the carry output. The ripple carry output thus enabled will produce a low-level pulse while the count is zero (all outputs low) counting down or 255 counting up (all outputs high). This low-level overflow carry pulse can be used to enable successive cascaded stages. Transitions at the enable $\overline{\mathrm{ENP}}$ and $\overline{\mathrm{ENT}}$ inputs are allowed regardless of the level of the clock input. All inputs are diode-clamped to minimize transmission-line effects, thereby simplifying system design.

## SN54AS867, SN54AS869, SN74AS867, SN74AS869 SYNCHRONOUS 8-BIT UP/DOWN COUNTERS

These counters feature a fully independent clock circuit. With the exception of the asynchronous clear on the 'AS867, changes at control inputs (S0, S1) that will modify the operating mode have no effect on the $Q$ outputs until clocking occurs. Anytime the $\overline{\mathrm{ENP}}$ and/or $\overline{\mathrm{ENT}}$ is taken high, $\overline{\mathrm{RCO}}$ will either go or remain high. The function of the counter (whether enabled, disabled, loading, or counting) will be dictated solely by the conditions meeting the stable setup and hold times.

The SN54AS867 and SN54AS869 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS867 and SN74AS869 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## logic symbols ${ }^{\dagger}$


${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.

FUNCTION TABLE

| S1 | S0 | FUNCTION |
| :---: | :---: | :--- |
| L | L | Clear |
| L | H | Count down |
| H | L | Load |
| H | H | Count up |

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |  |
| :---: | :---: | :---: |
| Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |  |
| Operating free-air temperature range: | SN54AS867, SN54AS869 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74AS867, SN74AS869 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54AS867, SN74AS867 <br> SYNCHRONOUS 8-BIT UP/DOWN COUNTERS WITH ASYNCHRONOUS CLEAR

recommended operating conditions

${ }^{\dagger}$ This setup time is required to ensure stable data.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS867 |  |  | SN74AS867 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text {¢ }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{1}=18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{v}_{\mathrm{CC}}-2$ |  |  | $\mathrm{v}_{\mathrm{CC}}-2$ |  |  | V |
| VOL |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad!\mathrm{OL}=20 \mathrm{~mA}$ |  | 0.34 | 0.5 |  | 0.34 | 0.5 | V |
| 1 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IJH | ENT | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
|  | Other inputs |  |  |  | 20 |  |  | 20 |  |
| IIL | ENT | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  | -4 |  |  | -4 | mA |
|  | Other inputs |  |  |  | -2 |  |  | -2 |  |
| $10^{\S}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | - 112 | -30 |  | -112 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  | 134 | 195 |  | 134 | 195 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
recommended operating conditions

|  |  |  | SN54AS869 |  |  | SN74AS869 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High-level output current |  |  |  | -2 |  |  | -2 | mA |
| ${ }^{\prime} \mathrm{OL}$ | Low-level output current |  |  |  | 20 |  |  | 20 | mA |
| $\mathrm{f}_{\text {clock }}$ | Clock frequency |  | 0 |  | 40 | 0 |  | 45 | MHz |
| ${ }^{\text {w }}$ ( (clock) | Duration |  | 12.5 |  |  | 11 |  |  | ns |
| ${ }^{\text {t }}$ su | Setup time ${ }^{\dagger}$ | Data inputs A-H | 6 |  |  | 5 |  |  | ns |
|  |  | Enable $\mathrm{P}(\overline{\mathrm{ENP}})$ or <br> Enable T (ENT) | 10 |  |  | 9 |  |  | ns |
|  |  | S0 or S1 (load) | 13 |  |  | 11 |  |  | ns |
|  |  | S0 or S1 (clear) | 13 |  |  | 11 |  |  | ns |
|  |  | S0 or S1 (count down) | 52 |  |  | 50 |  |  | ns |
|  |  | So or S1 (count up) | 52 |  |  | 50 |  |  | ns |
| $t_{h}$ | Hold time at any input with respect to clock $\uparrow$ |  | 0 |  |  | 0 |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ This setup time is required to ensure stable data.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS869 |  | SN74AS869 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} . \quad \bullet$ I $=18 \mathrm{~mA}$ |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | $\mathrm{V}_{\mathrm{cc}}-2$ |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OL}}=20 \mathrm{~mA}$ | 0.34 | 0.5 |  | 0.34 | 0.5 | V |
| 1 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, $\quad \mathrm{V}_{1}=7 \mathrm{~V}$ |  | 0.1 |  |  | 0.1 | mA |
| 1 H | ENT | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
|  | Other inputs |  |  | 20 |  |  | 20 |  |
| ILL | ENT | $V_{C C}=5.5 \mathrm{~V}, \quad V_{1}=0.4 \mathrm{~V}$ |  | -4 |  |  | -4 | mA |
|  | Other inputs |  |  | -2 |  |  | -2 |  |
| $10^{8}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | -30 |  | - 112 | mA |
| ICC |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$ | 125 | 180 |  | 125 | 180 | mA |

${ }^{\ddagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
§The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

## 'AS867 switching characteristics (see note 1)

| PARAMETER | FROM IINPUT | то OUTPUT | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega \\ & \mathrm{~T}_{A}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS867 |  | SN74AS867 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 40 |  | 50 |  | MHz |
| ${ }^{\text {tPLH }}$ | CLK | $\overline{\mathrm{RCO}}$ | 5 | 31 | 5 | 22 | ns |
| tPHL |  |  | 6 | 19 | 6 | 16 |  |
| tPLH | CLK | Any 0 | 3 | 12 | 3 | 11 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 4 | 16 | 4 | 15 |  |
| ${ }^{\text {tPLH }}$ | ENT | $\overline{\mathrm{RCO}}$ | 3 | 19 | 3 | 10 | ns |
| tPHL |  |  | 5 | 21 | 5 | 17 |  |
| tPLH | $\overline{E N P}$ | $\overleftarrow{\text { RCO }}$ | 5 | 14 | 5 | 14 | ns |
| tPHL |  |  | 5 | 21 | 5 | 17 |  |
| tPHL | $\begin{gathered} \text { Clear } \\ \text { (S0, S1 low) } \end{gathered}$ | Any Q | 7 | 23 | 7 | 21 | ns |

'AS869 switching characteristics (see note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS869 |  | SN74AS869 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 40 |  | 45. |  | MHz |
| tPLH | CLK | $\stackrel{\text { RCO }}{ }$ | 6 | 35 | 6 | 35 | ns |
| tPHL |  |  | 6 | 20 | 6 | 18 |  |
| tPLH | CLK | Any Q | 3 | 12 | 3 | 11 | ns |
| tPHL |  |  | 4 | 16 | 4 | 15 |  |
| ${ }_{\text {t PLH }}$ | $\overline{\text { ENT }}$ | $\overline{\mathrm{RCO}}$ | 3 | 25 | 3 | 15 | ns |
| tPHL |  |  | 6 | 21 | 6 | 17 |  |
| tPLH | $\overline{\mathrm{ENP}}$ | $\overline{\mathrm{RCO}}$ | 5 | 27 | 5 | 19 | ns |
| tpHL |  |  | 6 | 21 | 6 | 18 |  |

NOTE 1: Load circuit and voltage waveforms, are shown in Section 1.

- 'AS870 in 24-Pin Small Outline, 300-mil DIP and Both Plastic and Ceramic 28-Pin Chip Carriers
- 'AS871 in 28-Pin 600-mil DIP and Both Plastic and Ceramic Chip Carriers
- 3-State Buffer-Type Outputs Drive Bus Lines Directly
- Typical Access Time is 11 ns
- Each Register File Has Individual Write Enable Controls and Address Lines
- Designed Specifically for Multibus Architecture and Overlapping File Operations
- Prioritized B Input Port Prevents Write Conflicts During Dual Input Mode
- Dependable Texas Instruments Quality and Reliability


## description

These devices feature two 16 -word by 4 -bit register files. Each register file has individual write-enable controls and address lines. The 'AS870 has two 4-bit data $1 / 0$ ports (DQA1-DQA4 and DQB1-DQB4). The 'AS871 has one 4-bit data I/O port (DQB1-DQB4) with the other data port having individual data inputs (DA1-DA4) and data outputs (OA1-QA4). The data $1 / O$ ports can output to Bus $A$ and Bus $B$; receive input from Bus $A$ and Bus $B$, receive input from Bus A and output to Bus B, or output to Bus $A$ and receive input from Bus $B$. To prevent writing conflicts in the dual-input mode, the $B$ input port takes priority. Two select lines, SO and S1, control which port has access to which register. S2 determines whether the A ports are in the input or the output modes and S3 does likewise for the $B$ ports. The address lines (1A0-1A3 or 2A0-2A3) are decoded by an internal 1-of-16 decoder to select which register word is to be accessed. All outputs are 3-state buffer-type outputs designed specifically to drive bus lines directly.

The SN54AS870 and SN54AS871 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS870 and SN74AS871 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
SN54AS870 . . . JT PACKAGE
SN74AS870 . . . DW OR NT PACKAGE (TOP VIEW)

SN54AS871 . . . JD PACKAGE SN74AS871 . . . N PACKAGE (TOP VIEW)
DA1 $\quad 1 \mathrm{U}_{28}^{7} \mathrm{~V}_{\mathrm{CC}}$
DA2 On $_{2}$ 27DA4
SO ${ }^{3} \quad 26$ Dida
1 AO $\mathrm{H}_{4}^{25} \quad 25 \mathrm{~S} 1$
1A1 [5 $\quad 24$ 2A3
$\begin{array}{ll}1 A 2 \\ 1 A 3 & 23 \\ -1 & 2 A 2 \\ 7 & 2 A 1\end{array}$
$\begin{array}{ll}1 \bar{w} \\ \text { S2 } & 21 \\ 0 & 20 \\ 20 & 2 A O \\ 20\end{array}$
QA1 [10 19] S3
QA2 [11 118 DOB4
QA3 $\left[\begin{array}{ll}12 & 17 \\ \text { ODOB3 }\end{array}\right.$
GND $\left[14 \begin{array}{ll}15 & 15\end{array}\right]$ DQB1
SN54AS870 . . . FK PACKAGE SN74AS870 . . . FN PACKAGE (TOP VIEW)

SN54AS871 . . . FK PACKAGE SN74AS871 . . . FN PACKAGE
(TOP VIEW)


NC - No internal connection

## SN54AS870, SN54AS871, SN74AS870, SN74AS871

 DUAL 16-BY-4 REGISTER FILESlogic symbols ${ }^{\dagger}$

$\dagger$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
logic diagram (positive logic)


## SN54AS870, SN54AS871, SN74AS870, SN74AS871 <br> DUAL 16-BY-4 REGISTER FILES

| FILE SELECT |  |  | INPUT/OUTPUT |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| so | S1 | FILE SEL | S2 | S3 | I/O SEL |
| L | L | 1R TO A, 1R TO B |  |  |  |
| H | L | 2RTOA, 1RTOB | L | 1 | A OUT B OUT |
| L | H | 1R TO A, 2R TO B |  |  | A OUT, B OUT |
| H | H | 2R TOA, 2R TOB |  |  |  |
| L | L | A TO 1R, 1R TO B |  |  |  |
| H | L | A TO 2R, 1R TO B | H | L | A IN, B OUT |
| L | H | A TO 1R, 2R TO B |  |  |  |
| H | H | A TO 2R, 2R TO B |  |  |  |
| L | L | 1R TO A, B TO 1R |  |  |  |
| H | L | 2R TO A, B TO 1R | L | H | A OUT, BIN |
| L | H | 1 R TO A, B TO 2R |  |  |  |
| H | H | 2R TO A, B TO 2R |  |  |  |
| L | L | B TO 1R. |  |  |  |
| H | L | A TO 2R, B TO 1R | H | H | A IN, BIN |
| L | H | A TO 1R, B TO 2R | H | H | AN, BIN |
| H | H | B TO 2R |  |  |  |

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage: All inputs . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Voltage applied to a disabled 3 -state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54AS870, SN54AS871 . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74AS870, SN74AS871 . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  |  | $\begin{aligned} & \text { N54AS } \\ & \text { N54AS } \end{aligned}$ |  |  | $\begin{aligned} & \text { v74AS } \\ & \text { v74AS } \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM. | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltag |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level inp |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level inp |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level ou |  |  |  | -12 |  |  | -15 | mA |
| ${ }^{\text {OL }}$ | Low-level output current |  |  |  | 32 |  |  | 48 | mA |
| $\mathrm{t}_{\mathrm{w}}$ | Duration of |  | 12 |  |  | 12 |  |  | ns |
| ${ }^{\text {tsu }}$ | Setup times | Address before write $\downarrow$ | 5 |  |  | 5 |  |  | ns |
|  |  | Data before write $\uparrow$ | 15 |  |  | 15 |  |  |  |
|  |  | Select before write! | 12 |  |  | 12 |  |  |  |
| $t^{\prime}$ | Hold times | Address after write $\uparrow$ | 0 |  |  | 0 |  |  | ns |
|  |  | Data after write $\uparrow$ | 0 |  |  | 0 |  |  |  |
|  |  | Select after write $\dagger$ | 12 |  |  | 12 |  |  |  |
| TA | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{2} \mathrm{C}$ |

## SN54AS870, SN54AS871, SN74AS870, SN74AS871 DUAL 16-BY-4 REGISTER FILES

'AS870 electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

'AS871 electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^24]SN54AS870, SN54AS871, SN74AS870, SN74AS871
DUAL 16-BY-4 REGISTER FILES
'AS870 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | $\begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{1}=500 \Omega, \\ & \mathrm{R}_{2}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to MAX } \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS870 |  | SN74AS870 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $t a(A)$ | Any A | Any DQ | 5 | 20 | 5 | 15 | ns |
| ${ }^{\mathrm{t}}$ (S) | So | Any DQA | 3 | 15 | 3 | 13 | ns |
|  | S1 | Any DQB | 3 | 15 | 3 | 13 |  |
| ${ }^{\text {t }}$ dis | S2 | Any DQA | 3 | 12 | 3 | 11 | ns |
|  | S3 | Any DQB | 3 | 12 | 3 | 11 |  |
| $t_{\text {en }}$ | S2 | Any DQA | 3 | 15 | 3 | 12 | ns |
|  | S3 | Any DOB | 3 | 15 | 3 | 12 |  |
| $t_{\text {pd }}$ | W | Any DO | 5 | 23 | 5 | 19 |  |
|  | DQA | DQB | 5 | 25 | 5 | 22 | ns |
|  | DQB | DQA | 5 | 25 | 5 | 22 |  |

'AS871 switching characteristics (see Note 1)

| PARAMETER | $\begin{aligned} & \text { FROM } \\ & \text { (INPUT) } \end{aligned}$ | то (OUTPUT) | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R_{1}=500 \Omega, \\ & R_{2}=500 \Omega, \\ & T_{A}=\text { MIN to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS871 |  | SN74AS871 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $t_{a}(\mathrm{~A})$ | Any A | Any QA or DQB | 5 | 20 | 5 | 16 | ns |
| $\mathrm{ta}_{\text {a }} \mathrm{S}$ ) | SO | Any QA | 3 | 15 | 3 | 13 | ns |
|  | S1 | Any DQB | 3 | 15 | 3 | 13 |  |
| ${ }^{\text {d }}$ dis | S2 | Any QA | 3 | 12 | 3 | 11 | ns |
|  | S3 | Any DOB | 3 | 12 | 3 | 11 |  |
| ${ }^{\text {ten }}$ | S2 | Any QA | 3 | 15 | 3 | 12 | ns |
|  | S3 | Ańy DQB | 3 | 15 | 3 | 12 |  |
| ${ }^{\text {tpd }}$ | W | Any QA or DQB | 5 | 23 | 5 | 19 |  |
|  | DA | DOB | 5 | 26 | 5 | 23 | ns |
|  | DQB | QA | 5 | 26 | 5 | 23 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Included Among the Package Options are Compact, 24-Pin, 300-mil-Wide Dips and Both 28-Pin Plastic and Ceramic Chip Carriers
- Buffered 3-State Outputs Drive Bus Lines Directly
- Cascaded to n-Bits
- Eight Selectable Transceiver/Port Functions:

A to B or B to A
Register to $A$ or Register to $B$ Shifted to A or Shifted to B
Off-Line Shifts (A and B Ports in HighImpedance State)
Register Clear

- Particularly Suitable for Use in SignatureAnalysis Circuitry
- Serial Register Provides:

Parallel Storage of Either A or B Input Data
Serial Transmission of Data from Either $A$ or B Port

- Dependable Texas Instruments Quality and Reliability


## description

The 'AS877 features two 8-bit l/O ports (A1-A8 and B1-B8), an 8-bit parallel-load, serial-in, parallel-out shift register, and control logic. With these features, this device is capable of performing eight selectable transceiver or port functions, depending on the state of the three select lines S0, S1, and S2. These functions include: transferring data from port $A$ to port $B$ or vice versa (i.e., the transceiver function), transferring data from the register to either port, serial shifting data to either port, performing off-line shifts (with A and B ports in high-impedance state), and clearing the register. Synchronous parallel loading of the internal register can be accomplished from either port on the positive transition of the clock while serially shifting data in via the SERIN input. The 'AS877 is ideally suited fór applications needing signature-analysis circuitry to enhance system verification and/or fault analysis. All serial data is shifted right. All outputs are buffer-type outputs designed specifically to drive bus lines directly and all are 3-state except for Q8, which is a totem-pole output.

The SN54AS877 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS877 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## 8-BIT UNIVERSAL TRANSCEIVER PORT CONTROLLERS

| FUNCTION TABLE |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{array}{\|c\|} \hline \text { MODE } \\ \text { S2 S1 SO } \\ \hline \end{array}$ | CLOCK | SERIN | A1 01 B1 | A2 $02 \mathrm{B2}$ | A3 03 B3 | A4 04 B4 | A5 05 B5 | A6 06 B6 | A7 0787 | A8 08 B8 | PORT FUNCTION |
| $\begin{aligned} & L L L \\ & L L L \end{aligned}$ |  | X X | $\begin{aligned} & \hline Z Q_{n} A 1 \\ & Z A 1 A 1 \end{aligned}$ | $\mathrm{Z} \mathrm{O}_{\mathrm{n}} \mathrm{A} 2$ $\mathrm{ZA} \mathrm{A}^{\text {A2 }}$ | $z Q_{n} A 3$ $Z ~ A 3 ~ A 3 ~$ | $\begin{aligned} & \mathrm{Z} \mathrm{O}_{\mathrm{n}} \mathrm{~A} 4 \\ & \mathrm{ZA4} \mathrm{A4} \end{aligned}$ | $Z Q_{n} A 5$ $Z ~ A 5 ~ A 5 ~$ |  | $\begin{aligned} & \hline Z Q_{n} A 7 \\ & Z A 7 A 7 \end{aligned}$ | $\begin{aligned} & \mathrm{Z} \mathrm{O}_{n} \mathrm{AB} \\ & \mathrm{Z} A 8 \mathrm{~A} 8 \end{aligned}$ | A TO B |
| $\begin{aligned} & \mathrm{L} L \mathrm{~L} \\ & \mathrm{~L} L \mathrm{H} \end{aligned}$ | $\mathrm{H} \text { or } \mathrm{L}$ | X | $\begin{aligned} & \mathrm{B} 1 \mathrm{O}_{\mathrm{n}} \mathrm{Z} \\ & \mathrm{~B} 1 \mathrm{~B} 1 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & B 2 Q_{n} Z \\ & B 2 \mathrm{~B} 2 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \text { B3 } Q_{n} Z \\ & \text { B3 B3 } Z \end{aligned}$ | $\begin{aligned} & B 4 Q_{n} Z \\ & B 4 B 4 Z \end{aligned}$ | $\begin{aligned} & \text { B5 } Q_{n} Z \\ & \text { B5 } \mathrm{B} 5 \mathrm{Z} \end{aligned}$ | B6 $\mathrm{O}_{\mathrm{n}} \mathrm{Z}$ $\mathrm{B6} \mathrm{B6} \mathrm{Z}$ | $\begin{aligned} & B 7 a_{n} Z \\ & B 7 B 7 Z \end{aligned}$ | $\begin{aligned} & B 8 Q_{n} Z \\ & B 8 B 8 Z \end{aligned}$ | B TO A |
|  | H or L | X |  | $X Q_{n}$ Q2 $Z A 2 A 2$ | $X Q_{n}$ Q3 Z A3 A3 | $\mathrm{X} \mathrm{Q}_{\mathrm{n}} \mathrm{O4}$ $\mathrm{ZA4} A 4$ | $\begin{aligned} & x Q_{n} Q 5 \\ & Z A 5 A 5 \end{aligned}$ | $\mathrm{X} \mathrm{a}_{\mathrm{n}}$ Q6 $\mathrm{z} \mathrm{A6} \mathrm{A6}$ | $\begin{array}{\|l\|l\|} \hline X \quad Q_{n} \quad 07 \\ Z A 7 \quad A 7 \end{array}$ | $\begin{aligned} & x \alpha_{n} 08 \\ & z A 8 A 8 \end{aligned}$ | $\mathrm{O}_{\mathrm{N}}$ TO BN |
| $\begin{aligned} & \mathrm{LHH} \\ & \mathrm{LHH} \end{aligned}$ | $\mathrm{H} \text { or } \mathrm{L}$ | $\begin{aligned} & \hline x \\ & x \end{aligned}$ | $\left.\begin{array}{\|lll} \hline \text { Q1 } & a_{n} \times \\ B 1 & \text { B } & Z \end{array} \right\rvert\,$ | $\begin{aligned} & \mathrm{O} 2 \mathrm{a}_{\mathrm{n}} \mathrm{x} \\ & \mathrm{~B} 2 \mathrm{~B} 2 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \mathrm{Q} 3 \mathrm{Q}_{n} \mathrm{X} \\ & \mathrm{~B} 3 \mathrm{~B} 3 \mathrm{Z} \end{aligned}$ | $\begin{aligned} & \mathrm{C} 4 \mathrm{Q}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{~B} 4 \mathrm{B4} Z \end{aligned}$ | $\begin{gathered} \mathrm{O}^{\mathrm{O}} \mathrm{Q}_{\mathrm{n}} \mathrm{X} \\ \text { B5 B5 } \mathrm{z} \end{gathered}$ | $\begin{aligned} & \mathrm{O}_{6} \mathrm{X} \mathrm{X} \\ & \mathrm{B6} \mathrm{B6Z} \end{aligned}$ | $\begin{aligned} & \mathrm{Q} 7 \mathrm{Q}_{\mathrm{n}} \mathrm{X} \\ & \mathrm{B7} \mathrm{B7} \mathrm{Z} \end{aligned}$ | $\begin{aligned} & 08 \mathrm{a}_{\mathrm{n}} \mathrm{x} \\ & \text { B8 B8 Z } \end{aligned}$ | $\mathrm{O}_{\mathrm{N}}$ TO $\mathrm{A}_{\mathrm{N}}$ |
| $\begin{aligned} & H L L \\ & H L L \\ & H L L \end{aligned}$ | $\mathrm{H} \text { or } \mathrm{L}$ | $\begin{aligned} & \mathrm{X} \\ & \mathrm{H} \end{aligned}$ | $\begin{array}{\|ccc\|} \hline Z & a_{n} & 01 \\ Z & H & H \\ Z & L & L \end{array}$ | $\begin{array}{lll} z & a_{n} & 02 \\ z & 01 & 01 \\ z & 01 & 01 \end{array}$ |  | $\begin{array}{llll} \hline z & a_{n} & 04 \\ z & \text { Q3 } & \text { Q3 } \\ z & \text { Q } & \text { Q3 } \\ \hline \end{array}$ |  | $\begin{array}{lll} \hline z & 0_{n} & 06 \\ z & 05 & 05 \\ z & 05 & 05 \\ \hline \end{array}$ | $\begin{array}{\|lll} \hline z & a_{n} & 07 \\ z & 06 & 06 \\ z & 06 & 06 \end{array}$ | $\begin{array}{lll} z & 0_{n} 08 \\ z & 07 & 07 \\ z & 07 & 07 \end{array}$ | $\begin{gathered} \text { SHIFT } \\ \text { TO } \\ \text { B } \\ \hline \end{gathered}$ |
| $\begin{aligned} & H \text { L H } \\ & \text { H L H } \\ & \text { H L H } \end{aligned}$ | H or L | $\begin{aligned} & \mathrm{X} \\ & \mathrm{H} \\ & \mathrm{~L} \end{aligned}$ | $01 \mathrm{a}_{\mathrm{n}} \mathrm{Z}$ H H Z <br> L L Z | $\begin{aligned} & \text { Q2 } a_{n} z \\ & \text { Q1 Q1 } z \\ & \text { Q1 } 01 z \end{aligned}$ |  | $04 a_{n} z$ Q3 03 z Q3 03 Z | $\begin{aligned} & \text { Q5 Q } Q_{n} Z \\ & \text { Q4 Q4 Z } \\ & \text { Q4 Q4 Z } \end{aligned}$ | $\begin{aligned} & \text { Q6 } Q_{n} z \\ & \text { Q } 25 z \\ & \text { Q } 05 z \end{aligned}$ | $\begin{aligned} & 07 Q_{n} Z \\ & \text { Q6 Q6 } Z \\ & \text { 06 } 06 Z \end{aligned}$ |  | $\begin{gathered} \text { SHIFT } \\ \text { TO } \\ \text { A } \end{gathered}$ |
| $\begin{aligned} & \mathrm{HHL} \\ & \mathrm{HHL} \\ & \mathrm{HHL} \end{aligned}$ | Hor L | $\bar{x}$ |  | $\begin{aligned} & z 0_{n} z \\ & z 01 z \\ & z 01 z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z 02 z \\ & z \text { Q2 } z \end{aligned}$ | $\begin{aligned} & z 0_{n} z \\ & z 03 z \\ & z 03 z \end{aligned}$ | $\begin{aligned} & z Q_{n} Z \\ & z 04 z \\ & z 04 Z \end{aligned}$ | $\begin{aligned} & z 0_{n} z \\ & z 05 z \\ & z 05 z \\ & \hline \end{aligned}$ | $\begin{aligned} & z 0_{n} z \\ & z 06 z \\ & z 06 z \\ & \hline \end{aligned}$ | $z Q_{n} Z$ Z 07 Z Z Q7 Z | SHIFT |
| $\begin{aligned} & \mathrm{HHH} \\ & \mathrm{HHH} \end{aligned}$ | H or L | $\begin{aligned} & \hline x \\ & x \\ & \hline \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z a_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | $\begin{aligned} & z Q_{n} z \\ & z L z \end{aligned}$ | CLEAR |

$n=$ level of $Q_{n}(n=1,2 \ldots 8)$ established on most recent $\uparrow$ transition of CLK. Q 1 thru Q 8 are the shift register outputs; only Q 8 is available externally. The double inversions that take place as data travels from port to port are ignored in this table.

## logic symbol ${ }^{\dagger}$



[^25]
## logic diagram (positive logic)




Pin numbers shown are for DW, JT, and NT packages.

## SN54AS877, SN74AS877

## 8-BIT UNIVERSAL TRANSCEIVER PORT CONTROLLERS

absolute maximum ratings over free-air temperature range

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |
| :---: | :---: |
| Input voltage: All inputs |  |
| I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V |  |
| Voltage applied to a disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V |  |
| Operating free-air temperature range: SN54AS877 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74AS877 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  |

recommended operating conditions


## SN54AS877, SN74AS877 8-BIT UNIVERSAL TRANSCEIVER PORT CONTROLLERS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS877 |  |  | SN74AS877 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| VOH | A1-A8 | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OH}}=-12 \mathrm{~mA}$ | 2 | 3.2 |  |  |  |  | V |
|  | B1-B8 | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | ${ }^{1} \mathrm{OH}=-15 \mathrm{~mA}$ |  |  |  | 2 | 3.3 |  |  |
|  | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , $\mathrm{I}^{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | All outputs except 08 | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=32 \mathrm{~mA}$ |  | 0.25 | 0.5 |  |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | 08 | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}$ = 20 mA |  | 0.25 | 0.5 |  | 0.25 | 0.5 |  |
| 1 | S0, S1, S2 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.3 |  |  | 0.3 | mA |
|  | CLK and SERIN |  |  |  |  | 0.1 |  |  | 0.1 |  |
|  | A1-A8, B1-B8 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$. | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.2 |  |  | 0.2 |  |
| ${ }^{1} \mathrm{H}$ | S0, S1, S2 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $V_{1}=2.7 \mathrm{~V}$ |  |  | 60 |  |  | 60 | $\mu \mathrm{A}$ |
|  | CLK and SERIN |  |  |  |  | 20 |  |  | 20 |  |
|  | A1-A8, B1-B8 ${ }^{\ddagger}$ |  |  |  |  | 70 |  |  | 70 |  |
| ILL | So, S1, S2 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$. | $V_{1}=0.4 \mathrm{~V}$ |  |  | -1 |  |  | -1 | mA |
|  | CLK and SERIN |  |  |  |  | -0.5 |  |  | -0.5 |  |
|  | A1-A8, B1-B8 ${ }^{\ddagger}$ |  |  |  |  | -0.75 |  |  | -0.75 |  |
| 10 § | Except 08 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
|  | Q8 |  |  | -20 |  | -112 | -20 |  | -112 |  |
| ICC |  | $V_{C C}=5.5 \mathrm{~V}$ |  |  | 136 | 220 |  | 136 | 220 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{\mathrm{IL}}$ include the output currents $\mathrm{I}_{\mathrm{OZH}}$ and $\mathrm{I}_{\mathrm{OZL}}$. respectively.
${ }^{5}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R1}=500 \Omega, \\ & \mathrm{R} 2=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN to } \mathrm{MAX} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS877 |  | SN74AS877 |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  | 45 |  | 50 |  | MHz |
| tple | Any A port | Any B port | 2 | 8.5 | 2 | 7 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 3 | 10.5 | 3 | 9 | ns |
| tPL.H | Any B port | Any A port | 2 | 9 | 2 | 7.5 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 3 | 10.5 | 3 | 9 |  |
| tPLH | so, s1, s2 ${ }^{\text {f }}$ | $\begin{gathered} \text { Any } A \text { or } B \\ \text { port } \end{gathered}$ | 3 | 11.5 | 3 | 10 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 2 | 9.5 | 2 | 8 |  |
| tplH | CLK | Any A or B port | 2 | 11 | 2 | 9 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 3 | 13 | 3 | 11.5 | ns |
| tPLH | CLK | QB | 2 | 10.5 | 2 | 8 | ns |
| ${ }_{\text {tPHL }}$ |  |  | 3 | 10 | 3 | 8.5 |  |
| ${ }^{\text {t PHZ }}$ | S0, S1, S2 | Any A or B port | 2 | 7.5 | 2 | 6.5 | ns |
| tplz |  |  | 3 | 13 | 3 | 10.5 |  |
| tPZH |  |  | 2 | 9 | 2 | 7 | is |
| tPZL |  |  | 3 | 11.5 | 3 | 9.5 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
IThe positive transition of S2 will cause low-level data at the A output Bus or stored in the shift register to be invalid for 12 ns .

TYPICAL APPLICATION DATA


## SN54AS882A, SN74AS882A 32-BIT LOOK-AHEAD CARRY GENERATORS

- Directly Compatible with 'AS181B, 'AS1181, 'AS881B, and 'AS1881 ALUs
- Included among the Package Options are Compact, 24-Pin, 300-mil-Wide DIPs and Both 28-Pin Plastic and Ceramic Chip Carriers
- Capable of Anticipating the Carry Across a Group of Eight 4-Bit Binary Adders
- Cascadable to Perform Look-Ahead Across n-Bit Adders
- Typical Carry Time, $\mathbf{C}_{\mathrm{n}}$ to Any $\mathrm{C}_{\mathrm{n}+\mathrm{i}}$, is Less Than 6 ns
- Dependable Texas Instruments Quality and Reliability


## description

The 'AS882A is a high-speed look-ahead carry generator capable of anticipating the carry across a group of eight 4-bit adders permitting the designer to implement look-ahead for a 32-bit ALU with a single package or, by cascading 'AS882A's, full look-ahead is possible across $n$-bit adders.

The SN54AS882A is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS882A is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
'AS882A LOGIC EQUATIONS
$\mathrm{C}_{\mathrm{n}+8}=\mathrm{G} 1+\mathrm{P} 1 \mathrm{G} 0+\mathrm{P}_{1} \mathrm{POC}_{\mathrm{n}}$
$\mathrm{C}_{\mathrm{n}+16}=\mathrm{G} 3+\mathrm{P} 3 \mathrm{G} 2+\mathrm{P} 3 \mathrm{P} 2 \mathrm{G} 1+\mathrm{P} 3 \mathrm{P} 2 \mathrm{P} 1 \mathrm{G} 0$

+ P3P2P1POC $_{n}$
$\mathrm{C}_{\mathrm{n}+24}=\mathrm{G} 5+\mathrm{P} 5 \mathrm{G} 4+\mathrm{P} 5 \mathrm{P} 4 \mathrm{G} 3+\mathrm{P} 5 \mathrm{P} 4 \mathrm{P} 3 \mathrm{G} 2$
+ P5P4P3P2G1 + P5P4P3P2P1G0
+ P5P4P3P2P1POC $_{n}$
$\mathrm{C}_{\mathrm{n}}+32=\mathrm{G} 7+\mathrm{P} 7 \mathrm{G} 6+\mathrm{P} 7 \mathrm{P} 6 \mathrm{G} 5+\mathrm{P} 7 \mathrm{P} 6 \mathrm{P} 5 \mathrm{G} 4$
+P7P6P5P4G3 + P7P6P5P4P3G2
+ P7P6P5P4P3P2G1 + P7P6P5P4P3P2P1G0
+ P7P6P5P4P3P2P1POC $n$

| $\begin{array}{r} \text { SN54AS882A } \\ \text { SN74AS882A } \end{array}$ | . . . JT.PACKAGE DW OR NT PACKAGE P VIEW) |
| :---: | :---: |
| $\mathrm{C}_{n} 51$ | $\mathrm{O}_{24} \mathrm{~V}_{\mathrm{CC}}$ |
| $\overline{\mathrm{G}} \mathrm{L}^{2}$ | $23 \cap \mathrm{NC}$ |
| PO ${ }^{3}$ | $22 \mathrm{C}_{\mathrm{n}}+32$ |
| G1 ${ }^{4}$ | 21 П¢7 |
| P1 $\square_{5}^{5}$ | $20 \square \overline{\mathrm{G}} 7$ |
| $c_{n+8} 6$ | 19 ¢ P 6 |
| - ${ }^{\text {G } 2 \text { - }}$ | 18 Ḡ 6 |
| - 2 2 | $17{ }^{17} C_{n}+24$ |
| G3 $\square_{9}$ | 16 P $\overline{5}$ |
| Р3 10 | 15 G5 |
| $c_{n+16}$ | 14 П $\overline{\mathrm{P}} 4$ |
| GND 12 | 13 - $\overline{\mathrm{G}} 4$ |

SN54AS882A . . . FK PACKAGE SN74AS882A . . . FN PACKAGE (TOP VIEW)


## SN54AS882A, SN74AS882A

32-BIT LOOK-AHEAD CARRY GENERATORS
logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.

FUNCTION TABLE
FOR $\mathrm{C}_{\mathrm{n}}+16$ OUTPUT

| INPUTS |  |  |  |  |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| G]3 | $\overline{\text { G }}$ | Ḡ1 | Ḡ0 | $\overline{\text { P3 }}$ | 戸2 | ¢1 | P0 | $\mathrm{c}_{\mathrm{n}}$ | $\mathrm{C}_{\mathrm{n}+16}$ |
| L | X | X | X | X | X | X | X | X | H |
| X | L | X | x | L | $\times$ | X | X | $x$ | H |
| X | X | L | X | L | L | X | X | X | H |
|  | x | x | L | L | L | L | x | X | H |
| X | X | X | X | L | L | L | L | H | H |
| All other combinations |  |  |  |  |  |  |  |  | L |

FUNCTION TABLE FOR $\mathrm{C}_{\mathrm{n}+8}$ OUTPUT

| INPUTS |  |  |  |  | OUTPET |
| :---: | :---: | :---: | :---: | :---: | :---: |
| G1 | $\overline{\mathbf{G}} 0$ | $\overline{\text { ¢ }} 1$ | $\stackrel{\text { PO }}{ }$ | $\mathrm{c}_{\mathrm{n}}$ | $C_{n+8}$ |
| L | X | X | X | X | H |
| X | L | L | x | X | H |
| X | X | L | L | H | H |
| All other combinations |  |  |  |  | L |

Any inputs not shown in a given table are irrelevant with respect to that output.
logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC |  | 7 V |
| :---: | :---: | :---: |
| Input voltage |  | 7 V |
| Operating free-air temperature range: | SN54AS882A | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74AS822A | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

|  |  | SN54AS882A |  |  | SN74AS882A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current |  |  | -2 |  |  | -2 | mA |
| ${ }_{\text {IOL }}$ | Low-level output current |  |  | 20 |  |  | 20 | mA |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS882A |  |  | SN74AS882A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, |  | $1=-18 \mathrm{~mA}$ |  |  | -1.2 |  | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=20 \mathrm{~mA}$ |  | 0.3 | 0.5 |  | 0.3 | 0.5 | V |
| 1 | $\mathrm{C}_{\mathrm{n}}, \overline{\mathrm{P}}$, $\overline{\mathrm{P}} 1$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  |  | 0.4 |  |  | 0.4 | mA |
|  | Ḡ0, $\overline{\mathrm{G}} 6$ |  |  |  |  | 0.8 |  |  | 0.8 |  |
|  | $\overline{\mathrm{G}} 1, \overline{\mathrm{G}} 2, \overline{\mathrm{G}} 4$ |  |  |  |  | 1.2 |  |  | 1.2 |  |
|  | $\overline{\mathrm{G}} 3, \mathrm{G} 5$ |  |  |  |  | 1.5 |  |  | 1.5 |  |
|  | $\overline{\mathrm{G}} 7$ |  |  |  |  | 0.9 |  |  | 0.9 |  |
|  | $\overline{\mathrm{P}} 2, \mathrm{P} 3$ |  |  |  |  | 0.3 |  |  | 0.3 |  |
|  | $\overline{\mathrm{P}} 4, \overline{\mathrm{P}} 5$ |  |  |  |  | 0.2 |  |  | 0.2 |  |
|  |  |  |  |  |  | 0.1 |  |  | 0.1 |  |
| IH | $\mathrm{C}_{\mathrm{n}}, \overline{\mathrm{P}}, \mathrm{P}_{1}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $V_{1}=2.7 \mathrm{~V}$ |  |  | 80 |  |  | 80 | $\mu \mathrm{A}$ |
|  | $\overline{\mathrm{G}} 0, \mathrm{G} 6$ |  |  |  |  | 160 |  |  | 160 |  |
|  | $\overline{\mathrm{G}} 1, \overline{\mathrm{G}} 2, \overline{\mathrm{G}} 4$ |  |  |  |  | 240 |  |  | 240 |  |
|  | $\overline{\mathrm{G}} 3, \overline{\mathrm{G}} 5$ |  |  |  |  | 300 |  |  | 300 |  |
|  | $\overline{\mathrm{G}} 7$ |  |  |  |  | 180 |  |  | 180 |  |
|  | $\overline{\mathrm{P}} 2, \overline{\mathrm{P}} 3$ |  |  |  |  | 60 |  |  | 60 |  |
|  | $\overline{\mathrm{P}} 4, \overline{\mathrm{P}} 5$ |  |  |  |  | 40 |  |  | 40 |  |
|  | $\overline{\mathrm{P}}_{6, ~ \bar{P}} 7$ |  |  |  |  | 20 |  |  | 20 |  |
| ILL | $\mathrm{C}_{\mathrm{n}}, \stackrel{\overline{\mathrm{P}}}{ }, \overline{\mathrm{P}} 1$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=0.4 \mathrm{~V}$ |  |  |  | -2 |  |  | -2 | mA |
|  | $\overline{\mathrm{G}} 0, \overline{\mathrm{G}} 6$ |  |  |  |  | -4 |  |  | -4 |  |
|  | $\overline{\mathrm{G}} 1, \overline{\mathrm{G}} 2, \overline{\mathrm{G}} 4$ |  |  |  |  | -6 |  |  | -6 |  |
|  | $\overline{\mathrm{G}} 3, \mathrm{G} 5$ |  |  |  |  | -7.5 |  |  | -7.5 |  |
|  | G7 |  |  |  |  | -4.5 |  |  | -4.5 |  |
|  | $\overline{\mathrm{P}} 2, \overline{\mathrm{P}} 3$ |  |  |  |  | -1.5 |  |  | -1.5 |  |
|  | $\overline{\mathrm{P}} 4, \overline{\mathrm{P}} 5$ |  |  |  |  | -1 |  |  | -1 |  |
|  | $\overline{\mathrm{P}} 6, \overline{\mathrm{P}} 7$ |  |  |  |  | -0.5 |  |  | -0.5 |  |
| $10^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -130 | -30 |  | -130 | mA |
| ICC |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  | $44 \quad 70$ |  |  | 44 |  | 70 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS822A |  | SN74AS882A |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| tPLH | $C_{n}$ | Any output | 2 | 10 | 2 | 9 | ns |
| tPHL |  |  | 3 | 15 | 3 | 14 |  |
| tPLH | $\overline{\mathrm{P}}$ or $\overline{\mathrm{G}}$ | $\mathrm{C}_{\mathrm{n}+8}$ | 2 | 8 | 2 | 7 |  |
| ${ }^{\text {tPHL }}$ |  |  | 2 | 8 | 2 | 7 |  |
| ${ }_{\text {t }}$ PLH | $\overline{\mathrm{P}}$ or $\overline{\mathrm{G}}$ | $C_{n+16}$ | 2 | 8 | 2 | 7 |  |
| tPHL |  |  | 2 | 8 | 2 | 7 |  |
| ${ }_{\text {tPLH }}$ | $\overline{\mathrm{P}}$ or $\overline{\mathrm{G}}$ | $C_{n+24}$ | 2 | 8 | 2 | 7 |  |
| tPHL |  |  | 2 | 11 | 2 | 10 |  |
| ${ }_{\text {tPLH }}$ | $\overline{\mathrm{P}}$ or $\overline{\mathrm{G}}$ | $C_{n+32}$ | 1.5 | 9 | 2 | 8 |  |
| tPHL |  |  | 2 | 13 | 2 | 12 |  |

NOTE 1: Load circuits and voltage waveforms are shown in Section 1.

## TYPICAL APPLICATION DATA

The application given in Figure 1 illustrates how the 'AS882A can implement look-ahead carry for a 32-bit ALU (in this case, the popular 'AS881A) with a single package. Typical carry times shown are derived using the standard Advanced Schottky load circuit.


FIGURE 1
Likewise, Figure 2 illustrates the same 32 -bit ALU using two 'AS882s. This shows the worst-case delay from LSB to MSB to be 19 ns as opposed to 25 ns in Figure 1.


FIGURE 2

- Included among the Package Options Are Compact, 24-Pin, 300-mil DIPs and Both 28-Pin Ceramic and Plastic Chip Carriers
- Latchable P Input Ports with Power-Up Clear
- Choice of Logical or Arithmetic (2's Complement) Comparison
- Data and PLE Inputs Utilize P-N-P Input Transistors to Reduce DC Loading Effects
- Approximately 35\% Improvement in AC Performance Over Schottky TTL while Performing More Functions
- Cascadable to $n$-Bits while Maintaining High Performance
- 10\% Less Power than STTL for an 8-Bit Comparison
- Dependable Texas Instruments Quality and Reliability


## description

These advanced Schottky devices are capable of performing high-speed arithmetic or logic comparisons on two 8-bit binary or two's complement words. Two fully decoded decisions about words $P$ and $Q$ are externally available at two outputs. These devices are fully expandable to any number of bits without external gates. The $\mathrm{P}>\mathrm{Q}$ and $\mathrm{P}<\mathrm{Q}$ outputs of a stage handling less-significant bits may be connected to the $\mathrm{P}>\mathrm{Q}$ and $\mathrm{P}<\mathrm{Q}$ inputs of the next stage handling more-significant bits to obtain comparisons of words of longer lengths. The cascading paths are implemented with only a two-gate-level delay to reduce overall comparison times for long words. Two alternative methods of cascading are shown in the typical application data.

The latch is transparent when $P$ Latch Enable (PLE) is high; the $P$ input port is latched when PLE is low. This provides the designer with temporary storage for the $P$ data word. The enable circuitry is implemented with minimal delay times to enhance performance when cascaded for longer words. The PLE and P and Q data inputs utilize p-n-p input transistors to reduce the low-level current input requirement to typically -0.25 mA , which minimizes dc loading effects.
The SN54AS885 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS885 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## SN54AS885, SN74AS885 <br> 8-BIT MAGNITUDE COMPARATORS

logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
FUNCTION TABLE

| COMPARISON | L/ $\overline{\mathbf{A}}$ | DATA INPUTS PO-P7, Q0-07 | INPUT$P>Q$ | INPUT$P<Q$ | OUTPUTS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | $\mathbf{P}>\mathbf{Q}$ | $\mathrm{P}<0$ |
| LOGICAL | H | $P>0$ | X | X | H | L |
| LOGICAL | H | $P<0$ | X | X | L | H |
| LOGICAL $\ddagger$ | H | $P=0$ | H OR L | H OR L | H OR L | H ORL |
| ARITHMETIC | L | $P A G Q$ | $X$ | $x$ | H | L |
| ARITHMETIC | L | Q AG P | $X$ | $x$ | L | H |
| ARITHMETIC ${ }^{\ddagger}$ | L | $P=0$ | HORL | H OR L | H OR L | H OR L |

$\ddagger$ In these cases the $P>Q$ output will follow the $P>Q$ input, and the $P<Q$ output will
follow the $P<Q$ input.
$A G$ - arithmetically greater than
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Operating free-air temperature range: SN54AS885 . . . . . . . . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74AS885 . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## SN54AS885, SN74AS885

## 8-BIT MAGNITUDE COMPARATORS

recommended operating conditions

| PARAMETER |  | SN54AS885 |  |  | SN74AS885 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current |  |  | -2 |  |  | -2 | mA |
| ${ }^{1} \mathrm{OL}$ | Low-level output current |  |  | 20 |  |  | 20 | mA |
| $\mathrm{t}_{\text {su }}$ | Setup time to PLE $\downarrow$ | 2 |  |  | 2 |  |  | ns |
| $t_{\text {h }}$ | Hold time after PLE $\downarrow$ | 4 |  |  | 4 |  |  | ns |
| TA | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS885 |  |  | SN74AS885 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5$ to | $\mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~m}$ | VCC |  |  | VCC |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{OL}}=20 \mathrm{~mA}$ |  | 0.35 | 0.5 |  | 0.35 | 0.5 | V |
| 1 |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$ | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | $\mu \mathrm{A}$ |
| $\mathrm{IIH}^{\text {H }}$ | L/ $\bar{A}$ | $V_{C C}=5.5$ | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
|  | Others |  |  |  |  | 20 |  |  | 20 |  |
| IL | $L / \bar{A}$ | $V_{C C}=5.5 \mathrm{~V}, \quad V_{1}=0.4 \mathrm{~V}$ |  |  |  | -4 |  |  | -4 | mA |
|  | $\begin{aligned} & P>Q_{\text {in }} \\ & P<Q_{\text {in }} \end{aligned}$ |  |  |  |  | -2 |  |  | -2 |  |
|  | P, Q, PLE |  |  |  |  | -1 |  |  | -1 |  |
| $\frac{10}{10}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -20 |  | -112 | -20 |  | -112 | mA |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | See Note 1 |  | 130 | 210 |  | 130 | 210 | mA |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit current, IOS.
NOTE 1: $I_{C C}$ is measured with all inputs high except $L / \bar{A}$, which is low.
switching characteristics (see Note 2)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
NOTE 2: Load circuit and voltage waveforms are shown in Section 1.

## TYPICAL APPLICATION DATA

The 'AS885 can be cascaded to compare words longer than 8 -bits. Figure 1 shows the comparison of two 32-bit words; however, the design is expandable to $n$-bits. Figure 1 shows the optimum cascading arrangement for comparing words of 32 bits or greater. Typical delay times shown are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, and use the standard Advanced Schottky load of $R_{L}=500 \Omega, C_{L}=50 \mathrm{pF}$.


FIGURE 1. 32-BIT TO 72 (N)-BIT MAGNITUDE COMPARATOR

## TYPICAL APPLICATION DATA

The method shown in Figure 2 is the fastest cascading arrangement for comparing 16-bit or 24-bit words. Typical delay times shown are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, and use the standard Advanced Schottky load of $\mathrm{R}_{\mathrm{L}}=500 \Omega$, $C_{L}=50 \mathrm{pF}$.


FIGURE 2

- STL-AS Technology
- Parallel 8-Bit ALU with Expansion Inputs and Outputs
- 13 Arithmetic and Logic Functions
- 8 Conditional Shifts (Single and Double Length)
- 4 Instructions that Manipulate Bits
- Add and Subtract Immediate Instructions
- Absolute Value Instruction
- Signed Magnitude to/from Two's Complement Conversion
- Single- and Double-Length Normalize
- Select Functions
- Signed and Unsigned Divides with Overflow Detection; Input does not Need to be Prescaled
- Signed, Mixed, and Unsigned Multiplies
- Three-Operand, 16-Word Register File
- Full Carry Look Ahead Support
- Sign, Carry Out, Overflow, and Zero-Detect Status Capabilities
- Excess-3 BCD Arithmetic
- Internal Shift Multiplexers that Eliminate the Need for External Shift Control Parts
- ALU Bypass Path to Increase Speeds of Multiply, Divide, and Normalize Instructions and to Provide New Instructions such as Bit Set, Bit Reset, and Bit Test
- 3-Operand Register Files to Allow an Operation and a Move Instruction to be Combined
- Bit Masks that are Shared with Register Address Fields to Minimize Control Store Word Width
- 3 Data Input/Output Paths to Maximize Data Throughput


## description

These 8-bit Advanced Schottky TTL integrated circuits are designed to implement high performance digital computers or controllers. An architecture and instruction set has been chosen that supports a fast system clock, a narrow micro-code word width, and a high system throughput. The powerful instruction set allows high-speed system architecture to be implemented and also allows an existing system's performance to be upgraded while protecting software investments. These processors are non-cascadable versions of the 'AS888. They are designed for 8-bit applications only.

The SN54AS887 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS887 and SN74AS887-1 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

Package options include both plastic and ceramic chip carriers in addition to a 68 -pin grid array ceramic package.


| PIN GRID ARRAY | $\begin{gathered} \text { CHIP } \\ \text { CARRIER } \end{gathered}$ | NAME | 1/0 | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| A-10 | 28 | TEST | 1 | Test input pin. Connected to ground for normal operation. |
| B-7 | 29 | SSF | 1/0 | Special shift function. Used to transfer required information between packages during special instruction execution. |
| A-9 | 30 | ZERO | 1/0 | Device zero detection, open collector. Input during certain special instructions. |
| A. 8 | 31 | OVR | 0 | ALU overflow, low active. |
| A-7 | 32 | N | 0 | ALU negative, low active. |
| A. 6 | 33 | $\mathrm{C}_{\mathrm{n}+8}$ | 0 | ALU ripple carry output. |
| B-6 | 34 | $\overline{\text { S107 }}$ | 1/0 |  |
| A-5 | 35 | $\overline{0107}$ | 1/0 |  |
| A-4 | 36 | $\overline{0100}$ | 1/0 | Bidirectional shift pin, low active. |
| A-3 | 37 | Stoo | 1/0 |  |
| A-2 | 38 | $\mathrm{C}_{n}$ | 1 | ALU carry input. |
| B-4 | 39 | 10 | 1 |  |
| B-3 | 40 | 11 | 1 |  |
| B-1 | 41 | 12 | 1 |  |
| B-2 | 42 | 13 | 1 |  |
| B-5 | 43 | 14 | 1 | Instruction input. |
| C-1 | 44 | 15 | 1 |  |
| D-1 | 45 | 16 | 1 |  |
| E-1 | 46 | 17 | 1 |  |
| C-2 | 47 | $\mathrm{V}_{\mathrm{CC} 2}$ |  | Low voltage power supply (2 V). |
| D-2 | 48 | $\mathrm{V}_{\text {CC1 }}$ |  | I/O interface supply voltage ( 5 V ). |
| E-2 | 49 | OEA | 1 | DA bus enable, low active. |
| F-1 | 50 | $\overline{E A}$ | 1 | ALU input operand select. High state selects external DA bus and low state selects register file. |
| F-2 | 51 | GND |  | Ground pin. |
| G-2 | 52 | DAO | 1/0 |  |
| $\mathrm{H}-2$ | 53 | DA1 | 1/0 |  |
| G-1 | 54 | DA2 | 1/0 |  |
| H-1 | 55 | DA3 | $1 / 0$ | A port data bus. Outputs register file data ( $\overline{E A}=0)$ or inputs external data ( $\overline{E A}=1$ ) |
| J-1 | 56 | DA4 | 1/0 | A port data bus. Outputs register file data ( $E A=0)$ or inputs external data $(E A=1)$. |
| J-2 | 57 | DA5 | 1/0 |  |
| K-1 | 58 | DA6 | $1 / 0$ |  |
| K-2 | 59 | DA7 | 1/0 |  |
| L.2 | 60 | CK | 1 | Clocks all synchronous registers on positive edge. |
| K-3 | 61 | C0 | 1 |  |
| L-3 | 62 | C1 | 1 | Register file write address select. |
| K-4 | 63 | C2 | 1 |  |
| L-4 | 64 | C3 | 1 |  |
| K-5 | 65 | AO | 1 |  |
| L-5 | 66 | A1 | 1 | file |
| L-6 | 67 | A2 | 1 | Register tile A port read address select. |
| K-6 | 68 | A3 | 1 |  |

## SN54AS887, SN74AS887

8-BIT PROCESSORS

N LSI Devices

| PIN GRID ARRAY | $\begin{gathered} \text { CHIP } \\ \text { CARRIER } \end{gathered}$ | NAME | I/O | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| K-7 | 1 | $\overline{\text { WE }}$ | 1 | Register file (RF) write enable. Data is written into RF when $\overline{W E}$ is low and a low-to-high clock transition occurs. RF write is inhibited when $\overline{W E}$ is high. |
| L-7 | 2 | B3 | 1 |  |
| L-8 | 3 | B2 | 1 | Register file B port read address select ( $0=$ LSB) |
| L-9 | 4 | B1 | 1 | Register file B port read address select. (0 = LSB). |
| L-10 | 5 | BO | 1 |  |
| K-10 | 6 | EBO | 1 | ALU input operand select. EB0 and EB1 selects the source of data that the S multiplexer |
| K-11 | 7 | EB1 | 1 | provides for the $S$ bus. Independent control of the DB bus and data path selection allow the user to isolate the DB bus while the ALU continues to process data. |
| K-9 | 8 | OEB | 1 | DB bus enable, low active. |
| K-8 | 9 | DB7 | 1/0 |  |
| H-10 | 10 | DB6 | $1 / 0$ |  |
| J-11 | 11 | DB5 | 1/0 |  |
| H-11 | 12 | DB4 | 1/0 | B port data bus. Outputs register data ( $\overline{\mathrm{OEB}}=0$ ) or used to input external data |
| G-11 | 13 | DB3 | 1/0 | $(\overline{O E B}=1),(0=L S B)$. |
| F-11 | 14 | DB2 | !/0 |  |
| E-11 | 15 | DB1 | I/O |  |
| G-10 | 16 | DBO | 1/0 |  |
| J-10 | 17 | SELY | 1 | Y bus select, high active. |
| D-11 | 18 | Y7 | 1/0 |  |
| C-11 | 19 | Y6 | 1/0 |  |
| D-10 | 20 | Y5 | I/O |  |
| C-10 | 21 | Y4 | 1/0 | Y port data bus. Outputs instruction results ( $\overline{O E Y}=0$ ) or used to put external data into |
| F-10 | 22 | Y3 | 1/0 | register file ( $\overline{O E Y}=1$ ). |
| E-10 | 23 | Y2 | 1/0 |  |
| B-11 | 24 | Y1 | 1/0 |  |
| B-10 | 25 | Y0 | 1/0 |  |
| B-9 | 26 | $\overline{\mathrm{OEY}}$ | 1 | Y bus output enable, low active. |
| F-2 | 27 | GND |  | Ground pin |

functional block diagram


## architectural elements

## 3-port register file

Working registers consist of 128 storage elements organized into sixteen 8 -bit words. These storage elements appear to the user as 16 positive edge-triggered registers. The three port addresses, one write $(C)$ and two reads ( $A$ and $B$ ), are completely independent of each other to implement a 3-operand register file. Data is written into the register file when $\overline{W E}$ is low and a low-to-high clock transition occurs. The ADD and SUBTRACT immediate instructions require only one source operand. The B address is used as the source address, and the bits of the $A$ address are used to provide a constant field. The SET, RESET, and TEST BIT instructions use the B addressed register as both the source and destination register while the $A$ and $C$ addresses are used as masks. These instructions are explained in more detail in the instruction section.

## S multiplexer

The S multiplexer selects the ALU operand, as follows:

| EB1 | EB0 | S bus |
| :--- | :--- | :--- |
| Low | Low | RF data |
| Low | High | MQ data |
| High | Low | DB data |
| High | High | MQ data |

DB port
The 8-bit bidirectional DB port inputs external data to the ALU or outputs the register file. If $\overline{O E B}$ is low, the $D B$ bus is active; if $\overline{O E B}$ is high, the $D B$ bus is in the high impedance state. Notice that the DB port may be isolated at the same time that register file data is passed to the ALU.

R multiplexer
The $R$ multiplexer selects the other operand of the ALU. Except for those instructions that require constants or masks, the $R$ bus will contain DA if $\overline{E A}$ is high or the RF data pointed to by $A$ if $\overline{E A}$ is low.

## DA port

The 8-bit bidirectional DA port inputs external data to the ALU or outputs the register file. If $\overline{\mathrm{OEA}}$ is low, the DA bus is active; if $\overline{\mathrm{OEA}}$ is high, the DA bus is in the high-impedance state.

Notice that the DA bus may be isolated while register file data is passed to the ALU.

## ALU

The shift instructions are summarized in Table 4 and illustrated in Figure 2. The ALU can perform seven arithmetic and six logical instructions on two 8-bit operands. It also supports multiplication, division, normalization, bit set, reset, test, byte operations, and excess-3 BCD arithmetic. These source operands are the outputs of the $S$ and $R$ multiplexers.

## ALU and MQ shifters

ALU and MQ shifters perform all of the shift, multiply, divide, and normalize functions. Table 4 shows the value of the $\overline{\mathrm{SIO7}}$ and $\overline{\mathrm{Q1O7}}$ pins of the most significant package. The standard shifts may be made into conditional shifts and the serial data may be input or output with the aid of two three-state gates. These capabilities are discussed further in the arithmetic and logic section.

## MO register

The multiplier-quotient (MO) register has specific functions in multiplication, division, and normalization. This register may also be used as a temporary storage register. The MQ register may be loaded if the instruction code on pins 17-IO is E1-E7 or E9-EE (See Table 1).

## Y bus

The Y bus contains the output of the ALU shifter if $\overline{\mathrm{OEY}}$ is low and is a high impedance input if $\overline{\mathrm{OEY}}$ is high. SELY must be low to pass the internal ALU shift bus and must be high to pass the external $Y$ bus to the register file.

## status

Four status pins are available on the most significant package, overflow (OVR), sign ( $N$ ), carry out ( $C_{n+8}$ ), and zero (ZERO). The $C_{n}+8$ line signifies the ALU result while OVR, ZERO, and $N$ refer the status after the ALU shift has occurred. Notice that the ZERO pin cannot be used to detect whether an input placed on a high impedance $Y$ bus is zero.

## divide BCD flip-flops

The multiply-divide flip-flops contain the status of the previous multiply or divide instruction. They are affected by the following instructions:

```
DIVIDE REMAINDER FIX
SIGNED DIVIDE QUOTIENT FIX
SIGNED MULTIPLY
SIGNED MULTIPLY TERMINATE
SIGNED DIVIDE INITIALIZE
SIGNED DIVIDE START
```

```
SIGNED DIVIDE ITERATE
UNSIGNED DIVIDE START
UNSIGNED DIVIDE ITERATE
UNSIGNED MULTIPLY
SIGNED DIVIDE TERMINATE
UNSIGNED DIVIDE TERMINATE
```

The excess-3 BCD flip-flops are affected by all instructions except NOP. The clear function clears these flip-flops. They preserve the carry from each nibble (4-bits) in excess-3/BCD operations.

## test pin (test)

This pin should be connected to ground.
special shift function (SSF) pin
Conditional shifting algorithms may be implemented via control of the SSF pin. The applied voltage to this pin may be set as a function of a potential overflow condition (the two most significant bits are not equal) or any other condition (see Group 1 instructions).

## instruction set

The 'AS887 bit-slice processor uses bits 17-IO as instruction inputs. A combination of bits I3-IO (Group 1 instructions) and bits 17-14 (Group 2-5 instructions) are used to develop the 8 -bit op code for a specific instruction. Group 1 and Group 2 instructions can be combined to perform arithmetic or logical functions plus a shift function in one instruction cycle. A summary of the instruction set is given in Table 1.

TABLE 1. INSTRUCTION SET

| INSTRUCTION BITS (I3-10) hex CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| 0 1 2, 3 4 5 6 7 8 9 A B C D E F | ADD <br> SUBR <br> SUBS <br> INCS <br> INCNS <br> INCR <br> INCNR <br> XOR <br> AND <br> OR <br> NAND <br> NOR <br> ANDNR | Accesses Group 4 instructions $\begin{aligned} & R+S+C_{n} \\ & \bar{R}+S+C_{n} \\ & R+\bar{S}+C_{n} \\ & S+C_{n} \\ & \bar{S}+C_{n} \\ & R+C_{n} \\ & \bar{R}+C_{n} \end{aligned}$ <br> Accesses Group 3 instructions <br> R XOR S <br> R AND S <br> R OR S <br> R NAND S <br> R NOR S <br> $\overline{\mathrm{R}}$ AND S <br> Accesses Group 5 instructions |
| GROUP 2 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-14) HEX CODE | MNEMONIC | FUNCTION |
| 0 <br> 1 <br> 2 <br> 3 <br> 4 <br> 5 <br> 6 <br> 7 <br> 8 <br> 9 <br> A <br> B <br> C <br> D <br> E <br> F | SRA <br> SRAD <br> SRL <br> SRLD <br> SLA <br> SLAD <br> SLC <br> SLCD <br> SRC <br> SRCD <br> MQSRA <br> MOSRL <br> MQSLL <br> MQSLC <br> LOADMQ <br> PASS | Arithmetic Right Single <br> Arithmetic Right Double <br> Logical Right Single <br> Logical Right Double <br> Arithmetic Left Single <br> Arithmetic Left Double <br> Circular Left Single <br> Circular Left Double <br> Circular Right Single <br> Circular Right Double <br> Pass $(F \rightarrow Y)$ and Arithmetic Right MQ <br> Pass $(F \rightarrow Y)$ and Logical Right MQ <br> Pass ( $F \rightarrow Y$ ) and Logical Left MQ <br> Pass $(F \rightarrow Y)$ and Circular Left MQ <br> Pass $(F \rightarrow Y)$ and Load $M Q(F=M Q)$ <br> Pass ( $F \rightarrow Y$ ) |

tAble 1. INSTRUCTION SET (Continued)

| INSTRUCTION BITS (17-10) HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| 08 18 28 38 48 58 68 78 88 98 A8 $B 8$ C8 $D 8$ E8 F8 | SET1 SETO TB1 TBO ABS SMTC ADDI SUBI | Set Bit <br> Reset Bit <br> Test Bit (One) <br> Test Bit (Zero) <br> Absolute Value <br> Sign Magnitude/Two's Complement <br> Add Immediate <br> Subtract Immediate <br> Reserved <br> Reserved <br> Reserved <br> Reserved <br> Reserved <br> Reserved <br> Reserved <br> Reserved |
| GROUP 4 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-10) HEX CODE | MNEMONIC | FUNCTION |
| 00 10 20 30 40 50 60 70 80 90 AO $B O$ $C O$ $D O$ $E O$ FO | SEL <br> SNORM <br> DNORM <br> DIVRF <br> SDIVQF <br> SMULI <br> SMULT <br> SDIVIN <br> SDIVIS <br> SDIVI <br> UDIVIS <br> UDIVI <br> UMULI <br> SDIVIT <br> UDIVIT | Reserved <br> Select S/R <br> Single Length Normalize <br> Double Length Normalize <br> Divide Remainder Fix <br> Signed Divide Quotient Fix <br> Signed Multiply Iterate <br> Signed Multiply Terminate <br> Signed Divide Initialize <br> Signed Divide Start <br> Signed Divide Iterate <br> Unsigned Divide Start <br> Unsigned Divide Iterate <br> Unsigned Multiply Iterate <br> Signed Divide Terminate <br> Unsigned Divide Terminate |

TABLE 1. INSTRUCTION SET (Concluded)

| GROUP 5 INSTRUCTIONS |  |  |
| :---: | :---: | :--- |
| INSTRUCTION BITS (17-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| 5 F | CLR | Clear |
| 6 F | CLR | Clear |
| 7 F | BCDBIN | BCD to Binary |
| 8 F |  | Reserved |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No.Operation |

group 1 instructions
tABLE 2. GROUP 1 INSTRUCTIONS

| INSTRUCTION BITS (I3-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 0 |  | Accesses Group 4 instructions |
| 1 | ADD | $R+S+C_{n}$ |
| 2 | SUBR | $\bar{R}+S+C_{n}$ |
| 3 | SUBS | $R+\bar{S}+C_{n}$ |
| 4 | INCS | $S+C_{n}$ |
| 5 | INCNS | $\bar{S}+\mathrm{C}_{n}$ |
| 6 | INCR | $R+C_{n}$ |
| 7 | INCNR | $\bar{R}+\mathrm{C}_{n}$ |
| 8 |  | Accesses Group 3 instructions |
| 9 | XOR | $R$ XOR S |
| A | AND | R AND S |
| $B$ | OR | R OR S |
| C | NAND | R NAND S |
| D | NOR | R NOR S |
| E | ANDNR | $\bar{R}$ AND S |
| F |  | Accesses Group 5 instructions |

Group 1 instructions (excluding hex codes 0,8 , and F), shown in Table 2, may be used in conjunction with Group 2 shift instructions to perform arithmetic or logical functions plus a shift function ${ }^{\dagger}$ in one instruction cycle (hex codes 0,8 , and $F$ are used to access Group 4, 3, and 5 instructions, respectively). Each shift may be made into a conditional shift by forcing the special shift function (SSF) pin into the proper state. If the SSF pin is high or floating, the shifted ALU output will be sent to the output buffers. If the SSF pin is pulled low externally, the ALU result will be passed directly to the output buffers. Conditional shifting is useful for scaling inputs in data arrays or in signal processing algorithms.
These instructions set the BCD flip-flop for the excess-3 correct instruction. The status is set with the following results ( $C_{n}+8$ is ALU carry out and is independent of shift operation; others are evaluated after shift operation).
${ }^{\dagger}$ Double-precision shifts involve both the ALU and MO register.
Status is set with the following results:
Arithmetic

| N | $\rightarrow$ | MSB of result |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Signed arithmetic overflow |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |
| Logic |  |  |
| N | $\rightarrow$ | MSB of result |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Result equal zero |

TABLE 3. GROUP 2 INSTRUCTIONS

| INSTRUCTION BITS (I7-14) <br> HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 0 | SRA | Arithmetic Right Single |
| 1 | SRAD | Arithmetic Right Double |
| 2 | SRL | Logical Right Single |
| 3 | SRLD | Logical Right Double |
| 4 | SLA | Arithmetic Left Single |
| 5 | SLAD | Arithmetic Left Double |
| 6 | SLC | Circular Left Single |
| 7 | SLCD | Circular Left Double |
| 8 | SRC | Circular Right Single |
| 9 | SRCD | Circular Right Doubie |
| A | MOSRA | Pass $(F \rightarrow Y)$ and Arithmetic Right MQ |
| B | MQSRL | Pass $(F \rightarrow Y)$ and Logical Right MQ |
| C | MQSLL | Pass $(F \rightarrow Y)$ and Logical Left MQ |
| D | MQSLC | Pass $(F \rightarrow Y)$ and Circular Left MQ |
| E | LOADMQ | Pass $(F \rightarrow Y)$ and Load MQ $(F=M Q)$ |
| F | PASS | Pass $(F \rightarrow Y)$ |

The processor's shift instructions are implemented using Group 2 instructions (Table 3 ). The connections are the same on all instructions including multiply, divide, and normalization functions.

The following external connections are required:

$$
\overline{\overline{\mathrm{SIO7}} \text { to } \overline{\mathrm{SIOO}}}
$$

Single- and double-precision shifts are supported. Double-precision shifts assume the most significant half has come through the ALU and will be placed (if $\overline{W E}$ is low) into the register file on the rising edge of the clock and the least significant half lies in the MQ register. All Group 2 shifts may be made conditional. (see previous page)

The following definitions apply to Group 2 shift instructions:
Arithmetic right shifts copy the sign of the number if no overflow occurs from the ALU calculation; if overflow occurs, the sign bit is inverted.
Arithmetic left shifts do not retain the sign of the number if an overflow occurs. A zero is filled into the LSB if not forced externally.
Logical right shifts fill a zero in the MSB position if not forced externally.
Circular right shifts fill the LSB in the MSB position.
Circular left shifts fill the MSB in the LSB position.
Shifting left is defined as moving a bit position towards the MSB (doubling).
Shifting right is defined as moving a bit towards the LSB (halving).


FIGURE 1. SERIAL I/O

Serial input may be performed using the circuitry shown in Figure 1. A single-/or double-precision arithmetic left or logical right shift fills the complement of the data on $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{SIO7}}$ into the LSB or MSB of the data word(s). Note that if $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{SIO}}$ are floating $(\mathrm{HI}-\mathrm{Z})$, a zero will be filled as an end condition.

Serial output may be performed with circular instructions.
The shift instructions are summarized in Table 4 and illustrated in Figure 2. In Figure 2 and all succeeding figures that illustrate instruction execution, the following definitions apply:

QBT - End fill for signed divide.
MQF - End fill for unsigned divide.
SRF - End fill for signed multiply and the arithmetic right shifts.
TABLE 4. SHIFT INSTRUCTIONS

| OP <br> CODE | SHIFT FUNCTION |  |  |
| :---: | :--- | :--- | :---: |
| ON | Arithmetic Right Single | $\overline{\text { SIO7 }} \cdot \overline{\text { SIOO }}$ <br> WIRED VALUE | $\overline{\text { QIO7 }} \cdot \overline{\text { QIOO }}$ <br> WIRED VALUE |
| 1 N | ALU-LSB Output | - |  |
| 2 N | Logical Right Single | MQ-LSB Output | ALU-LSB Output |
| 3 N | Logical Right Double to ALU-MSB | ALU-LSB Output |  |
| 4 N | Arithmetic Left Single | Input to ALU-MSB | ALU-LSB Output |
| 5 N | Arithmetic Left Double | Input to MLU-LSB | ALU-MSB Output |
| 6 N | Circular Left Single | ALU-MSB Output | MQ-MSB Output |
| 7 N | Circular Left Double | ALU-MSB Output | MQ-MSB Output |
| 8 N | Circular Right Single | ALU-LSB Output | - |
| 9 N | Circular Right Double | MQ-LSB Output | ALU-LSB Output |
| AN | Arithmetic Right (MQ only) | MQ-LSB Output | MQ-LSB Output |
| BN | Logical Right (MQ only) | MQ-LSB Output | Input to MQ-MSB |
| CN | Logical Left (MQ only) | Input to MQ-LSB | MQ-MSB Output |
| DN | Circular Left (MQ only) | MQ-MSB Output | MQ-MSB Output |

${ }^{\dagger} O p$ Code $N \neq 0,8$, or $F$; these select special instruction Groups 4,3 , and 5 respectively.
${ }^{\ddagger}$ Shift $1 / O$ pins are active low. Therefore, inputs and outputs must be inverted if true logical values are required.

Status is set with the following results:

## Arithmetic

$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Signed arithmetic overflow ${ }^{\dagger}$
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal one
Z $\rightarrow$ Result equal zero
Logic
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Zero
$\mathrm{C}_{\mathrm{n}+8} \rightarrow$ Zero
$\mathrm{Z} \rightarrow$ Result equal zero
$\dagger$ For the SLA and SLAD instructions, OVR is set if signed arithmetic overflow or if the ALU result MSB XOR MSB-1 equals one.


ARITHMETIC RIGHT DOUBLE


FIGURE 2. SHIFT INSTRUCTIONS

FILLS ZERO IF NOT FORCED


LOGICAL RIGHT DOUBLE
FILLS ZERO IF NOT FORCED


FIGURE 2. SHIFT INSTRUCTIONS (Continued)


ARITHMETIC LEFT DOUBLE


FIGURE 2. SHIFT INSTRUCTIONS (Continued)


CIRCULAR LEFT DOUBLE


FIGURE 2. SHIFT INSTRUCTIONS (Continued)


CIRCULAR RIGHT DOUBLE


FIGURE 2. SHIFT INSTRUCTIONS (Continued)

SERIAL DATA OUT


LOGICAL RIGHT (MO ONLY)


FILLS ZERO IF NOT FORCED
FIGURE 2. SHIFT INSTRUCTIONS (Continued)


CIRCULAR LEFT (MO ONLY)


FIGURE 2. SHIFT INSTRUCTIONS (Concluded)

## group 3 instructions

Hex code 8 of Group 1 instructions is used to access Group 3 instructions. Group 3 instructions are summarized in Table 5.

TABLE 5. GROUP 3 INSTRUCTIONS

| INSTRUCTION BITS (17-I0) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 08 | SET1 | Set Bit |
| 18 | SETO | Reset Bit |
| 28 | TB1 | Test Bit (One) |
| 38 | TBO | Test Bit (Zero) |
| 48 | ABS | Absolute Value |
| 58 | SMTC | Sign Magnitude/Two's Complement |
| 68 | ADDI | Add Immediate |
| 78 | SUBI | Subtract Immediate |
| 88 |  | Reserved |
| 98 |  | Reserved |
| A8 |  | Reserved |
| B8 |  | Reserved |
| C8 |  | Reserved |
| D8 |  | Reserved |
| E8 |  | Reserved |
| F8 |  |  |

## set bit instruction (set1): $17-10=0816$

This instruction (Figure 3) is used to force selected bits to one (any combination of zero to eight bits). The desired bits are specified by an 8-bit mask (C3-CO)::(A3-AO) ${ }^{\dagger}$ consisting of register file address ports that are not required to support this instruction. All bits that are in the same bit positions as ones in the mask are forced to a logical one. The B3-B0 address field is used for both source and destination of this instruction. The $S$ bus is the source word for this instruction. $\overline{S I O O}$ must be forced low for proper operation. If $\overline{\mathrm{SIOO}}$ is high, data on the S bus is passed unaltered. The status set by the set bit instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { None (force to zero) } \\
\text { OVR } & \rightarrow & \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

$\dagger$ The symbol '::' is concaténation operator

## reset bit instruction (set0): $17-10=1816$

This instruction (Figure 3) is used to force selected bits to zero. The desired bits are specified by an 8-bit mask (C3-C0)::(A3-A0) consisting of register file address ports that are not required to support this instruction. All bits in the selected byte(s) that are in the same bit positions as ones in the mask are reset. The B3-BO address field is used for both source and destination of this instruction. The $S$ bus is the source word for this instruction. $\overline{S I O O}$ must be forced low for proper operation. If $\overline{S I O O}$ is high, data on the $S$ bus is passed unaltered. The status set by the reset bit instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { None (force to zero) } \\
\text { OVR } & \rightarrow \\
\text { None (force to zero) } \\
\mathrm{C}_{n}+8 & \rightarrow \\
\mathrm{Z} & \rightarrow \\
\text { None (force to zero) } \\
\text { Result equal zero }
\end{array}
$$



NOTES: 1. Force $\overline{\mathrm{SIOO}}$ low for proper operation.
2. Bit mask (C3-C0)::(A3-A0) will set desired bits to one.

FIGURE 3. SET BIT (OR RESET BIT)
test bit (one) instruction (TB1): 17-10 = 2816
This instruction (Figure 4) is used to test selected bits for ones. Bits to be tested are specified by an 8-bit mask (C3-C0)::(A3-A0) consisting of register file address ports that are not required to support this instruction. Write Enable ( $\overline{\mathrm{WE}}$ ) is internally disabled during this instruction. The test will pass if the selected byte has ones at all bit locations specified by the ones of the mask (Figure 5). The $S$ bus is the source word for this instruction. $\overline{\mathrm{SIOO}}$ must be forced low for proper operation. The status set by the test bit (one) instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { None (force to zero) } \\
\text { OVR } & \rightarrow & \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Pass }
\end{array}
$$



NOTES: 1. Force $\overline{S I O O}$ low for proper operation.
2. Bit mask (C3-CO)::(A3-AO) will define bits for testing.
3. Pass/fail is indicated on $Z$ output.

FIGURE 4. TEST BIT
test bit (zero) instruction (TBO): $17-10=3816$
This instruction (Figure 4) is used to test selected bits for ones. Bits to be tested are specified by an 8-bit mask (C3-C0)::(A3-A0) consisting of register file address ports that are not required to support this instruction. Write Enable ( $\overline{\mathrm{WE}}$ ) is internally disabled during this instruction. The test will pass if the selected byte has zeros at all bit locations specified by the ones of the mask (Figure 6). The S bus is the source word for this instruction. $\overline{\mathrm{SIOO}}$ must be forced low for proper operation. The status set by the test bit (zero) instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \text { None (force to zero) } \\
\text { OVR } & \rightarrow \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \\
\mathrm{Z} & \rightarrow \text { Pase (force to zero) }
\end{array}
$$



FIGURE 5. TEST BIT ONE EXAMPLES


FIGURE 6. TEST BIT ZERO EXAMPLES
absolute value instruction (ABS): $17-10=4816$
This instruction is used to convert two's complement numbers to their positive value. The operand placed on the $S$ bus is the source for this instruction. The 'AS887 will test the sign of the S bus and force the SSF pin to the proper value. The status set by the absolute value instruction is as follows:
$\mathrm{N} \rightarrow$ Input MSB equal one
OVR $\rightarrow$ Input equal 80 (hex)
$\mathrm{C}_{\mathrm{n}+8} \rightarrow \mathrm{~S}=0$
Z $\rightarrow$ Result equal zero
sign magnitude/two's complement instruction (SMTC): $17-10=5816$
This instruction allows conversion from two's complement representation to sign magnitude representation, or vice-versa, in one clock cycle. The operand placed on the S bus is the source for this instruction.

When a negative zero ( 80 hex ) is converted, the result is 00 with an overflow. If the input is in two's complement notation, the overflow indicates an illegal conversion. The status set by the sign magnitude/two's complement instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Input equal 80 (hex)
$\mathrm{C}_{\mathrm{n}+8} \rightarrow$ Input equal 00 (hex)
Z $\quad \rightarrow$ Result equal zero
add immediate instruction (ADDI): $17-10=6816$
This instruction is used to add a specified constant value to the operand placed on the S bus. The constant will be between the values of 0 and 15 . The constant value is specified by the unused register file address (A port) not required to support this instruction. Forcing the carry input will add an additional one to the result. The status set by the add immediate instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Arithmetic signed overflow
$C_{n}+8 \rightarrow$ Carry out equal one
$\mathrm{Z} \rightarrow$ Result equal zero
subtract immediate instruction (SUBI): 17-10 $=7816$
This instruction is used to subtract a specified constant value from the operand placed on the $S$ bus. The constant value is specified by the unused register file address (A port) that is not required to support this instruction. The constant applied is the least significant four bits of a two's complement number. The device sign extends the constant over the entire word length. The status set by the subtract immediate instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Arithmetic signed overflow
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal one
$\mathrm{Z} \rightarrow$ Result equal zero

## group 4 instructions

Hex code 0 of Group 1 instructions is used to access Group 4 instructions. Group 4 instructions are summarized in Table 6.

TABLE 6. GROUP 4 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 00 |  | Reserved |
| 10 | SEL | Select S/R |
| 20 | SNORM | Single Length Normalize |
| 30 | DNORM | Double Length Normalize |
| 40 | DIVRF | Divide Remainder Fix |
| 50 | SDIVQF | Signed Divide Quotient Fix |
| 60. | SMULI | Signed Multiply Iterate |
| 70 | SMULT | Signed Multiply Terminate |
| 80 | SDIVIN | Signed Divide Initialize |
| 90 | SDIVIS | Signed Divide Start |
| AO | SDIVI | Signed Divide Iterate |
| BO | UDIVIS | Unsigned Divide Start |
| CO | UDIVI | Unsigned Divide Iterate |
| DO | UMULI | Unsigned Multiply Iterate |
| EO | SDIVIT | Signed Divide Terminate |
| FO | UDIVIT | Unsigned Divide Terminate |

select $S / R$ instruction (SEL): $17-10=1016$
This instruction is used to pass either the $S$ bus or the $R$ bus to the output depending on the state of the SSF input pin. Normally, the preceding instruction would test the two operands and the resulting status information would be used to force the SSF input pin. SSF $=0$ will output the $R$ bus and SSF $=1$ will output the $S$ bus. The status set by the select $S / R$ instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Result MSB equal one } \\
\text { OVR } & \rightarrow \\
\text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \\
\text { None (force to zero) } \\
\mathrm{Z} & \rightarrow \\
\text { Result equal zero }
\end{array}
$$

single-length normalize instruction (SNORM): 17-IO $=\mathbf{2 0 1 6}$
This instruction will cause the contents of the MQ register to shift toward the most significant bit. Zeros are shifted in via the $\overline{\mathrm{Q} I O O}$ input. The number of shifts performed can be counted and stored in one of the register files by forcing a high at the $C_{n}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.

The chip contains conditional logic that inhibits the shift function (and also inhibits the register file increment) if the number within the MQ register is already normalized at the beginning of the instruction (Figure 7). The status set by the single-length normalize instruction is as follows:

```
N }->\mathrm{ MSB of result
OVR }->\mathrm{ MSB XOR 2nd MSB
Cn+8 }->\mathrm{ Carry out equal one,
Z }->\mathrm{ Result equal zero
```



DOUBLE-LENGTH NORMALIZE

figure 7. SINGLE- AND dOUble-LeNGTh NORMALIZE

## SN54AS887, SN74AS887 8.BIT PROCESSORS

double-length normalize instruction (DNORM): 17-10 $=\mathbf{3 0 1 6}$
This instruction will cause the contents of a double-length word (register file contains the most significant half and the MO register contains the least significant half) to shift toward the most significant bit. Zeros are shifted in via the $\overline{\mathrm{Q} O \mathrm{O}}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.

The chip contains conditional logic which inhibits the shift function if the number is already normalized at the beginning of the instruction (Figure 7). The most significant half of the operand must be placed on the $S$ bus. The status set by the double-length normalize instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad \mathrm{MSB}$ of result
OVR $\rightarrow$ MSB XOR 2nd MSB
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ None (force to zero)
Z $\rightarrow$ Result equal zero

## multiply operations

Thie ALU performs three unique types of 8 by 8 multiplies each of which produces a 16 -bit result (Figure 8 ). All three types of multiplication proceed via the following recursion:

$$
\mathrm{P}(\mathrm{~J}+1)=2[\mathrm{P}(\mathrm{~J})+\text { Multiplicand } \times \mathrm{M}(8-\mathrm{J})]
$$

where
$\mathrm{P}(\mathrm{J}) \quad=$ partial product at iteration number J
$P(J+1)=$ partial product at iteration number $J+1$
$J$ varies from 0 to 8
M (8-J) $=$ mode bit (unique to multiply type)
2 denotes some type of shift (unique to multiply)
Notice that by proper choice of mode terms and shifting operations, signed, unsigned, and mixed multiplies (signed times unsigned) may be performed.

All multiplies assume that the multiplier is stored in MO before the operation begins (in the case of mixed multiply, the unsigned number must be the multiplier).

The processor has the following multiply instructions:

1. SIGNED MULTIPLY ITERATE (SMULI): $17-10=6016$
2. SIGNED MULTIPLY TERMINATE (SMULT): $17-10=7016$
3. UNSIGNED MULTIPLY ITERATE (UMULI): $17-10=\mathrm{DO} 16$

The signed multiply iterate (SMULI) instruction performs a signed times signed iteration. This instruction interprets $\mathrm{M}(8-\mathrm{J})$ as the $8-\mathrm{J}$ bit of the multiplier. The shift is a double-precision right shift one bit. This instruction is repeated 7 times for a $8 \times 8$ signed multiply. This instruction will be used 7 consecutive times for a mixed multiplication.
The signed multiply terminate (SMULT) instruction provides correct (negative) weighting of the sign bit of a negative multiplier in signed multiplication. The instruction is identical to signed multiply iterate (SMULI) except that $M(8-J)$ is interpreted as -1 if the sign bit of the multiplier is 1 , and 0 if the sign bit of the multiplier is 0 .


UMULI


FIGURE 8. MULTIPLICATION OPERATIONS

## signed multiplication

Signed multiplication performs a ten clock cycle, two's complement multiply. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MO with multiplier
SMULI (repeat 7 times) $\quad \mathrm{S}$ port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Iteration Result
SMULT
Sport $=$. Accumulator
R port $=$ Multiplicand
F port $=\operatorname{Product}(\mathrm{MSH})$
At completion, the accumulator will contain the 8 most significant bits and MO will contain the 8 least significant bits of the product.

The status for the signed multiply iterate should not be used for any testing (overflow is not set by SMULI). The following status is set for the signed multiply terminate instruction:
$\mathrm{N} \rightarrow$ Result MSB equal one
OVR $\rightarrow$ Forced to zero
$C_{n+8} \rightarrow$ Carry out equal to one
$z \rightarrow$ Double precision result is zero

## unsigned multiplication

Unsigned multiplication produces an unsigned times unsigned product in ten clocks. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MO with multiplier
UMULI (8 times) S port $=$ Accumulator
R.port $=$ Multiplicand

F port $=$ Iteration result (product MSH on final result)
Upon completion, the accumulator will contain the 8 most significant bits and MO will contain the 8 least significant bits of the product.

The status set by the unsigned multiply iteration is meaningless except on the final execution of the instruction. The status set by the unsigned multiply iteration instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Result MSB equal one } \\
\mathrm{OVR} & \rightarrow \\
\text { Forced to zero } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \\
\text { Carry out equal to one } \\
\mathrm{Z} & \rightarrow
\end{array} \text { Double-precision result is zero }
$$

## mixed multiplication

Mixed multiplication multiplies a signed multiplicand times an unsigned multiplier to produce a signed result in ten clocks. The steps are as follows:

Zero register used for accumulator
Load MO with unsigned multipler
SMULI (8 times) S port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Iteration result
Upon completion, the accumulator will contain the 8 most significant bits and MO will contain the 8 least significant bits of the product.
The following status is set by the last SMULI instruction:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Forced to zero
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal to one
Z $\rightarrow$ Double-precision result is zero
divide operations
The divide uses a nonrestoring technique to perform both signed and unsigned division of a 16 bit integer dividend and an 8 bit integer divisor (Figure 9). It produces an 8 integer quotient and remainder.

The remainder and quotient will be such that the following equation is satisfied:

$$
\text { (Quotient) } \times(\text { Divisor })+\text { Remainder }=\text { Dividend }
$$

The processor has the following divide instructions:

1. UNSIGNED DIVIDE START (UDIVIS): $17-10=\mathrm{BO}_{16}$
2. UNSIGNED DIVIDE ITERATE (UDIVI): $17-10=\mathrm{CO}_{16}$
3. UNSIGNED DIVIDE TERMINATE (UDIVIT): $17-10=\mathrm{FO}_{16}$
4. SIGNED DIVIDE INITIALIZE (SDIVIN): $17-10=8016$
5. SIGNED DIVIDE OVERFLOW TEST (SDIVO): $17-10=$ AF $_{16}$
6. SIGNED DIVIDE START (SDIVIS): $17-10=9016$
7. SIGNED DIVIDE ITERATE (SDIVI): $17-10=A 0_{16}$
8. SIGNED DIVIDE TERMINATE (SDIVIT): $17-10=E 0_{16}$
9. DIVIDE REMAINDER FIX (DIVRF): $17-10=40_{16}$
10. SIGNED DIVIDE QUOTIENT FIX (SDIVQF): $17-10=5016$


FIGURE 9. DIVIDE OPERATIONS

uDIVT


FIGURE 9. DIVIDE OPERATIONS (Continued)

The unsigned divide iterate start (UDIVIS) instruction begins the iterate procedure while testing for overflow. Overflow is reported when the first subtraction of the divisor from the MSH of the dividend produces carry out. The test detects quotient overflow and divide by zero.

The unsigned divide iterate terminate (UDIVIT) instruction completes the iterate procedure generating the last quotient bit.

The signed divide initialize (SDIVIN) instruction prepares for iteration by shifting the dividend and storing the sign of the dividend for use in the following instructions and overflow tests.
The signed divide overflow test (SDIVO) checks for overflow possibilities. This instruction may be deleted from the divide operation if the OVR pin is ignored. If it is removed some overflow conditions will go undetected. $\overline{W E}$ must be high (writing inhibited) when this instruction is used.

The signed divide iterate start (SDIVIS) instruction calculates the difference between the divisor and MSH of the dividend. Partial detection of overflow is also done during this instruction. Operations with like signs (positive quotient) and division by zero will overflow during this instruction (including zero divisor). Operations with unlike signs are tested for overflow during the signed divide quotient fix instruction (SDIVQF). Partial overflow results are saved and will be used during SDIVQF when overflow is reported.
The signed divide iterate (SDIVI) instruction forms the quotient and remainder through iterative subtract/addshift operations of the divisor and dividend. One quotient bit is generated on each clock.

The signed divide iterate terminate (SDIVIT) instruction completes the iterate procedure, generating the last quotient bit. It also tests for a remainder equal to zero, which determines the action to be taken in the following correction (fix) instructions.
The divide remainder fix (DIVRF) instruction corrects the remainder. If a zero remainder was detected by the previous instructions, the remainder is forced to zero. For nonzero remainder cases where the remainder and dividend have the same sign, the remainder is correct. When the remainder and dividend have unlike signs, a correction add/subtract of the divisor to the remainder is performed.

The signed divide quotient fix (SDIVQF) instruction corrects the quotient if necessary. This correction requires adding one to the incorrect quotient. An incorrect quotient results if the signs of the divisor and dividend differ and the remainder is nonzero. An incorrect quotient also results if the sign of the divisor is negative and the remainder is zero.
Overflow detection is completed during this instruction. Overflow may be generated for differing signs of the dividend and divisor. The partial overflow test result performed during SDIVIS is ORed with this test result to produce a true overflow indication.

## signed divide usage

The instructions necessary to perform an algebraically correct division of signed numbers are as follows:
Load MQ with the least significant half of the dividend

| SDIVIN | $\begin{aligned} & \text { S port }=\text { MSH of dividend } \\ & \text { R port }=\text { Divisor } \\ & \text { F port }=\text { Intermediate result } \end{aligned}$ |
| :---: | :---: |
| SDIVO | $\begin{aligned} & \text { S port }=\text { Result of SDIVIN } \\ & \mathrm{R} \mathrm{port}=\text { Divisor } \\ & \text { F port }=\text { Test result } \\ & (\overline{W E} \text { must be high }) \end{aligned}$ |
| SDIVIS | $\begin{aligned} & \text { S port }=\text { Result of SDIVIN } \\ & \text { R port }=\text { Divisor } \\ & \text { F port }=\text { Intermediate result } \end{aligned}$ |
| SDIVI (8N-2 times) | ```S port = Result of SDIVIS (or SDIVI) R port = Divisor F port = Intermediate result``` |
| SDIVIT | ```S port = Result of last SDIVI R port = Divisor F port = Intermediate result``` |
| DIVRF | ```S port = Result of SDIVIT R port = Divisor F port = Remainder``` |
| SDIVAF | $\begin{aligned} & \text { S port }=\text { MQ register } \\ & \text { R port }=\text { Divisor } \\ & \text { F port }=\text { Quotient } \end{aligned}$ |

The status of all signed divide instructions except SDIVIN, DIVRF, and SDIVQF is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Forced to zero } \\
\text { OVR } & \rightarrow \\
\text { Forced to zero } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \\
\mathrm{Carry} \text { out equal to one } \\
\mathrm{Z} & \rightarrow \\
\text { Intermediate result is zero }
\end{array}
$$

The status of the SDIVIN instruction is as follows:

```
N }\quad->\quad\mathrm{ Forced to zero
OVR }->\mathrm{ Forced to zero
Cn+8 }->\mathrm{ Forced to zero
Z }->\mathrm{ Divisor is zero
```

The status of the DIVRF instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| Forced to zero |  |
| OVR | $\rightarrow$ Forced to zero |
| $C_{n}+8$ | $\rightarrow$ |
| $Z$ | $\rightarrow$ |
| $Z$ | Remairy out equal to one |
|  |  |

## SN54AS887, SN74AS887 <br> 8-BIT PROCESSORS

The status of the SDIVQF instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { Sign of quotient } \\
\text { OVR } & \rightarrow & \text { Divide overflow } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { Carry out equal to one } \\
\mathrm{Z} & \rightarrow & \text { Quotient is zero }
\end{array}
$$

The quotient is stored in the MQ register and the remainder is stored in the register file location that originally held the most significant word of the dividend. If fractions are divided, the quotient must be shifted right one bit and the remainder right three bits to obtain the correct fractional representations.

The signed division algorithm is summarized in Table 7.
TABLE 7. SIGNED DIVISION ALGORITHM

| $\begin{gathered} \mathrm{OP} \\ \mathrm{CODE} \end{gathered}$ | MNEMONIC | CLOCK CYCLES | InPUT <br> S PORT | INPUT <br> R PORT | OUTPUT <br> F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMO | 1 | Dividend (LSH) | - | Dividend (LSH) |
| 80 | SDIVIN | 1 | Dividend (MSH) | Divisor | Remainder |
| AF | SDIVO | 1 | Remainder | Divisor | Test Result |
| 90 | SDIVIS | 1 | Remainder | Divisor | Remainder |
| AO | SDIVI | 7 | Remainder | Divisor | Remainder |
| EO | SDIVIT | 1 | Remainder | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |
| 50 | SDIVQF | 1 | MO Register | Divisor | Quotient |

unsigned divide usage
The instructions necessary to perform an algebraically correct division of unsigned numbers are as follows:
Load MQ with the least significant half of the dividend
UDIVIS $\quad$ S port $=$ MSH of dividend
R port $=$ Divisor
F port $=$ Intermediate result
UDIVI (8-1 times) $\quad$ S port $=$ Result of UDIVIS (OR UDIVI)
R port $=$ Divisor
F port $=$ Intermediate result
UDIVIT $\quad$ S port $=$ Result of last UDIVI
R port $=$ Divisor
F port $=$ Remainder (unfixed)
DIVRF $\quad$ S port $=$ Result of UDIVIT
R port $=$ Divisor
F port $=$ Remainder
The status of all unsigned divide instructions except UDIVIS is as follows:

| N | $\rightarrow$ | Forced to zero |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Forced to zero |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal to one |
| Z | $\rightarrow$ | Intermediate result is zero |

The status of the UDIVIS instruction is as follows:
$\mathrm{N} \rightarrow \quad$ Forced to zero
OVR $\rightarrow$ Divide overflow
$C_{n+8} \rightarrow$ Carry out equal to one
Z $\rightarrow$ Intermediate result is zero
If fractions are divided, the remainder must be shifted right two bits to obtain the correct fractional representation. The quotient is correct as is. The quotient is stored in the MQ register at the completion of the divide.
The unsigned division algorithm is summarized in Table 8.
TABLE 8. UNSIGNED DIVISION ALGORITHM

| OP <br> CODE | MNEMONIC | CLOCK <br> CYCLES | INPUT <br> S PORT | INPUT <br> R PORT | OUTPUT <br> F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMQ | 1 | Dividend (LSH) | - | Dividend (LSH) |
| BO | UDIVIS | 1 | Dividend (MSH) | Divisor | Remainder |
| CO | UDIVI | 7 | Remainder | Divisor | Remainder |
| FO | UDIVIT | 1 | Remainder | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |

## group 5 instructions

Hex code $F$ of Group 1 instructions is used to access Group 5 instructions. Group 5 instructions are summarized in Table 9.

TABLE 9. GROUP 5 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| $5 F$ | CLR | Clear |
| $6 F$ | CLR | Clear |
| $7 F$ | BCDBIN | BCD to Binary |
| $8 F$ |  | Reserved |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No Operation |

## clear instructions (CLR)

There are 11 clear instructions listed in Table 9. The instructions force the ALU output to be zero and the BCD flip-flops to be cleared. The status set by the clear instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { None (force to zero) } \\
\text { OVR } & \rightarrow \\
\text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \\
\mathrm{None} \text { (force to zero) } \\
\mathrm{Z} & \rightarrow \text { Active (one) }
\end{array}
$$

no operation instruction (NOP): 17-10 = FF16
This instruction is identical to the clear instructions except that the BCD flip-flops retain their old value.
excess-3 correction instructions (EX3C): 9F16
This instruction corrects excess-3 additions (subtractions). For correct excess-3 arithmetic, this instruction must follow each add/subtract. The operand must be on the $S$ port.

NOTE: The previous arithmetic overflow should be ignored.
The status set by the EX3C instruction is as follows:

$$
\begin{array}{ll}
\text { N } & \rightarrow \\
\text { MSB of result } \\
\text { OVR } & \rightarrow
\end{array} \text { Signed overflow } 1 \text { (force to one) }
$$

radix conversions
Conversions between decimal and binary number representations are performed with the aid of two special instructions: BINEX3 and BCDBIN.

BCD to binary instructions (BCDBIN): 17-10 = 7F16
This instruction (Figure 10) allows the user to convert a 2-digit BCD number to an 8-bit binary number in 12 clocks. This function sums the $R$ bus, the $S$ bus, and the $C_{n}$ bit, performs an arithmetic left shift on the ALU result, and simultaneously circular shifts the MO left. The status set by the BCD to binary instruction is as follows:
$N \quad \rightarrow \quad$ MSB of result
OVR $\rightarrow$ Signed arithmetic overflow ${ }^{\dagger}$
$C_{n}+8 \rightarrow$ Carry out equal one
$\mathrm{Z} \rightarrow$ Result equal zero
${ }^{\dagger}$ Overflow may be the result of an ALU operation or the arithmetic left shift operation.

The following code illustrates the BCD to binary conversion technique.
Let ACC be an accumulator register
Let NUM be the register which contains the BCD number
Let MSK be a mask register

| LOADMO NUM | ; LOAD MQ WITH BCD NUMBER |
| :---: | :---: |
| SUB ACC, ACC, SLCMO | ; CLEAR ACC AND ALIGN MQ |
| SUB, MSK, MSK, SLCMQ | ; CLEAR MSK AND ALIGN MQ |
| SLCMQ | ; ALIGN |
| SLCMQ | ; ALIGN |
| ADDI ACC, MSK, 1510 | ; MSK = 1510 |
| AND MQ, MSK, R1, SLCMO | ; EXTRACT ONE DIGIT <br> ; ALIGN MO |
| ADD, ACC, R1, R1, SLCMQ | $\begin{aligned} & \text {; ACC + DIGIT } \\ & \text {; IS STORED IN R1 } \\ & \text {; ALIGN MQ } \end{aligned}$ |
| BCDBIN, R1, R1, ACC | $; 4 \times($ ACC + DIGIT $)$ <br> ; IS STORED IN ACC ; ALIGN MQ |
| BCDBIN, ACC, R1, ACC | $\begin{aligned} & ; 10 \times(\text { ACC }+ \text { DIGIT }) \\ & \text {; IS STORED IN ACC } \\ & \text {; ALIGN MQ } \end{aligned}$ |
| AND MQ, MSK, R1 | ; FETCH LAST DIGIT |
| $\mathrm{ACC}+\mathrm{R1} \rightarrow \mathrm{ACC}$ | ; ADD IN LAST DIGIT |

The previous code generates a binary number by executing the standard conversion formula for a 2-digit BCD number.

$$
A B=A \times 10+B
$$

Notice that the conversion begins with the most significant BCD digit and that the addition is performed in radix 2.

## binary to excess-3 instructions (BINEX3): $17-10=$ DF16

This instruction (Figure 11) allows the user to convert an 8-bit binary number to 2-digit excess-3 number representation in 19 clocks. The data on the $R$ and $S$ ports are summed with the MSB of the MQ register. The MO register is simultaneously shifted left circularly. The status set by the binary to excess- 3 instruction is as follows:

| N | $\rightarrow$ | MSB of result |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Signed arithmetic overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |



FIGURE 10. BCD TO BINARY
BINEX3


FIGURE 11. BINARY TO EXCESS-3

The following illustrates the binary to excess- 3 conversion technique.
Let NUM be a register containing an unsigned binary number
Let ACC be an accumulator

| M1: | LOADMQ NUM | ; LOAD MO WITH BINARY |
| :--- | :--- | :--- |
|  |  | ; NUMBER |
| M2: | CLEAR ACC | ; CLEAR ACC |
| M3: | SET1 ACC H/33/ | ACC $\rightarrow$ HEX/3333 . . |
| L1: | BINEX3 ACC, ACC, ACC | DOUBLE ACC AND ADD IN |
|  |  | MSB OF MO |
| L2: |  | FALIGN MO |
|  | EX3C ACC, ACC | EXCESS 3 CORRECT |
|  |  | REPEAT L1 AND L2 |
|  |  | 7 TIMES |

The previous code generates an excess-3 number by executing the standard conversion formula for a binary number.

$$
a_{n} 2^{n}+a_{n-1} 2^{n-1}+a_{n-2} 2^{n-2}+\ldots a_{0} 2^{0}=\left[\left(2 a_{n}+a_{n-1}\right) 2+a_{n-2}\right] 2+\ldots a_{0}
$$

Notice that the conversion begins with the most significant binary bit and that the addition is performed in radix-10 (excess-3).

## decimal arithmetic

Decimal numbers are represented in excess 3 code. Excess -3 code numbers may be generated by adding three to each digit of a Binary Coded Decimal (BCD) number. The hardware necessary to implement excess-3 arithmetic is only slightly different from binary arithmetic. Carries from one digit to another during addition in BCD occur when the sum of the two digits plus the carry-in is greater than or equal to ten. If both numbers are excess-3, the sum will be excess-6, which will produce the proper carries. Therefore, every addition or subtraction operation may use the binary adder. To convert the result from excess- 6 to excess- 3 , one must consider two cases resulting from a BCD digit add: (1) where a carry-out is produced, and (2) where a carry-out is not produced. If a carry-out is not produced, three must be subtracted from the resulting digit. If a carry is produced, the digit is correct as a BCD number. For example, if BCD 5 is added to BCD 6, the excess- 3 result would be $8+9=1$ (with a carry). A carry rolls the number through the illegal BCD representations into a correct BCD representation. Binary 3 must be added to digit positions that produce a carry-out to correct the result to an excess-3 representation. Every addition and subtraction instruction stores the carry generated from each 4-bit digit location for use by the excess- 3 correction function. The correction instruction must be executed in the clock cycle immediately after the addition or subtraction operation.

## absolute maximum rating over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC1 ..... 7 V
Supply voltage, VCC2 ..... 3 V
Input voltage ..... 7 V
High-level voltage applied to 3-state outputs ..... 5.5 V
Operating case temperature range: SN54AS887 ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Operating free-air temperature range: SN74AS887, SN74AS887-1 ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## recommended operating conditions

|  |  |  |  | 54AS |  |  | $\begin{aligned} & \text { ل74AS } \\ & 74 \mathrm{ASB} \end{aligned}$ | $\begin{aligned} & 87 \\ & 37-1 \\ & \hline \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC} 1}$ | I/O supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{CC} 2}$ | STL internal logic supply |  | 1.9 | 2 | 2.1 | 1.9 | 2 | 2.1 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | High-level output current |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ |  |  |  |  | -1 |  |  | -2.6 | mA |
| ${ }^{\text {IOL }}$ | Low-level output current | All output except N and ZERO. |  |  | 8 |  |  | 8 | mA |
|  |  | N |  |  | 16 |  |  | 16 |  |
|  |  | 2ERO |  |  | 48 |  |  | 48 |  |
| ${ }^{T} \mathrm{C}$ | Operating case temperature |  | -55 |  | 125 |  |  |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  |  |  |  | 0 |  | 70 |  |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS887 |  | SN74AS887 <br> SN74AS887-1 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ MAX | MIN TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  | $\mathrm{V}_{\text {CC1 }}=4.5 \mathrm{~V}, \quad 11=-18 \mathrm{~mA}$ |  | -1.2 |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs except ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I} \mathrm{OH}=-0.4 \mathrm{~mA}$ | Vcc-2 |  | $\mathrm{V}_{\mathrm{CC}-2}$ |  | v |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, 1 \mathrm{l} \mathrm{IOH}=-1 \mathrm{~mA}$ | 2.4 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  |  | 2.4 |  |  |
| IOH | ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  | 0.1 |  | 0.1 | mA |
| VOL | All outputs except $N$ and ZERO N ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  | 0.5 |  | 0.5 | V |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{IOL}=16 \mathrm{~mA}$ |  | 0.5 |  | 0.5 |  |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  | 0.5 |  | 0.5 |  |
| 1 | $1 / 0$ <br> All others | $\mathrm{V}_{\mathrm{CCI}}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=5.5 \mathrm{~V}$ |  | 0.1 |  | 0.1 | mA |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=7 \mathrm{~V}$ |  | 0.1 |  | 0.1 |  |
| ${ }_{11 \mathrm{H}^{\ddagger}}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  | 20 |  | 20 | $\mu \mathrm{A}$ |
| 112 ${ }^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=0.5 \mathrm{~V}$ |  | -0.4 |  | -0.4 | mA |
| $10^{\text {§ }}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | $-30$ | -112 | mA |
| ${ }^{\text {ICC1 }}$ |  | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$ |  | 150 |  | 130 | mA |
| ICC2 |  | $\mathrm{V}_{\mathrm{CC} 2}=2.1 \mathrm{~V}$ |  | 410 |  | 390 | mA |

[^26]SN54AS887 maximum switching characteristics, $\mathrm{V} C \mathrm{C}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T} \mathrm{C}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $\mathrm{C}_{n+8}$ | $\overline{\mathbf{G}}, \overline{\mathbf{P}}$ | $z^{\dagger}$ | N | OVR | DA | DB | $\overline{\mathrm{O}} \mathrm{O}$ | SIO |  |
| ${ }^{t} \mathrm{pd}$ | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 62 | 42 | 48 | 69 | 62 | 60 | 18 | 18 | 65 | 66 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DB0 } \end{aligned}$ | 47 | 28 | 28 | 58 | 50 | 42 | - | - | 50 | 50 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 25 | 14 | - | 32 | 24 | 18 | - | - | 32 | 32 |  |
|  | EA | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | $\stackrel{\text { EB }}{ }$ | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | 17-10 | 58 | 32 | 32 | 62 | 52 | 41 | - | - | 58 | 58 |  |
|  | $\overline{\text { OEB }}$ | - | - | - | - | - | - | - | 14 | - | - |  |
|  | OEY | 14 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{QIO}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | - | - | - | - | - | -. |  |
|  | $\overline{\mathrm{SIO}}(\mathrm{n})$ <br> Shift | 15 | - | -- | 24 | 22 | - | - | - | - | - |  |
|  | CK | 68 | 60 | 56 | 62 | 50 | 68 | 38 | 38 | 70 | 70 |  |
|  | $\overline{\text { OEA }}$ | - | - | - | - | - | - | 14 | - | - | - |  |

${ }^{\dagger}$ Load resistor $\mathrm{R1}=100 \Omega$.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

SN74AS887 maximum switching characteristics, $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $Y$ | $\mathrm{C}_{\mathrm{n}+8}$ | $\overline{\mathrm{G}}, \overline{\mathrm{P}}$ | $z^{\dagger}$ | N | OVR | DA | DB | $\overline{010}$ | $\overline{\text { SIO }}$ |  |
|  | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 54 | 36 | 42 | 60 | 52 | 50 | 18 | 18 | 58 | 58 | ns |
|  | $\begin{aligned} & \hline \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 44 | 26 | 26 | 52 | 46 | 38 | - | - | 44 | 44 |  |
|  | $\mathrm{C}_{n}$ | 25 | 8 | - | 32 | 24 | 18 | - | - | 31 | 31 |  |
|  | $\overline{E A}$ | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | $\overline{E B}$ | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | 17-10 | 55 | 30 | 30 | 60 | 49 | 39 | - | - | 54 | 54 |  |
| ${ }^{\text {tpd }}$ | $\overline{O E B}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\begin{aligned} & \hline \overline{\mathrm{OlO}}(n) \\ & \text { Shift } \\ & \hline \end{aligned}$ | 15 | - | - | 24 | - | - | - | - | - | - |  |
|  | $\begin{aligned} & \hline \text { SIO }(n) \\ & \text { Shift } \end{aligned}$ | 15 | - | - | 24 | 19 | - | - | - | - | - |  |
|  | CK | 58 | 55 | 52 | 61 | 52 | 62 | 35 | 35 | 60 | 60 |  |
|  | $\overline{\text { OEA }}$ | - | - | - | - | - | - | 12 | - | - | - |  |

${ }^{\dagger}$ Load resistor R1 $=100 \Omega$.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

SN74AS887-1 maximum switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $\mathrm{C}_{\mathrm{n}+8}$ | $\overline{\mathbf{G}}, \overline{\mathbf{P}}$ | $\mathbf{z}^{\dagger}$ | N | OVR | DA | DB | $\overline{\mathrm{O}} \mathrm{O}$ | $\overline{\text { SIO }}$ |  |
| ${ }^{t} \mathrm{pd}$ | $\begin{aligned} & \hline \text { A3-AO } \\ & \text { B3-BO } \end{aligned}$ | 44 | 30 | 36 | 50 | 44 | 44 | 17 | 17 | 48 | 48 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 36 | 24 | 24 | 46 | 41 | 32 | - | - | 40 | 40 |  |
|  | $\mathrm{C}_{n}$ | 22 | 8 | - | 27 | 21 | 16 | - | - | 25 | 25 |  |
|  | $\overline{E A}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | $\overline{\text { EB }}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | 17-10 | 46 | 27. | 27 | 50 | 42 | 35 | - | - | 45 | 45 |  |
|  | $\overline{\mathrm{OEB}}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | OEY | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\begin{aligned} & \hline \overline{\mathrm{OO}}(\mathrm{n}) \\ & \text { Shift } \\ & \hline \end{aligned}$ | 14 | - | - | 20 | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{S} O}(\mathrm{O})$ <br> Shift | 14 | - | - | 20 | 18 | - | - | - | - | - |  |
|  | CK | 50 | 46 | 46 | 50 | 50 | 50 | 30 | 30 | 50 | 50 |  |
|  | $\overline{O E A}$ | - | - | - | - | - | - | 12 | $-$ | - | - |  |

$\dagger$ Load resistor R1 $=100 \Omega$.
register file write setup and hold times

| PARAMETER |  | SN54AS887 |  | SN74AS887 |  | SN74AS887-1 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{su}}$ | C3-C0 | 8 |  | 7 |  | 6 |  | ns |
|  | DB§ | 14 |  | 12 |  | 11 |  |  |
|  | 17-14 | 16 |  | 14 |  | 13 |  |  |
|  | 13.10 | 24 |  | 22 |  | 21 |  |  |
|  | $\overline{\text { OEY }}$ | 4 |  | 3 |  | 3 |  |  |
|  | Y7-Y0 | 2 |  | 2 |  | 2 |  |  |
|  | WE | 8 |  | 6 |  | 6 |  |  |
|  | $\overline{\mathrm{O} 10}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 6 |  | 5 |  | 5 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |
| th | C3-C0 | 0 |  | 0 |  | 0 |  | ns |
|  | DB§ | 0 |  | 0 |  | 0 |  |  |
|  | 17-14 | 0 |  | 0 |  | 0 |  |  |
|  | $13-10$ | 0 |  | 0 |  | 0 |  |  |
|  | $\overline{\mathrm{OEY}}$ | 6 |  | 5 |  | 5 |  |  |
|  | Y7.Y0 | 10 |  | 10 |  | 10 |  |  |
|  | WE | 3 |  | 2 |  | 2 |  |  |
|  | $\overline{\mathrm{O} 10}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 0 |  | 0 |  | 0 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |

[^27]special instruction switching characteristics
The SSF pin is used internally during certain instructions. The following tables list the instructions which force the SSF pin during their execution. The propagation delay from various inputs is also shown. The parameter which limits normal system performance is indicated by a dagger.

| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP <br> TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $C_{n}$ | I $(\mathrm{n})$ | CK | $B_{(n)}$ |  |
| SNORM | 20 | - | $29^{\dagger}$ | 46 | - | 20 |
| DNORM | 30 | - | 29 | 55 | $40^{\dagger}$ | 20 |
| DIVRF | 40 | - | $29^{\dagger}$ | 46 | - | 20 |
| SDIVQF | 50 | - | $26^{\dagger}$ | - | - | 18 |
| SMULI | 60 | - | $26^{\dagger}$ | 43 | - | 0 |
| SDIVIN | 80 | - | 48 | 64 | $44^{\dagger}$ | 0 |
| SDIVIS | 90 | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| SDIVI | AO | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| UDIVIS | B0 | $18^{\dagger}$ | 45 | 64 | 46 | 0 |
| UDIVI | CO | $18^{\dagger}$ | 50 | 54 | 40 | 0 |
| UMULI | DO | - | $25^{\dagger}$ | 48 | - | 0 |
| SDIVIT | EO | $26^{\dagger}$ | 50 | 56 | 54 | 0 |
| ABX | 48 | - | 34 | 62 | $39^{\dagger}$ | 20 |
| SMTC | 58 | - | 29 | 58 | $39{ }^{\dagger}$ | 20 |
| BINEX3 | DF | - | $29^{\dagger}$ | 58 | - | 18 |
| LOADMQ (Arith) |  | $23^{\dagger}$ | 34 | 62 | 40 | 0 |
| LOADMQ (Log) |  | - | 33 | 62 | $40^{\dagger}$ | 0 |

[^28]| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP <br> TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $C_{n}$ | $1(\mathrm{n})$ | CK | $B_{(n)}$ |  |
| SNORM | 20 | - | $26^{\dagger}$ | 40 | - | 17 |
| DNORM | 30 | - | 26 | 52 | $37^{\dagger}$ | 17 |
| DIVRF | 40 | - | $26^{\dagger}$ | 40 | - | 17 |
| SDIVQF | 50 | - | $25^{\dagger}$ | - | - | 17 |
| SMULI | 60 | - | $25^{\dagger}$ | 40 | - | 0 |
| SDIVIN | 80 | - | 38 | 60 | $40^{\dagger}$ | 0 |
| SDIVIS | 90 | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| SDIVI | AO | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| UDIVIS | B0 | $17^{\dagger}$ | 43 | 60 | 45 | 0 |
| UDIVI | CO | $17^{\dagger}$ | 44 | 52 | 37 | 0 |
| UMULI | D0 | - | $26^{\dagger}$ | 40 | - | 0 |
| SDIVIT | EO | $25^{\dagger}$ | 46 | 52 | 49 | 0 |
| ABX | 48 | - | 32 | 60 | 38 | 17 |
| SMTC | 58 | - | 26 | 52 | $38^{t}$ | 17 |
| BINEX3 | DF | - | $26^{\dagger}$ | 40 | - | 17 |
| LOADMO (Arith) |  | $22^{\dagger}$ | 32 | 50 | 38 | 0 |
| LOADMQ (Log) |  | - | 32 | 50 | $38^{\dagger}$ | 0 |

[^29]| SN74AS887-1 SSF PIN DELAYS AND SETUP TIMES |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP |
|  |  | $\mathrm{C}_{\mathrm{n}}$ | ${ }^{(n)}$ | CK | $\mathrm{B}_{\text {( } ~}^{\text {) }}$ | TIME (ns) |
| SNORM | 20 | - | $23{ }^{\dagger}$ | 28 | - | 14 |
| DNORM | 30 | - | 23 | 40 | $34^{\dagger}$ | 14 |
| DIVRF | 40 | - | $23^{\dagger}$ | 27 | - | 14 |
| SDIVGF | 50 | - | $23^{\dagger}$ | - | - | 14 |
| SMULI | 60 | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIN | 80 | - | 35 | 46 | $35^{\dagger}$ | 0 |
| SDIVIS | 90 | $22^{\dagger}$ | 42 | 48 | 42 | 0 |
| SDIVI | AO | $22^{\dagger}$ | 42 | 46 | 42 | 0 |
| UDIVIS | BO | $16^{\dagger}$ | 42 | 46 | 38 | 0 |
| UDIVI | co | $16^{\dagger}$ | 36 | 46 | 34 | 0 |
| UMULI | D0 | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIT | EO | $21^{\dagger}$ | 40 | 44 | 42 | 0 |
| ABX | 48 | - | 28 | 46 | $30^{\dagger}$ | 14 |
| SMTC | 58 | - | 24 | 44 | $30^{\dagger}$ | 14 |
| BINEX3 | DF | - | $23{ }^{\dagger}$ | 27 | - | 14 |
| LOADMO (Arith) |  | $19^{\dagger}$ | 28 | 40 | 30 | 0 |
| LOADMO (Log) |  | - | 28 | 35 | $30^{\dagger}$ | 0 |

[^30]- STL-AS Technology
- Parallel 8-Bit ALU with Expansion Inputs and Outputs
- 13 Arithmetic and Logic Functions
- 8 Conditional Shifts (Single and Double Length)
- 9 Instructions that Manipulate Bytes
- 4 Instructions that Manipulate Bits
- Add and Subtract Immediate Instructions
- Absolute Value Instruction
- Signed Magnitude to/from Two's Complement Conversion
- Single- and Double-Length Normalize
- Select Functions
- Signed and Unsigned Divides with Overflow Detection; Input does not Need to be Prescaled
- Signed, Mixed, and Unsigned Multiplies
- Three-Operand, 16-Word Register File
- Full Carry Look Ahead Support
- Sign, Carry Out, Overflow, and Zero-Detect Status Capabilities
- Excess-3 BCD Arithmetic
- Internal Shift Multiplexers that Eliminate the Need for External Shift Control Parts
- ALU Bypass Path to Increase Speeds of Multiply, Divide, and Normalize Instructions and to Provide New Instructions such as Bit Set, Bit Reset, Bit Test, Byte Subtract, Byte Add, and Byte Logical
- 3-Operand Register Files to Allow an Operation and a Move Instruction to be Combined
- Byte Select Controlled by External 3-State Buffers that may be Eliminated if Bit and Byte Manipulation are not Needed
- Bit and Byte Masks that are Shared with Register Address Fields to Minimize Control Store Word Width
- 3 Data Input/Output Paths to Maximize Data Throughput


## description

These 8-bit Advanced Schottky TTL integrated circuits are designed to implement high performance digital computers or controllers. An architecture and instruction set has been chosen that supports a fast system clock, a narrow micro-code word width, and a high system throughput. The powerful instruction set allows high-speed system architecture to be implemented and also allows an existing system's performance to be upgraded while protecting software investments. These processors are designed to be cascadable to any word width 16 bits or greater.
The SN54AS888 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS888 and SN74AS888-1 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

Package options include both plastic and ceramic chip carriers in addition to a 68-pin grid array ceramic package.


GB PACKAGE PIN ASSIGNMENTS

| PIN | NAME | PIN | NAME | PIN | NAME | PIN | NAME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A-2 | $\mathrm{C}_{n}$ | B-9 | $\overline{\mathrm{OEY}}$ | F-10 | Y3 | K-4 | C2 |
| A-3 | SIOO | B. 10 | Yo | F-11 | DB2 | K-5 | A0 |
| A-4 | $\overline{0100}$ | B-11 | Y1 | G-1 | DA2 | K-6 | A3 |
| A-5 | $\square 107$ | C-1 | 15 | G-2 | DAO | K-7 | WE |
| A-6 | $\mathrm{C}_{\mathrm{n}+8}$ | C-2 | $\mathrm{v}_{\mathrm{CC} 2}$ | G-10 | DBO | K-8 | DB7 |
| A-7 | $\overline{\mathrm{G}} / \mathrm{N}$ | C-10 | Y4 | G-11 | DB3 | K-9 | $\overline{\mathrm{OEB}}$ |
| A-8 | ¢/OVR | C-11 | Y6 | H-1 | DA3 | K-10 | EBO |
| A-9 | ZERO | D-1 | 16 | H-2 | DA1 | K-11 | EB1 |
| A-10 | PPP | D-2 | $\mathrm{V}_{\mathrm{CC} 1}$ | H-10 | DB6 | L-2 | CK |
| B-1 | 12 | D-10 | Y5 | H-11 | DB4 | L-3 | C1 |
| B-2 | 13 | D-11 | Y7 | J-1 | DA4 | L-4 | C3 |
| B-3 | 11 | E. 1 | 17 | J-2 | DA5 | L-5 | A1 |
| B-4 | 10 | E-2 | $\overline{\text { OEA }}$ | J-10 | Sely | L-6 | A2 |
| B-5 | 14 | E-10 | Y2 | J-11 | DB5 | L-7 | B3 |
| B-6 | $\overline{S 107}$ | E-11 | DB1 | K-1 | DA6 | L-8 | B2 |
| B-7 | SSF | F-1 | EA | K-2 | DA7 | L-9 | B1 |
| B-8 |  | F-2 | GND | K-3 | CO | L-10 | B0 |

PIN FUNCTIONAL DESCRIPTION

| PIN GRID ARRAY | CHIP CARRIER | NAME | 1/0 | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| A-10 | 28 | PPP | I | Package position pin. Tri-level input used to define package significance during instruction execution. Leave open for intermediate positions, tie to $V_{C C}$ for most significant package, and tie to GND for least significant package. |
| B-7 | 29 | SSF | 1/0 | Special shift function. Used to transfer required information between packages during special instruction execution. |
| A-9 | 30 | ZERO | I/O | Device zero detection, open collector. Input during certain special instructions. |
| A-8 | 31 | $\overline{\text { P/OVR }}$ | 0 | ALU propagate/instruction overflow for most significant package, low active. |
| A. 7 | 32 | $\overline{\mathrm{G}} / \mathrm{N}$ | 0 | ALU generate/negative result for most significant package, low active. |
| A-6 | 33 | $C_{n+8}$ | 0 | ALU ripple carry output. |
| B-6 | 34 | $\overline{\mathrm{SIO7}}$ | 1/0 |  |
| A-5 | 35 | $\overline{0107}$ | 1/0 |  |
| A-4 | 36 | $\overline{0100}$ | 1/0 | Bidirectional shift pin, low active. |
| A-3 | 37 | $\overline{\mathrm{SIO}}$ | I/O |  |
| A-2 | 38 | $\mathrm{C}_{\mathrm{n}}$ | 1 | ALU carry input. |
| B-4 | 39 | 10 | 1 |  |
| B-3 | 40 | 11 | 1 | , |
| B. 1 | 41 | 12 | 1 | . |
| B-2 | 42. | 13 | 1 |  |
| B-5 | 43 | 14 | 1 | instruction input. |
| C-1 | 44 | 15 | 1 |  |
| D-1 | 45 | 16 | 1 |  |
| E. 1 | 46 | 17 | 1 | Len |
| C. 2 | 47 | $\mathrm{V}_{\mathrm{CC} 2}$ |  | Low voltage power supply (2 V). |
| D-2 | 48 | $V_{\text {CC1 }}$ |  | $1 / \mathrm{O}$ interface supply voltage ( 5 V ). |
| E. 2 | 49 | $\overline{O E A}$ | 1 | DA bus enable, low active. |
| F-1 | 50 | $\overline{E A}$ | 1 | ALU input operand select. High state selects external DA bus and low state selects register file. |
| F-2 | 51 | GND |  | Ground pin. |
| G-2 | 52 | DAO | 1/0 |  |
| H-2 | 53 | DA1 | 1/0 |  |
| G-1 | 54 | DA2 | 1/0 |  |
| H-1 | 55 | DA3 | 1/0 | A port data bus. Outputs register file data $(\overline{E A}=0)$ or inputs external data $(\overline{E A}=1)$. |
| J-1 | 56 | DA4 | 1/O | A port data bus. Outputs register file data $(E A=0)$ or inputs external data $(E A=1)$. |
| J-2 | 57 | DA5 | 1/O |  |
| K-1 | 58 | DA6 | 1/0 |  |
| K-2 | 59 | DA7 | 1/0 |  |
| L-2 | 60 | CK | 1 | Clocks all synchronous registers on positive edge. |
| K-3 | 61 | CO | 1 |  |
| L-3 | 62 | C1 | 1 |  |
| K-4 | 63 | C2 | 1 | Register file write address select. |
| L-4 | 64 | C3 | 1 |  |
| K-5 | 65 | AO | 1 |  |
| L-5 | 66 | A1 | 1 | Register file A port read address select. |
| L-6 | 67 | A2 | 1 | Register file A port read address select. |
| K-6 | 68 | A3 | 1 |  |

## PIN FUNCTIONAL DESCRIPTION

| PIN GRID ARRAY | CHIP <br> CARRIER | NAME | I/0 | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| K-7 | 1 | $\overline{\text { WE }}$ | 1 | Register file (RF) write enable. Data is written into RF when $\overline{\text { WE }}$ is low and a low-to-high clock transition occurs. RF write is inhibited when $\overline{W E}$ is high. |
| L-7 | 2 | B3 | 1 |  |
| L-8 | 3 | B2 | 1 |  |
| L-9 | 4 | B1 | 1 | Register file B port read address select. $(0=$ LSB $)$. |
| L-10 | 5 | B0 | 1 |  |
| K-10 | 6 | EBO | 1 | ALU input operand select. EB0 and EB1 selects the source of data that the S multiplexer |
| K-11 | 7 | EB1 | 1 | provides for the S bus. Independent control of the DB bus and data path selection allow the user to isolate the DB bus while the ALU continues to process data. |
| K-9 | 8 | $\overline{\text { OEB }}$ | 1 | DB bus enable, low active. |
| K-8 | 9 | DB7 | 1/0 |  |
| H-10 | 10 | DB6 | 1/0 |  |
| J-11 | 11 | DB5 | 1/0 |  |
| H-11 | 12 | DB4 | 1/0 | $B$ port data bus. Outputs register data ( $\overline{\mathrm{OEB}}=0$ ) or used to input external data |
| G. 11 | 13 | DB3 | 1/0 | ( $\overline{O E B}=1$ ), (0 $=$ LSB) |
| F-11 | 14 | DB2 | 1/0 |  |
| E-11 | 15 | DB1 | 1/0 |  |
| G-10 | 16 | DB0 | 1/0 |  |
| J-10 | 17 | SELY | 1 | Y bus select, high active. |
| D-11 | 18 | Y7 | 1/0 |  |
| C-11 | 19 | Y6 | $1 / 0$ |  |
| D. 10 | 20 | Y5 | 1/0 |  |
| C-10 | 21 | Y4 | $1 / 0$ | Y port data bus. Outputs instruction results ( $\overline{O E Y}=0$ ) or used to put external data into |
| F-10 | 22 | Y3 | I/O | register file ( $\overline{O E Y}=1$ ). |
| E-10 | 23 | Y2 | I/O |  |
| B-11 | 24 | Y1 | I/O |  |
| B-10 | 25 | Yo | 1/0 |  |
| B-9 | 26 | $\overline{\mathrm{OEY}}$ | 1 | Y bus output enable, low active. |
| F-2 | 27 | GND |  | Ground pin |

functional block diagram


## SN54AS888, SN74AS888 <br> 8-BIT PROCESSOR SLICES

## architectural elements

## 3-port register file

Working registers consist of 128 storage elements organized into sixteen 8 -bit words. These storage elements appear to the user as 16 positive edge-triggered registers. The three port addresses, one write $(C)$ and two reads ( $A$ and $B$ ), are completely independent of each other to implement a 3-operand register file. Data is written into the register file when $\overline{W E}$ is low and a low-to-high clock transition occurs. The ADD and SUBTRACT immediate instructions require only one source operand. The B address is used as the source address, and the bits of the $A$ address are used to provide a constant field. The SET, RESET, and TEST BIT instructions use the B addressed register as both the source and destination register while the $A$ and $C$ addresses are used as masks. These instructions are explained in more detail in the instruction section.

## S multiplexer

The $S$ multiplexer selects the ALU operand, as follows:

| EB1 | EB0 | S bus |
| :--- | :--- | :--- |
| Low | Low | RF data |
| Low | High | MQ data |
| High | Low | DB data |
| High | High | MQ data |

DB port
Data is passed through the ALU or received from the register file on the 8-bit DB port. If $\overline{O E B}$ is low, the $D B$ bus is active; if $\overline{O E B}$ is high, the $D B$ bus is in the high impedance state. Notice that the DB port may be isolated at the same time that register file data is passed to the ALU.

## R multiplexer

The R multiplexer selects the other operand of the ALU. Except for those instructions that require constants or masks, the R bus will contain DA if $\overline{E A}$ is high or the RF data pointed to by $A$ if $\overline{E A}$ is low.

DA bus
The DA bus is active (with register file data) if $\overline{\text { OEA }}$ is low. Notice that the DA bus may be isolated while register file data is passed to the ALU.

## ALU

The shift instructions are summarized in Table 4 and illustrated in Figure 2. The ALU can perform seven arithmetic and six logical instructions on two 8 -bit operands. It also supports multiplication, division, normalization, bit set, reset, test, byte operations, and excess-3 BCD arithmetic. These source operands are the outputs of the $S$ and $R$ multiplexers.

## ALU and MQ shifters

ALU and MQ shifters perform all of the shift, multiply, divide, and normalize functions. Table 4 shows the value of the $\overline{\mathrm{SIO7}}$ and $\overline{\mathrm{QIO7}}$ pins of the most significant package. The standard shifts may be made into conditional shifts and the serial data may be input or output with the aid of two three-state gates. These capabilities are discussed further in the arithmetic and logic section.

## MO register

The multiplier-quotient (MQ) register has specific functions in multiplication, division, and normalization. This register may also be used as a temporary storage register. The MQ register may be loaded if the instruction code on pins 17-10 is E1-E7 or E9-EE (See Table 1).

## Y bus

The $Y$ bus contains the output of the ALU shifter if $\overline{O E Y}$ is low and is a high impedance input if $\overline{O E Y}$ is high. SELY must be low to pass the internal ALU shift bus and must be high to pass the external $Y$ bus to the register file.

## status

Four status pins are available on the most significant package, overflow (OVR), sign ( $N$ ), carry out ( $C_{n}+8$ ), and zero (ZERO). The $C_{n}+8$ line signifies the ALU result while OVR, ZERO, and $N$ refer the status after the ALU shift has occurred. Notice that the ZERO pin cannot be used to detect whether an input placed on a high impedance $Y$ bus is zero.

## divide BCD flip-flops

The multiply-divide flip-flops contain the status of the previous multiply or divide instruction. They are affected by the following instructions:

```
DIVIDE REMAINDER FIX
SIGNED DIVIDE QUOTIENT FIX
SIGNED MULTIPLY
SIGNED MULTIPLY TERMINATE
SIGNED DIVIDE INITIALIZE
SIGNED DIVIDE START
```

```
SIGNED DIVIDE ITERATE
UNSIGNED DIVIDE START
UNSIGNED DIVIDE ITERATE
UNSIGNED MULTIPLY
SIGNED DIVIDE TERMINATE
UNSIGNED DIVIDE TERMINATE
```

The excess-3 BCD flip-flops are affected by all instructions except NOP. The clear function clears these flip-flops. They preserve the carry from each nibble (4-bits) in excess-3/BCD operations.

## package position pin (PPP)

The position of the processor in the system is defined by the voltage level applied to the package position pin (PPP). Intermediate positions are selected by leaving the pin open. Tying the pin to $V_{C C}$ makes the processor the most significant package and tying the pin to GND makes the processor the least significant package.

## special shift function (SSF) pin

Conditional shifting algorithms may be implemented via control of the SSF pin. The applied voltage to this pin may be set as a function of a potential overflow condition (the two most significant bits are not equal) or any other condition (see Group 1 instructions).

## instruction set

The 'AS888 bit-slice processor uses bits $17-10$ as instruction inputs. A combination of bits $13-10$ (Group 1 instructions) and bits 17-14 (Group 2-5 instructions) are used to develop the 8-bit op code for a specific instruction. Group 1 and Group 2 instructions can be combined to perform arithmetic or logical functions plus a shift function in one instruction cycle. A summary of the instruction set is given in Table 1.

TABLE 1. INSTRUCTION SET
GROUP 1 INSTRUCTIONS

| INSTRUCTION BITS (I3-IO) HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| B <br> C <br> D <br> E <br> F | ADD <br> SUBR <br> SUBS <br> INCS <br> INCNS <br> INCR <br> INCNR <br> XOR <br> AND <br> OR <br> NAND <br> NOR <br> ANDNR | Accesses Group 4 instructions $\begin{aligned} & R+S+C_{n} \\ & \vec{R}+S+C_{n} \\ & R+\bar{S}+C_{n} \\ & S+C_{n} \\ & \bar{S}+C_{n} \\ & R+C_{n} \\ & \bar{R}+C_{n} \end{aligned}$ <br> Accesses Group 3 instructions <br> R XOR S <br> R AND S <br> R OR S <br> R NAND S <br> R NOR S <br> $\bar{R}$ AND S <br> Accesses Group 5 instructions |
| GROUP 2 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-14) HEX CODE | MNEMONIC | FUNCTION |
| $\begin{aligned} & 0 \\ & 1 \\ & 2 \\ & 3 \\ & 4 \\ & 5 \\ & 6 \end{aligned}$ | SRA SRAD SRL SRLD SLA SLAD SLC SLCD SRC SRCD MQSRA MQSRL MQSLL MQSLC LOADMO PASS | Arithmetic Right Single <br> Arithmetic Right Double <br> Logical Right Single <br> Logical Right Double <br> Arithmetic Left Single <br> Arithmetic Left Double <br> Circular Left Single <br> Circular Left Double <br> Circular Right Single <br> Circular Right Double <br> Pass $(F \rightarrow Y)$ and Arithmetic Right MQ <br> Pass $(F \rightarrow Y)$ and Logical Right MQ <br> Pass $(F \rightarrow Y)$ and Logical Left $M Q$ <br> Pass $(F \rightarrow Y)$ and Circular Left $M Q$ <br> Pass $(F \rightarrow Y)$ and Load MQ $(F=M Q)$ <br> Pass $(F \rightarrow Y)$ |

TABLE 1. INSTRUCTION SET (Continued)
GROUP 3 INSTRUCTIONS

| INSTRUCTION BITS (17-IO) hex code | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| $\begin{aligned} & \text { 08 } \\ & 18 \\ & 28 \\ & 38 \\ & 48 \\ & 58 \\ & 68 \\ & 78 \\ & 88 \\ & 98 \\ & \text { A8 } \\ & \text { B8 } \\ & \text { C8 } \\ & \text { D8 } \\ & \text { E8 } \\ & \text { F8 } \end{aligned}$ | SET 1 <br> SETO <br> TB1 <br> TBO <br> ABS <br> SMTC <br> ADDI <br> SUBI <br> BADD <br> BSUBS <br> BSUBR <br> BINCS <br> BINCNS <br> BXOR <br> BAND <br> BOR | Set Bit <br> Reset Bit <br> Test Bit (One) <br> Test Bit (Zero) <br> Absolute Value <br> Sign Magnitude/Two's Complement <br> Add Immediate <br> Subtract Immediate <br> Byte Add R to S <br> Byte Subtract S from R <br> Byte Subtract R from S <br> Byte Increment S <br> Byte Increment Negative S <br> Byte XOR R and S <br> Byte AND R and S <br> Byte OR R and S |
| GROUP 4 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-IO) HEX CODE | MNEMONIC | FUNCTION |
| $\begin{aligned} & 00 \\ & 10 \\ & 20 \\ & 30 \\ & 40 \\ & 50 \\ & 60 \\ & 70 \\ & 80 \\ & 90 \\ & \text { AO } \\ & \text { BO } \\ & \text { CO } \\ & \text { DO } \\ & \text { EO } \\ & \text { FO } \end{aligned}$ | SEL <br> SNORM <br> DNORM <br> DIVRF <br> SDIVQF <br> SMULI <br> SMULT <br> SDIVIN <br> SDIVIS <br> SDIVI <br> UDIVIS <br> UDIVI <br> UMULI <br> SDIVIT <br> UDIVIT | Reserved <br> Select S/R <br> Single Length Normalize <br> Double Length Normalize <br> Divide Remainder Fix <br> Signed Divide Quotient Fix <br> Signed Multiply Iterate <br> Signed Multiply Terminate <br> Signed Divide Initialize <br> Signed Divide Start <br> Signed Divide Iterate <br> Unsigned Divide Start <br> Unsigned Divide Iterate <br> Unsigned Multiply Iterate <br> Signed Divide Terminate <br> Unsigned Divide Terminate |

table 1. INSTRUCTION SET (Concluded)

| GROUP 5 INSTRUCTIONS |  |  |
| :---: | :---: | :--- |
| INSTRUCTION BITS (I7-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| $5 F$ | CLR | Clear |
| $6 F$ | CLR | Clear |
| $7 F$ | BCDBIN | BCO to Binary |
| $8 F$ | EX3BC | Excess-3 Byte Correction |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No Operation |

TABLE 2. GROUP 1 INSTRUCTIONS

| INSTRUCTION BITS (I3-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 0 |  | Accesses Group 4 instructions |
| 1 | ADD | $R+S+C_{n}$ |
| 2 | SUBR | $\bar{R}+S+C_{n}$ |
| 3 | SUBS | $R+\bar{S}+C_{n}$ |
| 4 | INCS | $S+C_{n}$ |
| 5 | INCNS | $\bar{S}+C_{n}$ |
| 6 | INCR | $R+C_{n}$ |
| 7 | INCNR | $\bar{R}+C_{n}$ |
| 8 |  | Accesses Group 3 instructions |
| 9 | XOR | $R$ XOR S |
| A | AND | $R$ AND S |
| $B$ | OR | R OR S |
| C | NAND | R NAND S |
| D | NOR | R NOR S |
| E | ANDNR | $\bar{R}$ AND S |
| F |  | Accesses Group 5 instructions |

Group 1 instructions (excluding hex codes 0,8 , and $F$ ), shown in Table 2, may be used in conjunction with Group 2 shift instructions to perform arithmetic or logical functions plus a shift function ${ }^{\dagger}$ in one instruction cycle (hex codes 0,8 , and $F$ are used to access Group 4, 3, and 5 instructions, respectively). Each shift may be made into a conditional shift by forcing the special shift function (SSF) pin into the proper state. If the SSF pin is high or floating, the shifted ALU output will be sent to the output buffers. If the SSF pin is pulled low externally, the ALU result will be passed directly to the output buffers. Conditional shifting is useful for scaling inputs in data arrays or in signal processing algorithms.

These instructions set the BCD flip-flop for the excess-3 correct instruction. The status is set with the following results ( $C_{n}+8$ is ÁLU carry out and is independent of shift operation; others are evaluated after shift operation).
${ }^{\dagger}$ Double-precision shifts involve both the ALU and MO register.

## condition code

Arithmetic

| N | - | MSB of result |
| :--- | :--- | :--- |
| OVR | - Signed arithmetic overflow |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | - Carry out equal one |  |
| Z | - | Result equal zero |

Logic
N $\quad-\quad$ MSB of result
OVR - None (force to zero)
$\mathrm{C}_{\mathrm{n}}+8$ - None (force to zero)
Z $\quad-\quad$ Result equal zero
group 2 instructions
TABLE 3. GROUP 2 INSTRUCTIONS

| INSTRUCTION BITS (17-14) hex CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| 0 | SRA | Arithmetic Right Single |
| 1 | SRAD | Arithmetic Right Double |
| 2 | SRL | Logical Right Single |
| 3 | SRLD | Logical Right Double |
| 4 | SLA | Arithmetic Left Single |
| 5 | SLAD | Arithmetic Left Double |
| 6 | SLC | Circular Left Single |
| 7 | SLCD | Circular Left Double |
| 8 | SRC. | Circular Right Single |
| 9 | SRCD | Circular Right Double |
| A | MOSRA | Pass ( $F \rightarrow Y$ ) and Arithmetic Right MQ |
| B | MOSRL | Pass ( $F \rightarrow Y$ ) and Logical Right MQ |
| C | MQSLL | Pass ( $F \rightarrow Y$ ) and Logical Left MQ |
| D | MQSLC | Pass ( $F \rightarrow Y$ ) and Circular Left MQ |
| E | LOADMQ | Pass ( $F \rightarrow Y$ ) and Load MQ ( $F=M Q$ ) |
| F | PASS | Pass ( $F \rightarrow Y$ ) |

The processor's shift instructions are implemented by a combination of Group 2 instructions (Table 3) and certain wired connections on the packages used. The following external connections are required. On intermediate packages:
$\overline{\mathrm{SIO7}}$ is connected to $\overline{\mathrm{SIOO}}$ of the next most significant package
$\overline{\mathrm{QIO7}}$ is connected to $\overline{\mathrm{QIOO}}$ of the next most significant package
$\overline{\mathrm{SIOO}}$ is connected to $\overline{\mathrm{SIO7}}$ of the next least significant package
$\overline{\mathrm{QIOO}}$ is connected to $\overline{\mathrm{QIO}}$ of the next least significant package
On the two end packages:
$\overline{\mathrm{SIOT}}$ on the most significant package is connected to $\overline{\mathrm{SIOO}}$ of the least significant package
$\overline{\mathrm{QIOF}}$ on the most significant package is connected to $\overline{\mathrm{QIOO}}$ of the least significant package
The connections are the same on all instructions including multiply, divide, CRC, and normalization functions.
Single- and double-precision shifts are supported. Double-precision shifts assume the most significant half has come through the ALU and will be placed (if $\overline{W E}$ is low) into the register file on the rising edge of the clock and the least significant half lies in the MQ register. All Group 2 shifts may be made conditional (see previous page).
The following definitions apply to Group 2 shift instructions:
Arithmetic right shifts copy the sign of the number if no overflow occurs from the ALU calculation; if overflow occurs, the sign bit is inverted.
Arithmetic left shifts do not retain the sign of the number if an overflow occurs. A zero is filled into the LSB if not forced externally.
Logical right shifts fill a zero in the MSB position if not forced externally.
Circular right shifts fill the LSB in the MSB position.
Circular left shifts fill the MSB in the LSB position.
Shifting left is defined as moving a bit position towards the MSB (doubling).
Shifting right is defined as moving a bit towards the LSB (halving).
Serial input may be performed using the circuitry shown in Figure 1. A single-/or double-precision arithmetic left or logical right shift fills the complement of the data on $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{SIO7}}$ into the LSB or MSB of the data word(s). Note that if $\overline{S I O O}$ and $\overline{S I O 7}$ are floating (HI-Z), a zero will be filled as an end condition.

Serial output may be performed with circular instructions.


FIGURE 1. SERIAL I/O

The shift instructions are summarized in Table 4 and illustrated in Figure 2. In Figure 2 and all succeeding figures that illustrate instruction execution, the following definitions apply:

CRF - CRC accumulator end fill.
QBT - End fill for signed divide.
MQF - End fill for unsigned divide.
SRF - End fill for signed multiply and the arithmetic right shifts.
TABLE 4. SHIFT INSTRUCTIONS

| OP CODE ${ }^{\dagger}$ | SHIFT FUNCTION ${ }^{\ddagger}$ | $\begin{aligned} & \overline{\mathrm{SIO7}} \cdot \overline{\mathrm{SIOO}} \\ & \text { WIRED VALUE } \end{aligned}$ | $\overline{\mathrm{a} 107} \cdot \overline{\mathrm{a} 100}$ <br> WIRED VALUE |
| :---: | :---: | :---: | :---: |
| ON | Arithmetic Right Single | ALU-LSB Output | - |
| 1 N | Arithmetic Right Double | MQ-LSB Output | ALU-LSB Output |
| 2N | Logical Right Single | Input to ALU-MSB | ALU-LSB Output |
| 3N | Logical Right Double | Input to ALU-MSB | ALU-LSB Output |
| 4 N | Arithmetic Left Single | Input to ALU-LSB | ALU-MSB Output |
| 5N | Arithmetic Left Double | Input to MQ-LSB | MQ-MSB Output |
| 6N | Circular Left Single | ALU-MSB Output | - |
| 7 N | Circular Left Double | ALU-MSB Output | MQ-MSB Output |
| 8 N | Circular Right Single | ALU-LSB Output | - |
| 9N | Circular Right Double | MQ-LSB Output | ALU-LSB Output |
| AN | Arithmetic Right (MO only) | MQ-LSB Output | MQ-LSB Output |
| BN | Logical Right (MQ only) | MQ-LSB Output | Input to MQ-MSB |
| CN | Logical Left (MO only) | Input to MQ-LSB | MQ-MSB Output |
| DN | Circular Left '(MQ only) | MQ-MSB Output | MQ-MSB Output |

${ }^{\dagger}$ Op Code $N \neq 0,8$, or $F$; these select special instruction Groups 4,3 , and 5 respectively.
${ }^{\ddagger}$ Shift l/O pins are active low. Therefore, inputs and outputs must be inverted if true logical values are required.

Status is set with the following results:
Arithmetic
N $\quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Signed arithmetic overflow ${ }^{\dagger}$
$C_{n}+8 \rightarrow$ Carry out equal one
$\mathrm{Z} \quad \rightarrow \quad$ Result equal zero
Logic
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Zero
$\mathrm{C}_{\mathrm{n}+8} \rightarrow$ Zero
$\mathrm{Z} \rightarrow$ Result equal zero

[^31]
FIGURE 2. SHIFT INSTRUCTIONS




FIGURE 2. SHIFT INSTRUCTIONS (Continued)


LOGICAL LEFT (MO ONLY) SERIAL DATA IN

FIGURE 2. SHIFT INSTRUCTIONS (Concluded)

## group 3 instructions

Hex code 8 of Group 1 instructions is used to access Group 3 instructions. Group 3 instructions are summarized in Table 5.

TABLE 5. GROUP 3 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 08 | SET1 | Set Bit |
| 18 | SETO | Reset Bit |
| 28 | TB1 | Test Bit (One) |
| 38 | TBO | Test Bit (Zero) |
| 48 | ABS | Absolute Value |
| 58 | SMTC | Sign Magnitude/Two's Complement |
| 68 | ADDI | Add Immediate |
| 78 | SUBI | Subtract Immediate |
| 88 | BADD | Byte Add R to S |
| 98 | BSUBS | Byte Subtract S from R |
| A8 | BSUBR | Byte Subtract R from S |
| B8 | BINCS | Byte Increment S |
| C8 | BINCNS | Byte Increment Negative S |
| D8 | BXOR | Byte XOR R and S |
| E8 | BAND | Byte AND R and S |
| F8 | BOR | Byte OR R and S |

set bit instruction $(\operatorname{set} 1): 17-10=0816$
This instruction (Figure 3) is used to force selected bits of a desired byte(s) to one (any combination of zero to eight bits). The desired bits are specified by an 8-bit mask (C3-CO)::(A3-A0) $\dagger$ consisting of register file address ports that are not required to support this instruction. All bits in the selected byte(s) that are in the same bit positions as ones in the mask are forced to a logical one. The B3-B0 address field is used for both source and destination of this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. Nonselected packages pass the byte through unaltered. The $S$ bus is the source word for this instruction. The status set by the set bit instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
|  | None (force to zero) |
| OVR | $\rightarrow$ |
|  | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Z | $\rightarrow$ |
|  | Rene (force to zero) |
| Z |  |

${ }^{\dagger}$ The symbol $: \because \prime$ is concatenation operator


FIGURE 3. SET BIT (OR RESET BIT)
NOTES: 1. Force $\overline{\mathrm{SIOO}}$ low to select byte.
2. Bit mask (C3-C0)::(A3-A0) will set desired bits to one.
reset bit instruction (set0): $17-10=1816$
This instruction (Figure 3) is used to force selected bits of a desired byte(s) to zero (any combination of one to eight bits). The desired bits are specified by an 8-bit mask (C3-C0)::(A3-A0) consisting of register file address ports that are not required to support this instruction. All bits in the selected byte(s) that are in the same bit positions as ones in the mask are reset. The B3-BO address field is used for both source

## SN54AS888, SN74AS888 8-BIT PROCESSOR SLICES

and destination of this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. Nonselected packages pass the byte through unaltered. The S bus is the source word for this instruction. The status set by the reset bit instruction is as follows:

| N | $\rightarrow$ | None (force to zero) |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Result equal zero |

test bit (one) instruction (TB1): 17-IO $\mathbf{= 2 8 1 6}$
This instruction (Figure 4) is used to test selected bits of a desired byte(s)(any combination of one to eight bits). Bits to be tested are specified by an 8 -bit mask (C3-CO)::(A3-AO) consisting of register file address ports that are not required to support this instruction. Write Enable ( $\overline{\mathrm{WE}}$ ) is internally disabled during this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. The test will pass if the selected byte has ones at all bit locations specified by the ones of the mask (Figure 5 ). The S bus is the source word for this instruction. The status set by the test bit (one) instruction is as follows:

| N | $\rightarrow$ | None (force to zero) |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Pass |



FIGURE 4. TEST BIT
NOTES: 1. Force $\overline{\text { SIOO }}$ low to select byte.
2. Bit mask (C3-CO)::(A3-AO) will define bits for testing.
3. Pass/fail is indicated on $Z$ output.

## SN54AS888, SN74AS888 8-BIT PROCESSOR SLICES

test bit (zero) instruction (TBO): 17-10 $=3816$
This instruction (Figure 4) is used to test selected bits of a desired byte(s) (any combination of one to eight bits). Bits to be tested are specified by an 8-bit mask (C3-CO)::(A3-AO) consisting of register file address ports that are not required to support this instruction. Write Enable ( $\overline{\mathrm{WE}})$ is internally disabled during this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. The test will pass if the selected byte has zeros at all bit locations specified by the ones of the mask (Figure 6). The S bus is the source word for this instruction. The status set by the test bit (zero) instruction is as follows:

| N | $\rightarrow$ | None (force to zero) |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Pass |


figure 5. TEST bit one examples


FIGURE 6. TEST BIT ZERO EXAMPLES
absolute value instruction (ABS): $17-10=4816$
This instruction is used to convert two's complement numbers to their positive value. The operand placed on the S bus is the source for this instruction. The MSP will test the sign of the S bus and force the SSF pin to the proper value. All other packages use the SSF pin as input to determine instruction execution. The status set by the absolute value instruction is as follows:

```
\(\mathrm{N} \rightarrow\) Input MSB equal one
OVR \(\rightarrow\) Input equal 8000 (hex)
\(\mathrm{C}_{\mathrm{n}+8} \rightarrow \mathrm{~S}=0\)
\(z \quad \rightarrow\) Result equal zero
```

sign magnitude/two's complement instruction (SMTC): $17-10=5816$
This instruction allows conversion from two's complement representation to sign magnitude representation, or vice-versa, in one clock cycle. The operand placed on the $S$ bus is the source for this instruction.
When a negative zero ( 8000 hex ) is converted, the result is 0000 with an overflow. If the input is in two's complement notation, the overflow indicates an illegal conversion. The status set by the sign magnitude/two's complement instruction is as follows:

| N | $\rightarrow$ | Result MSB equal one |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Input equal 8000 (hex) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Input equal 0000 (hex) |
| Z | $\rightarrow$ | Result equal zero |

add immediate instruction (ADDI): 17-10 $=6816$
This instruction is used to add a specified constant value to the operand placed on the $S$ bus. The constant will be between the values of 0 and 15 . The constant value is specified by the unused register file address (A port) not required to support this instruction. Forcing the carry input will add an additional one to the result. The status set by the add immediate instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| Result MSB equal one |  |
| OVR | $\rightarrow$ |
| Arithmetic signed overflow |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Carry out equal one |  |
| Z | $\rightarrow$ Result equal zero |

## subtract immediate instruction (SUBI): 17-10 $=\mathbf{7 8 1 6}$

This instruction is used to subtract a specified constant value from the operand placed on the S bus. The constant value is specified by the unused register file address (A port) that is not required to support this instruction. The constant applied is the least significant four bits of a two's complement number. The device sign extends the constant over the entire word length. The status set by the subtract immediate instruction is as follows:

| N | $\rightarrow$ | Result MSB equal one |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Arithmetic signed overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |

## byte instructions

There are eight byte instructions in Group 3. These instructions modify selected bytes of the operand on the S bus. A byte is selected by forcing SIOO to a low value (same as SET1, SETO, TB1, and TBO instructions). Multiple bytes may be selected only if they are adjacent to one another.

NOTE: At least one byte must be nonselected during these instructions.
The nonselected bytes are passed through unaltered. Byte status is forced through the most significant package except for the sign of the result ( $N$ ), which is forced to zero (low). The status set by the byte instructions is as follows:

## (Most Significant Package)

| N | $\rightarrow$ |
| :--- | :--- |
| None (force to zero) |  |
| OVR | $\rightarrow$ |
| Byte signed overflow |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Z | Byte carry out equal one |
| Z | Byte result equal to zero |

## (Selected BYTES -other than MSP)

$\begin{array}{lll}\overline{\mathrm{G}} & \rightarrow & \text { Normal generate } \\ \overline{\mathrm{P}} & \rightarrow & \text { Normal }\end{array}$
$\overline{\mathrm{P}} \quad \rightarrow \quad$ Normal propagate
$\mathrm{C}_{\mathrm{n}+8} \rightarrow$ Normal carry out
Z $\quad \rightarrow \quad$ Result equal to zero

## (Nonselected BYTES-other than MSP)

$\overline{\mathrm{G}} \quad \rightarrow \quad$ No generate (force to one)
$\overline{\mathrm{P}} \quad \rightarrow \quad$ Propagate (force to zero)
$\mathrm{C}_{\mathrm{n}+8} \rightarrow \mathrm{C}_{\mathrm{n}}$
$\mathrm{Z} \rightarrow$ None (force to one)

## group 4 instructions

Hex code 0 of Group 1 instructions is used to access Group 4 instructions. Group 4 instructions are summarized in Table 6.

TABLE 6. GROUP 4 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEXI | MNEMONIC | FUNCTION |
| :--- | :--- | :--- |
| 00 |  | Reserved |
| 10 | SEL | Select S/R |
| 20 | SNORM | Single Length Normalize |
| 30 | DNORM | Double Length Normalize |
| 40 | DIVRF | Divide Remainder Fix |
| 50 | SDIVQF | Signed Divide Quotient Fix |
| 60 | SMULI | Signed Multiply Iterate |
| 70 | SMULT | Signed Multiply Terminate |
| 80 | SDIVIN | Signed Divide Initialize |
| 90 | SDIVIS | Signed Divide Start |
| AO | SDIVI | Signed Divide Iterate |
| BO | UDIVIS | Unsigned Divide Start |
| CO | UDIVI | Unsigned Divide Iterate |
| DO | UMULI | Unsigned Multiply Iterate |
| EO | SDIVIT | Signed Divide Terminate |
| FO | UDIVIT | Unsigned Divide Terminate |

## select $S / R$ instruction (SEL): $17-10=1016$

This instruction is used to pass either the $S$ bus or the $R$ bus to the output depending on the state of the SSF input pin. Normally, the preceding instruction would test the two operands and the resulting status information would be used to force the SSF input pin. SSF $=0$ will output the $R$ bus and SSF $=1$ will output the $S$ bus. The status set by the select $S / R$ instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Result MSB equal one } \\
\text { OVR } & \rightarrow \\
\text { None (force to zero) } \\
\mathrm{C}_{n}+8 & \rightarrow \\
\mathrm{Z} & \rightarrow \\
\text { Rene (force to zero) } \\
\mathrm{Z} &
\end{array}
$$

## single-length normalize instruction (SNORM): 17-10 = $\mathbf{2 0 1 6}$

This instruction will cause the contents of the MO register to shift toward the most significant bit. Zeros are shifted in via the $\overline{\mathrm{QOO}}$ input. The number of shifts performed can be counted and stored in one of the register files by forcing a high at the $C_{n}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.

The chip contains conditional logic that inhibits the shift function (and also inhibits the register file increment) if the number within the MQ register is already normalized at the beginning of the instruction (Figure 7). The status set by the single-length normalize instruction is as follows:

```
N }\quad->\quad\mathrm{ MSB of result
OVR }->\mathrm{ MSB XOR 2nd MSB
Cn+8 傽 Carry out equal one
Z }\quad->\quad\mathrm{ Result equal zero
```

SINGLE-LENGTH NORMALIZE

FIGURE 7. SINGLE- AND DOUBLE-LENGTH NORMALIZE

## SN54AS888, SN74AS888 <br> 8-BIT PROCESSOR SLICES

double-length normalize instruction (DNORM): 17 -IO $=\mathbf{3 0 1 6}$
This instruction will cause the contents of a double-length word (register file contains the most significant half and the MQ register contains the least significant half) to shift toward the most significant bit. Zeros are shifted in via the $\overrightarrow{Q I O O}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.
The chip contains conditional logic which inhibits the shift function if the number is already normalized at the beginning of the instruction (Figure 7). The most significant half of the operand must be placed on the S bus. The status set by the double-length normalize instruction is as follows:

$$
\begin{array}{lll}
\text { N } & \rightarrow & \text { MSB of result } \\
\text { OVR } & \rightarrow & \text { MSB XOR 2nd MSB } \\
\mathrm{C}_{n}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

## multiply operations

The ALU performs three unique types of $N$ by $N$ multiplies each of which produces a 2 N -bit result (Figure 8). All three types of multiplication proceed via the following recursion:
$P(J+1)=2[P(J)+$ Multiplicand $\times M(8 N-J)]$
where
$P(J) \quad=$ partial product at iteration number $J$
$N=$ number of 'AS888 packages that are cascaded
$P(J+1)=$ partial product at iteration number $J+1$
$J$ varies from 0 to $8 N[N=2$ for $16 \times 16$ multiply]
$\mathrm{M}(8 \mathrm{~N}-\mathrm{J})=$ mode bit (unique to multiply type)
2 denotes some type of shift (unique to multiply)
Notice that by proper choice of mode terms and shifting operations, signed, unsigned, and mixed multiplies (signed times unsigned) may be performed.

All multiplies assume that the multiplier is stored in MQ before the operation begins (in the case of mixed multiply, the unsigned number must be the multiplier).

The processor has the following multiply instructions:

1. SIGNED MULTIPLY ITERATE (SMULI): $17-10=6016$
2. SIGNED MULTIPLY TERMINATE (SMULT): $17-10=70_{16}$
3. UNSIGNED MULTIPLY ITERATE (UMULI): $17-10=D 0_{16}$
SMULI, SMULT


The signed multiply iterate (SMULI) instruction performs a signed times signed iteration. This instruction interprets $M(8 N-J)$ as the $8 N-J$ bit of the multiplier. The shift is a double-precision right shift one bit. This instruction is repeated 15 times for a $16 \times 16$ signed multiply. This instruction will be used 16 consecutive times for a mixed multiplication.
The signed multiply terminate (SMULT) instruction provides correct (negative) weighting of the sign bit of a negative multiplier in signed multiplication. The instruction is identical to signed multiply iterate (SMULI) except that $M(8 N-J)$ is interpreted as -1 if the sign bit of the multiplier is 1 , and 0 if the sign bit of the multiplier is 0 .

The unsigned multiply iterate (UMULI) performs an unsigned multiplication iteration. This instruction interprets $\mathrm{M}(8 \mathrm{~N}-\mathrm{J})$ as the $8 \mathrm{~N}-\mathrm{J}$ bit of the multiplier. The shift is a double-precision right shift with the carry out from the $P(J)+$ Multiplicand $\times M(8 N-J)$ operation forced into bit $8 N$ of $P(J+1)$. This instruction is used in unsigned and mixed multiplication.

## signed multiplication

Signed multiplication performs an $8 \mathrm{~N}+2$ clock two's complement multiply. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MQ with multiplier
SMULI (repeat $8 \mathrm{~N}-1$ times)
S port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Iteration result
S port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Product $(\mathrm{MSH})$

At completion, the accumulator will contain the 8 N most significant bits and the MQ contains the 8 N least significant bits of the product.

The status for the signed multiply iterate should not be used for any testing (overflow is not set by SMULI). The following status is set for the signed multiply terminate instruction:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \text { Result MSB equal one } \\
\text { OVR } & \rightarrow \text { Forced to zero } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \text { Carry out equal to one } \\
\mathrm{Z} & \rightarrow \text { Double precision result is zero }
\end{array}
$$

## unsigned multiplication

Unsigned multiplication produces an unsigned times unsigned product in $8 \mathrm{~N}+2$ clocks. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MQ with multiplier
UMULI ( 8 N times) $\quad$ S port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Iteration result (product MSH on final result)

Upon completion, the accumulator will contain the 8 N most significant bits and-the MQ contains the 8 N least significant bits of the product.

The status set by the unsigned multiply iteration is meaningless except on the final execution of the instruction. The status set by the unsigned multiply iteration instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| Result MSB equal one |  |
| OVR | $\rightarrow$ |
| Forced to zero |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Z | Carry out equal to one |
| Z | Double-precision result is zero |

## mixed multiplication

Mixed multiplication multiplies a signed multiplicand times an unsigned multiplier to produce a signed result in $8 \mathrm{~N}+2$ clocks. The steps are as follows:

Zero register used for accumulator
Load MQ with unsigned multipler
SMULI ( 8 N times)

$$
\begin{aligned}
& \text { S port }=\text { Accumulator } \\
& \text { R port }=\text { Multiplicand } \\
& \text { F port }=\text { Iteration result }
\end{aligned}
$$

## divide operations

The divide uses a nonrestoring technique to perform both signed and unsigned division of a 16 N bit integer dividend and an 8 N bit integer divisor (Figure 9). It produces an 8 N integer quotient and remainder.

The remainder and quotient will be such that the following equation is satisfied:

$$
\text { (Quotient) } \times \text { (Divisor) }+ \text { Remainder }=\text { Dividend }
$$

The processor has the following divide instructions:

1. UNSIGNED DIVIDE START (UDIVIS): $17-10=B 016$
2. UNSIGNED DIVIDE ITERATE (UDIVI): $17-10=\mathrm{CO} 16$
3. UNSIGNED DIVIDE TERMINATE (UDIVIT): $17-10=$ FO 16
4. SIGNED DIVIDE INITIALIZE (SDIVIN): $17-10=8016$
5. SIGNED DIVIDE OVERFLOW TEST (SDIVO): $17-10=A F_{16}$
6. SIGNED DIVIDE START (SDIVIS): $17-10=9016$
7. SIGNED DIVIDE ITERATE (SDIVI): $17-10=A 016$
8. SIGNED DIVIDE TERMINATE (SDIVIT): $17-10=$ E016
9. DIVIDE REMAINDER FIX (DIVRF): $17-10=4016$
10. SIGNED DIVIDE QUOTIENT FIX (SDIVQF): $17-I 0=5016$


FIGURE 9. DIVIDE OPERATIONS
UDIVS, UDIVI


LSI Devices

The unsigned divide iterate start (UDIVIS) instruction begins the iterate procedure while testing for overflow. Overflow is reported when the first subtraction of the divisor from the MSH of the dividend produces carry out. The test detects quotient overflow and divide by zero.
The unsigned divide iterate terminate (UDIVIT) instruction completes the iterate procedure generating the last quotient bit.

The signed divide initialize (SDIVIN) instruction prepares for iteration by shifting the dividend and storing the sign of the dividend for use in the following instructions and overflow tests.
The signed divide overflow test (SDIVO) checks for overflow possibilities. This instruction may be deleted from the divide operation if the OVR pin is ignored. If it is removed some overflow conditions will go undetected. $\overline{W E}$ must be high (writing inhibited) when this instruction is used.
The signed divide iterate start (SDIVIS) instruction calculates the difference between the divisor and MSH of the dividend. Partial detection of overflow is also done during this instruction. Operations with like signs (positive quotient) and division by zero will overflow during this instruction (including zero divisor). Operations with unlike signs are tested for overflow during the signed divide quotient fix instruction (SDIVQF). Partial overflow results are saved and will be used during SDIVQF when overflow is reported.
The signed divide iterate (SDIVI) instruction forms the quotient and remainder through iterative subtract/addshift operations of the divisor and dividend. One quotient bit is generated on each clock.
The signed divide iterate terminate (SDIVIT) instruction completes the iterate procedure, generating the last quotient bit. It also tests for a remainder equal to zero, which determines the action to be taken in the following correction (fix) instructions.
The divide remainder fix (DIVRF) instruction corrects the remainder. If a zero remainder was detected by the previous instructions, the remainder is forced to zero. For nonzero remainder cases where the remainder and dividend have the same sign, the remainder is correct. When the remainder and dividend have unlike signs, a correction add/subtract of the divisor to the remainder is performed.
The signed divide quotient fix (SDIVQF) instruction corrects the quotient if necessary. This correction requires adding one to the incorrect quotient. An incorrect quotient results if the signs of the divisor and dividend differ and the remainder is nonzero. An incorrect quotient also results if the sign of the divisor is negative and the remainder is zero.
Overflow detection is completed during this instruction. Overflow may be generated for differing signs of the dividend and divisor. The partial overflow test result performed during SDIVIS is ORed with this test result to produce a true overflow indication.
signed divide usage
The instructions necessary to perform an algebraically correct division of signed numbers are as follows:
Load MO with the leasst significant half of the dividend
SDIVIN $\quad$ S port $=\mathrm{MSH}$ of dividend R port $=$ Divisor F port $=$ Intermediate result
SDIVO $\quad$ S port $=$ Result of SDIVIN
R port $=$ Divisor
F port $=$ Test result
( $\overline{W E}$ must be high)
SDIVIS $\quad$ S port $=$ Result of SDIVIN
R port $=$ Divisor
F port $=$ Intermediate result

| SDIVI (8N-2 times) | S port$=$ Result of SDIVIS (or SDIVI) |
| :--- | :--- |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
| SDIVIT | S port $=$ Result of last SDIVI |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
| DIVRF | S port $=$ Result of SDIVIT |
|  | R port $=$ Divisor |
|  | F port $=$ Remainder |
| SDIVQF | S port $=$ MQ register |
|  | R port $=$ Divisor |
|  | F port $=$ Quotient |

The status of all signed divide instructions except SDIVIN, DIVRF, and SDIVQF is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Forced to zero } \\
\text { OVR } & \rightarrow \\
\text { Forced to zero } \\
\mathrm{C}_{n}+8 & \rightarrow \\
\mathrm{Carry} \text { out equal to one } \\
\mathrm{Z} & \rightarrow \\
\text { Intermediate result is zero }
\end{array}
$$

The status of the SDIVIN instruction is as follows:

| N | $\rightarrow$ | Forced to zero |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Forced to zero |
| $\mathrm{C}_{\mathrm{n}}+8$ |  | Forced to zero |
| Z | $\rightarrow$ | Divisor is zero |

The status of the DIVRF instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| O Forced to zero |  |
| OVR | $\rightarrow$ |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ Corced to zero |
| Z | $\rightarrow$ | Remainder is zero

The status of the SDIVQF instruction is as follows:

| N | $\rightarrow$ | Sign of quotient |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Divide overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal to one |
| Z | $\rightarrow$ | Quotient is zero |

The quotient is stored in the MQ register and the remainder is stored in the register file location that originally held the most significant word of the dividend. If fractions are divided, the quotient must be shifted right one bit and the remainder right three bits to obtain the correct fractional representations.

The signed division algorithm is summarized in Table 7.
table 7. SIGNED division ALgorithm

| $\begin{gathered} \mathrm{OP} \\ \mathrm{CODE} \end{gathered}$ | MNEMONIC | CLOCK CYCLES | INPUT <br> S PORT | INPUT <br> R PORT | OUTPUT F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMQ | 1 | Dividend (LSH) | - | Dividend (LSH) |
| 80 | SDIVIN | 1 | Dividend (MSH) | Divisor | Remainder ( N ) |
| AF | SDIVO | 1 | Remainder ( N ) | Divisor | Test Result |
| 90 | SDIVIS | 1 | Remainder ( N ) | Divisor | Remainder ( N ) |
| AO | SDIVI | $8 \mathrm{~N}-2^{\dagger}$ | Remainder ( N ) | Divisor | Remainder ( N ) |
| EO | SDIVIT | 1 | Remainder ( N ) | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |
| 50 | SDIVAF | 1 | MQ Register | Divisor | Quotient |

${ }^{\dagger} N=$ Number of cascaded packages.
unsigned divide usage
The instructions necessary to perform an algebraically correct division of unsigned numbers are as follows:
Load MO with the least significant half of the dividend

| UDIVIS | $\begin{aligned} & \mathrm{S} \text { port }= \\ & \mathrm{R} \text { port }= \\ & \mathrm{F} \text { port }= \end{aligned}$ | MSH of dividend Divisor Intermediate result |
| :---: | :---: | :---: |
| UDIVI (8N-1 times) | $\begin{aligned} & \text { S port }= \\ & \text { R port }= \\ & \text { F port }= \end{aligned}$ | Result of UDIVIS (OR UDIVI) <br> Divisor <br> Intermediate result |
| UDIVIT | $\begin{aligned} & \text { S port }= \\ & \text { R port }= \\ & \text { F port }= \end{aligned}$ | Result of last UDIVI Divisor <br> Remainder (unfixed) |
| DIVRF | $\begin{aligned} & \text { S port }= \\ & \text { R port }= \\ & \text { F port }= \end{aligned}$ | Result of UDIVIT Divisor Remainder |

The status of all unsigned divide instructions except UDIVIS is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| OVrced to zero |  |
| OVR | $\rightarrow$ |
| $\mathrm{C}_{\mathrm{n}}+8$ | Forced to zero |
| Z | $\rightarrow$ |
| Carry out equal to one |  |
|  | Intermediate result is zero |

The status of the UDIVIS instruction is as follows:

| N | $\rightarrow$ |
| :--- | :--- |
| Forced to zero |  |
| OVR | $\rightarrow$ |
| Divide overflow |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Z | $\rightarrow$ |
| Carry out equal to one |  |

If fractions are divided, the remainder must be shifted right two bits to obtain the correct fractional representation. The quotient is correct as is. The quotient is stored in the MQ register at the completion of the divide.
The unsigned division algorithm is summarized in Table 8.

TABLE 8. UNSIGNED DIVISION ALGORITHM

| OP <br> CODE | MNEMONIC | CLOCK <br> CYCLES | INPUT <br> S PORT | INPUT <br> R PORT | OUTPUT <br> F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMQ | 1 | Dividend (LSH) | - | Dividend (LSH) |
| BO | UDIVIS | 1 | Dividend (MSH) | Divisor | Remainder (N) |
| C0 | UDIVI | $8 N-1^{\dagger}$ | Remainder (N) | Divisor | Remainder (N) |
| FO | UDIVIT | 1 | Remainder (N) | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |

$\dagger \mathrm{N}=$ Number of cascaded packages.

## group 5 instructions

Hex code F of Group 1 instructions is used to access Group 5 instructions. Group 5 instructions are summarized in Table 9.

TABLE 9. GROUP 5 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| $5 F$ | CLR | Clear |
| $6 F$ | CLR | Clear |
| $7 F$ | BCDBIN | BCD to Binary |
| $8 F$ | EX3BC | Excess-3 Byte Correction |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No Operation |

## clear instructions (CLR)

There are 11 clear instructions listed in Table 9. The instructions force the ALU output to be zero and the BCD flip-flops to be cleared. The status set by the clear instruction is as follows:

$$
\begin{array}{lll}
N & \rightarrow & \text { None (force to zero) } \\
\text { OVR } & \rightarrow & \text { None (force to zero) } \\
C_{n}+8 & \rightarrow & \text { None (force to zero) } \\
Z & \rightarrow & \text { Active (one) }
\end{array}
$$

no operation instruction (NOP): 17-10 $=$ FF16
This instruction is identical to the clear instructions except that the BCD flip-flops retain their old value.
excess-3 correction instructions (EX3BC, EX3C)
Two excess- 3 correction instructions are available:

1. Excess-3 byte correction (EX3BC): $17-10=8 \mathrm{~F}_{16}$
2. Excess-3 word correction (EX3C): $17-10=9 \mathrm{~F}_{16}$

One instruction supports the byte mode and the other supports the word mode. These instructions correct the excess-3 additions (subtractions) in either the byte or word mode. For correct excess-3 arithmetic, this instruction must follow each add/subtract. The operand must be on the S port.
NOTE: The previous arithmetic overflow should be ignored.
The status of the EX3C instruction is as follows:

```
N }->\mathrm{ MSB of result
OVR }->\mathrm{ Signed overflow
Cn+8 }->\mathrm{ Carry out equal one
Z }->\quad\mathrm{ None (force to one)
```

The status of the EX3BC instruction is as follows:
$\mathrm{N} \rightarrow \quad$ None (force to zero)
OVR $\rightarrow$ Byte signed overflow
$\mathrm{C}_{\mathrm{n}+8} \rightarrow$ Carry out equal one
$Z \rightarrow$ None (force to one)

## radix conversions

Conversions between decimal and binary number representations are performed with the aid of two special instructions: BINEX3 and BCDBIN.
$B C D$ to binary instructions ( BCDBIN ): $17-10=7 \mathrm{~F}_{16}$
This instruction (Figure 10) allows the user to convert an N -digit BCD number to a 4 N -bit binary number in $4(\mathrm{~N}-1)$ plus 8 clocks. This function sums the $R$ bus, the $S$ bus, and the $C_{n}$ bit, performs an arithmetic left shift on the ALU result, and simultaneously circular shifts the MQ left. The status set by the BCD to binary instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { MSB of result } \\
\text { OVR } & \rightarrow & \text { Signed arithmetic overflow } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { Carry out equal one } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

${ }^{\dagger}$ Overflow may be the result of an ALU operation or the arithmetic left shift operation.

The following code illustrates the $B C D$ to binary conversion technique.
Let ACC be an accumulator register
Let NUM be the register which contains the BCD number
Let MSK be a mask register

| M1: | LOADMO NUM | ; LOAD MO WITH BCD NUMBER |
| :---: | :---: | :---: |
| M2: | SUB ACC, ACC, SLCMO | ; CLEAR ACC AND ALIGN MO |
| M3: | SUB, MSK, MSK, SLCMQ | ; CLEAR MSK AND ALIGN MO |
| M4: | SLCMO | ; ALIGN |
| M5: | SLCMO | ; ALIGN |
| M6: | ADDI ACC, MSK, 1510 | ; MSK = 1510 |
|  |  | ; REPEAT L1 THRU L4 <br> ; $\mathrm{N}-1$ TIMES $\mathbb{N}=$ number of <br> ; BCD digits) |
| L1: | AND MQ, MSK, R1, SLCMO | ; EXTRACT ONE DIGIT <br> ; ALIGN MQ |
| L2: | ADD, ACC, R1, R1, SLCMQ | ACC + DIGIT IS STORED IN R1 ALIGN MQ |
| L3: | BCDBIN, R1, R1, ACC | $; 4 \times(\mathrm{ACC}+$ DIGIT $)$ IS STORED IN ACC ; ALIGN MQ |
| L4: | BCDBIN, ACC, R1, ACC | ; $10 \times(A C C+$ DIGIT $)$ <br> ; IS STORED IN ACC <br> ; ALIGN MQ |
| M7: | AND MQ, MSK, R1 | ; FETCH LAST DIGIT |
| M8: | ACC + R1 $\rightarrow$ ACC | ; ADD IN LAST DIGIT |

The previous code generates a binary number by executing the standard conversion formula for a $B C D$ number (shown for 32 bits).

$$
A B C D=[(A \times 10+B) \times 10+C l \times 10+D
$$

Notice that the conversion begins with the most significant $B C D$ digit and that the addition is performed in radix 2 .
binary to excess-3 instructions (BINEX3): $17-10=$ DF $_{16}$
This instruction (Figure 11 ) allows the user to convert an N -bit binary number to an $\mathrm{N} / 4$-bit excess- 3 number representation in $2 N+3$ clocks. The data on the $R$ and $S$ ports are summed with the $M S B$ of the $M Q$ register. The MQ register is simultaneously shifted left circularly. The status set by the binary to excess-3 instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { MSB of result } \\
\mathrm{OVR} & \rightarrow & \text { Signed arithmetic overflow } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { Carry out equal one } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$



```
The following illustrates the binary to excess-3 conversion technique.
Let NUM be a register containing an unsigned binary number
Let ACC be an accumulator
\begin{tabular}{|c|c|c|}
\hline M1: & LOADMO NUM & \begin{tabular}{l}
; LOAD MO WITH BINARY \\
: NUMBER
\end{tabular} \\
\hline M2: & CLEAR ACC & ; CLEAR ACC \\
\hline M3: & SET1 ACC H/33/ & ; ACC \(\rightarrow\) HEX/3333 \\
\hline L1: & BINEX3 ACC, ACC, ACC & \begin{tabular}{l}
; DOUBLE ACC AND ADD IN \\
; MSB OF MQ
\end{tabular} \\
\hline & & ; ALIGN MO \\
\hline \multirow[t]{2}{*}{L2:} & \multirow[t]{2}{*}{EX3C ACC, ACC} & ; EXCESS 3 CORRECT \\
\hline & & ; REPEAT L1 AND L2
; N-1 TIMES \\
\hline
\end{tabular}
```

The previous code generates an excess-3 number by executing the standard conversion formula for a binary number.

$$
a_{n} 2^{n}+a_{n}-1^{2 n-1}+a_{n-2} 2^{n-2}+\ldots a_{0} 2^{0}=\left[\left(2 a_{n}+a_{n}-1\right) 2+a_{n}-2\right]^{12}+\ldots a_{0}
$$

Notice that the conversion begins with the most significant binary bit and that the addition is performed in radix-10 (excess-3).

## decimal arithmetic

Decimal numbers are represented in excess- 3 code. Excess- 3 code numbers may be generated by adding three to each digit of a Binary Coded Decimal (BCD) number. The hardware necessary to implement excess-3 arithmetic is only slightly different from binary arithmetic. Carries from one digit to another during addition in BCD occur when the sum of the two digits plus the carry-in is greater than or equal to ten. If both numbers are excess-3, the sum will be excess-6, which will produce the proper carries. Therefore, every addition or subtraction operation may use the binary adder. To convert the result from excess-6 to excess-3, one must consider two cases resulting from a BCD digit add: (1) where a carry-out is produced, and (2) where a carry-out is not produced. If a carry-out is not produced, three must be subtracted from the resulting digit. If a carry is produced, the digit is correct as a $B C D$ number. For example, if $B C D 5$ is added to $B C D 6$, the excess- 3 result would be $8+9=1$ (with a carry). A carry rolls the number through the illegal $B C D$ representations into a correct BCD representation. Binary 3 must be added to digit positions that produce a carry-out to correct the result to an excess-3 representation. Every addition and subtraction instruction stores the carry generated from each 4-bit digit location for use by the excess- 3 correction functions. These correction instructions (word or byte) must be executed in the clock cycle immediately after the addition or subtraction operation.
Signed numbers may be represented in ten's complement form by complementing the excess- 3 number. As an example, add the decimal number -423 to the decimal number 24 , which will be represented by 8AA and 357 in excess-3, respectively.

| 8AA |  |
| ---: | :--- |
| 357 |  |
| C01 | Sum |
| 011 | Carry |
| 934 | Excess-3 correct |
| $-6 C C$ | Complement |
| -399 | Excess-3 to decimal |

Complements of excess- 3 numbers may be generated by subtracting the excess- 3 number from an excess- 3 zero followed by an excess-3 correct.

## excess-3 to USASCII conversion

Input/output devices or files represent numbers differently than high-speed central processing units. I/O devices handle all alphanumeric data similarly. CPUs handle more numeric data than alphabetic data and store numeric data in packed form to minimize calculation throughout and reduce memory requirements. To represent the cost of a shirt that was $\$ 10.96$, the I/O device would handle the six USASCII characters " $\$$ ", " 1 ", " 0 ",'".",'" $9 ", " 6 "$, which would require 6 bytes of storage. In packed BCD, this number could be stored as 1096 in two bytes of data. The 'AS888 may be programmed to perform data format conversions such as converting excess-3 BCD to USASCII.

The code below converts a packed word of excess-3 BCD to two unpacked words of USASCII code. Instruction "MAIN1" reads the input word from memory into Register 0 (RO). For illustrative purposes, suppose this data was 43C9, which represents the $\$ 10.96$ shirt in excess- 3 code. "MAIN2" and "MAIN3" generate a constant of 2D2D16, which is an offset constant to convert excess-3 numbers to USASCII. "MAIN4" copies RO into R2 to set up the subroutine parameters and calls the subroutine "UNPACK", UNPACK2" strips off the upper byte leaving OOC9 in R2. "UNPACK2" and "UNPACK3" together shift the contents of R2 one character position and places the result OC90 into R3. "UNPACK4" performs a logical OR operation to produce OCD9 in register 2. "UNPACK5" clears the most significant nibble in each byte to produce 0CO9 in R2. "UNPACK6' adds the constant 2D2D 16 to R2 to produce 3936 the USASCII representation of the numerals 96 and returns program control to "MAIN5". "MAIN5" through '"MAIN9" align the two remaining characters and call UNPACK and the process repeats. Finally the USASCII representation of 1096 is stored into memory. (Note that no attempt was made to pack the "\$" or "." characters.)

Unpacking Excess-3 to USASCII:

| MAIN1: | READ, RFA 0 ) | ; READ IN PACKED EXCESS-3 |
| :---: | :---: | :---: |
| MAIN2: | XOR, RFA(4), RFB(4), $\mathrm{RFC}(4)$ | ; CLEAR R4 |
| MAIN3: | SET1, RFB(40), RDC(2), RFA(D), MSH, LSH | ; GENERATE HEXADECIMAL ; 2D2D16 |
| MAIN4: | MOVE, RFA(0), RFC(2), JSR(UNPACK) | ; COPY RFA(0) INTO RFA(2), ; PROCEDURE CALL |
| MAIN5: | MOVE, RFA(2), RFC(1) | ; TWO CHARACTERS IN R1 |
| MAIN6: | ADDRS, $\mathrm{RFB}(0), \mathrm{RFA}(0), \mathrm{RFC}(0), \mathrm{SLC}$ | RO SHIFTED 2 |
| MAIN7: | ADDRS, RFB(0), RFA (0), RFC(0), SLC | ; RO SHIFTED 4 |
| MAIN8: | ADDRS, RFB(0), RFA(0), RFC(0), SLC | ; RO SHIFTED 6 |
| MAIN9: | ADDRS, $R F B(0), \operatorname{RFA}(0), \operatorname{RFC}(0), S L C$ JSR (UNPACK) | ; RO SHIFTED 8 |
| MAIN10: | STORE, RFA(1) | ; STORE USASCII, TWO <br> ; CHARACTERS IN R2 |
| MAIN11: | STORE, RFA(2) | ; STORE USASCII |
| UNPACK1: | SETO, RFB(2), RFC(F), MSH | CLEAR MSH |
| UNPACK2: | ADDRS, RFB(2), RFA(2), RFC(3), SLC | ; SHIFT R2 TWO PLACES |
| UNPACK3: | ADDRS, RFB(3), RFA(3), RFC(3), SLC | S SHIFT R3 TWO PLACES |
| UNPACK4: | OR, RFB(2), RFA(3), RFC(2) | ; OR R3 TO R2 |
| UNPACK5: | SETO, RFB(2), RFC(F), RFA(0), LSH, MSH | ; CLEAR MOST SIGNIFICANT 4 <br> ; BITS IN EACH BYTE |
| UNPACK6: | ADDRS, RFB(2), RFB(4), RFC( 2 ), RTS | ; ADD HEX 2D, RETURN |

absolute maximum rating over operating free-air temperature range (unless otherwise noted)

recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS888 |  | SN74AS888 SN74AS888-1 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {¢ }}$ MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{VCC1}=4.5 \mathrm{~V}, \mathrm{H}=-18 \mathrm{~mA}$ |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs except ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I} \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | $V_{C C}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.4 |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  |  | 2.4 |  |  |  |
| ${ }^{1} \mathrm{OH}$ | ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  | 0.1 |  |  | 0.1 | mA |
| VOL | All outputs except $\overline{\mathrm{G}}$ and ZERO | $\mathrm{V}_{\mathrm{CC1}}=4.5 \mathrm{~V}, \mathrm{l}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  | 0.5 |  |  | 0.5 | V |
|  | $\overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OL}}=16 \mathrm{~mA}$ |  | 0.5 |  |  | 0.5 |  |
|  | ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OL}}=48 \mathrm{~mA}$ |  | 0.5 |  |  | 0.5 |  |
| 4 | I/O | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=5.5 \mathrm{~V}$ |  | 0.1 |  |  | 0.1 | mA |
|  | All others | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=7 \mathrm{~V}$ |  | 0.1 |  |  | 0.1 |  |
| $\mathrm{IIH}^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| $\mathrm{IL}^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=0.5 \mathrm{~V}$ |  | -0.4 |  |  | -0.4 | mA |
| $10^{5}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | -30 |  | -112 | mA |
| ${ }^{\text {ICC1 }}$ |  | $\mathrm{VCC1}=5.5 \mathrm{~V}$ |  | 150 |  |  | 130 | mA |
| ICC2 |  | $\mathrm{VCC} 2=2.1 \mathrm{~V}$ |  | 410 |  |  | 390 | mA |

[^32]SN54AS888 maximum switching characteristics, $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T} \mathrm{C}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) ${ }^{\text {P }}$ |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $C_{n+8}$ | $\overline{\mathbf{G}}, \overline{\mathbf{P}}$ | $z^{\dagger}$ | N | OVR | DA | DB | Q10 | $\overline{\mathrm{SIO}}$ |  |
| $t_{p d}$ | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 62 | 42 | 48 | 69 | 62 | 60 | 18 | 18 | 65 | 66 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 47 | 28 | 28 | 58 | 50 | 42 | - | - | 50 | 50 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 25 | 14 | - | 32 | 24 | 18 | - | - | 32 | 32 |  |
|  | $\overline{E A}$ | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | $\overline{\mathrm{EB}}$ | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | 17-10 | 58 | 32 | 32 | 62 | 52 | 41 | - | - | 58 | 58 |  |
|  | $\overline{\mathrm{OEB}}$ | - | - | - | - | - | - | - | 14 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 14 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{QIO}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | - | - | - | - | - | - |  |
|  | $\mathrm{SIO}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | 22 | - | - | - | - | - |  |
|  | CK | 68 | 60 | 56 | 62 | 50 | 68 | 38 | 38 | 70 | 70 |  |
|  | $\overline{O E A}$ | - | - | - | - | - | - | 14 | - | - | - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 14 | - | - | - | - |  |

$\dagger$ Load resistor R1 $=100 \Omega$.
$\ddagger$ For byte instructions only.
NOTE 1:-Load circuit and voltage waveforms are shown in Section 1.

SN74AS888 maximum switching characteristics, $\mathrm{V} C \mathrm{C}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{TA}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM <br> (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $C_{n+8}$ | $\overline{\mathrm{G}}, \overline{\mathbf{P}}$ | $z^{\dagger}$ | N | OVR | DA | DB | $\overline{\mathrm{OLO}}$ | $\overline{\text { SIO }}$ |  |
| $t_{p d}$ | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 54 | 36 | 42 | 60 | 52 | 50 | 18 | 18 | 58 | 58 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 44 | 26 | 26 | 52 | 46 | 38 | - | - | 44 | 44 |  |
|  | $\mathrm{C}_{n}$ | 25 | 8 | - | 32 | 24 | 18 | - | - | 31 | 31 |  |
|  | EA | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | $\overline{\mathrm{EB}}$ | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | 17-10 | 55 | 30 | 30 | 60 | 49 | 39 | - | - | 54 | 54 |  |
|  | $\overline{\mathrm{OEB}}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{QIO}}(n)$ <br> Shift | 15 | - | - | 24 | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{SiO}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | 19 | - | -- | - | - | - |  |
|  | CK | 58 | 55 | 52 | 61 | 52 | 62 | 35 | 35 | 60 | 60 |  |
|  | $\overline{\mathrm{OEA}}$ | - | - | - | - | - | - | 12 | - | - | - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 12 | - | - | - | - |  |

$\dagger_{\text {Load resistor }} \mathrm{R} 1=100 \Omega$.
$\ddagger$ For byte instructions only.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

SN74AS888-1 maximum switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $\mathrm{C}_{\mathrm{n}+8}$ | $\overline{\mathbf{G}}, \overline{\mathbf{P}}$ | $Z^{\dagger}$ | N | OVR | DA | DB | $\overline{\mathrm{QIO}}$ | STO |  |
| ${ }^{t} \mathrm{pd}$ | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 44 | 30 | 36 | 50 | 44 | 44 | 17 | 17 | 48 | 48 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DB0 } \end{aligned}$ | 36 | 24 | 24 | 46 | 41 | 32 | - | - | 40 | 40 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 22 | 8 | - | 27 | 21 | 16 | - | - | 25 | 25 |  |
|  | $\overline{E A}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | $\overline{E B}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | 17-10 | 46 | 27 | 27 | 50 | 42 | 35 | - | - | 45 | 45 |  |
|  | $\overline{O E B}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\widehat{\mathrm{QIO}}(\mathrm{n})$ <br> Shift | 14 | - | - | 20 | - | - | - | - | - | - |  |
|  | $\begin{aligned} & \overline{\mathrm{SIO}}(\mathrm{n}) \\ & \text { Shift } \end{aligned}$ | 14 | - | - | 20 | 18 | - | - | - | - | - |  |
|  | CK | 50 | 46 | 46 | 50 | 50 | 50 | 30 | 30 | 50 | 50 |  |
|  | $\overline{\text { OEA }}$ | - | - | - | - | - | - | 12 | - | - | - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 12 | -- | - | - | - |  |

${ }^{\dagger}$ Load resistor R1 $=100 \Omega$.
${ }^{\ddagger}$ For byte instructions only.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
register file write setup and hold times

| PARAMETER |  | SN54AS888 |  | SN74AS888 |  | SN74AS888-1 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{t_{\mathrm{su}}}$ | C3-C0 | 8 |  | 7 |  | 6 |  | ns |
|  | DB§ | 14 |  | 12 |  | 11 |  |  |
|  | 17-14 | 16 |  | 14 |  | 13 |  |  |
|  | $13-10$ | 24 |  | 22 |  | 21 |  |  |
|  | $\overline{\text { OEY }}$ | 4 |  | 3 |  | 3 |  |  |
|  | Y7-Y0 | 2 |  | 2 |  | 2 |  |  |
|  | WE | 8 |  | 6 |  | 6 |  |  |
|  | $\overline{\mathrm{OLO}}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 6 |  | 5 |  | 5 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |
| $t_{\text {h }}$ | C3-C0 | 0 |  | 0 |  | 0 |  | ns |
|  | DB§ | 0 |  | 0 |  | 0 |  |  |
|  | 17-14 | 0 |  | 0 |  | 0 |  |  |
|  | 13.10 | 0 |  | 0 |  | 0 |  |  |
|  | $\overline{\mathrm{OEY}}$ | 6 |  | 5 |  | 5 |  |  |
|  | Y7-Y0 | 10 |  | 10 |  | 10 |  |  |
|  | WE | 3 |  | 2 |  | 2 |  |  |
|  | $\overline{\mathrm{O} 1 \mathrm{O}}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 0 |  | 0 |  | 0 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |

§ DB (during select instruction) through $Y$ port.
special instruction switching characteristics
During various special instructions, the SSF pin is used to pass required information between the 'AS888 packages which make up a total system.

For instance, during the multiplication process, the LSB of the multiplier determines whether an ADD/SHIFT or SHIFT operation is performed. During multiplication, the SSF pin of the least significant package (LSP) becomes an output pin while all other packages become input pins.

Similarly, during normalization, the required operation depends on whether the two data MSBs are the same or different. Therefore, during normalization the SSF pin of the most significant package (MSP) becomes an output pin while all other packages become input pins.

Tables 10, 11, and 12 list the instructions which force the SSF pin during their execution. The propagation delay from various inputs is also shown. The parameter which limits normal system performance is indicated by a dagger.

TABLE 10. SN54AS888 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP <br> TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LSP | MSP | $\mathrm{C}_{\mathrm{n}}$ | I n ) | CK | $B_{(n)}$ |  |
| CRC | 00 | X |  | - | 29 | 58 | $40^{\dagger}$ | 20 |
| SNORM | 20 |  | $x$ | - | $29^{\dagger}$ | 46 | - | 20 |
| DNORM | 30 |  | $x$ | - | 29 | 55 | $40^{\dagger}$ | 20 |
| DIVRF | 40 |  | $x$ | - | $29^{\dagger}$ | 46 | - | 20 |
| SDIVAF | 50 |  | X | - | $26^{\dagger}$ | - | - | 18 |
| SMULI | 60 | $x$ |  | - | $26^{\dagger}$ | 43 | - | 0 |
| SDIVIN | 80 |  | $x$ | - | 48 | 64 | $44^{\dagger}$ | 0 |
| SDIVIS | 90 |  | $x$ | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| SDIVI | AO |  | X | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| UDIVIS | B0 |  | $x$ | $18^{\dagger}$ | 45 | 64 | 46 | 0 |
| UDIVI | CO |  | X | $18^{\dagger}$ | 50 | 54 | 40 | 0 |
| UMULI | DO | $x$ |  | - | $25^{\dagger}$ | 48 | -- | 0 |
| SDIVIT | EO |  | $x$ | $26^{\dagger}$ | 50 | 56 | 54 | 0 |
| ABX | 48 |  | $x$ | - | 34 | 62 | $39^{\dagger}$ | 20 |
| SMTC | 58 |  | $x$ | - | 29 | 58 | $39^{\dagger}$ | 20 |
| BINEX3 | DF |  | $x$ | - | $29^{\dagger}$ | 58 | - | 18 |
| LOADMQ (Arith) |  | $x$ |  | $23^{\dagger}$ | 34 | 62 | 40 | 0 |
| LOADMO (Log) |  | X |  | - | 33 | 62 | $40^{\dagger}$ | 0 |
| BADD | 88 |  |  | $18^{\dagger}$ | 58 | 62 | 49 | - |
| BSUBS | 98 |  |  | $18^{\dagger}$ | 58 | 62 | 49 | - |
| BSUBR | A8 |  |  | $18^{\dagger}$ | 58 | 71 | 49 | - |
| BINCS | B8 |  |  | $18^{\dagger}$ | 58 | 60 | 49 | - |
| BINCNS | C8 |  |  | $18^{\dagger}$ | 58 | 71 | 49 | - |
| BXOR | D8 |  |  | - | 58 | - | - | - |
| BAND | E8 |  |  | - | 58 | - | - | - |
| BOR | F8 |  |  | - | 58 | - | - | - |
| EX3BC | 8F |  |  | - | 58 | 46 | $49^{\dagger}$ | - |

[^33]SN54AS888, SN74AS888 8-BIT PROCESSOR SLICES

TABLE 11. SN74AS888 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | $\begin{gathered} \text { SSF SETUP } \\ \text { TIME (ns) } \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LSP | MSP | $\mathrm{c}_{n}$ | ${ }_{\text {( }}^{\text {n }}$ ) | CK | $\mathrm{B}_{(\mathrm{n})}$ |  |
| CRC | 00 | X |  | - | 26 | 52 | $37^{\dagger}$ | 17 |
| SNORM | 20 |  | $x$ | - | $26^{\dagger}$ | 40 | - | 17 |
| DNORM | 30 |  | x | - | 26 | 52 | $37^{\dagger}$ | 17 |
| DIVRF | 40 |  | x | - | $26^{\dagger}$ | 40 | - | 17 |
| SDIVOF | 50 |  | x | - | $25^{\dagger}$ | - | - | 17 |
| SMULI | 60 | x |  | - | $25^{\dagger}$ | 40 | - | 0 |
| SDIVIN | 80 |  | $x$ | - | 38 | 60 | $40^{+}$ | 0 |
| SDIVIS | 90 |  | x | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| SDIVI | AO |  | x | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| udivis | Bо |  | $x$ | $17^{\dagger}$ | 43 | 60 | 45 | 0 |
| UDIVI | co |  | x | $17^{\dagger}$ | 44 | 52 | 37 | 0 |
| UMULI | Do | x |  | - | $26^{\dagger}$ | 40 | - | 0 |
| SDIVIT | EO |  | $x$ | $25^{\dagger}$ | 46 | 52 | 49 | 0 |
| ABX | 48 |  | $x$ | - | 32 | 60 | 38 | 17 |
| SMTC | 58 |  | x | - | 26 | 52 | $38^{\dagger}$ | 17 |
| BINEX3 | DF |  | x | - | $26^{\dagger}$ | 40 | - | 17 |
| LOADMO (Arith) |  | $x$ |  | $22^{\dagger}$ | 32 | 50 | 38 | 0 |
| LOADMO (Log) |  | $\times$ |  | - | 32 | 50 | $38^{\dagger}$ | 0 |
| BADD | 88 |  |  | $17^{\dagger}$ | 52 | 55 | 46 | - |
| BSUBS | 98 |  |  | $17{ }^{\dagger}$ | 52 | 55 | 46 | - |
| BSUBR | A8 |  |  | $17{ }^{\dagger}$ | 52 | 62 | 46 | - |
| BINCS | B8 |  |  | $17{ }^{\dagger}$ | 52 | 55 | 46 | - |
| BINCNS | C8 |  |  | $17{ }^{\dagger}$ | 52 | 62 | 46 | - |
| BXOR | D8 |  |  | - | 52 | - | - | - |
| BAND | E8 |  |  | -- | 52 | - | - | - |
| BOR | F8 |  |  | - | 52 | - | - | - |
| EX3BC | 8 F |  |  | - | 45 | 45 | $46^{\dagger}$ | - |

[^34]TABLE 12. SN74AS888-1 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | HEX | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | CODE | LSP | MSP | $\mathrm{C}_{\mathrm{n}}$ | '(n) | СК | $\mathrm{B}_{(\mathrm{n})}$ |  |
| CRC | 00 | X |  | - | 23 | 42 | $34^{\dagger}$ | 14 |
| SNORM | 20 |  | $x$ | - | $23^{\dagger}$ | 28 | - | 14 |
| DNORM | 30 |  | x | - | 23 | 40 | $34^{\dagger}$ | 14 |
| DIVRF | 40 |  | X | - | $23^{\dagger}$ | 27 | - | 14 |
| SDIVQF | 50 |  | x | - | $23^{\dagger}$ | - | - | 14 |
| SMULI | 60 | x |  | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIN | 80 |  | $x$ | - | 35 | 46 | $35^{\dagger}$ | 0 |
| SDIVIS | 90 |  | x | $22^{\dagger}$ | 42 | 48 | 42 | 0 |
| SDIVI | AO |  | X | $22^{\dagger}$ | 42 | 46 | 42 | 0 |
| UDIVIS | во |  | x | $16^{\dagger}$ | 42 | 46 | 38 | 0 |
| UDIVI | co |  | x | $16^{\dagger}$ | 36 | 46 | 34 | 0 |
| UMULI | DO | $x$ |  | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIT | EO |  | $x$ | $21^{\dagger}$ | 40 | 44 | 42 | 0 |
| ABX | 48 |  | x | - | 28 | 46 | $30^{\dagger}$ | 14 |
| SMTC | 58 |  | X | - | 24 | 44 | $30^{\dagger}$ | 14 |
| BINEX3 | DF |  | x | - | $23^{\dagger}$ | 27 | - | 14 |
| LOADMO (Arith) |  | $x$ |  | $19^{\dagger}$ | 28 | 40 | 30 | 0 |
| LOADMO (Log) |  | X |  | - | 28 | 35 | $30^{\dagger}$ | 0 |
| BADD | 88 |  |  | $16^{\dagger}$ | 42 | 42 | 40 | - |
| BSUBS | 98 |  |  | $16^{\dagger}$ | 42 | 40 | 40 | - |
| BSUBR | A8 |  |  | $16^{\dagger}$ | 42 | 50 | 40 | - |
| BINCS | B8 |  |  | $16^{\dagger}$ | 42 | 46 | 40 | - |
| BINCNS | C8 |  |  | $16^{\dagger}$ | 42 | 54 | 42 | - |
| BXOR | D8 |  |  | - | 42 | - | - | - |
| BAND | E8 |  |  | - | 42 | - | _ | - |
| BOR | F8 |  |  | - | 42 | - | - | - |
| EX3BC | 8F |  |  | - | 42 | 42 | $42^{\dagger}$ | - |

[^35]- 14 Bits Wide-Addresses up to 16,384 Words of Microcode with One Chip
- Selects Address from One of Eight Sources
- STL-AS Technology
- Independent Read Pointer for Aid in Microcode Diagnostics
- Supports Real-Time Interrupts
- Two Independent Loop Counters
- Supports 64 Powerful Instructions
- Dependable Texas Instruments Quality and Reliability


## description

The 'AS890 is a powerful microsequencer that is the result of the implementation of $\mathrm{TI}^{\prime} \mathrm{s}$ Advanced Schottky and Schottky Transistor Logic. Approximately 2400 Schottky gate equivalents are used to construct this highperformance sequencer. The 'AS890 can generate an address and provide register status in only 29 ns while typically requiring only 1.8 watts of power. All internal STL logic in these devices operates on a 2 -volt power supply that must be supplied externally. The information generated by the internal STL logic is communicated in the rest of the system via 5-volt Advanced Schottky TTL-compatible I/O ports.

The microsequencers select a 14-bit microaddress from one of eight sources to provide the proper microinstruction sequence for bit-slice processor or other microcode based systems. These high-performance devices are capable of addressing 16,384 control store memory locations either sequentially or via conditional branching algorithms. This multiway branching capability, coupled with a nine-word deep FILO (first in, last out) stack, allows the microprogrammer to arrange his code in blocks so that microprograms may be structured in the same fashion as such high-level languages as ALGOL, Pascal, or Ada.

Both polled and real-time interrupt routines are supported by the 'AS890 to enhance system throughput capability. Vectored interrupts may occur during any instruction, including PUSHes and POPs.

SN74AS890 . . . GB PACKAGE
(TOP VIEW)


AS890

| PIN, |  | PIN |  | PIN |  | PIN |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| NO. | NAME | No. | NAME | No. | NAME | NO. | NAME |
| A. 2 | DRE10 | B. 9 | STKWRN:RER | F. 10 | $\mathrm{V}_{\mathrm{CC1}}$ | K.4 | DRA13 |
| A. 3 | DR89 | B-10 | zero | F.11 | MUX2 | K. 5 | DRA11 |
| A. 4 | DRB8 | B. 11 | CK | G. 1 | Y5 | K-6 | DRAB |
| A. 5 | DRE7 | C. 1 | Y 13 | G. 2 | YOE | K. 7 | DRA7 |
| A. 6 | DRB6 | C. 2 | Y 10 | G. 10 | RC1 | K 8 | DRAO |
| A. 7 | DRB5 | C. 10 | $\overline{\mathrm{CC}}$ | G. 11 | MUX1 | K. 9 | DRA1 |
| A. 8 | DRB4 | C. 11 | S1 | H. 1 | Y4 | K. 10 | DRA3 |
| A. 9 | DR83 | D. 1 | Y12 | H. 2 | Y6 | K. 11 | DRA2 |
| A. 10 | DRB 1 | D-2 | Y9 | H-10 | B0 | L. 2 | B2 |
| B. 1 | DRB13 | D10 | S2 | H-11 | MUXO | L. 3 | INC |
| B. 2 | INT | D. 11 | So | J. 1 | Y3 | L. 4 | DRA12 |
| B. 3 | DRB12 | E. 1 | V11 | $\checkmark 2$ | Y2 | L. 5 | DRA10 |
| B. 4 | DRB11 | E. 2 | Y8 | J. 10 | RC2 | L. 6 | dra9 |
| B-5 | 83 | E. 10 | $\mathrm{V}_{\mathrm{CC} 2}$ | J. 11 | OSEL | L-7 | $\widehat{\text { RAOE }}$ |
| B. 6 | $\overline{\text { RBOE }}$ | E. 11 | RCO | K-1 | Y1 | L. 8 | dra6 |
| 8.7 | DRB2 | F. 1 | Y7 | K-2 | Yo | 1.9 | DRA5 |
| B. 8 | DRBO | F 2 | GND | K. 3 | B1 | L 10 | DRA4 |

SN54AS890 . . . FD PACKAGE SN74AS890 . . . FN PACKAGE
(TOP VIEW)


## functional block diagram


pin descriptions

| PIN NAME | 1/0 | PIN FUNCTION |
| :---: | :---: | :---: |
| $\overline{\text { RAOE }}$ | In | Enables DRA output, active low |
| DRA6-DRAO | In/Out | Seven LSBs of the A direct data l/O port |
| OSEL | In | MUX control for the source to DRA. Low selects RA, high selects stack. |
| MUX2-MUXO | In | MUX control for Y output bus (see Table 1) |
| RC2-RCO | In | Register/counter controls (see Table 3) |
| S2.S0 | In | Stack control (see Table 2) |
| $\stackrel{\rightharpoonup}{\text { CC }}$ | In | Condition code |
| $\mathrm{v}_{\mathrm{CC} 1}$ |  | 5 -volt supply for TTL compatible I/O |
| $\mathrm{V}_{\mathrm{CC} 2}$ |  | 2-volt supply for internal STL |
| CK | In | Clock |
| zero | Out | Zero detect flag for register A and B |
| STKWRN/RER | Out | Stack overflow, underflow/read error flag |
| DRB6-DRBO | In/Out | Seven LSBs of the B direct data $\mathrm{I} / \mathrm{O}$ port ( $0=$ LSB) |
| RBOE | In | Enables DRB output, active low |
| DRB13-DRB7 | In/Out | Seven MSBs of the B direct data I/O port |
| INT | In | Active low selects INT RT register to stack |
| Y13-Y8 | In/Out | Six MSBs of bidirectional Y port |
| GND |  | Ground |
| Y7 | In/Out | Seventh bit of bidirectional Y port |
| YOE | In | Enables $Y$ output bus, active low |
| Y6-Yo | In/Out | Seven LSBs of bidirectional $Y$ port ( $0=$ LSB) |
| INC | In | Incrementer control |
| DRA13-DRA7 | In/Out | Seven MSBs of direct B data I/O port |
| B3-B0 | In | 16 -way branch inputs on |

## description (continued)

Two 14-bit loadable registers/counters may be used for temporary storage of data or utilized as down counters for repetitive instructions such as multiplication and division or as loop counters when iterative routines are required.

An additional feature is a 24-bit port that appends four user-definable bits to the DRA or DRB address value for support of 16 -way branches for the execution of relative branch addressing schemes.

## Y output multiplexer

The $Y$ output multiplexer of the 'AS890 is capable of selecting the next branch address from one of eight locations. Addresses may be sourced from:

1. The top of the 14 -bit by 9 -word address stack
2. An external input on the DRA port, potentially a pipeline register
3. An external input on the DRB port, potentially a pipeline register
4. Internal register/counter. $A$
5. Internal register/counter $B$
6. An internal microprogram counter (MPC register)
7. An external input onto the bidirectional $Y$ output port
8. A 16 -way branch -4 bits appended to DRA, DRB, register/counter $A$ or register/counter B.

The source of the next address is dependent upon the previous state of the microsequencer, the MUX controls (MUX2-MUXO), the condition code ( $\overline{C C}$ ) input, and the state of an internal status flag (status externally available at the ZERO output) that indicates that one of the on-chip registers is being decremented to zero.

The entire instruction set may be made conditional by manipulation of the condition code ( $\overline{\mathrm{CC}})$ input. Allowing the $\overline{\mathrm{CC}}$ value to vary as a result of data or status provides for state-dependent or data-dependent branching. Unconditional branches may be achieved by forcing $\overline{\mathrm{CC}}$ high when selecting control store addresses. Holding this pin low will provide for conditional or unconditional branches as dictated by the state of the zero-detect flag. The required control signals for selection of the Y output source are listed in Table 1. Note that the dependence of the 'AS890 on two variables for conditional branches and jumps allows a conditional branch or conditional jump to subroutine in any clock cycle. Also note that all multiplexer inputs are overridden when all of the stack control inputs are pulled low. This instruction resets the stack and read pointers to zero and places all lines of the $Y$ output bus at the low level.

TABLE 1. Y OUTPUT CONTROL

|  | MUX CONTROL |  |  | RESET* | Y OUTPUT SOURCE |  | Y OUTPUT SOURCE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MUX2 | MUX1 | MUXO |  | $\text { ZERO }=\mathbf{L}$ | $\text { ZERO }=\mathrm{H}$ | $\overline{\mathbf{c c}}=\mathbf{H}$ |
| 2 | X | X | X | YES | ALL LOW | ALL LOW | ALL LOW |
|  | L | L | L | NO | STK | MPC | DRA |
|  | L | L | H | No | STK | MPC | DRB |
| $\boldsymbol{O}$ | L | H | L | NO | STK | DRA | MPC |
|  | L | H | H | NO | STK | DRB | MPC |
| 0 | H | L | L | NO | DRA | MPC | DRB |
| (1) | H | L | H | NO | DRA' (16-WAY BRANCH) | MPC | DRB' (16-WAY BRANCH) |
| $\leq$ | H | H | L | No | DRA | STK | MPC |
| $\underset{\mathbf{D}}{\mathbf{Q}}$ | H | H | H | NO | DRB | STK | MPC |



[^36]
## 14-bit by 9 -word address stack

The positive-edge-triggered 14 -bit address stack supplies on-board storage of nine control store addresses that support up to nine nested levels of microsubroutine, looping, and real-time interrupt functions. The stack pointer (SP), which operates as an up-down counter, is updated after the execution of each PUSH operation and before each POP. In a PUSH operation, the address stored in the MPC register is loaded into the stack location addressed by the stack pointer, and the stack pointer is incremented. This address is available at the DRA port by enabling DRA ( $\overline{R A O E}$ low and OSEL high).
A POP operation causes the stack pointer to be decremented on the first rising clock edge following the arrival of the POP instruction at the S2-SO pins. The value that was indexed by the stack pointer is effectively removed from the top of the stack. All PUSH and POP instructions are conditionally dependent upon the stack control inputs (S2-SO), the condition code ( $\overline{\mathrm{CC}}$ ), the input value, and the zero-detect status. The desired option may be selected using the stack control inputs listed in Table 2.

TABLE 2. STACK CONTROL

| STACK CONTROL |  |  | STACK OPERATION, $\overline{\mathrm{CC}}=\mathrm{L}$ |  |  | $\overline{\mathrm{CC}}=\mathrm{H}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| S2 | S1 | So | OSEL | ZERO $=\mathrm{L}$ | ZERO $=\mathrm{H}$ |  |
| L | L | L | X | RESET/CLEAR | RESET/CLEAR | RESET/CLEAR |
| L | L | H | $x$ | CLEAR SP, RP | HOLD | HOLD |
| L | H | L | $x$ | HOLD | POP | POP |
| L | H | H | $x$ | POP | HOLD | HOLD |
| H | L | L | $x$ | HOLD | PUSH | PUSH |
| H | L | H | $x$ | PUSH | HOLD | HOLD |
| H | H | L | X | PUSH | HOLD | PUSH |
| H | H | H | H | READ | READ | READ |
| H | H | H | L | HOLD | HOLD | HOLD |

The read pointer (RP) is a useful tool in debugging microcoded systems. A microprogrammer now has the ability to perform a nondestructive, sequential read of the stack contents from the DRA port. This capability provides the user with a method of backtracking through the address sequence to determine the cause of overflow without affecting program flow, the status of the stack-pointer or the internal data of the stack. Placing a high value on all of the stack inputs (S2-SO) and OSEL places the 'AS890 into the read mode. At each low-to-high clock transition, the value pointed to by the read pointer is available at the DRA port and the read pointer is decremented. Microcode diagnostics are simplified by the ability of the 'AS890 to sequentially dump the contents of its stack. The bottom of the stack is detected by monitoring the STKWRN/RER (stack warning/read error) pin. A high will appear when the stack contains one word and a READ instruction is applied to the S2-S0 pins. This signifies that the last address has been read. The stack pointer and stack contents are uneffected by the READ operation. Under normal PUSH and POP operations the read pointer is updated with the stack pointer and contains identical information.

The STKWRN/RER pin alerts the system to a potential stack overflow or underflow condition. STKWRN/RER becomes active under two additional conditions. If seven of the nine stack locations ( $0-8$ ) are full (the stack pointer is at 7) and a PUSH occurs, the STKWRN/RER pin will produce a high-level signal to warn that the stack is approaching its capacity, and will be full after one more PUSH. Knowledge that overflow potential exists allows bit-slice-based systems to continuously process real-time interrupt vectors. This signal will remain high, if HOLD, PUSH, or POP instructions occur, until the stack pointer is decremented to 7.

The user may be protected from attempting to POP an empty stack by monitoring STKWRN/RER before POP operations. A high level at this pin signifies that the last address has been removed from the stack $(S P=0)$. This condition remains until an address is pushed onto the stack and the stack pointer is incremented to one.
Clearing the stack and read pointer is accomplished by placing low levels onto the stack control lines (S2-SO). This function overrides all of the $Y$ output MUX controls and places the $Y$ bus into a low state.

## SN54AS890, SN74AS890 MICROSEQUENCERS

## register/counters

Two loadable 14-bit registers extend the looping and branching capabilities. Addresses may be loaded directly into register/counter $A(R A)$ and register/counter $B$ (RB) through the direct data ports DRA13-DRA0 and DRB13-DRB0. The values stored in these registers may either be held, decremented, or read as a result of the register control inputs ( $\mathrm{RC} 2-\mathrm{RCO}$ ), $\overline{\mathrm{RAOE}}$, and $\overline{\mathrm{RBOE}}$. All combinations of these functions are supported with the exception of a simultaneous decrement of both registers. Generation of iteration routines may be accomplished by loading RA and/or RB and operating them as a down counter. Loop termination is acknowledged by the ZERO output going high to indicate that a register contains a binary one and that a decrement is about to take place. Because of this facility, a "decrement and branch on loop" termination may be executed in the same clock cycle.

The contents of RA are accessible to the DRA port when OSEL is low and the output bus is enabled by RAOE being low. Data from RB is available when DRB is enabled by $\overline{R B O E}$ being low. Note that control of the registers is maintained while an external value is active on the DRA and DRB ports. A value being directed from the DRA and DRB buses to the output will not inhibit the decrement operation.

Register/counter controls are listed in Table 3.
TABLE 3. REGISTER CONTROL

| RC2 | RC1 | RCO | REG A | REG B |
| :---: | :---: | :---: | :---: | :---: |
| L | L | L | HOLD | HOLD |
| L | L | H | DEC | HOLD |
| L | H | L | LOAD | HOLD |
| L | H | H | DEC | LOAD |
| H | L | L | LOAD | DEC |
| H | L | H | HOLD | LOAD |
| H | H | L | HOLD | DEC |
| H | H | H | LOAD |  |

microprogram register and increment
The microprogram register (MPC) and the incrementer (INC) provide the means for generating the next microprogram address for sequential addressing operations. The MPC may be loaded with either the outgoing address on the $Y$ bus or may receive an external address for processing interrupt vectors.

The current address on the Y bus is passed to the MPC at each rising clock edge, either unaltered (INC low) for repeating statements, or incremented by one (INC high) for addressing sequential control store locations.

The MPC may also be externally loaded for subroutine and interrupt functions. Taking $\overline{\text { YOE }}$ high and forcing the new address onto the bidirectional Y bus loads the MPC with the new address at the positive clock edge. This value may also be incremented prior to storage in the MPC for sequential addressing of subroutines or interrupt routines.

## interrupts

Real-time vectored interrupt routines are supported for those applications where polling would impede system throughput. Any instruction, including PUSHes and POPs, may be interrupted. To process an interrupt, the following procedure should be followed:

1. The bidirectional $Y$ bus is placed into the high-impedance state by forcing $\overline{Y O E}$ high.
2. The interrupt entry point vector is then forced onto the $Y$ bus and incremented to become the second microinstruction of the interrupt routine. This is accomplished by making INC high.
3. At the following clock edge, the second microaddress is stored in the MPC and the interrupted address will be stored in the INT RT register which always contains the outgoing value on the Y bus. This edge also causes the processor to begin execution of the first instruction of the interrupt routine. This first instruction must PUSH the address stored in the INT RT register onto the stack so that the proper return linkage is maintained. This is accomplished by making INT low and performing a PUSH. If this instruction were to be interrupted, the process would be repeated and the proper return linkage preserved.

## control inputs

A listing of the response of internal elements to various control inputs is given in Table 4.

TABLE 4. RESPONSE TO CONTROL INPUTS

| PIN NAME | LOGIC LEVEL |  |
| :---: | :---: | :---: |
|  | HIGH | LOW |
| $\overline{R B O E}$ | DRA output in high-Z state | DRA output is active |
| $\overline{\text { YOE }}$ | DRB output in high-Z state | DRB output is active |
| $\overline{\text { INT }}$ | Y output in high-Z state | Y output is active |
| OSEL | MPC to stack | INT RT register to stack |
| INC | Stack to DRA butfer input | RA to DRA buffer input |
| MUX2-MUXO | Adds one to Y output and stores in MPC | Passes Y output to MPC unaltered |
| S2-SO | Table 1 | Table 1 |
| RC2-RCO | Table 2 | Table 2 |

## instruction set

Sixty-four microsequencing instructions enable the 'AS890 to generate micro-addresses for up to 16,384 locations. Any instruction can be made conditional depending upon the value of the externally applied condition code ( $\overline{\mathrm{CC}}$ ) and the value stored in either of the internal register/counters.

The required signals for selection of the $Y$ output source were listed in Table 1. Suggested methods for implementing a few commonly used instructions are given in Table 5 and flowcharts showing execution examples are illustrated in Figure 1.

It should be noted that the term jump refers to a subroutine call that must be accompanied by a return instruction. The term branch implies that a deviation from the program flow is accomplished but no return is required.
table 5. SUGgested Coding for representative instructions

| FUNCTION | MNEMONIC | MUX2 | MUX1 | muxo | S2 | S1 | so | $\overline{\mathrm{CC}}$ | FIGURE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Continue | CONT | X | H | $\times$ | H | H | H | H | 1 (a) |
| Unconditional branch | BR | L | L | X | H | H | H | H | 1 (b) |
| Conditional branch | CBR | H | H | X | H | H | H | V | 1 (c) |
| Three-way branch | BR2W | H | L | L | H | H | H | V | 1 (d) |
| Conditional loop on stack | LOOPS | L | L | x | L | H | L | L | 1 (e) |
| Repeat | REPEAT | L | L | $x$ | H | H | H | L. | 1 (f) |
| Loop on stack with exit | LSWE | L | L | x | L | H | L | $v$ | 1 (g) |
| Conditional jump to subroutine | CJSR | H | H | x | H | L | H | V | 1 (h) |
| Jump to subroutine | JSR | L | L | X | H | L | H | H | 1 (i) |
| Two-way jump to subroutine | JSR2W | H | L | L | H | H | 1 | V | 1 (j) |
| Repeat until | UNTIL | L | H | X | L | H | L | V | 1(k) |
| Return from subroutine | RTS | L | H | x | L | H | H | L | 1 (1) |
| Conditional return from subroutine | CRTS | L | H | x | L | H | H | $v$ | 1 (m) |
| Conditional return from subroutine or branch | CRTSB | L | H | X | L | H | H | v | 1 (n) |
| Conditional branch and PUSH | CBRP | H | H | x | H | L | H | $v$ | 1 (o) |
| Conditional branch and POP | CBRPO | H | H | x | L | H | H | v | 1 (p) |
| PUSH and continue | PUSH | L | H | x | H | L | L | H | 1 (q) |
| POP and continue | POP | x | H | x | L | H | L | H | 1 (r) |
| Exit from loop | EXITLP | L | L | x | L | H | L | $v$ | 1(s) |
| Reset and clear stack/read pointer | RESET | X | X | x | L | L | L | x | 1 (t) |
| 32-way branch | BR32W | H | L | H | H | H | H | $\checkmark$ | 1 (u) |
| Execute n times | NEX | L | L | x | L | H | L | L | 1(v) |

[^37]

NOTE 1: $\overline{\mathrm{CC}}$ and ZERO are completed in the same clock cycle.
FIGURE 1. INSTRUCTION SET FLOWCHARTS

(g) CONDITIONAL LOOP ON STACK WITH EXIT (DEC ENABLED) ${ }^{1}$

NOTE 1: $\overline{\mathrm{CC}}$ and ZERO are completed in the same clock cycle.
FIGURE 1. INSTRUCTION SET FLOWCHARTS (continued)


FIGURE 1. INSTRUCTION SET FLOWCHARTS (continued)

(m) CONDITIONAL RETURN FROM SUBROUTINE (DEC DISABLED)

(o) CONDITIONAL BRANCH AND PUSH (DEC DISABLED)

(n) CONDITIONAL RETURN FROM SUBROUTINE OR BRANCH (DEC ENABLED) ${ }^{1}$

(p) CONDITIONAL BRANCH AND POP (DEC DISABLED)

NOTE 1: $\overline{\mathrm{CC}}$ and ZERO are completed in the same clock cycle.
FIGURE 1. INSTRUCTION SET FLOWCHARTS (continued)


NOTE 1: $\overline{\mathrm{CC}}$ and ZERO are completed in the same clock cycle.
FIGURE 1. INSTRUCTION SET FLOWCHARTS (continued)


NOTES: 1. $\overline{C C}$ and ZERO are completed in the same clock cycle.
2. The least significant four bits, DRA and DRB, will he stripped off and four new hits appended to them from the B3-BO port.

FIGURE 1. INSTRUCTION SET FLOWCHARTS (concluded)
absolute maximum ratings over operating temperature range (unless otherwise noted)

```
Supply voltage, VCC1 . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
```



```
Input voltage: All inputs . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
    I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating case temperature range, SN54AS890 . . . . . . . . . . . . . . . . . . . . . . . . - 55 年C to 125 %}\textrm{C
Operating free-air temperature range, SN74AS890 . . . . . . . . . . . . . . . . . . . . . . . . . . 0 0 C C to 70 % C
Storage temperature range ................................................ . . . . - 65 % C to 150 % C
```

recommended operating conditions

|  |  |  | SN54AS890 |  |  | SN74AS890 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC} 1}$ | 1/O supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{CC} 2}$ | STL internal logic supply voltage |  | 1.9 | 2 | 2.1 | 1.9 | 2 | 2.1 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltge |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High-level output current |  |  |  | -1 |  |  | -2.6 | mA |
| ${ }^{1} \mathrm{OL}$ | Low-level output current | All outputs except Y13-Y0 |  |  | 8 |  |  | 8 | mA |
|  |  | Y13-Y0 |  |  | 12 |  |  | 12 |  |
| $\mathrm{T}_{\mathrm{C}}$ | Operating case temperature |  | -55 |  | 125 |  |  |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {A }}$ | Operating free air temperature |  |  |  |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS890 |  | SN74AS890 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ MAX | MIN | TYP ${ }^{\dagger}$ MAX |  |
| $V_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  | -1.2 |  | -1.2 |  |
| VOH |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$ to 5.5 V . | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  | v |
|  |  | $\mathrm{V}_{\text {CC1 }}=4.5 \mathrm{~V}$. | $1 \mathrm{OH}=-1 \mathrm{~mA}$ | 2.43 .4 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-2.6 \mathrm{~mA}$ |  |  | 2.4 |  |  |
| $V_{\text {OL }}$ | All outputs except Y13-Y0 | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{l}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  | 0.5 |  | 0.5 | V |
|  | Y13-Y0 | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$. | $\mathrm{I}_{\mathrm{OL}}=12 \mathrm{~mA}$ |  | 0.5 |  | 0.5 |  |
| 1 | Inputs | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  | 0.1 |  | 0.1 | mA |
|  | 1/O ports | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  | 0.1 |  | 0.1 |  |
| $\mathrm{IIH}^{\text {H }}$ | Inputs | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  | 20 |  | 20 | $\mu \mathrm{A}$ |
|  | I/O ports ${ }^{\ddagger}$ |  |  |  | 40 |  | 40 |  |
| $1 /{ }^{\ddagger}$ |  | $\mathrm{V}_{C C 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -0.4 |  | -0.4 | mA |
| $10^{5}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | -30 | -112 | mA |
| ${ }^{1} \mathrm{CCl}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$ |  |  | 185 |  | 178 | mA |
| ${ }^{\text {I CC2 }}$ |  | $\mathrm{V}_{\mathrm{CC} 2}=2.1 \mathrm{~V}$ |  |  | 420 |  | 400 | mA |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $1 / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include output current $I_{O Z L}$ and $I_{O Z L}$, respectively.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit current, IOS.

SN54AS890 maximum switching characteristics: $\mathrm{V}_{\mathrm{CC}} 1=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=1.9 \mathrm{~V}$ to 2.1 V , $\mathrm{T} \mathrm{C}=55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ (see Note 2)

$\dagger$ Decrementing Register/Counter A or B and sensing a zero.
NOTE 2: Load circuit and voltage waveforms are shown in Section 1
SN54AS890 setup and hold times

| PARAMETER | FROM | TO (DESTINATION) | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {su }}$ | $\overline{\mathrm{CC}}$ | Stack | 10 |  | ns |
|  | DRA13-DRAO | RCA, INT RT | 5 |  |  |
|  | DRB13-DRB0 | RCB, INT RT | 5 |  |  |
|  | INC | MPC | 10 |  |  |
|  | $\overline{\text { INT }}$ | Stack | 10 |  |  |
|  | RC2-RCO | Stack | 16 |  |  |
|  |  | RCA, RCB | 10 |  |  |
|  |  | INT RT | 14 |  |  |
|  | S2-50 | Stack | 10 |  |  |
|  |  | INT RT | 10 |  |  |
|  | MUX2-MUX0 | INT RT | 14 |  |  |
|  | B3-80 | INT RT | 14 |  |  |
|  | Y13-Y0 | MPC | 12 |  |  |
| th | Any Input | Any Destination | 2 |  |  |

SN54AS890 minimum clock requirements (see Note 3)

| PARAMETER |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $t_{\text {wL }}$ (CK) | Pulse duration, clock low | 10 |  | ns |
| $\mathrm{t}_{\mathrm{wH}}$ (CK) | Pulse duration, clock high | 20 |  |  |
| ${ }^{\text {c }}$ (CK) | Clock cycle time | $55^{\dagger}$ |  |  |
|  |  | 45 |  |  |

${ }^{\dagger}$ Decrementing Register/Counter A or B and sensing a zero.
NOTE 3: The total clock period of clock high and clock low must not be less than clock cycle time. The minimum pulse durations specified are only for clock high or clock low. but not for both simultaneously.

SN74AS890 maximum switching characteristics: $\mathrm{VCC1}_{\mathrm{C}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{VCC} 2=1.9 \mathrm{~V}$ to 2.1 V , $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 2)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | ZERO | DRA | DRB | STKWRN |  |
| ${ }^{\text {p }}$ d | $\overline{\mathrm{CC}}$ | 29 |  |  |  |  | ns |
|  | CK | 29 |  | 29 | 29 | 29 |  |
|  |  | $50^{\dagger}$ | $39^{\dagger}$ |  |  |  |  |
|  | DRA13-DRAO | 15 |  |  |  |  |  |
|  | DRB13-DRBO | 15 |  |  |  |  |  |
|  | MUX2-MUXO | 35 |  |  |  |  |  |
|  | RC2-RC0 | 30 | 13 |  |  |  |  |
|  | S2-S0 | 28 |  |  |  |  |  |
|  | B2-B0 | 20 |  |  |  |  |  |
|  | OSEL |  |  | 18 |  |  |  |
| ten | $\overline{\mathrm{Y} O E}$ | 15 |  |  |  |  | ns |
|  | $\widehat{\text { RAOE }}$ |  |  | 15 |  |  |  |
|  | $\overline{\text { RBOE }}$ |  |  |  | 15 |  |  |
| ${ }_{\text {did }}$ | YOE | 16 |  |  |  |  | ns |
|  | $\overline{\text { RAOE }}$ |  |  | 16 |  |  |  |
|  | $\overline{\mathrm{RBOE}}$ |  |  |  | 16 |  |  |

${ }^{\dagger}$ Decrementing Register/Counter A or B and sensing a zero.
NOTE 2: Load circuit and voltage waveforms are shown in Section 1.
SN74AS890 setup and hold times

| PARAMETER | FROM | TO (DESTINATION) | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\text {tsu }}$ | $\overline{\mathrm{CC}}$ | Stack | 10 |  | ns |
|  | DRA13-DRAO | RCA, INT RT | 5 |  |  |
|  | DRB13-DRB0 | RCB, INT RT | 5 |  |  |
|  | INC | MPC | 10 |  |  |
|  | $\overline{\text { INT }}$ | Stack | 10 |  |  |
|  |  | Stack | 14 |  |  |
|  | RC2-RC0 | RCA, RCB | 10 |  |  |
|  |  | INT RT | 12 |  |  |
|  | S2-S0 | Any Destination | 10 |  |  |
|  | MUX2-MUXO | INT RT | 12 |  |  |
|  | B3-B0 | INT RT | 14 |  |  |
|  | Y13-Y0 | MPC | 10 |  |  |
| $t_{\text {h }}$ | Any Input | Any Destination | 2 |  |  |

SN74AS890 minimum clock requirements (see Note 3)

| PARAMETER |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {wLICK }}$ | Pulse duration, clock low | 10 |  | ns |
| $\mathrm{t}_{\mathrm{w} H}(\mathrm{CK})$ | Pulse duration, clock high | 20 |  |  |
| ${ }^{\mathrm{t}} \mathrm{C}$ (CK) | Clock cycle time | $50^{1}$ |  |  |
|  |  | 36 |  |  |

[^38]
## SN74AS890-1 <br> MICROSEQUENCERS

SN74AS890-1 maximum switching characteristics: $\mathrm{V}_{\mathrm{CC}} 1=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=1.9 \mathrm{~V}$ to 2.1 V , TA $=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 2)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | ZERO | DRA | DRB | STKWRN |  |
| ${ }^{t} \mathrm{pd}$ | $\overline{\mathrm{CC}}$ | 25 |  |  |  |  | ns |
|  | - CK | 25 |  | 25 | 25 | 25 |  |
|  |  | $42^{\dagger}$ | $34^{\dagger}$ |  |  |  |  |
|  | DRA13-DRAO | 14 |  |  |  |  |  |
|  | DRB13-DRB0 | 14 |  |  |  |  |  |
|  | MUX2-MUX0 | 31 |  |  |  |  |  |
|  | RC2-RCO | 26 | 12 |  |  |  |  |
|  | S2-S0 | 25 |  |  |  |  |  |
|  | B2-B0 | 19 |  |  |  |  |  |
|  | OSEL | 17 |  |  |  |  |  |
| ten | YOE | 15 |  |  |  |  | ns |
|  | $\overline{\text { RAOE }}$ |  |  | 15 |  |  |  |
|  | $\overline{\mathrm{RBOE}}$ | 15 |  |  |  |  |  |
| ${ }^{\text {d }}$ dis | $\overline{\mathrm{YOE}}$ | 16 |  |  |  |  | ns |
|  | $\overline{\mathrm{RAOE}}$ | 16 |  |  |  |  |  |
|  | $\widehat{\text { RBOE }}$ |  |  |  | 16 |  |  |

${ }^{\dagger}$ Decrementing Register/Counter A or B and sensing a zero.
NOTE 2: Load circuit and voltage waveforms are shown in Section 1.
SN74AS890-1 setup and hold times

| PARAMETER | FROM | TO (DESTINATION) | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }_{\text {t }}^{\text {su }}$ | $\overline{\mathrm{C}}$ | Stack | 10 |  | ns |
|  | DRA 13-DRAO | RCA, INT RT | 5 |  |  |
|  | DRB13-DRB0 | RCB, INT RT | 5 |  |  |
|  | INC | MPC | 10 |  |  |
|  | INT | Stack | 10 |  |  |
|  | RC2-RC0 | Stack | 14 |  |  |
|  |  | RCA, RCB | 10 |  |  |
|  |  | INT RT | 12 |  |  |
|  | S2-S0 | Any Destination | 10 |  |  |
|  | MUX2-MUXO | INT RT | 12 |  |  |
|  | B3-B0 | INT RT | 14 |  |  |
|  | Y13-Y0 | MPC | 10 |  |  |
| th | Any Input | Any Destination | 2 |  |  |

## SN74AS890-1 minimum clock requirements (see Note 3)

|  |  | PARAMETER | MIN |
| :--- | :--- | :---: | :---: |
| $t_{\text {WL }}(C K)$ | Pulse duration, clock low | 10 |  |
| $t_{\text {wH }}(C K)$ | Pulse duration, clock high | 20 |  |
| ${ }^{t_{C}(C K)}$ Clock cycle time |  | $42^{\dagger}$ |  |

${ }^{\dagger}$ Decrementing Register/Counter A or B and sensing a zero.
NOTE 3: The total clock period of clock high and clock low must not be less than clock cycle time. The minimum pulse durations specified are only for clock high or clock low, but not for both simultaneously.

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

- STL-AS Technology
- Parallel 8-Bit ALU with Expansion Inputs and Outputs
- 13 Arithmetic and Logic Functions
- 8 Conditional Shifts (Single and Double Length)
- 9 Instructions that Manipulate Bytes
- 4 Instructions that Manipulate Bits
- Add and Subtract Immediate Instructions
- Absolute Value Instruction
- Signed Magnitude to/from Two's Complement Conversion
- Single- and Double-Length Normalize
- Select Functions
- Signed and Unsigned Divides with Overflow Detection; Input does not Need to be Prescaled
- Signed, Mixed, and Unsigned Multiplies
- Three-Operand, 16-Word Register File
- Full Carry Look Ahead Support
- Sign, Carry Out, Overflow, and Zero-Detect Status Capabilities
- Excess-3 BCD Arithmetic
- MQ Register is Externally Available through the DB Port
- Internal Shift Multiplexers that Eliminate the Need for External Shift Control Parts
- ALU Bypass Path to Increase Speeds of Multiply, Divide, and Normalize Instructions and to Provide New Instructions such as Bit Set, Bit Reset, Bit Test, Byte Subtract, Byte Add, and Byte Logical
- 3-Operand Register Files to Allow an Operation and a Move Instruction to be Combined
- Byte Select Controlled by External 3-State Buffers that may be Eliminated if Bit and Byte Manipulation are not Needed
- Bit and Byte Masks that are Shared with Register Address Fields to Minimize Control Store Word Width
- 3 Data Input/Output Paths to Maximize Data Throughput


## description

These 8-bit Advanced Schottky TTL integrated circuits are designed to implement high performance digital computers or controllers. An architecture and instruction set has been chosen that supports a fast system clock, a narrow micro-code word width, and a high system throughput. The powerful instruction set allows high-speed system architecture to be implemented and also allows an existing system's performance to be upgraded while protecting software investments. These processors are designed to be cascadable to any word width 16 bits or greater.

The only difference between the 'AS888 Bit-Slice Processor and the 'AS895 Memory Address Generators is the function of the DB port. The 'AS888 DB port outputs the register file. The 'AS895 DB port can be used to read the MQ register result during the same clock cycle that the ALU result is available at the Y port.

The SN54AS895 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS895 and SN74AS895-1 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

Package options include both plastic and ceramic chip carriers in addition to a 68-pin grid array ceramic package.

gB PACKAGE PIN ASSIGNMENTS

| PIN | NAME | PIN | NAME | PIN | NAME | PIN | NAME |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A. 2 | $\mathrm{C}_{n}$ | B.9 | $\overline{\mathrm{OEY}}$ | F-10 | Y3 | K-4 | C2 |
| A. 3 | $\overline{5100}$ | B-10 | Yo | F-11 | DB2 | K-5 | A0 |
| A. 4 | $\overline{0100}$ | B-11 | Y1 | G-1 | DA2 | K-6 | A3 |
| A. 5 | $\overline{0107}$ | C-1 | 15 | G.2 | DAO | K-7 | $\overline{W E}$ |
| A-6 | $\mathrm{C}_{\mathrm{n}+8}$ | C-2 | $\mathrm{V}_{\mathrm{CC} 2}$ | G-10 | DBO | K-8 | DB7 |
| A. 7 | $\overline{\mathrm{G}} / \mathrm{N}$ | C-10 | Y4 | G-11 | D83 | K-9 | $\overline{\mathrm{OEB}}$ |
| A. 8 | P/OVR | C-11 | Y6 | H-1 | DA3 | K-10 | EBO |
| A-9 | zero | D-1 | 16 | H-2 | DA1 | K-11 | EB1 |
| A-10 | PPp. | D-2 | $\mathrm{V}_{\mathrm{CC} 1}$ | H-10 | DB6 | L-2 | CK |
| B-1 | 12 | D-10 | Y5 | H-11 | DB4 | L-3 | C1 |
| B-2 | 13 | D-11 | Y7 | J-1 | DA4 | L-4 | C3 |
| B-3 | 11 | E. 1 | 17 | J-2 | DA5 | L-5 | A1 |
| B-4 | 10 | E-2 | $\overline{O E A}$ | J-10 | SELY | L-6 | A2 |
| B-5 | 14 | E-10 | Y2 | J-11 | DB5 | L. 7 | B3 |
| B. 6 | $\overline{\text { S107 }}$ | E-11 | DB1 | K-1 | DA6 | L-8 | B2 |
| B-7 | SSF | F-1 | $\overline{E A}$ | K-2 | DA7 | L-9 | B1 |
| B. 8 |  | F-2 | GND | K. 3 | CO | L-10 | B0 |

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

| PIN GRID ARRAY | CHIP CARRIER | NAME | I/O | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| A-10 | 28 | PPP | 1 | Package position pin. Tri-level input used to define package significance during instruction execution. Leave open for intermediate positions, tie to $V_{C C}$ for most significant package, and tie to GND for least significant package. |
| B-7 | 29 | SSF | I/O | Special shift function. Used to transfer required information between packages during special instruction execution. |
| A.9 | 30 | ZERO | 1/0 | Device zero detection, open collector. Input during certain special instructions. |
| A. 8 | 31 | $\overline{\mathrm{P}} / \mathrm{OVR}$ | 0 | ALU propagate/instruction overflow for most significant package, low active. |
| A. 7 | 32 | $\overrightarrow{\mathrm{G}} / \mathrm{N}$ | 0 | ALU generate/negative result for most significant package, low active. |
| A-6 | 33 | $C_{n+8}$ | 0 | ALU ripple carry output. |
| $\begin{aligned} & \text { B-6 } \\ & \text { A- } 5 \\ & \text { A- } 4 \\ & \text { A-3 } \end{aligned}$ | $\begin{aligned} & 34 \\ & 35 \\ & 36 \\ & 37 \end{aligned}$ | $\begin{aligned} & \overline{\overline{\mathrm{SO} O 7}} \\ & \overline{\mathrm{Q} 107} \\ & \overline{\mathrm{Q} 100} \\ & \overline{\mathrm{SIO}} \end{aligned}$ | $\begin{aligned} & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & \hline \end{aligned}$ | Bidirectional shift pin, low active. |
| A-2 | 38 | $\mathrm{C}_{\mathrm{n}}$ | 1 | ALU carry input. |
| B-4 <br> B-3 <br> B-1 <br> B-2 <br> B-5 <br> C-1 <br> D-1 <br> E-1 | $\begin{aligned} & 39 \\ & 40 \\ & 41 \\ & 42 \\ & 43 \\ & 44 \\ & 45 \\ & 46 \\ & \hline \end{aligned}$ | 10 <br> 11 <br> 12 <br> 13 <br> 14 <br> 15 <br> 16 <br> 17 | $\begin{aligned} & 1 \\ & 1 \\ & 1 \\ & 1 \\ & 1 \\ & 1 \\ & 1 \\ & 1 \end{aligned}$ | Instruction input. |
| C-2 | 47 | $\mathrm{V}_{\mathrm{CC} 2}$ |  | Low voltage power supply (2 V). |
| D-2 | 48 | $\mathrm{V}_{\mathrm{CC} 1}$ |  | $1 / \mathrm{O}$ interface supply voltage ( 5 V ). |
| E-2 | 49 | $\overline{O E A}$ | 1 | DA bus enable, low active. |
| F-1 | 50 | $\overline{E A}$ | 1 | ALU input operand select. High state selects external DA bus and low state selects register file. |
| F-2 | 51 | GND |  | Ground pin. |
| $\begin{gathered} \mathrm{G}-2 \\ \mathrm{H}-2 \\ \mathrm{G}-1 \\ \mathrm{H}-1 \\ \mathrm{~J}-1 \\ \mathrm{~J}-2 \\ \mathrm{~K}-1 \\ \mathrm{~K}-2 \end{gathered}$ | $\begin{aligned} & 52 \\ & 53 \\ & 54 \\ & 55 \\ & 56 \\ & 57 \\ & 58 \\ & 59 \end{aligned}$ | DAO <br> DA1 <br> DA2 <br> DA3 <br> DA4 <br> DA5 <br> DA6 <br> DA7 | $\begin{aligned} & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \\ & 1 / 0 \end{aligned}$ | A port data bus. Outputs register file data ( $\overline{\mathrm{EA}}=0$ ) or inputs external data ( $\overline{\mathrm{EA}}=1$ ). |
| L-2 | 60 | CK | 1 | Clocks all synchronous registers on positive edge. . |
| $\begin{aligned} & \mathrm{K}-3 \\ & \mathrm{~L}-3 \\ & \mathrm{~K}-4 \\ & \mathrm{~L}-4 \\ & \hline \end{aligned}$ | $\begin{aligned} & 61 \\ & 62 \\ & 63 \\ & 64 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{C} 0 \\ & \mathrm{C} 1 \\ & \mathrm{C} 2 \\ & \mathrm{C} 3 \\ & \hline \end{aligned}$ | $\begin{aligned} & 1 \\ & 1 \\ & 1 \\ & 1 \end{aligned}$ | Register file write address select. |
| $\begin{aligned} & \mathrm{K}-5 \\ & \mathrm{~L}-5 \\ & \mathrm{~L}-6 \\ & \mathrm{~K}-6 \\ & \hline \end{aligned}$ | $\begin{aligned} & 65 \\ & 66 \\ & 67 \\ & 68 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{A} 0 \\ & \mathrm{~A} 1 \\ & \mathrm{~A} 2 \\ & \mathrm{~A} 3 \\ & \hline \end{aligned}$ | $\begin{aligned} & 1 \\ & 1 \\ & 1 \\ & 1 \end{aligned}$ | Register file A port read address select. |


| PIN GRID ARRAY | CHIP CARRIER | NAME | 1/0 | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: |
| K-7 | 1 | $\overline{\text { WE }}$ | 1 | Register file (RF) write enable. Data is written into $\overline{\mathrm{RF}}$ when $\overline{\mathrm{WE}}$ is low and a low-to-high clock transition occurs. RF write is inhibited when $\overline{W E}$ is high. |
| L-7 | 2 | B3 | 1 |  |
| L-8 | 3 | B2 | 1 |  |
| L-9 | 4 | B1 | 1 | Register file B port read address select. ( $0=$ LSB). |
| L-10 | 5 | B0 | 1 |  |
| K-10 | 6 | EBO | 1 | ALU input operand select. EBO and EB1 selects the source of data that the S |
| K-11 | 7 | EB1 | 1 | multiplexer provides for the $S$ bus. Independent control of the DB bus and data path selection allow the user to isolate the DB bus while the ALU continues to process data. |
| K-9 | 8 | $\overline{\text { OEB }}$ | 1 | DB bus enable, low active. |
| K-8 | 9 | DB7 | 1/0 |  |
| H-10 | 10 | DB6 | 1/0 |  |
| J-11 | 11 | DB5 | 1/0 |  |
| H-11 | 12 | DB4 | $1 / 0$ | $B$ port data bus. Outputs MQ register data ( $\overline{\mathrm{OEB}}=0$ ) or used to input external data |
| G-11 | 13 | DB3 | 1/0 | $(\overline{O E B}=1),(0=L S B)$. |
| F-11 | 14 | DB2 | 1/0 |  |
| E-11 | 15 | DB1 | 1/0 |  |
| G-10 | 16 | DBO | $1 / 0$ |  |
| J-10 | 17 | SELY | 1 | Y bus select, high active. |
| D-11 | 18 | Y7 | 1/0 |  |
| C-11 | 19 | Y6 | 1/0 |  |
| D-10 | 20 | Y5 | I/O |  |
| C-10 | 21 | Y4 | 1/0 | Y port data bus. Outputs instruction results ( $\overline{\mathrm{OEY}}=0$ ) or used to put external data into |
| F-10 | 22 | Y3 | 1/0 | register file $(\overline{O E Y}=1)$. |
| E-10 | 23 | Y2 | 1/0 |  |
| B-11 | 24 | Y1 | 1/0 |  |
| B-10 | 25 | Yo | 1/0 |  |
| B-9 | 26 | $\overline{O E Y}$ | 1 | Y bus output enable, low active. |
| F-2 | 27 | GND |  | Ground pin |

functional block diagram


## architectural elements

## 3 -port register file

Working registers consist of 128 storage elements organized into sixteen 8 -bit words. These storage elements appear to the user as 16 positive edge-triggered registers. The three port addresses, one write (C) and two reads ( A and B ), are completely independent of each other to implement a 3-operand register file. Data is written into the register file when $\overline{\mathrm{WE}}$ is low and a low-to-high clock transition occurs. The ADD and SUBTRACT immediate instructions require only one source operand. The B address is used as the source address, and the bits of the A address are used to provide a constant field. The SET, RESET, and TEST BIT instructions use the B addressed register as both the source and destination register while the A and C addresses are used as masks. These instructions are explained in more detail in the instruction section.

S multiplexer
The S multiplexer selects the ALU operand, as follows:

| EB1 | EBO | S bus |
| :--- | :--- | :--- |
| Low | Low | RF data |
| Low | High | MQ data |
| High | Low | DB data |
| High | High | MO data |

DB port
The 8-bit bidirectional DB port inputs external data to the ALU or outputs the MO register. If $\overline{\mathrm{OEB}}$ is low, the DB bus is active; if $\overline{O E B}$ is high, the $D B$ bus is in the high impedance state. Notice that the DB port may be isolated at the same time that MO register data is passed to the ALU.

## $R$ multiplexer

The R multiplexer selects the other operand of the ALU. Except for those instructions that require constants or masks, the $R$ bus will contain DA if $\overline{E A}$ is high or the RF data pointed to by $A$ if $\overline{E A}$ is low.

## DA port

The 8 -bit bidirectional DA port inputs external data to the ALU or outputs the register file. If $\overline{\mathrm{OEA}}$ is low, the DA bus is active; if $\overline{O E A}$ is high, the DA bus is in the high-impedance state. Notice that the DA bus may be isolated while register file data is passed to the ALU.

## ALU

The shift instructions are summarized in Table 4 and illustrated in Figure 2. The ALU can perform seven arithmetic and six logical instructions on two 8 -bit operands. It also supports multiplication, division, normalization, bit set, reset, test, byte operations, and excess-3 BCD arithmetic. These source operands are the outputs of the S and R multiplexers.

## ALU and MO shifters

ALU and MO shifters perform all of the shift, multiply, divide, and normalize functions. Table 4 shows the value of the $\overline{\mathrm{SIO7}}$ and $\overline{\mathrm{O} 107}$ pins of the most significant package. The standard shifts may be made into conditional shifts and the serial data may be input or output with the aid of two three-state gates. These capabilities are discussed further in the arithmetic and logic section.

## MQ register

The multiplier-quotient ( MQ ) register has specific functions in multiplication, division, and normalization. This register may also be used as a temporary storage register. The MQ register may be loaded if the instruction code on pins 17-IO is E1-E7 or E9-EE (See Table 1).

## $Y$ bus

The $Y$ bus contains the output of the ALU shifter if $\overline{O E Y}$ is low and is a high impedance input if $\overline{O E Y}$ is high. SELY must be low to pass the internal ALU shift bus and must be high to pass the external $Y$ bus to the register file.

## status

Four status pins are available on the most significant package, overflow (OVR), sign ( $N$ ), carry out ( $\mathrm{C}_{\mathrm{n}}+8$ ), and zero (ZERO). The $C_{n}+8$ line signifies the ALU result while OVR, ZERO, and $N$ refer the status after the ALU shift has occurred. Notice that the ZERO pin cannot be used to detect whether an input placed on a high impedance $Y$ bus is zero.

## divide BCD flip-flops

The multiply-divide flip-flops contain the status of the previous multiply or divide instruction. They are affected by the following instructions:

```
DIVIDE REMAINDER FIX
SIGNED DIVIDE QUOTIENT FIX
SIGNED MULTIPLY
SIGNED MULTIPLY TERMINATE
SIGNED DIVIDE INITIALIZE
SIGNED DIVIDE START
```

```
SIGNED DIVIDE ITERATE
UNSIGNED DIVIDE START
UNSIGNED DIVIDE ITERATE
UNSIGNED MULTIPLY
SIGNED DIVIDE TERMINATE
UNSIGNED DIVIDE TERMINATE
```

The excess-3 BCD flip-flops are affected by all instructions except NOP. The clear function clears these flip-flops. They preserve the carry from each nibble (4-bits) in excess-3/BCD operations.

## package position pin (PPP)

The position of the processor in the system is defined by the voltage level applied to the package position pin (PPP). Intermediate positions are selected by leaving the pin open. Tying the pin to VCC makes the processor the most significant package and tying the pin to GND makes the processor the least significant package.
special shift function (SSF) pin
Conditional shifting algorithms may be implemented via control of the SSF pin. The applied voltage to this pin may be set as a function of a potential overflow condition (the two most significant bits are not equal) or any other condition (see Group 1 instructions).

## instruction set

The 'AS895 bit-slice processor uses bits 17-10 as instruction inputs. A combination of bits 13 -IO (Group 1 instructions) and bits 17-14 (Group 2-5 instructions) are used to develop the 8-bit op code for a specific instruction. Group 1 and Group 2 instructions can be combined to perform arithmetic or logical functions plus a shift function in one instruction cycle. A summary of the instruction set is given in Table 1.

## TABLE 1. INSTRUCTION SET

GROUP 1 INSTRUCTIONS

| INSTRUCTION BITS (I3-IO) HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| $\begin{aligned} & \hline 0 \\ & 1 \\ & 2 \\ & 3 \\ & 4 \\ & 5 \\ & 6 \\ & 7 \\ & 8 \\ & 9 \\ & A \\ & B \\ & C \\ & D \\ & \text { E } \end{aligned}$ | ADD <br> SUBR <br> SUBS <br> INCS <br> INCNS <br> INCR <br> INCNR <br> XOR <br> AND <br> OR <br> NAND <br> NOR <br> ANDNR | Accesses Group 4 instructions $\begin{aligned} & R+S+C_{n} \\ & \bar{R}+S+C_{n} \\ & R+\bar{S}+C_{n} \\ & S+C_{n} \\ & \bar{S}+C_{n} \\ & R+C_{n} \\ & \bar{R}+C_{n} \end{aligned}$ <br> Accesses Group 3 instructions $\dot{R} \times O R S$ <br> R AND S <br> R OR S <br> R NAND S <br> R NOR S <br> $\overline{\mathrm{R}}$ AND S <br> Accesses Group 5 instructions |
| GROUP 2 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-14) HEX CODE | MNEMONIC | FUNCTION |
| 0 1 2 3 4 5 6 7 8 9 A B C D E F | SRA SRAD SRL SRLD SLA SLAD SLC SLCD SRC SRCD MQSRA MQSRL MOSLL MQSLC LOADMQ PASS | Arithmetic Right Single <br> Arithmetic Right Double <br> Logical Right Single <br> Logical Right Double <br> Arithmetic Left Single <br> Arithmetic Left Double <br> Circular Left Single <br> Circular Left Double <br> Circular Right Single <br> Circular Right Double <br> Pass $(F \rightarrow Y)$ and Arithmetic Right $M O$ <br> Pass $(F \rightarrow Y)$ and Logical Right MQ <br> Pass $(F \rightarrow Y)$ and Logical Left MQ <br> Pass $(F \rightarrow Y)$ and Circular Left MQ <br> Pass $(F \rightarrow Y)$ and Load MQ ( $F=M Q$ ) <br> Pass ( $F \rightarrow Y$ ) |

table 1. Instruction set (Continued)

| INSTRUCTION BITS (17-10) HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :---: |
| 08 18 28 38 48 58 68 78 88 98 A8 B8 C8 D8 E8 F8 | SET 1 <br> SETO <br> TB1 <br> TBO <br> ABS <br> SMTC <br> ADDI <br> SUBI <br> BADD <br> BSUBS <br> BSUBR <br> BINCS <br> BINCNS <br> BXOR <br> BAND <br> BOR | Set Bit <br> Reset Bit <br> Test Bit (One) <br> Test Bit (Zero) <br> Absolute Value <br> Sign Magnitude/Two's Complement <br> Add Immediate <br> Subtract Immediate <br> Byte Add R to $S$ <br> Byte Subtract $S$ from $R$ <br> Byte Subtract R from $S$ <br> Byte Increment S <br> Byte Increment Negative $S$ <br> Byte XOR R and S <br> Byte AND R and S <br> Byte OR R and S |
| GROUP 4 INSTRUCTIONS |  |  |
| INSTRUCTION BITS (17-10) HEX CODE | MNEMONIC | FUNCTION |
| OO 10 20 30 40 50 60 70 80 90 AO BO CO DO EO FO | SEL <br> SNORM <br> DNORM <br> DIVRF <br> SDIVQF <br> SMULI <br> SMULT <br> SDIVIN <br> SDIVIS <br> SDIVI <br> UDIVIS <br> UDIVI <br> UMULI <br> SDIVIT <br> UDIVIT | Reserved <br> Select S/R <br> Single Length Normalize <br> Double Length Normalize <br> Divide Remainder Fix <br> Signed Divide Quotient Fix <br> Signed Multiply Iterate <br> Signed Multiply Terminate <br> Signed Divide Initialize <br> Signed Divide Start <br> Signed Divide Iterate <br> Unsigned Divide Start <br> Unsigned Divide Iterate <br> Unsigned Multiply Iterate <br> Signed Divide Terminate <br> Unsigned Divide Terminate |

TABLE 1. INSTRUCTION SET (Concluded)

| GROUP 5 INSTRUCTIONS |  |  |
| :---: | :---: | :--- |
| INSTRUCTION BITS (I7-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| $5 F$ | CLR | Clear |
| $6 F$ | CLR | Clear |
| $7 F$ | BCDBIN | BCD to Binary |
| $8 F$ | EX3BC | Excess-3 Byte Correction |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No Operation |

TABLE 2. GROUP 1 INSTRUCTIONS

| INSTRUCTION BITS (I3-IO) <br> HEX CODE | MNEMONIC | FUNCTION |
| :---: | :--- | :--- |
| 0 |  | Accesses Group 4 instructions |
| 1 | ADD | $R+S+C_{n}$ |
| 2 | SUBR | $\bar{R}+S+C_{n}$ |
| 3 | SUBS | $R+\bar{S}+C_{n}$ |
| 4 | INCS | $S+C_{n}$ |
| 5 | INCNS | $\bar{S}+C_{n}$ |
| 6 | INCR | $R+C_{n}$ |
| 7 | INCNR | $\bar{R}+C_{n}$ |
| 8 |  | Accesses Group 3 instructions |
| 9 | XOR | $R$ XOR S |
| A | AND | R AND S |
| $B$ | OR | R OR S |
| C | NAND | $R$ NAND S |
| D | NOR | R NOR S |
| E | ANDNR | $\bar{R}$ AND S |
| F |  | Accesses Group 5 instructions |

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

Group 1 instructions (excluding hex codes 0,8 , and $F$ ), shown in Table 2, may be used in conjunction with Group 2 shift instructions to perform arithmetic or logical functions plus a shift function ${ }^{\dagger}$ in one instruction cycle (hex codes 0,8 , and $F$ are used to access Group 4, 3, and 5 instructions, respectively). Each shift may be made into a conditional shift by forcing the special shift function (SSF) pin into the proper state. If the SSF pin is high or floating, the shifted ALU output will be sent to the output buffers. If the SSF pin is pulled low externally, the ALU result will be passed directly to the output buffers. Conditional shifting is useful for scaling inputs in data arrays or in signal processing algorithms.

These instructions set the BCD flip-flop for the excess-3 correct instruction. The status is set with the following results $\left\langle C_{n}+8\right.$ is ALU carry out and is independent of shift operation; others are evaluated after shift operation).
${ }^{\dagger}$ Double-precision shifts involve both the ALU and MQ register.
Status is set with the following results:
Arithmetic

| N | $\rightarrow$ | MSB of result |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Signed arithmetic overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |
| Logic |  |  |
| N | $\rightarrow$ | MSB of result |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Result equal zero |

TABLE 3. GROUP 2 INSTRUCTIONS
group 2 instructions

| INSTRUCTION BITS (I7-14) <br> HEX CODE | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 0 | SRA | Arithmetic Right Single |
| 1 | SRAD | Arithmetic Right Double |
| 2 | SRL | Logical Right Single |
| 3 | SRLD | Logical Right Double |
| 4 | SLA | Arithmetic Left Single |
| 5 | SLAD | Arithmetic Left Double |
| 6 | SLC | Circular Left Single |
| 7 | SLCD | Circular Left Double |
| 8 | SRC | Circular Right Single |
| 9 | SRCD | Circular Right Double |
| A | MQSRA | Pass $(F \rightarrow Y)$ and Arithmetic Right MQ |
| B | MQSRL | Pass $(F \rightarrow Y)$ and Logical Right MQ |
| C | MQSLL | Pass $(F \rightarrow Y)$ and Logical Left MQ |
| D | MQSLC | Pass $(F \rightarrow Y)$ and Circular Left MQ |
| E | LOADMQ | Pass $(F \rightarrow Y)$ and Load MQ $(F=M Q)$ |
| F | PASS | Pass $(F \rightarrow Y)$ |

The processor's shift instructions are implemented by a combination of Group 2 instructions (Table 3) and certain wired connections on the packages used. The following external connections are required.

On intermediate packages:
SIO7 is connected to $\overline{S I O O}$ of the next most significant package
Q107 is connected to $\overline{0100}$ of the next most significant package SIOO is connected to STO7 of the next least significant package $\overline{01 O D}$ is connected to $\overline{Q 107}$ of the next least significant package

On the two end packages:
SIO7 on the most significant package is connected to SIOO of the least significant package . $\overline{0107}$ on the most significant package is connected to $\overline{01 O O}$ of the least significant package

The connections are the same on all instructions including multiply, divide, and normalization functions.
Single- and double-precision shifts are supported. Double-precision shifts assume the most significant half has come through the ALU and will be placed (if $\bar{W}$ is low) into the register file on the rising edge of the clock and the least significant half lies in the $M Q$ register. All Group 2 shifts may be made conditional (see previous page).

The following definitions apply to Group 2 shift instructions:
Arithmetic right shifts copy the sign of the number if no overflow occurs from the ALU calculation; if overflow occurs, the sign bit is inverted.
Arithmetic left shifts do not retain the sign of the number if an overflow occurs. A zero is filled into the LSB if not forced externally.
Logical right shifts fill a zero in the MSB position if not forced externally.
Logical left shifts fill a zero in the LSB position if not forced externally.
Circular right shifts fill the LSB in the MSB position.
Circular left shifts fill the MSB in the LSB position.
Shifting left is defined as moving a bit position towards the MSB (doubling).
Shifting right is defined as moving a bit towards the LSB (halving).
Serial input may be performed using the circuitry shown in Figure 1. A single-/or double-precision arithmetic left or logical right shift fills the complement of the data on $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{SIO}}$ into the LSB or MSB of the data word(s). Note that if $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{SIOO}}$ are floating ( $\mathrm{HI}-\mathrm{Z}$ ), a zero will be filled as an end condition.

Serial output may be performed with circular instructions.


FIGURE 1. SERIAL I/O

The shift instructions are summarized in Table 4 and illustrated in Figure 2. In Figure 2 and all succeeding figures that illustrate instruction execution, the following definitions apply:

QBT - End fill for signed divide.
MOF - End fill for unsigned divide.
SRF - End fill for signed multiply and the arithmetic right shifts.
TABLE 4. SHIFT INSTRUCTIONS

| $\begin{gathered} O P \\ \text { CODE } \end{gathered}$ | SHIFT FUNCTION ${ }^{\ddagger}$ | SIO7•S100 <br> WIRED VALUE | $0107 \cdot 0100$ <br> WIRED VALUE |
| :---: | :---: | :---: | :---: |
| ON | Arithmetic Right Single | ALU-LSB Output | - |
| 1N | Arithmetic Right Double | MQ-LSB Output | ALU-LSB Output |
| 2 N | Logical Right Single | Input to ALU-MSB | ALU-LSB Output |
| 3N | Logical Right Double | Input to ALU-MSB | ALU-LSB Output |
| 4 N | Arithmetic Left Single | Input to ALU-LSB | ALU-MSB Output |
| 5 N | Arithmetic Left Double | Input to MQ-LSB | MQ-MSB Output |
| 6 N | Circular Left Single | ALU-MSB Output |  |
| 7N | Circular Left Double | ALU-MSB Output | MQ-MSB Output |
| 8 N | Circular Right Single | ALU-LSB Output | - |
| 9 N | Circular Right Double | MO-LSB Output | ALU-LSB Output |
| AN | Arithmetic Right (MO only) | MQ-LSB Output | MQ-LSB Output |
| BN | Logical Right (MQ only) | MQ-LSB Output | Input to MQ-MSB |
| CN | Logical Left (MO only) | Input to MQ-LSB | MQ-MSB Output |
| DN | Circular Left (MQ only) | MQ-MSB Output | MQ-MSB Output |

${ }^{\dagger}$ Op Code $N \neq 0,8$, or $F$; these select special instruction Groups 4, 3, and 5 respectively.
${ }^{\ddagger}$ Shift I/O pins are active low. Therefore, inputs and outputs must be inverted if true logical values are required.

Status is set with the following results:

## Arithmetic

| N | $\rightarrow$ |
| :--- | :--- |
| Result MSB equal one |  |
| OVR | $\rightarrow$ |
| Signed arithmetic overflow |  |
|  |  |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ |
| Z | $\rightarrow$ |
| Result equal zero |  |

Logic
$N \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Zero
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Zero
$\mathrm{Z} \rightarrow$ Result equal zero
${ }^{\dagger}$ For the SLA and SLAD instructions, OVR is set if signed arithmetic overflow or if the ALU result MSB XOR MSB- 1 equals one.

(FILLS ZERO IF NOT FORCED)

FIGURE 2. SHIFT INSTRUCTIONS (Continued)
(FILLS ZERO IF NOT FORCED)
ARITHMETIC LEFT SINGLE


CIRCULAR RIGHT SINGLE


LOGICAL LEFT (MQ ONLY) (FILLS ZERO IF NOT FORCED)

FIGURE 2. SHIFT INSTRUCTIONS (Concluded)
group 3 instructions
Hex code 8 of Group 1 instructions is used to access Group 3 instructions. Group 3 instructions are summarized in Table 5.

TABLE 5. GROUP 3 INSTRUCTIONS

| INSTRUCTION BITS (17-I0) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 08 | SET1 | Set Bit |
| 18 | SETO | Reset Bit |
| 28 | TB1 | Test Bit (One) |
| 38 | TBO | Test Bit (Zero) |
| 48 | ABS | Absolute Value |
| 58 | SMTC | Sign Magnitude/Two's Complement |
| 68 | ADDI | Add Immediate |
| 78 | SUBI | Subtract Immediate |
| 88 | BADD | Byte Add R to S |
| 98 | BSUBS | Byte Subtract S from R |
| A8 | BSUBR | Byte Subtract R from S |
| B8 | BINCS | Byte Increment S |
| C8 | BINCNS | Byte Increment Negative S |
| D8 | BXOR | Byte XOR R and S |
| E8 | BAND | Byte AND R and S |
| F8 | BOR | Byte OR R and S |

set bit instruction (set1): $17-10=0816$
This instruction (Figure 3) is used to force selected bits of a desired byte(s) to one. The desired bits are specified by an 8-bit mask (C3-CO)::(A3-A0) ${ }^{\dagger}$ consisting of register file address ports that are not required to support this instruction. All bits in the selected byte(s) that are in the same bit positions as ones in the mask are forced to a logical one. The B3-B0 address field is used for both source and destination of this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. Nonselected packages pass the byte through unaltered. The $S$ bus is the source word for this instruction. The status set by the set bit instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { None (force to zero) } \\
\text { OVR } & \rightarrow & \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

$\dagger$ The symbol ' $::$ ' is concatenation operator


FIGURE 3. SET BIT (OR RESET BIT)
NOTES: 1. Force $\overline{\text { SIOO }}=$ low to select byte.
2. Bit mast (C3-CO)::(A3-AO) will set desired bits to one.

## reset bit instruction $(\operatorname{set})$ ): $\mathbf{1 7 - 1 0}=1816$

This instruction (Figure 3) is used to force selected bits of a desired byte(s) to zero. The desired bits are specified by an 8-bit mask (C3-CO):: (A3-AO) consisting of register file address ports that are not required to support this instruction. All bits in the selected byte(s) that are in the same bit positions as ones in the mask are reset. The B3-B0 address field is used for both source and destination of this instruction.

The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. Nonselected packages pass the byte through unaltered. The S bus is the source word for this instruction. The status set by the reset bit instruction is as follows:

| N | $\rightarrow$ | None (force to zero) |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | None (force to zero) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | None (force to zero) |
| Z | $\rightarrow$ | Result equal zero |

test bit (one) instruction (TB1): 17-10 $\mathbf{= 2 8 1 6}$
This instruction (Figure 4) is used to test selected bits of a desired byte(s). Bits to be tested are specified by an 8 -bit mask (C3-CO)::(A3-AO) consisting of register file address ports that are not required to support this instruction. Write Enable (WE) is internally disabled during this instruction. The desired byte is specified by forcing $\overline{S I O O}$ to a low value. The test will pass if the selected byte has ones at all bit locations specified by the ones of the mask (Figure 5). The $\mathbf{S}$ bus is the source word for this instruction. The status set by the test bit (one) instruction is as follows:


FIGURE 4. TEST BIT
NOTES: 1. Force $\overline{S I O O}=$ low to select byte.
2. Bit mask (C3-CO)::(A3-A0) will define bits for testing.
3. Pass/fail is indicated on $Z$ output.
test bit (zero) instruction (TBO): 17-10 $=3816$
This instruction (Figure 4) is used to test selected bits of a desired byte(s). Bits to be tested are specified by an 8-bit mask (C3-C0)::(A3-A0) consisting of register file address ports that are not required to support this instruction. Write Enable ( $\overline{\mathrm{WE}}$ ) is internally disabled during this instruction. The desired byte is specified by forcing $\overline{\mathrm{SIOO}}$ to a low value. The test will pass if the selected byte has zeros at all bit locations specified by the ones of the mask (Figure 6). The $S$ bus is the source word for this instruction. The status set by the test bit (zero) instruction is as follows:

| $N$ | $\rightarrow$ | None (force to zero) |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | None (force to zero) |
| $C_{n}+8$ | $\rightarrow$ | None (force to zero) |
| $Z$ | $\rightarrow$ | Pass |



FIGURE 5. TEST BIT ONE EXAMPLES


FIGURE 6. TEST BIT ZERO EXAMPLES
absolute value instruction (ABS): $17-10=4816$
This instruction is used to convert two's complement numbers to their positive value. The operand placed on the $S$ bus is the source for this instruction. The MSP will test the sign of the $S$ bus and force the SSF pin to the proper value. All other packages use the SSF pin as input to determine instruction execution. The status set by the absolute value instruction is as follows:

| N | $\rightarrow$ | Input MSB equal one |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Input equal 8000 (hex) |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ | $\mathrm{~S}=0$ |
| Z | $\rightarrow$ | Result equal zero |

sign magnitude/two's complement instruction (SMTC): $17-10=5816$
This instruction allows conversion from two's complement representation to sign magnitude representation, or vice-versa, in one clock cycle. The operand placed on the $S$ bus is the source for this instruction.
When a negative zero ( 8000 hex ) is converted, the result is 0000 with an overflow. If the input is in two's complement notation, the overflow indicates an illegal conversion. The status set by the sign magnitude/two's complement instruction is as follows:

| N | $\rightarrow$ | Result MSB equal one |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Input equal 8000 (hex) |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Input equal 0000 (hex) |
| Z | $\rightarrow$ | Result equal zero |

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

add immediate instruction (ADDI): $17-10=6816$
This instruction is used to add a specified constant value to the operand placed on the S bus. The constant will be between the values of 0 and 15 . The constant value is specified by the unused register file address (A port) not required to support this instruction. Forcing the carry input will add an additional one to the result. The status set by the add immediate instruction is as follows:

| N | $\rightarrow$ Result MSB equal one |
| :--- | :--- |
| OVR | $\rightarrow$ Arithmetic signed overflow |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ Carry out equal one |
| Z | $\rightarrow$ Result equal zero |

subtract immediate instruction (SUBI): 17-10 $=7816$
This instruction is used to subtract a specified constant value from the operand placed on the $S$ bus. The constant value is specified by the unused register file address (A port) that is not required to support this instruction. The constant applied is the least significant four bits of a two's complement number. The device sign extends the constant over the entire word length. The status set by the subtract immediate instruction is as follows:

| N | $\rightarrow$ | Result MSB equal one |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Arithmetic signed overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |

## byte instructions

There are eight byte instructions in Group 3. These instructions modify selected bytes of the operand on the S bus. A byte is selected by forcing $\overline{\mathrm{SIOO}}$ to a low value (same as SET1, SETO, TB1, and TBO instructions). Multiple bytes may be selected only if they are adjacent to one another.

NOTE: At least one byte must be nonselected during these instructions.
The nonselected bytes are passed through unaltered. Byte status is forced through the most significant package except for the sign of the result ( N ), which is forced to zero (low). The status set by the byte instructions is as follows:
(Most Significant Package)
$N \quad \rightarrow \quad$ None (force to zero)
OVR $\rightarrow$ Byte signed overflow
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Byte carry out equal one
$\mathrm{Z} \rightarrow \quad$ Byte result equal to zero

## (Selected BYTES - other than MSP)

G $\quad \rightarrow \quad$ Normal generate
$\mathrm{P} \quad \rightarrow \quad$ Normal propagate
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Normal carry out
Z $\quad \rightarrow \quad$ Result equal to zero
(Nonselected BYTES-other than MSP)
G $\quad \rightarrow \quad$ No generate (force to one)
$\mathrm{P} \rightarrow$ Propagate (force to zero)
$C_{n+8} \rightarrow C_{n}$
$Z \rightarrow \quad$ None (force to one)

## group 4 instructions

Hex code 0 of Group 1 instructions is used to access Group 4 instructions. Group 4 instructions are summarized in Table 6.

TABLE 6. GROUP 4 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| 00 |  | Reserved |
| 10 | SEL | Select S/R |
| 20 | SNORM | Single Length Normalize |
| 30 | DNORM | Double Length Normalize |
| 40 | DIVRF | Divide Remainder Fix |
| 50 | SDIVQF. | Signed Divide Quotient Fix |
| 60 | SMULI | Signed Multiply Iterate |
| 70 | SMULT. | Signed Multiply Terminate |
| 80 | SDIVIN | Signed Divide Initialize |
| 90 | SDIVIS | Signed Divide Start |
| AO | SDIVI | Signed Divide Iterate |
| BO | UDIVIS | Unsigned Divide Start |
| CO | UDIVI | Unsigned Divide Iterate |
| DO | UMULI | Unsigned Multiply Iterate |
| EO | SDIVIT | Signed Divide Terminate |
| FO | UDIVIT | Unsigned Divide Terminate |

select S/R instruction (SEL): 17-10 $=1016$
This instruction is used to pass either the $S$ bus or the $R$ bus to the output depending on the state of the SSF input pin. Normally, the preceding instruction would test the two operands and the resulting status information would be used to force the SSF input pin. SSF $=0$ will output the R bus and SSF $=1$ will output the $S$ bus. The status set by the select $S / R$ instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { Result MSB equal one } \\
\mathrm{OVR} & \rightarrow & \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

## single-length normalize instruction (SNORM): $17-10=\mathbf{2 0 1 6}$

This instruction will cause the contents of the MQ register to shift toward the most significant bit. Zeros are shifted in via the $\overline{\mathrm{O} O O}$ input. The number of shifts performed can be counted and stored in one of the register files by forcing a high at the $\mathrm{C}_{\mathrm{n}}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.
The chip contains conditional logic that inhibits the shift function (and also inhibits the register file increment) if the number within the MQ register is already normalized at the beginning of the instruction (Figure 7). The status set by the single-length normalize instruction is as follows:

| N | $\rightarrow$ | MSB of result |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | MSB XOR 2 nd MSB |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |

SINGLE-LENGTH NORMALIZE

FIGURE 7. SINGLE-AND DOUBLE-LENGTH NORMALIZE
double-length normalize instruction (DNORM): 17-10 $=\mathbf{3 0 1 6}$
This instruction will cause the contents of a double-length word (register file contains the most significant half and the MO register contains the least significant half) to shift toward the most significant bit. Zeros are shifted in via the $\overline{\mathrm{OLOO}}$ input. When the two most significant bits are of opposite value, normalization is complete. This condition is indicated on the microcycle that completes the normalization at the OVR output.
The chip contains conditional logic which inhibits the shift function if the number is already normalized at the beginning of the instruction (Figure 7). The most significant half of the operand must be placed on the S bus. The status set by the double-length normalize instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { MSB of result } \\
\text { OVR } & \rightarrow & \text { MSB XOR 2nd MSB } \\
\mathrm{C}_{n}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Result equal zero }
\end{array}
$$

## multiply operations

The ALU performs three unique types of N by N multiplies each of which produces a 2 N -bit result (Figure 8).
All three types of multiplication proceed via the following recursion:

$$
P(J+1)=2[P(J)+\text { Multiplicand } \times M(8 N-J)]
$$

where
$\mathrm{P}(\mathrm{J}) \quad=$ partial product at iteration number J
$\mathrm{N}=\quad$ number of 'AS888 packages that are cascaded
$\mathrm{P}(\mathrm{J}+1)=$ partial product at iteration number $\mathrm{J}+1$
$J$ varies from 0 to $8 N[N=2$ for $16 \times 16$ multiply]
$\mathrm{M}(8 \mathrm{~N}-\mathrm{J})=$ mode bit (unique to multiply type)
2 denotes some type of shift (unique to multiply)
Notice that by proper choice of mode terms and shifting operations, signed, unsigned, and mixed multiplies (signed times unsigned) may be performed.

All multiplies assume that the multiplier is stored in MO before the operation begins (in the case of mixed multiply, the unsigned number must be the multiplier).

The processor has the following multiply instructions:

1. SIGNED MULTIPLY ITERATE (SMULI): $17-10=6016$
2. SIGNED MULTIPLY TERMINATE (SMULT): $17-10=7016$
3. UNSIGNED MULTIPLY ITERATE (UMULI): $17-10=\mathrm{DO}_{16}$
SMULI, SMULT


LSI Devices

The signed multiply iterate (SMULI) instruction performs a signed times signed iteration. This instruction interprets $M(8 N-J)$ as the $8 \mathrm{~N}-J$ bit of the multiplier. The shift is a double-precision right shift one bit. This instruction is repeated 15 times for a $16 \times 16$ signed multiply. This instruction will be used 16 consecutive times for a mixed multiplication.

The signed multiply terminate (SMULT) instruction provides correct (negative) weighting of the sign bit of a negative multiplier in signed multiplication. The instruction is identical to signed multiply iterate (SMULI) except that $M(8 N-J)$ is interpreted as -1 if the sign bit of the multiplier is 1 , and 0 if the sign bit of the multiplier is 0 .
The unsigned multiply iterate (UMULI) performs an unsigned multiplication iteration. This instruction interprets $\mathrm{M}(8 \mathrm{~N}-\mathrm{J})$ as the $8 \mathrm{~N}-\mathrm{J}$ bit of the multiplier. The shift is a double-precision right shift with the carry out from the $P(J)+$ Multiplicand $\times M(8 N-J)$ operation forced into bit $8 N$ of $P(J+1)$. This instruction is used in unsigned and mixed multiplication.

## signed multiplication

Signed multiplication performs an $8 \mathrm{~N}+2$ clock two's complement multiply. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MQ with multiplier
SMULI (repeat $8 \mathrm{~N}-1$ times)

SMULT $\quad$ S port $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Product (MSH)
At completion, the accumulator will contain the 8 N most significant bits and the MQ contains the 8 N least significant bits of the product.

The status for the signed multiply iterate should not be used for any testing (overflow is not set by SMULI). The following status is set for the signed multiply terminate instruction:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Forced to zero
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal to one
$\mathrm{Z} \rightarrow \quad$ Double precision result is zero

## unsigned multiplication

Unsigned multiplication produces an unsigned times unsigned product in $8 \mathrm{~N}+2$ clocks. The instructions necessary to produce an algebraically correct result proceed in the following manner:

Zero register to be used for accumulator
Load MO with multiplier
UMULI ( 8 N times)
Sport $=$ Accumulator
R port $=$ Multiplicand
F port $=$ Iteration result (product MSH on final result)

Upon completion, the accumulator will contain the 8 N most significant bits and the MQ contains the 8 N least significant bits of the product.
The status set by the unsigned multiply iteration is meaningless except on the final execution of the instruction. The status set by the unsigned multiply iteration instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ Result MSB equal one
OVR $\rightarrow$ Forced to zero
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal to one
Z $\rightarrow$ Double-precision result is zero
mixed multiplication
Mixed multiplication multiplies a signed multiplicand times an unsigned multiplier to produce a signed result in $8 \mathrm{~N}+2$ clocks. The steps are as follows:

Zero register used for accumulator
Load MO with unsigned multipler


Upon completion, the accumulator will contain the 8 N most significant bits and the MQ will contain the 8 N least significant bits of the product.
The following status is set by the last SMULI instruction:
$\mathrm{N} \rightarrow$ Result MSB equal one
OVR $\rightarrow$ Forced to zero
$\mathrm{C}_{\mathrm{n}}+8 \rightarrow$ Carry out equal to one
Z $\rightarrow$ Double-precision result is zero

## divide operations

The divide uses a nonrestoring technique to perform both signed and unsigned division of a 16 N bit integer dividend and an 8 N bit integer divisor (Figure 9). It produces an 8 N integer quotient and remainder.
The remainder and quotient will be such that the following equation is satisfied:

$$
\text { (Quotient) } \times(\text { Divisor })+\text { Remainder }=\text { Dividend }
$$

The processor has the following divide instructions:

1. UNSIGNED DIVIDE START (UDIVIS): $17-10=\mathrm{BO}_{16}$
2. UNSIGNED DIVIDE ITERATE (UDIVI): $17-10=\mathrm{C} 016$
3. UNSIGNED DIVIDE TERMINATE (UDIVIT): $17-10=\mathrm{FO}_{16}$
4. SIGNED DIVIDE INITIALIZE (SDIVIN): $17-10=8016$
5. SIGNED DIVIDE OVERFLOW TEST (SDIVO): $17-10=$ AF $_{16}$
6. SIGNED DIVIDE START (SDIVIS): $17-10=90_{16}$
7. SIGNED DIVIDE ITERATE (SDIVI): $17-10=A 0_{16}$
8. SIGNED DIVIDE TERMINATE (SDIVIT): $17-10=E 0_{16}$
9. DIVIDE REMAINDER FIX (DIVRF): $17-10=4016$
10. SIGNED DIVIDE QUOTIENT FIX (SDIVQF): $17-10=5016$

SDIVT

FIGURE 9. DIVIDE OPERATIONS


FIGURE 9. DIVIDE OPERATIONS (Continued)

The unsigned divide iterate start (UDIVIS) instruction begins the iterate procedure while testing for overflow. Overflow is reported when the first subtraction of the divisor from the MSH of the dividend produces carry out. The test detects quotient overflow and divide by zero.

The unsigned divide iterate terminate (UDIVIT) instruction completes the iterate procedure generating the last quotient bit.

The signed divide initialize (SDIVIN) instruction prepares for iteration by shifting the dividend and storing the sign of the dividend for use in the following instructions and overflow tests.

The signed divide overflow test (SDIVO) checks for overflow possibilities. This instruction may be deleted from the divide operation if the OVR pin is ignored. If it is removed some overflow conditions will go undetected. $\overline{W E}$ must be high (writing inhibited) when this instruction is used.

The signed divide iterate start (SDIVIS) instruction calculates the difference between the divisor and MSH of the dividend. Partial detection of overflow is also done during this instruction. Operations with like signs (positive quotient) and division by zero will overflow during this instruction (including zero divisor). Operations with unlike signs are tested for overflow during the signed divide quotient fix instruction (SDIVQF). Partial overflow results are saved and will be used during SDIVOF when overflow is reported.

The signed divide iterate (SDIVI) instruction forms the quotient and remainder through iterative subtract/addshift operations of the divisor and dividend. One quotient bit is generated on each clock.

The signed divide iterate terminate (SDIVIT) instruction completes the iterate procedure, generating the last quotient bit. It also tests for a remainder equal to zero, which determines the action to be taken in the following correction (fix) instructions.
The divide remainder fix (DIVRF) instruction corrects the remainder. If a zero remainder was detected by the previous instructions, the remainder is forced to zero. For nonzero remainder cases where the remainder and dividend have the same sign, the remainder is correct. When the remainder and dividend have unlike signs, a correction add/subtract of the divisor to the remainder is performed.

The signed divide quotient fix (SDIVQF) instruction corrects the quotient if necessary. This correction requires adding one to the incorrect quotient. An incorrect quotient results if the signs of the divisor and dividend differ and the remainder is nonzero. An incorrect quotient also results if the sign of the divisor is negative and the remainder is zero.

Overflow detection is completed during this instruction. Overflow may be generated for differing signs of the dividend and divisor. The partial overflow test result performed during SDIVIS is ORed with this test result to produce a true overflow indication.
signed divide usage
The instructions necessary to perform an algebraically correct division of signed numbers are as follows:
Load MQ with the least significant half of the dividend
SDIVIN $\quad$ S port $=$ MSH of dividend
R port $=$ Divisor
F port $=$ Intermediate result
SDIVO $\quad$ S port $=$ Result of SDIVIN R port $=$ Divisor F port $=$ Test result
( $\overline{W E}$ must be high)
SDIVIS $\quad$ S port $=$ Result of SDIVIN
R port $=$ Divisor
F port $=$ Intermediate result

| SDIVI (8N-2 times) | S port $=$ Result of SDIVIS (or SDIVI) |
| :--- | :--- |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
| SDIVIT | S port $=$ Result of last SDIVI |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
|  | S port $=$ Result of SDIVIT |
|  | R port $=$ Divisor |
|  | F port $=$ Remainder |
|  | S port $=$ MQ register |
|  | R port $=$ Divisor |
|  | F port $=$ Quotient |

The status of all signed divide instructions except SDIVIN, DIVRF, and SDIVQF is as follows:

```
N }->\mathrm{ Forced to zero
OVR 献 Forced to zero
Cn+8 }\mp@subsup{C}{n}{}\mathrm{ Carry out equal to one
Z }\quad->\quad\mathrm{ Intermediate result is zero
```

The status of the SDIVIN instruction is as follows:

| N | $\rightarrow$ | Forced to zero |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Forced to zero |
| $\mathrm{C}_{\mathrm{n}}+8$ |  | Forced to zero |
| Z | $\rightarrow$ | Divisor is zero |

The status of the DIVRF instruction is as follows:

| N | $\rightarrow$ | Forced to zero |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Forced to zero |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal to one |
| Z | $\rightarrow$ | Remainder is zero |

The status of the SDIVQF instruction is as follows:

| N | $\rightarrow$ | Sign of quotient |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Divide overflow |
| $\mathrm{C}_{\mathrm{n}}+8$ | $\rightarrow$ | Carry out equal to one |
| Z | $\rightarrow$ | Quotient is zero |

The quotient is stored in the MQ register and the remainder is stored in the register file location that originally held the most significant word of the dividend. If fractions are divided, the quotient must be shifted right one bit and the remainder right three bits to obtain the correct fractional representations.

The signed division algorithm is summarized in Table 7.

TABLE 7. SIGNED DIVISION ALGORITHM

| OP <br> CODE | MNEMONIC | CLOCK <br> CYCLES | INPUT <br> S PORT | INPUT <br> R PORT | OUTPUT <br> F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMQ | 1 | Dividend (LSH) | - | Dividend (LSH) |
| 80 | SDIVIN | 1 | Dividend (MSH) | Divisor | Remainder (N) |
| AF | SDIVO | 1 | Remainder (N) | Divisor | Test Result |
| 90 | SDIVIS | 1 | Remainder (N) | Divisor | Remainder (N) |
| AO | SDIVI | $8 N-2^{\dagger}$ | Remainder (N) | Divisor | Remainder (N) |
| EO | SDIVIT | 1 | Remainder (N) | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |
| 50 | SDIVQF | 1 | MQ Register | Divisor | Quotient . |

${ }^{\dagger} \mathrm{N}=$ Number of cascaded packages.
unsigned divide usage
The instructions necessary to perform an algebraically correct division of unsigned numbers are as follows:
Load MO with the least significant half of the dividend

|  | S port $=$ MSH of dividend |
| :--- | :--- |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
| UDIVI (8N-1 times) | S port $=$ Result of UDIVIS (OR UDIVI) |
|  | R port $=$ Divisor |
|  | F port $=$ Intermediate result |
| UDIVIT | S port $=$ Result of Iast UDIVI |
|  | R port $=$ Divisor |
|  | F port $=$ Remainder (unfixed) |
|  | S port $=$ Result of UDIVIT |
|  | R port $=$ Divisor |
|  | F port $=$ Remainder |

The status of all unsigned divide instructions except UDIVIS is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \text { Forced to zero } \\
\mathrm{OVR} & \rightarrow \text { Forced to zero } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \text { Carry out equal to one } \\
\mathrm{Z} & \rightarrow \\
\text { Intermediate result is zero }
\end{array}
$$

The status of the UDIVIS instruction is as follows:

$$
\begin{array}{ll}
\mathrm{N} & \rightarrow \\
\text { Forced to zero } \\
\text { OVR } & \rightarrow \text { Divide overflow } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow \text { Carry out equal to one } \\
\mathrm{Z} & \rightarrow \\
\text { Intermediate result is zero }
\end{array}
$$

If fractions are divided, the remainder must be shifted right two bits to obtain the correct fractional representation. The quotient is correct as is. The quotient is stored in the MQ register at the completion of the divide.

The unsigned division algorithm is summarized in Table 8.

TABLE 8. UNSIGNED DIVISION ALGORITHM

| OP <br> CODE | MNEMONIC | CLOCK <br> CYCLES | INPUT <br> S PORT | INPUT <br> R PORT | OUTPUT <br> F PORT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| E4 | LOADMQ | 1 | Dividend (LSH) | - | Dividend (LSH) |
| BO | UDIVIS | 1 | Dividend (MSH) | Divisor | Remainder (N) |
| CO | UDIVI | $8 N-1 t$ | Remainder (N) | Divisor | Remainder (N) |
| FO | UDIVIT | 1 | Remainder (N) | Divisor | Remainder (Unfixed) |
| 40 | DIVRF | 1 | Remainder (Unfixed) | Divisor | Remainder |

$\dagger \mathrm{N}=$ Number of cascaded packages.

## group 5 instructions

Hex code F of Group 1 instructions is used to access Group 5 instructions. Group 5 instructions are summarized in Table 9.

TABLE 9. GROUP 5 INSTRUCTIONS

| INSTRUCTION BITS (I7-IO) <br> OP CODE (HEX) | MNEMONIC | FUNCTION |
| :---: | :---: | :--- |
| OF | CLR | Clear |
| $1 F$ | CLR | Clear |
| $2 F$ | CLR | Clear |
| $3 F$ | CLR | Clear |
| $4 F$ | CLR | Clear |
| $5 F$ | CLR | Clear |
| $6 F$ | CLR | Clear |
| $7 F$ | BCDBIN | BCD to Binary |
| $8 F$ | EX3BC | Excess-3 Byte Correction |
| $9 F$ | EX3C | Excess-3 Word Correction |
| AF | SDIVO | Signed Divide Overflow Check |
| BF | CLR | Clear |
| CF | CLR | Clear |
| DF | BINEX3 | Binary to Excess-3 |
| EF | CLR | Clear |
| FF | NOP | No Operation |

clear instructions (CLR)
There are 11 clear instructions listed in Table 9. The instructions force the ALU output to be zero and the BCD flip-flops to be cleared. The status set by the clear instruction is as follows:

$$
\begin{array}{lll}
\mathrm{N} & \rightarrow & \text { None (force to zero) } \\
\text { OVR } & \rightarrow & \text { None (force to zero) } \\
\mathrm{C}_{\mathrm{n}}+8 & \rightarrow & \text { None (force to zero) } \\
\mathrm{Z} & \rightarrow & \text { Active (one) }
\end{array}
$$

no operation instruction (NOP): 17-10 $=\mathrm{FF}_{16}$
This instruction is identical to the clear instructions except that the BCD flip-flops retain their old value.

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

excess- 3 correction instructions (EX3BC, EX3C)
Two excess- 3 correction instructions are available:

1. Excess-3 byte correction (EX3BC): 17-10 $=8 \mathrm{~F}_{16}$
2. Excess-3 word correction (EX3C): $17-10=9 F 16$

One instruction supports the byte mode and the other supports the word mode. These instructions correct the excess -3 additions (subtractions) in either the byte or word mode. For correct excess- 3 arithmetic, this instruction must follow each add/subtract. The operand must be on the S port.

NOTE: The previous arithmetic overflow should be ignored.
The status of the EX3C instruction is as follows:
$N \quad \rightarrow \quad$ MSB of result
OVR $\rightarrow$ Signed overflow
$C_{n}+8 \rightarrow$ Carry out equal one
$Z \rightarrow \quad$ None (force to one)
The status of the EX3BC instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ None (force to zero)
OVR $\rightarrow$ Byte signed overflow
$C_{n}+8 \rightarrow$ Carry out equal one
Z $\quad \rightarrow \quad$ None (force to one)
radix conversions
Conversions between decimal and binary number representations are performed with the aid of two special instructions: BINEX3 and BCDBIN. (Figure 10)
$B C D$ to binary instructions (BCDBIN): 17-IO =7F16
This instruction (Figure 11) allows the user to convert an N -digit BCD number to a 4 N -bit binary number in $4(N-1)$ plus 8 clocks. This function sums the $R$ bus, the $S$ bus, and the $C_{n}$ bit, performs an arithmetic left shift on the ALU result, and simultaneously circular shifts the MQ left. The status set by the BCD to binary instruction is as follows:
$\mathrm{N} \quad \rightarrow \quad$ MSB of result
OVR $\rightarrow$ Signed arithmetic overflow ${ }^{\dagger}$
$C_{n+8} \rightarrow$ Carry out equal one
$Z \quad \rightarrow \quad$ Result equal zero
$\dagger$ Overflow may be the result of an ALU operation or the arithmetic left shift operation.

The following code illustrates the BCD to binary conversion technique.
Let ACC be an accumulator register
Let NUM be the register which contains the BCD number
Let MSK be a mask register

| M1: | LOADMQ NUM | ; LOAD MQ WITH BCD NUMBER |
| :---: | :---: | :---: |
| M2: | SUB ACC, ACC, SLCMO | ; CLEAR ACC AND ALIGN MQ |
| M3: | SUB, MSK, MSK, SLCMQ | ; CLEAR MSK AND ALIGN MQ |
| M4: | SLCMQ | ; ALIGN |
| M5: | SLCMQ | ; ALIGN |
| M6: | ADDI ACC, MSK, 1510 | ; MSK = 1510 |
|  |  | ; REPEAT L1 THRU L4 <br> ; $\mathrm{N}-1$ TIMES ( $\mathrm{N}=$ number of <br> ; $B C D$ digits) |
| L1: | AND MQ, MSK, R1, SLCMO | ; EXTRACT ONE DIGIT <br> ; ALIGN MQ |
| L2: | ADD, ACC, R1, R1, SLCMQ | $\begin{aligned} & \text {; ACC + DIGIT } \\ & \text {; IS STORED IN R1 } \\ & \text {; ALIGN MQ } \end{aligned}$ |
| L3: | BCDBIN, R1, R1, ACC | $\begin{aligned} & ; 4 \times(\mathrm{ACC}+\mathrm{DIGIT}) \\ & ; \text { IS STORED IN ACC } \\ & \text {; ALIGN MQ } \end{aligned}$ |
| L4: | BCDBIN, ACC, R1, ACC | $; 10 \times($ ACC + DIGIT $)$ ; IS STORED IN ACC ; ALIGN MQ |
| M7: | AND MQ, MSK, R1 | ; FETCH LAST DIGIT |
| M8: | $A C C+R 1 \rightarrow A C C$ | ; ADD IN LAST DIGIT |

The previous code generates a binary number by executing the standard conversion formula for a BCD number (shown for 32 bits).

$$
A B C D=[(A \times 10+B) \times 10+C] \times 10+D
$$

Notice that the conversion begins with the most significant BCD digit and that the addition is performed in radix 2.

## binary to excess-3 instructions (BINEX3): $17-10=$ DF $_{16}$

This instruction (Figure 12) allows the user to convert an N -bit binary number to an $\mathrm{N} / 4$-bit excess- 3 number representation in $2 N+3$ clocks. The data on the $R$ and $S$ ports are summed with the MSB of the MQ register. The MO register is simultaneously shifted left circularly. The status set by the binary to excess-3 instruction is as follows:

| N | $\rightarrow$ | MSB of result |
| :--- | :--- | :--- |
| OVR | $\rightarrow$ | Signed arithmetic overflow |
| $\mathrm{C}_{n}+8$ | $\rightarrow$ | Carry out equal one |
| Z | $\rightarrow$ | Result equal zero |



The following illustrates the binary to excess-3 conversion technique.
Let NUM be a register containing an unsigned binary number
Let $A C C$ be an accumulator

| M1: | LOADMQ NUM | ; LOAD MO WITH BINARY <br> ; NUMBER |
| :---: | :---: | :---: |
| M2: | CLEAR ACC | ; CLEAR ACC |
| M3: | SET1 ACC H/33/ | ; ACC $\rightarrow$ HEX/3333 |
| L1: | BINEX3 ACC, ACC, ACC | ; DOUBLE ACC AND ADD IN <br> ; MSB OF MQ <br> ; ALIGN MQ |
| L2: | EX3C ACC, ACC | ; EXCESS 3 CORRECT <br> ; REPEAT L1 AND L2 <br> ; N-1 TIMES |

The previous code generates an excess -3 number by executing the standard conversion formula for a binary number.

$$
a_{n} 2^{n}+a_{n-1} 2^{n-1}+a_{n}-2^{2 n-2}+\ldots a_{0} 2^{0}=\left[\left(2 a_{n}+a_{n-1}\right) 2+a_{n-2}\right] 2+\ldots a_{0}
$$

Notice that the conversion begins with the most significant binary bit and that the addition is performed in radix-10 (excess-3).

## decimal arithmetic

Decimal numbers are represented in excess -3 code. Excess- 3 code numbers may be generated by adding three to each digit of a Binary Coded Decimal (BCD) number. The hardware necessary to implement excess-3 arithmetic is only slightly different from binary arithmetic. Carries from one digit to another during addition in BCD occur when the sum of the two digits plus the carry-in is greater than or equal to ten. If both numbers are excess-3, the sum will be excess-6, which will produce the proper carries. Therefore, every addition or subtraction operation may use the binary adder. To convert the result from excess- 6 to excess- 3 , one must consider two cases resulting from a BCD digit add: (1) where a carry-out is produced, and (2) where a carry-out is not produced. If a carry-out is not produced, three must be subtracted from the resulting digit. If a carry is produced, the digit is correct as a $B C D$ number. For example, if $B C D 5$ is added to BCD 6, the excess -3 result would be $8+9=1$ (with a carry). A carry rolls the number through the illegal BCD representations into a correct BCD representation. Binary 3 must be added to digit positions that produce a carry-out to correct the result to an excess-3 representation. Every addition and subtraction instruction stores the carry generated from each 4-bit digit location for use by the excess-3 correction functions. These correction instructions (word or byte) must be executed in the clock cycle immediately after the addition or subtraction operation.

Signed numbers may be represented in ten's complement form by complementing the excess-3 number. As an example, add the decimal number -423 to the decimal number 24 , which will be represented by 8 AA and 357 in excess-3, respectively.

| 8AA |  |
| ---: | :--- |
| 357 |  |
| C01 | Sum |
| 011 | Carry |
| 934 | Excess-3 correct |
| $-6 C C$ | Complement |
| -399 | Excess-3 to decimal |

Complements of excess- 3 numbers may be generated by subtracting the excess -3 number from an excess- 3 zero followed by an excess-3 correct.

## excess-3 to USASCII conversion

Input/output devices or files represent numbers differently than high-speed central processing units. 1/0 devices handle all alphanumeric data similarly. CPUs handle more numeric data than alphabetic data and store numeric data in packed form to minimize calculation throughout and reduce memory requirements. To represent the cost of a shirt that was $\$ 10.96$, the I/O device would handle the six USASCII characters " $\$$ ", " 1 "," $0^{\prime \prime}$,"."," 9 "," 6 ", which would require 6 bytes of storage. In packed BCD, this number could be stored as 1096 in two bytes of data. The 'AS895 may be programmed to perform data format conversions such as converting excess-3 BCD to USASCII.

The code below converts a packed word of excess-3 BCD to two unpacked words of USASCII code. Instruction "MAIN1" reads the input word from memory into Register 0 (RO). For illustrative purposes, suppose this data was 43C9, which represents the $\$ 10.96$ shirt in excess- 3 code. "MAIN2" and "MAIN3" generate a constant of 2D2D 16, which is an offset constant to convert excess-3 numbers to USASCII. "MAIN4" copies RO into R2 to set up the subroutine parameters and calls the subroutine "UNPACK", UNPACK2' strips off the upper byte leaving OOC9 in R2. 'UNPACK2' and 'UNPACK3' together shift the contents of R2 one character position and places the result OC90 into R3. "UNPACK4" performs a logical OR operation to produce OCD9 in register 2. "UNPACK5" clears the most significant nibble in each byte to produce OCO9 in R2. "UNPACK6" adds the constant 2D2D16 to R2 to produce 3936 the USASCII representation of the numerals 96 and returns program control to "MAIN5'. "MAIN5" through "MAIN9" align the two remaining characters and call UNPACK and the process repeats. Finally the USASCII representation of 1096 is stored into memory. (Note that no attempt was made to pack the "\$" or "." characters.)

Unpacking Excess-3 to USASCII:

| MAIN1: | READ, RFA 0 ) | READ IN PACKED EXCESS-3 |
| :---: | :---: | :---: |
| MAIN2: | XOR, RFA (4), RFB(4), RFC(4) | CLEAR R4 |
| MAIN3: | SET1, RFB(40), RDC(2), RFA(D), MSH, LSH | $\begin{aligned} & \text {; GENERATE HEXADECIMAL } \\ & ; 2 \mathrm{D}_{2} \mathrm{D}_{16} \end{aligned}$ |
| MAIN4: | MOVE, RFA(0), RFC(2), JSR(UNPACK) | ; COPY RFA(0) INTO RFA(2), ; PROCEDURE CALL |
| MAIN5: | MOVE, RFA(2), RFC(1) | TWO CHARACTERS IN R1 |
| MAIN6: | ADDRS, RFB(0), RFA (0), RFC(0), SLC | RO SHIFTED 2 |
| MAIN7: | ADDRS, RFB $(0), \operatorname{RFA}(0), \mathrm{RFC}(0), \mathrm{SLC}$ | RO SHIFTED 4 |
| MAIN8: | ADDRS, RFB(0), RFA (0), RFC(0), SLC | RO SHIFTED 6 |
| MAIN9: | ADDRS, RFB(0), RFA(0), RFC(0), SLC JSR (UNPACK) | RO SHIFTED 8 |
| MAIN10: | STORE, RFA(1) | ; STORE USASCII, TWO <br> ; CHARACTERS IN R2 |
| MAIN11: | STORE, RFA(2) | ; STORE USASCII |
| UNPACK1: | SETO, RFB (2), RFC(F), MSH | ; CLEAR MSH |
| UNPACK2: | ADDRS, RFB(2), RFA(2), RFC(3), SLC | ; SHIFT R2 TWO PLACES |
| UNPACK3: | ADDRS, RFB(3), RFA(3), RFC(3), SLC | ; SHIFT R3 TWO PLACES |
| UNPACK4: | OR, RFB(2), RFA(3), RFC(2) | OR R3 TO R2 |
| UNPACK5: | SETO, RFB(2), RFC(F), RFA(0), LSH, MSH | ; CLEAR MOST SIGNIFICANT 4 <br> ; BITS IN EACH BYTE |
| UNPACK6: | ADDRS, RFB(2), RFB(4), RFC(2), RTS | ; ADD HEX 2D, RETURN |

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

absolute maximum rating over operating free-air temperature range (unless otherwise noted)

```Supply voltage, VCC17 V
```

Supply voltage, VCC2 ..... 3 V
Input voltage ..... 7 V
High-level voltage applied to 3 -state outputs ..... 5.5 V
Operating case temperature range: SN54AS895 ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Operating free-air temperature range: SN74AS895, SN74AS895-1 ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  |  | 54AS |  |  | $\begin{aligned} & \text { 774AS } \\ & \text { 74AS8 } \end{aligned}$ | $\begin{aligned} & 895 \\ & 95-1 \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{\text {CC1 }}$ | I/O supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {CC2 }}$ | STL internal logic supply voltage |  | 1.9 | 2 | 2.1 | 1.9 | 2 | 2.1 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltageHigh-level output current |  |  |  | 0.8 |  |  | - 0.8 | V |
| ${ }^{\mathrm{I} \mathrm{OH}}$ |  |  |  |  | -1 |  |  | -2.6 | mA |
| ${ }^{\text {O OL }}$ | Low-level output current | All output except $\overline{\mathrm{G}}$ and ZERO |  |  | 8 |  |  | 8 | mA |
|  |  | $\overline{\mathrm{G}}$ |  |  | 16 | 16 |  |  |  |
|  |  | ZERO | 48 |  |  | 48 |  |  |  |
| $\mathrm{T}_{\mathrm{C}}$ | Operating case temperatureOperating free-air temperature |  | -55 |  | 125 |  |  |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {A }}$ |  |  |  |  |  | 0 |  | 70 |  |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | SN54AS895 |  | SN74AS895 SN74AS895-1 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ MAX | MIN | TYP ${ }^{\dagger}$ MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \quad \mathrm{I}=-18 \mathrm{~mA}$ |  | -1.2 |  | -1.2 | V |
| VOH | All outputs except ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{IOH}=-1 \mathrm{~mA}$ | 2.4 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{l}_{\mathrm{OH}}=-2.6 \mathrm{~mA}$ | 0.1 |  | 2.4 |  |  |
| ${ }^{1} \mathrm{OH}$ | ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  |  | 0.1 | mA |
| $\mathrm{V}_{\text {OL }}$ | All outputs except $\overline{\mathrm{G}}$ and ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V},{ }^{\prime} \mathrm{OL}=8 \mathrm{~mA}$ |  | 0.5 |  | 0.5 | v |
|  | $\overline{\mathrm{G}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, 1 \mathrm{OL}=16 \mathrm{~mA}$ |  | 0.5 |  | 0.5 |  |
|  | ZERO | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}, \mathrm{I}^{\mathrm{OL}}=48 \mathrm{~mA}$ |  | 0.5 |  | 0.5 |  |
| 1 | I/O | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=5.5 \mathrm{~V}$ |  | 0.1 |  | 0.1 | mA |
|  | All others | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=7 \mathrm{~V}$ |  | 0.1 |  | 0.1 |  |
| $\mathrm{lil}^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=2.7 \mathrm{~V}$ |  | 20 |  | 20 | $\mu \mathrm{A}$ |
| $\mathrm{IL}^{\ddagger}{ }^{\ddagger}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{1}=0.5 \mathrm{~V}$ |  | -0.4 |  | -0.4 | mA |
| $10^{8}$ |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | -30 | -112 | mA |
| ICC1 |  | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$ |  | 150 |  | 130 | mA |
| ${ }^{\text {I CC2 }}$ |  | $\mathrm{V}_{\mathrm{CC} 2}=2.1 \mathrm{~V}$ |  | 410 |  | 390 | mA |

[^39]
## 8-BIT MEMORY ADDRESS GENERATORS

SN54AS895 maximum switching characteristics, $\mathrm{V} C \mathrm{C}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{TC}=-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $\mathrm{C}_{n+8}$ | $\overline{\mathbf{G}}, \overline{\mathbf{P}}$ | $z^{\dagger}$ | N | OVR | DA | DB | $\overline{010}$ | $\overline{\text { SIO }}$ |  |
| ${ }^{\text {p }}$ p | $\begin{aligned} & \mathrm{A} 3-\mathrm{AO} \\ & \mathrm{~B} 3-\mathrm{BO} \end{aligned}$ | 62 | 42 | 48 | 69 | 62 | 60 | 18 | - | 65 | 66 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 47 | 28 | 28 | 58 | 50 | 42 | - | - | 50 | 50 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 25 | 14 | - | 32 | 24 | 18 | - | - | 32 | 32 |  |
|  | EA | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | $\overline{E B}$ | 54 | 32 | 35 | 62 | 52 | 52 | - | - | 58 | 58 |  |
|  | 17-10 | 58 | 32 | 32 | 62 | 52 | 41 | - | - | 58 | 58 |  |
|  | $\overline{\mathrm{OEB}}$ | - | - | - | - | - | - | - | 14 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 14 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{O} \overline{\mathrm{O}}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{SIO}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | 22 | - | - | - | - | - |  |
|  | CK | 68 | 60 | 56 | 62 | 50 | 68 | 38 | 30 | 70 | 70 |  |
|  | OEA | - | - | - | - | - | - | 14 | - | - | - - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 14 | - | - | - | - |  |

${ }^{\dagger}$ Load resistor R1 $=100 \Omega$.
${ }^{\ddagger}$ For byte instructions only.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
SN74AS895 maximum switching characteristics, $\mathrm{VCC}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{TA}_{\mathrm{C}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $C_{n+8}$ | $\overline{\mathrm{G}}, \overline{\mathbf{P}}$ | $z^{+}$ | N | OVR | DA | DB | $\overline{\mathrm{QIO}}$ | $\overline{\text { SIO }}$ |  |
| $t_{\text {pd }}$ | $\begin{aligned} & \text { A3-AO } \\ & \text { B3-BO } \end{aligned}$ | 54 | 36 | 42 | 60 | 52 | 50 | - | - | 58 | 58 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \end{aligned}$ | 44 | 26 | 26 | 52 | 46 | 38 | - | - | 44 | 44 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 25 | 9 | - | 32 | 24 | 18 | - | - | 31 | 31 |  |
|  | $\overline{E A}$ | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | $\overline{\mathrm{E}} \overline{\mathrm{B}}$ | 49 | 29 | 29 | 58 | 49 | 47 | - | - | 54 | 54 |  |
|  | 17-10 | 55 | 30 | 30 | 60 | 49 | 39 | - | - | 54 | 54 |  |
|  | $\overline{\text { OEB }}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{Q} 1 \mathrm{O}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{SIO}}(\mathrm{n})$ <br> Shift | 15 | - | - | 24 | 19 | - | - | - | - | - |  |
|  | CK | 58 | 55 | 52 | 61 | 52 | 62 | 35 | 25 | 60 | 60 |  |
|  | $\overline{O E A}$ | - | - | - | - | - | - | 12 | - | - | - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 12 | - | - | - | - |  |

[^40]$\ddagger$ For byte instructions only.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54AS895, SN74AS895 8-BIT MEMORY ADDRESS GENERATORS

SN74AS895-1 maximum switching characteristics, $\mathrm{V}_{\mathrm{C}} \mathrm{C}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ (see Note 1)

| PARAMETER | $\begin{gathered} \hline \text { FROM } \\ \text { (INPUT) } \end{gathered}$ | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $\mathrm{c}_{\mathrm{n}+8}$ | $\overline{\mathrm{G}}, \overline{\mathrm{P}}$ | $\mathrm{z}^{\dagger}$ | N | OVR | DA | DB | $\overline{\mathrm{O}} \overline{\mathrm{O}}$ | $\overline{\text { SIO }}$ |  |
| ${ }^{\text {tpd }}$ | $\begin{aligned} & \text { A3-AO } \\ & \text { B3-BO } \end{aligned}$ | 44 | 30 | 36 | 50 | 44 | 44 | 17 | - | 48 | 48 | ns |
|  | $\begin{aligned} & \text { DA7-DAO, } \\ & \text { DB7-DBO } \\ & \hline \end{aligned}$ | 36 | 24 | 24 | 46 | 41 | 32 | - | - | 40 | 40 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 22 | 8 | - | 27 | 21 | 16 | - | - | 25 | 25 |  |
|  | $\overline{E A}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | $\overline{E B}$ | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | 17-10 | 46 | 27 | 27 | 50 | 42 | 35 | - | - | 45 | 45 |  |
|  | $\overline{\mathrm{OEB}}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{Q} O} \mathrm{O}(\mathrm{n})$ <br> Shift | 14 | - | - | 20 | - | - | - | - | - | - |  |
|  | $\overline{\mathrm{SIO}}(\mathrm{n})$ Shift | 14 | - | - | 20 | 18 | - | - | - | - | - |  |
|  | CK | 50 | 46 | 46 | 50 | 50 | 50 | 30 | 22 | 50 | 50 |  |
|  | $\overline{\text { OEA }}$ | - | - | - | - | - | - | 12 | - | - | - |  |
|  | SSF ${ }^{\ddagger}$ | - | - | - | - | - | 12 | - | - | - | - |  |

${ }^{\dagger}$ Load resistor R1 $=100 \Omega$.
${ }^{\ddagger}$ For byte instructions only.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.
register file write setup and hold times

| PARAMETER |  | SN54AS895 |  | SN74AS895 |  | SN74AS895-1 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MiN | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tsu }}$ | C3-CO | 8 |  | 7 |  | 6 |  | ns |
|  | DB§ | 14 |  | 12 |  | 11 |  |  |
|  | 17-14 | 16 |  | 14 |  | 13 |  |  |
|  | $13-10$ | 24 |  | 22 |  | 21 |  |  |
|  | $\overline{\mathrm{OEY}}$ | 4. |  | 3 |  | 3 |  |  |
|  | Y7-Y0 | 2 |  | 2 |  | 2 |  |  |
|  | WE | 8 |  | 6 |  | 6 |  |  |
|  | $\overline{\mathrm{O}} \mathrm{O}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 6 |  | 5 |  | 5 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |
| $t^{\text {h }}$ | C3-C0 | 0 |  | 0 |  | 0 |  | ns |
|  | DB§ | 0 |  | 0 |  | 0 |  |  |
|  | 17-14 | 0 |  | 0 |  | 0 |  |  |
|  | 13-10 | 0 |  | 0 |  | 0 |  |  |
|  | $\overline{\mathrm{OEY}}$ | 6 |  | 5 |  | 5 |  |  |
|  | Y7-Y0 | 10 |  | 10 |  | 10 |  |  |
|  | $\overline{\text { WE }}$ | 3 |  | 2 |  | 2 |  |  |
|  | $\overline{\mathrm{O} I \mathrm{O}}(\mathrm{n}), \overline{\mathrm{SIO}}(\mathrm{n})$ | 0 |  | 0 |  | 0 |  |  |
|  | SELY | 8 |  | 6 |  | 6 |  |  |

$\S_{\text {DB }}$ (during select instruction) through $Y$ port.
special instruction switching characteristics
During various special instructions, the SSF pin is used to pass required information between the 'AS888 packages which make up a total system.

For instance, during the multiplication process, the LSB of the multiplier determines whether an ADD/SHIFT or SHIFT operation is performed. During multiplication, the SSF pin of the least significant package (LSP) becomes an output pin while all other packages become input pins.

Similarly, during normalization, the required operation depends on whether the two data MSBs are the same or different. Therefore, during normalization the SSF pin of the most significant package (MSP) becomes an output pin while all other packages become input pins.

Tables 10, 11, and 12 list the instructions which force the SSF pin during their execution. The propagation delay from various inputs is also shown. The parameter which limits normal system performance is indicated by a dagger.

TABLE 10. SN54AS895 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LSP | MSP | $\mathrm{C}_{\mathrm{n}}$ | $1(\mathrm{n})$ | CK | $\mathrm{B}(\mathrm{n})$ |  |
| SNORM | 20 |  | X | - | $29^{\dagger}$ | 46 | - | 20 |
| DNORM | 30 |  | $x$ | - | 29 | 55 | $40^{\dagger}$ | 20 |
| DIVRF | 40 |  | $x$ | - | $29^{\dagger}$ | 46 | - | 20 |
| SDIVQF | 50 |  | $x$ | - | $26^{\dagger}$ | - | - | 18 |
| SMULI | 60 | $x$ |  | - | $26^{\dagger}$ | 43 | - | 0 |
| SDIVIN | 80 |  | $x$ | - | 48 | 64 | $44^{\dagger}$ | 0 |
| SDIVIS | 90 |  | $x$ | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| SDIVI | AO |  | $x$ | $26^{\dagger}$ | 51 | 64 | 55 | 0 |
| UDIVIS | B0 |  | $x$ | $18^{\dagger}$ | 45 | 64 | 46 | 0 |
| UDIVI | CO |  | $x$ | $18^{\dagger}$ | 50 | 54 | 40 | 0 |
| UMULI | DO | $x$ |  | - | $25^{\dagger}$ | 48 | - | 0 |
| SDIVIT | EO |  | $x$ | $26^{\dagger}$ | 50 | 56 | 54 | 0 |
| ABS | 48 |  | X | - | 34 | 62 | $39^{\dagger}$ | 20 |
| SMTC | 58 |  | $x$ | - | 29 | 58 | $39^{\dagger}$ | 20 |
| BINEX3 | DF |  | $x$ | - | $29^{\dagger}$ | 58 | - | 18 |
| LOADMQ (Arith) |  | $x$ |  | $23^{\dagger}$ | 34 | 62 | 40 | 0 |
| LOADMQ (Log) |  | X |  | - | 33 | 62 | $40^{\dagger}$ | 0 |
| BADD | 88 |  |  | $18^{\dagger}$ | 58 | 62 | 49 | - |
| BSUBS | 98 |  |  | $18^{\dagger}$ | 58 | 62 | 49 | - |
| BSUBR | A8 |  |  | $18^{\dagger}$ | 58 | 71 | 49 | - |
| BINCS | B8 |  |  | $18^{\dagger}$ | 58 | 60 | 49 | - |
| BINCNS | C8 |  |  | $18^{\dagger}$ | 58 | 71 | 49 | - |
| BXOR | D8 |  |  | - | 58 | - | - | - |
| BAND | E8 |  |  | - | 58 | - | - | - |
| BOR | F8 |  |  | - | 58 | - | - | - |
| EX3BC | 8F |  |  | - | 58 | 46 | $49^{\dagger}$ | - |

[^41]
## SN54AS895, SN74AS895 <br> 8-BIT MEMORY ADDRESS GENERATORS

TABLE 11. SN74AS895 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | $\begin{aligned} & \text { HEX } \\ & \text { CODE } \end{aligned}$ | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LSP | MSP | $\mathrm{C}_{\mathrm{n}}$ | $1(n)$ | CK | $\mathrm{B}_{(\mathrm{n})}$ |  |
| SNORM | 20 |  | X | - | $26^{\dagger}$ | 40 | - | 17 |
| DNORM | 30 |  | x | - | 26 | 52 | $37^{\dagger}$ | 17 |
| DIVRF | 40 |  | X | - | $26^{\dagger}$ | 40 | - | 17 |
| SDIVGF | 50 |  | x | - | $25^{\dagger}$ | - | - | 17 |
| SMULI | 60 | x |  | - | $25^{\dagger}$ | 40 | $\rightarrow$ | 0 |
| SDIVIN | 80 |  | $x$ | - | 38 | 60 | $40^{\dagger}$ | 0 |
| SDIVIS | 90 |  | x | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| SDIVI | AO |  | x | $24^{\dagger}$ | 48 | 60 | 52 | 0 |
| UDIVIS | B0 |  | x | $17^{\dagger}$ | 43 | 60 | 45 | 0 |
| UDIVI | CO |  | X | $17{ }^{\dagger}$ | 44 | 52 | 37 | 0 |
| UMULI | DO | x |  | - | $26^{+}$ | 40 | - | 0 |
| SDIVIT | EO |  | $x$ | $25^{\dagger}$ | 46 | 52 | 49 | 0 |
| ABS | 48 |  | x | - | 32 | 60 | 38 | 17 |
| SMTC | 58 |  | $x$ | - | 26 | 52 | $38^{\dagger}$ | 17 |
| BINEX3 | DF |  | X | - | $26^{\dagger}$ | 40 | - | 17 |
| LOADMO (Arith) |  | x |  | $22^{\dagger}$ | 32 | 50 | 38 | 0 |
| LOADMQ (Log) |  | x |  | - | 32 | 50 | $38^{\dagger}$ | 0 |
| BADD | 88 |  |  | $17^{\dagger}$ | 52 | 55 | 46 | - |
| BSUBS | 98 |  |  | $17{ }^{\text {¢ }}$ | 52 | 55 | 46 | - |
| BSUBR | A8 |  |  | $17^{\dagger}$ | 52 | 62 | 46 | - |
| BINCS | B8 |  |  | $17^{\dagger}$ | 52 | 55 | 46 | - |
| BINCNS | C8 |  |  | $17{ }^{\dagger}$ | 52 | 62 | 46 | - |
| BXOR | D8 |  |  | - | 52 | - | - | - |
| BAND | E8 |  |  | - | 52 | - | - | - |
| BOR | F8 |  |  | - | 52 | - | - | - |
| EX3BC | 8F |  |  | - | 45 | 45 | $46^{\dagger}$ | - |

${ }^{\dagger}$ This parameter limits normal system performance.

TABLE 12. SN74AS895-1 SSF PIN DELAYS AND SETUP TIMES

| MNEMONIC | $\begin{aligned} & \hline \text { HEX } \\ & \text { CODE } \end{aligned}$ | SSF SOURCE |  | INPUT $\rightarrow$ SSF (ns) |  |  |  | SSF SETUP TIME (ns) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LSP | MSP | $\mathrm{C}_{\mathrm{n}}$ | I(n) | CK | $B_{(n)}$ |  |
| SNORM | 20 |  | X | - | $23^{\dagger}$ | 28 | - | 14 |
| DNORM | 30 |  | X | - | 23 | 40 | $34{ }^{\text {t }}$ | 14 |
| DIVRF | 40 |  | X | - | $23^{\dagger}$ | 27 | - | 14 |
| SDIVAF | 50 |  | x | - | $23^{\dagger}$ | - | - | 14 |
| SMULI | 60 | $x$ |  | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIN | 80 |  | X | - | 35 | 46 | $35^{\dagger}$ | 0 |
| SDIVIS | 90 |  | X | $22^{\dagger}$ | 42 | 48 | 42 | 0 |
| SDIVI | AO |  | $x$ | $22^{\dagger}$ | 42 | 46 | 42 | 0 |
| UDIVIS | Bо |  | x | $16^{\dagger}$ | 42 | 46 | 38 | 0 |
| UDIVI | CO |  | X | $16^{\dagger}$ | 36 | 46 | 34 | 0 |
| UMULI | D0 | $x$ |  | - | $22^{\dagger}$ | 27 | - | 0 |
| SDIVIT | EO |  | x | $21^{\dagger}$ | 40 | 44 | 42 | 0 |
| ABS | 48 |  | x | - | 28 | 46 | $30^{\dagger}$ | 14 |
| SMTC | 58 |  | x | - | 24 | 44 | $30^{t}$ | 14 |
| BINEX3 | DF |  | X | - | $23^{\dagger}$ | 27 | - | 14 |
| LOADMO (Arith) |  | x |  | $19^{\dagger}$ | 28 | 40 | 30 | 0 |
| LOADMQ (Log) |  | x |  | - | 28 | 35 | $30^{\dagger}$ | 0 |
| BADD | 88 |  |  | $16^{\dagger}$ | 42 | 42 | 40 | - |
| BSUBS | 98 |  |  | $16^{\dagger}$ | 42 | 40 | 40 | - |
| BSUBR | A8 |  |  | $16^{\dagger}$ | 42 | 50 | 40 | - |
| BINCS | B8 |  |  | $16^{\dagger}$ | 42 | 46 | 40 | - |
| BINCNS | C8 |  |  | $16^{\dagger}$ | 42 | 54 | 42 | - |
| BXOR | D8 |  |  | - | 42 | - | - | - |
| BAND | E8 |  |  | - | 42 | -- | - | - |
| BOR | F8 |  |  | - | 42 | - | - | - |
| EX3BC | 8F |  |  | - | 42 | 42 | $42^{\dagger}$ | - |

[^42]D2885, OCTOBER 1985-REVISED MARCH 1986

## - High-Speed "Flash" Shift Operations

- Expandable to 32 Bits
- Hexadecimal and Binary Normalization with Leading Zero Detection
- Bit Reversal
- Merge Capabilities
- Texas Instruments Quality and Reliability


## description

The SN54AS897A and SN74AS897A are multipurpose 16-bit barrel shifters in a 68-pin ceramic pin-grid-array package. The devices are capable of several different types of shift operations, as well as other more specialized functions such as hexadecimal and binary normalization, bit replacement, and leading-zero detection.

The unique feature of all barrel shifters is how the shift function is implemented. In conventional shift registers, shift operations are controlled by the number of input clock pulses applied. With barrel shifters, the desired number of positions to be shifted is determined by an input decoder. This form of implementation does not require an input clock and results in a shift operation that is restricted only by internal propagation delays. This delay is the same regardless of the number of positions to be shifted. The result is a high-speed "flash" type of shift.

The 'AS897A offers the system designer a much broader range of capabilities than previous conventional shift registers. Normalization of data in floating-point computations, bit-reversal when generating Fast Fourier Transform (FFT) addresses, and insertion of stop/start bits in asynchronous data communications are just a few of the applications that are possible with this device.

The 'AS897A can be operated as an 'AS897 by connecting the HEX/BIN pin (J1) to ground.

## SN54AS897A, SN74AS897A GB PIN-GRID ARRAY PACKAGE (TOP VIEW)



PIN ASSIGNMENT TABLE

| PIN | PIN | PIN | PIN |
| :--- | :--- | :--- | :--- |
| NO. | NAME | NO. | NAME |
| A2 | ZN1 | F10 | GND |
| A3 | ZN2 | F11 | Y9 |
| A4 | ZN3 | G1 | D4 |
| A5 | GND | G2 | GND |
| A6 | NORM | G10 | Y11 |
| A7 | ZL | G11 | Y8 |
| A8 | GND | H1 | NC |
| A9 | 16B/32B | H2 | D5 |
| A10 | OP | H10 | GND |
| B1 | D14 | H11 | Y7 |
| B2 | D13 | J1 | HEX/BIN |
| B3 | D15 | J2 | D3 |
| B4 | ZNO | J10 | GND |
| B5 | VCC2 | J11 | GND |
| B6 | ZN4 | K1 | D2 |
| B7 | IP | K2 | D1 |
| B8 | VCC1 | K3 | VCC1 |
| B9 | GND | K4 | M1 |
| B10 | S | K5 | GND |
| B11 | Y15 | K6 | CLK |
| C1 | D12 | K7 | GND |
| C2 | D9 | K8 | VCC2 |
| C10 | Y13 | K9 | Y6 |
| C11 | Y12 | K10 | Y4 |
| D1 | D11 | K11 | Y5 |
| D2 | D8 | L2 | D0 |
| D10 | NC | L3 | M2 |
| D11 | GND | L4 | MO |
| E1 | D10 | L5 | TP |
| E2 | D7 | L6 | OEY |
| E10 | Y14 | L7 | Y0 |
| E11 | Y10 | L8 | Y1 |
| F2 | GND | D6 | L9 |
| YY2 | Y3 |  |  |

NC-No internal connection
Chip Carrier information available from factory upon request.
logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984.
functional block diagram (positive logic)


| PIN |  | 1/0 | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| NAME | NO. |  |  |
| 16B/32B | A9 | 1 | When high, 16-bit operation is selected. When low, 32-bit operation is selected. |
| CLK | K6 | 1. | Clock input. Loads the internal register on the low-to-high transition. In 16-bit circular mode, acts as clock for the 16 -bit/14-bit counter. |
| DO | L2 | 1 | , |
| D1 | K2 | 1 |  |
| D2 | K1 | 1 |  |
| D3 | J2 | 1 | . |
| D.4 | G1 | 1 |  |
| D5 | H2 | 1 | . |
| D6 | F2 | 1 |  |
| D7 | E2 | 1 | ut data bits 0 through |
| D8 | D2 | 1 | ut data bits 0 through |
| D9 | C 2 | 1 |  |
| D10 | E1 | 1 |  |
| D11 | D1 | 1 |  |
| D12 | C1 | 1 | - |
| D13 | B2 | 1 |  |
| D14 | B1 | 1 |  |
| D15 | B3 | 1 |  |
| GND | A5 |  | . |
| GND | A8 |  |  |
| GND | B9 |  |  |
| GND | D11 |  |  |
| GND | F1 |  |  |
| GND | F10 |  |  |
| GND | G2 |  | Ground (All ground pins should be used) |
| GND | H10 |  | , |
| GND | J10 |  | . ${ }^{\text {a }}$ |
| GND | J11 |  |  |
| GND | K5 |  |  |
| GND | K7 |  |  |
| HEX/ETN | $J 1$ | 1 | Controls mode of operation for leading zero detector. When low, causes the number of leading binary zeros to be counted. When high, causes the number of binary zeros in leading hexadecimal groups (binary 0000s) to be counted. When tied to ground, causes the 'AS897A to operate as an 'AS897. |
| IP | B7 | 1 | In the 16 -bit mode, controls the bit-reversal option. A high logic level causes data selected by OP to be bit-reversed before it is passed to the shifter. When IP is low, data is passed unaltered. <br> In the 32 -bit mode, defines the data input position. When IP is high, D15-D0 are in the most significant input position. When IP is low, D15-D0 are in the least significant position. |
| $\overline{\mathrm{MO}}$ | $\overline{L 4}$ | I | Shift instruction control. Determine the type of shift operation to be performed. See Table 1 for further |
| M1 | K4 | 1 | information. |
| M2 | L3 | 1 |  |
| $\begin{aligned} & \mathrm{NC} \\ & \mathrm{NC} \end{aligned}$ | $\begin{aligned} & \text { D10 } \\ & \text { H1 } \end{aligned}$ |  | No internal connection |
| $\overline{\text { NORM }}$ | A6 | 1 | A three-state control input for ZN4-ZNO I/O ports used only in normalize instructions. When $\overline{N O R M}$ is low, the number of leading zeros detected in the data present on D15-DO is output on ZN4-ZN0. When NORM is high, ZN4-ZNO act only as inputs. |

## SN54AS897A, SN74AS897A 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

| PIN |  | I/O | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| NAME | NO. |  |  |
| $\overline{\mathrm{OEY}}$. | L. 6 | 1 | Control input for the Y15-Y0 I/O ports. When $\overline{\mathrm{OEY}}$ is low, the Y outputs are enabled. |
| OP | A10 | I | In the 16 -bit mode, controls the source of input data. A logic high on this input selects data from the register/counter. A low selects data on the D15-DO inputs. <br> In the 32-bit mode, defines the package output positions. When OP is high, Y15-Y0 are in the most significant output position. When OP is low, Y15-Y0 are in the least significant output position. |
| S | B10 | 1 | Specifies the logic level that will fill the bit position or positions vacated during all shift operations except 16 -bit circular. In the 16 -bit circular mode, when $S$ is high, the data latch operates as a 16 -bit binary counter. When $S$ is low, the register functions as a data latch. |
| $\overline{\text { TP }}$ | L5 | I | Functional testing input. When low, transforms the 16 -bit counter into four 4-bit counters. During normal operation, $\overline{T P}$ must be maintained at a high logic level. |
| $\begin{aligned} & \mathrm{V}_{\mathrm{CC} 1} \\ & \mathrm{v}_{\mathrm{CC} 1} \end{aligned}$ | $\begin{aligned} & \text { B8 } \\ & \text { K3 } \end{aligned}$ |  | 5-volt supply for TTL-compatible I/O |
| $\begin{aligned} & v_{\mathrm{CC} 2} \\ & \mathrm{v}_{\mathrm{CC} 2} \end{aligned}$ | $\begin{aligned} & \mathrm{B5} \\ & \mathrm{~K} 8 \end{aligned}$ |  | 2-volt supply for internal Schottky Transistor Logic (STL) |
| YO | L7 | I/O |  |
| Y1 | L8 | I/O |  |
| Y2 | L9 | 1/O |  |
| Y3 | L10 | 1/0 |  |
| Y4 | K10 | 1/0 |  |
| Y5 | K11 | 1/O |  |
| Y6 | K9 | 1/0 |  |
| Y7 | H11 | 1/0 | Input/output bits 0-15. As an input, they load the data register. A an output, they present the shifted data. |
| Y8 | G11 | 1/0 | Input/output bit 0-15. As an input, theyload the data register. A an output, hey present the shifed data. |
| Y9 | F11 | 1/0 |  |
| Y10 | E11 | 1/O |  |
| Y11 | G10 | 1/0 |  |
| Y12 | C11 | 1/0 | . |
| Y13 | C10 | 1/0 |  |
| Y14 | E10 | 1/0 |  |
| Y15 | B11 | 1/0 |  |
| ZL | A7 | I/O | An input/open-collector output used primarily in 32-bit applications. When the input at D15-D0 is zero, the $Z L$ output is high. The ZL outputs of cascaded packages are connected in a wired-AND configuration to detect if all inputs are zero. A recommended pull-up resistor of 200 to $680 \Omega$ must be provided externally for proper operation in the 32 -bit mode. |
| ZNO | B4 | I/O | A four-bit code that performs the following functions in the 16-bit mode: |
| ZN1 | A2 | 1/O | 1. As an input in shift instructions, specifies how many bit positions are to be shifted. |
| ZN2 | A3 | 1/0 | 2. As an input in replace instructions, specifies position of the bit to be replaced. |
| ZN3 | A4 | 1/0 | 3. As an input to the normalize instruction, specifies the number of left shifts to be performed. <br> 4. As an output from the normalize instruction, when $\overline{\text { NORM }}=L$, specifies the number of leading zeros in the data on D15-DO. |
| ZN4 | B6 | 1/0 | ZN4 is concatenated with ZN3-ZNO for use in 32-bit shift operations as described above. In 16-bit normalization operations, ZN4 indicates when the input to the shifter is zero. In 16-bit left and right shifts and in shift and merge operations, a high on ZN4 causes all 16 -bits to be filled with the logic level on the $S$ input. |

## description (continued)

## control block

The control block decodes the M2-MO instruction inputs, $16 B / \overline{32 B}$ configuration select, IP and OP data select/bit reversal options, and other control inputs and transmits the resulting control signals to the rest of the internal logic.

## instruction set

The 'AS897A can operate in any of the eight user-programmable shift modes shown in Table 1. Selection of these instructions is controlled by pins M2-MO.
table 1. INSTRUCTION SET

| M2 | M1 | MO | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| L | L | L | Shift right the number of bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). Fill vacated bit positions with logic level on S input. A high on ZN4 causes all bits in the 16 -bit mode to be filled with the logic level on S . |
| L | L | H | Shift left the number of bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). Fill vacated bit positions with logic level on S input. A high on ZN4 causes all bits in the 16 -bit mode to be filled with the logic level on S. |
| L | H | L | Circular right shift the number or bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). |
| L | H | H | Circular left shift the number of bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). |
| H | L | L | Shift right the number of bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). Fill vacated bit positions with logic level on S input. Merge result with data from the register/counter. A high on ZN4 causes all bits in the 16 -bit mode to be filled with the logic level on $S$. |
| H | L | H | Shift left the number of bit positions defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). Fill vacated bit positions with logic level on $S$ input. Merge result with data from the register/counter. A high on ZN4 causes all bits in the 16 -bit mode to be filled with the logic level on $S$. |
| H | H | $L$ | Set the bit position defined by ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode) to the logic level on the S input. |
| H | H | H | If $\overline{\text { NORM }}$ is low, shift data left the number of bit positions defined by the leading-zero detector. Fill vacated bit positions with logic level on S input. Output number of leading zeros in D15-DO on ZN3-ZNO (16-bit mode) or ZN4-ZNO (32-bit mode). Note: If $\overline{\text { NORM }}$ is high, this instruction performs like the left shift described above for $M 2=L, M 1=L, M O=H$. |

## mode configuration

The 'AS897A can be configured to operate on 16 -bit or 32 -bit words. Configuration is controlled by $16 B / \overline{32 B}$. When $16 B / \overline{32 B}$ is high, the 'AS897A operates in 16 -bit mode.

Figure 1 illustrates the connection of four 'AS897As to provide a 32-bit barrel shifter that can perform all Table 1 shift instructions. For 32 -bit mode operation, the $16 B / \overline{32 B}$ inputs of all 'AS897A devices must be low and should be configured as shown in Figure 1.


FIGURE 1. 32-BIT BARREL SHIFTER

## data input/output

Data can be input to the chip from two ports: D15-DO, which passes data to the zero detector and to the shifter via the data select and bit-reversal multiplexers, and Y15-YO, which passes data to the register/counter. Y15-Y0 is also used to output the shift result from the chip.

Data input and output positions in the 32 -bit mode are defined by IP and OP (see Table 2). When IP is high, the D15-D0 port is the most significant input position; when IP is low, the D15-DO input port is the least significant. If $O P$ is high, the $Y 15-Y 0$ port is the most significant output position; if $O P$ is low, the $\mathrm{Y} 15-\mathrm{YO}$ port is the least significant position.

TABLE 2. IP AND OP CONTROLS

| SIGNAL | 16-BIT OPERATION <br> $(16 B / \overline{32 B}=\mathrm{H})$ | 32-BIT OPERATION <br> $(16 \mathrm{~B} / \overline{32 B}=\mathrm{L})$ |
| :---: | :--- | :--- |
| $\mathrm{IP}=\mathrm{L}$ | Bit-reversal option off | $\mathrm{D} 15-\mathrm{DO}$ is least significant input position |
| $\mathrm{IP}=\mathrm{H}$ | Bit-reversal option on | $\mathrm{D} 15-\mathrm{DO}$ is most significant input position |
| $\mathrm{OP}=\mathrm{L}$ | $\mathrm{D} 15-\mathrm{DO}$ is shifted | $\mathrm{Y} 15-\mathrm{YO}$ is least significant output position |
| $\mathrm{OP}=\mathrm{H}$ | Register/counter data <br> is shifted | $\mathrm{Y} 15-\mathrm{YO}$ is most significant output position |

## zero detector

The zero detector detects the number of leading zeros at the D15-DO input port. If HEX/ $\overline{\mathrm{BIN}}$ is high, the zero detector counts only those binary zeros that are part of a leading hexadecimal zero group. For example, given the binary number 0000000000010001 , the leading-zero count will be decimal 11 if HEX/BIN is low and decimal 8 if $\mathrm{HEX} / \overline{\mathrm{BIN}}$ is high.
If all zeros are detected at the D port, the ZL output transistor will be turned off. If the ZL output pin is pulled up through the recommended pull-up resistor (see pin description table), the resulting signal will be high. If anything other than a zero is detected on the D15-DO inputs, the output transistor will be turned on; this will pull the ZL signal low.

During data normalization ( $M 2=H, M 1=H, M O=H$ ), the zero-detector outputs the leading zero count to the ZN4-ZNO I/O ports, provided $\overline{\text { NORM }}$ is low. When $\overline{\text { NORM }}$ is high, ZN4-ZNO act only as inputs in this mode. For operations other than normalization, the state of $\overline{\text { NORM }}$ is irrelevant.

In the data-normalization mode, a high logic level will be output on the ZN4 pin when the D15-D0 bus contains all lows and $\overline{\text { NORM }}$ is low (see Table 3).

TABLE 3. ZN4 I/O PORT

| SIGNAL | 1/0 | 16-BIT CONFIGURATION $(16 B / \overline{32 B}=H)$ | 32-BIT CONFIGURATION $(16 B / \overline{32 B}=L)$ |
| :---: | :---: | :---: | :---: |
| ZN4 | 1 | In shift-left, shift-right, and shift-and-merge modes, a high fills all bits with the logic level on the $S$ input. Inactive in other modes. | With ZN3-ZNO indicates number of bits to be shifted in shift operations and position of bit to be replaced in replace-bit mode. |
|  | 0 | In the normalization mode, when $\overline{\text { NORM }}=\mathrm{L}$, indicates when the input to the shifter is zero | In the normalization mode, when $\overline{\text { NORM }}=\mathrm{L}, \mathrm{ZN4}-\mathrm{ZNO}$ indicates number of leading zeros detected in D15-DO and number of places to be shifted for normalization. |

## data selector multiplexer

The data selector multiplexer is used only in 16 -bit operation $(16 B / \overline{32 B}=H)$. OP controls the mux and selects the data to be presented to the bit-reversal block. OP high selects the register/counter; OP low selects D15-D0 (see Table 2).

## bit reversal

Bit reversal is also available only in the 16 -bit mode ( $16 \mathrm{~B} / \overline{32 \mathrm{~B}}=\mathrm{H}$ ) and is controlled by IP (see Table 2). When the bit-reversal option is selected (IP = H), data selected by OP is bit-reversed before it is passed to the shifter: the most significant bit becomes the least significant bit, the second most significant bit becomes the second least significant bit, and so forth. When the bit-reversal option is off (IP $=\mathrm{L}$ ), the data presented to the shifter is not altered.

## register/counter

During most instructions, the register/counter operates as a data latch. Data on the Y15-Y0 bus is latched into the register/counter on the rising edge of the clock. Data can be input to the register/counter from the shifter $(\overline{\mathrm{OEY}}=\mathrm{L})$ or from the bidirectional Y port $(\overline{\mathrm{OEY}}=\mathrm{H})$.
In the 16-bit circular-shift mode $(16 B / \overline{32 B}=H, M 2=L, M 1=H, M O=X)$, the register counter will function as a 16 -bit counter on the rising edge of the clock when $S$ is high. Under these same conditions, the register/counter will function as four 4-bit counters when $\overline{\mathrm{TP}}$ is low. In the 16-bit circular-shift mode, the register/counter functions as a register when $S$ is low. The counter option is not available for other instructions in the 16 -bit mode or for any instructions in the 32-bit mode.

## shifter

The shifter performs the operations specified by the M2-M0 inputs (see Table 1). The number of bits to be shifted or the position of the bit to be replaced is specified by ZN3-ZNO (16-bit operation) or ZN4-ZNO (32-bit operation).

## SN54AS897A, SN74AS897A 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

## merge

During the shift and merge instruction ( $\mathrm{M} 2=\mathrm{H}, \mathrm{M} 1=\mathrm{L}, \mathrm{MO}=\mathrm{X}$ ), the merge block ORs the shift result with data from the register/counter.

S or $Z$ fill
During bit replacement ( $\mathrm{M} 2=\mathrm{H}, \mathrm{M} 1=\mathrm{H}, \mathrm{MO}=\mathrm{L}$ ) in the 16 -bit mode, this block sets the bit specified on the ZN3-ZNO inputs with the logic level on the S input. This option works identically in the 32-bit mode, except that the bit to be replaced is specified on the $\mathrm{Z4}-\mathrm{ZO}$ inputs. During all other instructions except circular shifts, the $S$ input specifies the logic level that will fill the bit position or positions vacated during the shift.
$Z$ fill is used in the 32-bit mode to selectively put the device outputs in a high-impedance state. This feature is necessary to properly select the correct bit locations that will combine to form the shifted output. An example of a 32-bit circular shift four positions to the right, which illustrates the Z-fill technique, is shown in Figure 2.


## SHIFT OPERATION EXAMPLES

Examples of 'AS897A shift instructions are provided in the following paragraphs. Unless otherwise specified, the examples assume a 16 -bit configuration.

## shift left or right $(M 2=L, M 1=L, M 0=X)$

When in the shift-right ( $\mathrm{MO}=\mathrm{L}$ ) or shift-left ( $\mathrm{MO}=\mathrm{H}$ ) modes, ZN3-ZNO define the number of bit positions to be shifted. If, for example, ZN3-ZNO is equal to a decimal 10 , the data selected by OP will be shifted 10 bit positions. The positions vacated during the shift operation are filled with the logic level being applied to the S input. $\overline{N O R M}$ is inactive in all shift modes except normalization and is therefore shown as a don't care. If IP is high, the data selected by OP will be bit-reversed before it is passed to the shifter.

## Example

Shift a 16 -bit word on the data bus ten positions to the left and fill the least significant bits with highs.
CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO SHIFT | BIT <br> REVERSAL | DATA <br> SOURCE | BIT <br> FILL | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-M0 | $\overline{\text { NORM }}$ | ZN4-ZNO | IP | OP | S | 16B/32B |
| 001 | $X$ | 01010 | 0 | 0 | 1 | 1 |

Assume D15-DO contains hex AF50:

|  | D15-D0 |
| :--- | :---: |
| Input Data | 1010111101010000 <br> Result$\quad 015-\mathrm{YO}$ |
|  |  |

## Example

Shift a 32 -bit word on the data bus 20 positions to the right. Fill vacated bit positions with highs.
CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO SHIFT | BIT <br> REVERSAL | DATA <br> SOURCE | BIT <br> FILL | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-MO | $\overline{\text { NORM }}$ | ZN4-ZNO | IP | OP | S | 16B/32B |
| 000 | $X$ | 10100 | See Figure 1 |  | 1 | 1 |

Assume D15-D0 contains hex 75BB FCAE:

| Input Data | D31-D16 | D15-D0 |
| :---: | :---: | :---: |
|  | 0111010110111011 | 1111110010101110 |
|  | Y31-Y16 | Y15-Y0 |
| Result | 1111111111111111 | 1111011101011011 |

## SN54AS897A, SN74AS897A 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

## circular shift left or right ( $\mathrm{M} 2=\mathrm{L}, \mathrm{M} 1=\mathrm{H}, \mathrm{MO}=\mathrm{X}$ )

In this mode, data selected by OP is circular shifted left $(M O=H)$ or right $(M O=L)$ the number of bit positions specified by ZN3-ZNO. If, for example, the device is in the circular-shift-right mode ( $\mathrm{MO}=\mathrm{L}$ ) and ZN3-ZNO contains a decimal five, the data selected by OP will be shifted right five positions.
In all shift modes except 16 -bit circular, the $S$ input contains the bit used for end fill or bit replacement. In the 16-bit circular-shift mode, the $S$ input controls whether the register/counter will operate as a 16-bit counter or as a data register. When $S$ is high, the register/counter operates as a 16 -bit binary counter; when $S$ is low, the register/counter operates as a 16 -bit data latch. Both functions are controlled on the positive edge of the CLK input. Data on Y15-Y0 will be latched into the register/counter on the rising edge of the clock when $S$ is low.

## Example

Circular shift a 16 -bit word in the register/counter five positions to the right.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO SHIFT | BIT <br> REVERSAL | DATA <br> SOURCE | LATCH OR <br> COUNTER | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-MO | $\overline{\text { NORM }}$ | ZN4-ZNO | IP | OP | S | $16 B / \overline{32 B}$ |
| 010 | $X$ | X0101 | 0 | 1 | 0 | 1 |

Assume the register/counter contains hex A016:


## shift and merge ( $\mathbf{M} 2=\mathrm{H}, \mathbf{M 1}=\mathbf{L}, \mathbf{M O}=\mathrm{X}$ )

In the shift-and-merge mode, data selected by OP is shifted by OP is shifted left $(\mathrm{MO}=\mathrm{H})$ or right $(\mathrm{MO}=\mathrm{L})$ the number of positions specified by ZN3-ZNO, bit positions vacated by the shift are filled by the logic level on $S$, and the result is ORed with data in the register/counter.

## Example

Shift data on the data bus six positions to the left, and fill vacated positions with zeros. Merge the shifted data with data from the data register.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO SHIFT | BIT <br> REVERSAL | DATA <br> SOURCE | END <br> FILL | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-M0 | $\overline{\text { NORM }}$ | ZN4-ZNO | IP | OP | S | $16 B / \overline{32 B}$ |
| 100 | $X$ | 00110 | 0 | 0 | 0 | 1 |

## SN54AS897A, SN74AS897A <br> 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

Assume D15-DO contains hex 6174 and register/counter contains hex 320B:

|  | D15-D0 |
| :---: | :---: |
| Input Data | 01100001.01110100 |
|  | Shift Result |
| Intermediate Result | 0101110100000000 |
|  | Register/Counter |
| Input Data | 0011001000001011 |
|  | Y15-Y0 |
| Result | 0111111100001011 |

bit replacement $(M 2=H, M 1=H, M 0=L)$
In the bit-replacement mode, data in the bit position specified by ZN3-ZNO is replaced by the logic level on the $S$ input. If, for example, ZN3-ZNO contains a decimal seven and $S$ contains a logic high, bit 7 of the data selected by OP will be set high regardless of its original state. In the following example, OP has been set high to select data from the register/counter. Because IP has been set high, the data will be bitreversed before it enters the shifter..

## Example

Bit-reverse the data in the register/counter and set bit 7 of the result to zero.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | POSITION OF BIT <br> TO BE INSERTED | BIT <br> REVERSAL | DATA <br> SOURCE | INSERT <br> BIT | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-M0 | $\overline{\text { NORM }}$ | ZN4-ZNO | IP | OP | S | $16 \mathrm{~B} / \overline{32 B}$ |
| 110 | X | XO111 | 1 | 1 | 0 | 1 |

Register/Counter
Input Data

> | 0110000100110100 |
| :--- |

Result after Bit-Reversal
Intermediate
Result

Y15-Y0
Result
0010110000000110

## SN54AS897A, SN74AS897A <br> 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

data normalization ( $M 2=H, M 1=H, M 0=L$ )
The data-normalization mode shifts data on D15-D0 to the left until a high logic level appears in the most-significant-bit position of output Y15-Y0 if HEX/BIN is low. If HEX/BIN is high, only 4-digit groups containing leading zeros are shifted left. The number of positions shifted to accomplish this is determined by the leadingzero detector. This count will be output on ZN3-ZNO when the $\overline{\text { NORM }}$ input is low.

Since the leading-zero detector counts leading zeros in the D15-D0 input, the normalization is designed to operate on data from the data bus rather than the register/counter. Therefore OP is set low in the following example. The $S$ input is programmed low so that all bit positions vacated during the shift will be filled with zeros.

## Example

Perform a hex normalization on a 16-bit data word from the data bus.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO BE SHIFTED | LEADING-ZERO <br> MODE | BIT <br> REVERSAL | DATA <br> SOURCE | INSERT <br> BIT | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-MO | $\overline{\text { NORM }}$ | ZN4-ZNO | HEX/ $\overline{\text { BIN }}$ | IP | OP | S | 16B/32B |
| 111 | 0 | Outputs leading <br> zero count | 1 | 0 | 0 | 0 | 1 |

Assume D15-DO contains hex 002B:

|  | D15-DO |
| :--- | :---: |
| Input Data | 0000000000101011 |
| Leading-Zero <br> Count | 1000 |
|  | ZN3-ZNO |
| Result | 1010101100000000 |
|  |  |

## Example

Perform a binary normalization on a 32-bit word from the data bus.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION | NORMALIZE | NUMBER OF BITS <br> TO SHIFT | LEADING-ZERO <br> MODE | BIT <br> REVERSAL | DATA <br> SOURCE | BIT <br> FILL | CONFIGURATION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| M2-MO | $\overline{\text { NORM }}$ | ZN4-ZNO | HEX/BIN | IP | OP | S | 16B/32B |
| 111 | 0 | Outputs leading <br> zero count | 0 | See Figure 1 | 0 | 0 |  |

## SN54AS897A, SN74AS897A

16-BIT PARALLEL/SERIAL BARREL SHIFTERS

Assume D31-D0 contains hex 0000 3D61:

|  | D31-D16 | D15-D0 |
| :---: | :---: | :---: |
| Input Data | 0000000000000000 | 0011110101100001 |
|  | ZN4-ZNO |  |
| Leading-Zero Count | 10010 |  |
|  | Y31-Y16 | Y15-Y0 |
| Result | 1111010110000100 | 0000000000000000 |

## IEEE floating-point normalization

Floating-point normalization is used to preserve number resolution after subtraction or some other floatingpoint algorithm that results in orders of magnitude reduction. Three 'AS897A devices can be configured to convert a 32-bit data word into the IEEE floating-point format shown in Figure 3.

| 1 BIT | 8 BITS | 23 BITS |
| :---: | :---: | :---: |
| S | E | F |
| S - sign bit <br> E - 8-bit exponent |  |  |
|  |  |  |
|  |  |  |

FIGURE 3. IEEE FLOATING-POINT FORMAT

Figure 4 shows the three-device configuration. The limitation of this application is that only 23 bits of the 32 bits are used in the significand, and the sign bit must be set from hardware. As an alternate to the IEEE floating-point format, the same hardware configuration can be used to normalize a 32-bit data word resulting in a 32-bit significand and a five-bit exponent.


FIGURE 4. THREE-DEVICE CONFIGURATION FOR IEEE FLOATING-POINT FORMAT

## SN54AS897A, SN74AS897A

## 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

## Example

Input data in IEEE floating point format

| Sign | Previous |
| :--- | :--- |
| Bit | Exponent |

$$
\begin{array}{|l|l|l|l|}
\hline 1 & 00101001 & 00010010001000100010001 \\
\hline
\end{array}
$$

Input mantissa concatenated with: 000000000 to D31-D0 of the 'AS897As
D31-D16 D15-D0

$$
\begin{array}{|l|l|l|}
\hline 0001001000100010 & 0010001000000000 \\
\hline
\end{array}
$$

Normalize mantissa and output the leading zero count on ZN4-ZNO.


Pack result in IEEE floating point format

## SN54AS897A, SN74AS897A 16-BIT PARALLEL/SERIAL BARREL SHIFTERS

recommended operating conditions

${ }^{\dagger}$ These parameters only apply in the circular mode and with $16 \mathrm{~B} / \overline{32 \mathrm{~B}}$ high.
$\ddagger$ These parameters only apply in the circular mode.
electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54AS897A |  |  | SN74AS897A |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\dagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}=18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{I}^{\mathrm{OH}}$ | ZL | $V_{C C}=4.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{OH}}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{l}^{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | Y15-Y0 | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.43 .2 |  |  |  |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\text {OL }}$ | ZN4-ZNO | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | ${ }^{\mathrm{OLL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | ZL, Y15-Y0 | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$. | $\mathrm{IOL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 1 | 1/O ports ${ }^{\ddagger}$ | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | All others | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| It | 1/O ports ${ }^{\ddagger}$ | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{mA}$ |
|  | All others |  |  |  |  | 20 |  |  | 20 |  |
| IIL | All inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
| $10^{5}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{\text {ICC1 }}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | See Note 1 |  |  | 100 |  |  | 90 | mA |
| ${ }^{\text {I CC2 }}$ |  | $\mathrm{V}_{\mathrm{CC}}=2.1 \mathrm{~V}$, | See Note 1 |  |  | 180 |  |  | 170 | mA |

[^43] NOTE 1: Supply currents ICC1 and ICC2 are measured with MO, M1, M2, IP, OP, S, ZN3-ZNO, D15-DO, and $\overline{O E Y}$ low; 16B/32B, $\overline{\mathrm{NORM}}$,
switching characteristics over recommended operating temperature range

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R} 2=500 \Omega \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54AS897A |  | SN74AS897A |  |  |
|  |  |  | MIN | MAX | MIN | MAX |  |
| ${ }^{t} \mathrm{pd}$ | D15-D0 | Y15-Y0 |  | 37 |  | 33 | ns |
|  | S | Y15-Y0 |  | 20 |  | 17 |  |
|  | ZN3-2NO | Y15-Y0 |  | 24 |  | 22 |  |
|  | IP | Y15-Y0 |  | 33 |  | 29 |  |
|  | OP | Y15-Y0 |  | 33 |  | 29 |  |
|  | M0, M1, M2 | Y15-Y0 |  | 24 |  | 21 |  |
|  | CLK ${ }^{\dagger}$ | Y15-Y0 |  | 47 |  | 42 |  |
|  | D15-D0 | ZL |  | 28 |  | 27 |  |
|  | D15-D0 ${ }^{\text {\# }}$ | ZN4-ZNO |  | 28 |  | 26 |  |
| $t_{\text {en }}$ | MO, M1, M2 ${ }^{\text {§ }}$ | ZN4-ZNO |  | 25 |  | 20 | ns |
|  | 168/32B | Y15-Y0 |  | 29 |  | 26 |  |
|  | $\overline{\text { NORM }}{ }^{\ddagger}$ | ZN3-ZNO |  | 26 |  | 21 |  |
|  | $\overline{\mathrm{OEY}}$ | Y15-Y0 |  | 22 |  | 19 |  |
|  | ZN4, ZL | Y15-Y0 |  | 32 |  | 29 |  |
| ${ }^{\text {dis }}$ | MO, M1, M $2^{\text {§ }}$ | ZN4-ZNO |  | 22 |  | 20 | ns |
|  | 16B/32B | Y15-Y0 |  | 31 |  | 27 |  |
|  | $\overline{\text { NORM }}{ }^{\ddagger}$ | ZN3-ZNO |  | 14 |  | 12 |  |
|  | $\overline{O E Y}$ | Y15-Y0 |  | 10 |  | 9 |  |
|  | ZN4, ZL | Y15-Y0 |  | 30 |  | 26 |  |

[^44]- Serial-to-Parallel and Parallel-to-Serial Conversions
- Parallel I/O Registers
- Data Exchangeable Between I/O Register and Shift Register
- Choice of Synchronous and/or Asynchronous Clear
- Independent or Dual Register Clocking
- Functionally Similar to National Semiconductor DM74LS962
- Dependable Texas Instruments Quality and Reliability


## description

The 'ALS963 and 'ALS964 each contain an 8-bit shift register in parallel with an 8-bit l/O register. In addition to serial-to-parallel and parallel-toserial conversions, these devices are capable of exchanging data between the shift and $1 / O$ registers. Control lines determine the mode of operation as shown in the function table.

The 'ALS963 features individual shift and I/O register clock inputs whereas the 'ALS964 features simultaneous register clocking through a single clock input. Clocking in both cases is achieved by positive transitions at the clock inputs.

The clear function for the 'ALS963 is synchronous (active high). The 'ALS964 features active-high synchronous and asynchronous clearing.

The SN54ALS963 and SN54ALS964 are characterized for operation over the full military of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS963 and SN74ALS964 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


SN54ALS963 . . . FK PACKAGE SN74ALS963 . . . FN PACKAGE (TOP VIEW)


SN54ALS964 . . . JT PACKAGE SN74ALS964 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{O E}$ | $1 \mathrm{~J}^{20}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| SERIN | 219 | $\mathrm{A}^{\prime} \mathrm{O}_{\mathrm{A}}$ |
| $\overline{\mathrm{GIN}}$ | 318 | $B / Q_{B}$ |
| $\overline{\text { G2-1 }}$ | $4 \quad 17$ | $\mathrm{C} / \mathrm{O}_{\mathrm{C}}$ |
| SCLR | $5 \quad 16$ | ]/ $\mathrm{Q}_{\mathrm{D}}$ |
| $\overline{\mathrm{G} 1-2}$ | $6 \quad 15$ | $E / Q_{E}$ |
| $\overline{\mathrm{GSH}}$ | 714 | $\mathrm{F} / \mathrm{O}_{\mathrm{F}}$ |
| SEROUT | $8 \quad 13$ | $\mathrm{G} / \mathrm{Q}_{\mathrm{G}}$ |
| CLK | $9 \quad 12$ | $\mathrm{H} / \mathrm{Q}_{\mathrm{H}}$ |
| GND | $10 \quad 11]$ | $\square \mathrm{ACLR}$ |

SN54ALS964 . . . FK PACKAGE SN74ALS964 . . . FN PACKAGE (TOP VIEW)

'ALS963 logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSIIIEEE Std 91-1984 and IEC Publication 617-12.
'ALS963 register-level logic diagram

'ALS963 gate-level logic diagram (positive logic)


FUNCTION TABLE

| INPUTS |  |  |  |  |  |  |  | A/QA <br> THROUGH <br> H/QH | OPERATION OR FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{O E}$ | $\overline{\text { GIN }}$ | $\overline{\text { GE-1 }}$ | G1-2 | $\overline{\mathrm{GSH}}$ | CLK1 | CLK2 | SCLR |  |  |
| H | H | H | H | H | X | X | L | HI-Z | All data stable |
| L | H | H | H | H | x | x | L | OUTPUT | All data stable |
| X | L | H | H | H | $\uparrow$ | X | L | INPUT | Enter data from 1/O into Reg 1 |
| H | H | L | H | H | $\uparrow$ | X | L | HI-Z | Copy data from Reg 2 to Reg 1 |
| L | H | L | H | H | $\uparrow$ | X | L | OUTPUT | Copy data from Reg 2 to Reg 1 |
| x | L | L | H | H | $\dagger$ | $\uparrow$ | L | InPut | Reg 1 ORs data from Reg 2 and I/O |
| H | H | H | L | X | X | $\uparrow$ | L | HI-Z | Copy data from Reg 1 to Reg 2 |
| L | H | H | L | x | x | $\uparrow$ | L | OUTPUT | Copy data from Reg 1 to Reg 2 |
| X | L | H | L | X | $\dagger$ | $\uparrow$ | L | INPUT | Copy data from Reg 1 to Reg 2, enter new data from I/O into Reg 1 |
| H | H | L | L | X | $\uparrow$ | $\uparrow$ | L | $\mathrm{HI}-\mathrm{Z}$ | Exchange data between registers |
| L | H | L | L | x | $\dagger$ | $\uparrow$ | L | OUTPUT | Exchange data between registers |
| X | L | L | L | X | $\dagger$ | $\uparrow$ | L | InPUT | Copy data from Reg 1 to Reg 2, <br> Reg 1 ORs data from Reg 2 and I/O |
| H | H | H | H | L | X | $\uparrow$ | L | HI-Z | Shift data in Reg 2 |
| L | H | H | H | L | x | $\uparrow$ | L | OUTPUT | Shift data in Reg 2 |
| x | L | H | H | L | $\dagger$ | $\uparrow$ | L | input | Shift data in Reg 2, enter new data from I/O into Reg 1 |
| H | H | L | H | L | $\dagger$ | $\uparrow$ | L | HI-Z | Copy data from Reg 2 to Reg 1, shift data in Reg 2 |
| $L$ | H | L | H | L | $\uparrow$ | $\uparrow$ | L | OUTPUT | Copy data from Reg 2 to Reg 1, shift data in Reg 2 |
| x | L | L | H | L | $\uparrow$ | $\uparrow$ | L | input | Reg 1 ORs data from Reg 2 and $1 / \mathrm{O}$, shift data in Reg 2 |
| X | H | X | X | X | $\uparrow$ | X | H |  | Synchronously clear Reg 1 |
| x | X | x | $x$ | x | x | $\dagger$ | H |  | Synchronously clear Reg 2 |
| x | H | x | x | X | $\dagger$ | $\dagger$ | H |  | Synchronously clear both registers |
| x | L | x | X | X | $\uparrow$ | $\dagger$ | H | InPut | Enter data from $/ / O$ into Reg 1 and synchronously clear Reg 2 |
| X | L | x | x | x | $\dagger$ | x | H | INPUT | Enter data from I/O into Reg 1 |

## 'ALS964 logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
'ALS964 register-level logic diagram

'ALS964 gate-level logic diagram (positive logic)

'ALS964
FUNCTION TABLE

| INPUTS |  |  |  |  |  |  |  | A/QA THROUGH $\mathrm{H} / \mathrm{OH}$ | OPERATION OR FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\stackrel{\rightharpoonup}{\mathrm{OE}}$ | $\overline{\text { GIN }}$ | $\overline{\text { G2-1 }}$ | $\overline{\text { G1-2 }}$ | $\overline{\text { GSH }}$ | CLK | ACLR | SCLR |  |  |
| H | H | H | H | H | X | L | L | HI-Z | All data stable |
| L | H | H | H | H | X | L | L | OUTPUT | All data stable |
| X | L | H | H | H. | $\dagger$ | L | L | INPUT | Enter data from I/O into Reg 1 |
| H | H | L | H | H | $\uparrow$ | L | L | $\mathrm{HI}-\mathrm{Z}$ | Copy data from Reg 2 to Reg 1 |
| L | H | L | H | H | $\uparrow$ | L | L | OUTPUT | Copy data from Reg 2 to Reg 1 |
| X | L | L | H | H | $\uparrow$ | L | L | INPUT | Reg 1 ORs data from Reg 2 and I/O |
| H | H | H | L | X | $\uparrow$ | L | L | HI-Z | Copy data from Reg 1 to Reg 2 |
| L | H | H | L | $x$ | $\uparrow$ | L | L | OUTPUT | Copy data from Reg 1 to Reg 2 |
| X | L | H | L | $x$ | $\dagger$ | L | L | INPUT | Copy data from Reg 1 to Reg 2, enter new data from I/O into Reg 1 |
| H | H | L | L | X | $\uparrow$ | L | L | $\mathrm{HI}-\mathrm{Z}$ | Exchange data between registers |
| L | H | L | L | $x$ | $\uparrow$ | L | L | OUTPUT | Exchange data between registers |
| X | L | L | L | $x$ | $\uparrow$ | L | L | INPUT | Copy data from Reg 1 to Reg 2, <br> Reg 1 ORs data from Reg 2 and I/O |
| H | H | H | H | L | $\uparrow$ | L | L | HI-Z. | Shift data in Reg 2 |
| L | H | H | H | L | $\dagger$ | L | L | OUTPUT | Shift data in Reg 2 |
| X | L | H | H | L | $\dagger$ | L | L | INPUT | Shift data in Reg 2, enter new data from I/O into Reg 1 |
| H | H | L | H | L | $\uparrow$ | L | L | $\mathrm{HI}-\mathrm{Z}$ | Copy data from Reg 2 to Reg 1 . shift data in Reg 2 |
| L | H | L | H | L | $\uparrow$ | L | L | OUTPUT | Copy data from Reg 2 to Reg 1, shift data in Reg 2 |
| X | L | L | H | L | $\uparrow$ | L | L. | INPUT | Reg 1 ORs data from Reg 2 and I/O, shift data in Reg 2 |
| X | H | X | X | X | $\uparrow$ | L | H |  | Synchronously clear Reg 1 and Reg 2 |
| X | X | $x$ | $x$ | X | $x$ | H | X |  | Asynchronously clear Reg 1 and Reg 2 |
| $x$ | L | $x$ | X | X | $\uparrow$ | L | H | INPUT | Enter data from I/O into Reg 1 and synchronously clear Reg 2 |

## 'ALS963 typical sequence

Illustrated below is the following sequence:

1. Clear both registers to zero.
2. Input 00110011 in Reg 1.
3. Transfer 00110011 from Reg 1 to Reg 2.
4. Input 01110111 into Reg 1.
5. Shift contents of Reg 2, SERIN $=0$
6. Shift contents of Reg 2, SERIN $=1$
7. Exchange contents of Reg 1 with Reg 2.


## 'ALS964 typical sequence

Illustrated below is the following sequence:

1. Asynchronously clear Reg 1 and Reg 2 to zero, operate, then synchronously clear.
2. Input 00110011 into Reg 1.
3. Transfer 00110011 from Reg 1 to Reg 2 and input 01110111 into Reg 1.
4. Shift contents of Reg 2, SERIN $=0$
5. Shift contents of Reg 2, SERIN $=1$
6. Exchange contents of Reg 1 with Reg 2.


## SN54ALS963, SN54ALS964, SN74ALS963, SN74ALS964 DUAL-RANK 8-BIT SHIFT REGISTERS WITH 3-STATE OUTPUTS

| absolute maximum ratings over operating free-air temperature range (unless otherwise noted) |  |
| :---: | :---: |
| Supply voltage, VCC | 7 V |
| Input voltage: All inputs |  |
| I/O ports | 5.5 V |
| Operating free-air temperature range | SN54ALS963, SN54ALS964 . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74ALS963, SN74ALS964 . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

## 'ALS963 recommended operating conditions

|  |  |  |  | 54ALS | 963 |  | 4ALS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX | UNIT |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | $\checkmark$ |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current |  |  |  | -1 |  |  | -2.6 | mA |
|  | Low-level output current | SEROUT |  |  | 8 |  |  | 16 | mA |
|  | Low-level output current | $\mathrm{Q}_{\text {A }}$ thru $\mathrm{O}_{H}$ |  |  | 12 |  |  | 24 |  |
| $\mathrm{f}_{\text {clock }}$ | Clock frequency (at 50\% | duty cycle) | 0 |  | 25 | 0 |  | 25 | MHz |
|  | Pulse duration | CLK1 high or low | 20 |  |  | 20 |  |  |  |
|  | Pulse duration | CLK2 high or low | 20 |  |  | 20 |  |  |  |
|  |  | Data before CLK1 $\dagger$ |  |  |  |  |  |  |  |
|  |  | $\overline{\text { GIN }}$ before CLK 11 |  |  |  |  |  |  |  |
|  | Setup time | $\overline{\mathrm{G1} 1-2}$ before CLK $2 \uparrow$ |  |  |  |  |  |  | ns |
| $\mathrm{t}_{\text {su }}$ | Setup time | $\overline{\text { G2-1 }}$ before CLK1 $\uparrow$ |  |  |  |  |  |  |  |
|  |  | $\overline{\text { GSH }}$ before CLK $2 \uparrow$ |  |  |  |  |  |  |  |
|  |  | SCLR before CLK $1 \uparrow$ or CLK $2 \uparrow$ |  |  |  |  |  |  |  |
| $\mathrm{th}^{\text {h }}$ | Hold time after CLK $1 \uparrow$ or | CLK2 $\uparrow$ |  |  |  |  |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air tempera | ture | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

'ALS964 recommended operating conditions


## SN54ALS963, SN54ALS964, SN74ALS963, SN74ALS964 DUAL-RANK 8-BIT SHIFT REGISTERS WITH 3-STATE OUTPUTS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | SN54ALS963 <br> SN54ALS964 |  |  | SN74ALS963 <br> SN74ALS964 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | Min | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ to 5.5 V , | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{Cc}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-1 \mathrm{~mA}$ | $2.4 \quad 3.3$ |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\text {O }}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\text {OL }}$ | SEROUT | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{2}=8 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\text {O }}$ = 16 mA |  |  |  |  | 0.35 | 0.5 |  |
|  | $\mathrm{O}_{\mathrm{A}}$ thru $\mathrm{O}_{\mathrm{H}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\text {O }}$ 24 mA |  |  |  |  | 0.35 | 0.5 |  |
| 1 | A thru H | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
|  | Any other | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 |  |
| $\mathrm{IIH}^{\ddagger}$ |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| -115 |  | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{8}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ${ }^{\text {I C C }}$ | 'ALS963 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | Outputs high |  |  |  |  |  |  | mA |
|  |  |  | Outputs low |  |  |  |  |  |  |  |
|  |  |  | Outputs disabled |  |  |  |  |  |  |  |
|  | 'ALS964 | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$ | Outputs high |  |  |  |  |  |  | mA |
|  |  |  | Outputs low |  |  |  |  |  |  |  |
|  |  |  | Outputs disabled |  |  |  |  |  |  |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports $\left(\mathrm{O}_{\mathrm{A}}\right.$ throuh $\left.\mathrm{O}_{\mathrm{H}}\right)$, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.

- ${ }^{\text {The }}$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
'ALS963 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF} \\ & \mathrm{R} 1=500 \Omega, \\ & \mathrm{R}_{2}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \\ & \hline \end{aligned}$ |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54ALS963 |  |  | SN74ALS963 |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| $f_{\text {max }}$ | CLK1 or CLK2 | Any Q | 25 | 30 |  | 25 | 30 |  | MHz |
| tPLiH | CLK 1 | Any 0 |  | 10 |  |  | 10 |  | ns |
| tPHL |  |  |  | 14 |  |  | 14 |  |  |
| tPLH | CLK2 | SEROUT |  | 10 |  |  | 10 |  | ns |
| ${ }^{\text {t PHL }}$ |  |  |  | 14 |  |  | 14 |  |  |
| ${ }_{\text {t }}$ PHZ | $\overline{\mathrm{OE}}$ | Any Q |  | 15 |  |  | 15 |  | ns |
| tPLZ |  |  |  | 18 |  |  | 18 |  |  |
| ${ }^{\text {tPZH }}$ | $\overline{O E}$ | Any 0 |  | 12 |  |  | 12 |  | ns |
| tPZL |  |  |  | 12 |  |  | 12 |  |  |

'ALS964 switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & R 1=500 \Omega, \\ & R 2=500 \Omega, \\ & T_{A}=\text { MIN to MAX } \end{aligned}$ |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | SN54ALS964 |  |  | SN74ALS964 |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| $f_{\text {max }}$ | CLK | Any Q | 25 | 30 |  | 25 | 30 |  | MHz |
| tPLH | CLK | Any 0 |  | 10 |  |  | 10 |  | ns |
| tPHL |  |  |  | 14 |  |  | 14 |  |  |
| tPLH | CLK | SEROUT |  | 10 |  |  | 10 |  | ns |
| tPHL |  |  |  | 14 |  |  | 14 |  |  |
| tPHZ | ACLR | Any Q or SEROUT |  | 14 |  |  | 14 |  | ns |
| ${ }_{\text {t }}$ | $\overline{O E}$ | Any 0 |  | 15 |  |  | 15 |  | ns |
| tPLZ |  |  |  | 18 |  |  | 18 |  |  |
| $\mathrm{t}_{\mathrm{P} Z \mathrm{H}}$ | $\overline{O E}$ | Any 0 |  | 12 |  |  | 12 |  | ns |
| tPZL |  |  |  | 12 |  |  | 12 |  |  |

NOTE: Load circuit and voltage waveforms are shown in Section 1.
－3－State I／O－Type Read－Back Inputs
－Bus－Structured Pinout
－Choice of True or Inverting Logic
＇ALS990 ．．．True Outputs
＇ALS991 ．．．Inverting Outputs
－Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
－Dependable Texas Instruments Quality and Reliability

## description

These 8－bit latches are designed specifically for storing the contents of the input data bus plus providing the capability of reading－back the stored data onto the input data bus．

The eight latches of the＇ALS990 and＇ALS991 are transparent D－type．While the enable（C）is high，the Q outputs of the＇ALS990 will follow the data（ D ）inputs．For the＇ALS991，the Q outputs will provide the complement of what is applied to its data（D）inputs．

Read－back is provided through the read－back control input（ $\overline{\mathrm{OERB}}$ ）．When the control is taken low，the data present at the output of the data latches will be allowed to pass back onto the input data bus．When it is taken high，the output of the data latches will be isolated from the data （D）inputs．The read－back control does not affect the internal operation of the latches；however， precautions should be taken not to create a bus－ conflict situation．

The SN74ALS990 and SN74ALS991 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ ．

SN74ALS990 ．．．DW OR N PACKAGE
（TOP VIEW）

| $\overline{\mathrm{OERB}} 1$ | $\mathrm{U}_{20}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| $10 \square 2$ | 19 | 10 |
| 20 $\square^{3}$ | 18 | 20 |
| 3D 4 | 17 | － 30 |
| 4D 5 | 16 | － 40 |
| 50［6 | 15 | 50 |
| $60 \square 7$ | 14 | ］ 6 |
| 70 8 | 13 | 70 |
| 8D $\square^{9}$ | 12 | 80 |
| GND 10 | $0 \quad 11$ | 万c |

SN74ALS990 ．．．FN PACKAGE
（TOP VIEW）


SN74ALS991 ．．．DW OR N PACKAGE
（TOP VIEW）

| $\overline{\text { OERB }} \square^{1}$ | $\left.\mathrm{U}_{20}\right] V_{\mathrm{CC}}$ |
| :---: | :---: |
| $10 \square 2$ | $19 \square 1 \overline{0}$ |
| $20-3$ | 18 П $2 \overline{\mathrm{Q}}$ |
| 30 $\square_{4}$ | $17 \square 3 \mathrm{O}$ |
| 4D 5 | $16 \square 4 \overrightarrow{0}$ |
| 50 $\square^{6}$ | 15 －${ }^{\text {a }}$ |
| 60 7 | $14 \square 6 \overline{\mathrm{Q}}$ |
| 70－8 | $13 \square 7 \overrightarrow{\mathrm{Q}}$ |
| 80 9 | 12 砍 |
| GND 10 | $11] \mathrm{c}$ |

SN74ALS991 ．．．FN PACKAGE （TOP VIEW）

logic symbols ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
logic diagrams (positive logic)



## SN74ALS990, SN74ALS991

## 8-BIT D-TYPE TRANSPARENT READ-BACK LATCHES

## timing diagram


${ }^{\dagger}$ This setup time ensures the readback circuit will not create a conflict on the input data bus.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
$\qquad$Input voltage, ( $\overline{O E R B}$ and $C$ inputs)V
Voltage applied to D inputs ..... 5.5 V
Operating free-air temperature range SN74ALS990, SN74ALS991 $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  |  | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current |  | 0 |  |  | -2.6 | mA |
|  |  |  | D |  |  | -0.4 |  |
| ${ }^{1} \mathrm{OL}$ | Low-level output current |  | Q |  |  | 24 | mA |
|  |  |  | D |  |  | 8 |  |
| $t_{w}$ | Pulse duration, enable C high |  |  | 10 |  |  | ns |
| ${ }^{\text {tsu }}$ | Setup time | Data before $\mathrm{C} \downarrow$ <br> Data before $\overline{\text { OERB }} \downarrow$ |  | 10 |  |  | ns |
|  |  |  |  | 10 |  |  | ns |
| $t_{h}$ | Hold time | Data after Cl |  | 5 |  |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $\mathrm{I} / \mathrm{O}$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce a current that closely approximates one half the true short-circuit output current, los.
'ALS990 switching characteristics

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \end{aligned}$ <br> See Figures 1 and 2 |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & C_{L}=50 \mathrm{pF} \\ & T_{A}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \\ & \text { See Figures } 1 \text { and } 2 \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| tPLH | D | Q |  | 8 | 14 | 4 | 17 | ns |
| tPHL |  |  |  | 11 | 22 | 5 | 24 |  |
| tPLH | C | 0 |  | 13 | 22 | 6 | 26 | ns |
| tPHL |  |  |  | 16 | 23 | 8 | 26 |  |
| $t_{\text {en }}$ | $\overline{\text { OERB }}$ | D |  | 12 | 18 | 4 | 21 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 10 | 18 | 4 | 19 |  |

$\mathrm{t}_{\mathrm{en}}=\mathrm{t}_{\mathrm{PZL}}$ or $\mathrm{t}_{\mathrm{PZH}}$
$\mathrm{t}_{\mathrm{dis}}=\mathrm{t}_{\mathrm{pLZ}}$ or $\mathrm{t}_{\mathrm{PH}} \mathrm{Z}$
'ALS991 switching characteristics

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~T}_{A}=25^{\circ} \mathrm{C} \end{aligned}$ <br> See Figures 1 and 2 |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}, \\ & \text { See Figures } 1 \text { and } 2 \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | $\overline{\mathrm{Q}}$ |  | 12 | 15 | 4 | 20 | ns |
| ${ }^{\text {t PHL }}$ |  |  |  | 9 | 12 | 4 | 15 |  |
| ${ }^{\text {tPLH }}$ | C | $\overline{\mathrm{Q}}$ |  | 17 | 21 | 9 | 28 | ns |
| tPHL |  |  |  | 14 | 18 | 7 | 23 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{\text { OERB }}$ | D |  | 12 | 17 | 4 | 22 | ns |
| $t_{\text {dis }}$ |  |  |  | 8 | 12 | 4 | 17 |  |

[^45]
## PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT FOR Q OR $\overline{\mathrm{O}}$ OUTPUTS

Figure 1


LOAD CIRCUIT FOR D OUTPUTS
FIGURE 2
NOTE A: $C_{L}$ includes probe and jig capacitance.


VOLTAGE WAVEFORMS SETUP AND HOLD TIMES


VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES


VOLTAGE WAVEFORMS PULSE WIDTHS


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses have the following characteristics: PRR $\leq 1 \mathrm{MHz}, t_{r}=t_{f}=2 \mathrm{~ns}$, duty cycle $=50 \%$.
D. When measuring propagation delay times of 3-state outputs, switch S1 is open.


- Bus-Structured Pinout
- Choice of True or Inverting Logic
'ALS992 . . . True Outputs
'ALS993 . . . Inverting Outputs
- Designed with 9 Bits for Parity Applications
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 9-bit latches are designed specifically for storing the contents of the input data bus plus providing the capability of reading-back the stored data onto the input data bus. In addition, they provide a 3-state buffer-type output and are easily implemented in parity applications.
The nine latches of the 'ALS992 and 'ALS993 are transparent $D$-type. While the enable (C) is high, the Q outputs of the 'ALS992 will follow the data ( $D$ ) inputs. For the 'ALS993, the $\overline{\mathrm{Q}}$ outputs will provide the complement of what is applied to its data (D) inputs. On both devices, the Q or $\overrightarrow{\mathrm{Q}}$ outputs will be in the 3 -state condition when output enable $\overline{\mathrm{OEO}}$ is high.
Read-back is provided through the read-back control input ( $\overline{O E R B}$ ). When the control is taken low, the data present at the output of the data latches will be allowed to pass back onto the input data bus. When it is taken high, the output of the data latches will be isolated from the data (D) inputs. The read-back control does not affect the internal operation of the latches; however, precautions should be taken not to create a busconflict situation.

The SN74ALS992 and SN74ALS993 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


SN74ALS992 . . . FN PACKAGE
(TOP VIEW)


SN74ALS993 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{O E R B}]$ | $\mathrm{V}_{24} \mathrm{~V}_{\text {CC }}$ |
| :---: | :---: |
| 10 2 | 23 -10 |
| 20 3 | 22 - $2 \overline{\mathrm{a}}$ |
| 30 $\square^{4}$ | 21 ¢ 300 |
| 4 D 5 | 20 ¢ 40 O |
| 50 | 19 50 |
| $60 \square$ | 18 60 |
| 70 ${ }^{8}$ | 17 7 वे |
| $8 \mathrm{C} \mathrm{C}^{9}$ | 16 ¢ $8 \overline{0}$ |
| 90 -10 | ${ }^{15} 90 \overline{0}$ |
| $\overline{\text { CLR }} \square_{11}$ | $14 \bigcirc \overline{O E O}$ |
| GND 12 | 13.7 |

SN74ALS993 . . . FN PACKAGE (TOP VIEW)


[^46]
## SN74ALS992, SN74ALS993

## 9.BIT D-TYPE TRANSPARENT READ-BACK LATCHES

 WITH 3-STATE OUTPUTSlogic symbols ${ }^{\dagger}$
-ALS992

'ALS993

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers are for DW and NT packages.
logic diagrams (positive logic)
-ALS992
$\overline{O E O} \xrightarrow{(14)} D$


$$
2 D
$$

$$
30
$$

$$
40
$$

$$
\begin{gathered}
50 \\
\end{gathered}
$$

$$
90
$$

'ALS993
$\overline{O E O}(14) \quad d$


## timing diagram


$\overline{\mathrm{CLR}}=\mathrm{H}, \overline{\mathrm{OEQ}}=\mathrm{L}$
*This setup time ensures the readback circuit will not create a conflict on the input data bus.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC ..... 7 V
Input voltage, ( $\overline{\mathrm{OERB}}, \overline{\mathrm{OE}}, \overline{\mathrm{CLR}}$, and C inputs) ..... 7 V
Voltage applied to D inputs and to disabled 3 -state outputs ..... 5.5 V
Operating free-air temperature range ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current | Q or $\overline{\mathrm{Q}}$ |  |  | -2.6 | mA |
|  |  | D |  |  | -0.4 |  |
| ${ }^{1} \mathrm{OL}$ | Low-level output current | Q or $\overline{\mathrm{Q}}$ |  |  | 24 | mA |
|  |  | D |  |  | 8 |  |
| ${ }_{\text {t }}$ w | Pulse duration | Enable C high | 10 |  |  | ns |
|  |  | CLR low | 10 |  |  |  |
| ${ }^{\text {tsu }}$ | Setup time | Data before Cl | 10 |  |  | ns |
|  |  | Data before $\overline{\text { OERB }} \downarrow$ | 10 |  |  |  |
| $t_{h}$ | Hold time | Data after $\mathrm{C} \downarrow$ | 5 |  |  | ns |
| ${ }^{\text {T }}$ A | Operating free-air temperature |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYPt | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIK |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | I $=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| VOH | $\begin{gathered} \text { All outputs } \\ \text { Q or } \mathrm{Q} \\ \hline \end{gathered}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V , | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-2.6 \mathrm{~mA}$ | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | D | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=8 \mathrm{~mA}$ |  | 0.35 | 0.5 |  |
|  | 0 or $\overline{0}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$, | $\mathrm{l}_{\mathrm{OL}}=24 \mathrm{~mA}$ |  | 0.35 | 0.5 |  |
| IOZH | $Q$ or $\overline{\mathrm{Q}}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |
| 1 | D inputs | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 | mA |
|  | All other | - $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |
| ${ }^{1} \mathrm{H}$ | D inputs ${ }^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{A}$ |
|  | All other |  |  |  |  | 20 |  |
| IIL | D inputs ${ }^{\ddagger}$ | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 | mA |
|  | All other |  |  |  |  | -0.1 |  |
| $10^{8}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | mA |
| ICC | 'ALS992 |  | Q outputs high |  | 30 | 50 | mA |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \overline{\text { OERB }}$ high | Q outputs low |  | 50 | 80 |  |
|  |  |  | Q outputs disabled |  | 35 | 55 |  |
|  | 'ALS993 | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \overline{\mathrm{OERB}} \mathrm{high}$ | $\overline{\mathrm{O}}$ outputs high |  | 30 | 50 | mA |
|  |  |  | $\overline{\mathrm{O}}$ outputs low |  | 52 | 82 |  |
|  |  |  | O$o u t p u t s ~ d i s a b l e d ~$ |  | 40 | 60 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $\mathrm{I} / \mathrm{O}$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
$\S$ The output conditions have been chosen to produce a current that closely approximates one half the true short-circuit output current, IOS.

## WITH 3-STATE OUTPUTS

'ALS992 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & C_{L}=50 \mathrm{pF} \\ & \mathrm{~T}_{A}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| tPLH | D | Q |  | 7 | 10 | 3 | 14 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 9 | 13 | 4 | 16 |  |
| tPLH | C | 0 |  | 12 | 15 | 6 | 20 | ns |
| ${ }^{\text {P PHL }}$ |  |  |  | 15 | 19 | 8 | 25 |  |
| ${ }_{\text {tPHL }}$ | $\overline{C L R}$ | Q |  | 12 | 16 | 6 | 20 | ns |
| ${ }^{\text {t }} \mathrm{PHL}$ |  | D |  | 15 | 22 | 8 | 26 |  |
| $t_{\text {en }}$ | $\overline{O E R B}$ | D |  | 11 | 17 | 4 | 21 | ns |
| $t_{\text {dis }}$ |  |  |  | 6 | 11 | 2 | 14 |  |
| $t_{\text {en }}$ | $\overline{O E O}$ | Q |  | 11 | 16 | 4 | 18 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 6 | 10 | 1 | 14 |  |

'ALS993 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathbf{C C}}=5 \mathrm{~V} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~T}_{\mathbf{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | $\overline{\mathrm{o}}$ |  | 11 | 14 | 6 | 20 | ns |
| ${ }_{\text {t }}^{\text {PHL }}$ |  |  |  | 8 | 11 | 4 | 15 |  |
| ${ }^{\text {tPLH }}$ | C | $\bar{\square}$ |  | 16 | 20 | 9 | 28 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 13 | 16 | 7 | 22 |  |
| ${ }^{\text {tPLH }}$ | $\overline{C L R}$ | $\overline{\mathrm{O}}$ |  | 10 | 13 | 5 | 17 | ns |
| ${ }^{\text {t PLH. }}$ |  | D |  | 15 | 22 | 8 | 26 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{O E R B}$ | D |  | 11 | 17 | 4 | 21 | ns |
| ${ }^{\text {d }}$ dis |  |  |  | 6 | 11 | 2 | 14 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{O E O}$ | $\overline{\mathrm{Q}}$ |  | 11 | 16 | 4 | 20 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 6 | 10 | 1 | 12 |  |

$t_{\text {en }}=t_{\text {PZH }}$ or tPZL
$\mathrm{t}_{\text {dis }}=\mathrm{t}_{\mathrm{PH}} \mathrm{HZ}$ or tpLZ

## PARAMETER MEASUREMENT INFORMATION



- 3-State I/O-Type Read-Back Inputs
- Bus-Structured Pinout
- Choice of True or Inverting Logic
'ALS994 . . . True Outputs
'ALS995 . . . Inverting Outputs
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit latches are designed specifically for storing the contents of the input data bus plus providing the capability of reading-back the stored data onto the input data bus.
The ten latches of the 'ALS994 and 'ALS995 are transparent $D$-type. While the enable ( $C$ ) is high, the Q outputs of the 'ALS994 will follow the data (D) inputs. For the 'ALS995, the Q outputs will provide the inverse of what is applied to its data (D) inputs.
Read-back is provided through the read-back control input ( $\overline{\mathrm{OERB}}$ ). When the control is taken low, the data present at the output of the data latches will be allowed to pass back onto the input data bus. When it is taken high, the output of the data latches will be isolated from the data (D) inputs. The read-back control does not affect the internal operation of the latches; however, precautions should be taken not to create a busconflict situation.

The SN74ALS994 and SN74ALS995 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN74ALS994 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{O E R B} \square_{1}$ | $\mathrm{U}_{24}$ | $\square \mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| 1D 2 | 23 | 10 |
| 2D $\square^{3}$ | 22 | 20 |
| 3D $\square_{4}$ | 21 | 30 |
| 4 D 5 | 20 | 40 |
| 5D $\square^{6}$ | 19 | 50 |
| $6 \mathrm{\square} 7$ | 18 | 60 |
| $70 \square$ | 17 | 70 |
| 80 $\square^{9}$ | 16 | 80 |
| 90 10 | 15 | 90 |
| 100 11 | 14 | 100 |
| GND 12 | 13 | C |

SN74ALS994 . . . FN PACKAGE (TOP VIEW)


NC-No internal connection.

Texas
INSTRUMENTS

## SN74ALS994, SN74ALS995

## 10-BIT D-TYPE TRANSPARENT READ-BACK LATCHES

SN74ALS995 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{\text { OERB }} 1$ | $\mathrm{U}_{24} \mathrm{~V}_{\mathrm{CC}}$ |
| :---: | :---: |
| 10 2 | 23 110 |
| 20 ${ }^{2}$ | 22 - $\overline{0}$ |
| 3D 4 | 21 -30 |
| 40 5 | 20 - $4 \overline{0}$ |
| 50 $\square^{6}$ | 19 ¢0 |
| $60 \square$ | 18 ¢ $6 \overline{\mathrm{Q}}$ |
| 70 8 | 17 万7 |
| 8 D 9 | 16 ¢ $8 \overrightarrow{0}$ |
| 90-10 | 15 - 90 |
| 10D 11 | 14 ¢ $10 \overline{\mathrm{Q}}$ |
| GND 12 | $13 \bigcirc \mathrm{C}$ |

NC - No internal connection
logic symbols ${ }^{\dagger}$


SN74ALS995 . . . FN PACKAGE (TOP VIEW)

'ALS995

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW and NT packages.

SN74ALS994, SN74ALS995 10-BIT D-TYPE TRANSPARENT READ-BACK LATCHES
logic diagrams (positive logic)


## timing diagram


${ }^{\dagger}$ This setup time ensures the readback circuit will not create a conflict on the input data bus.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC ..... 7 V
Input voltage ( $\overline{\mathrm{OERB}}$ and C ) ..... 7 V
Voltage applied to D inputs ..... 5.5 V
Operating free-air temperature range ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 | V |
| ${ }^{\mathrm{IOH}}$ | High-level output current | Q or $\overline{\mathrm{Q}}$ |  |  | -2.6 | mA |
|  |  | D |  |  | -0.4 |  |
| ${ }^{\text {IOL }}$ | Low-level output current | Q or $\overline{\mathrm{Q}}$ |  |  | 24 | mA |
|  |  | D |  |  | 8 |  |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, enable C high |  | 10 |  |  | ns |
| $\mathrm{t}_{\mathrm{su}}$ | Setup time | Data before C $\downarrow$ | 10 |  |  | ns |
|  |  | Data before $\overline{\text { OERB }} \downarrow^{\dagger}$ | 10 |  |  |  |
| $t_{\text {h }}$ | Hold time | Input data after C $\downarrow$ | 5 |  |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ This setup time ensures the readback circuit will not create a conflict on the input data bus.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYP ${ }^{\dagger}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IK}}$ |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | All outputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 55 V , $\mathrm{I}_{\mathrm{OH}}=-0.4 \mathrm{~mA}$ |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  | O or $\overline{\mathrm{Q}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}_{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  | 2.43 .2 |  |  |  |
| VOL | D | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OL}}=4 \mathrm{~mA}$ |  | 0.25 | 0.4 | v |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=8 \mathrm{~mA}$ |  | 0.35 | 0.5 |  |
|  | Q or $\overline{\mathrm{Q}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{l}_{\mathrm{OL}}=12 \mathrm{~mA}$ |  |  | 0.25 | 0.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ |  | 0.35 | 0.5 |  |
| 1 | OERB, C | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \quad \mathrm{~V}_{1}=7 \mathrm{~V}$ |  |  |  | 0.1 | mA |
|  | $D$ inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |
| ${ }_{1} \mathrm{H}$ | OERB, C | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 | $\mu \mathrm{A}$ |
|  | D inputs ${ }^{\ddagger}$ |  |  |  |  | 20 |  |
| IIL | OERB, C | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 | mA |
|  | D inputs ${ }^{\ddagger}$ |  |  |  |  | -0.1 |  |
| 108 |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 |  | mA |
| ${ }^{\text {I C C }}$ | 'ALS994 |  | Q outputs high |  | 30 | 50 | mA |
|  |  | $\begin{aligned} & V_{C C}=5.5 \mathrm{~V}, \\ & O E R B \text { high } \end{aligned}$ | Q outputs low |  | 52 | 82 |  |
|  | 'ALS995 |  | $\overline{\mathrm{O}}$ outputs high |  | 30 | 50 |  |
|  |  |  | $\overline{\mathrm{Q}}$ outputs low |  | 55 | 85 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
§The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit output current, IOS.

## 10-BIT D-TYPE TRANSPARENT READ-BACK LATCHES

## 'ALS994 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{\mathrm{L}}=50 \mathrm{pF}, \\ & T_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN TYP | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | D | 0 | 7 | 10 | 3 | 14 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 11 | 15 | 4 | 18 |  |
| ${ }^{\text {tPLH }}$ | C | 0 | 12 | 16 | 6 | 21 | ns |
| ${ }^{\text {tPHL }}$ |  |  | 16 | 21 | 8 | 27 |  |
| ten | $\overline{\text { OERB }}$ | D | 11 | 17 | 4 | 21 | ns |
| ${ }_{\text {d }}^{\text {dis }}$ |  |  | 9 | 13 | 2 | 16 |  |

'ALS995 switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| tPLH | D | $\overline{0}$ |  | 12 | 16 | 6 | 20 | ns |
| ${ }^{\text {t }}$ PHL |  |  |  | 9 | 12 | 4 | 15 |  |
| tPLH | C | $\overline{\mathrm{Q}}$ |  | 17 | 23 | 9 | 28 | ns |
| tPHL |  |  |  | 14 | 19 | 7 | 22 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{\text { OERB }}$ | D |  | 12 | 18 | 4 | 21 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 8 | 12 | 2 | 15 |  |

SN74ALS994, SN74ALS995
10-BIT D-TYPE TRANSPARENT READ-BACK LATCHES


FIGURE 1


## 8-BIT D-TYPE EDGE-TRIGGERED READ-BACK LATCHES

- 3-State I/O-Type Read-Back Inputs
- Bus-Structured Pinout
- T/高 Determines True or Complementary Data at O Outputs
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 8-bit registers are designed specifically for storing the contents of the input data bus plus providing the capability of reading-back the stored data onto that bus. The Q outputs are designed with bus-driving capability.

The edge-triggered flip-flops enter the data on the low-to-high transition of the clock (CL.K) when enable ( $\overline{\mathrm{EN}}$ ) is low. Data can be read-back onto the data inputs by taking the read input ( $\overline{\mathrm{RD}}$ ) low, in addition to having $\overline{\mathrm{EN}}$ low. Whenever $\overline{\mathrm{EN}}$ is high, both the read-back and write modes are disabled. Transitions on $\overline{E N}$ should only be made with CLK high in order to prevent false clocking.

The polarity of the Q outputs can be controlied by the polarity input $T / \overline{\mathrm{C}}$. When $\mathrm{T} / \overline{\mathrm{C}}$ is high, Q will be the same as is stored in the flip-flops. When $T / \bar{C}$ is low, the output data will be inverted. The Q outputs can be placed in a highimpedance state by taking the output control ( $\overline{\mathrm{G}}$ ) high. The output control $\overline{\mathrm{G}}$ does not affect the internal operations of the register. Old data can be retained or new data can be entered while the outputs are off.
A low level at the clear input ( $\overline{C L R}$ ) resets the internal registers low. The clear function is asynchronous and overrides all other register functions.

The -1 version of the SN74ALS996 is identical to the standard version except that the recommended maximum $I_{O L}$ is increased to 48 milliamperes.

The SN74ALS996 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## SN74ALS996

## 8-BIT D-TYPE EDGE-TRIGGERED READ.BACK LATCHES

logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
logic diagram (positive logic)


Pin numbers shown are for DW and NT packages.
timing diagram
( $\mathrm{T} / \overline{\mathrm{C}}=\mathrm{H}$ )
$\overline{C L R}$


$\stackrel{1}{\text { ASYNC }}$
CLEAR

This hold time ensures the readback circuit will not create a conflict on the input data bus.

| absolute maximum ratings over operating free-air temperature range (unless otherwise noted) |  |
| :---: | :---: |
| Supply voltage, $V_{C C}$ <br> Input voltage ( $\overline{\mathrm{G}}, \frac{\mathrm{RD}}{\mathrm{RD}}, \overline{\mathrm{EN}}, \mathrm{CLK}, \overline{\mathrm{CLR}}$, and $\left.\overline{\mathrm{T}} / \overline{\mathrm{C}}\right)$ |  |
| Voltage applied to D inputs and to disabled 3-state outputs | 5.5 V |
| Operating free-air temperature range | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

|  |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | V |
| $\mathrm{V}_{\text {iL }}$ | Low-level input voltage |  |  |  | 0.8 | V |
| ${ }^{1} \mathrm{OH}$ | High-level output current | 0 |  |  | 2.6 | mA |
|  |  | D |  |  | -0.4 |  |
| ${ }^{1} \mathrm{OL}$ | Low-level output current | 0 |  |  | 24 | mA |
|  |  |  |  |  | $48^{\dagger}$ |  |
|  |  | D |  |  | 8 |  |
| ${ }^{\text {c }}$ lock | Clock frequency |  | 0 |  | 35 | MHz |
| ${ }^{t} w$ | Pulse duration | $\overline{C L R}$ low | 10 |  |  | ns |
|  |  | CLK low | 14.5 |  |  |  |
|  |  | CLK high | 14.5 |  |  |  |
| ${ }^{\text {tsu }}$ | Setup time | Data before CLK $\uparrow$ | 15 |  |  | ns |
|  |  | $\overline{\mathrm{EN}}$ low before CLK $\uparrow$ | 10 |  |  |  |
|  |  | CLK high before ENT $\uparrow{ }^{\ddagger}$ | 15 |  |  |  |
|  |  | $\overline{\text { CLR }}$ high (inactive) before CLK $\uparrow$ | 10 |  |  |  |
| ${ }^{\text {th }}$ | Hold time | Data after CLK $\uparrow$ | 0 |  |  | ns |
|  |  | $\overline{\mathrm{EN}}$ low after CLK $\dagger$ | 5 |  |  |  |
|  |  | $\overline{\mathrm{RD}}$ high after $\mathrm{CLK} \dagger^{\text {§ }}$ | 5 |  |  |  |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | 0 |  | . 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The $48-\mathrm{mA}$ limit applies for the SN74ALS966-1 only and only if $\mathrm{V}_{\mathrm{CC}}$ is maintained between 4.75 V and 5.25 V .
$\ddagger$ This setup time guarantees that $\overline{E N}$ will not false clock the data register.
${ }^{\S}$ This hold time ensures there will be no conflict on the input data bus.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\ddagger}$ For $I / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
${ }^{\S}$ The output conditions have been chosen to produce current that closely approximates one half of the true short-circuit output current, $l_{\mathrm{OS}}$.
switching characteristics (see Figure 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{I}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & C_{L}=50 \mathrm{pF} . \\ & \mathrm{T}_{A}=0^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C} \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| $f_{\text {max }}$ |  |  |  | 40 |  | 35 |  | MHz |
| - tPLH | $\begin{gathered} \mathrm{CLK} \\ (\mathrm{~T} / \overline{\mathrm{C}}=\mathrm{H} \text { or } \mathrm{L}) \end{gathered}$ | 0 |  | 16 | 24 | 5 | 28 | ns |
| tpHL |  |  |  | 16 | 24 | 5 | 28 |  |
| tPLH | $\overline{\mathrm{CLR}}(\mathrm{T} / \overline{\mathrm{C}}=\mathrm{L})$ | 0 |  | 15 | 23 | 7 | 27 | ns |
| tphL | $\overline{\mathrm{CLR}}(\mathrm{T} / \overline{\mathrm{C}}=\mathrm{H})$ |  |  | 13 | 19 | 7 | 23 |  |
| tPLH | T/ $\overline{\mathrm{C}}$ | 0 |  | 13 | 20 | 5 | 23 | ns |
| tPHL |  |  |  | 13 | 20 | 5 | 23 |  |
| tpHL | $\overline{\text { CLR }}$ | D |  | 19 | 25 | 8 | 30 | ns |
| ten | $\overline{\text { RD }}$ | D |  | 9 | 15 | 3 | 16 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 10 | 16 | 3 | 19 |  |
| ten | $\overline{\mathrm{EN}}$ | D |  | 9 | 14 | 3 | 16 | ns |
| $\mathrm{t}_{\text {dis }}$ |  |  |  | 10 | 16 | 3 | 19 |  |
| $\mathrm{t}_{\text {en }}$ | $\overline{\mathrm{G}}$ | 0 |  | 8 | 13 | 4 | 15 | ns |
| ${ }^{\text {dis }}$ |  |  |  | 4 | 8 | 1 | 10 |  |

[^47]
## 8-BIT D-TYPE EDGE-TRIGGERED READ-BACK LATCHES

## PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT FOR Q OUTPUTS


LOAD CIRCUIT FOR D OUTPUTS


VOLTAGE WAVEFORMS PULSE WIDTHS


VOLTAGE WAVEFORMS
enable and disable times, three-state outputs

NOTES:
A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses have the following characteristics: $\mathrm{PRR} \leq 1 \mathrm{MHz}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=2 \mathrm{~ns}$, duty cycle $=50 \%$.
D. When measuring propagation delay times of 3 -state outputs, switch S 1 is open.

FIGURE 1

## SN54AS1181, SN74AS1181 ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

- Package Options Include Compact 300-mil or Standard 600-mil DIPs and Both Plastic and Ceramic Chip Carriers
- Full Look-Ahead for High-Speed Operations on Long Words
- Arithmetic Operating Modes:


## Addition

Subtraction
Shift Operand A One Position
Magnitude Comparison
Plus Twelve Other Arithmetic Operations

- Logic Function Modes

Exclusive-OR
Comparator
AND, NAND, OR, NOR

- Dependable Texas Instruments Quality and Reliability
logic symbol ${ }^{\dagger}$


SN54AS1181 . . . JT OR JW PACKAGE SN74AS1181 . . . DW, NT, OR NW PACKAGE (TOP VIEW)

| $\overline{\mathrm{B}} 0 \square_{1}$ | $\mathrm{U}_{24} \square \mathrm{~V}_{\mathrm{CC}}$ |
| :---: | :---: |
| $\overline{\mathrm{A}} 0$ | 23 - ${ }^{\text {A }} 1$ |
| S3 3 |  |
| S2 4 | 21 A 2 |
| S1 $\square^{5}$ | 20 - ${ }^{\text {B }}$ |
| So 0 | 19 Ā3 |
| $\mathrm{Cn}_{\mathrm{n}}-7$ | 18 - $\overline{\text { B }}$ |
| M $\square^{8}$ | $\left.{ }_{17}\right] \mathrm{G}$ |
| FO $\square^{9}$ | $16 \square C_{n+4}$ |
| F1 10 | 15 P |
| F2 11 | $14 \mathrm{~A}=\mathrm{B}$ |
| GND 12 | ${ }_{13} \square^{\text {F }} 3$ |

```
SN54AS1181 . . . FK PACKAGE
SN74AS1181 . . . FN PACKAGE (TOP VIEW)
```



NC - No internal connection
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, JW, NT, and NW packages.
TYPICAL ADDITION TIMES $C_{L}=15 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=280 \Omega, \mathrm{~T}_{\mathrm{A}}{ }^{\prime}=25^{\circ} \mathrm{C}$

| NUMBER OF BITS | ADDITION TIMES |  |  | PACKAGE COUNT |  | CARRY METHOD BETWEEN ALUs |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | USING 'AS1181 <br> AND'AS882 | USING 'AS181A AND 'AS882 | USING 'S181 AND 'S182 | ARITHMETIC LOGIC UNITS | LOOK-AHEAD CARRY GENERATORS |  |
| 1 to 4 | 5 ns | 5 ns | 11 ns | 1 |  | NONE |
| 5 to 8 | 10 ns | 10 ns | 18 ns | 2 |  | RIPPLE |
| 9 to 16 | 14 ns | 14 ns | 19 ns | 3 or 4 | 1 | FULL LOOK-AHEAD |
| 17 to 64 | 19 ns | 19 ns | 28 ns | 5 to 16 | 2 to 5 | FULL LOOK-AHEAD |

## description

The 'AS1181 arithmetic logic units (ALU)/function generators have a complexity of 75 equivalent gates on a monolithic chip. These circuits perform 16 binary arithmetic operations on two 4-bit words as shown in Tables 1 and 2. These operations are selected by the four function-select lines (S0, S1, S2, S3) and include addition, subtraction, decrement, and straight transfer. When performing arithmetic manipulations, the internal carries must be enabled by applying a low-level voltage to the mode control input (M). A full carry look-ahead scheme is made available in these devices for fast, simultaneous carry generation by means of two cascade-outputs (pins 15 and 17) for the four bits in the package. When used in conjunction with the SN54AS882 or SN74AS882 full carry look-ahead circuits, high-speed arithmetic operations can be performed. The typical addition times shown previously illustrate the little additional time required for addition of longer words when full carry look-ahead is employed. The method of cascading 'AS882 circuits with these ALUs to provide multilevel full carry look-ahead is illustrated under signal designations.
If high speed is not of importance, a ripple-carry input $\left(C_{n}\right)$ and a ripple-carry output $\left(C_{n}+4\right)$ are available. However, the ripple-carry delay has also been minimized so that arithmetic manipulations for small word lengths can be performed without external circuitry.

The 'AS1181 will accommodate active-high or active-low data if the pin designations are interpreted as follows:

| PIN NUMBER | $\mathbf{2}$ | $\mathbf{1}$ | $\mathbf{2 3}$ | $\mathbf{2 2}$ | $\mathbf{2 1}$ | $\mathbf{2 0}$ | $\mathbf{1 9}$ | $\mathbf{1 8}$ | $\mathbf{9}$ | $\mathbf{1 0}$ | $\mathbf{1 1}$ | $\mathbf{1 3}$ | $\mathbf{7}$ | $\mathbf{1 6}$ | $\mathbf{1 5}$ | $\mathbf{1 7}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Active-low data (Table 1) | $\overline{\mathrm{A}} 0$ | $\overline{\mathrm{~B}} 0$ | $\overline{\mathrm{~A}} 1$ | $\overline{\mathrm{~B}} 1$ | $\overline{\mathrm{~A}} 2$ | $\overline{\mathrm{~B}} 2$ | $\overline{\mathrm{~A}} 3$ | $\overline{\mathrm{~B}} 3$ | $\overline{\mathrm{~F}} 0$ | $\overline{\mathrm{~F}} 1$ | $\overline{\mathrm{~F}} 2$ | $\overline{\mathrm{~F}} 3$ | $\mathrm{C}_{n}$ | $\mathrm{C}_{\mathrm{n}}+4$ | $\overline{\mathrm{P}}$ | $\overline{\mathrm{G}}$ |
| Active-high data (Table 2) | A 0 | B 0 | A 1 | B 1 | A 2 | B 2 | A 3 | B 3 | F 0 | F 1 | F 2 | F 3 | $\overline{\mathrm{C}}_{\mathrm{n}}$ | $\overline{\mathrm{C}}_{\mathrm{n}}+4$ | X | Y |

Subtraction is accomplished by 1's complement addition where the 1 's complement of the subtrahend is generated internally. The resultant output is $A-B-1$, which requires an end-around or forced carry to provide $\mathrm{A}-\mathrm{B}$.

The 'AS1181 can also be utilized as a comparator. The $A=B$ output is internally decoded from the function outputs (F0, F1, F2, F3) so that when two words of equal magnitude are applied at the A and B inputs, it will assume a high level to indicate equality $(A=B)$. The ALU must be in the subtract mode with $C_{n}=H$ when performing this comparison. The $A=B$ output is open-collector so that it can be wired-AND connected to give a comparison for more than four bits. The carry output ( $C_{n}+4$ ) can also be used to supply relative magnitude information. Again, the ALU must be placed in the subtract mode by placing the function select input S3, S2, S1, S0 at L, H, H, L, respectively.

| INPUT $\mathbf{C}_{\boldsymbol{n}}$ | OUTPUT $\mathbf{C}_{\boldsymbol{n}}+\mathbf{4}$ | ACTIVE-LOW DATA <br> (FIGURE 1) | ACTIVE-HIGH DATA <br> (FIGURE 2) |
| :---: | :---: | :---: | :---: |
| H | H | $\mathrm{A} \geq \mathrm{B}$ | $\mathrm{A} \leq \mathrm{B}$ |
| H | L | $\mathrm{A}<\mathrm{B}$ | $\mathrm{A}>\mathrm{B}$ |
| L | H | $\mathrm{A}>\mathrm{B}$ | $\mathrm{A}<\mathrm{B}$ |
| L | L | $\mathrm{A} \leq \mathrm{B}$ | $\mathrm{A} \geq \mathrm{B}$ |

These circuits have been designed to not only incorporate all of the designer's requirements for arithmetic operations, but also to provide 16 possible functions of two Boolean variables without the use of external circuitry. These logic functions are selected by use of the four function-select inputs (SO, S1, S2, S3) with the mode-control input ( $M$ ) at a high level to disable the internal carry. The 16 logic functions are detailed in Tables 1 and 2 and include exclusive-OR, NAND, AND, NOR, and OR functions.

## signal designations

In both Figures 1 and 2, the polarity indicators ( $\Delta$ ) indicate that the associated input or output is activelow with respect to the function shown inside the symbol and the symbols are the same in both figures. The signal designations in Figure 1 agree with the indicated internal functions based on active-low data, and are for use with the logic functions and arithmetic operations shown in Table 1. The signal designations have been changed in Figure 2 to accommodate the logic functions and arithmetic operations for the activehigh data given in Table 2. The 'AS1181 together with 'AS882 and 'S182 can be used with the signal designation of either Figure 1 or Figure 2.


Pin numbers shown for the 'AS1181 are for DW, JT, JW, NT, and NW packages.

## TABLE 1

| SELECTION | ACTIVELOW DATA |  |  |
| :---: | :---: | :---: | :---: |
|  | $\mathrm{M}=\mathrm{H}$ | M = L: ARITHM | TIC OPERATIONS |
| S3 S2 S1 S0 | LOGIC FUNCTIONS | $C_{n}=L$ <br> (no carry) | $C_{n}=H$ <br> (with carry) |
| L L L L | $F=\bar{A}$ | $F=A$ MINUS 1 | $F=A$ |
| L L L H | $F=\overline{A B}$ | $F=A B$ MINUS 1 | $F=A B$ |
| L L H L | $F=\bar{A}+B$ | $F=A \bar{B}$ MINUS 1 | $F=A \bar{B}$ |
| L L H H | $F=1$ | $F=$ MINUS 1 (2's COMP) | $F=Z E R O$ |
| L H L L | $F=\overline{A+B}$ | $F=A P L U S(A+\vec{B})$ | $F \therefore A$ PLUS $(A+\bar{B})$ PLUS 1 |
| L H L H | $F=\bar{B}$ | $F=A B P L U S(A+\bar{B})$ | $F=A B P L U S(A+\bar{B}) P$ LUS 1 |
| L H H L | $F=A \oplus B$ | $F=A$ MINUS B MINUS 1 | $F=A$ MINUS B |
| L H H H | $F=A+\bar{B}$ | $F=A+\bar{B}$ | $F=(A+\bar{B})$ PLUS 1 |
| H L L L | $F=\bar{A} 8$ | $F=A P L U S(A+B)$ | $F=A$ PLUS $(A+B)$ PLUS 1 |
| H L L H | $F=A \oplus B$ | $F=A$ PLUS B | $F=A$ PLUS B PLUS 1 |
| H L H L | $F=B$ | $F=A \bar{B} \operatorname{PLUS}(A+B)$ | $F=A \bar{B} P \operatorname{CUS}(A+B) P$ LUS 1 |
| H L H H | $F=A+B$ | $F=(A+B)$ | $F=\{A+B)$ PLUS 1 |
| H H L L | $F=0$ | $F=A$ PLUS $A^{\dagger}$ | $F=A P L U S A P L U S 1$ |
| H H L H | $F=A \bar{B}$ | $F=A B$ PLUS $A$ | $F=A B$ PLUS A PLUS 1 |
| H H H L | $F=A B$ | $F=A \bar{B} P L U S A$ | $F=A \bar{B} P L U S A P L U S 1$ |
| $\mathrm{H} \mathrm{H} \quad \mathrm{H} \quad \mathrm{H}$ | $F=A$ | $F=A$ | $F=A P L U S 1$ |

TABLE 2

| SELECTION | ACTIVE.HIGH DATA |  |  |
| :---: | :---: | :---: | :---: |
|  | $\mathrm{M}=\mathrm{H}$ | M = L: ARITHME | TIC OPERATIONS |
| S3 S2 S1 S0 | LOGIC FUNCTIONS | $\bar{C}_{n}=H$ <br> (no carry) | $\bar{C}_{n}=L$ <br> (with carry) |
| L L L L | $F=\bar{A}$ | $F=A$ | $F=A P L U S 1$ |
| L L L H | $F=\overline{A+B}$ | $F=A+B$ | $F=(A+B) P$ PLUS 1 |
| L L H L | $F=\bar{A} B$ | $F=A+\bar{B}$ | $F=(A+\bar{B})$ PLUS $i$ |
| L L H H | $F=0$ | $F=$ MINUS 1 (2's COMPL) | $F=Z E R O$ |
| L H L L | $F=\overline{A B}$ | $F=A P L U S A \bar{B}$ | $F=A P L U S A \bar{B} P$ PLUS 1 |
| L H L H | $F=\bar{B}$ | $F=(A+B) P L U S A \bar{B}$ | $F=(A+B) P L U S A \bar{B}$ PLUS 1 |
| L H H L | $F=A \oplus B$ | $F=A$ MINUS B MINUS 1 | $F=A$ MINUS $B$ |
| L H H H | $F=A \bar{B}$ | $F=A \bar{B}$ MINUS 1 | $F=A \bar{B}$ |
| H L L L | $F=\bar{A}+B$ | $F=A P L U S A B$ | $F=A$ PLUS AB PLUS ; |
| H L L H | $F=A \oplus B$ | $F=A P L U S B$ | $F=A$ PLUS B PLUS 1 |
| H L H L | $F=B$ | $F=(A+\bar{B})$ PLUS $A B$ | $F=(A+\bar{B})$ PLUS $A B$ PLUS 1 |
| H L H H | $F=A B$ | $F=A B$ MINUS 1 | $F=A B$ |
| H H L L | $F=1$ | $F=A P L U S A^{\dagger}$ | $F=A$ PLUS A PLUS 1 |
| H H L H | $F=A+\bar{B}$ | $F=(A+B) P L U S A$ | $F=(A+B)$ PLUS A PLUS 1 |
| H H H H | $F=A+B$ | $F=(A+\bar{B})$ PLUS $A$ | $F=(A+\bar{B})$ PLUS $A$ PLUS 1 |
| H H H H | $F=A$ | $F=A$ MINUS 1 | $F=A$ |

${ }^{\dagger}$ Each bit is shifted to the next more significant position.
logic diagram (positive logic)


Pin numbers shown are for DW, JT, JW, NT, and NW packages.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |
| :---: | :---: |
| Input voltage ........................................................................ . . . 7 V |  |
| Off-state output voltge ( $\mathrm{A}=\mathrm{B}$ output only) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |
| Operating free-air temperature range: SN54AS1181 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| SN74AS1181 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

|  |  |  | SN54AS1181 |  |  | SN74AS1181 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MiN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High-level output voltage | A = B output only |  |  | 5.5 |  |  | 5.5 | V |
| IOH | High-level output current | All outputs except $\mathrm{A}=\mathrm{B} \text { and } \overline{\mathrm{G}}$ |  |  | -2 |  |  | -2 | mA |
|  |  | $\overline{\mathrm{G}}$ output |  |  | -3 |  |  | -3 | mA |
| ${ }^{\text {IOL }}$ | Low-level output current | All outputs except $\overline{\mathrm{G}}$ |  |  | 20 |  |  | 20 | mA |
|  |  | $\overline{\mathrm{G}}$ output |  |  | 48 |  |  | 48 | mA |
| $T_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.
switching characteristics (see Note 1)

| PARAMETER. | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega, \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | SN54AS1181 |  | SN74AS1181 |  |  |
|  |  |  |  | MIN | MAX | M! ${ }^{\text {N }}$ | MAX |  |
| ${ }^{\text {tPLH }}$ | $C_{n}$ | $C_{n+4}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & \mathrm{~S} 0=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 3 | 9 | 3 | 8.5 | ns |
| tPHL |  |  |  | 2 | 7 | 2 | 6.5 |  |
| tPLH | $\begin{gathered} \text { Any } \\ \bar{A} \text { or } \bar{B} \end{gathered}$ | $C_{n+4}$ |  | 3.5 | 13 | 5 | 12 | ns |
| tPHL |  |  |  | 3.5 | 12.5 | 5 | 12 |  |
| ${ }^{\text {tPLH }}$ | $\begin{gathered} \text { Any } \\ \bar{A} \text { or } \bar{B} \end{gathered}$ | $C_{n+4}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{SO}=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V} \text { (DIFF } \text { mode }) \end{aligned}$ | 5 | 14.5 | 5 | 13 | ns |
| tPHL |  |  |  | 5 | 13.5 | 5 | 12.5 |  |
| tPLH | $\mathrm{C}_{n}$ | Any $\overline{\mathrm{F}}$ | $\mathrm{M}=0 \vee$ ( $\overline{\mathrm{SUM}}$ or $\overline{\mathrm{DFFF}}$ mode) | 3 | 10.5 | 3 | 9 | ns |
| tPHL |  |  |  | 3 | 8 | 3 | 7.5 |  |
| tPLH | $\overline{A n y} \bar{A}$ | $\overline{\mathrm{G}}$ | $\begin{aligned} & \hline M=0 \mathrm{~V}, \mathrm{~S} 1=S 2=0 \mathrm{~V}, \\ & S 0=S 3=4.5 \vee(\overline{S U M} \text { mode }) \end{aligned}$ | 3 | 8.5 | 3 | 8 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 2 | 7 | 2 | 6 |  |
| ${ }_{\text {tPLH }}$ | $\bar{A} \text { Any } \bar{B}$ | $\overline{\mathrm{G}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{SO}=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V} \text { (DIFF mode }) \end{aligned}$ | 3 | 10.5 | 3 | 9.5 | ns |
| ${ }_{\text {t }}$ PHL |  |  |  | 2 | 9 | 2 | 7 |  |
| tPLH | $\overline{A n y} \bar{A} \text { or } \bar{B}$ | $\overline{\mathrm{P}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & S 0=S 3=4.5 \vee(\overline{S U M} \text { mode }) \end{aligned}$ | 3 | 8.5 | 3 | 7.5 | ns |
| tPHL |  |  |  | 2 | 7.5 | 2 | 6 |  |
| tPLH | $\begin{gathered} \text { Any } \\ \bar{A} \text { or } \bar{B} \end{gathered}$ | $\overline{\mathrm{P}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 0=S 3=0 \mathrm{~V}, \\ & S 1=S 2=4.5 \mathrm{~V} \text { (DIFF } \text { mode }) \end{aligned}$ | 3 | 10.5 | 3 | 9 | ns |
| tPHL |  |  |  | 3 | 8.5 | 3 | 8 |  |
| tPLH | $\begin{gathered} \overline{\mathrm{A} i} \mathrm{or} \\ \overline{\mathrm{~B}} \mathrm{i} \end{gathered}$ | $\overline{\mathrm{F}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & \mathrm{~S} 0=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 3 | 11 | 3 | 9.5 | ns |
| tPHL |  |  |  | 3 | 9 | 3 | 7.5 |  |
| ${ }^{\text {tPLH }}$ | $\begin{gathered} \overline{\mathrm{A} i} \text { or } \\ \overline{\mathrm{Bi}} \\ \hline \end{gathered}$ | $\overline{\mathrm{Fi}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{SO}=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V}(\overline{\mathrm{DIFF}} \text { mode }) \end{aligned}$ | 3 | 12 | 3 | 10.5 | ns |
| tPHL |  |  |  | 3 | 11 | 3 | 9.5 |  |
| tPLH | $\overline{A n y} \bar{A} \text { or } \bar{B}$ | Any $\overline{\mathrm{F}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & S 0=S 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode }) \end{aligned}$ | 3 | 13.5 | 3 | 12 | ns |
| ${ }^{\text {t PHL }}$ |  |  |  | 3 | 13 | 3 | 11.5 |  |
| ${ }^{\text {t PLH }}$ | $\overline{A n y} \bar{A} \text { or } \bar{B}$ | Any $\overline{\mathrm{F}}$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{~S} 0=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V} \text { (DIFF mode) } \end{aligned}$ | 3 | 16 | 3 | 14.5 | ns |
| ${ }^{\text {tPHL }}$ |  |  |  | 3 | 13 | 3 | 12.5 |  |
| ${ }^{\text {P PLH }}$ | $\begin{gathered} \bar{A} i \text { or } \\ \bar{B} i \end{gathered}$ | $\overline{\mathrm{Fi}}$ | $\mathrm{M}=4.5 \mathrm{~V}$ (LOGIC mode) | 3 | 12.5 | 3 | 11 | ns |
| tPHL |  |  |  | 3 | 10 | 3 | 9.5 |  |
| tPLH | $\overline{A n y} \bar{A} \text { or } \bar{B}$ | $A=B$ | $\begin{aligned} & \mathrm{M}=0 \mathrm{~V}, \mathrm{SO}=\mathrm{S} 3=0 \mathrm{~V}, \\ & \mathrm{~S} 1=\mathrm{S} 2=4.5 \mathrm{~V} \text { (DIFF mode }) \end{aligned}$ | 4 | 19 | 4 | 17 | ns |
| tPHL |  |  |  | 5 | 18.5 | 5 | 15 |  |
| tPLH | Any S | Any $\bar{F}$ | $\mathrm{M}=0 \mathrm{~V}(\overline{\text { ARITH }}$ mode $)$ | 3 | 12.5 | 3 | 11 | ns |
| tPHL |  |  |  | 3 | 11.5 | 3 | 11 |  |
| ${ }^{\text {P PLH }}$ | Any S | $A=B$ | $\mathrm{M}=0 \mathrm{~V}$ ( $\overline{\text { ARITH }}$ mode) | 5 | 20 | 5 | 18 | ns |
| tPHL |  |  |  | 5 | 21 | 5 | 18 |  |
| tPLH | Any S | $c_{n+4}$ | $\mathrm{M}=4.5 \mathrm{~V}$ (LOGIC mode) | 2 | 16.5 | 4.5 | 15.5 | ns |
| ${ }_{\text {tPHL }}$ |  |  |  | 3 | 12.5 | 3 | 12 |  |
| tpLH | Any S | $\overline{\mathrm{G}}$ | $\mathrm{M}=0 \mathrm{~V}(\overline{\text { ARITH }}$ mode) | 3 | 9.5 | 3 | 9 | ns |
| ${ }_{\text {t PHL }}$ |  |  |  | 2 | 6.5 | 2 | 6 |  |
| ${ }_{\text {tPLH }}$ | Any S | $\overline{\text { P }}$ | $\mathrm{M}=4.5 \mathrm{~V}$ (LOGIC mode) | 3 | 8.5 | 3 | 7.5 | ns |
| ${ }_{\text {tPHL }}$ |  |  |  | 2 | 6.5 | 2 | 6.5 |  |
| tPLH | M | Any $\overline{\mathrm{F}}$ | $\begin{aligned} & \mathrm{S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & \mathrm{SO}=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\mathrm{SUM}} \text { mode) } \end{aligned}$ | 5 | 12 | 5 | 11.5 | ns |
| tPHL |  |  |  | 5 | 12 | 5 | 11.5 |  |
| ${ }_{\text {tPLH }}$ | M | $A=B$ | $\begin{aligned} & \mathrm{S} 1=\mathrm{S} 2=0 \mathrm{~V}, \\ & \mathrm{~S} 0=\mathrm{S} 3=4.5 \mathrm{~V}(\overline{\text { SUM }} \text { mode }) \end{aligned}$ | 7 | 19 | 7 | 17.5 | ns |
| tphL |  |  |  | 8 | 21 | 8 | 17.5 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## PARAMETER MEASUREMENT INFORMATION

SUM MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{SO}=\mathrm{S} 3=4.5 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=\mathrm{M}=0 \mathrm{~V}$

| PARAMETER | INPUT <br> UNDER <br> TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT <br> UNDER <br> TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND | APPLY $4.5 \mathrm{~V}$ | APPLY GND |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{Bi}}$ | None | Remaining $\bar{A}$ and $\bar{B}$ | $C_{n}$ | $\overline{\mathrm{Fi}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {t PL H }}$ | $\bar{B} i$ | $\overline{\mathrm{A}} \mathrm{i}$ | None | Remaining $\bar{A}$ and $\bar{B}$ | $\mathrm{C}_{n}$ | $\overline{\mathrm{Fi}}$ | In-Phase |
| ${ }_{\text {tPHL }}$ |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{A}} \mathrm{i}$ | $\overline{\mathrm{B}} \mathrm{i}$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\bar{P}$ | In-Phase |
| ${ }^{\text {tPHL}}$ |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{B}} \mathrm{i}$ | $\bar{A} i$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\bar{P}$ | In-Phase |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  |  |  |
| ${ }^{\text {PPLH }}$ | $\bar{A} i$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | Remaining $\stackrel{\rightharpoonup}{B}$ | Remaining $\bar{A}, C_{n}$ | $\overline{\mathrm{G}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{Bi}}$ | None | $\bar{A} i$ | Remaining $\bar{B}$ | Remaining $\bar{A}, C_{n}$ | - $\overline{\mathrm{G}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\mathrm{C}_{\mathrm{n}}$ | None | None | All | $\frac{\mathrm{All}}{\frac{1}{B}}$ | $\begin{aligned} & \text { Any } \bar{F} \\ & \text { or } C_{n}+4 \end{aligned}$ | In-Phase |
| ${ }^{\text {tPHL}}$ |  |  |  |  |  |  |  |
| ${ }^{\text {P PLH }}$ | $\bar{A} i$ | None | $\bar{B} i$ | Remaining $\bar{B}$ | $\begin{gathered} \text { Remaining } \\ \bar{A}, C_{n} \\ \hline \end{gathered}$ | $C_{n+4}$ | Out-of-Phase |
| ${ }^{\text {t PHL }}$ |  |  |  |  |  |  |  |
| ${ }^{\text {P PLH }}$ | $\overline{\mathrm{B}}$ | None | $\overline{\text { A }}$ | Remaining $\bar{B}$ | Remaining $\bar{A}, C_{n}$ | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | Any $\bar{A}$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | Remaining $\bar{B}, \bar{A} 3$ | Remaining $\bar{A}, C_{n}$ | Any $\bar{F}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | Any $\bar{B}$ | None | $\overline{\mathrm{A}}$ | $\begin{aligned} & \text { Remaining } \\ & \overline{\mathrm{A}}, \overline{\mathrm{~B}} 3 \end{aligned}$ | $\begin{gathered} \text { Remaining } \\ \bar{B}, C_{n} \\ \hline \end{gathered}$ | $\begin{gathered} \text { Any } \\ \bar{F} \end{gathered}$ | In-Phase |
| ${ }_{\text {t PHL }}$ |  |  |  |  |  |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## PARAMETER MEASUREMENT INFORMATION

DIFF MODE TEST TABLE
FUNCTION INPUTS: S1-S2=4.5V,SO=S3-M=0 V

| PARAMETER | INPUT UNDER TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT UNDER TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \hline \text { APPLY } \\ 4.5 \mathrm{~V} \end{gathered}$ | APPLY GND | $\begin{aligned} & \text { APPLY } \\ & 4.5 \mathrm{~V} \end{aligned}$ | APPLY GND |  |  |
| ${ }_{\text {tPLH }}$ | $\bar{A} i$ | None | $\bar{B} \mathrm{i}$ | $\begin{gathered} \text { Remaining } \\ \bar{A} \end{gathered}$ | Remaining $\bar{B}, C_{n}$ | $\overline{F i}$ | In-Phase |
| ${ }^{\text {t }}$ PHL |  |  |  |  |  |  |  |
| ${ }_{\text {tPLH }}$ | $\overline{\mathrm{B}}$ | $\overline{\text { A }}$ | None | $\begin{gathered} \text { Remaining } \\ \bar{A} \end{gathered}$ | Remaining $\bar{B}, C_{n}$ | $\overline{\mathrm{Fi}}$ | Out-of-Phase |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{A} i$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | None | $\begin{aligned} & \text { Remaining } \\ & \bar{A} \text { and } \bar{B}, C_{n} \end{aligned}$ | $\overline{\mathrm{P}}$ | In-Phase |
| tpHL |  |  |  |  |  |  |  |
| tPLH | $\bar{B} i$ | $\bar{A} i$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{P}}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{B}}$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{G}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{Bi}}$ | None | $\bar{A} i$ | None | $\begin{gathered} \text { Remaining } \\ \bar{A} \text { and } \bar{B}, C_{n} \end{gathered}$ | $\overline{\mathrm{G}}$ | Out-of-Phase |
| tphL |  |  |  |  |  |  |  |
| ${ }_{\text {tPLH }}$ | $\bar{A} i$ | None | $\overline{\mathrm{B}} \mathrm{i}$ | $\begin{gathered} \text { Remaining } \\ \bar{A} \end{gathered}$ | $\begin{gathered} \text { Remaining } \\ \bar{B}, C_{n} \end{gathered}$ | $A=B$ | In-Phase |
| ${ }^{\text {t PHL }}$ |  |  |  |  |  |  |  |
| tPLH | $\overline{\mathrm{B}}$ | $\bar{A} i$ | None | $\begin{gathered} \text { Remaining } \\ \bar{A} \end{gathered}$ | $\begin{aligned} & \text { Remaining } \\ & \bar{B}, C_{n} \end{aligned}$ | $A=B$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\mathrm{C}_{n}$ | None | None | $\stackrel{\mathrm{All}}{\overline{\mathrm{~A}} \text { and } \overline{\mathrm{B}}}$ | None | $\begin{gathered} C_{n}+4 \\ \text { or any } \bar{F} \end{gathered}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{Bi}}$ | None | None | Remaining $\bar{A}, \bar{B}, C_{n}$ | $c_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLLH }}$ | $\bar{B} i$ | None | $\overline{\text { A }}$ | None | Remaining$\overline{\mathrm{A}}, \overline{\mathrm{~B}}, \mathrm{C}_{\mathrm{n}}$ | $C_{n+4}$ | In-Phase |
| tpHL |  |  |  |  |  |  |  |
| tPLH | $\begin{aligned} & \text { Any } \\ & \bar{A} \end{aligned}$ | $\bar{B} i$ | None | $\overline{\text { A }}$ | $\begin{aligned} & \hline \text { Remaining } \\ & \overline{\mathrm{A}}, \overline{\mathrm{~B}}, \mathrm{C}_{\mathrm{n}} \end{aligned}$ | $\begin{aligned} & \overline{A n y} \\ & \bar{F} \end{aligned}$ | In-Phase |
| tphL |  |  |  |  |  |  |  |
| tPLH | $\begin{gathered} \text { Any } \\ \bar{B} \end{gathered}$ | None | $\bar{A} i$ | A] | Remaining $\bar{A}, \bar{B}, C_{n}$ | $\begin{gathered} \overline{\text { Any }} \\ \bar{F} \end{gathered}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## SN54AS1181, SN74AS1181 ARITHMETIC LOGIC UNITS|FUNCTION GENERATORS

## PARAMETER MEASUREMENT INFORMATION

LOGIC MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{S} 1=\mathrm{S} 2=\mathrm{M}=4.5 \mathrm{~V}, \mathrm{SO}=\mathrm{S} 3=0 \mathrm{~V}$

| PARAMETER | INPUT <br> UNDER <br> TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT <br> UNDER <br> TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \text { APPLY } \\ 4.5 \mathrm{~V} \end{gathered}$ | APPLY GND | $\begin{aligned} & \text { APPLY } \\ & 4.5 \mathrm{~V} \end{aligned}$ | APPLY GND |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{A}} \mathbf{i}$ | $\bar{B}$ | None | None | Remaining | $\overrightarrow{F i}$ | Out-of-Phase |
| tPHL |  |  |  |  | A and $\overline{\mathrm{B}}, \mathrm{C}_{n}$ |  |  |
| $t_{\text {PLH }}$ | $\overline{\mathrm{Bi}}$ | $\vec{A} i$ | None | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{Fi}}$ | Out-ot-Phase |
| tPHL |  |  |  |  |  |  |  |

INPUT BITS EQUAL/NOT EQUAL TEST TABLE
FUNCTION INPUTS: $S 0=S 3=M=4.5 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}$

| PARAMETER | INPUT <br> UNDER <br> TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT <br> UNDER <br> TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{B}} \mathrm{i}$ | None | Remaining $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ | None | $\overline{\mathrm{P}}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\overrightarrow{B i}$ | $\bar{A} i$ | None | Remaining $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ | None | $\overline{\mathbf{P}}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{A} i$ | None | $\overline{\mathrm{Bi}}$ | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $\overline{\mathrm{P}}$ | In-Phase |
| ${ }_{\text {PHL }}$ |  |  |  |  |  |  |  |
| tPLH | $\bar{B} i$ | None | $\bar{A} i$ | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $\overline{\mathbf{P}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\bar{A} i$ | $\overline{\mathrm{Bi}}$ | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $C_{n+4}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\overrightarrow{B i}$ | $\bar{A} i$ | None | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $C_{n+4}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{A}}$ | None | $\overline{B i}$ | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\bar{B} i$ | None | $\overline{\mathrm{A}}$ | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | None | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |

INPUT PAIRS HIGH/NOT HIGH TEST TABLE
FUNCTION INPUTS: $\mathrm{S} 2=\mathrm{M}=\mathbf{4 . 5} \mathrm{V}, \mathrm{SO}=\mathrm{S} 1=\mathrm{S} 3=\mathrm{OV}$

| PARAMETER | INPUT <br> UNDER TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT <br> UNDER TEST | output WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND | APPLY <br> 4.5 V | APPLY <br> GND |  |  |
| ${ }^{\text {P PLH }}$ | $\bar{A} i$ | $\bar{B} i$ | None | Remaining $\bar{A}, C_{n}$ | Remaining $\bar{B}$ | ¢ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | $\overline{\mathrm{B}}$ | $\bar{A} i$ | None | Remaining $\bar{B}, C_{n}$ | $\begin{gathered} \text { Remaining } \\ \bar{A} \end{gathered}$ | $\overline{\mathrm{P}}$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| tPLH | $\overline{\mathrm{A}} \mathrm{i}$ | $\overline{\mathrm{B}} \mathrm{i}$ | None | Remaining $\bar{A}, C_{n}$ | Remaining $\bar{B}$ | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |
| ${ }_{\text {t PLH }}$ | $\bar{B} i$ | $\bar{A} i$ | None | Remaining $\bar{B}, C_{n}$ | Remaining $\bar{A}$ | $C_{n+4}$ | Out-of-Phase |
| tPHL |  |  |  |  |  |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

## PARAMETER MEASUREMENT INFORMATION

SELECT INPUT/LOGIC MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{M}=4.5 \mathrm{~V}$

| PARAMETER | INPUT <br> UNDER TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT <br> UNDER <br> TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY $4.5 \mathrm{~V}$ | APPLY GND | APPLY $4.5 \mathrm{~V}$ | APPLY GND |  |  |
| tPLH | Any S | - | - | Remaining $\bar{B}$ | $\bar{A}, \bar{B} O, C_{n}$ | $C_{n+4}$ | Out-of-Phase |
| ${ }^{\text {t }} \mathrm{PHL}$ |  |  |  |  |  |  |  |
| ${ }_{\text {t PLH }}$ | Any S | - | - | $\bar{B}, \overline{\mathrm{~A}} 2$ | $\begin{aligned} & \text { Remaining } \\ & \bar{A}, C_{n} \end{aligned}$ | $\bar{P}$ | In-Phase |
| ${ }^{\text {tPHL}}$ |  |  |  |  |  |  |  |

SELECT INPUT/ARITH MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{M}=0 \mathrm{~V}$

| PARAMETER | INPUT <br> UNDER <br> TEST | OTHER INPUT SAME BIT |  | OTHER.DATA INPUTS |  | OUTPUT <br> UNDER <br> TEST | OUTPUT <br> WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND | APPLY $4.5 \mathrm{~V}$ | APPLY <br> GND |  |  |
| $t_{\text {PLH }}$ | Any S | $-$ | - | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{A}} \mathrm{O}, \overline{\mathrm{B}} \mathrm{O}$ | $\frac{\text { Any }}{\text { F }}$ | In-Phase |
| ${ }^{\text {P PHL }}$ |  |  |  |  |  |  |  |
| ${ }_{\text {PLLH }}$ | Any S | -- | - | Remaining $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}, \mathrm{C}_{\mathrm{n}}$ | $\overline{\mathrm{A}} \mathrm{O}, \overline{\mathrm{B}} 0$ | $A=B$ | In-Phase |
| tPHL |  |  |  |  |  |  |  |
| $\mathbf{t P L H}$ | Any <br> S | - | - | Remaining $\bar{A}$ and $\bar{B}, C_{n}$ | $\overline{\mathrm{A}} \mathrm{O}, \overline{\mathrm{B}} \mathrm{O}$ | $\overline{\mathrm{G}}$ | In-Phase |
| ${ }_{\text {tPHL }}$ |  |  |  |  |  |  |  |

MODE INPUT/SUM MODE TEST TABLE
FUNCTION INPUTS: $\mathrm{S} 0=\mathrm{S} 3=4.5 \mathrm{~V}, \mathrm{~S} 1=\mathrm{S} 2=0 \mathrm{~V}$

| PARAMETER | INPUT UNDER TEST | OTHER INPUT SAME BIT |  | OTHER DATA INPUTS |  | OUTPUT UNDER TEST | OUTPUT WAVEFORM (SEE NOTE 1) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \text { APPLY } \\ 4.5 \mathrm{~V} \end{gathered}$ | $\begin{aligned} & \text { APPLY } \\ & \text { GND } \end{aligned}$ | $\begin{gathered} \text { APPLY } \\ 4.5 \mathrm{~V} \end{gathered}$ | $\begin{aligned} & \text { APPLY } \\ & \text { GND } \end{aligned}$ |  |  |
| ${ }^{\text {tPLH }}$ | M | - | - | Remaining $\bar{A}$ and $\bar{B}$ | $\bar{B} 2, \bar{A} 2, C_{n}$ | $\overline{\mathrm{Any}} \overline{\mathrm{~F}}$ | In-Phase |
| ${ }^{\text {t PHL }}$ |  |  |  |  |  |  |  |
| ${ }^{\text {tPLH }}$ | M | - | - | $\begin{aligned} & \text { Remaining } \\ & \bar{A} \text { and } \bar{B} \end{aligned}$ | $\overline{\mathrm{B}} 1, \overline{\mathrm{~A}} 1, \mathrm{C}_{\mathrm{n}}$ | $A=B$ | In-Phase |
| ${ }^{\text {t PHL }}$ |  |  |  |  |  |  |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- Provides Control for 16K, 64K, and 256K Dynamic RAMs
- Highest-Order Two-Address Bits Select One of Four Banks of RAMs
- Supports Scrubbing Operations and NibbleMode Access
- Separate Output Enable for Multi-Channel Access to Memory
- 48-Pin Dual-In-Line Package
- 'ALS2968 is Designed to be Interchangeable with AMD AM2968


## description

The 'ALS2967 and 'ALS2968 dynamic memory controllers (DMCs) are designed for use in today's high-performance memory systems. The DMC acts as the address controller between any processor and dynamic memory array.
Two versions are provided that help simplify interfacing to the system dynamic timing controller. The 'ALS2967 offers active-low Row Address Strobe Input ( $\overline{\text { RASI }) ~ a n d ~ C o l u m n ~}$ Address Strobe Input ( $\overline{\mathrm{CASI}}$ ), while the 'ALS2968 offers active-high Row Address Strobe Input (RASI) and Column Address Strobe Input (CASI) inputs.
Using two 9-bit address latches, the DMC will hold the row and column addresses for any DRAM up to 256 K . These latches and the two row/column refresh address counters feed into a 9-bit, 4-input MUX for output to the dynamic RAM address lines. A 2-bit bank select latch is provided to select one of the four $\overline{\mathrm{RAS}}$ and $\overline{\mathrm{CAS}}$ outputs. The two bits are normally obtained from the two highest-order address bits.

SN54ALS2967, SN54ALS2968 . . . JD PACKAGE
SN74ALS2967, SN74ALS2968 . . JD OR N PACKAGE
(TOP VIEW)

| $\overline{\mathrm{CS}}$ | 1 | $\bigcirc_{48}$ | ] $\overline{\text { CASI }}$ or CASI ${ }^{\dagger}$ |
| :---: | :---: | :---: | :---: |
| MSEL | 2 | 47 | $\square \overline{\mathrm{RASO}}$ |
| AO | 3 | 46 | $\square$ CAS0 |
| A9 | 4 | 45 | $\square \overline{\mathrm{RAS}} 1$ |
| A1 | 5 | 44 | $\square \overline{\mathrm{CAS}} 1$ |
| A10 | 6 | 43 | $\square 00$ |
| A2 | 7 | 42 | Q Q1 |
| A11 | 8 | 41 | $\bigcirc{ }^{\square}$ |
| A3 | 9 | 40 | Q3 |
| A12 | 10 | 39 | Q4 |
| A4 | 11 | 38 | 7 GND |
| A13 | 12 | 37 | $\square \overline{O E}$ |
| GND | 13 | 36 | $\mathrm{V}_{\mathrm{CC}}$ |
| le $\square^{\square}$ | 14 | 35 | $\bigcirc 05$ |
| A5 | 15 | 34 | $\square 06$ |
| A14 | 16 | 33 | $\square 07$ |
| A6 | 17 | 32 | - 08 |
| A15 | 18 | 31 | $\overline{\mathrm{RAS}} 2$ |
| A7 | 19 | 30 | $\square \overline{C A S} 2$ |
| A16 | 20 | 29 | $\square \overline{\mathrm{RAS}}$ |
| A8 | 21 | 28 | $\square \overline{\mathrm{CAS}} 3$ |
| A17 | 22 | 27 | $\square \overline{\text { RASI }}$ or RASI ${ }^{\dagger}$ |
| SELO | 23 | 26 | $\square \mathrm{Mco}$ |
| SEL1 | 24 | 25 | M MC1 |

†'ALS2967 has active-low inputs CASI and $\overline{\text { RASI; 'ALS2968 has }}$ active-high inputs CASI and RASI.

The 'ALS2967 and 'ALS2968 have two basic modes of operation, read/write and refresh. During normal read/write operations, the row and column addresses are multiplexed to the dynamic RAM, with the corresponding $\overline{\mathrm{RAS}}$ and $\overline{\mathrm{CAS}}$ signals activated to strobe the addresses into the RAM. In the refresh mode, the two counters cycle through the refresh addresses. If memory scrubbing is not being implemented, only the row counter is used. When memory scrubbing is being performed, both the row and column counters are used to perform read-modify-write cycles. In this mode all $\overline{R A S}$ outputs will be active (low) while only one CAS output is active at a time.

The SN54ALS2967 and SN54ALS2968 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS2967 and SN74ALS2968 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
logic symbols ${ }^{\dagger}$

2
$\Gamma$
$\infty$
0
$\infty$
$\vdots$
$\vdots$
0
$\infty$

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
logic diagram (positive logic)


## table 1. PIN FUNCTION



TABLE 2. MODE-CONTROL FUNCTION TABLE

| MC1 | MCO | OPERATING MODE |
| :---: | :---: | :---: |
| L | L | Refresh Mode without Scrubbing. Refresh cycles are performed with only the row counter being used to generate the addresses. In this mode, all four $\overline{\text { RAS }}$ outputs are active while the four $\overline{\mathrm{CAS}}$ outputs remain high. |
| L | H | Refresh with Scrubbing/Initialize. During this mode, refresh cycles are done with both the row and column counters generating the addresses. MSEL is used to select either the row or the column counter. All four $\overline{\operatorname{RAS}}$ outputs go low in response to $\overline{\operatorname{RASI}}(' A L S 2967$ ) or RASI ('ALS2968), while only one $\overline{\mathrm{CAS}}$ n output goes low in response to $\overline{\mathrm{CASI}}$ ('ALS2967) or CASI ('ALS2968). The bank counter keeps track of which $\overline{C A S}$ output goes active. This mode can also be used during system power-up so that the memory can be written with a known data pattern. |
| H | L | Read/Write. This mode is used to perform read/write cycles. Both the Row and Column addresses are multiplexed to the address output lines using MSEL. SELO and SEL1 are decoded to determine which $\overline{\operatorname{RAS}} \mathrm{n}$ and $\overline{\mathrm{CAS}} \mathrm{n}$ outputs will be active. |
| H | H | Clear Refresh Counters. This mode clears the three refresh counters (row, column, and bank) on the inactive transition of $\overline{R A S I}$ ('ALS2967) or RASI ('ALS2968), putting them at start of the refresh sequence (see timing diagrams for more detail). In this mode, all four $\overline{\operatorname{RAS}}$ outputs are driven low after the active edge of $\overline{\mathrm{RASI}}$ ('ALS2967) or RASI ('ALS2968) so that DRAM wake-up cycles may also be performed. |

## SN54ALS2967, SN74ALS2967, SN54ALS2968, SN74ALS2968 DYNAMIC MEMORY CONTROLLERS

TABLE 3. ADDRESS OUTPUT FUNCTIONS

| MODE | INPUTS |  |  |  | OUTPUTS Q0-08 |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MC1 | MCO | MSEL | $\overline{\mathrm{CS}}$ |  |
| Refresh without scrubbing | L | L | X | X | Row counter address |
| Refresh with scrubbing | L | H | L | X | Row counter address |
|  |  |  | H | X | Column counter address |
| Read/write | H | L | L | L | Row address ${ }^{\dagger}$ |
|  |  |  | H | L | Column address ${ }^{\dagger}$ |
|  |  |  | X | H | All L |
| Clear refresh counter ${ }^{\ddagger}$ | H | H | X | X | All L |

TABLE 4. RAS OUTPUT FUNCTIONS

| INPUTS |  |  |  |  |  | OUTPUTS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{array}{cc}\text { 'ALS2967 } \\ \text { 'ALS2968 } \\ \text { RASI } & \text { RASI }\end{array}$ | MC1 | MCO | SEL1 ${ }^{\dagger}$ | SELO ${ }^{\dagger}$ | $\overline{\text { CS }}$ | $\overline{\text { RAS }} 0$ | $\overline{\text { RAS } 1}$ | $\overline{\text { RAS } 2}$ | $\overline{\mathrm{RAS}} 3$ |
| L H | $L$ | L | X | $X$ | X | L | L | L | $L$ |
| $\mathrm{L} \quad \mathrm{H}$ | L | H | X | X | X | L | L | L | L |
|  |  |  | L | L | L | L | H | H | H |
|  |  |  | L | H | L | H | L | H | H |
| L H | H | L | H | L | L | H | H | L | H |
|  |  |  | H | H | 1 | H | H | H | L |
|  |  |  | X | X | H | H | H | H | H |
| L H | H | H | X | X | X | L | L | L | L |
| H L | X | X | X | X | X | H | H | H | H |

TABLE 5. CAS OUTPUT FUNCTIONS

| INPUTS |  |  |  |  |  |  |  |  | OUTPUTS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 'ALS2967 'ALS2968 <br> $\overline{\text { CASI }}$ CASI |  | MC1 | MCO | SEL1 ${ }^{\dagger}$ SELO ${ }^{\dagger}$ |  | INTERNAL |  | $\overline{\text { CS }}$ | $\overline{\text { CASO }}$ | $\overline{\text { CAS }} 1$ | $\overline{\text { CAS } 2}$ | $\overline{\text { CAS }} 3$ |
|  |  | BC1 |  |  |  | BCO |  |  |  |  |  |
| L | H |  | L | L | X | X | X | X | X | H | H | H | H |
| L | H | L | H | X | X | L | L | X | L | H | H | H |
|  |  |  |  |  |  | L | H | X | H | L | H | H |
|  |  |  |  |  |  | H | L | X | H | H | L | H |
|  |  |  |  |  |  | H | H | X | H | H | H | L |
| L | H | H | L | L | L | X | X | L | L | H | H | H |
|  |  |  |  | L | H | X | X | L | H | L | H | H |
|  |  |  |  | H | L | X | X | L | H | H | L | H |
|  |  |  |  | H | H | X | X | L | H | H | H | L |
|  |  |  |  | X | X | X | X | H | H | H | H | H |
| L | H | H | H | X | X | X | X | X | H | H | H | H |
| H | L | X | X | X | X | X | X | $\times$ | H | H | H | H |

$\dagger$ If LE is low, outputs will be the levels entered when LE was last high. If LE is high, outputs will follow address inputs as selected by MSEL.
$\ddagger$ For 'ALS2967, clearing occurs on the low-to-high transition of RASI; for 'ALS2968, clearing occurs on the high-to-low transition of RASI.
read/write operation details
During normal read/write operations, the row and column addresses are multiplexed to the dynamic RAM controlled by the MSEL input. The corresponding $\overline{\operatorname{RAS}} n$ and $\overline{\mathrm{CAS}} n$ output signals strobe the addresses into memory. The block diagram in Figure 1 shows a typical system interface for a one-megaword dynamic memory. The DMC is used to control the four banks of 256 K memory.

For systems where addresses and data are multiplexed onto a single bus, the DMC uses latches, (row, column, and bank) to hold the address information. Figure 5 shows a typical timing diagram using the input latches. The twenty input latches are transparent when latch enable (LE) is high, and latch the input data whenever LE is taken low. For systems in which the processor has separate address and data buses, LE may be permanently high (see timing diagram in Figure 4).


FIGURE 1. 1-MEGAWORD X 16-BIT DYNAMIC MEMORY

## SN54ALS2967, SN74ALS2967, SN54ALS2968, SN74ALS2968 DYNAMIC MEMORY CONTROLLERS

## read/write operations (continued)

The DMC is designed with heavy-duty outputs that are capable of driving four banks of 16-bit words, including six checkbits used for error detection and correction.

In addition to heavy-duty output drivers, the outputs are designed with balanced output impedances (25 $\Omega$ both high and low). This feature optimizes the drive low characteristics, based on safe undershoot, while providing symmetrical drive high characteristics. It also eliminates the external resistors required to pull the outputs up to the MOS $\mathrm{V}_{\mathrm{OH}}$ level (VCC -1.5 V ).


FIGURE 2. 1-MEGAWORD X 16-BIT DYNAMIC MEMORY WITH ERROR DETECTION AND CORRECTION

## memory expansion

With a 9-bit address path, the DMC can control up to one megaword when using 256 K dynamic RAMs. If a larger memory size is desired, the DMC's chip select ( $\overline{\mathrm{CS}}$ ) makes it easy to expand the memory size by using additional DMCs. A four-megaword memory system is shown in Figure 3.

To maintain maximum performance in 32-bit applications, it is recommended that individual bus drivers be used for each bank.


FIGURE 3. 4-MEGAWORD X 16-BIT DYNAMIC MEMORY

## SN54ALS2967, SN74ALS2967, SN54ALS2968, SN74ALS2968 DYNAMIC MEMORY CONTROLLERS

## refresh operations

The two 9 -bit counters in the 'ALS2967 and 'ALS2968 support 128-, 256-, and 512 -line refresh operations. Transparent, burst, synchronous, or asynchronous refresh modes are all possible. The refresh counters are advanced on the low-to-high transition of RASI on the 'ALS2967, and on the high-to-low transition of RASI on the 'ALS2968. The refresh counters are reset to zero on the low-to-high transition of RASI on the 'ALS2967, and on the high-to-low transition of RASI on the 'ALS2968, if MC1 and MCO are at a low logic level. See Figure 8 for additional timing details.

When performing refresh cycles without memory scrubbing (MC1 and MCO both low), all four $\overline{\text { RAS }}$ outputs go low, while all $\overline{C A S}$ outputs are driven high. Typical timing for this mode of operation is shown in Figure 6.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V |  |  |
| :---: | :---: | :---: |
| Input voltage ..................................................................................... 7 V |  |  |
| Voltage applied to disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V |  |  |
| Operating free-air temperature range | SN54ALS2967, SN54ALS2968 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74ALS2967, SN74ALS2968 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54ALS2967 SN54ALS2968 |  |  | SN74ALS2967 <br> SN74ALS2968 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $1 /=-18 \mathrm{~mA}$ |  |  | -1.5 |  |  | -1.5 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-1 \mathrm{~mA}$ | 2.4 | 3.3 |  |  |  |  | V |
|  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$. | $\mathrm{I}_{\mathrm{OL}}=1 \mathrm{~mA}$ |  | 0.15 | 0.5 |  | 0.15 | 0.5 | V |
|  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=12 \mathrm{~mA}$ |  | 0.35 | 0.8 |  | 0.35 | 0.8 |  |
| $\mathrm{IOL}^{\ddagger}$ | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2 \mathrm{~V}$ | 30 |  |  | 30 |  |  | mA |
| IOZH | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| 1 | $\mathrm{V}_{\text {cc }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| 1 IH | $V_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IL | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $10^{5}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 |  | -112 | $-30$ |  | -112 | mA |
| ICC | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  |  |  |  |  |  |  | mA |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
$\ddagger$ Not more than one output should be tested at a time, and duration should not exceed 1 second.
§ The output conditions have been chosen to produce a current that closely approximates one half the true short-circuit output current, IOS.
'ALS2967 switching characteristics, $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEST CONDITIONS ${ }^{\dagger}$ | SN54ALS2967 |  |  | SN74ALS2967 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP $\ddagger$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathbf{t}_{\mathrm{pd}}(1)$ | $\overline{\text { RASI }}$ | Any Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ | 12 |  |  |  | 12 | . | ns |
| $t_{\text {pd(2) }}$ | RASI | $\overline{\text { RAS }}$ |  | 10 |  |  |  | 10 |  | ns |
| ${ }^{\text {t }} \mathrm{pd}(3)$ | $\overline{\text { CASI }}$ | CASn |  | 8 |  |  |  | 8 |  | ns |
| ${ }^{\text {t }}$ pd(4) | Any A | Any 0 |  | 22 |  |  |  | 22 |  | ns |
| ${ }^{t} \mathrm{pd}(5)$ | MSEL | Any Q |  | 14 |  |  |  | 14 |  | ns |
| $t_{\text {pd (6) }}$ | LE $\uparrow$ | Any Q |  | 15 |  |  |  | 15 |  | ns |
| $t_{\text {pd }}(7)$ | LE $\uparrow$ | Any RAS |  | 15 |  |  |  | 15 |  | ns |
| $t_{p d}(8)$ | LET | Any CAS |  | 14 |  |  |  | 14 |  | ns |
| ${ }^{1} \mathrm{pd}$ (9) | MCO or MC1 | Any 0 |  | 15 |  |  |  | 15 |  | ns |
| $t_{\text {pd }}(10)$ | MCO or MC1 | Any RAS |  | 14 |  |  |  | 14 |  | ns |
| $t_{\text {pd(11) }}$ | MCO or MC1 | Any CAS |  | 12 |  |  |  | 12 |  | ns |
| $t_{\text {pd(12) }}$ | $\overline{\mathrm{CS}}$ | Any Q |  | 16 |  |  |  | 16 |  | ns |
| $t_{\text {pd(13) }}$ | $\overline{\mathrm{CS}}$ | Any $\overline{\mathrm{RAS}}$ |  | 12 |  |  |  | 12 |  | ns |
| $t_{p d}(14)$ | $\overline{\mathrm{CS}}$ | Any CAS |  | 11 |  |  |  | 11 |  | ns |
| $t_{\text {pd(15) }}$ | SELO or SEL1 | Any RAS |  | 12 |  |  |  | 12 |  | ns |
| $t_{\text {pd(16) }}$ | SELO or SEL1 | Any CAS |  | 11 |  |  |  | 11 |  | ns |
| $t_{\text {en (17) }}$ | $\overline{\text { OE } \downarrow ~}$ | Any Q |  | 14 |  |  |  | 14 |  | ns |
| $t_{\text {en(18) }}$ | $\overline{\mathrm{OE}} \downarrow$ | Any $\overline{\mathrm{R} A}{ }^{\text {S }}$ |  | 13 |  |  |  | 13 |  | ns |
| $t_{\text {en(19) }}$ | $\overline{O E} \downarrow$ | Any $\overline{C A S}$ |  | 13 |  |  |  | 13 |  | ns |
| $\mathrm{t}_{\mathrm{dis}}(20)$ | $\overline{O E} \uparrow$ | Any 0 |  | 15 |  |  |  | 15 |  | ns |
| $\mathrm{t}_{\text {dis }}(21)$ | $\overline{\mathrm{OE}} \uparrow$ | Any $\overline{\mathrm{RAS}}$ |  | 13 |  |  |  | 13 |  | ns |
| $\mathrm{t}_{\text {dis(22) }}$ | $\overline{\mathrm{OE}} \uparrow$ | Any CAS |  | 13 |  |  |  | 13 |  | ns |

'ALS2967 switching characteristics, $\mathrm{C}_{\mathrm{L}}=150 \mathrm{pF}$

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEST CONDITIONS ${ }^{\dagger}$ | SN54ALS2967 |  |  | SN74ALS2967 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{t}_{\mathrm{pd}}(1)$ | $\overline{\text { RASI }}$ | Any Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{A}}=\operatorname{MIN} \text { to } \mathrm{MAX} \end{aligned}$ | . | 17 |  |  | 17 |  | ns |
| $t_{\text {pd(2) }}$ | हैASI | $\overline{\text { RAS }}$ |  |  | 15 |  |  | 15 |  | ns |
| $t_{\text {pd }}(3)$ | CASI | CASn |  |  | 14 |  |  | 14 |  | ns |
| ${ }^{\mathrm{t} p d}$ (4) | Any A | Any 0 |  |  | 27 |  |  | 27 |  | ns |
| ${ }^{\text {tpd }}$ (5) | MSEL | Any 0 |  |  | 19 |  |  | 19 |  | ns |
| ${ }^{\text {p }}$ d $(6)$ | LET | Any Q |  |  | 20 |  |  | 20 |  | ns |
| $t_{\text {pd }}(7)$ | LE $\uparrow$ | Any RAS |  |  | 20 |  |  | 20 |  | ns |
| $t_{\text {pd }}(8)$ | LEt | Any $\overline{\text { CAS }}$ |  |  | 19 |  |  | 19 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(9)$ | MC0 or MC1 | Any 0 |  |  | 20 |  |  | 20 |  | ns |
| $t \mathrm{pd}(10)$ | MC0 or MC1 | Any RAS |  |  | 19 |  |  | 19 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(11)$ | MCO or MC1 | Any $\overline{\text { CAS }}$ |  |  | 17 |  |  | 17 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(12)$ | $\overline{\text { CS }}$ | - Any 0 |  |  | 19 |  |  | 19 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(13)$ | $\overline{\text { CS }}$ | Any $\overline{\text { RAS }}$ |  |  | 14 |  |  | 14 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(14)$ | $\overline{\mathrm{CS}}$ | Any CAS |  |  | 14 |  |  | 14 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(15)$ | SELO or SEL1 | Any $\overline{\text { RAS }}$ |  |  | 15 |  |  | 15 |  | ns |
| $\mathrm{t}_{\mathrm{pd}}(16)$ | SELO or SEL1 | Any CAS |  |  | 14 |  |  | 14 |  | ns |

t See Figures 10, 11, 12, and 13 for test circuit and switching waveforms.
$\ddagger$ All typical values at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

## SN54ALS2968, SN74ALS2968 DYNAMIC MEMORY CONTROLLERS

'ALS2968 switching characteristics, $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEST CONDITIONS ${ }^{\dagger}$ | SN54ALS2968 |  |  | SN74ALS2968 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| ${ }^{t} \mathrm{pd}(1)$ | RASI | Any 0 | $\begin{aligned} & \mathrm{V}_{C C}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=\mathrm{MIN} \text { to MAX } \end{aligned}$ | 5 | 12 | 20 | 5 | 12 | 20 | ns |
| $t_{p d}(2)$ | RASI | $\overline{\text { RAS }}$ |  | 3 | 10 | 18 | 3 | 10 | 18 | ns |
| $t_{\text {pd }}(3)$ | CASI | CASn |  | 3 | 8 | 17 | 3 | 8 | 17 | ns |
| $t_{p d}(4)$ | Any A | Any 0 |  | 5 | 22 | 30 | 5 | 22 | 30 | ns |
| $t_{\text {pd(5) }}$ | MSEL | Any 0 |  | 3 | 14 | 20 | 3 | 14 | 20 | ns |
| $t_{\text {pd }}(6)$ | LEt | Any 0 |  |  | 15 | 25 |  | 15 | 25 | ns |
| $t_{\text {pd }}(7)$ | LEt | Any $\overline{\text { RAS }}$ |  |  | 15 | 25 |  | 15 | 25 | ns |
| $t_{\text {pd }}(8)$ | LET | Any $\overline{\mathrm{CAS}}$ |  |  | 14 | 24 |  | 14 | 24 | ns |
| $t_{\text {pd (9) }}$ | MCO or MC1 | Any Q |  | 5 | 15 | 25 | 5 | 15 | 25 | ns |
| $\mathrm{t}_{\mathrm{pd}}(10)$ | MCO or MC1 | Any $\overline{\mathrm{RAS}}$ |  | 3 | 14 | 21 | 3 | 14 | 21 | ns |
| $t_{p d(11)}$ | MCO or MC1 | Any $\overline{\mathrm{CAS}}$ |  | 3 | 12 | 19 | 3 | 12 | 19 | ns |
| $t_{\text {pd(12) }}$ | $\overline{\mathrm{CS}}$ | Any Q |  |  | 16 | 23 |  | 16 | 23 | ns |
| $t_{\text {pd(13) }}$ | CS | Any $\overline{\mathrm{RAS}}$ |  |  | 12 | 20 |  | 12 | 20 | ns |
| $t_{\text {pd }}(14)$ | $\overline{\mathrm{CS}}$ | Any CAS |  |  | 11 | 19 |  | 11 | 19 | ns |
| $t_{\text {pd }}(15)$ | SELO or SEL1 | Any $\overline{\text { RAS }}$ |  |  | 12 | 20 |  | 12 | 20 | ns |
| $t_{\text {pd( }}$ (16) | SELO or SEL1 | Any CAS |  |  | 11 | 18 |  | 11 | 18 | ns |
| $t_{\text {en }}(17)$ | OE $\downarrow$ | Any 0 |  |  | 14 | 21 |  | 14 | 21 | ns |
| $t_{e n(18)}$ | $\overline{\mathrm{OE}} \downarrow$ | Any $\overline{\text { RAS }}$ |  |  | 13 | 19 |  | 13 | 19 | ns |
| $t_{\text {en( }}$ (19) | $\overline{O E} \downarrow$ | Any $\overline{C A S}$ |  |  | 13 | 19 |  | 13 | 19 | ns |
| $t_{\text {dis }}(20)$ | $\overline{O E} \dagger$ | Any Q |  |  | 15 | 22 |  | 15 | 22 | ns |
| $\mathrm{t}_{\text {dis }}(21)$ | $\overline{O E} \uparrow$ | Any $\overline{\text { RAS }}$ |  |  | 13 | 20 |  | 13 | 20 | ns |
| $\mathrm{t}_{\text {dis(22) }}$ | $\overline{\mathrm{OE}} \uparrow$ | Any $\overline{C A S}$ |  |  | 13 | 20 |  | 13 | 20 | ns |

'ALS2968 switching characteristics, $\mathrm{CL}_{\mathrm{L}}=150 \mathrm{pF}$

| PARAMETER | $\begin{aligned} & \text { FROM } \\ & \text { (INPUT) } \\ & \hline \end{aligned}$ | то (OUTPUT) | TEST CONDITIONS ${ }^{\dagger}$ | SN54ALS2968 |  |  | SN74ALS2968 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP ${ }^{\text { }}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $t_{\text {pd }}(1)$ | RASt | Any Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} . \\ & \mathrm{T}_{\mathrm{A}}=\mathrm{MIN} \text { to } \mathrm{MAX} \end{aligned}$ | 12 | 17 | 30 | 12 | 17 | 30 | ns |
| ${ }^{\text {tpd }}$ (2) | RASI | $\overline{\mathrm{RAS}} \mathrm{n}$ |  | 9 | 15 | 23 | 9 | 15 | 23 | ns |
| ${ }_{\text {t }}{ }_{\text {d }}(3)$ | CASI | $\overline{\text { CAS }}$ |  | 9 | 14 | 22 | 9 | 14 | 22 | ns |
| ${ }^{\text {t }} \mathrm{pd}$ (4) | Any A | Any 0 |  | 10 | 27 | 35 | 10 | 27 | 35 | ns |
| ${ }^{\text {t }} \mathrm{pd}$ (5) | MSEL | Any 0 |  | 9 | 19 | 26 | 9 | 19 | 26 | ns |
| $\mathrm{t}_{\mathrm{pd}}(6)$ | LET | Any 0 |  |  | 20 | 28 |  | 20 | 28 | ns |
| $t_{\text {pd }}(7)$ | LET | Any $\overline{\mathrm{RAS}}$ |  |  | 20 | 28 |  | 20 | 28 | ns |
| ${ }^{\mathrm{t}} \mathrm{pd}(8)$ | LET | Any CAS |  |  | 19 | 27 |  | 19 | 27 | ns |
| ${ }^{\text {tpd }}$ (9) | MCO or MC1 | Any O |  | 10 | 20 | 27 | 10 | 20 | 27 | ns |
| ${ }^{\text {tpd }}$ (10) | MCO or MC1 | Any RAS |  | 9 | 19 | 25 | 9 | 19 | 25 | ns |
| ${ }^{\text {tpd }}$ (111) | MCO or MC1 | Any CAS |  | 9 | 17 | 23 | 9 | 17 | 23 | ns |
| tpd(12) | $\overline{\mathrm{CS}}$ | Any 0 |  |  | 19 | 27 |  | 19 | 27 | ns |
| $\mathrm{t}_{\mathrm{pd}(13)}$ | $\overline{\text { CS }}$ | Any $\overline{\text { RAS }}$ |  |  | 14 | 22 |  | 14 | 22 | ns |
| $\mathrm{t}_{\mathrm{pd}}(14)$ | $\overline{\text { CS }}$ | Any CAS |  |  | 14 | 22 |  | 14 | 22 | ns |
| $\mathrm{t}_{\mathrm{pd}}(15)$ | SELO or SEL1 | Any $\overline{\text { RaS }}$ |  |  | 15 | 23 |  | 15 | 23 | ns |
| $\mathrm{t}_{\mathrm{pd}}(16)$ | SELO or SEL1 | Any CAS |  |  | 14 | 22 |  | 14 | 22 | ns |

${ }^{\dagger}$ See Figures $10,11,12$, and 13 for test circuit and switching waveforms.
${ }^{\ddagger}$ All typical values at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.


FIGURE 4. READ/WRITE CYCLE TIMING (MC1, MCO $=1,0),(L E=H)$
${ }^{\dagger}$ Parameters $t_{s u}(A R), t_{s u}(A C)$, and $t_{h(A R)}$ are timing requirements of the dynamic RAM. Parameters $t 1$, $t 2$, and $t 3$ represent the minimum timing requirements at the inputs to the DMC that guarantee DRAM timing specifications and maximum system performance. The minimum requirements for $t 1, t 2$, and $t 3$ are as follows:

$$
\begin{aligned}
& \mathrm{t} 1(\min )=\mathrm{t}_{\mathrm{pd}(4)} \max +\mathrm{t}_{\mathrm{su}}(\mathrm{AR}) \min -\mathrm{t}_{\mathrm{pd}(2)} \min \\
& \mathrm{t} 2(\min )=\mathrm{t}_{\mathrm{pd}(2)} \max +\mathrm{t}_{\mathrm{h}}(\mathrm{AR}) \min -\mathrm{t}_{\mathrm{pd}(5)} \min \\
& \mathrm{t} 3(\min )=\mathrm{t}^{2} \min +t_{\mathrm{pd}}(5) \max +\mathrm{t}_{\mathrm{su}}(\mathrm{AC})-\mathrm{t}_{\mathrm{pd}(3)} \min
\end{aligned}
$$

See the DRAM data sheet for applicable $t_{s u}(A R), t_{S u}(A R)$, and $t_{h(A R)}$. In addition, note that propagation delay times given in the above equations are functions of capacitive loading. The values used in these equations must relate to actual system capacitive loading.

${ }^{\dagger} t_{s u(A R)}, t_{s u}(A C)$, and $t_{h(A R)}$ are timing requirements of the dynamic RAM. See the DRAM data sheet for applicable specifications.



FIGURE 7. REFRESH CYCLE TIMING (MC1, MCO = L; H) WITH MEMORY SCRUBBING
$\dagger$ Parameters $t_{s u}(A R), t_{s u}(A C)$, and $t_{h}(A R)$ are timing requirements of the dynamic RAM. Parameters $t 2, t 3$, and $t 4$ represent the minimum timing requirements at the inputs to the DMC that guarantee DRAM timing specifications and maximum system performance. The minimum requirement for $t 2, \mathrm{t} 3$, and t 4 are as follows:

```
t2(min)}=\mp@subsup{t}{pd(2) max }{\mathrm{ m }
t3(min)}=\textrm{t}2\mathrm{ min + tpd(5) max + tsu(AC) - tpd(3) min
t4(min) = tpd(9) max + tsu(AR) min - tpd(2) min
```

See the DRAM data sheet for applicable $t_{S u}(A R), t_{S u}(A C)$, and $t_{h(A R)}$. In addition, note that propagation delay times given in the above equations are functions of capacitive loading. The values used in these equations must correspond to actual system capacitive loading. $\ddagger \mathrm{A} \overline{\mathrm{CAS}}$ n output is selected by the bank counter. All other $\overline{\mathrm{CAS}} \mathrm{n}$ outputs will remain high.


$\overline{\text { RASI ('ALS2967) }} \mathbf{=}$ L, RASI ('ALS2968) $=\mathrm{H}, \mathrm{MSEL}=\mathrm{H}$ or L, CASI ('ALS2967) $=\mathrm{L}$, CASI ('ALS2968) $=\mathbf{H}$
FIGURE 9. MISCELLANEOUS TIMING

## SWITCHING TEST CIRCUIT


${ }^{*}{ }^{t}{ }_{\text {pd }}$ specified at $C_{L}=50,150 \mathrm{pF}$
Figure 10. CAPACITIVE LOAD SWITCHING
FIGURE 11. THREE-STATE ENABLE/DISABLE

TYPICAL SWITCHING CHARACTERISTICS


FIGURE 12. OUTPUT DRIVE LEVELS

THREE-STATE TIMING


NOTE: Decoupling is needed for all AC tests
FIGURE 13. THREE-STATE CONTROL LEVELS

- Provides Control for $16 \mathrm{~K}, 64 \mathrm{~K}, 256 \mathrm{~K}$, and 1M Dynamic RAMs
- Highest-Order Two-Address Bits Select One of Four Banks of RAMs
- Supports Scrubbing Operations and NibbleMode Access
- Separate Output Enable for Multi-Channel Access to Memory
- 52-Pin Dual-In-Line Package


## description

The 'ALS6301 and 'ALS6302 dynamic memory controllers (DMCs) are designed for use in today's high-performance memory systems. The DMC acts as the address controller between any processor and dynamic memory array.

Two versions are provided that help simplify interfacing to the system dynamic timing controller. The 'ALS6301 offers active-low Row Address Strobe Input ( $\overline{\mathrm{RASI}})$ and Column Address Strobe Input ( $\overline{\mathrm{CASI}}$ ), while the 'ALS6302 offers active-high Row Address Strobe Input (RASI) and Column Address Strobe Input (CASI) inputs.

Using two 10-bit address latches, the DMC will hold the row and column addresses for any DRAM up to 1 M . These latches and the two row/column refresh address counters feed into a 10-bit, 4 -input MUX for output to the dynamic RAM address lines. A 2-bit bank select latch is provided to select one of the four $\overline{R A S}$ and $\overline{C A S}$ outputs. The two bits are normally obtained from the two highest-order address bits.

SN54ALS6301, SN54ALS6302 . . JD PACKAGE SN74ALS6301, SN74ALS6302 . . . JD OR N PACKAGE (TOP VIEW)
CS
AO
$\dagger$ 'ALS6301 has active-low inputs $\overline{\text { CASI }}$ and $\overline{\text { RASI; 'ALS6302 has }}$ active-high inputs CASI and RASI.

The 'ALS6301 and 'ALS6302 have two basic modes of operation, read/write and refresh. During normal read/write operations, the row and column addresses are multiplexed to the dynamic RAM, with the corresponding $\overline{\mathrm{RAS}}$ and $\overline{\mathrm{CAS}}$ signals activated to strobe the addresses into the RAM. In the refresh mode, the two counters cycle through the refresh addresses. If memory scrubbing is not being implemented, only the row counter is used. When memory scrubbing is being performed, both the row and column counters are used to perform read-modify-write cycles. In this mode all $\overline{\mathrm{RAS}}$ outputs will be active (low) while only one $\overline{C A S}$ output is active at a time.

The SN54ALS6301 and SN54ALS6302 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS6301 and SN74ALS6302 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
logic diagram (positive logic)

logic symbols ${ }^{\dagger}$


2
səગ!^əด IS7
${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std-91-1984 and IEC Publication 617-12.

## TABLE 1. PIN FUNCTION

| PIN NAME | DESCRIPTION |
| :---: | :---: |
| AO-A19 | Address Inputs. A0-A9 are latched in as the nine-bit row address for the DRAM. These inputs drive $00-09$ when the DMC is in the read/write mode and MSEL is low. A10-A19 are latched in as the column address, and will drive 00-08 when MSEL is high and the DMC is in the read/write mode. The addresses are latched when the Latch Enable (LE) input signal is low. |
| SELO, SEL1 | Bank Select. These two inputs are normally the two highest-order address bits and are used in the read/write mode to select which bank of memory will be receiving the $\overline{\mathrm{RAS}}$ and $\overline{\mathrm{CAS}}$ signals after $\overline{\mathrm{RASI}}$ ('ALS6301) or RASI ('ALS6302) and CASI ('ALS6301) or CASI ('ALS6302) go active. |
| LE | Latch Enable. This active-high input causes the row, column, and bank select latches to become transparent, allowing the latches to accept new input data. A low input on LE latches the input data. |
| MSEL | Multiplexer Select. This input determines whether the row or column address will be sent to the memory address inputs. When MSEL is high, the column address is selected, while the row address is selected when MSEL is low. The address may come from either the address latch or refresh address counter depending on MCO and MC1 (see Mode Control Function Table). |
| $\overline{\mathrm{CS}}$ | Chip Select. This active-low input is used to enable the DMC. When $\overline{\mathrm{CS}}$ is active, the DMC operates normally in all four modes. When CS goes high, the device will not enter the read/write mode. This allows other devices to access the same memory that the DMC is controlling. |
| $\overline{O E}$ | Output Enable. This active-low input enables/disables the output signals. When $\overline{\mathrm{OE}}$ is high, the outputs of the DMC enter the high-impedance state. |
| MCO-MC1 | Mode Controls. These inputs determine in which of the four modes the DMC operates. The description of each of the four operating modes is given in Table 2. |
| 00-08 | Address Outputs. These address outputs feed the DRAM address inputs and provide drive for memory systems having capacitance of up to 500 picofarads. |
| $\overline{\text { RASI }}$ or <br> RASI | Row Address Strobe Input. During the normal memory cycles, the decoded $\overline{\mathrm{RAS}}$ n output ( $\overline{\mathrm{RAS}} 0, \overline{\mathrm{RAS}} 1, \overline{\mathrm{RAS}} 2$, or $\overline{\mathrm{RAS}} 3$ ) is forced low after receipt of an active Row Address Strobe Input signal. In either Refresh mode, all four $\overline{\text { RAS }}$ outputs will be low while the Row Address Strobe Input signal is active. The RASI on the 'ALS6301 is an active-low input while on the 'ALS6302, RASI is an active-high input. (For more details see timing diagrams). |
| $\overline{\text { RAS } 0-\overline{R A S}} 3$ | Row Address Strobe. Each of the Row Address Strobe outputs provides a $\overline{\text { RAS }}$ signal to one of the four banks of dynamic memory. Each $\overline{\text { RAS }}$ n output will go low when selected by SELO and SEL. 1 after $\overline{\text { RASI ('ALS6301) or RASI ('ALS6302) }}$ goes active. All four go low in response to $\overline{\text { RASI ('ALS6301) or RASI ('ALS6302) while in the refresh mode. }}$ |
| $\overline{\text { CASI }}$ or CASI | Column Address Strobe Input. This input going active causes the selected $\overline{\text { CAS }}$ output to be forced low. The CASI input on the 'ALS6301 is active low input while on the 'ALS6302, CASI is active high input. (For more details see timing diagrams.) |
| CAS0-CAS 3 | Column Address Strobe. During normal Read/Write cycles the two selected bits (SELO, SEL1) determine which CAS output will go active following CASI ('ALS6301) or CASI ('ALS6302) going active. When memory scrubbing is being performed, only the CASn signal selected will be active. For non-scrubbing cycles, all four CAS outputs will remain high. |
| $\overline{T P}$ | This active-low test input asynchronously sets the row and column input latches high, while forcing the two bank select latches low. In normal operation, $\overline{T P}$ is tied high. |

## TABLE 2. MODE-CONTROL FUNCTION TABLE

| MC1 <br> L | $\mathrm{MCO}$ L | OPERATING MODE <br> Refresh Mode without Scrubbing, Refresh cycles are performed with only the row counter being used to generate the addresses. In this mode, all four $\overline{\mathrm{RAS}}$ outputs are active while the four $\overline{\mathrm{CA}} \overline{\mathrm{S}}$ outputs remain high. |
| :---: | :---: | :---: |
| L | H | Refresh with Scrubbing/Initialize. During this mode, refresh cycles are done with both the row and column counters generating the addresses. MSEL is used to select either the row or the column counter. All four $\overline{\mathrm{RAS}}$ outputs go low in response to $\overline{\text { RASI }}$ ('ALS6301) or RASI ('ALS6302), while only one $\overline{\mathrm{CAS}} \mathrm{n}$ output goes low in response to $\overline{\mathrm{CASI}}$ ('ALS6301) or CASI ('ALS6302). The bank counter keeps track of which $\overline{C A S}$ output goes active. This mode can also be used during system power-up so that the memory can be written with a known data pattern. |
| H | L | Read/Write. This mode is used to perform read/write cycles. Both the Row and Column addresses are multiplexed to the address output lines using MSEL. SELO and SEL1 are decoded to determine which $\overline{\mathrm{RAS}} \mathrm{n}$ and $\overline{\mathrm{CAS}} \mathrm{n}$ outputs will be active. |
| H | H | Clear Refresh Counters. This mode clears the three refresh counters (row, column, and bank) on the inactive transition of RASII ('ALS6301) or RASI ('ALS6302), putting them at start of the refresh sequence (see timing diagrams for more detail). In this mode, all four $\overline{\operatorname{RAS}}$ outputs are driven low after the active edge of $\overline{\operatorname{RASI}(' A L S 6301) ~ o r ~ R A S I ~(' A L S 6302) ~}$ so that DRAM wake-up cycles may also be performed. |

- Direct Replacement for National Semiconductor DP8400
- Fast Single- and Double-Error Detection
- Fast Single-Error Correction and Functionally Expandable to 100\% Double-Error Correction Capability
- Double-Error Correction after Catastrophic Failure without Additional Check Bits or ICs
- Functionally Expandable Capability Up to Triple-Error Detection
- Expandable to and beyond 64 Bits with Additional 'ALS8400s
- Complete Error Recording
- Byte Parity Generating and Checking
- Separate Byte Controls for Data Output in Byte-Write Operation
- Syndrome I/O Port for Error Logging and Management
- Full Memory Check Diagnostic and Check Bits Simulation Diagnostics Capability
- Self-Test of 'ALS8400 on the Memory Card Under Processor Control
- Complete Memory Failure Detection

| JD DUAL-IN-LINE PACKAGE (TOP VIEW) |  |  |  |
| :---: | :---: | :---: | :---: |
| D05 | 1 C | $\mathrm{J}_{48}$ | - DQ4 |
| D06 | 2 | 47 | $\square$ DO3 |
| D07 | 3 | 46 | $\square$ DQ2 |
| D08 | 4 | 45 | $\square$ DQ1 |
| D09 | 5 | 44 | $\square$ DQO |
| D010 | 6 | 43 | $\square \overline{\mathrm{OB}}$ |
| D011 | 7 | 42 | $\square \overline{O L E}$ |
| D012 | 8 | 41 | $\square$ DLE |
| D013 | 9 | 40 | $\square$ EO |
| D014 | 10 | 39 | $\square \mathrm{AE}$ |
| D015 | 11 | 38 | $\square \mathrm{GND}$ |
| $\overline{\mathrm{OB}} 1$ | 12 | 37 | $\square \mathrm{XP}$ |
| GND | 13 | 36 | $\mathrm{V}_{\mathrm{CC}}$ |
| CO | 14 | 35 | ] E 1 |
| C1 | 15 | 34 | M 2 |
| C2 | 16 | 33 | M1 |
| C3 | 17 | 32 | MO |
| C4 | 18 | 31 | so |
| C5 | 19 | 30 | S1 |
| C6 | 20 | 29 | ¢ 52 |
| BPO(C7) | 21 | 28 | S3 |
| $\overline{\text { OES }}$ | 22 | 27 | S4 |
| CSLE | 23 | 26 | 口 S5 |
| BP1 | 24 | 25 | D 6 |

- Power-On Clears Data and Syndrome Latches


## description

The 'ALS8400 is a monolithic Advanced Low-Power Schottky error checker and corrector (ECC) integrated circuit designed to aid in system reliability and integrity by detecting errors in memory data and correcting single- or double-bit errors. The ECC has a separate syndrome I/O bus, which can be used for error logging or error management. It can also be used in BYTE-WRITE applications (for up to 72 data bits) because it has separate byte controls for the data buffers. In 16- or 32-bit systems, the 'ALS8400 will generate and check system byte parity, if required, for integrity of the data supplied from or to the processor. There are three latch controls to enable latching of data in various modes and configurations.

The 'ALS8400 is easily expandable to other data configurations. For 32-bit data bus with seven check bits, two 'ALS8400s can be used in cascade with no other ICs. Three 'ALS8400s can be used for 48 bits, and four 'ALS8400s for 64 data bits, both using eight check bits. In all these configurations, singleerror and double-error detection and single-error correction are easy to implement.
The 'ALS8400 is characterized for operation from ${ }^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

| NAMES | 10 | Description |
| :---: | :---: | :---: |
| ${ }^{\text {AE }}$ | 0 | When Iow $A E$ in |
| 8Po, | 10 | Byte parity $0 /$ check bit 7 . When $X P$ is at 0 V , this pin is byte- 0 parity $\mathrm{I} / \mathrm{O}$. In the normal write mode, BPO receives system byte-0 parity, and in the normal read mode, outputs system byte-0 parity. When the XP pin is open or at $V_{C C}$, the BPO/C7 pin becomes the check bit $C 7 / / O$, the eighth check bit for the memory check |
| ${ }^{\text {BP//S7 }}$ | 10 | Byte parity $1 /$ syndrome bit 7 . When XP pin is at 0 V , this pin is byte 1 parity $\mathrm{I} / \mathrm{O}$. In the normal write mode, BP1 receives system byte-1 parity, and in the normal read mode outputs system byte-1 parity. When the XP pin is open or at $\mathrm{V}_{\mathrm{CC}}$, the $\mathrm{BP} 1 / \mathrm{S} 7$ pin becomes the syndrome bit $\mathrm{S} 7 / / \mathrm{O}$, the eighth syndrome bit, for 48 -bit expansion configuration and beyond |
| CSLE | ' | Input check bit and syndrome latch enable. When high, the outputs of the check bit input latches follow input位 bit and if $\overline{O E S}$ is low, the outputs of the syndrome input latches follow the syndrome bit bus. |
| ${ }^{\text {co.c6 }}$ | 10 | Check-bit I/O port. A 7-bit bidirectional bus connected to the input of the check-bit input latches and the utputs of the check-bit output buffers. The check-bit output buffers are enabled whenever M2 pin is low. |
| DLE |  | Input data latch enable. When high, outputs of the data input latches follow the input data bus. When low, the data input latches store the input data. |
| 0 -0015 | 10 | Data I/O port. A 16 -bit bidirectional data bus connected to the input of the data input latches and the ou of the data output buffers, with DQ8-DQ15 also connected to the check-bit input latches. |
| ${ }^{\text {Eo }}$ | - | Error $O$ output. In the normal read mode, EO is high for a single-data error and low for other conditions. In the normal write mode, EO becomes PEO and is low if a parity error exists in byte-0 as transmitted from the processor. |
| ${ }^{\text {E1 }}$ | $\bigcirc$ | Error 1 output. In the normal read mode, E1 is high for a single-data error or a single check-bit error, and low for no error or a double error. In the normal write mode, E1 becomes PE1 and is low if a parity error exists in byte 1 as transmitted from the processor |
| No |  | System ground |
| мо-M2 | , | Mode control inputs. |
|  | ' | Output byte 0 and Output byte 1 enables. These inputs, when low, enable the outputs of the data output latches through the data output buffers onto the data bus. When $\overline{O B O}$ and $\overline{O B 1}$ are high, the outputs of the data output buffers are placed in the high-impedance state. |
| OES | ' | Output enable syndromes. I/O control of the syndrome latches. When high, the outputs of the syndrome output buffers are placed in the high-impedance state and external syndromes pass through the syndrome input latches with CSLE high. When $\overline{\mathrm{OES}}$ is low, the outputs of the syndrome output buffers are enabled and latches. |
| OIE | ' | Output latch enable. When low, $\overline{\text { OLE }}$ enables the internally generated data to enter the data output latches,解 bit output latches, and syndrome output latches. When $\overline{\mathrm{OLE}}$ is high, the latches store the data. |
| ${ }^{\text {so.S6 }}$ | 10 | Syndrome I/O port. A 7-bit bidirectional bus connected to the input of the syndrome input latches and the outputs of the syndrome output buffers. |
| ${ }_{\text {vec }}^{\text {xp }}$ |  |  |

## functional description

The 'ALS8400, with its 16 -bit bidirectional data bus connected to the memory data bus, monitors data between the processor and memory. It uses an encoding matrix to generate six check bits from the 16 bits of data. In a write cycle, the data word and the corresponding check bits are written into memory. When the same location of memory is subsequently read, the ECC generates six new check bits from the memory data and compares them with the six check bits read from memory to create six syndrome bits. If there is a difference (causing some syndrome bits to go high), then that memory location contains an error and the ECC indicates the type of error with three error flags. If the error is a single-bit error, the ECC will automatically correct it.

When the memory has more than one error, or better system integrity is preferred, double-error correction can be performed. One approach requires a further write-read cycle using complemented data and check bits from the ECC. If at least one of the two errors is a hard error, the ECC will correct both errors. This implementation requires no more memory check bits or ECCs than the single-error correct configuration.


- Advanced Schottky IMPACT-X ${ }^{T M}$ Process
- Three-Operand, 64-Word by 40-Bit Register File
- Supports 'AS888 and 'AS8832 Register File Expansion
- Four 10-Bit Input Ports with Individual Parity Checkers and Write Enables
- Four 10-Bit Output Ports with Individual Three-State Enables
- Two Write Address Ports
- Two Read Address Ports and Y Output Mux Permit LSH/MSH Swap Operations
- 156-Pin Package
- 8-mA Bus Drivers
- Texas Instruments Quality and Reliability


## description

The SN54AS8834 and SN74AS8834 are high speed, three-operand, 64-word register files in a 156 -pin ceramic pin grid array.

The register files are designed to support register file expansion for bit-slice systems using the'AS888 or 'AS8832. Internal parity checks and a 40-bit word width support 1/O operations for graphics and 32-bit error detection and correction boards.

The SN54AS8834 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS8834 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
logic symbol ${ }^{\dagger}$


[^48]
## SN54AS8834, SN74AS8834 <br> 40-BIT REGISTER FILE

|  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PIN |  | PIN |  | PIN |  | PIN |  | PIN |  | PIN |  |
| No. | NAME | No. | NAME | No. | NAME | No. | NAME | No. | NAME | NO. | NAME |
| A1 | Y29 | B12 | Y7 | D14 | Y3 | H12 | D3 | M3 | WAR3 | P5 | D36 |
| A2 | NC | B13 | Y8 | D15 | OEL2 | H13 | D2 | M7 | D28 | P6 | D32 |
| A3 | Y27 | B14 | NC | E1 | NC | H14 | D5 | M8 | PL2 | P7 | D30 |
| A4 | Y25 | B15 | Yo | E2 | Y36 | H15 | D4 | M10 | D18 | P8 | PL1 |
| A5 | Y23 | C1 | Y39 | E3 | GND1 | $J 1$ | RABO | M13 | WAL3 | P9 | D26 |
| A6 | Y21 | C2 | NC | E13 | GND1 | J2 | RAA5 | M14 | WAL2 | P10 | D22 |
| A7 | NC | C3 | NC | E14 | Y1 | J3 | RAA3 | M15 | NC | P11 | D16 |
| A8 | NC | C4 | Y32 | E15 | TP2 | J4 | RAA1 | N1 | NC | P12 | D12 |
| A9 | Y18 | C5 | $\mathrm{V}_{\mathrm{CC} 1}$ | F1 | OER1 | J 12 | D11 | N2 | WAR4 | P13 | WAL5 |
| A10 | Y16 | C6 | GND1 | F2 | Y38 | J13 | GND2 | N3 | WAR5 | P14 | D13 |
| A11 | Y14 | C7 | Y22 | F3 | GND2 | J14 | D7 | N4 | WER2 | P15 | CLK |
| A12 | Y12 | C8 | GND1 | F13 | GND2 | J15 | D6 | N5 | D38 | Q1 | WER1 |
| A13 | NC | C9 | Y17 | F14 | OEE1 | K1 | RAA4 | N6 | D34 | 02 | D35 |
| A14 | Y10 | C10 | GND1 | F15 | $A L / \overline{B R}$ | K2 | GND2 | N7 | $\mathrm{V}_{\mathrm{CC}} 1$ | Q3 | D33 |
| A15 | Y2 | C11 | $\mathrm{V}_{\mathrm{CC} 1}$ | G1 | RAB5 | K3 | GND2 | N8 | GND1 | 04 | D31 |
| B1 | Y37 | C12 | Y6 | G2 | AR/BL | K13 | $\mathrm{V}_{\text {CC2 }}$ | N9 | D24 | 05 | D29 |
| B2 | Y31 | C13 | NC | G3 | $\mathrm{V}_{\mathrm{CC} 2}$ | K14 | D9 | N10 | D20 | 06 | PR1 |
| B3 | Y33 | C14 | Y5 | G4 | $\overline{\mathrm{OEB}} 2$ | K15 | D8 | N11 | D14 | 07 | PR2 |
| B4 | Y30 | C15 | NC | G12 | $\overline{\mathrm{MOE}}$ | L1 | RAA2 | N 12 | WEL. 1. | 08 | NC |
| B5 | Y28 | D1 | NC | G13 | TP1 | L2 | WARO | N 13 | WAL4 | 09 | D27 |
| B6 | Y26 | D2 | Y35 | G14 | DO | L3 | $\mathrm{v}_{\text {CC2 }}$ | N14 | WALO | 010 | D25 |
| B7 | Y20 | D3 | Y34 | G15 | D1 | L13 | WAL! | N15 | NC | 011 | D23 |
| B8 | Y19 | D7 | Y24 | H1 | RAB3 | L14 | WEL2 | P1 | NC | 012 | D21 |
| B9 | Y13 | D8 | $\mathrm{V}_{\mathrm{CC} 1}$ | H2 | RAB4 | L15 | D10 | P2 | WAR1 | 013 | D19 |
| B10 | Y11 | D9 | Y15 | H3 | RAB2 | M1 | RAAO | P3 | D37 | 014 | D17 |
| B11 | Y9 | D13 | Y4 | H4 | RAB1 | M2 | WAR2 | P4 | D39 | 015 | D15 |

NC-No internal connection

| PIN |  |  | DESCRIPTION |  |
| :---: | :---: | :---: | :---: | :---: |
| NAME | No. | 1/0 |  |  |
| $A L / \overline{B R}$ | F15 | 1 | Output select for Y20-Y39 output data. High selects DA20-DA39; low selects DB0-DB19. |  |
| AR/ $\overline{\mathrm{BL}}$ | G2 | 1 | Output select for Y0-Y10 output data. High selects DAO-DA19; low selects DA20-DA39. |  |
| CLK | P15 | 1 | Clocks data into register file on rising edge. |  |
| DO | G14 | 1 | Input data bits 0 through 9 |  |
| D1 | G15 |  |  |  |
| D2 | H13 |  |  |  |
| D3 | H12 |  |  |  |
| D4 | H15 |  |  |  |
| D5 | H14 |  |  |  |
| D6 | J15 |  |  |  |
| D7 | J14 |  |  |  |
| D8 | K15 |  |  |  |
| D9 | K14 |  |  |  |
| D10 | 115 | 1 | Input data bits 10 through 19 |  |
| D11 | $J 12$ |  |  |  |
| D12 | P12 |  |  |  |
| D13 | P14 |  |  |  |
| D14 | N11 |  |  | $\bigcirc$ |
| D15 | 015 |  |  |  |
| D16 | P11 |  |  |  |
| D17 | Q14 |  |  | 0 |
| D18 | M10 |  |  |  |
| D19 | Q13 |  |  |  |
| D20 | N10 | 1 | Input data bits 20 through 29 |  |
| D21 | 012 |  |  | 0 |
| D22 | P10 |  |  |  |
| D23 | 011 |  |  | 0 |
| D24 | N9 |  |  |  |
| D25 | 010 |  |  |  |
| D26 | P9 |  |  |  |
| D27 | Q9 |  |  |  |
| D28 | M7 |  |  |  |
| D29 | 05 |  |  |  |
| D30 | P7 | 1 | Input data bits 30 through 39 |  |
| D31 | 04 |  |  |  |
| D32 | P6 |  |  |  |
| D33 | 03 |  |  |  |
| D34 | N6 |  |  |  |
| D35 | 02 |  |  |  |
| D36 | P5 |  |  |  |
| D37 | P3 |  |  |  |
| D38 | N5 |  |  |  |
| D39 | P4 |  |  |  |
| GND1 | E3 |  | 5-volt ground (All ground pins must be used.) |  |
| GND1 | E13 |  |  |  |
| GND1 | C6 |  |  |  |
| GND1 | C8 |  |  |  |
| GND1 | C10 |  |  |  |
| GND1 | N8 |  |  |  |


| PIN |  |  |  |
| :---: | :---: | :---: | :---: |
| NAME | NO. | 1/0 |  |
| GND2 | F3 |  | 2-volt ground (All ground pins must be used.) |
| GND2 | F13 |  |  |
| GND2 | J 13 |  |  |
| GND2 | K2 |  |  |
| GND2 | D3 |  |  |
| M8 | PL2 | 0 | Parity check result. High indicates odd number of high inputs on D30-D39. |
| $\overline{\mathrm{MOE}}$ | G12 | 1 | Master output enable, active low. Places YO-Y39 and parity outputs in the high-impedance state when high. |
| NC | A2 |  | No internal connection |
| NC | A7 |  |  |
| NC | A8 |  |  |
| NC | A13 |  |  |
| NC | B14 |  |  |
| NC | C2 |  |  |
| NC | C3 |  |  |
| NC | C13 |  |  |
| NC | C15 |  |  |
| NC | D1 |  |  |
| NC | E1 |  |  |
| NC | M15 |  |  |
| NC | N1 |  |  |
| NC | N15 |  |  |
| NC | P1 |  |  |
| NC | Q8 |  |  |
| $\overline{\text { OEL } 1}$ | F14 | I | Y20-Y29 output enable, active low Y30-Y39 output enable, active low Y0-Y9 output enable, active low Y10-Y19 output enable, active low |
| OEL2 | D15 |  |  |
| OER1 | F1 |  |  |
| OER2 | G4 |  |  |
| PL1 | P8 | 0 | "arity check result. High indicates odd number of high inputs on D20-D29. <br> Parity check result. High indicates odd number of high inputs on D30-D39. <br> Parity check result. High indicates odd number of high inputs on DO-D9. <br> Parity check result. High indicates odd number of high inputs on D10-D19. |
| PL2 | M8 |  |  |
| PR1 | Q6 |  |  |
| PR2 | 07 |  |  |
| RAAO | M1 | 1 | Register file A port read address select ( $0=$ LSB) |
| RAA 1 | J4 |  |  |
| RAA2 | L. 1 |  |  |
| RAA3 | J3 |  |  |
| RAA4 | K1 |  |  |
| RAA5 | J2 |  |  |
| RABO | J1 | 1 | Register file $A$ port read address select ( $0=$ LSB) |
| RAB1 | H4 |  |  |
| RAB2 | H3 |  |  |
| RAB3 | H1 |  |  |
| RAB4 | H2 |  |  |
| RAB5 | G1 |  |  |
| TP1 | G13 | I | Functional testing input. During normal operation, should be maintained high or open. |
| TP2 | E15 |  |  |



SN54AS8834, SN74AS8834

## 40-BIT REGISTER FILE

| PIN |  |  | DESCRIPTION |
| :--- | :--- | :--- | :--- |
| NAME | NO. | 110 |  |
| Y20 | B7 |  |  |
| Y21 | A6 |  |  |
| Y22 | C7 |  |  |
| Y23 | A5 |  |  |
| Y24 | D7 | 0 | Output data bits 20 through 29 |
| Y25 | A4 | 0 |  |
| Y26 | B6 |  |  |
| Y27 | A3 |  |  |
| Y28 | B5 |  |  |
| Y29 | A1 |  |  |
| Y30 | B4 |  |  |
| Y31 | B2 |  |  |
| Y32 | C4 |  |  |
| Y33 | B3 |  |  |
| Y34 | D3 | 0 | Output data bits 30 through 39 |
| Y35 | D2 |  |  |
| Y36 | E2 |  |  |
| Y37 | B1 |  |  |
| Y38 | F2 |  |  |
| Y39 | C1 |  |  |



## SN54AS8834, SN74AS8834

40-BIT REGISTER FILE

## data input/output ports

Data is input to the 'AS8834 through four 10-bit data ports: D30-D39, D20-D29, D10-D19 and DO-D9. Data is output from the register file through four 10-bit output ports: Y30-Y39, Y20-Y29, Y10-Y19 and Y0-Y9. The Y ports are enabled by four active low output enables: $\overline{\mathrm{OEL}} 2$ for $\mathrm{Y} 30-\mathrm{Y} 39, \overline{\mathrm{OEL}} 1$ for Y20-Y29, $\overline{\mathrm{OER}} 2$ for Y10-Y19, and $\overline{\mathrm{OER}} 1$ for YO-Y9.

## register file addressing

Data is stored in the register file on the rising edge of the clock. Two write address ports and two read address ports operate independently to implement a 40-bit register file that supports MSH/LSH swap operations. WALO-WAL5 is the write address for D20-D39 input data; WARO-WAR5 is the write address for D0-D19 input data. These separate write addresses permit the most significant and the least significant half of a word to be stored at different addresses. Register file writes are enabled by four write enables: WEL2 for D30-D39, WEL1 for D20-D29, WER2 for D10-D19, and WER1 for DO-D9.

Two read address lines are also provided: RAAO-RAA5 and RABO-RAB5. These lines control the selection of data to be output on internal data buses DAO-DA39 and DBO-DB39 respectively. Y-output data selection is controlled by $A L / \overline{B R}$ and $A R / \overline{B L}$ as shown in Table 1.

TABLE 1. OUTPUT FUNCTION TABLE

| SIGNAL | RESULT | SIGNAL | RESULT | RESULT WHEN COMBINED |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| AL/BR | Y20-Y39 | AR/BL | YO-Y19 | Y20-Y39 | YO-Y19 |
| H | A20-A39 | H | AO-A19 | A (MSH) | A (LSH) |
| H | A20-A39 | L | B20-B39 | A (MSH) | B (MSH) |
| L | BO-B19 | H | AO-A19 | B (LSH) | A (LSH) |
| L | B0-B19 | L | B20-B39 | B (LSH) | B (MSH) |

## parity checkers

Two parity checkers are provided for data on the D input ports. A high on output signals PL2, PL1, PR2 or PR1 indicate an odd number of high signals on data inputs D30-D39, D20-D29, D10-D19 and D0-D9 respectively.

## master output enable

When high, Master Output Enable, $\overline{\mathrm{MOE}}$, places the four Y output ports and the four parity output ports in the high-impedance state.

## absolute maximum ratings over operating temperature range (unless otherwise noted)

Supply voltage, VCC1 ..... 7 V
Supply voltage, VCC2 ..... 3 V
Input voltage ..... 7 V
High-level voltage applied to 3-state outputs ..... 5.5 V
Operating case temperature range: SN54AS8834 ..... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Operating free-air temperature range: SN74AS8834 ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

| PARAMETER | SN54AS8834 |  |  | SN74AS8834 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{\text {CC1 }}$ I/O supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {CC2 }}$ STL internal logic supply voltage | 1.9 | 2 | 2.1 | 1.9 | 2 | 2.1 | V |
| $\mathrm{V}_{\text {IH }} \quad$ High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{I}_{\mathrm{OH}} \quad$ High-level output current |  |  | -1 |  |  | 2.6 | mA |
| IOL Low-level output current |  |  | 8 |  |  | 8 | mA |
| TC Operating case temperature |  |  | 125 |  |  |  | ${ }^{\circ} \mathrm{C}$ |
| TA Operating free-air temperature | $-55$ |  |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54AS8834 |  |  | SN74AS8834 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP ${ }^{\text {t }}$ | MAX | MIN | TYP ${ }^{\text {t }}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $1 \mathrm{OH}=-1 \mathrm{~mA}$ | 2.4 |  |  |  |  |  | V |
|  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\mathrm{OH}}=-2.6 \mathrm{~mA}$ |  |  |  | 2.4 |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{IOL}=8 \mathrm{~mA}$ |  |  | 0.5 |  |  | 0.5 | V |
| IOZH | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.7 \mathrm{~V}$ |  |  |  |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=0.4 \mathrm{~V}$ |  |  |  |  |  | -0.4 | mA |
| 1 | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IL | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.5 \mathrm{~V}$ |  |  | -0.4 |  |  | -0.4 | mA |
| $10^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{0}=2.25 \mathrm{~V}$ | -30 |  | -112 | -30 |  | -112 | mA |
| ICC1 | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$ |  |  |  |  |  |  |  | mA |
| ICC2 | $\mathrm{V}_{\text {CC2 }}=2.1 \mathrm{~V}$ |  |  |  |  |  |  |  | mA |

${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, los.

## 40-BIT REGISTER FILE

## timing requirements

|  |  | PARAMETER | SN54AS8834 |  | SN74AS8834 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\text {su }}$ | Setup time | WEL1-WEL2 before CLK $\dagger$ |  |  |  |  | ns |
|  |  | $\overline{\text { WER }} 1-\overline{\text { WER } 2 ~ b e f o r e ~ C L K ~} \uparrow$ |  |  |  |  |  |
|  |  | WALO-WAL5 before CLK $\uparrow$ |  |  |  |  |  |
|  |  | WARO-WAR5 before CLK $\uparrow$ |  |  |  |  |  |
|  |  | D0-D39 before CLK $\dagger$ |  |  |  |  |  |
| $t_{\text {th }}$ | Hold time | WEL1-WEL2 after CLK $\uparrow$ |  |  |  |  | ns |
|  |  | $\overline{\text { WER1-WER2 } 2 \text { after CLK } \dagger ~}$ |  |  |  |  |  |
|  |  | WALO-WAL5 after CLK $\dagger$ |  |  |  |  |  |
|  |  | WARO-WAR5 after CLK $\dagger$ |  |  |  |  |  |
|  |  | D0-D39 after CLK $\dagger$ |  |  |  |  |  |

switching characteristics over recommended ranges of operating temperature and supply voltage (see Note 1)

| PARAMETER | FROM (INPUT) | $\begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}$ | SN54AS8834 |  | SN74AS8834 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{pd}}$ | D30.D39 | PL2 |  |  |  |  | ns |
|  | D20-D29 | PL1 |  |  |  |  |  |
|  | D10-D19 | PR2 |  |  |  |  |  |
|  | DO-D9 | PR1 |  |  |  |  |  |
|  | RAAO. RAA 5 | Y0-Y39 |  |  |  |  |  |
|  | RABO-RAB5 | Y0-Y39 |  |  |  |  |  |
|  | $\mathrm{AL} / \overline{\mathrm{BR}}$ | Y20-Y39 |  |  |  |  |  |
|  | AR/BL | Y0-Y19 |  |  |  |  |  |
|  | CLK | Y0.Y39 ${ }^{\text {t }}$ |  |  |  |  |  |
| ten | $\overline{\text { MOE }}$ | PL2-PL1 or PR2-PR1 |  |  |  |  | ns |
|  | $\overline{\mathrm{MOE}}$ | Y0-Y39 |  |  |  |  |  |
|  | OEL2 | Y30-Y39 |  |  |  |  |  |
|  | OEL1 | Y20.Y29 |  |  |  |  |  |
|  | $\overline{\text { OER2 }}$ | Y10-Y19 |  |  |  |  |  |
|  | OEK1 | Yo-y9 |  |  |  |  |  |
| $\mathrm{t}_{\text {dis }}$ | $\overline{\text { MOE }}$ | $\begin{gathered} \hline \text { PL2-PL1 or } \\ \text { PR2-PR1 } \end{gathered}$ |  |  |  |  | ns |
|  | $\overline{\text { MOE }}$ | Y0-Y39 |  |  |  |  |  |
|  | OEL2 | Y30-Y39 |  |  |  |  |  |
|  | OEL1 | Y20-Y29 |  |  |  |  |  |
|  | OER2 | Y10-Y19 |  |  |  |  |  |
|  | OER1 | Yo-y9 |  |  |  |  |  |

${ }^{\dagger}$ When read and write address are already selected.
NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- High-Speed "Flash" Shift Operations
- Shifts up to $\mathbf{3 2}$ Positions in Less than 25 ns
- Performs Logical, Circular, and Arithmetic Shifts
- 3-State Outputs Allow 32-Bit and 16-Bit Bus Interface
- 24-mA Bus Drivers
- 84-Pin Package
- Uses Less than 1.5 W (Max)
- Texas Instruments Quality and Reliability


## description

The SN54AS8838 and SN74AS8838 are highspeed 32-bit barrel shifters in an 84-pin ceramic pin-grid array. The devices can shift up to 32 bits in a single instruction cycle of under 25 nanoseconds. Five basic shifts can be programmed: circular left and right, logical left and right, and arithmetic right.

Unlike conventional shift registers, whose shift operations are controlled by the number of input clock pulses applied, the number of positions to be shifted by the 'AS8838 is determined by an input decoder. This form of implementation does not require an input clock, thus, the shift operation is restricted only by internal propagation delays. The delay is the same regardless of the number of positions to be shifted, resulting in a high-speed "flash" shift.

Three-state output controls allow the devices to be interfaced with 32 - or 16 -bit data buses.

The SN54AS8838 is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS8838 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN54AS8838. SN74AS8838 GB PIN-GRID-ARRAY PACKAGE (TOP VIEW)


| PIN |  | PIN |  |
| :---: | :---: | :---: | :---: |
| NO. | NAME | NO. | NAME |
| A1 | GND | F9 | $\overline{\text { YOEL }}$ |
| A2 | $V_{\text {CC2 }}$ | F10 | Y7 |
| A3 | Y30 | F11 | Y6 |
| A4 | Y28 | G1 | D20 |
| A5 | Y25 | G2 | D19 |
| A6 | Y23 | G3 | D18 |
| A7 | GND | G9 | Y4 |
| A8 | Y20 | G10 | Y5 |
| A9 | Y 18 | G11 | GND |
| A10 | Y16 | H1 | D17 |
| A11 | GND | H2 | D16 |
| B1 | D31 | H10 | Y2 |
| B2 | GND | H11 | Y3 |
| B3 | Y31 | J1 | D15 |
| B4 | Y29 | J2 | D14 |
| B5 | Y26 | J5 | D7 |
| B6 | Y24 | J6 | D2 |
| B7 | Y22 | J7 | MUX1 |
| B8 | Y19 | J10 | Yo |
| B9 | Y17 | J11 | Y1 |
| B10 | $\mathrm{V}_{\mathrm{CC} 1}$ | K 1 | VCCl |
| B11 | Y 15 | K2 | D13 |
| C1 | D29 | K3 | D11 |
| C2 | D30 | K4 | D9 |
| C5 | Y27 | K5 | D6 |
| C6 | YOEM | K6 | D3 |
| C7 | Y21. | K7 | D0 |
| C10 | Y14 | K8 | SFT4 |
| C11 | Y13 | K9 | GND |
| D1 | D27 | K10 | SFT1 |
| D2 | D28 | K11 | SFTO |
| D10 | Y12 | L1 | GND |
| D11 | Y11 | L2 | D12 |
| E1 | D24 | L3 | D10 |
| E2 | D25 | L4 | D8 |
| E3 | D26 | L5 | D5 |
| E9 | Y10 | L6 | D4 |
| E10 | Y9 | L. 7 | D1 |
| E11 | Y8 | L8 | MUXO |
| F1 | D23 | L9 | SFT3 |
| F2 | D22 | L10 | VCC2 |
| F3 | D21 | L11 | SFT2 |

logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984.


| PIN |  |  | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| NAME | NO. | 1/0 | DESCRIPTION |
| YO | J10 |  |  |
| Y1 | J11 |  |  |
| Y2 | H10 |  |  |
| Y3 | H11 |  |  |
| Y4 | G9 |  | \% |
| Y5 | G10 | 0 | Output data bits 0 through 10 |
| Y6 | F11 |  |  |
| Y7 | F10 |  |  |
| Y8 | E11 |  | - |
| Y9 | E10 |  |  |
| Y10 | E9 |  |  |
| Y11 | D11 |  |  |
| Y12 | D10 |  |  |
| Y13 | C11 |  |  |
| Y14 | C10 |  |  |
| Y15 | B11 |  |  |
| Y16 | A10 |  |  |
| Y17 | B9 |  |  |
| Y18 | A9 |  |  |
| Y19 | B8 |  |  |
| Y20 | A8 |  |  |
| Y21 | C7 | 0 | Output data bits 11 through 31 |
| Y22 | B7 |  |  |
| Y23. | A6 |  |  |
| Y24 | B6 |  |  |
| Y25 | A5 |  |  |
| Y26 | B5 |  |  |
| Y27 | C5 |  |  |
| Y28 | A4 |  |  |
| Y29 | B4 |  |  |
| Y30 | A3 |  |  |
| Y31 | B3 |  |  |
| YOEL | F9 | 1 | Control input for the Y15-YO output port. When YOEL is low, Y15-YO is enabled. |
| YOEM | C6 | 1 | Control input for the Y31-Y16 output port. When $\overline{\mathrm{YOEM}}$ is low, Y31-Y16 is enabled. |

## functional block diagram



## data input/output

Data is input to the 'AS8838 through the D31-D0 data port and output through two 16 -bit data ports, Y31-Y16 and Y15-Y0. Two 3-state output controls enable the Y data ports. The most significant half of the shift result is enabled when $\overline{\text { YOEM }}$ is low, the least significant half when YOEL is low.

## shift control block

The shift control block decodes the MUX1-MUX0 instruction inputs and the SFT4-SFTO shift position controls and transmits the resulting control signals to the shifter. MUX1-MUX0 control shift instruction selection as shown in Table 1. SFT4-SFTO specify the number of bit positions to be shifted. For right shifts, the two's complement of the number of bit positions must be placed on SFT4-SFTO.
table 1. Instruction set

| MUX1 $\quad$ MUXO | FUNCTION | OPERATION |  |
| :---: | :---: | :--- | :--- |
| L | L | Logical Left Shift | Shift left the number of bit positions defined by SFT4-SFTO. Fill vacated bit positions <br> with zeros. |
| L | H | Logical Right Shift | Shift right the number of bit positions specified by the two's complement of <br> SFT4-SFTO. Fill vacated bit positions with zeros. (A logical right shift with <br> SFT4-SFTO = 0 will fill all bits with zeros.) |
| H | L | Circular Left Shift | Circular left shift the number of bit positions defined by SFT4-SFTO. (A circular right <br> shift can be performed by putting the two's complement of number of bits to be <br> shifted on SFT4-SFTO.) |
| H | H | Arithmetic Right Shift | Shift right the number of bit positions defined by the two's complement of <br> SFT4-SFTO. Fill vacated bit positions with the D31 input value (sign bit) (An <br> arithmetic right shift with SFT4-SFTO $=0$ will fill all bits with the sign bit.). |

## SN54AS8838, SN74AS8838

32-BIT BARREL SHIFTERS
shift operation examples
logical shift left ( $\mathbf{M 1} \mathbf{- M 0}=\mathbf{L L}$ )
In the shift left mode, SFT4-SFTO define the number of bit positions to be shifted. The following example shifts a 32 -bit word 8 positions to the left and fills the vacated bit positions with zeros.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION <br> M2-MO | NUMBER OF BITS <br> TO SHIFT <br> SFT4-SFTO |
| :---: | :---: |
| 00 | 01000 |

Assume D31-DO is hex ABCD0123.


logical shift right ( $\mathbf{M 1} 1-\mathrm{MO}=\mathrm{LH}$ )
In the shift right mode, the two's complement of the number of bit positions to be shifted must be placed on SFT4-SFTO. The following example shifts a 32 -bit word 8 positions to the right and fills the vacated bit positions with zeros.

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION <br> M2-MO | NUMBER OF BITS <br> TO SHIFT <br> SFT4-SFTO |
| :---: | :---: |
| 01 | 11000 |

Assume D31-DO is hex ABCD0123.

D31-D0
Input Data 10101011110011010000000100100011

Y31-Y0

Result 00000000101010111100110100000001
circular shift left ( $\mathrm{M} 1-\mathrm{MO}=\mathrm{HL}$ )
In the circular shift left mode, SFT4-SFTO define the number of bit positions to be shifted. The following example circular shifts a 32 -bit word 8 positions to the left.

CONTROL SIGNALS

| SHIFT | NUMBER OF BITS |
| :---: | :---: |
| INSTRUCTION | TO SHIFT |
| M2-M0 | SFT4-SFTO |
| 10 | 01000 |

Assume D31-DO is hex $A B C D 0123$.
D31-D0

Input Data
10101011110011010000000100100011

circular shift right ( $\mathrm{M} 1-\mathrm{MO}=\mathrm{HL}$ )
A circular right shift can be performed by placing the two's complement of the number of bit positions to be shifted on SFT4-SFT0 and using the circular left shift mode ( $M 1-M 0=H L$ ). The following example circular shifts a 32-bit word 8 positions to the right.

CONTROL SIGNALS

| SHIFT | NUMBER OF BITS |
| :---: | :---: |
| INSTRUCTION | TO SHIFT |
| M2-M0 | SFT4-SFTO |
| 10 | 11000 |

Assume D31-D0 is hex ABCD0123.
D31-D0
Input Data
10101011110011010000000100100011

Y31-Y0
Result
00100011101010111100110100000001

## SN54AS8838, SN74AS8838 32-BIT BARREL SHIFTERS

arithmetic shift right $(\mathrm{M} 1-\mathrm{MO}=\mathrm{HH})$
In the arithmetic shift right mode, SFT4-SFTO define the number of bit positions to be shifted. The following example shifts a 32 -bit word 8 positions to the right and fills the vacated bit positions with the sign bit (D31 from the input data).

CONTROL SIGNALS

| SHIFT <br> INSTRUCTION <br> M2-MO | NUMBER OF BITS <br> TO SHIFT <br> SFT4-SFTO |
| :---: | :---: |
| 11 | 11000 |

Assume D31-DO is hex ABCD0123.
D31-D0
Input Data

$$
10101011110011010000000100100011
$$

## absolute maximum ratings over operating temperature range (unless otherwise noted)

| Supply voltage, VCC1 |  | V |
| :---: | :---: | :---: |
| Supply voltage, VCC2 |  | 3 |
| Input voltage |  | 7 V |
| Operating case temperature range: | SN54AS8838 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| Operating free-air temperature range: | SN74AS8838 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $-65^{\circ} \mathrm{C}$ to $150^{\circ}$ |

## recommended operating conditions

| PARAMETER |  | SN54AS8838 |  |  | SN74AS8838 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC} 1}$ | 1/O supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{CC} 2}$ | STL internal logic supply voltage | 1.9 | 2 | 2.1 | 1.9 | 2 | 2.1 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| IOH | High-level output current |  |  | -1 |  |  | 2.6 | mA |
| IOL | Low-level output current |  |  | 12 |  |  | 24 | mA |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature | -55 |  |  | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |
| TC | Operating case temperature |  |  | 125 |  |  |  | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN54AS8838 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP ${ }^{\dagger}$ MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{I}=-18 \mathrm{~mA}$ |  | -1.2 | $\checkmark$ |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\text {CCI }}=4.5 \mathrm{~V}$ to 5.5 V . | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | V |
|  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$. | $\mathrm{IOH}^{\prime}=-1 \mathrm{~mA}$ | 2.4 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=12 \mathrm{~mA}$ |  | 0.4 | V |
|  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $1 \mathrm{OL}=24 \mathrm{~mA}$ |  |  |  |
| IOZH | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  | 20 | $\mu \mathrm{A}$ |
| 'OZL | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -0.4 | mA |
| 1 | $\mathrm{V}_{\text {CCi }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  | 0.1 | mA |
| IIH | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  | 20 | $\mu \mathrm{A}$ |
| IL | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -0.4 | mA |
| $10^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | mA |
| ICC1 | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$ |  |  | 150 | mA |
| ICC2 | $\mathrm{V}_{\text {CC2 }}=2.1 \mathrm{~V}$ |  |  | 145 | mA |

switching characteristics over recommended operating temperature range (see Note 1)

| PARAMETER | FROM (INPUT) | T0 (OUTPUT) | $$ | UNIT |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN TYP ${ }^{\text {d }}$ MAX |  |
| ${ }^{t} \mathrm{pd}$ | MUX1-MUXO | Y31-Y0 | 22 | ns |
|  | SFT4-SFTO | Y31-Y0 | 22 |  |
|  | D31-D0 | Y31-Y0 | 22 |  |
| ${ }^{\text {t }}$ n | YOEL | Y15.Y0 | 12 | ns |
|  | YOEM | Y31-Y16 | 12 |  |
| ${ }^{\text {d }}$ dis | YOEL | Y15-Y0 | 6 | ns |
|  | YOEM | Y31-Y16 | 6 |  |

${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
$\ddagger$ The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, los. NOTE 1: For load circuit and voltage waveforms, see pages 1-12 of The TTL Data Book, Volume 3, 1984.

## 32-BIT BARREL SHIFTERS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | SN74AS8838 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX |  |
| $V_{\text {IK }}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{\text {CC1 }}=4.5 \mathrm{~V}$ to 5.5 V , | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  | v |
|  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{I}^{\mathrm{OH}}=-1 \mathrm{~mA}$ |  |  |  |
|  | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{IOH}^{\prime}=-2.6 \mathrm{~mA}$ | 2.4 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC} 1}=4.5 \mathrm{~V}$, | $\mathrm{IOL}^{\prime}=12 \mathrm{~mA}$ |  | 0.4 | V |
|  | $\mathrm{V}_{\text {CC1 }}=4.5 \mathrm{~V}$. | $\mathrm{I}^{\mathrm{OL}}=24 \mathrm{~mA}$ |  | 0.5 |  |
| IOZH | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.7 \mathrm{~V}$ |  | 20 | $\mu \mathrm{A}$ |
| IozL | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -0.4 | mA |
| 1 | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=7 \mathrm{~V}$ |  | 0.1 | mA |
| $1 / \mathrm{H}$ | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  | 20 | $\mu \mathrm{A}$ |
| ILL | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -0.4 | mA |
| $10^{\ddagger}$ | $\mathrm{V}_{\mathrm{CC} 1}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\mathrm{O}}=2.25 \mathrm{~V}$ | -30 | -112 | mA |
| ICC1 | $\mathrm{V}_{\text {CC1 }}=5.5 \mathrm{~V}$ |  |  | 150 | mA |
| ICC2 | $\mathrm{VCC2}=2.1 \mathrm{~V}$ |  |  | 145 | mA |

${ }^{\ddagger}$ The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, Ios.
switching characteristics (see Note 1)

| PARAMETER | FROM (INPUT) | то (OUTPUT) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{R} 1=500 \Omega \\ & \mathrm{R} 2=500 \Omega \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$SN74AS8838 |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{C}_{\mathrm{L}}= \\ & \mathrm{R} 1= \\ & \mathrm{R}_{2}= \\ & \mathrm{T}_{\mathrm{A}}= \end{aligned}$ | $3.5 \mathrm{~V} \text {, }$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  |
|  |  |  | MIN | TYP | MAX | MIN | MAX |  |
| ${ }^{\text {t }} \mathrm{pd}$ | MUX1-MUXO | Y31-Y0 |  | 22 | 26 |  | 29 | ns |
|  | SFT4-SFTO | Y31-Y0 |  | 20 | 22 |  | 25 |  |
|  | D31-D0 | Y31-Y0 |  | 22 | 26 |  | 29 |  |
| $t_{\text {en }}$ | YOEL | Y15-Y0 |  | 12 | 15 |  | 17 | ns |
|  | YOEM | Y31-Y16 |  | 12 | 15 |  | 17 |  |
| $\mathrm{t}_{\text {dis }}$ | YOEL | Y15-Y0 |  | 6 | 8 |  | 10 | ns |
|  | YOEM | Y31-Y16 |  | 6 | 8 |  | 10 |  |

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

- High-Speed 8-Bit Parallel Output Register
- Serial Shadow Register with Right-Shift Only
- 'ALS29818 Performs Parallel-to-Serial and Serial-to-Parallel Conversion
- Designed Specifically for Use in Applications such as:

Write Control Store ('ALS29818)
Serial Shadow-Register Diagnostics

- 'ALS29819 Provides Even-Parity Output
- Low Power Dissipation . . . 215 mW Typical
- 'ALS29818 is Functionally Equivalent to AMD AM29818
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

The 'ALS29818 and 'ALS29819 are 8-bit output registers with on-chip shadow register for use in applications such as write control store and shadow register diagnostics.

The output registers of the 'ALS29818 and 'ALS29819 are loaded in parallel from either the I/O port (DQO-DO7) or the shadow register. The shadow register of the 'ALS29818 is loaded serially from either the I/O port (YO-Y7) or the output register. The 'ALS29819 shadow register is loaded serially from the I/O port (DQ0-DQ7). In addition, the 'ALS29819 provides a ParityEven (PE) output, which monitors parity of the output register. Operation of these devices is controlled by the Mode and SDI inputs as shown in the function table.

The SN54ALS29818 and SN54ALS29819 are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74ALS29818 and SN74ALS29819 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
SN54ALS29818 . . . JT PACKAGE SN74ALS29818 . . . DW OR NT PACKAGE (TOP VIEW)

SN54ALS29818 . . . FK PACKAGE
SN74ALS29818 . . . FN PACKAGE
(TOP VIEW)

SN54ALS29819 . . . JT PACKAGE SN74ALS29819 . . . DW OR JT PACKAGE (TOP VIEW)

| PE | $\left.\mathrm{U}_{24}\right] \mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: |
| SRCLK ${ }^{2}$ | ${ }^{23} \mathrm{M}$ MODE |
| DQo ${ }^{3}$ | 22.7 Yo |
| DQ1 ${ }^{4}$ | 21.151 |
| DO2 ${ }^{5}$ | $20] \mathrm{Y} 2$ |
| D03 ${ }^{6}$ | 19 Y 3 |
| D04 ${ }^{\text {Cl }}$ | ${ }_{18} \mathrm{Y}_{4}$ |
| DO5 ${ }^{8}$ | ${ }_{17} \mathrm{Y}^{1}$ |
| 006 0 | ${ }_{16} \mathrm{Y} Y$ |
| 007 10 | 15 Y7 |
| Sol-11 | 14 SDO |
| GND 12 | 13 Orclk |

SN54ALS29819 . . . FK PACKAGE SN74ALS29819 . . . FN PACKAGE
(TOP VIEW)


NC-No internal connection
'ALS29818 FUNCTION TABLE

| INPUTS |  |  |  |  | OUTPUT AND I/O |  |  | OPERATION OR FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MODE | $\overline{\text { OEY }}$ | SDI | SRCLK | ORCLK | SDO | YO-Y7 | DQ0-DQ7 |  |
| L | X | X | $\dagger$ | X | SR7 | - | HI-Z | Serial input, shift right, disable DQO-DQ7 |
| H | H | L | $\uparrow$ | X | SDI | INPUT | HI-Z | Parallel load shadow register from YO-Y7, disable DQO-DQ7 |
| H | L | L | $\dagger$ | No ¢ | SDI | OUTPUT | HI-Z | Parallel load shadow register from output register, disable DQ0-DQ7 |
| L | X | x | X | $\uparrow$ | SR7 | - | INPUT ${ }^{\dagger}$ | Load output register from DQ0-DQ7 |
| L | X | X | $\uparrow$ | $\dagger$ | SR7 | - | INPUT ${ }^{\dagger}$ | Load output register from DQO-DO7 while shifting shadow register |
| H | X | x | No $\uparrow$ | $\dagger$ | SDI | - | - | Load output register from shadow register |
| H | X | X | X | X | SDI | - | - | Serial data in to serial data out |
| H | L | L | $\uparrow$ | $\dagger$ | SDI | OUTPUT | HI-Z | Exchange data between registers, DQ0-DQ7 disabled |
| H | X | H | X | X | SDI | - | - | Hold shadow register, transitions on SRCLK do not effect shadow register |
| H | X | H | $\dagger$ | X | SDI | - | OUTPUT | Enable DOO-DO7 for parallel shadow register output |

${ }^{\dagger}$ The DQO-DQ7 outputs must be disabled before applying data to DQ0-DQ7.

- ALS29819 FUNCTION TABLE

| INPUTS |  |  |  | OUTPUT AND I/O |  |  | OPERATION OR FUNCTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MODE | SDI | SRCLK | ORCLK | SDO | $\begin{gathered} \hline \mathrm{Y} 0-\mathrm{Y7} \\ \mathrm{PE} \\ \hline \end{gathered}$ | DO0-DO7 |  |
| L | X | $\dagger$ | X | SR7 | OUTPUT | HI-Z | Serial input, shift right |
| H | L | $\dagger$ | X | $\begin{aligned} & \hline \text { SDI } \\ & \text { (L) } \end{aligned}$ | OUTPUT | INPUT | Parallel load shadow register from DO0-DO7 |
| H | L | $\uparrow$ | $\uparrow$ | $\begin{aligned} & \hline \text { SDI } \\ & \text { (L) } \\ & \hline \end{aligned}$ | OUTPUT | INPUT | Parallel load shadow register and output register from DOO-DQ7 |
| $\begin{aligned} & \mathrm{L} \\ & \mathrm{X} \end{aligned}$ | $\begin{aligned} & \hline X \\ & L \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & \uparrow \\ & \uparrow \end{aligned}$ | SR7 | OUTPUT | INPUT | Load output register from DQ0-DQ7 |
| L | X | $\dagger$ | $\uparrow$ | SR7 | OUTPUT | INPUT | Load output register from DOO-DQ7 while shifting shadow register |
| H | H | No † | $\uparrow$ | $\begin{aligned} & \hline \text { SDI } \\ & (\mathrm{H}) \\ & \hline \end{aligned}$ | OUTPUT | OUTPUT | Load output register from shadow register |
| H | X | X | X | SDI | OUTPUT | - | Serial data in to serial data out |
| H | H | X. | X | $\begin{aligned} & \hline \text { SDI } \\ & (H) \end{aligned}$ | OUTPUT | OUTPUT <br> HOLD | Hold shadow register, enable DOO-DO7, transitions on SRCLK ignored |
| $\begin{aligned} & \mathrm{L} \\ & \mathrm{X} \end{aligned}$ | $x$ | $\begin{aligned} & \mathrm{X} \\ & \mathrm{x} \end{aligned}$ | $\begin{aligned} & \mathrm{x} \\ & \mathrm{x} \end{aligned}$ | - | OUTPUT | HI-Z | Disable DQ0-DQ7 outputs |

## SN54ALS29818, SN54ALS29819 SN74ALS29818, SN74ALS29819 8-BIT DIAGNOSTICS/PIPELINE REGISTERS

logic symbols ${ }^{\dagger}$

'ALS29818
'ALS29819

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

SN54ALS29818, SN54ALS29819
SN74ALS29818, SN74ALS29819
8-BIT DIAGNOSTICS/PIPELINE REGISTERS
logic diagrams (positive logic)

'ALS29818 gate-level logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## 8-BIT DIAGNOSTICS/PIPELINE REGISTERS

'ALS29819 gate-level logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.
'ALS29819 gate-level logic diagram (positive logic) (continued)


Pin numbers shown are for DW, JT, and NT packages.

## absolute maximum ratings over operating free-air temperature range


recommended operating conditions

${ }^{\dagger}$ This setup time ensures that the shadow register will see stable data from the output register.
${ }^{\ddagger}$ This setup time ensures that the output register will see stable data from the shadow register.

## SN54ALS29818, SN54ALS29819 <br> SN74ALS29818, SN74ALS29819 8-BIT DIAGNOSTICS/PIPELINE REGISTERS

electrical characteristics over recommended operating temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  | SN54ALS29818 SN54ALS29819 |  |  | SN74ALS29818 SN74ALS29819 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}_{1}=18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| V OH | All outputs | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$ to MAX, | $\mathrm{IOH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}-2}$ |  |  | V |
|  | YO-Y7 | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{IOH}^{\mathrm{O}}=-3 \mathrm{~mA}$ | 2.4 | 3.2 |  | 2.43 |  |  |  |
|  | All others | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}^{\mathrm{OH}}=-1 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| VOL | All outputs | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{IOL}^{\prime}=4 \mathrm{~mA}$ |  | 0.25 | 0.5 |  | 0.25 | 0.5 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
|  | YO-Y7 | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{IOL}=16 \mathrm{~mA}$ |  | 0.25 | 0.5 |  | 0.25 | 0.5 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{IOL}=24 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| 1 | MODE | $V_{C C}=M A X$, | $V_{1}=5.5 \mathrm{~V}$ |  |  | 0.4 |  |  | 0.4 | mA |
|  | SRCLK |  |  |  |  | 0.3 |  |  | 0.3 |  |
|  | SDI, $\overline{\mathrm{OEY}}$. |  |  |  |  | 0.2 |  |  | 0.2 |  |
|  | All others |  |  |  |  | 0.1 |  |  | 0.1 |  |
| $\mathrm{I}_{\mathrm{H}}$ | MODE | $V_{C C}=$ MAX, | $\mathrm{V}_{1}=2.4 \mathrm{~V}$ |  |  | 80 |  |  | 80 | $\mu \mathrm{A}$ |
|  | SRCLK |  |  |  |  | 60 |  |  | 60 |  |
|  | SDI, $\overline{O E Y}$ |  |  |  |  | 40 |  |  | 40 |  |
|  | All others ${ }^{\text {® }}$ |  |  |  |  | 20 |  |  | 20 |  |
| ILL | MODE | $V_{C C}=\operatorname{MAX}, \quad V_{1}=0.5 \mathrm{~V}$ |  |  |  | -0.4 |  |  | -0.4 | mA |
|  | SRCLK |  |  |  |  | -0.3 |  |  | -0.3 |  |
|  | SDI, $\overline{\mathrm{OEY}}$ |  |  |  |  | -0.2 |  |  | -0.2 |  |
|  | All others ${ }^{\text {§ }}$ |  |  |  |  | -0.1 |  |  | -0.1 |  |
| los ${ }^{1}$ |  | $V_{C C}=$ MAX, | $\mathrm{V}_{0}=0$ | -75 |  | -250 | -75 |  | -250 | mA |
| ICC |  | $V_{C C}=M A X$ | (see Note 1) | 43 |  |  | 43 |  |  | mA |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use appropriate value specified under recommended operating conditions.
$\ddagger$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
${ }^{5}$ For $\mathrm{I} / \mathrm{O}$ ports, the parameters $\mathrm{I}_{\mathrm{H}}$ and $\mathrm{I}_{\mathrm{L}}$ include the off-state output current.
I Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second. NOTE 1: ICC is measured with all three-state outputs in the high-impedance state.
'ALS29818 switching characteristics (see Note 2)

| PARAMETER |  | $\begin{gathered} \text { FROM } \\ \text { (INPUT) } \end{gathered}$ | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & C_{L}=50 \mathrm{pF} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & { }^{\prime} \mathrm{ALS} 29818 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & C_{L}=50 \mathrm{pF}, \\ & T_{A}=\text { MIN TO MAX } \dagger \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | SN |  |  |  |  |  | 818 | SN | 318 |  |
|  |  | MIN |  |  | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{+}$max | SRCLK |  |  |  |  |  | 37 |  |  |  |  |  | MHz |
|  | ORCLK |  |  |  |  |  | 37 |  |  |  |  |  |  |
| tPLH |  | MODE | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 8 |  |  |  |  |  | ns |  |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  | 8 |  |  |  |  |  |  |  |
| ${ }^{\text {t PLH }}$ |  | SDI | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 8 |  |  |  |  |  | ns |  |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  | 8 |  |  |  |  |  |  |  |
| tPLH |  | ORCLK | YO-Y7 | $\begin{aligned} & \text { R1 }=1 \mathrm{k} \Omega, \\ & \text { R2 }=280 \Omega \end{aligned}$ |  | 9 |  |  |  |  |  | ns |  |
| tPHL |  |  |  |  |  | 9 |  |  |  |  |  |  |  |
| tPLH |  | SRCLK | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 13 |  |  |  |  |  | ns |  |
| tPHL |  |  |  |  |  | 13 |  |  |  |  |  |  |  |
| tPLH |  | SRCLK | D00-D07 | $\begin{aligned} & \text { R1 }=5 \mathrm{k} \Omega, \\ & \mathrm{R} 2=2 \mathrm{k} \Omega \end{aligned}$ |  |  |  |  |  |  |  | ns |  |
| ${ }^{\text {P PHL }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |
| tPZH |  | SRCLK | D00-D07 | $\begin{aligned} & \mathrm{R} 1=5 \mathrm{k} \Omega, \\ & \mathrm{R} 2=2 \mathrm{k} \Omega \end{aligned}$ |  | 16 |  |  |  |  |  | ns |  |
| tPZL |  |  |  |  |  | 19 |  |  |  |  |  |  |  |
| tPHZ |  | SRCLK | D00-D07 | $\begin{aligned} & R 1=5 \cdot \mathrm{k} \Omega, \\ & R 2=2 \mathrm{k} \Omega \end{aligned}$ |  | 16 |  |  |  |  |  | ns |  |
| tPLZ |  |  |  |  |  | 19 |  |  |  |  |  |  |  |
| tPHZ |  | $\overline{\mathrm{OEY}}$ | Y0-Y7 | $\begin{aligned} & \text { R1 }=1 \mathrm{k} \Omega, \\ & \text { R2 }=280 \Omega \end{aligned}$ |  | 7 |  |  |  |  |  | ns |  |
| tPLZ |  |  |  |  |  | 10 |  |  |  |  |  |  |  |
| tPZH |  | $\overline{\mathrm{OEY}}$ | YO-Y7 | $\begin{aligned} & R 1=1 \mathrm{k} \Omega, \\ & R 2=280 \Omega \end{aligned}$ |  | 6 |  |  |  |  |  | ns |  |
| tPZL |  |  |  |  |  | 9 |  |  |  |  |  |  |  |

[^49]'ALS29819 switching characteristics (see Note 2)

| PARAMETER |  | FROM (INPUT) | ro (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS29819} \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\text { MIN TO MAX, }{ }^{\dagger} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \\ & \mathrm{~T}_{\mathrm{A}}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | SN54ALS29819 |  |  |  |  |  | SN74ALS29819 |  |  |
|  |  | MIN |  |  | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {fax }}$ | SRCLK |  |  |  |  |  | 37 |  |  |  |  |  | MHz |
|  | ORCLK |  |  |  |  |  | 37 |  |  |  |  |  |  |
| tple |  | MODE | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 8 |  |  |  |  |  | ns |  |
| ${ }^{\text {tPHL }}$ |  |  |  |  |  | 8 |  |  |  |  |  |  |  |
| tplH |  | SDI | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 8 |  |  |  |  |  | ns |  |
| tPHL |  |  |  |  |  | 8 |  |  |  |  |  |  |  |
| tPLH |  | ORCLK | YO-Y7 | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 9 |  |  |  |  |  | ns |  |
| ${ }_{\text {tPHL }}$ |  |  |  |  |  | 9 |  |  |  |  |  |  |  |
| tPLH |  | ORCLK | PE | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 9 |  |  |  |  |  | ns |  |
| tPHL |  |  |  |  |  | 5 |  |  |  |  |  |  |  |
| tpi |  | SRCLK | SDO | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ |  | 13 |  |  |  |  |  | ns |  |
| $\mathrm{t}_{\mathrm{PHL}}$ |  |  |  |  |  | 13 |  |  |  |  |  |  |  |
| tPLH |  | SRCLK | DQ0-D07 | $\begin{aligned} & \mathrm{R} 1=5 \mathrm{k} \Omega . \\ & \mathrm{R} 2=2 \mathrm{k} \Omega \\ & \hline \end{aligned}$ |  | 12 |  |  |  |  |  | ns |  |
| tPHL |  |  |  |  |  | 12 |  |  |  |  |  |  |  |
| tpZH |  | $\begin{aligned} & \hline \text { MODE } \\ & \text { or SDI } \end{aligned}$ | D00-D07 | $\begin{aligned} & \text { R1 }=5 \mathrm{k} \Omega, \\ & \text { R2 }=2 \mathrm{k} \Omega \end{aligned}$ |  | 7 |  |  |  |  |  | ns |  |
| tPZL |  |  |  |  |  | 9 |  |  |  |  |  |  |  |
| ${ }^{\text {tphz }}$ |  | MODE or SDI | D00-007 | $\begin{aligned} & \mathrm{R} 1=5 \mathrm{k} \Omega, \\ & \mathrm{R} 2=2 \mathrm{k} \Omega \end{aligned}$ |  | 7 |  |  |  |  |  | ns |  |
| tplZ |  |  |  |  |  | 9 |  |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

## PARAMETER MEASUREMENT INFORMATION


switch position table

| TEST | S1 | S2 |
| :---: | :---: | :---: |
| tPLH | Closed | Closed |
| tPHL | Closed | Closed |
| tPZH | Open | Closed |
| tPZL | Closed | Open |
| tPHZ | Closed | Closed |
| tPLZ | Closed | Closed |

LOAD CIRCUIT FOR
THREE-STATE OUTPUTS


NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- Functionally Equivalent to AMD's AM29821 and AM29822
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Outputs Have Undershoot Protection Circuitry
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Carriers in Addition to Plastic and Ceramic DIPs
- Buffered Control Inputs to Reduce DC Loading Effects
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit flip-flops feature three-state outputs designed specifically for driving highlycapacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.
The ten flip-flops are edge-triggered D-type flipflops. On the positive transition of the clock the Q outputs on the 'ALS29821 will be true, and on the 'ALS29822 will be complementary to the data input.
A buffered output-control ( $\overline{\mathrm{OC}}$ )input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. In the high-impedance state the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the highimpedance state.
The SN54'family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


SN54ALS29821, SN74ALS29821
10-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTS
'ALS29821 FUNCTION TABLE (EACH FLIP-FLOP)

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\mathbf{O C}$ | CLK | $\mathbf{D}$ | $\mathbf{Q}$ |
| $\mathbf{L}$ | $\uparrow$ | $H$ | $H$ |
| $L$ | $\uparrow$ | $L$ | $L$ |
| $L$ | $L$ | $X$ | $Q_{O}$ |
| $H$ | $X$ | $X$ | $Z$ |

'ALS29821 logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS29821 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.
'ALS29822 FUNCTION TABLE (EACH FLIP-FLOP)

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\overline{\text { OC }}$ | CLK | $\bar{D}$ | Q |
| L | $\uparrow$ | H | L |
| L | $\uparrow$ | L | H |
| L | L | $X$ | $Q_{0}$ |
| $H$ | $X$ | $X$ | $Z$ |

'ALS29822 logic symbol ${ }^{\dagger}$
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
'ALS29822 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54AS29821, SN54AS29822, SN74AS29821, SN74AS29822 10-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
$\qquad$
Input vóltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Voltage applied to a disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Input current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 100 mA
Output current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 30 mA to 5 mA
Operating free-air temperature range: SN54ALS29821, SN54ALS29822........ $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS29821, SN74ALS29822 . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range
$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$

## recommended operating conditions

|  |  | SN54ALS29821 <br> SN54ALS29822 |  |  | SN74ALS29821 <br> SN74ALS29822 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{C C}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| ${ }^{\mathrm{I}} \mathrm{OH}$ | High-level output current |  |  | -15 |  |  | -24 | mA |
| ${ }_{\mathrm{I}}^{\mathrm{OL}}$ | Low-level output currrent |  |  | 32 |  |  | 48 | mA |
| ${ }_{\text {t }}$ w | Pulse duration, CLK high or low |  |  |  |  |  |  | ns |
| $t_{\text {su }}$ | Setup time, data before CLK $\uparrow$ |  |  |  |  |  |  | ns |
| th | Hold time, data after CLK $\uparrow$ |  |  |  |  |  |  | ns |
| $T_{\text {A }}$ | Operating free-air temperature | $-55$ |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^50]Additional information on these products can be obtained from the factory as it becomes available.

## switching characteristics

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & \hline V_{C C}=5 \mathrm{~V}, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline \text { 'ALS29821 } \\ & \text { 'ALS29822 } \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\text { MIN TO MAX, }{ }^{\dagger} \\ & \mathrm{T}_{\mathbf{A}}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN54ALS29821 SN54ALS29822 |  | SN74ALS29821 <br> SN74ALS29822 |  |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | CLK | Any 0 | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  |  |  |
| tPLH |  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 6 |  |  |  |  |  |  |
| tPHL |  |  |  |  | 7 |  |  |  |  |  |  |
| tPZH | $\overline{O C}$ | Any 0 | $C_{L}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPZL |  |  |  |  |  |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 12 |  |  |  |  |  |  |
| tpZL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{OC}}$ | Any 0 | $C_{L}=50 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPLZ |  |  |  |  |  |  |  |  |  |  |  |
| tPHZ |  |  | $C_{L}=5 \mathrm{pF}$ |  | 5 |  |  |  |  |  |  |
| tplZ |  |  |  |  | 6 |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

Additional information on these products can be obtained from the factory as it becomes available.

## PARAMETER MEASUREMENT INFORMATION


SWITCH POSITION TABLE

| TEST | S 1 | S2 |
| :---: | :---: | :---: |
| tPLH | Closed | Closed |
| ${ }^{\text {tPHL }}$ | Closed | Closed |
| ${ }^{\text {tPZH }}$ | Open | Closed |
| ${ }^{\text {t P P L }}$ | Closed | Open |
| ${ }^{\text {t PHZ }}$ | Closed | Closed |
| tPLZ | Closed | Closed |

## LOAD CIRCUIT



Voltage waveforms
SETUP AND HOLD TIMES

VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES


VOLTAGE WAVEFORMS PULSE DURATIONS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- Functionally Equivalent to AMD's AM29823 and AM29824
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Outputs Have Undershoot Protection Circuitry
- Power-Up High-Impedance State
- Buffered Control Inputs to Reduce DC Loading Effects
- Package Options Include both Plastic and Ceramic Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 9-bit flip-flops feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, parity bus interfacing and working registers.
With the clock enable ( $\overline{C L K E N}$ ) low, the nine $D$ type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking CLKEN high will disable the clock buffer, thus latching the outputs. The 'ALS29823 has noninverting $D$ inputs and the 'ALS29824 has inverting $D$ inputs. Taking the $\overline{C L R}$ input low causes the nine $Q$ outputs to go low independently of the clock.
A buffered output-control input ( $\overline{\mathrm{OC}}$ ) can be used to place the nine outputs in either normal logic state (high or low level) or a high-impedance state. In the high-impedance state the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the highimpedance state.


SN54ALS29823 . . . FK PACKAGE SN74ALS29823 . . . FN PACKAGE (TOP VIEW)


SN54ALS29824 . . . JT PACKAGE SN74ALS29824 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{O C} \square^{1}$ | $\mathrm{U}_{24}$ | $\mathrm{V}_{C C}$ |
| :---: | :---: | :---: |
| 1可 2 | 23 | 10 |
| $2 \overline{\mathrm{D}}{ }^{3}$ | 22 | 20 |
| $3 \overline{\mathrm{D}} \mathrm{C}_{4}$ | 21 | 30 |
| 4 $\overline{\text { - }} 5$ | 20 | 40 |
| $5 \overline{\mathrm{D}} \mathrm{C}^{6}$ | 19 | 50 |
| $6 \overline{0} \square^{7}$ | 18 | 60 |
| $7 \overline{0}$ | 17 | 770 |
| $8 \overrightarrow{\mathrm{D}} \mathrm{C}$ | 16 | 80 |
| $9 \overline{\mathrm{D}}$-10 | 15 | 190 |
| $\overline{\text { CLR }} 11$ | 14 | $\square \overline{C L K E N}$ |
| GND 12 | 13 | CLK |

SN54ALS29824 . . . FK PACKAGE
SN74ALS29824 . . . FN PACKAGE
(TOP VIEW)


SN54ALS29823, SN54ALS29824, SN74ALS29823, SN74ALS29824

## 9-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

The SN54AS' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74AS' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
'ALS29823 FUNCTION TABLE

|  |  | INPUTS |  | OUTPUT |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { OC }}$ | $\overline{\text { CLR }}$ | $\overline{\text { CLKEN }}$ | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | $\uparrow$ | H | H |
| L | H | L | $\uparrow$ | L | L |
| L | H | H | X | X | $Q_{O}$ |
| H | X | X | X | X | Z |

'ALS29823 logic symbol ${ }^{\dagger}$
'ALS29823 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

| ALS29824 FUNCTION TABLE |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|       <br>  INPUTS   OUTPUT  <br> $\overline{\text { OC }}$ $\overline{\text { CLR }}$ $\overline{\text { CLKEN }}$ CLK $\overline{\text { D }}$ O <br> L L X X X L <br> L H L $\uparrow$ H L <br> L H L $\uparrow$ L H <br> L H H X X Q $_{0}$ <br> H X X X X Z |  |  |  |  |  |

'ALS29824 logic symbol ${ }^{\dagger}$

$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
'ALS29824 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS29823, SN54ALS29824, SN74ALS29823, SN74ALS29824

 9-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTSabsolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage, VCC |  |  |
| :---: | :---: | :---: |
| Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 l |  |  |
| Voltage applied to a disabled 3-state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V |  |  |
| Input current |  | 100 mA |
| Output current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . - 30 mA to 5 mA |  |  |
| Operating free-air temperature range: | SN54ALS29823, SN54ALS29824 | $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
|  | SN74ALS29823, SN74ALS29824 | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range |  |  |

recommended operating conditions

|  |  |  | SN54ALS29823 SN54ALS29824 |  |  | SN74ALS29823SN74ALS29824 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{IOH}^{\text {I }}$ | High-level output current |  |  |  | -15 |  |  | -24 | mA |
| 1 OL | Low-level output current |  |  |  | 32 |  |  | 48 | mA |
| $t_{w}$ | Pulse duration | $\overline{\text { CLR }}$ low |  |  |  |  |  |  | ns |
|  |  | CLK high or low |  |  |  |  |  |  |  |
| $\mathrm{t}_{\text {su }}$ | Setup time before CLK $\uparrow$ | $\overline{\mathrm{CLR}}$ inactive |  |  |  |  |  |  | ns |
|  |  | Data |  |  |  |  |  |  |  |
|  |  | $\overline{\text { CLKEN }}$ high or low |  |  |  |  |  |  |  |
| $t_{h}$ | Hold time, CLKEN or data after CLK $\dagger$ |  |  |  |  |  |  |  | ns |
| $\mathrm{T}_{\mathrm{A}}$ | Operating free-air temperature |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^51]Additional Information on these products can be obtained from the factory as it becomes available.

## SN54ALS29823, SN54ALS29824, SN74ALS29823, SN74ALS29824 9-BIT BUS INTERFACE FLIP.FLOPS WITH 3-STATE OUTPUTS

## switching characteristics

| PARAMETER | $\begin{array}{\|l} \text { FROM } \\ \text { (INPUT) } \end{array}$ | TO (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS29823} \\ & \prime \text { ALS29824 } \end{aligned}$ |  |  | $\begin{aligned} V_{C C} & =\text { MIN TO MAX, } \\ T_{A} & =\text { MIN TO MAX } \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN5 |  |  | $823$ |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tPLH }}$ | CLK | Any 0 | $C_{L}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  |  |  |
| tpLH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 5.5 |  |  |  |  |  |  |
| tPHL |  |  |  |  | 6.5 |  |  |  |  |  |  |
| tpHL | $\overline{C L R}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 13 |  |  |  |  |  | ns |
| tPZH | $\overline{\mathrm{OC}}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPZL |  |  |  |  |  |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | . 12 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{OC}}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPLZ |  |  |  |  |  |  |  |  |  |  |  |
| tpHz |  |  | $C_{L}=5 \mathrm{pF}$ |  | 5 |  |  |  |  |  |  |
| tPLZ |  |  |  |  | 5.5 |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

Additional information on these products can be obtained from the factory as it becomes available.

## D flip-flop signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type flip-flop and to draw its logic symbol based on the assumption of true data ( $D$ ) inputs. Then outputs that produce data in phase with the data inputs are called $Q$ and those producing complementary data are called $Q$. An input that causes a $Q$ output to go high or a $Q$ output to go low is called Preset; an input that causes a $Q$ output to go high or a Q output to go low is called Clear. Bars are used over these pin names (PRE and CLR) if they are active-low.

The devices on this data sheet are second-source designs and the pin-name convention used by the original manufacturer has been retained. That makes it necessary to designate the inputs and outputs of the inverting circuit $D$ and $Q$. In some applications it may be advantageous to redesignate the inputs and outputs as D and Q . In that case, outputs should be renamed as shown below. Also shown are corresponding changes in the graphical symbol. Arbitrary pin numbers are shown in parentheses.

Notice that Q and Q exchange names, which causes Preset and Clear to do likewise. Also notice that the polarity indicators ( $\triangle$ ) on PRE and CLR remain since these inputs are still active-low, but that the presence or absence of the polarity changes at $D, Q$, and $Q$. Of course pin $5(Q)$ is still in phase with the data input $D$, but now both are considered active high.


PARAMETER MEASUREMENT INFORMATION
SWITCH POSITION TABLE

| TEST | S1 | S2 |
| :---: | :---: | :---: |
| $t^{\text {PLHH }}$ | Closed | Closed |
| $\mathrm{t}_{\mathrm{PHL}}$ | Closed | Closed |
| $\mathrm{t}_{\mathrm{P} Z \mathrm{H}}$ | Open | Closed |
| $\mathrm{t}_{\mathrm{PZL}}$ | Closed | Open |
| $\mathrm{t}_{\mathrm{PHZ}}$ | Closed | Closed |
| $\mathrm{t}_{\mathrm{PLZ}}$ | Closed | Closed |

LOAD CIRCUIT


VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES


VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES
HIGH-LEVEL
PULSE
LOW-LEVEL PULSE

VOLTAGE WAVEFORMS PULSE DURATIONS


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega$, $\mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- Functionally Equivalent to AMD's AM29825 and AM29826
- Improved IOH Specifications
- Multiple Output Enables Allow Multiuser Control of the Interface
- Outputs Have Undershoot Protection Circuitry
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Buffered Control Inputs to Reduce DC Loading Effect
- Dependable Texas Instruments Quality and Reliability


## description

These 8-bit flip-flops feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing multiuser registers, I/O ports, bidirectional bus drivers, and working registers.
With the clock enable ( $\overline{\mathrm{CLKEN}}$ ) low, the eight D type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking CLKEN high will disable the clock buffer, thus latching the outputs. The 'ALS29825 has noninverting $D$ inputs and the 'ALS29826 has inverting $\bar{D}$ inputs. Taking the $\overline{C L R}$ input low causes the eight O outputs to go low independently of the clock.
Multiuser buffered output-control inputs ( $\overline{\mathrm{OC}} 1$, $\overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ ) can be used to place the eight outputs in either a normal logic state /high or low level) or a high-impedance state. In the highimpedance state the outputs neither load nor drive the bus lines significantly. The highimpedance state and increased drive provide the capability to drive the bus lines in a busorganized system without need for interface or pull-up components. The output controls do not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.


SN54ALS29825 . . FK PACKAGE SN74ALS29825 . . . FN PACKAGE
(TOP VIEW)


SN54ALS29826 . . . JT PACKAGE
SN74ALS29826 . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{\mathrm{OC}} 1 \square^{1}$ | $\mathrm{U}_{24}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| $\overline{\mathrm{OC}} 2 \mathrm{C}_{2}$ | 23 | OC3 |
| 1可 ${ }^{3}$ | 22 | 10 |
| 2可 ${ }^{4}$ | 21 | 120 |
| $3 \overline{\mathrm{D}} \mathrm{O}^{5}$ | 20 | ] 30 |
| 4 $\overline{\mathrm{D}}$ - 6 | 19 | 40 |
| 50.7 | 18 | 50 |
| 6 D - | 17 | 160 |
| 70. ${ }^{\text {a }}$ | 16 | 70 |
| 80̄ ${ }^{\text {¢ }}$ | 15 | 80 |
| $\overline{C L R}{ }^{11}$ | 14 | CLKEN |
| GND 12 | 13 | $\square \mathrm{CLK}$ |

SN54ALS29826 . $\quad$. FK PACKAGE SN74ALS29826 . . . FN PACKAGE (TOP VIEW)


NC - No internal connection

The SN54'family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$.
The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
'ALS29825 FUNCTION TABLE

| INPUTS |  |  |  |  | OUTPUT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { OC}}$ | $\overline{\text { CLR }}$ | $\overline{\text { CLKEN }}$ | CLK | D | $\mathbf{Q}$ |
| L | L | X | X | X | L |
| L | H | L | $\uparrow$ | $H$ | $H$ |
| L | $H$ | L | $\uparrow$ | L | L |
| L | $H$ | $H$ | $X$ | $X$ | $Q_{O}$ |
| $H$ | $X$ | $X$ | $X$ | $X$ | $Z$ |

$\overline{\mathrm{OC}}^{*}=\mathrm{H}$ if any of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, or $\overline{\mathrm{OC}} 3$ is high.
$\overline{\mathrm{OC}}{ }^{*}=\mathrm{L}$ if all of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ are low.
'ALS29825 logic symbol ${ }^{\dagger}$
${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12
Pin numbers shown are for DW, JT, and NT packages.
'ALS29825 logic diagram (positive logic)


Pin numbers are for DW, JT, and NT packages.

| INPUTS |  |  |  |  | $\begin{gathered} \text { OUTPUT } \\ 0 \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\mathrm{OC}}$ * | $\overline{C L R}$ | CLKEN | CLK | $\overline{\mathrm{D}}$ |  |
| L | L | X | X | X | L |
| L | H | L | $\uparrow$ | H | L |
| L | H | L | $\dagger$ | L | H |
| L | H | H | x | x | $\mathrm{O}_{0}$ |
| H | X | X | X | X | z |

$\overline{\mathrm{OC}} *=\mathrm{H}$ if any of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, or $\overline{\mathrm{OC}} 3$ is high.
$\overline{\mathrm{OC}}^{*}=\mathrm{L}$ if all of $\overline{\mathrm{OC}} 1, \overline{\mathrm{OC}} 2$, and $\overline{\mathrm{OC}} 3$ are low.
'ALS29826 logic symbol ${ }^{\dagger}$

${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers are for DW, JT, and NT packages.
'ALS29826 logic diagram (positive logic)


Pin numbers shown are for DW, JT, and NT packages.
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V

Voltage applied to a disabled 3 -state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Input current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 100 mA
Output current .................................................................. . . -30 mA to 5 mA
Operating free-air temperature range:
SN54ALS29825, SN54ALS29826 . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$

SN74ALS29825, SN74ALS29826 . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 65 to $150^{\circ} \mathrm{C}$

## 8-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

recommended operating conditions

|  |  |  |  | $\begin{aligned} & \text { 4ALS2S } \\ & \text { 4ALS2 } \end{aligned}$ |  | SN | $\begin{aligned} & \text { 4ALS2! } \\ & \text { 4ALS2 } \end{aligned}$ | $\begin{aligned} & 825 \\ & 826 \\ & \hline \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{C C}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  |  | 0.8 |  |  | 0.8 | $\checkmark$ |
| ${ }^{\mathrm{I} \mathrm{OH}}$ | High-level output current |  |  |  | -15 |  |  | -24 | mA |
| ${ }^{\mathrm{OL}}$ | Low-level output current |  |  |  | 32 |  |  | 48 | mA |
|  |  | CLR low |  |  |  |  |  |  |  |
| $t_{w}$ | Pulse duration | CLK high |  |  |  |  |  |  | ns |
|  |  | CLK low |  |  |  |  |  |  |  |
|  |  | $\overline{C L R}$ inactive |  |  |  |  |  |  |  |
| $\mathrm{t}_{\text {su }}$ | Setup time before CLK $\uparrow$ | Data |  |  |  |  |  |  | ns |
|  |  | CLKEN high or low |  |  |  |  |  |  |  |
|  |  | Data |  |  |  |  |  |  |  |
| th | Hold time, data after CLK | CLKEN |  |  |  |  |  |  | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperat |  | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  | SN54ALS29825 <br> SN54ALS29826 |  |  | SN74ALS29825 <br> SN74ALS29826 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\ddagger}$ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ |  |  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1{ }_{1}=-18 \mathrm{~mA}$ |  |  | -1.2 |  |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{OH}}$ |  | $V_{C C}=$ MIN to MAX, | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{Cc}}{ }^{-2}$ |  |  | V |
|  |  | $V_{C C}=\mathrm{MIN}$, | $\mathrm{IOH}^{\text {O }}$ - 15 mA | 2.43 .3 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{I}_{\mathrm{OH}}=-24 \mathrm{~mA}$ |  |  |  | 2.4 | 3.2 |  |  |
| V OL |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $1 \mathrm{OL}=32 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{IOL}^{\prime}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| ${ }^{1} \mathrm{OZH}$ |  | $\mathrm{V}_{C C}=\mathrm{MAX}$, | $\mathrm{V}_{\mathrm{O}}=2.4 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IOZL |  | $V_{C C}=M A X$, | $\mathrm{V}_{0}=0.4 \mathrm{~V}$ |  |  | -20 |  |  | -20 | $\mu \mathrm{A}$ |
| $1 /$ |  | $V_{C C}=M A X$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 0.1 |  |  | 0.1 | mA |
| IIH |  | $V_{C C}=M A X$, | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
| IIL |  | $V_{C C}=M A X$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
| $\mathrm{lOS}^{5}$ |  | $V_{C C}=M A X$, | $\mathrm{V}_{0}=0$ | -75 |  | -250 | -75 |  | -250 | mA |
| ${ }^{\text {I CC }}$ | 'ALS29825 | $V_{C C}=\mathrm{MAX}$ | Outputs high |  |  |  |  |  |  | mA |
|  |  |  | Outputs low |  |  |  |  |  |  |  |
|  |  |  | Outputs disabled |  | 48 |  |  | 48 |  |  |
|  | 'ALS29826 |  | Outputs high |  |  |  |  |  |  |  |
|  |  |  | Outputs low |  |  |  |  |  |  |  |
|  |  |  | Outputs disabled | 48 |  |  | 48 |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
${ }^{\ddagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
${ }^{\S}$ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.
Additional information on these products can be obtained from the factory as it becomes available.

## switching characteristics

| PARAMETER | $\left\lvert\, \begin{gathered} \text { FROM } \\ \text { (INPUT) } \end{gathered}\right.$ | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \text { 'ALS29825 } \\ & \text { 'ALS29826 } \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & T_{A}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN5 | $\begin{aligned} & 825 \\ & 826 \\ & \hline \end{aligned}$ | SN7 | $\begin{aligned} & 825 \\ & 826 \\ & \hline \end{aligned}$ |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | CLK | Any 0 | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPHL |  |  |  |  |  |  |  |  |  |  |  |
| tPLH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 6 |  |  |  |  |  |  |
| tPHL |  |  |  |  | 7 |  |  |  |  |  |  |
| ${ }^{\text {tPHL }}$ | $\overline{\text { CLR }}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 13 |  |  |  |  |  | ns |
| tPZH | $\overline{\mathrm{OC}}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tPZL |  |  |  |  |  |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 12 |  |  |  |  |  |  |
| tpZL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{OC}}$ | Any 0 | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  |  |  |  |  |  |  | ns |
| tpLZ |  |  |  |  |  |  |  |  |  |  |  |
| tPHZ |  |  | $C_{L}=5 \mathrm{pF}$ |  | 5 |  |  |  |  |  |  |
| tPLZ |  |  |  |  | 6 |  |  |  |  |  |  |

$\dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

Additional information on these products can be obtained from the factory as it becomes available.

## D flip-flop signal conventions

It is normal TI practice to name the outputs and other inputs of a D-type flip-flop and to draw its logic symbol based on the assumption of true data (D) inputs. Then outputs that produce data in phase with the data inputs are called Q and those producing complementary data are called $\overline{\mathrm{Q}}$. An input that causes a $Q$ output to go high or a $\overline{\mathrm{Q}}$ output to go low is called Preset; an input that causes a $\overline{\mathrm{Q}}$ output to go high or a Q output to go low is called Clear. Bars are used over these pin names ( $\overline{\mathrm{PRE}}$ and $\overline{\mathrm{CLR}}$ ) if they are active-low.

The devices on this data sheet are second-source designs and the pin-name convention used by the original manufacturer has been retained. That makes it necessary to designate the inputs and outputs of the inverting circuit $\overline{\mathrm{D}}$ and Q . In some applications it may be advantageous to redesignate the inputs and outputs as D and $\overline{\mathrm{Q}}$. In that case, outputs should be renamed as shown below. Also shown are corresponding changes in the graphical symbol. Arbitrary pin numbers are shown in parentheses.

Notice that Q and $\overline{\mathrm{Q}}$ exchange names, which causes Preset and Clear to do likewise. Also notice that the polarity indicators ( $\triangle$ ) on PRE and CLR remain since these inputs are still active-low, but that the presence or absence of the polarity changes at $\overline{\mathrm{D}}, \mathrm{Q}$, and $\overline{\mathrm{Q}}$. Of course pins $5(Q)$ is still in phase with the data input D , but now both are considered active high.



## 8-BIT BUS INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

## PARAMETER MEASUREMENT INFORMATION




VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES

HIGH-LEVEL PULSE

LOW-LEVEL PULSE


VOLTAGE WAVEFORMS PULSE DURATIONS


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: A. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
$C$. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- Functionally Equivalent to AM29827 and AM29828
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- P-N-P Inputs Reduce D-C Loading
- Data Flow-Thru Pinout (All Inputs on Opposite Side from Outputs)
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit buffers and bus drivers provide high-performance bus interface for wide data paths or busses carrying parity.
The three-state control gate is a 2 -input NOR such that if either $\overline{\mathrm{G} 1}$ or $\overline{\mathrm{G} 2}$ is high, all ten outputs are in the high-impedance state.
The 'ALS29827 provides true data and the 'ALS29828 provides inverted data at the outputs.

The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.


SN54ALS' . . . FK PACKAGE SN74ALS' . . . FN PACKAGE (TOP VIEW)


SN54ALS29827, SN54ALS29828
SN74ALS29827, SN74ALS29828

## 10-BIT BUFFERS AND BUS DRIVERS WITH 3-STATE OUTPUTS

## logic symbols ${ }^{\dagger}$



${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
logic diagrams (positive logic)


Pin numbers shown are DW, JT, and NT packages.

## SN54ALS29827, SN54ALS29828 SN74ALS29827, SN74ALS29828 10-BIT BUFFERS AND BUS DRIVERS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Voltage applied to a disabled 3 -state output . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54ALS29827, SN54ALS29828 .....: $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ SN74ALS29827, SN74ALS29828 . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^52]
## SN54ALS29827, SN54ALS29828 <br> SN74ALS29827, SN74ALS29828 <br> 10-bIT BUFFERS AND BUS DRIVERS WITH 3.STATEE OUTPUTS

## switching characteristics

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS29827} \\ & ' A L S 29828 \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & T_{A}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN5 | $\begin{aligned} & 827 \\ & 828 \end{aligned}$ |  | $\begin{aligned} & 827 \\ & 828 \end{aligned}$ |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | Min | MAX |  |
| tPLH | A | Y | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  | 8 |  |  |  |  |  | ns |
| tpHL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPLH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 5 |  |  |  |  |  |  |
| tPHL |  |  |  |  | 5 |  |  |  |  |  |  |
| tPZH | $\overline{\mathrm{G}}$ | Y | $C_{L}=300 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPZL |  |  |  |  | 18 |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 7 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 10 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{G}}$ | Y | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPLZ |  |  |  |  | 5 |  |  |  |  |  |  |
| tphz |  |  | $C_{L}=5 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tPLZ |  |  |  |  | 4 |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
Additional information on these products can be obtained from the factory as it becomes avalable.

## SN54ALS29827, SN54ALS29828 <br> SN74ALS29827, SN74ALS29828 10-BIT BUFFERS AND BUS DRIVERS WITH 3-STATE OUTPUTS

## PARAMETER MEASUREMENT INFORMATION


SWITCH POSITION TABLE

| TEST | S1 | S2 |
| :---: | :---: | :---: |
| ${ }^{\text {tPLH }}$ | Closed | Closed |
| ${ }^{\text {t}} \mathrm{PHL}$ | Closed | Closed |
| ${ }^{\text {tPZH }}$ | Open | Closed |
| ${ }^{\text {tPZL }}$ | Closed | Open |
| ${ }^{\text {tPHZ }}$ | Closed | Closed |
| $t^{\text {tPLZ }}$ | Closed | Closed |



VOLTAGE WAVEFORMS SETUP AND HOLD TIMES


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS
A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- Functionally Equivalent to AM29861 and AM29862
- Choice of True or Inverting Logic
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 10-bit bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic levels at the enable inputs ( $\overline{\mathrm{G}} \mathrm{BA}$ and $\overline{\mathrm{G}} \mathrm{AB}$ ).

The enable inputs can be used to disable the device so that the buses are effectively isolated.
The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

FUNCTION TABLE

| INPUTS |  | OPERATION |  |
| :---: | :---: | :---: | :---: |
| $\bar{G} A B$ | $\bar{G} B A$ | ALS29861 | ALS29862 |
| L | H | A to $B$ | $\bar{A}$ to $B$ |
| $H$ | L | B to $A$ | $\bar{B}$ to $A$ |
| $H$ | $H$ | Isolation | Isolation |
| L | L | Latch $A$ and $B$ | Latch $A$ and $B$ |
|  |  | $(A=B)$ | $(A=\bar{B})$ |

SN54ALS' . . . FK PACKAGE SN74ALS' . . . FN PACKAGE (TOP VIEW)


NC-No internal connection

SN54ALS29861, SN54ALS29862
SN74ALS29861, SN74ALS29862

## 10-BIT BUS TRANSCEIVERS WITH 3.STATE OUTPUTS

## logic symbols ${ }^{\dagger}$

'ALS29861

'ALS29862

$\dagger$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, JT, and NT packages.
logic diagrams
'ALS29861

'ALS29862


Pin numbers shown are for DW, JT, and NT packages.

## SN54ALS29861, SN54ALS29862

SN74ALS29861, SN74ALS29862

## 10-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC
Input voltage: All inputs and I/O ports 5.5 V
Operating free-air temperature range:
SN54ALS29861, SN54ALS29862 ...... $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS29861, SN74ALS29862 . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range
$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  |  |  | 4ALS2S | $\begin{aligned} & 1861 \\ & 1862 \end{aligned}$ |  | 74ALS: | $\begin{aligned} & 9861 \\ & 9862 \end{aligned}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| 1 OH | High-level output current |  |  | -15 |  |  | -24 | mA |
| IOL | Low-level output current |  |  | 32 |  |  | 48 | mA |
| TA | Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)


[^53]'ALS29861 switching characteristics

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline \text { 'ALS29861 } \end{aligned}$ |  |  | $\begin{aligned} & V_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & T_{A}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN54ALS29861 |  | SN74ALS29861 |  |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | A or B | B or A | $C_{L}=300 \mathrm{pF}$ |  | 8 |  |  |  |  |  | ns |
| tpHL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPLH |  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 5 |  |  |  |  |  |  |
| tpHL |  |  |  |  | 5 |  |  |  |  |  |  |
| tPZH | $\begin{gathered} \overline{\mathrm{G}} A B \\ \text { or } \\ \overline{\mathrm{G}} \mathrm{BA} \end{gathered}$ | $A$ or $B$ | $C_{L}=300 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPZL |  |  |  |  | 17 |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 7 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 10 |  |  |  |  |  |  |
| tphz | $\overline{\mathrm{G}} \mathrm{AB}$ or GBA | $A$ or B | $C_{L}=50 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPLZ |  |  |  |  | 5 |  |  |  |  |  |  |
| tPHZ |  |  | $C_{L}=5 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| ${ }_{\text {t PLZ }}$ |  |  |  |  | 4 |  |  |  |  |  |  |

## 'ALS29862 switching characteristics

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V}, \\ & T_{A}=25^{\circ} \mathrm{C} \\ & \hline{ }^{\prime} \mathrm{ALS} 29862 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & T_{A}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN54ALS29862 |  | SN74ALS29862 |  |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | A or B | B or A | $C_{L}=300 \mathrm{pF}$ |  | 7 |  |  |  |  |  | ns |
| tPHL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPLH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tpHL |  |  |  |  | 5 |  |  |  |  |  |  |
| tPZH | $\begin{gathered} \overline{\mathrm{G}} A B \\ \text { or } \\ \overline{\mathrm{G}} \mathrm{BA} \end{gathered}$ | $A$ or B | $C_{L}=300 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPZL |  |  |  |  | 17 |  |  |  |  |  |  |
| tpZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 7 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 10 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{G}} \mathrm{AB}$ or GBA | $A$ or B | $C_{L}=50 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPLZ |  |  |  |  | 5 |  |  |  |  |  |  |
| tPHZ |  |  | $C_{L}=5 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tPLZ |  |  |  |  | 4 |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

Additional information on these products can be obtained from the factory as it becomes available.

## 10-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

PROMAMETER MEASUREMENT INFORMATION


VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
enable and disable times, three-state outputs

NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, Z_{0}=50 \Omega, t_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5$ ns.

FIGURE 1

- Functionally Equivalent to AM29863 and AM29864
- Choice of True or Inverting Logic
- Power-Up High-Impedance State
- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability


## description

These 9-bit bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing.

These devices allow data transmission from the A bus to the $B$ bus or from the $B$ bus to the $A$ bus depending upon the logic levels at the enable inputs ( $\overline{\mathrm{G}} \mathrm{BA} 1, \overline{\mathrm{G}} \mathrm{BA} 2, \overline{\mathrm{G}} \mathrm{AB} 1$, and $\overline{\mathrm{G}} \mathrm{AB} 2$ ).

The SN54' family is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The SN74' family is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

SN54ALS' . . . JT PACKAGE
SN74ALS' . . . DW OR NT PACKAGE (TOP VIEW)

| $\overline{\mathrm{G}} \mathrm{BA} 1 \square^{1}$ | $\cup_{24}$ | $\mathrm{V}_{\mathrm{CC}}$ |
| :---: | :---: | :---: |
| A1 2 | 23 | B1 |
| A2 3 | 22 | B2 |
| A3 $\square^{4}$ | 21 | В3 |
| A4 5 | 20 | B4 |
| A5 6 | 19 | B5 |
| A6 $\square^{7}$ | 18 | B6 |
| A7 $\square_{8}^{8}$ | - 17 | B7 |
| A8 $\square^{9}$ | 16 | 88 |
| A9 10 | 15 | B9 |
| GBA2 $\square_{11}$ | 14 | ḠAB2 |
| GND-12 | 13 | ḠAB1 |

SN54ALS' . . FK PACKAGE SN74ALS' . . . FN PACKAGE (TOP VIEW)


NC - No internal connection

FUNCTION TABLE

| ENABLE INPUTS |  |  |  | OPERATION |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { GAB1 }}$ | $\overline{\text { GAB2 }}$ | $\overline{\text { GBA1 }}$ | $\overline{\text { GBA2 }}$ | 'ALS29863 | ALS29864 |
| L | L | L | L | Latch A and B | Latch A and B |
| L | L | H | X | A to B | A to $\bar{B}$ |
| L | L | X | H |  |  |
| H | X | L | L | B to A | B to $\bar{A}$ |
| X | $H$ | L | L |  |  |
| H | X | H | X |  | Isolation |
| H | X | X | H | Isolation |  |
| X | H | X | H |  |  |
| X | H | H | X |  |  |

## 9-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

## logic symbols ${ }^{\dagger}$

'ALS29863

${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
logic diagrams
'ALS29863


'ALS29864


Pin numbers shown are for DW, JT, and NT packages.

# SN54ALS29863, SN54ALS29864 <br> SN74ALS29863, SN74ALS29864 9-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS 

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 7 V
Input voltage: All inputs and I/O ports . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 5.5 V
Operating free-air temperature range: SN54ALS29863, SN54ALS29864 . . . . . . $55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
SN74ALS29863, SN74ALS29864 . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
recommended operating conditions

|  | SN54ALS29863 SN54ALS29864 |  |  | SN74ALS29863 SN74ALS29864 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $V_{C C}$ Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ High-level input voltage | 2 |  | , | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }} \quad$ Low-level input voltage |  |  | 0.8 |  |  | 0.8 | V |
| $\mathrm{I}^{\mathrm{OH}} \quad$ High-level output current |  |  | -15 |  |  | -24 | mA |
| IOL Low-level output current |  |  | 32 |  |  | 48 | mA |
| $\mathrm{T}_{\text {A }}$ Operating free-air temperature | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS ${ }^{\dagger}$ |  | SN54ALS29863 <br> SN54ALS29864 |  |  | SN74ALS29863 SN74ALS29864 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\ddagger}$ | MAX | MIN | TYP ${ }^{\text { }}$ | MAX |  |
| $\mathrm{V}_{\mathrm{IK}}$ |  |  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  |  | $-1.2$ |  |  | -1.2 | V |
| VOH |  | $\mathrm{V}_{\mathrm{CC}}=$ MIN to MAX, | $1 \mathrm{OH}=-0.4 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | $\mathrm{V}_{\mathrm{CC}}-2$ |  |  | V |
|  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{IOH}^{\prime}=-15 \mathrm{~mA}$ | 2 |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\text {CC }}=\mathrm{MIN}$, | $\mathrm{IOH}=-24 \mathrm{~mA}$ |  |  |  | 2 |  |  |  |
| $\mathrm{V}_{\text {OL }}$ |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $1 \mathrm{OH}=-32 \mathrm{~mA}$ |  | 0.25 | 0.4 |  | 0.25 | 0.4 | V |
|  |  | $\mathrm{V}_{C C}=\mathrm{MIN}$, | $\mathrm{I}_{\mathrm{OL}}=48 \mathrm{~mA}$ |  |  |  |  | 0.35 | 0.5 |  |
| II |  | $\mathrm{V}_{C C}=\mathrm{MAX}$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  |  |  |  |  | mA |
| ${ }^{1} \mathrm{H}$ | Control inputs | $V_{C C}=$ MAX , | $\mathrm{V}_{\mathrm{l}}=2.7 \mathrm{~V}$ |  |  | 20 |  |  | 20 | $\mu \mathrm{A}$ |
|  | A or B ports ${ }^{\text {s }}$ |  |  |  |  | 20 |  |  | 20 |  |
| IIL | Control inputs | $V_{C C}=M A X$, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  |  | -0.1 |  |  | -0.1 | mA |
|  | A or B ports ${ }^{\text {§ }}$ |  |  |  |  | -0.1 |  |  | -0.1 |  |
| los 1 |  | $V_{C C}=M A X$, | $\mathrm{V}_{0}=0$ | -75 | -250 |  | -75 |  | -250 | mA |
| ${ }^{\text {I C C }}$ |  | $V_{C C C}=$ MAX | Outputs high |  | 26 |  |  | 26 |  | mA |
|  | 'ALS29863 |  | Outputs low |  | 35 |  |  | 35 |  |  |
|  |  |  | Outputs disabled |  | 34 |  |  | 34 |  |  |
|  | -ALS29864 |  | Outputs high |  | 20 |  |  | 20 |  |  |
|  |  |  | Outputs low |  | 27 |  |  | 27 |  |  |
|  |  |  | Outputs disabled |  | 26 |  |  | 26 |  |  |

[^54]
## 9-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

'ALS29863 switching characteristics

| PARAMETER | FROM (INPUT) | то (OUTPUT) | TEST CONDITIONS See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \text { ALS29863 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{C C}=\operatorname{MIN} \text { TO MAX, }{ }^{\dagger} \\ & T_{A}=\operatorname{MIN} \text { TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  | 363 | SN7 | 863 |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tpLH | A or B | B or A | $C_{L}=300 \mathrm{pF}$ |  | 8 |  |  |  |  |  | ns |
| ${ }_{\text {t }}$ PHL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPLH |  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 5. |  |  |  |  |  |  |
| tPHL |  |  |  |  | 5 |  |  |  |  |  |  |
| tPZH | $\begin{gathered} \overline{\mathrm{G}} \mathrm{AB} \\ \text { or } \\ \overline{\mathrm{G}} \mathrm{BA} \end{gathered}$ | A or B | $\mathrm{C}_{\mathrm{L}}=300 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPZL |  |  |  |  | 17 |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 7 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 10 |  |  |  |  |  |  |
| tPHZ | $\overline{\mathrm{G}} \mathrm{AB}$ or $\overline{\mathrm{G}} \mathrm{BA}$ | $A$ or B | $C_{L}=50 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPLZ |  |  |  |  | 5 |  |  |  |  |  |  |
| tPHZ |  |  | $C_{L}=5 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tPLZ |  |  |  |  | 4 |  |  |  |  |  |  |

'ALS29864 switching characteristics

| PARAMETER | FROM (INPUT) | ro (OUTPUT) | TEST CONDITIONS <br> See Figure 1 | $\begin{aligned} & V_{C C}=5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \text { ALS29864 } \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{V}_{C C}=\text { MIN TO MAX, }{ }^{\dagger} \\ & \mathrm{T}_{\mathbf{A}}=\text { MIN TO MAX }{ }^{\dagger} \end{aligned}$ |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | SN54ALS29864 |  | SN74ALS29864 |  |  |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| tPLH | $A$ or B | $B$ or A | $C_{L}=300 \mathrm{pF}$ |  | 7 |  |  |  |  |  | ns |
| tPHL |  |  |  |  | 11 |  |  |  |  |  |  |
| tPLH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tPHL |  |  |  |  | 5 |  |  |  |  |  |  |
| tPZH | $\overline{\mathrm{G}} \mathrm{AB}$ or GBA | $A$ or B | $C_{L}=300 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tPZL |  |  |  |  | 17 |  |  |  |  |  |  |
| tPZH |  |  | $C_{L}=50 \mathrm{pF}$ |  | 7 |  |  |  |  |  |  |
| tPZL |  |  |  |  | 10 |  |  |  |  |  |  |
| tpHz | $\overline{\mathrm{G}} \mathrm{AB}$ or GBA | $A$ or $B$ | $C_{L}=50 \mathrm{pF}$ |  | 11 |  |  |  |  |  | ns |
| tplZ |  |  |  |  | 5 |  |  |  |  |  |  |
| tphz |  |  | $C_{L}=5 \mathrm{pF}$ |  | 4 |  |  |  |  |  |  |
| tplz |  |  |  |  | 4 |  |  |  |  |  |  |

${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

Additional information on these products can be obtained from the factory as it becomes available.

## PARAMETER MEASUREMENT INFORMATION




VOLTAGE WAVEFORMS SETUP AND HOLD TIMES


VOLTAGE WAVEFORMS PULSE DURATIONS


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega$, $\mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.

FIGURE 1

- 16-Bit by 16-Bit Parallel Multiplication/Accumulation
- 35-Bit-Wide Accumulator
- Inputs are TTL-Voltage Compatible
- Outputs Capable of Driving up to 10 LSTTL Loads
- Single 5-V Power Supply
- Low Power Dissipation . . . 150 mW Typical
- Pin-for-Pin Compatible with TRW TDC1010J (DIP only) and AM29510 (DIP only)
- High-Speed Twin-Well CMOS Process
- Package Options Include Ceramic and Plastic Chip Carriers and DIPs
- Dependable Texas Instruments Quality and Reliability


## description

The THCT1010 is a TTL-voltage-compatible, low-power, high-speed 16 -bit by 16 -bit multiplier/accumulator for digital signal processing, digital filters, fast Fourier transformations, array processing, and microprocessor throughput enhancement. These devices are pin-for-pin equivalent to the TRW TDC1010J but dissipate 20 times less power. The lower power dissipation causes the differences between junction and ambient temperatures to be minimized and, therefore, eliminates the heat-sink requirements and increases reliability. High speed is achieved by using a modified Booth algorithm, a feed-forward carry circuit, and a conditional sum adder that enhances the final adder stage of the multiplier.

The THCT1010 inputs consist of three registers, a 16-bit $X$ input, a 16-bit $Y$ input, and an input control register. The 35 -bit output product register consists of a 16-bit most-significantproduct (MSP) bus, a 16-bit least-significantproduct (LSP) bus that is shared with the 16 -bit Y input bus, and a 3-bit extended-product (XTP) bus (PR32 through PR34); see the functional block diagram. The input registers are

JD OR N DUAL-IN-LINE PACKAGE
(TOP VIEW)

| $\times 6 \square 1$ | $1 \cup_{64}$ | 17 |
| :---: | :---: | :---: |
| $\times 5 \square 2$ | 263 | $\square \times 8$ |
| $\times 4 \square^{3}$ | $3 \quad 62$ | ] $\times 9$ |
| $\times 3 \square 4$ | 461 | $] \times 10$ |
| $\times 2 \square 5$ | 560 | $\times 11$ |
| $\times 1$-6 | $6 \quad 59$ | ] 12 |
| $\times 0 \square$ | $7 \quad 58$ | $\times 13$ |
| YOIPRO 8 | $8 \quad 57$ | $7 \times 14$ |
| Y1/PR1 $\square^{9}$ | 956 | ] 15 |
| Y2/PR2 $\square_{10}$ | 1055 | ] $\overline{\text { OELS }}$ |
| Y3/PR3 $\square_{11}^{11}$ | 1154 | RND |
| Y4/PR4 12 | $12 \quad 53$ | SUB |
| Y5/PR5 $\square^{13}$ | $13 \quad 52$ | ACC |
| Y6/PR6 14 | $14 \quad 51$ | ] CLK $X$ |
| Y7/PR 7 -15 | $15 \quad 50$ | CLK Y |
| GND $\square 16$ | $16 \quad 49$ | ] CCC |
| Y8/PR8 17 | $17 \quad 48$ | ] TC |
| Y9/PR9 18 | $18 \quad 47$ | $\overline{O E X}$ |
| Y10/PR10 $\square_{19}$ | 1946 | PREL |
| Y11/PR11 20 | $20 \quad 45$ | $\overline{\text { OEMS }}$ |
| Y12/PR12 ${ }^{\text {Y }}$ | 2144 | CLK PR |
| Y13/PR13 ${ }^{\text {Y }} 22$ | $22 \quad 43$ | PR34 |
| Y14/PR14 ${ }^{\text {Y }}$ 23 | $23 \quad 42$ | PR33 |
| Y15/PR15 24 | $24 \quad 41$ | PR32 |
| PR16 25 | $25 \quad 40$ | PR31 |
| PR17 26 | $26 \quad 39$ | 1 PR 30 |
| PR18 27 | $27 \quad 38$ | PR29 |
| PR19 28 | $28 \quad 37$ | ] PR28 |
| PR20 29 | 2936 | PR27 |
| PR21 30 | $30 \quad 35$ | PR26 |
| PR22 31 | $31 \quad 34$ | ] PR25 |
| PR23 32 | $32 \quad 33$ | ] PR24 |

FK OR FN CHIP-CARRIER PACKAGE
(TOP VIEW)


음
웅
웅



NC - No internal connection

Caution. These devices have limited built-in gate protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.
independently controlled by CLK $X$ and CLK $Y$, and the product registers are D-type positive-edge-triggered flip-flops. Separate three-state output enables are provided for each output product register. These, in combination with the independent input clocks, allow operation on a microprocessor bus.
The THCT1010 has a round control (RND) that rounds the product to the 19 most significant bits. The preload control (PREL) is used in conjunction with the output enables to initialize the contents of the output registers. The THCT1010 will perform multiplication and addition, multiplication and subtraction, or straight multiplication depending upon the states of the accumulate control (ACC) and subtractor control (SUB). The TC control provides the capability of formatting the input data to be either two's complement or unsigned magnitude.

The THCT1010-160M is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The THCT1010-140E is characterized for operation from $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$. The THCT1010-100 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

| PIN |  | DESCRIPTION |
| :---: | :---: | :---: |
| No. | Name |  |
| 56-64, 1-7 | X15 thru X0 | $X$ data inputs, $X 15$ is the most-significant bit. The data is loaded into the $X$ register on the rising edge of CLKX. |
| 8-15, 17-24 | $\begin{gathered} \text { YO/PRO } \\ \text { thru } \\ \text { Y15/PR15 } \end{gathered}$ | I/O ports for least significant product (LSP) bits of output product register, input ports for Y data. YO/PRO is the least significant bit. The mode is controlled by the PREL and OEMS pins. |
| 25-43 | PR16 thru PR34 | I/O ports for output product register bits. PR16 through PR31 are the most-significant product (MSP) bits. PR32 through PR34 are the extended product (XTP) bits. The mode is controlled by PREL, $\overline{\mathrm{OELS}}, \overline{\mathrm{OEX}}$. |
| 44 | CLK PR | Product clock input. On the low-to-high transition, latches the LSP, MSP, and XTP into the output product register. |
| 45 | OEMS | Active-low output enable for MSP output product register. When high, causes the PR31 through PR16 outputs to be in the high-impedance state. |
| 46 | PREL | Preload control. When high, the output product register's outpúts are disabled. When an output enable ( $\overline{\mathrm{OELS}}, \overline{\mathrm{OEMS}}, \overline{\mathrm{OEX}}$ ) is high, preload data can be entered into the output product register from the PR I/O lines on the rising edge of CLK PR. |
| 47 | OEX | Active-low output enable for XTP output product register. When high, causes the PR32 through PR34 outputs to be in the high-impedance state. |
| 48 | TC | Two's complement control. When TC is high, the input data is in two's complement format. When TC is low, the input data is in unsigned magnitude format. The TC signal is loaded into the control register on the rising edge of CLK X or CLK Y. |
| 50 | CLK Y | $Y$ clock input. On the low-to-high transition, clocks data in from the Y inputs. |
| 51 | CLK X | X clock input. On the low-to-high transition, clocks data in from the X inputs. |
| 52 | ACC | Accumulator control. When ACC is high and SUB is low, the content of the output product register is added to the next product generated. The sum is then placed in the output product register on the rising edge of CLK PR. When ACC is low, the product is stored directly into the output register on the rising edge of CLK PR. The ACC signal is loaded into the control register at the rising edge of CLK X or CLK Y. |
| 53 | SUB | Subtraction control. When SUB and ACC are high, the content of the output product register is subtracted from the next product generated. The result is then placed in the output product register on the rising edge of CLK PR. When SUB is low and ACC is high, the addition operation is performed instead of subtraction. When ACC is low, SUB is a "Don't Care". The SUB signal is loaded into the control register on the rising edge of CLK X or CLK Y. |
| 54 | RND | Round control. When high, causes the product of the $X$ and $Y$ inputs to be rounded to the 19 most significant bits by adding a 1 to the MSB of the LSP. The RND signal is loaded into the control register on the rising edge of CLK X or CLK Y. |
| 55 | $\overline{\text { OELS }}$ | Active-low output enable for LSP output product register. When high, causes the PRO through PR15 outputs to be in the high-impedance state. |

Pin numbers shown are for the JD and $N$ packages.
 output pins will be loaded into the output register on the rising edge of CLK PR.
logic symbol


Pin numbers shown are for the JD and N packages.

## logic diagram (positive logic)



Pin numbers shown are for the JD and N packages.

## absolute maximum ratings over operating free-air temperature range ${ }^{\dagger}$

Supply voltage range, $\mathrm{V}_{\mathrm{CC}}$ -0.5 V to 7 V Input diode current, $\mathrm{I}_{\mathrm{K}}\left(\mathrm{V}_{\mathrm{I}}<0\right.$ or $\mathrm{V}_{\mathrm{I}}>\mathrm{V}_{\mathrm{CC}}$ )........... . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 20 \mathrm{~mA}$
Output diode current, IOK (VO 0 or $\mathrm{V}_{\mathrm{O}}>\mathrm{V}_{\mathrm{CC}}$ ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 20 \mathrm{~mA}$
Continuous output current, $\mathrm{IO}_{\mathrm{O}}\left(\mathrm{V}_{\mathrm{O}}=0\right.$ to $\mathrm{V}_{\mathrm{CC}}$ ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 25 \mathrm{~mA}$
Continuous current through VCC or GND pins . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 50 \mathrm{~mA}$
Lead temperature $1,6 \mathrm{~mm}\left(1 / 16\right.$ inch) from case for 60 seconds . . . . . . . . . . . . . . . . . . . . . $300^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
$\dagger$ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
recommended operating conditions

|  |  |  | THCT | 1010- | 60M | THC | 1010- | 140E | THC | T1010 | 100 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | NOM | MAX | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ | High-level input voltage | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | 2 |  |  | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | 0 |  | 0.8 | 0 |  | 0.8 | 0 |  | 0.8 | V |
| $V_{1}$ | Input voltage |  | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | 0 |  | $\mathrm{V}_{\text {CC }}$ | V |
| $\mathrm{V}_{\mathrm{O}}$ | Output voltage |  | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | 0 |  | VCC | 0 |  | VCC | V |
| $\mathrm{t}_{\mathrm{t}}$ | Input transition (rise and fall) times |  | 0 |  | 500 | 0 |  | 500 | 0 |  | 500 | ns |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -55 |  | 125 | -40 |  | 85 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

## THCT1010-160M, THCT1010-140E, THCT1010-100 16-BIT BY 16-BIT MULTIPLIERS/ACCUMULATORS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | VCC | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | THCT1010-160M |  | THCT1010-140E THCT1010-100 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{V}_{1}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }}, \mathrm{I}_{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 4.5 V | 4.4 |  |  | 4.4 |  | 4.4 |  | V |
|  | $\mathrm{V}_{1}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }}, \mathrm{IOH}^{\text {a }}=-4 \mathrm{~mA}$ | 4.5 V | 3.86 |  |  | 3.7 |  | 3.76 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{1}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }} \cdot \mathrm{I}_{\text {OL }}=20 \mu \mathrm{~A}$ | 4.5 V |  |  | 0.1 |  | 0.1 |  | 0.1 | V |
|  | $\mathrm{V}_{1}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }}, \mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA}$ | 4.5 V |  |  | 0.32 |  | 0.4 |  | 0.37 |  |
| $!$ | $V_{1}=0$ to $V_{C C}$ | 5.5 V |  | $\pm 5$ | $\pm 100$ |  | $\pm 1000$ |  | $\pm 1000$ | nA |
| IOZ | $V_{O}=V_{\text {CC }}$ or $0, V_{1}=V_{\text {IH }}$ or $V_{\text {IL }}$ | 5.5 V |  | $\pm 0.01$ | $\pm 0.5$ |  | $\pm 10$ |  | $\pm 5$ | $\mu \mathrm{A}$ |
| ${ }^{1} \mathrm{CC}^{\dagger}$ | $\mathrm{V}_{1}=\mathrm{V}_{\mathrm{CC}}$ or $0, \mathrm{l}_{\mathrm{O}}=0$ | 5.5 V |  |  | 0.75 |  | 2 |  | 1 | mA |
| $\mathrm{C}_{\mathrm{i}}$ |  | $\begin{gathered} 4.5 \mathrm{~V} \\ \text { to } \\ 5.5 \mathrm{~V} \end{gathered}$ |  | 3 | 10 |  | 10 |  | 10 | pF |

${ }^{\dagger}$ See Figure 4.
timing requirements over recommended operating free-air temperature range (unless otherwise noted) THCT1010-160M, THCT1010-140E

|  |  | $V_{\text {CC }}$ | $\mathrm{TA}_{\text {A }}=25^{\circ} \mathrm{C}$ |  | THCT1010-160M |  | THCT1010-140E |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $t_{w}$ | Pulse duration, clocks X and Y high or low | 4.5 V | 20 |  | 30 |  | 25 |  | ns |
|  |  | 5.5 V | 20 |  | 30 |  | 25 |  |  |
| $\mathrm{t}_{\mathrm{su}}$ | Setup time, $X$ input before CLK $X \uparrow$ or $Y$ input before CLK $Y \uparrow$ | 4.5 V | 10 |  | 30 |  | 25 |  | ns |
|  |  | 5.5 V | 10 |  | 30 |  | 25 |  |  |
| ${ }^{\text {th }}$ | Hold time, X input after CLK $\mathrm{X} \uparrow$ | 4.5 V | 6 |  | 12 |  | 10 |  | ns |
|  |  | 5.5 V | 6 |  | 12 |  | 10 |  |  |
| $t^{\prime}$ | Hold time, Y input after CLK $\mathrm{Y} \uparrow$ | 4.5 V | 1 |  | 7 |  | 5 |  | ns |
|  | or preload data after CLK PR $\uparrow$ | 5.5 V | 1 |  | 7 |  | 5 |  |  |

THCT1010-100

|  |  |  | $V_{C c}$ | $\mathrm{T}_{\text {A }}=25^{\circ} \mathrm{C}$ |  | THCT1010-100 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, clocks X and Y high or low |  |  | 4.75 V | 20 |  | 25 |  | ns |
| ${ }_{\text {t }}$ Su | Setup time, X input before CLK $\mathrm{X} \uparrow$ or Y input before CLK $\mathrm{Y} \uparrow$ |  | 4.75 V | 10 |  | 20 |  | ns |
| $t^{\prime}$ | Hold time | $X$ input after CLK $X \uparrow$ | 4.75 V | 6 |  | 10 |  | ns |
|  |  | Y input after CLK $\mathrm{Y} \uparrow$ or preload data after CLK PR $\uparrow$ | 4.75 V | 1 |  | 5 |  | ns |

switching characteristics over recommended operating free-air temperature range (unless otherwise noted), $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ (see Figure 3)
THCT1010-160M, THCT1010-140E

| PARAMETER |  | $V_{C C}$ | $T_{A}=25^{\circ} \mathrm{C}$ |  |  | THCT1010-160M |  | THCT1010-140E |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{t} \mathrm{pd}$ | Propagation delay time |  | 4.5 V |  | 45 |  |  | 65 |  | 55 | ns |
|  |  | 5.5 V |  |  |  |  | 60 |  | 50 |  |  |
| ten | Enable time | 4.5 V |  | 35 |  |  | 65 |  | 45 | ns |  |
|  |  | 5.5 V |  |  |  |  | 60 |  | 40 |  |  |
| ${ }^{\text {d }}$ dis | Disable time | 4.5 V |  | 35 |  |  | 60 |  | 45 | ns |  |
|  |  | 5.5 V |  |  |  |  | 55 |  | 40 |  |  |
| $t_{\text {mace }}$ | Multiply/accumulate time | 4.5 V |  | 100 |  |  | 160 |  | 140 | ns |  |
|  |  | 5.5 V |  |  |  |  | 140 |  | 120 |  |  |


| $\mathrm{C}_{\text {pd }}$ | Power dissipation capacitance | No load, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 750 pF typ |
| :--- | :--- | :--- | :--- |

THCT1010-100

|  |  | $V_{C C}$ | $T_{A}=25^{\circ} \mathrm{C}$ |  |  | THCT1010-100 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP ${ }^{\dagger}$ | MAX | MIN | MAX |  |
| ${ }^{\text {t }}$ pd | Propagation delay time |  | 4.75 V |  | 35 |  |  | 45 | ns |
| $\mathrm{t}_{\text {en }}$ | Enable time | 4.75 V |  | 30 |  |  | 40 | ns |
| $\mathrm{t}_{\text {dis }}$ | Disable time | 4.75 V |  | 30 |  |  | 40 | ns |
| $\mathrm{t}_{\text {macc }}$ | Multiply/accumulate time | 4.75 V |  | 90 |  |  | 100 | ns |

${ }^{\dagger}$ Typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$.

PARAMETER MEASUREMENT INFORMATION
TC, RND, ACC, SUB
 3 V

X INPUT
Y INPUT
 0 V


$\ddagger$ The measurement points for enable and disable times are as shown in Figure 2.
FIGURE 1. VOltage waverorms

## PARAMETER MEASUREMENT INFORMATION



NOTE: Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditons such that the output is high except when disabled by the output control.

FIGURE 2. DETAILED VOLTAGE WAVEFORMS FOR ENABLE AND DISABLE TIMES

${ }^{\dagger} C_{L}$ includes probe and test fixture capacitance

FIGURE 3. LOAD CIRCUITS

## TYPICAL CHARACTERISTICS



FIGURE 4

## THERMAL INFORMATION

THERMAL RESISTANCE

| PACKAGE | PINS | JUNCTION-TO-CASE THERMAL RESISTANCE, R RJC $\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ | JUNCTION-TO-FREE-AIR THERMAL RESISTANCE, R ${ }_{\theta J A}$ $\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| :---: | :---: | :---: | :---: |
| FK | 68 | 8 | 36 |
| FN | 68 |  |  |
| JD | 64 | 9 | 32 |
| N | 64 |  |  |

ORDERING INSTRUCTIONS
FN (Plastic leaded chip carrier)
JD (Ceramic DIP)
N (Plastic DIP)
5. Temperature Range

| M | $\ldots$ |
| ---: | :--- |
| E | $\ldots-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| (Blank) | $\ldots-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |  |

- Inputs are TTL- and CMOS-Voltage Compatible
- Interfaces Mechanical Devices to Data Bus
- Identifies and Measures Forward or Backward Rotation or Direction
- Measures Pulse Duration and Frequency
- Cascadable 16-Bit Up/Down Counter
- 8-Bit Parallel 3-State Bus with Each Output Capable of Driving up to 15 LSTTL Loads
- Dependable Texas Instruments Quality and Reliability


## description

The THCT2000 direction discriminator can determine the direction and displacement of a mechanical device based on input signals from two transducers in quadrature. It can also measure a pulse duration using a known clock rate, or a frequency over a known time interval. It includes a 16-bit counter, which can be used separately. Several of these devices may be cascaded to provide accuracy greater than 16-bits.

The device may be used in many diverse applications, and is specifically designed for use in many types of microprocessor-based systems. Some of the possibilities include motor controls, robotics, tracker balls (mice), lathe or tooling machines, automobiles, and conveyer belts or other transport mechanisms.

The THCT2000M is characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The THCT2OOOE is characterized for operation from $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$.


THCT2000M . . FK PACKAGE THCT2000E . . . FN PACKAGE (TOP VIEW)


THCT2000M, THCT2000E
DIRECTION DISCRIMINATORS

## logic symbol ${ }^{\dagger}$


${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984.
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functional block diagram


THCT2000M, THCT2000E DIRECTION DISCRIMINATORS

| PIN |  | DESCRIPTION |
| :---: | :---: | :---: |
| NAME | NUMBER |  |
| A, B | 20, 21 | Signal measurement inputs. |
| $\overline{\text { Bl }}$ | 26 | Cascade input for counting down. In mode $0, \overline{\mathrm{BI}}$ is used as the clock input for counting down. Triggering occurs on the high-to-low transition. |
| $\overline{\mathrm{BO}}$ | 12 | Counter output underflow signal. Active (low) for a duration equal to the low level of the input clock. |
| $\overline{\mathrm{Cl}}$ | 27 | Cascade input for counting up. In mode $0, \overline{\mathrm{Cl}}$ is used as the clock input for counting up. Triggering occurs on the high-to-low transition. |
| CLK | 22 | Clock input. Used for internal synchronization and control timing. |
| $\overline{\mathrm{Co}}$ | 13 | Counter output overflow signal. Active (low) for a duration equal to the low level of the input clock. |
| $\overline{\text { CS }}$ | 1 | Chip select input. This active-iow input is used to enable read and write functions. For additional details, see read and write timing diagrams. |
| D0-D7 | $\begin{gathered} 3,4,5,6, \\ 8,9,10,11 \end{gathered}$ | Counter load inputs/register output data lines. |
| GND | 7, 14 | Pins 7 and 14 are both internally connected to the ground rail of the integrated circuit but both should be connected to the system ground for proper operation. |
| LSB/MSB | 23 | Byte select input. During read operations, a high level selects the least significant byte, while a low level selects the most significant byte. For write operations, this input directs the data on the bus into the least significant or most significant byte position of the counter. See write timing diagrams for additional details. |
| M0, M1, M2 | 19, 18, 17 | Mode select inputs. |
| $\overline{\mathrm{RD}}$ | 2 | Read input. When active (low) in conjunction with $\overline{\mathrm{CS}}$ low, the data stored in the output register will be present on the data bus as selected by the LSB/MSB input. See read timing diagrams for additional details. |
| $\overline{\text { READY }}$ | 16 | Ready output. When active (low), this output indicates to the processor that it may complete the read or write operation. $\overline{\text { READY }}$ is synchronous with the negative-going edge of CLK. This output requires a pullup resistor ( $1 \mathrm{k} \Omega$ nominal). |
| RESET | 24 | Counter and control logic reset. When active (low), the counter is asynchronously reset to zero while the control logic is asynchronously initialized to the proper state as determined by the mode control inputs. The output register is not affected by RESET. |
| $\overline{\mathrm{RLI}} / \overline{\mathrm{RLO}}$ | 15 | Register load input/register load output (open drain). This pin can be used as an input to directly load the output register, or it can be used as an output to detect whenever the output register has been loaded. When used as an output, a pullup resistor ( $1 \mathrm{k} \Omega$ nominal) is required. See read timing diagrams for additional details. |
| $\mathrm{V}_{\text {CC }}$ | 28 | Power supply voltage. |
| WE | 25 | Write enable input. When active (low) in conjunction with $\overline{\mathrm{CS}}$ low, the data present on DO-D7 will be asynchronously loaded into the counter as selected by LSB/MSB. See write timing diagrams for additional details. |

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- Inputs are TTL- and CMOS-Voltage Compatible
- Controls Operation of 64 K and 256 K Dynamic RAMs
- Creates Static RAM Appearance
- One Package Contains Address Multiplexer, Refresh Control, and Timing Control
- Directly Addresses and Drives Up to 2 Megabytes of Memory Without External Drivers
- Operates from Microprocessor Clock
- No Crystals, Delay Lines, or RC Networks
- Eliminates Arbitration Delays
- Refresh May Be Internally or Externally Initiated
- Versatile
- Strap-Selected Refresh Rate
- Synchronous, Predictable Refresh
- Selection of Distributed, Transparent, and Cycle-Steal Refresh Modes
- Interfaces Easily to Popular Microprocessors
- Asynchronous RESET Function Provided in FK and FN Packages
- High-Performance Si-Gate CMOS Technology
- Strap-Selected Wait State Generation for Microprocessor/Memory Speed Matching
- Ability to Synchronize or Interleave Controller with the Microprocessor System (Including Multiple Controllers)
- 3-State Outputs Allow Multiport Memory Configuration
- Performance Range: 125 ns ALE low to CAS low
- Compatible with TMS4500A/B and with VTI VL4500A and VL4502
- Available in Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability



## description

The THCT4502 is a monolithic DRAM system controller providing address multiplexing, timing, control and refresh/access arbitration functions to simplify the interface of dynamic RAMs to microprocessor systems.

The controller contains an 18-bit multiplexer that generates the address lines for the memory device from the 18 system address bits and provides the strobe signals required by the memory to decode the address. A 9-bit refresh counter generates up to 512 row addresses required to refresh.

A refresh timer is provided to generate the necessary timing to refresh the dynamic memories and ensure data retention.

The THCT4502 also contains refresh/access arbitration circuitry to resolve conflicts between access requests and memory-refresh cycles.

The THCT4502 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## functional block diagram



Pin numbers shown are for JD and N packages.
pin descriptions

| RAO-RA8 | Input |
| :--- | :--- |
| CAO-CA8 | Input |
| MAO-MA8 | Output |
| ALE | Input |
| $\overline{C S}$ | Input |
| RENO, REN1 | Inputs |

$\overline{\mathrm{ACR}}, \overline{\mathrm{ACW}} \quad$ Input
CLK Input
$\overline{\text { REFREQ }}$ Input

RAS0, $\overline{R A S}$
RAS2, RAS3
$\overline{\mathrm{CAS}} 0, \overline{\mathrm{CAS}} 1 \quad$ Output

RDY Output

Row Address - These address inputs are used to generate the row address for the multiplexer.

Column Address - These address inputs are used to generate the column address for the multiplexer.

Memory Address - These three-state outputs are designed to drive the addresses of the dynamic RAM array.

Address Latch Enable - This input is used to latch the 18 address inputs, $\overline{\mathrm{CS}}$, RENO, and REN1. This also initiates an access cycle if $\overline{\mathrm{CS}}$ is low. The rising edge (low level to high level) of ALE returns all $\overline{\text { RAS }}$ outputs to the high level.

Chip Select - A low on this input enables an access cycle. The trailing edge of ALE latches the chip select input.
$\overline{\text { RAS }}$ Enable 0 and 1 - These inputs are used to select one of four banks of RAM when $\overline{\mathrm{CS}}$ is low. When REN1 is low, the lower banks are enabled via $\overline{\mathrm{CAS}} 0, \overline{\mathrm{RAS}} 0$, and $\overline{\mathrm{RAS}} 1$. When REN1 is high, the higher banks are enabled via $\overline{\mathrm{CAS}} 1, \overline{\mathrm{RAS}} 2$ and $\overline{\mathrm{RAS}} 3$. RENO selects $\overline{\mathrm{RAS}} 0$ and $\overline{\mathrm{RAS}} 2$ when low, or $\overline{\mathrm{RAS}} 1$ and $\overline{\mathrm{RAS}} 3$ when high. (see Table 2).

Access Control, Read; Access Control, Write - A low on either of these inputs causes the column address to appear on MAO-MA8 and a low-going pulse from $\overline{\mathrm{CAS}}$. The rising edge of $\overline{\mathrm{ACR}}$ or $\overline{\mathrm{ACW}}$ terminates the cycle by forcing $\overline{\operatorname{RAS}}$ and $\overline{\mathrm{CAS}}$ high. When $\overline{\mathrm{ACR}}$ and $\overline{\mathrm{ACW}}$ are both low, MAO-MA8, $\overline{\mathrm{RAS}} 0, \overline{\mathrm{RAS}} 1, \overline{\mathrm{RAS}} 2, \overline{\mathrm{RAS}} 3, \overline{\mathrm{CAS}} 0$ and $\overline{\mathrm{CAS}} 1$ go into a high-impedance (floating) state.

System Clock - This input provides the master timing to generate refresh cycle timings and refresh rate. Refresh rate is determined by the TWST, FS.1, and FSO inputs.

Refresh Request - This input should be driven by an open-collector or opendrain output. On input, a low-going edge initiates a refresh cycle and will cause the internal refresh timer to be reset on the next falling edge of the CLK. As an output, a low-going edge signals an internal refresh request and that the refresh timer will be reset on the next low-going edge of CLK. REFREO will remain low until the refresh cycle is in progress and the current refresh address is present on MAO-MA8. (Note: REFREO contains an internal active pullup with a nominal resistance of $10 \mathrm{k} \Omega$, which is disabled when $\overline{R E F R E Q}$ is low).

Row Address Strobe - These three-state outputs are used to latch the row address into the bank of DRAMs selected by RENO and REN1. On refresh, all $\overline{\mathrm{RAS}}$ signals are active.

Column Address Strobe - These three-state outputs are used to latch the column address into the DRAM array.

Ready - This totem-pole output synchronizes memories that are too slow to guarantee microprocessor access time requirements. This output is also used to inhibit access cycles during refresh when in cycle-steal mode.

## pin descriptions (continued)

| TWST | Input | Timing/Wait Strap - A high on this input indicates a wait state should be <br> added to each memory cycle. In addition it is used in conjunction with FSO <br> and FS1 to determine refresh rate and timing or initialize the controller. |
| :--- | :--- | :--- |
| FSO, FS1 | Inputs | Frequency Select 0; Frequency Select 1 - These are strap inputs to select |
| RESET |  |  |
|  | Mode and Frequency of operation as shown in Table 1. |  |

${ }^{\dagger}$ This function is available only in the FK and FN packages.
TABLE 1. STRAP CONFIGURATION

| STRAP INPUT MODES |  |  | WAIT STATES FOR MEMORY ACCESS | REFRESH RATE | MINIMUM CLOCK FREQUENCY (MHz) | REFRESH FREQUENCY (kHz) | CLOCK <br> CYCLES <br> FOR EACH <br> REFRESH |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TWST | FS1 | FSO |  |  |  |  |  |
| L | L | $L^{\dagger}$ | 0 | EXTERNAL | - | REFREQ | 4 |
| L | L | H | 0 | EXTERNAL | - | REFREO | 3 |
| L | H | L | 0 | CLK $\div 61$ | 3.904 | 64.95 ${ }^{\ddagger}$ | 3 |
| L | H | H | 0 | CLK $\div 91$ | 5.824 | $64.88{ }^{\text {§ }}$ | 4 |
| H | L | L | 1 | CLK $\div 61$ | 3.904 | $64.95{ }^{\ddagger}$ | 3 |
| H | L | H | 1 | CLK $\div 91$ | 5.824 | 64-75 ${ }^{\text { }}$ | 4 |
| H | H | L | 1 | CLK $\div 106$ | 6.784 | 64-73 ${ }^{\ddagger}$ | 4 |
| H | H | H | 1 | CLK $\div 121$ | 7.744 | 64-839 | 4 |

${ }^{\dagger}$ This strap configuration resets the Refresh Timer Circuitry.
$\ddagger$ Upper figure in refresh frequency is the frequency that is produced if the minimum clock frequency of the next select state is used.
${ }^{\S}$ Refresh frequency if clock frequency is 8 MHz .
\{Refresh frequency if clock frequency is 10 MHz .
table 2. OUTPUT Strobe selection

| CONTROL INPUT |  | SELECTED OUTPUT |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| REN1 | RENO | RASO | $\overline{\text { RAS }}$ | $\overline{\text { RAS } 2}$ | $\overline{\text { RAS }}$ | $\overline{\text { CAS }} 0$ | $\overline{\text { CAS }} 1$ |
| L | L | X |  |  |  | $x$ |  |
| L | H |  | X |  |  | X |  |
| H | L |  |  | X |  |  | X |
| H | H |  |  |  | X |  | X |

NOTE: Changing the logic value of REN1 after a low-to-high transition of ALE and before $\overline{\mathrm{ACX}}$ rises causes the other $\overline{\mathrm{CAS}}$ to fall. Both $\overline{\mathrm{CAS}}$ signals remain low until $\overline{\mathrm{ACX}}$ rises.

## functional description

The THCT4502 consists of six basic blocks: address and select latches, refresh rate generator, refresh counter, the multiplexer, the arbiter, and the timing and control block.

## address and select latches

The address and select latches allow the DRAM controller to be used in systems that multiplex address and data on the same lines without external latches. The row address latches are transparent, meaning that while ALE is high, the output at MAO-MA8 follows the inputs RAO-RA8.

## refresh rate generator

The refresh rate generator is a counter that indicates to the arbiter that it is time for a refresh cycle. The counter divides the clock frequency according to the configuration straps as shown in Table 1. The counter is reset when a refresh cycle is requested or when TWST, FS1, and FSO are low. The configuration straps allow the matching of memories to the system access time. Upon power-up it is necessary to provide a reset signal by driving all three straps to the controller (or RESET for devices in the FK and FN packages only) low. A systems power-on reset ( $\overline{\mathrm{RESET}}$ ) can be used to do this by connecting it to those straps that are desired high during operation. During this reset period, at least four clock cycles should occur.

## refresh counter

The refresh counter contains the address of the row to be refreshed. The counter is decremented after each refresh cycle. A low-to-high transition on TWST sets the refresh counter to $1 \mathrm{FF}_{16}\left(511_{10}\right)$.

## multiplexer

The multiplexer provides the DRAM array with row, column, and refresh addresses at the proper times. Its inputs are the address latches and the refresh counter. The outputs provide up to 18 multiplexed addresses on nine lines.

## arbiter

The arbiter provides two operational cycles: access and refresh. The arbiter resolves conflicts between cycle requests and cycles in execution, and schedules the inhibited cycle when used in cycle-steal mode.

## timing and control block

The timing and control block executes the operational cycle at the request of the arbiter. It provides the DRAM array with $\overline{\operatorname{RAS}}$ and $\overline{\mathrm{CAS}}$ signals. It provides the CPU with a RDY signal. It controls the multiplexer during all cycles. It resets the refresh rate generator and decrements the refresh counter during refresh cycles.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted) ${ }^{\dagger}$

Supply voltage range, $\mathrm{V}_{\mathrm{CC}}($ See Note 1$)$......................................... . -1.5 V to 7 V
Input diode current, $\mathrm{I}_{\mathrm{K}}\left(\mathrm{V}_{1}<0, \mathrm{~V}_{1}>\mathrm{V}_{\mathrm{CC}}\right.$ ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 20 \mathrm{~mA}$
Output diode current, $\mathrm{I}_{\mathrm{OK}}\left(\mathrm{V}_{\mathrm{O}}<0, \mathrm{~V}_{\mathrm{O}}>\mathrm{V}_{\mathrm{CC}}\right.$ ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 20 \mathrm{~mA}$
Continuous output current, $\mathrm{IO}_{\mathrm{O}}\left(\mathrm{V}_{\mathrm{O}}=0\right.$ to $\mathrm{V}_{\mathrm{CC}}$ ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 35 \mathrm{~mA}$
Continuous current through $V_{\text {CC }}$ or GND pins . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 70 \mathrm{~mA}$
Operating free-air temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
Lead temperature $1,6 \mathrm{~mm}$ ( $1 / 16 \mathrm{inch}$ ) from case for 60 seconds: FK or JD package ....... $300^{\circ} \mathrm{C}$
Lead temperature $1,6 \mathrm{~mm}$ ( $1 / 16 \mathrm{inch}$ ) from case for 10 seconds: FN or N package . . . . .... $260^{\circ} \mathrm{C}$
$\dagger$ Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTE 1: Voltage values are with respect to network ground.
recommended operating conditions

|  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $V_{C C}$ Supply voltage | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\text {IH }}$ High-level input voltage | 2 |  | $V_{C C}+0.5$ | V |
| $\mathrm{V}_{\text {IL }}$ Low-level input voltage | $-0.5^{\dagger}$ |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{O}} \quad$ Output voltage | -0.5 |  | $\mathrm{V}_{\text {CC }}+0.5$ | V |
| $\mathrm{t}_{\mathrm{t}} \quad$ Input transition (rise and fall) time | 0 |  | 500 | ns |
| $\mathrm{T}_{\mathrm{A}}$ Operating free-air temperature | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\dagger}$ The algebraic convention, where the more negative (less positive) limit is designated as minimum, is used in this data sheet for logic voltage levels only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  |  | TEST CONDITIONS | Vcc | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | MIN MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN |  | TYP MAX |  |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High-level output voltage | MAO-MAB, |  | $\mathrm{I}^{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 4.5 V | 4.4 |  | 4.4 | V |
|  |  | $\overline{\mathrm{CAS}} 0-\overline{\mathrm{CAS}} 1$ | $\mathrm{I}^{\mathrm{OH}}=-6 \mathrm{~mA}$ | 4.5 V | 3.86 |  | 3.76 |  |  |
|  |  | RDY | $\mathrm{I}^{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 4.5 V | 4.4 |  | 4.4 |  |  |
|  |  |  | $1 \mathrm{OH}=-4 \mathrm{~mA}$ | 4.5 V | 3.86 |  | 3.76 |  |  |
|  |  | REFREO | $\mathrm{I}_{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 4.5 V | 4 |  | 3.8 |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | Low-level output voltage | RDY, $\overline{\text { REFREO }}$ | $\mathrm{I}_{\mathrm{OL}}=20 \mu \mathrm{~A}$ | 4.5 V |  | 0.1 | 0.1 | V |  |
|  |  |  | $\mathrm{IOL}^{\text {a }}$ - 4 mA | 4.5 V |  | 0.32 | 0.37 |  |  |
|  |  | $\begin{array}{\|l\|} \hline \text { MAO }- \text { MA } 8, \\ \overline{\text { RAS } 0-\overline{R A S}} 3, \\ \overline{\text { CAS } 0, ~ \overline{C A S ~} 1} \\ \hline \end{array}$ | ${ }^{\prime} \mathrm{OL}=20 \mu \mathrm{~A}$ | 4.5 V |  | 0.1 | 0.1 |  |  |
|  |  |  | $\mathrm{I}^{\mathrm{OL}}=6 \mathrm{~mA}$ | 4.5 V |  | 0.32 | 0.37 |  |  |
|  | High-level input current except REFREQ |  | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ | 5.5 V |  | 0.1 | 1 | $\mu \mathrm{A}$ |  |
|  | Low-level input current | REFREQ | $V_{1}=0$ | 5.5 V |  | -5 | -50 | $\mu \mathrm{A}$ |  |
|  |  | RESET |  |  |  | -100 | -250 |  |  |
|  |  | All others |  |  |  | -0.1 | -1 |  |  |
| 10z ${ }^{\ddagger}$ | Off-state output current (3-state outputs only) |  | $\mathrm{V}_{\mathrm{O}}=0$ to 5.5 V | 5.5 V |  | $\pm 5$ | $\pm 50$ | $\mu \mathrm{A}$ |  |
| ${ }^{\text {I CC }}$ | Supply current |  | $\begin{aligned} & V_{1}=V_{C C} \text { or } 0, \\ & L_{0}=0 \end{aligned}$ | 5.5 V |  | 5 | 15 | mA |  |
| $\Delta^{\prime} \mathrm{CC}^{\text {§ }}$ | Supply current change |  | One input at 0.5 V or 2.4 V , Other inputs at 0 V or $\mathrm{V}_{\mathrm{CC}}$ | 5.5 V |  | 1.42 .4 | 3 | mA |  |
| $\mathrm{C}_{\mathrm{i}}$ | Input capacitance |  | $\begin{aligned} & V_{\mathrm{I}}=0, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | 5.5 V |  | 510 | 10 | pF |  |

$\ddagger$ This parameter, IOZ, the high impedance-state output current, applies only for three-state outputs and transceiver I/O pins.
${ }^{\S}$ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or $\mathrm{V}_{\mathrm{CC}}$.

## timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

| PARAMETER |  | THCT4502-125 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{c}}(\mathrm{C})$ | CLK cycle time | 100 |  | ns |
| $\mathrm{t}_{\mathrm{w}}(\mathrm{CH})$ | CLK high pulse duration | 45 |  | ns |
| ${ }_{\text {w }}$ (CLC) | CLK low pulse duration | 45 |  | ns |
| ${ }^{\text {t }}$ AEL-CL | Time delay, ALE low to CLK starting low (see Note 1) | 25 |  | ns |
| ${ }^{\text {t }}$ CL-AEL | Time delay, CLK low to ALE starting low (see Note 1) | 15 |  | ns |
| ${ }^{\text {t }}$ CL-AEH | Time delay, CLK low to ALE | 15 |  | ns |
| ${ }^{\text {t }}$ (AEH) | Pulse width ALE high | 45 |  | ns |
| tAV-AEL | Time delay, address REN1, CS valid to ALE low | 10 |  | ns |
| ${ }^{\text {A }}$ AEL-AX | Time delay, ALE low to address not valid | 15 |  | ns |
| ${ }^{\text {t } A E L-A C L ~}$ | Time delay, ALE low to $\overline{\mathrm{ACX}}$ low (see Notes 3, 4, 5, and 6) | $t_{h}($ R $A)+30$ |  | ns |
| ${ }^{\text {t }} \mathrm{ACH}-\mathrm{CL}$ | Time delay, $\overline{\mathrm{ACX}}$ high to CLK low (see Notes 3 and 7) | 30 |  | ns |
| ${ }^{\text {t }} \mathrm{ACL}-\mathrm{CH}$ | Time delay, $\overline{\mathrm{ACX}}$ low to CLK starting high (to remove RDY) | 30 |  | ns |
| ${ }^{\text {t } R Q L-C L}$ | Time delay, $\overline{\text { REFREQ }}$ low to CLK starting low (see Note 8) | 35 |  | ns |
| $\mathrm{t}_{\mathrm{W}}$ (RQL) | Pulse width REFREQ low | 30 |  | ns |
| $t_{w}(\mathrm{ACL})$ | $\overline{\text { ACX }}$ low width (see Note 9) | 120 |  | ns |
| treset | Power-up reset | ${ }^{4 t} \mathrm{t}_{\text {clek }}$ |  | ns |

NOTES: 1. Coincidence of the trailing edge of CLK and the trailing edge of ALE should be avoided as the refresh/access occurs on the trailing CLK edge.
2. If ALE rises before $\overline{A C X}$ and a refresh request is present, the falling edge of CLK after ${ }^{\mathrm{C}} \mathrm{CL}$-AEH will output the refresh address to MAO-MA7 and initiate a refresh cycle.
3. These specifications relate to system timing and do not directly reflect device performance.
4. On the access grant cycle following refresh, the occurrence of CAS low depends on the relative occurrence of ALE low to $\overline{A C X}$ low. If $\overline{A C X}$ occurs prior to or coincident with ALE, then $\overline{\mathrm{CAS}}$ is timed from the CLK high transition that causes $\overline{\mathrm{RAS}}$ low. If $\overline{\mathrm{ACX}}$ occurs 20 ns or more after ALE, then $\overline{\mathrm{CAS}}$ is timed from the CLK low transition following the CLK high transition causing $\overline{R A S}$ low.
5. For maximum speed access (internal delays on both access and access grant cycles), $\overline{\mathrm{ACX}}$ should occur prior to or coincident with ALE.
6. $t_{h}(R A)$ is the dynamic memory row address hold time. $\overline{A C X}$ should follow ALE by $t_{A E L}$-CEL in systems where the required $t_{h}(R A)$ is greater than $t_{\text {REL }}$-MAX minimum.
7. The minimum of 20 ns is specified to ensure arbitration will occur on falling CLK edge, $\mathrm{t}_{\mathrm{ACH}} \mathrm{CL}$ also affects precharge time such that the minimum $t^{A C H}-\mathrm{CL}$ should be equal or greater than: $\mathrm{t}_{\mathrm{w}}(\mathrm{RH})-\mathrm{t}_{\mathrm{w}(\mathrm{CL})}+30 \mathrm{~ns}$ (for a cycle where $\overline{\mathrm{ACX}}$ high occurs prior to ALE high) where $\mathrm{t}_{\mathrm{w}(\mathrm{RH})}$ is the DRAM $\overline{\mathrm{RAS}}$ precharge time.
8. This parameter is necessary only if refresh arbitration is to occur on this low-going CLK edge (in systems where refresh is synchronized to external events).
9. The specification $\mathrm{t}_{\mathrm{w}}(\mathrm{ACL})$ is designed to allow a $\overline{\mathrm{CAS}}$ pulse. This assures normal operation of the device in testing and system operation.

## switching characteristics over recommended supply voltage range and operating free-air temperature range (see Figure 1)

| PARAMETER |  | TEST CONDITIONS | THCT4502-125 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX |  |
| tAEL-REL | Time delay, ALE low to $\overline{\text { RAS }}$ starting low |  | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 45 | ns |
| traV-MAV | Time delay, row address valid to memory address valid | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 50 | ns |
| tAEH-MAV | Time delay, ALE high to valid memory address | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 90 | ns |
| ${ }^{\text {t AEL-RYL }}$ | Time delay, ALE to RDY starting low (TWST $=1$ or refresh in progress) | $C_{L}=40 \mathrm{pF}$ |  | 40 | ns |
| tAEL-CEL | Time delay, ALE low to $\overline{\mathrm{CAS}}$ starting low (see Note 10) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 50 | 125 | ns |
| ${ }^{\text {t }}$ AEH-REH | Time delay, ALE high to $\overline{\mathrm{RAS}}$ starting high | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 50 | ns |
| $t_{\text {ACL-MAX }}$ | Row address valid after $\overline{\mathrm{ACX}}$ | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 15 |  | ns |
| tMAV-CEL | Time delay, memory address valid to ट्टAS starting low | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 0 |  | ns |
| ${ }^{\text {t }}$ ACL-CEL | Time delay, $\overline{\mathrm{ACX}}$ low to $\overline{\mathrm{CAS}}$ starting low (see Note 10) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 40 | 100 | ns |
| tACH-REH | Time delay, $\overline{\text { ACX }}$ to $\overline{\mathrm{RAS}}$ starting high | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 55 | ns |
| ${ }^{\text {t }}$ ACH-CEH | Time delay, $\overline{\mathrm{ACX}}$ high to $\overline{\mathrm{CAS}}$ starting high | $C_{L}=360 \mathrm{pF}$ | 5 | 45 | ns |
| ${ }^{\text {t } A C H-M A X ~}$ | Column address valid after $\overline{A C X}$ high | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 10 |  | ns |
| ${ }^{\text {t }} \mathrm{CH}-\mathrm{RYH}$ | Time delay, CLK high to RDY starting high (after $\overline{\mathrm{ACX}}$ low) (see Note 11 ) | $C_{L}=40 \mathrm{pF}$ |  | 60 | ns |
| ${ }^{\text {t }}$ RFL-RFL | Time delay, $\overline{\operatorname{REFRRO}}$ external till supported by $\overline{\text { REFREO }}$ internal | $C_{L}=40 \mathrm{pF}$ |  | 35 | ns |
| ${ }^{\text {t }} \mathrm{CH}$-RFL | Time delay, CLK high till $\overline{\text { REFREO }}$ internal starting low | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ |  | 50 | ns |
| ${ }^{\text {t }}$ CL-MAV | Time delay, CLK low till refrefresh address valid | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 100 | ns |
| ${ }^{\text {t }}$ CH-RRL | Time delay, CLK high till refresh RAS starting low | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ | 10 | 60 | ns |
| tMAV-RRL | Time delay, refresh address valid till refresh $\overline{\mathrm{RAS}}$ low | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ | 5 |  | ns |
| ${ }^{\text {t CL-RFH }}$ | Time delay, CLK low to REFREO starting high (3 cycle refresh) | $C_{L}=40 \mathrm{pF}$ |  | 70 | ns |
| ${ }^{\text {t }} \mathrm{CH}-\mathrm{RFH}$ | Time delay, CLK high to $\overline{\text { EEFREQ }}$ starting high (4 cycle refresh) | $C_{L}=40 \mathrm{pF}$ |  | 70 | ns |
| ${ }^{\text {t }}$ CH-RRH | Time delay, CLK high to refresh $\overline{\mathrm{RAS}}$ starting high | $C_{L}=160 \mathrm{pF}$ | 5 | 60 | ns |
| ${ }^{\text {t }} \mathrm{CH}$-MAX | Refresh address valid after CLK high | $C_{L}=360 \mathrm{pF}$ | 10 |  | ns |

NOTES: 10. The falling edge of $\overline{C A S}$ occurs when both ALE low to $\overline{\mathrm{CAS}}$ low time delay ( $\mathrm{t}_{\mathrm{AEL}}$-CEL) and $\overline{\mathrm{ACX}}$ low to $\overline{\mathrm{CAS}}$ low time delay ( $t_{A C L}$ CEL) have elapsed, i.e., if $\overline{A C X}$ goes low prior to ( $t_{A E L}$-CEL $-t_{A C L}$ CEL) after the falling edge of $A L E$, the falling edge of CAS is measured from the falling edge of ALE (tAEL-CEL). Otherwise, the access time increases and the falling edge of $\overline{\mathrm{CAS}}$ is measured from the falling edge of $\overline{\mathrm{ACX}}$ ( $\left.\mathrm{t}_{\mathrm{ACL}} \mathrm{CEL}\right)$.
11. RDY returns high or the rising edge of CLK. If TWST $=0$, then on an access grant cycle RDY goes high on the same edge that causes access $\overline{\operatorname{RAS}}$ low. If TWST $=1$, then RDY goes to the high level on the first rising CLK edge after $\overline{\mathrm{ACX}}$ goes low on access cycles and on the next rising edge after the edge that causes access $\overline{R A S}$ low on access grant cycles fassuming $\overline{\mathrm{ACX}}$ low).
switching characteristics over recommended supply voltage range and operating free-air temperature range (see Figure 1) (continued)

| PARAMETER |  | TEST CONDITIONS | THCT4502-125 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX |  |
| ${ }^{\text {t }}$ CH-REL | Time delay, CLK high till access $\overline{\text { RAS }}$ starting low |  | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 60 | ns |
| ${ }^{\text {t CL-CEL }}$ | Time delay, CLK low to access $\overline{\mathrm{CAS}}$ starting low (see Note 12) | $C_{L}=360 \mathrm{pF}$ |  | 100 | ns |
| ${ }^{\text {t CL-MAX }}$ | Row address valid after CLK low | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 25 |  | ns |
| trel-max | Row address valid after RAS low | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 25 |  | ns |
| tAEH-MAX | Column address valid after ALE high | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 10 |  | ns |
| $\mathrm{t}_{\text {dis }}$ | Output disable time (3-state outputs) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 125 | ns |
| $\mathrm{t}_{\mathrm{en}}$ | Output enable time (3-state outputs) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 75 | ns |
| ${ }^{\text {t C }}$ AV-CEL | Time delay, column address valid to $\overline{\mathrm{CAS}}$ starting low after refresh (see Note 12) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ | 0 |  | ns |
| ${ }^{\text {t }} \mathrm{CH}$-CEL | Time delay, CLK high to access $\overline{\text { CAS }}$ starting low (see Note 13) | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 180 | ns |
| $\mathrm{t}_{\mathrm{t} \text { (CEEL) }}$ | $\overline{\mathrm{CAS}}$ fall time | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 20 | ns |
| $\mathrm{t}_{\mathrm{t}}$ (CEEH) | $\overline{\text { CAS }}$ rise time | $\mathrm{C}_{\mathrm{L}}=360 \mathrm{pF}$ |  | 50 | ns |
| $\mathrm{t}_{\mathrm{t} \text { (REL) }}$ | $\overline{\text { RAS }}$ fall time | $C_{L}=180 \mathrm{pF}$ |  | 30 | ns |
| $\mathrm{t}_{\mathrm{t} \text { (REH) }}$ | $\overline{\text { RAS }}$ rise time | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 40 | ns |
| $\mathrm{t}_{\mathrm{t}}(\mathrm{MAV})$ | Address transition time | $\mathrm{C}_{\mathrm{L}}=180 \mathrm{pF}$ |  | 40 | ns |
| $\mathrm{t}_{\mathrm{t}}(\mathrm{RYL})$ | RDY fall time | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ |  | 20 | ns |
| $\mathrm{t}_{\mathrm{t} \text { (RYH) }}$ | RDY rise time | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ |  | 50 | ns |

NOTES: 12. The occurrence of $\overline{C A S}$ low is guaranteed not to occur until the column address is valid on MAX.
13. On the access grant cycle following refresh, the occurrence of $\overline{C A S}$ low depends on the relative occurrence of ALE low to $\overline{A C X}$ low. If $\overline{A C X}$ occurs prior to or coincident with ALE then $\overline{C A S}$ is timed from the CLK high transition that causes $\overline{\operatorname{RAS}}$ low. If $\overline{A C X}$ occurs 20 ns or more after ALE then $\overline{\mathrm{CAS}}$ is timed from the CLK low transition following the CLK high transition causing $\overline{\mathrm{RAS}}$ low. (See Refresh Cycle Timing Diagram)

## PARAMETER MEASUREMENT INFORMATION



Figure 1. load circuit


NOTE 14: All transition times $\left(t_{t}\right)$ are measured between $10 \%$ and $90 \%$ points.
FIGURE 2. ACCESS CYCLE TIMING


Figure 3. REFRESH REQUEST TIMING
NOTE 15: All input pulses are supplied by generators having the following characteristics: $P R R \leq 1 \mathrm{MHz}, \mathrm{Z}_{\mathrm{out}}=50 \Omega, \mathrm{t}_{\mathrm{r}}=6 \mathrm{~ns}, \mathrm{tf}_{\mathrm{f}}=6 \mathrm{~ns}$.


NOTE 16: Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the access controls. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the access controls.

FIGURE 4. ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

${ }^{\dagger}$ On access grant cycle following refresh, $\overline{\mathrm{CAS}}$ low and address multiplexing are timed from CLK high transition (tCH-CEL) if $\overline{\mathrm{ACX}}$ low occurs prior to or coincident with the falling edge of ALE.
$\ddagger$ On access grant cycle following refresh, $\overline{\text { CAS }}$ low and address multiplexing are timed from CLK low transition (tCL-CEL) if $\overline{\operatorname{ACX}}$ low occurs 20 ns or more after the falling edge of ALE.
NOTE 15: All input pulses are supplied by generators having the following characteristics: PRR $\leq 1 \mathrm{MHz}, \mathrm{Z}_{\text {out }}=50 \Omega, \mathrm{t}_{\mathrm{r}}=6 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}=6 \mathrm{~ns}$.
figure 5. REFRESH CYCLE TIMING (THREE CYCLE)

$\dagger$ On access grant cycle following refresh, $\overline{\mathrm{CAS}}$ low and address multiplexing are timed from CLK high transition (t $\mathrm{CH}-\mathrm{CEL}$ ) if $\overline{\mathrm{ACX}}$ low occurs prior to or coincident with the falling edge of ALE.
$\ddagger$ On access grant cycle following refresh, $\overline{\mathrm{CAS}}$ low and address multiplexing are timed from CLK low transition (t CL -CEL) if $\overline{\mathrm{ACX}}$ low occurs 20 ns or more after the falling edge of ALE.
NOTE 15: All input pulses are supplied by generators having the following characteristics: $P R R \leq 1 \mathrm{MHz}, Z_{o u t}=50 \Omega, t_{r}=6 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}=6 \mathrm{~ns}$.
FIGURE 6. REFRESH CYCLE TIMING (FOUR CYCLE)


FIGURE 7. TYPICAL ACCESS/REFRESH/ACCESS CYCLE (THREE-CYCLE, TWST IS LOW)

figure 9. TYPICAL ACCESS/REFRESH/ACCESS CYCLE (THREE-CYCLE, TWST IS HIGH)


FIGURE 10. TYPICAL ACCESS/REFRESH/ACCESS CYCLE (FOUR-CYCLE, TWST IS HIGH)

${ }^{\dagger}$ Load is 360 pF for $\overline{\mathrm{CAS}}$ and MA outputs, 180 pF for all $\overline{\mathrm{RAS}}$ outputs.
FIGURE 11.

## ORDERING INSTRUCTIONS


$N, J D$ (Dual in-line packages)
FK, FN (Chip carrier packages)
səэ!ฺə๐ IS7

- Four 8-Bit Registers
- Dual 2-Level or Single 4-Level Pipeline Registers
- Any One of Four Registers Selectable for Output
- High-Speed Low-Power CMOS Logic
- Fully TTL Compatible
- Dependable Texas Instruments Quality and Reliability


## description

The THCT29520 and THCT29521 are highspeed CMOS multilevel pipeline registers. They are interchangeable with the Advanced Micro Device bipolar AM29520 and AM29521 but dissipate a fraction of the power.
The THCT29520 and THCT29521 contain four 8-bit positive-edge-triggered registers. The registers can operate as one set of 4 -level pipeline registers or two sets of 2 -level pipeline registers. The output can be selected from any one of the four registers.

The THCT29520 and THCT29521 differ in the way data is transferred in the dual 2-level register modes $(1=01$ or 10$)$. For the THCT29520, new data is written into the first-level register while the old data in the first-level register is shifted into the second-level register. For the THCT29521, new data is written over the old data in the first-level register. The data in the second-level register remains unchanged.
The THCT29520 and THCT29521 are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$. The THCT29520E and THCT29521E are characterized for operation from $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$.


| I1 | I0 | OPERATION | A1 | A2 | B1 | B2 |
| :---: | :---: | :--- | :---: | :---: | :---: | :---: |
| L | L | SHIFT A B | D | A10 | A20 | B10 |
| L | H | SHIFT B | A10 | A20 | D | B10 |
| H | L | SHIFT A | D | $\mathrm{A} 1_{0}$ | $\mathrm{~B} 1_{0}$ | $\mathrm{~B} 2_{0}$ |
| H | H | HOLD | A10 | A20 | B10 | B20 |

THCT29521 MODES


| I1 | 10 | OPERATION | A1 | A2 | B1 | B2 |
| :---: | :---: | :--- | :---: | :---: | :---: | :---: |
| L | L | SHIFT A B | D | A10 | A20 | B10 |
| L | H | LOAD B | A10 | A20 | D | B20 |
| H | L | LOAD A | D | A20 | B 10 | B20 |
| H | H | HOLD | A10 | A20 | B 10 | B20 |

OUTPUT FUNCTION TABLE

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| $\overline{\text { OE }}$ | S1 | SO | Y |
| L | L | L | B2 |
| L | L | H | B1. |
| L | H | L | A2 |
| L | H | H | A1 |
| H | X | X | Z |

logic symbols ${ }^{\dagger}$


[^55]logic diagram (positive logic)

"The label "0C4/2C4" means that the clock in register A2 affects the eight data inputs of that register, collectively labeled " 4 D ", only in modes 0 and 2111 , $10=L L$ and $H L$, respectively). This logic diagram applies specifically for the THCT29520. For the THCT29521, the labels marked with the asterisks in registers A2 and B2 would both be reduced to " $0 C 4$ '" indicating that these clocks have effect only in mode 0 in that device. Otherwise this diagram applies to both devices.

## absolute maximum rating over operating free-air temperature range (see Note 1)

$$
\begin{aligned}
& \text { Supply voltage, VCC . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } 0.5 \text { V to } 7 \text { V } \\
& \text { Input diode current, IIK ( } \mathrm{V}_{1}<0 \text { or } \mathrm{V}_{1}>\mathrm{V}_{\mathrm{C}} \mathrm{C} \text {. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } \pm 20 \mathrm{~mA}
\end{aligned}
$$

$$
\begin{aligned}
& \text { Continuous output current, } \mathrm{I}_{\mathrm{O}}\left(\mathrm{~V}_{\mathrm{O}}=0 \text { to } \mathrm{V}_{\mathrm{CC}} \text { ) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } \pm 35 \mathrm{~mA}\right. \\
& \text { Continuous current through VCC or GND . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . } \pm 70 \mathrm{~mA} \\
& \text { Lead temperature } 1,6 \mathrm{~mm}\left(1 / 16 \text { inch) from case for } 60 \text { seconds . . . . . . . . . . . . . . . . . . . . } 300^{\circ} \mathrm{C}\right. \\
& \text { Storage temperature range . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . }-65^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}
\end{aligned}
$$

NOTE 1: Stress beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the "recommended operating conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## THCT29520, THCT29521

## MULTILEVEL PIPELINE REGISTERS

## recommended operating conditions

|  | THCT29520E THCT29521E |  |  | $\begin{aligned} & \text { THCT29520 } \\ & \text { THCT29521 } \end{aligned}$ |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| $\mathrm{V}_{\mathrm{CC}}$ Supply voltage | 4.5 | 5 | 5.5 | 4.5 | 5 | 5.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$. High-level input voltage | 2 |  |  | 2 |  |  | V |
| $\mathrm{V}_{\mathrm{IL}}$ Low-level input voltage | 0 |  | 0.8 | 0 |  | 0.8 | V |
| $\mathrm{V}_{1} \quad$ Input voltage | 0 |  | $\mathrm{V}_{\mathrm{Cc}}$ | 0 |  | $\mathrm{V}_{\mathrm{Cc}}$ | V |
| $\mathrm{V}_{0}$ Output voltage | 0 |  | $V_{\text {cc }}$ | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{t}_{t} \quad$ Input transition (rise and fall) time | 0 |  | 500 | 0 |  | 500 | ns |
| $\mathrm{T}_{\mathrm{A}}$ Operating free-air temperature | -40 |  | 85 | -0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

electrical characteristics over recommended operating temperature range, $\mathrm{V}_{\mathbf{I}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | Vcc | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | THCT29520E <br> THCT29521E |  | THCT29520 <br> THCT29521 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | MAX | MiN | MAX |  |
| $\mathrm{VOH}^{\text {O }}$ | $\mathrm{I}^{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 4.5 V | 4.4 | 4.499 |  | 4.4 |  | 4.4 |  | V |
|  | $1 \mathrm{OH}=-8 \mathrm{~mA}$ | 4.5 V | 3.9 | 4.3 |  | 3.8 |  | 3.8 |  |  |
| VOL | $\mathrm{l}_{\mathrm{OL}}=20 \mu \mathrm{~A}$ | 4.5 V |  | 0.001 | 0.1 |  | 0.1 |  | 0.1 | V |
|  | $1 \mathrm{OL}=8 \mathrm{~mA}$ | 4.5 V |  | 0.17 | 0.26 |  | 0.33 |  | 0.33 |  |
| 4 | $\mathrm{V}_{1}=0$ to $\mathrm{V}_{\text {CC }}$ | 5.5 V |  | $\pm 0.1$ | +100 |  | $\pm 1000$ |  | $\pm 1000$ | nA |
| Ioz | $V_{1}=0$ or $V_{C C}$ | 5.5 V |  | $\pm 0.01$ | $\pm 0.5$ |  | $\pm 5$ |  | $\pm 5$ | $\mu \mathrm{A}$ |
| ICC | $\begin{aligned} & \mathrm{V}_{1}<0.5 \mathrm{~V} \text { or }>2.4 \mathrm{~V}, \\ & 1_{0}=0 \end{aligned}$ | 4.5 V |  |  | 8 |  | 80 |  | 80 | $\mu \mathrm{A}$ |
| $\mathrm{C}_{\mathrm{i}}$ |  | $\begin{gathered} 4.5 \mathrm{~V} \\ \text { to } \\ 5.5 \mathrm{~V} \end{gathered}$ |  | 3 | 10 |  | 10 |  | 10 | pF |

timing requirements over recommended operating free-air temperature range

| PARAMETER |  | Vcc | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | THCT29520E THCT29521E |  | THCT29520 <br> THCT29521 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{w}}$ | Pulse duration, CLK high or low |  | 4.5 V |  | 6 |  | 12 |  | 12 |  | ns |
|  |  | 5.5 V |  | 5 |  | 10 |  | 10 |  |  |  |
| ${ }_{\text {tsu }}$ | Setup time before CLK $\dagger$ | 4.5 V |  | 10 |  | 15 |  | 15 |  | ns |  |
|  |  | 5.5 V |  | 8 |  | 13 |  | 13 | $\cdot$ |  |  |
| $t^{\prime}$ | Hold time after CLK $\uparrow$ | 4.5 V |  | 0 |  | 0 |  | 0 |  | ns |  |
|  |  | 5.5 V |  | 0 |  | 0 |  | 0 |  |  |  |

THCT29520, THCT29521 MULTILEVEL PIPELINE REGISTERS
switching characteristics over recommended free-air temperature range, $C_{L}=50 \mathrm{pF}$ (unless otherwise noted) See Note 2

| PARAMETER | FROM | то | V cc | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | THCT29520E <br> THCT29521E |  | $\begin{aligned} & \text { THCT29520 } \\ & \text { THCT29521 } \end{aligned}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {tpd }}$ | CLK $\dagger$ | Y | 4.5 V |  | 18 |  |  | 27 |  | 26 | ns |
|  |  |  | 5.5 V |  | 16 |  |  | 25 |  | 24 |  |
| ${ }^{\text {tpd }}$ | S0, S1 | Y | 4.5 V |  | 17 |  |  | 27 |  | 26 | ns |
|  |  |  | 5.5 V |  | 15 |  |  | 25 |  | 24 |  |
| $t_{\text {en }}$ | $\overline{\mathrm{OE}} \downarrow$ | Y | 4.5 V |  | 10 |  |  | 16 |  | 15 | ns |
|  |  |  | 5.5 V |  | 7 |  |  | 15 |  | 14 |  |
| ${ }^{\text {d }}$ dis | $\overline{O E} \uparrow$ | Y | 4.5 V |  | 14 |  |  | 20 |  | 20 | ns |
|  |  |  | 5.5 V |  | 13 |  |  | 20 |  | 20 |  |
| $t_{t}$ |  | Y | 4.5 V |  | 7 |  |  | 12 |  | 12 | ns |
|  |  |  | 5.5 V |  | 7 |  |  | 12 |  | 12 |  |


| $\mathrm{C}_{\mathrm{pd}}$ | Power dissipation capacitance ${ }^{\dagger}$ | No load, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 110 pF typ |
| :--- | :--- | :--- | :--- |

[^56]

- Fast Address to Match Valid Delay - Three

Speed Ranges: 35 ns, 45 ns, 55 ns

- $512 \times 9$ Internal RAM
- 300-Mil 24-Pin Ceramic Side-Brazed or Plastic Dual-In-Line or Small Outline Packages
- Max Power Dissipation: 660 mW
- On-Chip Parity Generation and Checking
- Parity Error Output/Force Parity Error Input
- On-Chip Address/Data Comparator
- Asynchronous, Single-Cycle Reset
- Easily Expandable
- Fully Static
- Reliable SMOS (Scaled NMOS) Technology
- TTL- and CMOS-Compatible Inputs and Outputs


## description

This 8-bit-slice cache address comparator consists of a high-speed $512 \times 9$ static RAM array, parity generator, parity checker, and 9 -bit high-speed comparator. It is fabricated using N -channel silicon gate technology for high speed and simple interface with MOS and bipolar TTL circuits. The cache address comparator is easily cascadable for wider tag addresses or deeper tag memories. Significant reductions in cache memory component count, board area, and power dissipation can be achieved with this device.
When $\bar{S}$ is low and $\bar{W}$ is high, the cache address comparator compares the contents of the memory location addressed by AO-A8 with the data on DO-D7 plus generated parity. An equality is indicated by a high level on the MATCH output. A low-level output from $\overline{\mathrm{PE}}$ signifies a parity error in the internal RAM data. $\overline{P E}$ is an N-channel open-drain output for easy OR-tying. During a write cycle ( $\bar{S}$ and $\bar{W}$ low), data on DO-D7 plus generated even parity are written in the 9-bit memory location addressed by A0-A8. Also during write, a parity error may be forced by holding $\overline{P E}$ low.
A $\overline{\text { RESET }}$ input is provided for initialization. When $\overline{\text { RESET }}$ goes low, all $512 \times 9$ RAM locations are cleared and the MATCH output is forced high.

The cache address comparator operates from a single +5 V supply and is offered in a 24 -pin 300-mil ceramic side brazed or plastic dual-in-line packages. The device is fully TTL compatible and is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## MATCH OUTPUT DESCRIPTION

$$
\begin{aligned}
& \mathrm{MATCH}=\mathrm{VOH}_{\mathrm{OH}} \text { if: } {[A O-A 8]=D O-D 7+\text { parity, } } \\
& \text { or: } \overline{\operatorname{RESET}}=V_{I L}, \\
& \text { or: } \overline{\mathrm{S}}=V_{I H}, \\
& \text { or: } \bar{W}=V_{I L} \\
& M A T C H=V_{O L} \quad \text { if: } {[A O-A 8] \neq D O-D 7+\text { parity, } } \\
& \text { with } \overline{\text { RESET }}=V_{I H}, \\
& \bar{S}=V_{I L}, \text { and } \bar{W}=V_{I H}
\end{aligned}
$$

FUNCTION TABLE

| OUTPUT |  | FUNCTION <br> DESCRIPTION |
| :---: | :---: | :---: |
| MATCH | $\overline{\text { PE }}$ |  |
| L | L | Not Equal |
| L | H | Undefined Error |
| H | L | Equal |
| H | H |  |

Where $S=V_{I L}, W=V_{I H}$, RESET $=V_{I H}$
functional block diagram (positive logic)


This diagram has been changed to correct errors in previous versions. No functional change has been made in the chip.

|  |  | DESCRIPTION |
| :---: | :---: | :---: |
| NAME | NO. |  |
| RESET | 1 | $\overline{\text { RESET }}$ input. Asynchronously clears entire RAM array and forces MATCH high when $\overline{\text { RESET }}$ is at $V_{I L}$ and $\bar{W}$ is at $V_{I H}$. |
| AO | 22 |  |
| A1 | 23 |  |
| A2 | 5 |  |
| A3 | 4 |  |
| A4 | 3 | the duration of the write cycle. |
| A5 | - 2 |  |
| A6 | 19 |  |
| A7 | 20 |  |
| A8 | 21 |  |
| D0 | 7 |  |
| D1 | 8 |  |
| D2 | 9 |  |
| D3 | 6 | Data inputs. Compared with memory location addressed by AO-A8 when $\bar{W}$ is at $V_{1 H}$ and $\overline{\mathrm{S}}$ is at |
| D4 | 17 | $V_{I L}$. Provide input data to RAM when $\bar{W}$ is at $V_{I L}$ and $\overline{\mathrm{S}}$ is at $\mathrm{V}_{\mathrm{IL}}$. |
| D5 | 18 |  |
| D6 | 15 |  |
| D7 | 16 |  |
| $\overline{\text { w }}$ | 10 | Write control input. Writes DO through D7 and generated parity into RAM and forces MATCH high when $\bar{W}$ is at $V_{I L}$ and $\bar{S}$ is at $V_{I L}$. Places selected device in compare mode if $\bar{W}$ is at $V_{I H}$. |
| $\overline{\text { PE }}$ | 11 | Parity error input/output. During write cycles, $\overline{\mathrm{PE}}$ can force a parity error into the 9 -bit location specified by AO through A8 when $\overline{P E}$ is at $V_{I L}$. For compare cycles, $\overline{P E}$ at $V_{O L}$ indicates a parity error in the stored data. $\overline{\mathrm{PE}}$ is an open-drain output so an external pull-up resistor is required. |
| GND | 12 | Ground |
| $\overline{\mathrm{s}}$ | 13 | Chip select input. Enables device when $\overline{\mathrm{S}}$ is at $\mathrm{V}_{\mathrm{IL}}$. Deselects device and forces MATCH high when $\bar{s}$ is at $V_{I H}$. |
| MATCH | 14 | When MATCH output is at $\mathrm{V}_{\mathrm{OH}}$ during a compare cycle, D0 through D7 plus parity equal the contents of the 9 -bit memory location addressed by A0 through A8. |
| $\mathrm{V}_{\mathrm{CC}}$ | 24 | $5-\mathrm{V}$ supply voltage |

## absolute maximum ratings over operating free-air temperature range (unless otherwise specified)



NOTE 1: All voltage values are with respect to GND.

## recommended operating conditions

|  | PARAMETER | MIN |
| :--- | :---: | :---: |
| Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ | 4.5 | 5 |
| High-level input voltage, $\mathrm{V}_{\mathrm{IH}}$ | 5.5 | V |
| Low-level input voltage, $\mathrm{V}_{\mathrm{IL}}$ (See Note 2) | 2 | -1 |
| Operating free-air temperature, $\mathrm{T}_{\mathrm{A}}$ | 6 | V |

NOTE 2: The algebraic convention, where the more negative (less positive) limit is designated as minimum, is used in this data sheet for logic voltage levels only.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS | TMS2150-3 |  | TMS2150-4 TMS2150-5 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP MAX | MIN | TYP MAX |  |
| $\mathrm{VOH}_{\text {(M) }}$ | MATCH high-level output voltage |  | ${ }^{1} \mathrm{OH}=-2 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | 2.4 |  | 2.4 |  | V |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | 3.5 |  | 3.5 |  |  |  |
| $\left.\mathrm{V}_{\text {OLI }} \mathrm{M}\right)$ | MATCH low-level output voltage | $\mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA}, \quad \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ |  | 0.4 |  | 0.4 | V |  |
| $\mathrm{V}_{\text {OL(PE) }}$ | PE low-level output voltage | $\mathrm{I}_{\mathrm{OL}}=12 \mathrm{~mA}, \quad \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ |  | 0.4 |  | 0.4 | V |  |
| 1 | Input current | $\mathrm{V}_{1}=0 \mathrm{~V}$ to 5.5 V |  | 10 |  | 10 | $\mu \mathrm{A}$ |  |
| ${ }^{1} \mathrm{OL}(\mathrm{PE})$ | $\overline{\text { PE }}$ output sink current | $\mathrm{V}_{\mathrm{OL}}=0.4 \mathrm{~V}, \quad \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | 12 |  | 12 |  | mA |  |
| Ios | Short-circuit MATCH output current | $\mathrm{V}_{\mathrm{O}}=\mathrm{GND}, \quad \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ |  | -150 |  | -150 | mA |  |
| ${ }^{\text {CCC1 }}$ | Supply current (operative) | $\overline{\text { RESET }}=\mathrm{V}_{1 H}$ |  | 145 |  | 135 | mA |  |
| $\mathrm{I}_{\mathrm{C} 2}$ | Suply current (reset) | $\overline{\text { RESET }}=\mathrm{V}_{\text {IL }}$ |  | 155 |  | 145 | mA |  |
| $\mathrm{C}_{\mathrm{i}}$ | Input capacitance | $\mathrm{V}_{1}=0 \mathrm{~V}, \quad \mathrm{f}=1 \mathrm{MHz}$ |  | 5 |  | 5 | pF |  |
| $\mathrm{C}_{0}$ | Output capacitance | $\mathrm{V}_{\mathrm{O}}=0 \mathrm{~V}, \quad f=1 \mathrm{MHz}$ |  | 6 |  | 6 | pF |  |

switching characteristics over recommended ranges of supply voltage and operating free-air temperature

| PARAMETER |  | TMS2150-3 |  | TMS2150-4 |  | TMS2150-5 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| ta(A) | Access time from address to MATCH |  | 35 |  | 45 |  | 55 | ns |
| $\mathrm{ta}_{\mathrm{a}}(\mathrm{A}-\mathrm{P})$ | Access time from address to $\overline{\mathrm{PE}}$ |  | 45 |  | 55 |  | 65 | ns |
| $\mathrm{ta}_{\text {a }}(\mathrm{S})$ | Access time from $\overline{\mathbf{S}}$ to MATCH |  | 20 |  | 25 |  | 35 | ns |
| $\mathrm{t}_{\mathrm{p} \text { ( } \mathrm{D})}$ | Propagation time, data inputs to MATCH |  | 20 |  | 35 |  | 45 | ns |
| $\mathrm{t}_{\mathrm{p}}$ (R-MH) | Propagation time, $\overline{\text { RESET }}$ low to MATCH high |  | 30 |  | 30 |  | 40 | ns |
| $\mathrm{t}_{\mathrm{p} \text { (S-MH }}$ | Propagation time, $\overline{\mathrm{S}}$ high to MATCH high |  | 20 |  | 25 |  | 35 | ns |
| $\mathrm{t}_{\mathrm{p} \text { ( } \mathrm{W}-\mathrm{MH})}$ | Propagation time, $\overline{\mathrm{W}}$ low to MATCH high |  | 20 |  | 25 |  | 35 | ns |
| $\mathrm{t}_{\mathrm{p}(\mathrm{W}-\mathrm{PH})}$ | Propagation time, $\bar{W}$ low to $\overline{\text { PE }}$ high |  | 20 |  | 25 |  | 35 | ns |
| $t_{v}(\mathrm{~A})$ | MATCH valid time after change of address | 5 |  | 5 |  | 5 |  | ns |
| $\mathrm{t}_{\mathrm{v}(\mathrm{A}-\mathrm{P})}$ | $\overline{\mathrm{PE}}$ valid time after change of address | 15 |  | 15 |  | 15 |  | ns |

timing requirements over recommended ranges of supply voltage and operating free-air temperature

| PARAMETER |  | TMS2150-3 |  | TMS2150-4 |  | TMS2150-5 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{c}}(\mathrm{W})$ | Write cycle time, without writing $\overline{P E}$ | 30 |  | 40 |  | 50 |  | ns |
| $\mathrm{t}_{\mathrm{c}} \mathrm{PE}(\mathrm{W})$ | Write cycle time, writing $\overline{\mathrm{PE}}$ (see Note 3) | 35 |  | 40 |  | 50 |  | ns |
| ${ }^{t_{c}(\mathrm{rd}}$ ) | Read cycle time | 35 |  | 45 |  | 55 |  | ns |
| $\mathrm{t}_{\mathrm{w}}$ (RL) | Pulse duration, $\overline{\text { RESET }}$ low | 35 |  | 35 |  | 45 |  | ns |
| $\mathrm{t}_{\mathrm{w}}$ (WL) | Pulse duration, $\overline{\mathrm{W}}$ low, without writing $\overline{\mathrm{PE}}$ | 20 |  | 25 |  | 30 |  | ns |
| $\mathrm{t}_{\text {w }}$ PE(WL) | Pulse duration, $\bar{W}$ low, writing $\overline{\text { PE }}$ (see Note 3) | 35 |  | 40 |  | 45 |  | ns |
| $\mathrm{t}_{\text {su }}(\mathrm{A})$ | Address setup time before $\overline{\mathrm{W}}$ low | 0 |  | 0 |  | 0 |  | ns |
| $\mathrm{t}_{\text {su }}(\mathrm{D})$ | Data setup time before $\bar{W}$ high | 20 |  | 25 |  | 30 |  | ns |
| $\mathrm{t}_{\text {su }}(\mathrm{P})$ | $\overline{\mathrm{PE}}$ setup time before $\overline{\mathrm{W}}$ high (see Note 3) | 20 |  | 25 |  | 30 |  | ns |
| $\mathrm{t}_{\text {su }}(\mathrm{S})$ | Chip select setup time before $\bar{W}$ high | 20 |  | 25 |  | 30 |  | ns |
| $\mathrm{t}_{\text {SU(RH) }}$ | $\overline{\mathrm{RESET}}$ inactive setup time before first tag cycle | 0 |  | 0 |  | 0 |  | ns |
| th(A) | Address hold time after $\overline{\mathrm{W}}$ high | 0 |  | 0 |  | 5 |  | ns |
| $t_{\text {h }}(\mathrm{D})$ | Data hold time after $\bar{W}$ high | 5 |  | 5 |  | 10. |  | ns |
| th(P) | $\overline{\text { PE }}$ hold time after $\bar{W}$ high | 0 |  | 0 |  | 5 |  | ns |
| th(S) | Chip select hold time after $\bar{W}$ high | 0 |  | 0 |  | 0 |  | ns |
| taVWh | Address valid to write enable high. | 30 |  | 40 |  | 50 |  | ns |



## ac test conditions



## CACHE ADDRESS COMPARATOR

PARAMETER MEASUREMENT INFORMATION


FIGURE 1. $\overline{P E}$ OUTPUT LOAD CIRCUIT


FIGURE 2. MATCH OUTPUT LOAD CIRCUIT compare cycle timing (see Note 4)


NOTE 4: Input pulse levels are 0 V and 3 V , with rise and fall times of 5 ns . The timing reference levels on the input pulses are 0.8 V and 2.0 V . The timing reference level for output pulses is 1.5 V . See Figures 1 and 2 for output loading.

## PARAMETER MEASUREMENT INFORMATION

write cycle timing (see Note 4)

reset cycle timing (see Note 4)


NOTES: 3. Parameters $t_{w P E(W L)}$ and $t_{S u}(P)$ apply only during the write cycle time when writing a parity error, $t_{c} P E(W)$.
4. Input pulse levels are 0 V and 3 V , with rise and fall times of 5 ns . The timing reference levels on the input pulses are 0.8 V and 2.0 V . The timing reference level for output pulses is 1.5 V . See Figures 1 and 2 for output loading.


- Controls Operation of $8 \mathrm{~K}, 16 \mathrm{~K}, 32 \mathrm{~K}$, and 64K Dynamic RAMs
- Creates Static RAM Appearance
- One Package Contains Address Multiplexer, Refresh Control, and Timing Control
- Directly Addresses and Drives Up to 256K Bytes of Memory Without External Drivers
- Operates from Microprocessor Clock
- No Crystals, Delay Lines, or RC Networks
- Eliminates Arbitration Delays
- Refresh May Be Internally or Externally Initiated
- Versatile
- Strap-Selected Refresh Rate
- Synchronous, Predictable Refresh
- Selection of Distributed, Transparent, and Cycle-Steal Refresh Modes
- Interfaces Easily to Popular Microprocessors
- Strap-Selected Wait-State Generation for Microprocessor/Memory Speed Matching
- Ability to Synchronize or Interleave Controller with the Microprocessor System (including Multiple Controllers)
- 3-State Outputs Allow Multiport Memory Configuration
- Performance Ranges of 150 ns, 200 ns, or 250 ns


## description

The TMS4500A is a monolithic DRAM system controller designed to provide address multiplexing, timing, control and refresh/access arbitration functions to simplify the interface of dynamic RAMs to microprocessor systems.

TMS4500A . . . NL PACKAGE
(TOP VIEW)
CLK
RDY
REN 1

TMS4500A . . . FN PACKAGE (TOP VIEW)


The controller contains a 16 -bit multiplexer that generates the address lines for the memory device from the 16 system address bits and provides the strobe signals required by the memory to decode the address. An 8-bit refresh counter generates the 256-row addresses required for refresh.
A refresh timer is provided that generates the necessary timing to refresh the dynamic memories and assure data retention.
The TMS4500A also contains refresh/access arbitration circuitry to resolve conflicts between memory access requests and memory refresh cycles. The TMS4500A is offered in a 40-pin, 600-mil dual-in-line plastic package and 44-pin, 650-mil square plastic chip carrier package. It is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

pin descriptions
RAO-RA7 Input . Row Address - These address inputs are used to generate the row address for the multiplexer.
Column Address - These address inputs are used to generate the column address for the multiplexer.

Memory Address - These three-state outputs are designed to drive the addresses of the dynamic RAM array.
Address Latch Enable - This input is used to latch the 16 address inputs, $\overline{\mathrm{CS}}$ and REN1. This also initiates an access cycle if chip select is valid. The rising edge (low level to high level) of ALE returns $\overline{\operatorname{RAS}}$ to the high level.
$\overline{\mathrm{CS}} \quad$ Input Chip Select - A low on this input enables an access cycle. The trailing edge of ALE latches the chip select input.

## pin descriptions (continued)

| REN1 | Input |
| :--- | :--- |
| $\overline{\text { ACR }, ~ A C W ~}$ | Input |
|  |  |
| CLK | Input |
| $\overline{\text { REFREQ }}$ | Input/Output |

$\overline{\text { RASO }}, \overline{\text { RAS }} 1 \quad$ Outpu
$\overline{\text { CAS }}$ Output
TWST Input

FSO, FS1 Input

RAS Enable 1 - This input is used to select one of two banks of RAM via the $\overline{\text { RAS }} 0$ and $\overline{\text { RAS }} 1$ outputs when chip select is present. When it is low, $\overline{\mathrm{RAS}} 0$ is selected; when it is high, $\overline{\mathrm{RAS}} 1$ is selected.

Access Control, Read; Access Control, Write - A low on either of these inputs causes the column address to appear on MAO-MA7 and the column address strobe. The rising edge of $\overline{\mathrm{ACR}}$ or $\overline{\mathrm{ACW}}$ terminates the cycle by ending $\overline{\mathrm{RAS}}$ and $\overline{\mathrm{CAS}}$ strobes. When $\overline{\mathrm{ACR}}$ and $\overline{\mathrm{ACW}}$ are both low, MAO-MA7, $\overline{\mathrm{RAS}}, \overline{\mathrm{RAS} 1, \text { and } \overline{\mathrm{CAS}} \text { go into a high-impedance }}$ (floating) state.
System Clock - This input provides the master timing to generate refresh cycle timings and refresh rate. Refresh rate is determined by the TWST, FS1, FSO inputs.

Refresh Request - (This input should be driven by an open-collector output.) On input, a low-going edge initiates a refresh cycle and will cause the internal refresh timer to be reset on the next falling edge of the CLK. As an output, a low-going edge signals an internal refresh request and that the refresh timer will be reset on the next low-going edge of CLK. $\overline{\text { REFREO }}$ will remain low until the refresh cycle in progress and the current refresh address is present on MAO-MA7. (Note: REFREO contains an internal pull-up resistor with a nominal resistance of 10 kilohms.)

Row Address Strobe - These three-state outputs are used to latch the row address into the bank of DRAMs selected by REN1. On refresh both signals are driven.
Column Address Strobe - This three-state output is used to latch the column address into the DRAM array.

Ready - This totem-pole output synchronizes memories that are too slow to guarantee microprocessor access time requirements. This output is also used to inhibit access cycles during refresh when in cycle-steal mode.
Timing/Wait Strap - A high on this input indicates a wait state should be added to each memory cycle. In addition it is used in conjunction with FSO and FS1 to determine refresh rate and timing.

Frequency Select 0; Frequency Select 1 - These are strap inputs to select Mode and Frequency of operation as shown in Table 1.

TABLE 1. STRAP CONFIGURATION

| STRAP INPUT MODES |  |  | WAIT STATES FOR MEMORY ACCESS | REFRESH RATE | MINIMUM CLK FREQ. (MHz) | REFRESH FREQ. (kHz) | CLOCK <br> FOR EACH <br> FOR EACH <br> REFRESH |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| L | L | $\mathrm{L}^{+}$ | 0 | EXTERNAL | - | REFREQ | 4 |
| L | L | H | 0 | CLK +31 | 1,984 | 64-95 ${ }^{\ddagger}$ | 3 |
| L | H | L | 0 | CLK +46 | 2,944 | 64-85 ${ }^{\text { }}$ | 3 |
| L | H | H | 0 | CLK +61 | 3,904 | 64-82 ${ }^{\text {§ }}$ | 4 |
| H | L | L. | 1 | CLK + 46 | 2,944 | 64-85 ${ }^{\ddagger}$ | 3 |
| H | L | H | 1 | CLK +61 | 3,904 | 64-80 $\ddagger$ | 4 |
| H | H | L | 1 | CLK + 76 | 4,864 | 64-77 $\ddagger$ | 4 |
| H | H | H | 1 | CLK + 91 | 5,824 | 64-88! | 4 |

$\dagger$ This strap configuration resets the Refresh Timer circuitry.
$\ddagger$ The highest frequency in the refresh frequency column is the frequency that is produced if the minimum CLK frequency of the next select state is used.
${ }^{\S}$ The highest frequency in the refresh column is the refresh frequency if the CLK frequency is 5 MHz .
IThe highest frequency in the refresh column is the refresh frequency if the CLK frequency is 8 MHz .

## functional description

TMS4500A consists of six basic blocks; address and select latches, refresh rate generator, refresh counter, the multiplexer, the arbiter, and timing and control block.

## address and select latches

The address and select latches allow the DRAM controller to be used in systems that multiplex address and data on the same lines without external latches. The row address latches are transparent, meaning that while ALE is high, the output at MAO-MA7 follows the inputs RAO-RA7.

## refresh rate generator

The refresh rate generator is a counter that indicates to the arbiter that it is time for a refresh cycle. The counter divides the clock frequency according to the configuration straps as shown in Table 1. The counter is reset when a refresh cycle is requested or when TWST, FS1 and FSO are low. The configuration straps allow the matching of memories to the system access time.

Upon Power-Up it is necessary to provide a reset signal by driving all three straps to the controller low to initialize internal counters. A system's low-active, power-on reset ( $\overline{\mathrm{RESET}}$ ) can be used to accomplish this by connecting it to those straps that are desired high during operation. During this reset period, at least four clock cycles should occur.

## refresh counter

The refresh counter contains the address of the row to be refreshed. The counter is decremented after each refresh cycle. [A low-to-high transition on TWST sets the refresh counter to FF16 (25510).]

## multiplexer

The multiplexer provides the DRAM array with row, column, and refresh addresses at the proper times. Its inputs are the address latches and the refresh counter. The outputs provide up to 16 multiplexed addresses on eight lines.

## arbiter

The arbiter provides two operational cycles: access and refresh. The arbiter resolves conflicts between cycle requests and cycles in execution, and schedules the inhibited cycle when used in cycle-steal mode.

## timing and control block

The timing and control block executes the operational cycle at the request of the arbiter. It provides the DRAM array with $\overline{\operatorname{RAS}}$ and $\overline{\mathrm{CAS}}$ signals. It provides the CPU with a RDY signal. It controls the multiplexer during all cycles. It resets the refresh rate generator and decrements the refresh counter during refresh cycles.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted) $\dagger$

| Supply voltage range, VCC (see Note | -1.5 V to 7 V |
| :---: | :---: |
| Input voltage range (any input) | -1.5 V to 7 V |
| Continuous power dissipation | 1.2 W |
| Operating free-air temperature range | $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ |
| Storage temperature range | $65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |

† Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions" section of this specification is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.
NOTE 1: Voltage values are with respect to the ground terminal.
recommended operating conditions

| PARAMETER | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ | 4.5 | 5 | 5.5 | V |
| High-level input voltage, $\mathrm{V}_{1 \mathrm{H}}$ | 2.4 |  | 6 | V |
| Low-level input voltage, $\mathrm{V}_{\text {IL }}$ | $-1^{\ddagger}$ |  | 0.8 | $\checkmark$ |
| High-level output current, IOH |  |  | -1 | mA |
| Low-level output current, 1OL |  |  | 4 | mA |
| Short-circuit output current, IOS ${ }^{\text {§ }}$ |  |  | -50 | mA |
| Operating free-air temperature, $\mathrm{T}_{\mathrm{A}}$ | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

${ }^{\ddagger}$ The algebraic convention, where the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic voltage levels only.
${ }^{\S}$ Not more than one output should be shorted at a time.
electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  |  | TEST CONDITIONS | MIN | TYP ${ }^{\text {I }}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{OH}}$ High-level output voltage |  | MAO-MA7, RDY | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{I}^{\mathrm{OH}}=-1 \mathrm{~mA}$ | 2.4 |  |  | v |
|  |  | $\overline{\text { RAS } 0, ~ \overline{R A S} 1, ~ \overline{C A S}}$ |  | 2.7 |  |  |  |
|  |  | REFREQ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{OH}}=-100 \mu \mathrm{~A}$ | 2.4 |  |  |  |
| V ${ }_{\text {OL }}$ | Low-level output voltage |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}, \quad \mathrm{l}_{\mathrm{OL}}=4 \mathrm{~mA}$ |  |  | 0.4 | $\checkmark$ |
| ${ }_{1}$ | High-level input current except $\overline{\text { REFREQ }}$ |  | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
| ILL | Low-level input current | REFREQ | $V_{1}=0$ |  |  | -1.25 | mA |
|  |  | All others |  |  |  | -10 | $\mu \mathrm{A}$ |
| loz | Off-state output current |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}, \mathrm{~V}_{0}=0$ to 4.5 V |  |  | $\pm 50$ | $\mu \mathrm{A}$ |
| ${ }^{1} \mathrm{CC}$ | Operating supply current |  | $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ |  | 100 | 140 | mA |
| $\mathrm{C}_{\mathrm{i}}$ | Input capacitance |  | $\mathrm{V}_{1}=0, \quad \mathrm{f}=1 \mathrm{MHz}$ |  | 5 |  | pF |
| $\mathrm{C}_{0}$ | Output capacitance |  | $\mathrm{V}_{\mathrm{O}}=0, \quad \mathrm{f}=1 \mathrm{MHz}$ |  | 6 |  | pF |

$\Upsilon_{\text {All typical values are at }} \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

## timing requirements over recommended supply voltage range and operating free-air temperature (unless otherwise noted)

| PARAMETER |  | TMS4500A-15 | TMS4500A-20 | TMS4500A-25 | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN MAX | MIN MAX | MIN MAX |  |
| $\mathrm{t}_{\mathrm{C}}(\mathrm{C})$ | CLK cycle time | 100 | 120 | 140 | ns |
| $\mathrm{t}_{\mathrm{w}}(\mathrm{CH})$ | CLK high pulse duration | 40 | 40 | 40 |  |
| $\mathrm{t}_{\mathrm{w}}(\mathrm{CL})$ | CLK low pulse duration | 40 | 45 | 45 |  |
| $t_{t}$ | Transition time, all inputs | 50 | 50 | 50 |  |
| ${ }^{\text {t }}$ AEL-CL | Time delay, ALE low to CLK starting low (see Note 1) | 10 | 10 | 15 |  |
| ${ }^{\text {t }} \mathrm{CL}$-AEL | Time delay, CLK low to ALE starting low (see Note 1) | 10 | 10 | 15 |  |
| ${ }^{t} \mathrm{CL}-\mathrm{AEH}$ | Time delay, CLK low to ALE starting high (see Note 2) | 15 | 20 | 20 |  |
| $\mathrm{t}_{\mathrm{w}}(\mathrm{AEH})$ | Pulse duration, ALE high | 50 | 60 | 60 |  |
| tAV-AEL | Time delay, address REN1, $\overline{\mathrm{CS}}$ valid to ALE low | 5 | 10 | 15 |  |
| ${ }^{\text {t }}$ AEL-AX | Time delay, ALE low to address not valid | 10 | 10 | 10 |  |
| ${ }^{\text {t }}$ AEL-ACL | Time delay, ALE low to $\overline{\mathrm{ACX}}$ low (see Notes 3, 4, 5, and 6) | $t_{\text {h }}(\mathrm{RA})+30$ | $t_{\text {t }}(\mathrm{RA} A)+40$ | $t_{\text {h }}(\mathrm{RA})+50$ |  |
| ${ }^{\text {t }} \mathrm{ACH}-\mathrm{CL}$ | Time delay, $\overline{\mathrm{ACX}}$ high to CLK low (see Notes 3 and 7) | 20 | 20 | 20 |  |
| ${ }^{t} \mathrm{ACL} \cdot \mathrm{CH}$ | Time delay, $\overline{\mathrm{ACX}}$ low to CLK starting high (to remove RDY) | 30 | 30 | 30 |  |
| $t_{\text {R }} \mathrm{LL}-\mathrm{CL}$ | Time delay, $\overline{\text { REFREQ }}$ low to CLK starting low (see Note 8) | 20 | 20 | 20 |  |
| $\mathrm{t}_{\mathrm{w} \text { (ROL) }}$ | Pulse duration, $\overline{\text { REFREQ }}$ low | 20 | 20 | 20 |  |
| ${ }^{\text {t }}$ (ACL) | $\overline{\mathrm{ACX}}$ low duration (see Note 9) | 110 | 140 | 175 |  |

NOTES: 1. Coincidence of the trailing edge of CLK and the trailing edge of ALE should be avoided as the refresh/access occurs on the trailing CLK edge. A trailing edge of CLK should occur during the interval from $\overline{A C X}$ high to ALE Iow.
2. If $A L E$ rises before $\overline{A C X}$ and a refresh request is present, the falling edge of CLK after ${ }^{t} C L-A E H$ will output the refresh address to MAO-MA7 and initiate a refresh cycle.
3. These specifications relate to system timing and do not directly reflect device performance.
4. On the access grant cycle following refresh, the occurrence of $\overline{C A S}$ low depends on the relative occurrence of ALE low to $\overline{A C X}$ low. If $\overline{A C X}$ occurs prior to or coincident with ALE then $\overline{C A S}$ is timed from the, CLK high transition that causes $\overline{\operatorname{RAS}}$ low. If $\overline{A C X}$ occurs 20 ns or more after ALE then $\overline{\mathrm{CAS}}$ is timed from the CLK low transition following the CLK high transition causing $\overline{\mathrm{RAS}}$ low.
5. For maximum speed access (internal delays on both access and access grant cycles), $\overline{\mathrm{ACX}}$ should occur prior to or coincident with ALE.
6. $t_{h}(R A)$ is the dynamic memory row address hold time. $\overline{A C X}$ should follow ALE by ${ }^{t} A E L-C E L$ in systems where the required $t_{h}(R A)$ is greater than trEL-MAX minimum.
7. The minimum of 20 ns is specified to ensure arbitration will occur on falling CLK edge, $\mathrm{t}_{\mathrm{ACH}} \mathrm{CL}$ also affects precharge time such that the minimum $t_{A C H}-C L$ should be equal or greater than: $t_{w}(R H)-t_{W}(C L)+30 n s$ (for a cycle where $\overline{A C X}$ high occurs prior to ALE high) where $t_{W}(R H)$ is the DRAM $\overline{R A S}$ precharge time.
8. This parameter is necessary only if refresh arbitration is to occur on this low-going CLK edge (in systems where refresh is synchronized to external events).
9. The specification $t_{W}(A C L)$ is designed to allow a $\overline{C A S}$ pulse. This assures normal operation of the device in testing and system operation.
switching characteristics over recommended supply voltage range and operating free-air temperature range (see Figure 1)

| PARAMETER |  | TEST | TMS4500A-15 |  | TMS4500A-20 |  | TMS4500A-25 |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | CONDITIONS | MIN | MAX | MIN | MAX | MIN | MAX |  |
| ${ }^{\text {t }}$ AEL-REL | Time delay, ALE low to $\overline{\text { RAS }}$ starting low | $C_{L}=160 \mathrm{pF}$ |  | 35 |  | 40 |  | 50 |  |
| trAV-MAV | Time delay, row address valid to memory address valid |  |  | 45 |  | 50 |  | 60 |  |
| tAEH-MAV | Time delay, ALE high to valid memory address |  |  | 65 |  | 75 |  | 90 |  |
| ${ }^{\text {t AEL-RYL }}$ | Time delay, ALE to RDY starting low (TWST $=1$ or refresh in progress) | $C_{L}=40 \mathrm{pF}$ |  | 40 |  | 40 |  | 40 |  |
| ${ }^{\text {t }}$ AEL-CEL | Time delay, ALE low to $\overline{\mathrm{CAS}}$ starting low (see Note 10) | $C_{L}=160 \mathrm{pF}$ | 60 | 150 | 70 | 200 | 80 | 250 |  |
| ${ }^{\text {t AEH }}$-REH | Time delay, ALE high to $\overline{\mathrm{RAS}}$ starting high |  |  | 30 |  | 30 |  | 40 |  |
| ${ }^{\text {t } A C L}$-MAX | Row address valid after $\overline{\mathrm{ACX}}$ low |  | 15 |  | 20 |  | 25 |  |  |
| tMAV-CEL | Time delay, memory address valid to $\overrightarrow{C A S}$ starting low |  | 0 |  | 0 |  | 0 |  |  |
| ${ }^{\text {t }}$ ACL-CEL | Time delay, $\overline{\mathrm{ACX}}$ low to $\overline{\mathrm{CAS}}$ starting low (see Note 10) |  | 40 | 100 | 45 | 130 | 50 | 165 |  |
| tACH-REH | Time delay, $\overline{\mathrm{ACX}}$ to $\overline{\mathrm{RAS}}$ starting high |  |  | 30 |  | 40 |  | 50 |  |
| ${ }^{1} \mathrm{ACH}-\mathrm{CEH}$ | Time delay, $\overline{\mathrm{ACX}}$ high to $\overline{\mathrm{CAS}}$ starting high |  | 5 | 30 | 10 | 40 | 15 | 50 | ns |
| tACH-MAX | Column address valid after $\overline{A C X}$ high |  | 10 |  | 15 |  | 15 |  | ns |
| ${ }^{\text {t }} \mathrm{CH}-\mathrm{RYH}$ | Time delay, CLK high to RDY starting high (after $\overline{\operatorname{ACX}}$ low) (see Note 11) | $C_{L}=40 \mathrm{pF}$ |  | 40 |  | 45 |  | 60 |  |
| ${ }^{\text {tr }}$ RFL-RFL | Time delay, $\overline{\text { REFREQ external till }}$ supported by $\overline{\text { REFREQ }}$ internal |  |  | 30 |  | 35 |  | 35 |  |
| ${ }^{\text {t }} \mathrm{CH}-\mathrm{RFL}$ | Time delay, CLK high till $\overline{\text { REFREO }}$ internal starting low |  |  | 30 |  | 35 |  | 45 |  |
| ${ }^{\text {t CL-MAV }}$ | Time delay, CLK low till refresh address valid | $C_{L}=160 \mathrm{pF}$ |  | 75 |  | 100 |  | 125 |  |
| ${ }^{\text {t }} \mathrm{CH}$-RRL | Time delay, CLK high till refresh $\overline{\text { RAS }}$ starting low |  | 10 | 50 | 15 | 60 | 20 | 80 |  |
| ${ }^{\text {t M M }}$ M-RRL | Time delay, refresh address valid till refresh $\overline{\mathrm{RAS}}$ low |  | 5 |  | 5 |  | 5 |  |  |
| ${ }^{\text {t }} \mathrm{CL}$-RFH | Time delay, CLK low to $\overline{\text { REFREQ }}$ starting high ( 3 cycle refresh) |  |  | 50 |  | 55 |  | 75 |  |
| ${ }^{\text {t }} \mathrm{CH}-\mathrm{RFH}$ | Time delay, CLK high to $\overline{\text { REFREQ }}$ starting high (4 cycle refresh) |  |  | 50 |  | 55 |  | 75 |  |
| ${ }^{t} \mathrm{CH}-\mathrm{RRH}$ | Time delay, CLK high to refresh $\overline{\text { RAS }}$ starting high |  | 5 | 35 | 10 | 45 | 10 | 60 |  |
| ${ }^{\text {t }}$ CH-MAX | Refresh address valid after CLK high |  | . 15 |  | 20 |  | 25 |  |  |

NOTES: 10. The falling edge of $\overline{C A S}$ occurs when both ALE low to $\overline{C A S}$ low time delay (tAEL-CEL) and $\overline{A C X}$ low to $\overline{C A S}$ low time delay ( $t_{A C L}$ CEL) have elapsed, i.e., if $\overline{A C X}$ goes low prior to ( $\mathrm{t} A E L-C E L-t_{A C L}$ CEL) after the falting edge of ALE, the falling edge of $\overline{C A S}$ is measured from the falling edge of ALE ( $\mathrm{t} A E L-C E L$ ). Otherwise, the access time increases and the falling edge of $\overline{C A S}$ is measured from the falling edge of $\overline{A C X}$ (t $A C L-C E L$ ).
11. RDY returns high on the rising edge of CLK. If TWST $=0$, then on an access grant cycle RDY goes high on the same edge that causes access $\overline{\text { RAS }}$ low. If TWST $=1$, then RDY goes to the high level on the first rising CLK edge after $\overline{\mathrm{ACX}}$ goes low on access cycles and on the next rising edge after the edge that causes access $\overline{\mathrm{RAS}}$ low on access grant cycles (assuming $\overline{\mathrm{ACX}}$ low).

## switching characteristics over recommended supply voltage range and operating free-air temperature

 range (see Figure 1) (continued)| PARAMETER |  | TEST CONDITIONS | TMS4500A-15 | TMS4500A-20 | TMS4500A-25 | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN MAX | MIN MAX | MIN MAX |  |
| ${ }^{\text {t }}$ CH-REL | Time delay, CLK high till access $\overline{\text { RAS }}$ starting low |  | $C_{L}=160 \mathrm{pF}$ | 60 | 70 | 95 | ns |
| ${ }^{\text {t }}$ CL-CEL | Time delay, CLK low to access $\overline{\mathrm{CAS}}$ starting low (see Note 12) | 125 |  | 140 | 185 |  |  |
| ${ }^{\text {t CL-MAX }}$ | Row address valid after CLK low | 25 |  | 30 | 40 |  |  |
| trel-MAX | Row address valid after $\overline{\text { RAS }}$ low | 25 |  | 30 | 35 |  |  |
| t ${ }^{\text {AEH}}$-MAX | Column address valid after ALE high | $C_{L}=160 \mathrm{pF}$ | 10 | 15 | 20 |  |  |
| $\mathrm{t}_{\text {dis }}$ | Output disable time (3-state outputs) |  | 100 | 125 | 165 |  |  |
| ten | Output enable time (3-state outputs) |  | 75 | 80 | 105 |  |  |
| ${ }^{\text {t }}$ CAV-CEL | Time delay, column address valid to $\overline{\mathrm{CAS}}$ starting low after refresh |  | 0 | 0 | 0 |  |  |
| ${ }^{\text {t }}$ CH-CEL | Time delay, CLK high to access $\overline{\text { CAS }}$ starting low (see Note 12) |  | 180 | 200 | 235 |  |  |
| ${ }^{\text {t }}$ ACL-CL | $\overline{A C X}$ low to CLK starting low | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ | 25 | 35 | 45 |  |  |
| $t_{\text {ACL-RYH }}$ | $\overline{\text { ACX }}$ low to RDY starting high | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ | 40 | 50 | 60 |  |  |
| ${ }^{\text {t CL-ACL }}$ | CLK low to $\overline{\text { ACX }}$ starting low | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ | 0 | 0 | 0 |  |  |
|  | $\overline{\text { CAS }}$ fall time | 320 | 15 | 20 | 25 |  |  |
| $\mathrm{t}_{\text {t }}$ (CEH) | $\overline{\text { C̄AS }}$ rise time | 320 | 30 | 35 | 45 |  |  |
| $\mathrm{t}_{\text {t }}$ (REL) | RAS fall time | $C_{L}=160 \mathrm{pF}$ | 15 | 20 | 25 |  |  |
| $\mathrm{t}_{\mathrm{t}}$ (REM) | $\overline{\text { RAS }}$ rise time |  | 15 | 20 | 25 |  |  |
| $\mathrm{t}_{\mathrm{t}}(\mathrm{MAV})$ | Address transition time |  | 20 | 20 | 25 |  |  |
| $t_{t}\left(\mathrm{RY},{ }_{\text {c }}\right.$ | RDY fall time | $\mathrm{C}_{\mathrm{L}}=40 \mathrm{pF}$ | 10 | 15 | 20 |  |  |
| $t_{t}(\mathrm{RYH})$ | RDY rise time |  | 20 | 25 | 35 |  |  |

NOTE 12: On the access grant cycle following refresh, the occurrence of $\overline{C A S}$ low depends on the relative occurrence of ALE low to $\overline{A C X}$ low. If $\overline{A C X}$ occurs prior to or coincident with ALE then $\overline{C A S}$ is timed from the CLK high transition that causes $\overline{\operatorname{RAS}}$ low. If $\overline{A C X}$ occurs 20 ns or more after ALE then $\overline{\mathrm{CAS}}$ is timed from the CLK low transition following the CLK high transition causing $\overline{\mathrm{RAS}}$ low. (See Refresh Cycle Timing Diagram)

## PARAMETER MEASUREMENT INFORMATION



FIGURE 1 - LOAD CIRCUIT

## TMS4500A <br> DYNAMIC-RAM CONTROLLER

## access cycle timing


refresh request timing

ready timing (ACX during CLK high) (see notes 13 thru 16)


RDY starting high is timed from $\overline{\mathrm{ACX}}$ law (t ACL -RYM) for the condition $\overline{\mathrm{ACX}}$ going low while CLK high.
ready timing (ACX during CLK low) (see notes 13 thru 16)


RDY starting high is timed from CLK high ( $\mathrm{t} \mathrm{CH}-\mathrm{RYH}$ ) for the condition ACX going low while CLK low.
NOTES: 13. For RDY high transition (during normal access) to be timed from the rising edge of CLK, $\overline{\mathrm{ACX}}$ must occur $\mathrm{CL}-\mathrm{ACL}$ after the falling edge of CLK.
14. For $\overline{A C X}$ prior to the falling edge of CLK by $t_{A C L}$. $C L$, the RDY high transition will be tACL-RYH.
15. $t^{t} A C L-C L$ is a limiting parameter for control of RDY to be dependent upon $\overline{A C X}$ low.
 clock edge or falling edge of $\overline{\mathrm{ACX}}$.
output 3-state timing

ACR-ACW

refresh cycle timing (three-cycle)

refresh cycle timing (four-cycle)

${ }^{\dagger}$ On access grant cycle following refresh, $\overline{\mathrm{CAS}}$ low and address multiplexing are timed from CLK high transition ( $\mathrm{t}_{\mathrm{C}} \mathrm{CH}-\mathrm{CEL}$ ) if $\overline{\mathrm{ACX}}$ tow occurs prior to or coincident with the falling edge of ALE.
$\ddagger$ On access grant cycle following refresh, $\overline{\mathrm{CAS}}$ low and address multiplexing are timed from CLK low transition ( t CL-CEL) if $\overline{\mathrm{ACX}}$ low occurs 20 ns or more after the falling edge of ALE.
typical access/refresh/access cycle
(three-cycle, TWST is low)

typical access/refresh/access cycle
(four-cycle, TWST is low)


## TMS4500A

DYNAMIC-RAM CONTROLLER
typical access/refresh/access cycle
(three-cycle, TWST is high)

typical access/refresh/access cycle (four-cycle, TWST is high)


## General Information

1

Numerical Index
Glossary
Explanation of Function Tables
Parameter Measurement Information
Functional Index

## LSI Devices

## Application Reports

Advanced Schottky Family
Error Detection and Correction
Memory Mapping
Bit-Slice Processor 8-Bit Family
Excerpt - SN74AS888, SN74AS890
Bit-Slice Processor User's Guide

## Mechanical Data

# Advanced Schottky Family 

3

## IMPORTANT NOTICE

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## Advanced Schottky Family (ALS/AS) Application

## Contents

Title Page
INTRODUCTION TO ADVANCED SCHOTTKY FAMILY ..... 3-9
Speed-Power Slots Filled By Advanced Schottky TTL ..... 3-9
Additional Advantages Offered by 'ALS and 'AS Devices ..... 3-9
Concepts of Defining 'ALS and 'AS ..... 3-10
Compatibility With Other TTL ..... 3-10
Fanout ..... 3-10
Using the Schottky Barrier-Diode ..... 3-10
Analysis of Schottky-Clamped Transistor ..... 3-10
Analysis of 'ALS and 'AS NAND Gates ..... 3-13
Circuit Parameters ..... 3-16
Transfer Characteristics ..... 3-16
Input Characteristics ..... 3-17
Low-Level Input Current ..... 3-17
Input Clamping Diode Test ..... 3-18
High-Level Input Current ..... 3-18
Input Breakdown Test ..... 3-18
Output Characteristics ..... 3-18
High-Level Output Characteristics ..... 3-18
Low-Level Output Characteristics ..... 3-19
Switching Speed ..... 3-19
DC Noise Margins ..... 3-20
Specified Logic Levels and Thresholds ..... 3-22
Noise Rejection ..... 3-22
GUIDELINES FOR SERIES 'ALS/'AS TTL SYSTEM DESIGN ..... 3-24
Power Supply Regulation ..... 3-25
Supply Voltage Ripple ..... 3-27
Noise Considerations ..... 3-28
Noise Types and Control Methods ..... 3-28
Shielding ..... 3-29
Grounding and Decoupling ..... 3-29
Cross Talk ..... 3-34
Back-Panel Interconnections ..... 3-34
Printed Circuit Card Conductors ..... 3-36
Transmission-Line Driving Reflections ..... 3-37
APPENDIXES
A Normalized Load Factors ..... 3-45
B Letter Symbols, Terms, and Definitions ..... 3-46
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## List of Illustrations

Figure Title Page
1 Speed-Power Relationships of Digital Integrated Circuits ..... 3-10
2 Series 54/74 TTL Family Compatible Levels Showing DC Noise Margins ..... 3-11
3 Fanout Capability ..... 3-11
4 Baker Clamp ..... 3-11
5 Schottky Clamped-Transistor ..... 3-11
6 Schottky Barrier-Diode ..... 3-12
7 Schottky Barrier-Diode Energy Diagrams ..... 3-12
8 Metal-N Diode Current-Voltage Characteristics ..... 3-12
9 Difference Between P-N and Schottky Barrier-Diodes ..... 3-13
10 Standard Process ('LS/'S) ..... 3-13
11 Advanced Process ('ALS/'AS) ..... 3-13
12 'ALSOOA NAND Gate Schematic ..... 3-14
13 'AS00 NAND Gate Schematic ..... 3-15
14 Input Voltage vs Output Voltage 'ALS/'AS ..... 3-16
15 Input Current vs Input Voltage for TTL Families ..... 3-17
16 Low-Level Input Current vs High-Level Input Voltage ..... 3-18
17 DC Equivalent Input Circuit for Series 'ALS Gates ..... 3-18
18 Equivalent Output Circuit for 'ALS/'AS Gates ..... 3-19
19 High-Level Output Voltage vs High-Level Output Current ..... 3-19
20 Low-Level Output Circuit for 'ALS/'AS Gates ..... 3-20
21 Low-Level Output Voltage vs Low-Level Output Current ..... 3-20
22 High- to Low-Level Propagation Delay vs Load Capacitance ..... 3-21
23 Low- to High-Level Propagation Delay vs Load Capacitance ..... 3-21
24 Power Dissipation per Gate vs Frequency ..... 3-22
25 Stray Coupling Capacitance ..... 3-23
26 Evaluations of Gate Response to Fast Input Pulses ..... 3-23
27 Theoretical Required Pulse Width vs Pulse Amplitude for 'ALS and 'AS Inputs ..... 3-24
28 Parameter Measurement Information ..... 3-25
29 Effect of Source Impedance on Input Noise ..... 3-28
30 Spurious Output Produced by Supply Voltage Ripple ..... 3-28
31 Effect of Ground Noise on Noise Margin ..... 3-28
32 Typical Logic Circuit with Noisy Input ..... 3-28
33 Diagram Representing a Gate Driving a Transmission Line ..... 3-29
34 Noise Generation Caused by Poor Transmission-Line Return ..... 3-29
35 Ideal Transmission-Line Current Handling ..... 3-30
36 Circuit with Effective Capacitive Loading ..... 3-30
37 Supply Current Transient Comparisons ..... 3-31
38 Transmission-Line Power Buses ..... 3-33
39 Capacitive Storage Supply Voltage System ..... 3-33
40 Commonly Used Power Distribution and Decoupling System ..... 3-33
41 Equivalent Circuit for Sending Line ..... 3-34
42 Equivalent Circuit for Cross Talk ..... 3-34
43 Capacitive Cross Talk Between Two Signal Lines ..... 3-35
44 Coupling Impedances Involved in Cross Talk ..... 3-35
45 Equivalent Cross-Talk Network ..... 3-35
46 Microstrip Line ..... 3-36
47 Strip Line ..... 3-36
48 Line Spacing Versus Cross-Talk Constant ..... 3-37
49 TTL Bergeron Diagram ..... 3-37
50 'ALS/'AS Driving Twisted Pair ..... 3-37

## List of Illustrations (Continued)

Figure Title Page
51 'AS - ve Transition Bergeron Diagram ..... 3-38
52 'AS - ve Voltage/Time Plot ..... 3-38
53 'AS + ve Transition Bergeron Diagram ..... 3-39
54 'AS + ve Voltage/Time Plot ..... 3-39
55 'ALS - ve Transition Bergeron Diagram ..... 3-40
56 'ALS - ve Voltage/Time Plot ..... 3-40
57 'ALS + ve Transition Bergeron Diagram ..... 3-41
58 'ALS + ve Voltage/Time Plot ..... 3-41
59 Oscilloscope Photograph of 'AS00 - ve Transition Using 50-Ohm Line ..... 3-42
60 Oscilloscope Photograph of 'AS00 + ve Transition Using 50-Ohm Line ..... 3-42
61 Oscilloscope Photograph of 'ASOO - ve Transition Using 25-Ohm Line ..... 3-42
62 Oscilloscope Photograph of 'ASO0 + ve Transition Using 25-Ohm Line ..... 3-42
63 Oscilloscope Photograph of 'ALS00A - ve Transition Using 50-Ohm Line ..... 3-42
64 Oscilloscope Photograph of 'ALS00A + ve Transition Using 50-Ohm Line ..... 3-42
65 Oscilloscope Photograph of 'ALS00A - ve Transition Using 25-Ohm Line ..... 3-43
66 Oscilloscope Photograph of 'ALS00A + ve Transition Using 25-Ohm Line ..... 3-43
List of Tables
Table Title ..... Page
1 Typical Performance Characteristics by TTL Series ..... 3-10
2 Worst-Case Output Parameters ..... 3-22
3 Guidelines for Systems Design for Advanced Schottky TTL ..... 3-26
4 Guidelines for Printed Circuit Board Layout Advanced Schottky TTL ..... 3-26
5 Guidelines for General Usage of Advanced Schottky TTL ..... 3-27
6 Guidelines for Gates and Flip-Flops Using Advanced Schottky TTL ..... 3-27
7 Typical Impedance of Microstrip Lines ..... 3-36
8 Typical Impedance of Strip Lines ..... 3-36
A-1 Normalized Input Currents ..... 3-45
A-2 Fanout Capability ..... 3-46

## INTRODUCTION

The purpose of this Application Report is to assist the designers of high-performance digital logic systems in the use of the new series of Advanced Schottky-clamped* TTL integrated circuits.

Detailed electrical characteristics of these devices are provided and, if available, tables have been included that compare specific parameters of the devices with those of other logic families. In addition, interfamily information is provided to allow system designers to mix logic families in the same circuit. This allows the designer to use the relative merits of each logic family in high preformance state-of-theart designs.

The major subject areas covered in this Application Report are as follows:

- Advanced Schottky process
- Fanouts
- Transfer characteristics
- Input and output parameters
- Speed and power information
- Noise margins
- Power supply considerations
- Noise sources and their abatement
- Back panel and printed circuit wiring guidelines
- Line driving and receiving


## INTRODUCTION TO ADVANCED SCHOTTKY-CLAMPED TTL

Series 54/74 transistor-transistor logic (TTL) has, since its introduction in 1965, become the most popular digital integrated circuit logic family ever offered. Its popularity has allowed the development of high-volume production techniques which have made it the most economical approach to the implementation of major portions of medium-to-high performance digital logic systems. These systems range from simple decision making to highly complex real-time computer installations that handle worldwide data processing.

The proliferation of and economical impact of these digital logic systems has created a demand for constant improvement in efficiency. In response to demand, Texas Instruments examined the advantages gained by Schottky clamping. An increase in speed and performance was discovered in the use of Schottky barrier-diode clamping. The process was patented in the United States and the Schottky series 54S/74S catalog parts were made available in the early 1970s. A series 54LS/74LS was introduced later. The series 54LS/74LS was slower that the 54S/74S series but had a much lower power consumption.

[^57]Recent innovations in integrated circuit design have made it possible to develop two new families: the Advanced Schottky (54AS/74AS) series and the Advanced Low-Power Schottky (54ALS/74ALS) series. The 'ALS and 'AS series provide considerable higher speeds than the 'LS and 'S series, respectively. The 'ALS series offers a substantial reduction in power consumption over the 'LS series, and the 'AS series offers a substantial reduction in power consumption over the 'S series. The 'ALS/'AS series is pin-to-pin compatible with the 'LS/'S series.

## SPEED-POWER SLOTS FILLED BY 'ALS AND 'AS TTL

Digital integrated circuits have historically been characterized for both speed and power. The series $54 \mathrm{~S} / 74 \mathrm{~S}$ devices contain 19 mW NAND gates and $125-\mathrm{MHz}$ flip-flops and the series 54LS/74LS devices contain 2-mW NAND gates and $45-\mathrm{MHz}$ flip-flops. Either of these logic families could be used to design a $2-\mathrm{MHz}$ system, therefore categorization strictly on the basis of power and speed is inconclusive with respect to system efficiency. To provide a means of measuring the overall circuit efficiency and performance, a speed-power product efficiency index for integrated circuits was developed. The rating of an integrated circuit is obtained by multiplying the gate propagation delay by the gate power dissipation.

Table 1 provides propagation delay times, power dissipation, and speed-power product for the Texas Instruments TTL series. In addition, it provides flip-flop frequency for each family as an indicator of system performance. The speed-power product rating system (measured in picojoules) is divided into circuits where speed is the prime factor and circuits where low-power is the prime factor. The 'ALS series speed-power product is approximately 4 times less than that of the 'LS series and the 'AS series speed-power product is approximately 4 times less than the 'S series. Figure 1 is a graphic analysis of the speed-power points for the various TTL families.

## ADDITIONAL ADVANTAGES OFFERED BY 'ALS AND 'AS DEVICES

The 'ALS and 'AS devices offer the following additional advantages:

1. TTL compatible with $54 / 74,54 \mathrm{~S} / 74 \mathrm{~S}, 54 \mathrm{~L} / 74 \mathrm{~L}$, $54 \mathrm{LS} / 74 \mathrm{LS}$, and $54 \mathrm{H} / 74 \mathrm{H}$ series gates for selectively upgrading existing systems
2. Suppresses the effects of line ringing and significantly reduces undershoot
3. Higher thresholds (noise immunity) and better stability across operating free-air temperature range
4. Input current requirement reduced by up to $50 \%$

Table 1. Typical Performance Characteristics by TTL Series

|  | MINIMIZING POWER |  |  |  |  | MINIMIZING DELAY TIME |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CIRCUIT TECHNOLOGY | FAMILY | PROP DELAY (ns) | $\begin{aligned} & \hline \text { PWR } \\ & \text { DISS } \\ & (\mathrm{mW}) \\ & \hline \end{aligned}$ | SPD/PWR PRODUCT (pJ) | MAXIMUM FLIP-FLOP FREQ ( MHz ) | FAMILY | PROP DELAY (ns) | $\begin{aligned} & \text { PWR } \\ & \text { DISS } \\ & \text { (mW) } \end{aligned}$ | SPD/PWR PRODUCT (pJ) | MAXIMUM FLIP-FLOP FREQ ( MHz ) |
|  | TTL | 10 | 10 | 100 | 35 | TTL | 10 | 10 | 100 | 35 |
| d | LTTL | 33 | 1 | 33 | 3 | H TTL | 6 | 22 | 132 | 50 |
|  | LS TTL | 9 | 2 | 18 | . 45 | S TTL | 3 | 19 | 57 | 125 |
|  | 'ALS | 4 | 1.2 | 4.8 | 70 | 'AS | 1.7 | 8 | 13.6 | 200 |



Figure 1. Speed-Power Relationships of Digital Integrated Circuits
5. Fanout is doubled
6. Terminated lines or controlled impedance circuit boards are normally not required.
7. The 'AS series offers shorter propagation delays and higher clock frequencies with relatively low power consumption.
8. The maximum flip-flop frequency has been increased to 200 MHz .

## CONCEPTS OF DEFINING SERIES 'AS AND 'ALS

Both the 'ALS and 'AS series are electrically and pinout compatible with existing TTL series. The 'ALS series is suitable for replacing all TTL families except in the very highest frequency applications. Replacement with 'ALS will result in lower power consumption, smaller power supply current spikes, and, in some cases, better noise immunity than the other families. In those cases where a very high operating frequency is required, the 'AS series can be used. The 'AS devices require less than one-half of the supply current of the 'S series and has approximately twice the clocking frequency. The 'ALS devices are ideal for improving effeciency at the lower speeds. The 'AS devices
are ideal for replacement of high-speed logic families including ECL 10 K series.

## Compatibility With Other TTL Families

To ensure complete electrical compatibility in systems using or intending to use a mixture of existing TTL families and the new 'ALS/'AS families, specific guidelines have been implemented. These guidelines ensure the continuation of desirable characteristics and incorporate newer techniques to improve performance and/or simplify the use of TTL families. Figure 2 illustrates the comparison of essential parameters of each family and shows that complete compatibility is maintained throughout the $54 / 74$ families.

## Fanout

The compatible ratings for fanout simplify the implementation of logic and provide a freedom of choice in the use of any of the seven performance ranges to design a digital logic system. Any of the Texas Instruments TTL series gates can be used to drive any other gate without the use of an interface or level-shifting circuit. The use of totem-pole-(push-pull) type output stages provides a low output impedance and the capability for both sourcing and sinking current. The output is easily adapted for driving MOS and CMOS circuits as well as the interface circuits between the output and the devices it controls. Figure 3 illustrates fanout capability.

## USING THE SCHOTTKY BARRIER DIODE

The Advanced Schottky Family has been developed from two earlier concepts: the Baker Clamp and the Schottky Barrier-Diode (SBD). The use of the Baker Clamp and SBD concepts resulted in the Schottky Clamped Transistor. The Schottky clamped transistor produced the increased switching speed associated with the S series integrated circuits. The additional advances that have led to the development of 'ALS and 'AS gates and the actual gates are discussed later.

## Analysis of the Schottky Clamped Transistor

The use of the Baker Clamp, shown in Figure 4, is a method of avoiding saturation of a discrete transistor. The diode forward voltage is 0.3 V to 0.4 V as compared to 0.7 V for the base-emitter junction diode. When the transistor is turned on, base current drives the transistor toward


Figure 2. Series 54/74 TTL Family Compatible Levels Showing DC Noise Margins


Figure 3. Fanout Capability


Figure 4. Baker Clamp
saturation. The collector voltage drops, the germanium diode begins to conduct forward current, and excess base drive is diverted from the base-collector junction of the transistor. This causes the transistor to be held out of deep saturation, the excess base charge to not be stored, and the turn-off time to be dramatically reduced.

A germanium diode cannot be incorporated into a monolithic silicon integrated circuit. Therefore, the germanium diode must be replaced with a silicon diode which


SYMBOL FOR MONOLITHIC SBD-CLAMPED TRANSISTOR

Figure 5. The Schottky-Clamped Transistor
has a lower forward voltage drop than the base-collector junction of the transistor. A normal p-n diode will not meet this requirement. The SBD illustrated in Figure 5 can be used to meet the requirement.

The SBD illustrated in Figure 6 is a rectifying metalsemiconductor contact formed between a metal and a highly doped N semiconductor.


Figure 6. Schottky Barrier-Diode
The qualitative physics of an SBD is illustrated in Figure 7. The valence and conduction bands in a metal overlap make available a large number of free-energy states. The free-energy states can be filled by any electrons which are injected into the conduction band. A finite number of electrons exist in the conduction band of a semiconductor. The number of electrons depends mainly upon the thermal energy and the level of impurity atoms in the material. When a metal-semiconductor junction is formed, free electrons flow across the junction from the semiconductor, via the conduction band, and fill the free-energy states in the metal. This flow of electrons builds a depletion potential across the barrier. This depletion potential opposes the electron flow and, eventually, is sufficient to sustain a balance where there is no net electron flow across the barrier.

Under forward bias (metal positive), there are many electrons with enough thermal energy to cross the barrier potential into the metal. This forward bias is called "hot injection." Because the barrier width is decreased as forward bias $\mathrm{V}_{\mathrm{F}}$ increases, forward current will increase rapidly with an increase in $\mathrm{V}_{\mathrm{F}}$.

When the SBD is reverse biased, electrons in the semiconductor require greater energy to cross the barrier. However, electrons in the metal see a barrier potential from the side essentially independent of the bias voltage and a small net reverse current will flow. Since this current flow is relatively independent of the applied reverse bias, the reverse current flow will not increase significantly until avalanche breakdown occurs.

A simple metal-n semiconductor collector contact is an ohmic contact while the SBD contact is a rectifying contact. The difference is controlled by the level of doping in the semiconductor material. As the doping is increased, the contact becomes more ohmic. Figure 8 illustrates the currentvoltage characteristics according the doping applied.

Current in the SBD is carried by majority carriers. Current in the p-n junction is carried by minority carriers. The resultant minority carrier storage causes the switching


Figure 8. Metal-N Diode Current-Voltage Characteristics


Figure 7. Schottky Barrier-Diode Energy Diagrams
time of a p-n junction to be limited when switched from forward bias to reverse bias. A p-n junction is inherently slower than an SBD even when doped with gold.

Another major difference between the SBD and p-n junction is the forward voltage drop. For diodes of the same surface area, the SBD will have a larger forward current at the same forward bias regardless of the type of metal used. The SBD forward voltage drop is lower at a given current than a p-n junction. Figure 9 illustrates the current carriers and forward current-voltage characteristics differences between the SBD and p-n junction. The SBD meets the requirements of a silicon diode which will clamp a silicon $\mathrm{n}-\mathrm{p}-\mathrm{n}$ transistor out of saturation.


Figure 9. Differences Between P-N and Schottky Barrier-Diodes

The Advanced Schottky process differs from the Schottky process in that it uses ion implantation of impurities instead of diffusion. Ion implantation gives greater control on the depth of doping and resolution. Because of a thinner epitaxial layer and smaller all around geometries, smaller parasitic capacitances are encountered. The performance of the SBD is also enhanced by the use of oxide isolation of the transistors. This reduces the collector-substrate capacitance. Figure 10 illustrates the 'LS/'S process which consists of conventional masks, junction isolation, and a


Figure 10. Standard Process ('LS/'S)


Figure 11. Advanced Process ('ALS/'AS)
standard metal system and Figure 11 illustrates the 'ALS/'AS process which consists of composed masks, ion implantation, oxide isolation, and a standard metal system.

## Analysis of 'ALS and 'AS NAND Gates

The 'ALS and 'AS NAND gates in Figures 12 and 13 combine the desirable features of improved TTL circuits with the technological advantages of full Schottky clamping, ion implantation, and oxide isolation to achieve very fast switching times at a reduced speed-power product. The improvements and advantages are as follows:

1. Full Schottky clamping of all saturating transistors virtually eliminates storing excessive base charge and significantly enhances turn-off time of the transistors.
2. Elimination of transistor storage time provides stable switching times across the temperature range.
3. An active turn-off is added to square up the transfer characteristic and provide an improved high-level noise immunity.


Figure 12. 'ALS00A NAND Gate Schematic
4. Input and output clamping is implemented with Schottky diodes to reduce negative-going excursions on the inputs and outputs. Because of its lower forward voltage drop and fast recovery time, the Schottky input diode provides improved clamping action over a conventional $\mathrm{p}-\mathrm{n}$ junction diode.
5. The ion implantation process allows small geometries giving less parasitic capacitances so that switching times are decreased.
6. The reduction of the epi-substrate capacitance using oxide isolation also decreases switching times.
A key feature of the 'ALS and 'AS families is the improvement in typical input-threshold voltage. Figure 12 is a schematic diagram of the 'ALSOOA NAND gate. Figure 13 is a schematic diagram of the 'AS00 NAND gate. The input threshold voltage of the devices is determined by the equation:

$$
\begin{align*}
\mathrm{VT}= & \mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q} 2+\mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q} 3 \\
& +\mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q} 5-\mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q1A} \\
& \left(\text { or } \mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q} 1 \mathrm{~B}\right) \tag{1}
\end{align*}
$$

From Eq. (1) it can be determined that the input threshold voltage is two times $\mathrm{V}_{\mathrm{BE}}$ or approximately 1.4 V . Low-level input current $\mathrm{I}_{\text {IL }}$ is reduced in the 'ALSOOA/'ASOO gates because of the improved input circuits. Buffering by transistors Q1A (or Q1B) and Q2 causes a significant reduction in low-level input current. Lowlevel input current is determined by the equation:

$$
\begin{align*}
\mathrm{I}_{\mathrm{IL}}= & \mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{BE}} \text { of Q1A } \\
& -\mathrm{V}_{\mathrm{I}} /\left[\mathrm{R}\left(\mathrm{~h}_{\mathrm{FE}} \text { of Q1A }+1\right)\right] \tag{2}
\end{align*}
$$

By using Eq. (2) low-level input current is reduced by at least the factor of $\mathrm{h}_{\mathrm{FE}}$ of Q1A +1 and is typically $-10 \mu \mathrm{~A}$ for the 'ALS00A and $-50 \mu \mathrm{~A}$ for the 'AS00. Highlevel output voltage $\mathrm{V}_{\mathrm{OH}}$ is determined primarily by $\mathrm{V}_{\mathrm{CC}}$,


Figure 13. 'AS00 NAND Gate Schematic
resistors R4 and R7, and transistors Q6 and Q7. With no load, the high-level output voltage is approximately equal to $\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{BE}}$ of Q 6 because the voltage across resistor R 4 is 0 V . For medium-level currents, the high-level output voltage is equal to $\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{BE}}$ of $\mathrm{Q} 6-\mathrm{V}_{\mathrm{BE}}$ of Q 7 because of the Darlington gain of transistors Q6 and Q7. The current through resistor R3 is typically less than $1 \mu \mathrm{~A}$ and, therefore, the voltage drop is negligible. As conduction through transistors Q6 and Q7 is increased, the voltage drop across limiting resistor R7 will increase until the Schottky clamping diode of transistor Q6 starts to become forward biased. At this point, the current through resistor R3 (and the voltage drop) is no longer negligible and the high-level output voltage is determined by:

$$
\begin{align*}
\mathrm{v}_{\mathrm{OH}}= & \mathrm{V}_{\mathrm{CC}}-\mathrm{I}_{\mathrm{OH}} \text { through } \mathrm{R} 7 \times \mathrm{R} 7 \\
& -\mathrm{v}_{\mathrm{CE}} \text { of } \mathrm{Q} 6-\mathrm{V}_{\mathrm{BE}} \text { of } \mathrm{Q} 7 \tag{3}
\end{align*}
$$

Low-level output voltage $\mathrm{V}_{\mathrm{OL}}$ is determined by the turning on of transistor Q5. When the input is high and transistor

Q2 is turned on, high-current transistor Q5 is turned on by a current path through transistor Q3 and resistor R3. Sufficient base drive is supplied to keep transistor Q5 fully turned on at an apparent output resistance of $14 \Omega$ for 'ALS and $6 \Omega$ for 'AS.

The fanout is up to 40 for a '54ALS device that is driving a '54ALS device and up to 80 for a '74ALS device, that is driving a ${ }^{\prime} 74 \mathrm{ALS}$ device and provides a guaranteed low-level output current of 4 mA and 8 mA , respectively.

The increase in speed-power product of '54ALS/'74ALS devices, a factor four times better than '54LS/'74LS devices, is due to the design consideration of the quiescent and switching operations of the circuit. In the quiescent state, transistor Q2 allows the use of a reduced low-level input current. This reduces the fanout and reduces the overall quiescent current requirements.

The design of diodes D2 and D3 (or transistor Q8) and transistor Q4 enhances the speed-power product of the device. Transistor Q4 reduces the turn-off time and consequently the current transients caused by conduction
overlap of transistor Q5. The same principle is used by diodes D2 and D3 and transistor Q3 in turning off transistor Q7. In addition, the active turn-off design produces a square transfer characteristic.

The 'ASOO gate has additional circuits not on the 'ALS00A gate. The circuits are added to enhance the throughput of the 'AS Family.

Transistor Q10 has been added as a discharge path for the base-collector capacitance of transistor Q5. Without transistor Q10, rising voltages at the collector of transistor Q5 would force current, via the base-collector capacitance, into the base of transistor Q5 causing it to turn on. However, diode D10 causes transistor Q10 to turn on (during rising voltage) and keeps transistor Q5 turned off. Diodes D6 and D9 serve as a discharge path for capacitor-diode D10.

## CIRCUIT PARAMETERS

Worst-case testing of 'ALS/'AS devices provides a margin of safety. [All dc limits shown on the data sheet are guaranteed over the entire temperature range $\left(-55^{\circ} \mathrm{C}\right.$ to $125^{\circ} \mathrm{C}$ ) for series $54 \mathrm{ALS} / 54 \mathrm{AS}$ and $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ for series $74 \mathrm{ALS} / 74 \mathrm{AS})$ ]. In addition, the dc limits are guaranteed over the entire supply voltage range ( 4.5 V to 5.5 V ).

## Transfer Characteristics

Since the most common application for a logic gate is to drive a similar logic gate, the input and output logic levels
must be compatible. The input and output logic levels for 'ALS/'AS devices are as follows:
$\mathrm{V}_{\mathrm{IL}}$ - The voltage value required for a low-level input voltage that guarantees operation
$\mathrm{V}_{\mathrm{IH}}$ - The voltage value required for a high-level input voltage that guarantees operation
$\mathrm{V}_{\mathrm{OL}}$ - The guaranteed maximum low-level output voltage of a gate
$\mathrm{V}_{\mathrm{OH}}$ - The guaranteed minimum high-level output voltage of a gate.
With the exception of high-level ouput voltage (which is a direct function of supply voltage), these values remain virtually unchanged over the temperature range and under normal operating conditions of the device.

Analysis of the input and output response characteristics of 'ALS/'AS TTL gates is necessary to understand the operation of these devices in most system applications. The dc response characteristics can best be depicted by an input voltage $\mathrm{V}_{\mathrm{I}}$ versus output voltage $\mathrm{V}_{\mathrm{O}}$ transfer plot.

Figure 14 plots the 'ALS/'AS characteristics as compared with members of other TTL logic families.

As shown in Figure 14, the 'ALS and 'AS devices exhibit a much better output savings when compared with standard TTL devices. The better high-level output voltage is primarily because of the active turn off of the low-level output transistor. The diode voltage drop in the normal output is replaced by a low-current $\mathrm{V}_{\mathrm{BE}}$ voltage drop. This provides


Figure 14. Input Voltage vs Output Voltage of 'ALS/'AS
a better high-level noise immunity in 'ALS and and 'AS over standard TTL devices.

## Input Characteristics

To use 'ALS/'AS devices fully, a knowledge of the input and output characteristics is required. This is particularly true when a device interfaces with a device not in the same TTL series. In addition, knowledge of voltage and current relationships for all elements is important for proper design.

Figure 15 illustrates a typical plot for input current $I_{I}$ versus input voltage, $\mathrm{V}_{\mathrm{I}}$, characteristics for 'ALS/'AS gate inputs during normal operation. A typical series 54/74 characteristic plot is also shown for reference. Any device used to drive a TTL gate must source and sink current. Conventionally, current flowing toward a device input terminal is designated as positive and current flowing out
of a device input terminal is designated as negative. Lowlevel input current is negative current because it flows out of the input terminal. High-level' input current is a positive current because it flows into the input terminal.

For transmission line conditions, a more accurate plot of the reverse bias section of these curves is required. These curves, Figure 16, are characteristic of the input clamping diode.

## Low-Level Input Current

Figure 17 illustrates the de equivalent of a standard 'ALS/'AS input circuit and shows the input current paths during a low-level input state. The low-level input current is primarily determined by resistor R1. However, low-level input current is also a function of the supply voltage, the ambient temperature, and the low-level input voltage. To


Figure 15. Input Current vs Input Voltage for TTL Families


Figure 16. Low-Level Input Current vs High-Level Input Voltage for TTL Families
assure desired device operation under all possible conditions, the worst-case test is performed on all devices. Supply voltage is taken to the highest allowable value to cause the low-level input current to be at a maximum. With the exception of the input under test, all unused inputs are taken to a high level. This enhances any contribution of these inputs to the low-level input current of the emitter under test.

## Input Clamping Diode Test

The quality of the input clamping SBD (D2 in Figure 17) is tested by ensuring that the forward voltage drop is not


Figure 17. DC Equivalent Input Circuit for Series 'ALS Gate
greater than -1.2 V for 'AS and -1.5 V for 'ALS with a forward current of 18 mA . These values are guaranteed at minimum supply voltage and are valid across the operating temperature range. The characteristic of the input diode is illustrated in Figure 16.

## High-Level Input Current

Another input parameter that must be measured and controlled is high-level input current. To ensure desired device operation under all possible conditions, the worst-case test is performed with all unused inputs grounded and supply voltage at its maximum value. This provides the highest value of low-level input current. Those devices with a high-level input current of sufficient magnitude to cause a degradation of high-level output voltage at an output must be screened out.

## Input Breakdown Test

An additional high-level input current test is performed to check for base-emitter breakdown under the application of the full range of input voltages. This test is performed under the worst-case supply voltage conditions and is important because the base-emitter junction is small and can easily be overdissipated during the breakdown conditions.

## Output Characteristics

The most versatile TTL output configuration is the pushpull (totem-pole) type. The totem-pole output has a low output impedance drive capability at both high and low logic levels. Both 'ALS and 'AS families use this configuration and have fanouts of 40 in both the high- and low-level states.

## High-Level Output Characteristics

The ability of the totem-pole output to supply high-level output current is parametrically tested by applying a highlevel input current value during measurement of high-level output voltage. However, the quality of the output stage is best indicated by parametrically measuring its current sourcing IOS capability when connected to ground. Figure 18 shows the equivalent output circuit under high-level output conditions.

Figure 19 illustrates typical high-level characteristics. When measuring worst-case high-level output voltage, minimum supply voltage is used. A worst-case low-level
input voltage is applied to an input and all unused inputs are tied to supply voltage.


Figure 18. Equivalent Output Circuit for 'ALS/'AS Gates

## Low-Level Output Characteristics

Figure 20 shows that section of the output drive circuit which produces a low-level output voltage VOL. This characteristic is also tested at minimum supply voltage. Figure 21 illustrates the typical curve.

## Switching Speed

Two switching-speed parameters are guaranteed on Series 'ALS and 'AS gates: propagation delay time for a high-level to a low-level at the output tpHL, and a low-level to high-level transition time $\mathrm{t}_{\mathrm{PLH}}$. Both parameters are specified with respect to the input pulse using standard test conditions as follows:

$$
\begin{aligned}
\mathrm{V}_{\mathrm{CC}} & =4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\
\mathrm{C}_{\mathrm{L}} & =50 \mathrm{pF} \\
\mathrm{R}_{\mathrm{L}} & =500 \\
\mathrm{~T}_{\mathrm{A}} & =\text { MIN to MAX }
\end{aligned}
$$

Under these conditions, times in the order of 4 ns for 'ALS and 1.7 ns for 'AS are typical. Figures 22 and 23 illustrate how the propagation delay time for 'ALS and 'AS devices vary with load capacitance.

Most current in the output stage is drawn when both output transistors are on (i.e., during output transitions, the average power dissipation of a gate with a totem-pole output increases with operating frequency). This is caused by more high-current transitions per second at the output as the frequency increases. Figure 24 illustrates the effect for both 'ALS and 'AS devices.


Figure 19. High-Level Output Voltage vs High-Level Output Current

## DC Noise Margins

Noise margin is a voltage specification which guarantees the static de immunity of a circuit to adverse operating conditions. Noise margin is defined as the difference between the worst-case input logic level ( $\mathrm{V}_{\mathrm{IH}}$ minimum or $\mathrm{V}_{\mathrm{IL}}$
maximum) and the guaranteed worst-case output ( V OH minimum or $\mathrm{V}_{\mathrm{OL}}$ maximum) specified to drive the inputs. Table 2 lists the worst-case output limits for the 'AS and 'ALS families.


Figure 20. Low-Level Output Circuit for 'ALS/'AS Gates


Figure 21. Low-Level Output Voltage vs Low-Level Output Current


Figure 22. High- to Low-Level Propagation Delay vs Load Capacitance


Figure 23. Low- to High-Level Propagation Delay vs Load Capacitance


Figure 24. Power Dissipation per Gate vs Frequency

## Specified Logic Levels and Thresholds

The high-level noise margin is obtained by subtracting $\mathrm{V}_{\mathrm{OH}}$ minimum from $\mathrm{V}_{\mathrm{IH}}$ minimum. The low-level noise margin is obtained by subtracting $\mathrm{V}_{\mathrm{IL}}$ maximum from $\mathrm{V}_{\mathrm{OL}}$ maximum. The worst-case high-level noise margin is guaranteed to be at least 500 mV for both 'AS and 'ALS devices and at least 300 mV for low-level noise immunity across the operating free-air temperature ranges.

The usefulness of noise margins at the system design level is the ability of a device to be impervious to noise spikes at the input. The input voltage falls into one of three categories: low-logic state (between ground and 0.8 V ), threshold region (between 0.8 V and 2 V ), or high-logic state (between 2 V and $\mathrm{V}_{\mathrm{CC}}$ ). If an input voltage remains exclusively in the low-logic or high-logic state, it can undergo
any excursions within that state. A level change from 5.5 V to 2 V or from ground to 0.8 V should not affect the output state of the device. To guarantee an expected output level change, the appropriate input has to undergo a change from one input state to the other input state (i.e., a transition through the threshold region). If a device will not remain in the correct state when voltage excursions on the input are occurring, it is violating its truth table.

## Noise Rejection

The ability of a logic element to operate in a noise environment involves more than the dc or ac noise margins previously discussed. To present a problem, an externally generated noise pulse must be received into the system and cause a malfunction. Stable logic systems with no storage

Table 2. Worst Case Output Parameters

| PARAMETER <br> (V) | $\begin{gathered} \text { AS } \\ \left.10^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}\right) \end{gathered}$ | 'ALS $\left.10^{\circ} \mathrm{C} \text { to } 70^{\circ} \mathrm{C}\right)$ | $\begin{gathered} \text { 'AS } \\ \left(-55^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C}\right) \end{gathered}$ | 'ALS $\left(-55^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C}\right)$ |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IH }}(\mathrm{MIN})$ | 2 | 2 | 2 | 2 |
| $\mathrm{V}_{\text {IL }}$ (MAX) | 0.8 | 0.8 | 0.8 | 0.8 |
| $\mathrm{V}_{\mathrm{OH}}(\mathrm{MIN}) @ \mathrm{CC}=4.5 \mathrm{~V}^{*}$ | 2.5 | 2.5 | 2.5 | 2.5 |
| $\mathrm{V}_{\text {OL }}(\mathrm{MAX})$ | 0.5 | 0.5 | 0.5 | 0.4 |
| High Level Noise <br> Margin $\left(\mathrm{V}_{\mathrm{OH}}-\mathrm{V}_{\mathrm{IH}}\right)$ | 0.5 | 0.5 | 0.5 | 0.5 |
| Low Level Noise Margin ( $\mathrm{V}_{\text {IL }}-\mathrm{V}_{\mathrm{OL}}$ ) | 0.3 | 0.3 | 0.3 | 0.4 |

*Actual specification for $\mathrm{V}_{\mathrm{OH}(\text { min })}$ is $\mathrm{V}_{\mathrm{CC}}-2 \mathrm{~V}$.
elements are practically impervious to ac noise. However, large dc voltages could cause noise problems. Systems with triggerable storage elements or those operating fast enough for the noise to appear as a signal are much more susceptible to noise.

The noise voltage must be radiated or coupled into the circuit. The amount of noise required to develop a given voltage is a function of the circuit impedance. Because of the low output impedance of TTL circuits, noise immunity is improved. Noise is transferred from the source (with some arbitrary impedance) through a coupling impedance to the impedance of the circuit under consideration.

Figure 25 shows a circuit where the coupling impedance is stray capacitance and the load impedance is provided by the gates. The relatively tight coupling of this circuit and the loading effect on the driving source is significant enough


Figure 25. Stray Coupling Capacitance
to be considered. However, since the source effect is difficult to assess and is in a direction to improve rather than degrade the noise rejection, its effects are ignored. This results in a worst-case type of response indication. In the case of radiated noise, the source resistance is a definite factor in noise coupling and essentially replaces the reactive coupling impedance.

By ignoring the driving source impedance to make conditions more nearly standard, it is possible to determine a set of curves relating the developed noise pulse to the noise source amplitude, the noise rise or fall time, the coupling impedance, and the load impedance. Curves have been developed ${ }^{1}$ for several different input waveforms. Since the 'ALS waveform is essentially a ramp with a dv/vt of $1 \mathrm{~V} / \mathrm{ns}$ (approximately $2.5 \mathrm{~V} / \mathrm{ns}$ for 'AS), the most applicable curve is that for a ramp input.

Figure 26(a) shows the equivalent circuit from which the ramp response plot in Figure 26(b) was developed. The input pulse shown in Figure 26(c) is a ramp input.

$$
e_{i}(t)=\frac{E_{i}}{T} \quad i
$$

where

$$
\begin{aligned}
\mathrm{E}_{\mathrm{i}} & =\text { Maximum input voltage and } \\
\mathrm{T} & =\text { Total rise time of input voltage }
\end{aligned}
$$

The output pulse is represented analytically by

$$
\begin{aligned}
& \mathrm{e}_{0}(\mathrm{t})=\frac{\mathrm{E}_{\mathrm{i}}}{\mathrm{~T}} \mathrm{RC}\left(1-\mathrm{e}^{-\frac{\mathrm{t} / \mathrm{T}}{\mathrm{RC} / \mathrm{T}}}\right) \\
& \mathrm{e}_{0}(\mathrm{i})=\mathrm{E}_{\mathrm{i}} \tau\left(1-\mathrm{e}^{-\mathrm{i} / \tau}\right)
\end{aligned}
$$

where

$$
\begin{aligned}
\tau & =\frac{\mathrm{RC}}{\mathrm{~T}} \\
\theta(\mathrm{i}) & =\tau\left(1-\mathrm{e}^{-\mathrm{i} / \tau}\right) . \\
\theta(\mathrm{i}) & =\frac{\mathrm{e}_{0(\mathrm{i})}}{\mathrm{E}_{\mathrm{i}}}
\end{aligned}
$$

with holding for unit time. This is followed by an exponentially decaying voltage with a time constant $\tau$. Values of $\tau$ and $i$ on the figure are normalized by the value of the total rise time of the stimulated noise pulse $\mathrm{e}_{\mathrm{i}}$. Using Figure 26(b), the pulse width and amplitude of the coupled noise pulse can be estimated.

As an example, using the circuit shown in Figure 25, apply a noise pulse of 3 V in amplitude and rising at $1 \mathrm{~V} / \mathrm{ns}$

with gate 2 at a high-logic state. Assume a nominal output impedance of $58 \Omega$ ( $30 \Omega$ for 'AS) and coupling capacitance of 10 pF . Use the following formula:

Total rise time $T=\frac{3 \mathrm{~V}}{1 \mathrm{~V} / \mathrm{ns}^{* *}}=3 \mathrm{~ns}^{\dagger}$

$$
\begin{aligned}
\tau & =\frac{\mathrm{RC}}{\mathrm{~T}}=\frac{\left(10 \times 10^{-12}\right)(58)}{3} \\
& =\frac{0.58 \times 10^{-9}}{3}=0.19 \mathrm{~ns}
\end{aligned}
$$

**2.5 V/ns for 'AS
${ }^{\dagger} 1.2 \mathrm{~ns}$ for ${ }^{\mathrm{AS}}$
To convert the normalized values of $\tau$ and i in Figure 26(b) to actual values, multiply by 3 ns . The output voltage scale will be multiplied by 3 V . Using the $\tau=0.19$ curve gives a peak $\mathrm{e}_{\mathrm{O}}$ of $0.57 \mathrm{~V}(0.19 \times 3)$ and a pulse width of 3 ns at the $50 \%$ points. To determine whether this pulse will cause interference, enter these values ( 0.57 V and 3 ns ) on the graph shown in Figure 27. Since the gates have approximately 1.8 V of noise immunity at this point, they should not be affected.

If an open-collector gate is used with a passive $1 \mathrm{k} \Omega$ pullup resistor, the situation would change. Use the following formula:

Total rise time $=\frac{3 \mathrm{~V}}{1 \mathrm{~V} / \mathrm{ns}^{* *}}=3 \mathrm{~ns}{ }^{\dagger}$

$$
\begin{aligned}
\tau & =\frac{\left(10 \times 10^{-12}\right)\left(1 \times 10^{3}\right)}{3} \\
& =\frac{10 \times 10^{-9}}{3}=\frac{10}{3} \mathrm{~ns}
\end{aligned}
$$

$* * 2.5 \mathrm{~V} / \mathrm{ns}$ for 'AS
$\dagger_{1.2 \mathrm{~ns} \text { for }{ }^{\prime} \mathrm{AS}}$
Now the amplitude (from the curves) approaches 2.58 V $(0.86 \times 3)$ and the pulse width at the $50 \%$ points is approximately $8.52 \mathrm{~ns}(2.84 \times 3)$. The next gate will propagate this pulse.

This example is an oversimplification. The coupling impedances are complex (but resolvable into RLC series coupling elements) and the gate output impedance changes with load. Our purpose is to show why and how the low impedance of the active TTL output rejects noise and to make a comparison with a passive pull-up.

The ability to operate in a noisy environment is an interaction of the built-in operating margins, the time required for the device to react, and the ease with which a noise voltage is developed. In all cases, except the ability to react to short noise pulses, the TTL design has emhasized noise rejection.

Nothing has been discussed concerning noise in devices other than gate circuits. Many MSI devices are complex gate
networks and, because of their small size, are more superior in a noisy environment operation than their discrete gate equivalents. Noise tolerance of latching devices is implied in the setup times, hold times, clock pulse width, data pulse widths, and similar parameters. Output impedances and input noise margins are quite similar to those of the gates and may be treated in a similar manner. If a latching device does become noise triggered, the effective error is stored and does not disappear with the noise.

Parameter measurement information is shown in Figure 28.


Figure 27. Theoretical Required Pulse Width vs Pulse Amplitude for 'AS and 'ALS Inputs

## GUIDELINES FOR SERIES 'ALS/'AS TTL SYSTEM DESIGN

System layout and design requirements for Advanced Schottky TTL circuits are essentially the same as those guidelines which have previously been established and are applicable for all high-performance digital systems. Tables 3 through 6 provide a brief summary of the solutions to most design decisions needed to implement systems using Advanced Schottky TTL. Supplementary data which may be useful for developing specific answers to unique problems is provided later.


NOTES: 1. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.
2. All input pulses have the following characteristics PRR $\leq 1 \mathrm{MHz}, \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=2 \mathrm{~ns}$, duty cycle $=50 \%$.
3. When measuring propagation delay times of 3 -state outputs, switch S 1 is open.
4. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

Figure 28. Parameter Measurement Information

## POWER SUPPLY REGULATION

Power supply regulation cannot be treated as if it is an independent characteristic of the device involved. Power supply regulation, along with temperature range, affects noise margins, fanout, switching-speed, and several other parameters. The characteristics most affected are noise
margin and fanout. When these two parameters are within the specified limits, the power-supply regulation will normally be within specified limits. However, on a device where auxiliary parameters are more critically specified, a more restrictive power-supply regulation is normally required. When power-supply regulation is slightly outside the specified limits for TTL devices, the device may still
operate satisfactorily. However, if high ambient-noise levels and extreme temperatures are encountered, failures may occur.

Application of a supply voltage above 7 V (absolute maximum rating) will result in damage to the circuit.

Since power dissipation in the package is directly related to supply voltage, the maximum recommended supply voltage for TTL devices is specified at 5.5 V . This provides an adequate margin to ensure that functional capability and long-term reliability are not jeopardized.

High-level output voltage is almost directly proportional to supply voltage (i.e., a drop in supply voltage causes a drop in high-level output voltage and an increase in supply voltage
results in an increase in high-level output voltage). Because of this relationship, high-level output voltage for 'ALS/'AS devices is specified as supply voltage $-2 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{CC}}-2 \mathrm{~V}\right)$.

Since high-level output voltage is directly related to supply voltage, the output current of the device is also directly related. The output current value is established by choosing output conditions to produce a current that is approximately one-half of the true short-circuit current.

It is advantageous to regulate or clamp the maximum supply voltage at 5.5 V including noise ripple and spikes. When this conditions exists, unused AND and NAND gates can be connected directly to the supply voltage.

Table 3. Guidelines for Systems Design for Advanced Schottky TTL

| ITEM | GUIDELINE |
| :--- | :--- |
| Single wire connections | Wire lengths up to approximately 12 inches may be used. A form of ground plane is desirable. <br> Use point-to-point routing rather than parallel. If the wire is longer than 12 inches, use either a <br> dense ground plane with the wire routed as close to it as possible, or use a twisted-pair cable. |
| Coaxial and twisted-pair cables |  |
| Design around approximately $80 \Omega$ to $100 \Omega$ of characteristic impedance. Cross talk increases at |  |
| higher impedances. Use a coaxial cable of $93 \Omega$ impedance fe.g., Microdot 293-3913). For twisted- |  |
| pair cable, use number 26 or number 28 wire with the insulation twisted at the rate of 30 turns |  |
| per foot. |  |
| Cross talk | Ensure that transmission-line ground returns are carried through at both transmitting and receiving <br> ends. VCC decoupling ground, device ground, and transmission-line ground should have a common <br> tie point. <br> Use point-to-point back-panel wiring to minimize noise pickup between lines. Avoid long unshielded <br> parallel runs. However, if they must be used, they should carry signals that propagate in the same <br> direction. <br> Reflections occur when data interconnects become long enough that 2 -line propagation delays <br> are pulse transition times. For series TTL, reflections are normally of no importance for lines shorter |
| Resistive pull-up |  |

Table 4. Guidelines for Printed Circuit Board Layout for Advanced Schottky TTL

| ITEM | GUIDELINE |
| :--- | :--- |
| Signal connections | Whenever possible, distribute loads along direct connections. Signal leads should be kept as short as possible. <br> However, lead lengths of up to 15 inches will perform satisfactorily. This is especially for large boards that <br> use a ground plane, ground, and/or VCC plane. In addition, it will perform satisfactorily for small boards using <br> ground mesh or grid. In high-frequency applications, avoid radial fanouts and stubs. If they must be used to <br> drive some loads, reduce lead length proportionally and avoid sharp bends. Normal on-board fanouts and <br> interconnections do not require terminations. Response of lines driving large numbers or highly capacitive loads <br> can be improved with terminations of $300 \Omega$ to. VCC and $600 \Omega$ to ground in parallel with the last load if fanout <br> of the driving output permits. |
| Conductor widths | Signal-line widths down to 0.015 inch are adequate for most signal leads. <br> Signal-lead spacing on any layer down to 0.015 inch can be used especially if care is taken to avoid adjacent <br> use of maximum length and minimum spacing. Increase spacing wherever layout permits. Pay particular attention <br> to clock and/or other sensitive signals. <br> Insulator material <br> Thickness of insulation material used for a multilayer board is not critical. If ground and VCC planes or meshes <br> are used, their capacitive proximity can be used to reduce the number of decoupling capacitors needed and <br> this also supplements the supply bypass capacitor. |

Table 5. Guidelines for General Usage of Advanced Schottky TTL

| ITEM | GUIDELINE |
| :--- | :--- |
| Power supply | For RF bypass supply primary, maintain ripple and regulation at less than or equal to $10 \%$. |
| $V_{\text {CC }}$ decoupling | Decouple every 2 to 5 packages with RF capacitors of 0.01 to $0.1 \mu \mathrm{~F}$. Capacitors should be located as near <br> as possible to the decoupled devices. Decouple line driving or receiving devices separately with $0.1 \mu \mathrm{~F}$ capacitors <br> between $V_{C C}$ and the ground pins. |
| On-board grounding | A ground plane is essential when the PCB is relatively large lover 12 inches). Smaller boards will work with <br> ground and/or $V_{C C}$ mesh or grid. |
| System grounding | Try to simulate bus bars with a width to thickness ratio greater than or equal to 4. This can be accomplished <br> by multiple parallel wires or by using flat braid. Performance will be enhanced when a copper or silver-copper <br> bus is used. The width to thickness ratio required will vary between systems, but greater than or equal to 4 <br> will satisfy most systems. |

Table 6. Guidelines for Gates and Flip-Flops Using Advanced Schottky TTL

| ITEM | GUIDELINE |
| :---: | :---: |
| Data input rise and fall times | Reduce input rise and fall times as driver output impedance increases. Rise and fall times should be equal to or less than $15 \mathrm{~ns} / \mathrm{V}$ and essentially free of noise ripple. |
| Unused input of AND and NAND gates and unused preset and clear inputs of flip-flops | Tie the unused input of AND and NAND gates and the unused preset and/or clear inputs of flip-flops as follows: <br> 1. Directly to $\mathrm{V}_{\mathrm{CC}}$, if the input voltage rating of 5.5 V maximum is not exceeded. <br> 2. Through a resistor equal to or greater than $1 \mathrm{k} \Omega$ to $V_{C C}$. Several inputs can be tied to one resistor. <br> 3. Directly to a used input of the same gate, if maximum fanout of driving device will not be exceeded. Only the high-level loading of the driver is increased. <br> 4. Directly to an unused gate output, if the gate is wired to provide a constant high-level output. Input voltage should not exceed 5.5 V . |
| Unused input of NOR gates | Tie unused input to used input of same gate, if maximum fanout of driving device will not be exceeded or tie unused input to ground. |
| Unused gates | Tie input of unused NAND and NOR gates to ground for lowest power drain. Tie inputs of unused AND gates high and use output for driving unused AND or NAND gate inputs. |
| Increasing gate/buffer fanout | Connect gates of same package in parallel. |
| Clock pulse of flip-flops | Drive clock inputs with a TTL output. If not available, rise and fall times should be less than $50 \mathrm{~ns} / \mathrm{V}$ and free of ripple noise spikes. |

## SUPPLY VOLTAGE RIPPLE

Ripple in the supply voltage is generally considered a part of the supply voltage regulation. However, when combined with other effects (e.g., slow rise times), ripple voltage is more significant.

The effect of ripple voltage $V_{R}$ can appear on either the supply voltage $\mathrm{V}_{\mathrm{CC}}$ or the ground supply GND. When ripple appears on the supply voltage, it causes modulation of the input signal. The extent of the effect depends upon circuit parameters and source impedance.

The turning on of transistor Q5, shown in Figures 12 and 13 , is controlled by the voltage at the base of transistor Q2 with respect to ground in accordance with the formula:

$$
V_{B}=V_{B E} \text { of } Q 2+V_{B E} \text { of } Q 3+V_{B E} \text { of } Q 5
$$

When ripple voltage is modulated onto the input voltage, the amplitude depends on the source impedance (Figure 29). The amplitude can be determined by the following equation:

$$
\begin{aligned}
\Delta \mathrm{V}_{\mathrm{R}} & =\mathrm{V}_{\mathrm{R}}\left(\frac{\mathrm{R} 1 / \beta}{\mathrm{R} 1 / \beta+\mathrm{R} 2}\right) \\
& =\mathrm{V}_{\mathrm{R}}\left(\frac{\mathrm{R} 1}{\mathrm{R} 1+\beta \mathrm{R} 2}\right)
\end{aligned}
$$

where $\mathrm{R} 1=$ source impedance

$$
\beta=\text { gain of transistor } \mathrm{Q} 1 .
$$

Ripple voltage has the effect of adding extra pulses to the input signal (Figure 30). When ripple voltage appears in the ground supply, the threshold voltage is modulated and extra pulses occur (Figure 31).

Although decreasing the source impedance will reduce the effects of ripple voltage, it cannot be eliminated entirely because the emitter-base junction has an apparent resistance of approximately $30 \Omega$. Because of cancellation between the driving gate and the driven gate, low-frequency ripple is not a problem.


Figure 29. Effect of Source Impedance on Input Noise


Figure 30. Spurious Output Produced by Supply Voltage Ripple


Figure 31. Effect of Ground Noise on Noise Margin

## NOISE CONSIDERATIONS

Extraneous voltages and currents (called noise) introduced into a digital logic circuit are discussed in the following paragraphs. Figure 32(a) is a typical digital logic

(a)

(b)

(c)

Figure 32. Typical Logic Circuit with Noisy Input
circuit consisting of a NAND gate and a J-K flip-flop. When a small noise pulse is coupled onto the clock input [(Figure 32(b)], the flip-flop does not respond and the Q output is correct. However, when a large noise pulse is coupled onto the clock input [(Figure 32(c)], the flip-flop sees the pulse as a clock transition and an erroneous Q output occurs. Therefore, it is essential to protect digital logic circuits from noise.

## Noise Types and Control Methods

The noise types encountered in digital logic systems, their source, and the method of controlling them are as follows:

1. Externa! noise - External noises radiated into the system. The sources include circuit breakers, motor brushes, arcing relay contacts, and magnetic-field-generating. The methods of controlled to be considered are shielding, grounding, or decoupling.
2. Power-line noise - Noise coupled through the ac or dc power distribution system. The initial sources and controlling methods are the same as for external noise
3. Cross talk - Noise induced into signal lines from adjacent signal lines. Controlling methods to consider are shielding, grounding, decoupling, and, where possible, increasing the distance between the signal lines.
4. Signal-current noise - Noise generated in stray impedances throughout the circuit. The controlling methods to consider are shielding, grounding, decoupling, and, where possible, reduction of stray capacitance in the circuit.
5. Transmission-line reflections - Noise from unterminated transmission lines that cause ringing and overshoot. The method of control is to use, where possible, terminated transmission lines.
6. Supply-current spikes - Noise caused by switching several digital loads simultaneously. The controlling method is to design, where possible, the system so that digital loads are not switched simultaneously.

## Shielding

In addition to its own internally generated noise, electrical equipment must operate in an extremely noisy environment. Noise pulses, which may come from a number of sources, consist of an electrostatic field, and electromagnetic field, or both. The noise waveform must be prevented from entering the equipment. This is accomplished by shielding. Since the noise fields are usually changing at a rapid rate, the shield required to exclude them may be very small. For effective exclusion, the sensitive circuits must be completely shielded.

Aluminum or similar materials are effective in stopping electrostatic noise. However, only a ferrous metal can successfully protect equipment against magnetic fields. Whiie it is helpful to connect the system to earth ground, the shield system must be complete and must be grounded to the system ground to prevent the shield from coupling noise into the system:

External noise may be conducted into the system by the power lines. Decoupling and filtering of these lines should be standard design procedure.

## Grounding and Decoupling

The total propagation delay is of secondary importance in generation of internal noise. The actual transition time determines the amplitude and frequency spectrum of the generated signal at the higher harmonics. Application of the Fourier integral to series 'ALS/'AS waveforms shows frequency components of significant amplitude that exceed 100 MHz . Because of the frequency spectrum generated when an 'ALS/'AS device switches, a system using these devices must consider problems caused by radio frequency (RF) even though the repetition rates may be only a few megahertz. The transient currents generated by charging capacitors, changes in the levels of dc, line driving, etc., must be considered. In Figure 33 for example, a gate driving a transmission line is represented by a voltage source E , having an output impedance $Z_{S}$ connected to an impedance $\mathrm{Z}_{0}$, and loaded with a resistance $\mathrm{R}_{\mathrm{L}}$.

Until after a reflected pulse returns from the termination of the transmitting device, line termination is not a factor in drive current. In a practical TTL circuit, the line termination must be high relative to the line impedance. For


Figure 33. Diagram Representing a Gate Driving a Transmission Line
explanation purposes, assume that the source voltage is 5 V in amplitude, the output impedance of the source is $50 \Omega$ and the line impedance is $50 \Omega$. When the source voltage makes the transition from 0 V to 5 V , the voltage across the input of the line $\mathrm{V}_{\mathrm{I}}$ is determined by the following equation:

$$
\text { where } \begin{aligned}
\mathrm{V}_{\mathrm{I}} & =\mathrm{E} \frac{\mathrm{Z}_{0}}{\mathrm{Z}_{\mathrm{S}}+\mathrm{Z}_{0}}=2.5 \mathrm{~V} \\
\mathrm{E} & =\text { source voltage } \\
\mathrm{Z}_{0} & =\text { line impedance } \\
\mathrm{Z}_{\mathrm{S}} & =\text { source impedance }
\end{aligned}
$$

For the $50 \Omega$ line to become charged, the current that must flow onto the line is determined by the following equation:

$$
\mathrm{I}_{\text {line }} \frac{\mathrm{V}_{\mathrm{in}}}{\mathrm{Z}_{0}}=\frac{2.5}{50}=50 \mathrm{~mA}
$$

In addition, this current flows in the ground return, which, in this case, is the transmission-line ground. If the line and return are originated and terminated close to the driving and receiving devices, there is no discontinuity in the line. Where the ground is poorly returned, the current flow sees the discontinuity in the cable as a high impedance and a noise spike is generated (i.e., the ground current sees a low impedance and a current cancellation if the ground is properly carried through and, if not, it sees a high impedance). Figure 34 presents a specific example. Assume that the gate driving the line is switched from the high to low state. Current flow is indicated by the arrow marked with an I. Since the line is improperly returned to the driver, a pulse is developed across the impedance. A possible consequence is the false output of gate 3 (G3).

If the ground return is properly connected, the proper results are obtained. The impedance discontinuity is eliminated and current cancellation occurs at the ground point. Undesirable voltage spikes are then eliminated. Two empirical rules to reduce transmission-line currents have been established and have been found to be effective (Figure 35).

1. Carry all returns, including twisted pair and coaxial cables, to a good ground termination. Ground line returns close to the driving and receiving devices.


Figure 34. Noise Generation Caused by Poor Transmission-Line Return
2. Decouple the supply voltage of line-driving and line-receiving gates with a $0.1-\mu \mathrm{F}$ disk ceramic capacitor.
As the devices change state, current levels change because of the different device currents required in each state, the external loading, the transients caused by charging and discharging capacitive loads, and the conduction overlap in the totem-pole output stage. When a gate changes states, its internal supply current changes from high to low (these values are stated on the data sheet for each device). In addition, any capacitance, stray or otherwise, must be charged or discharged for a logic state change. The capacitance must be charged by a current determined by

$$
\begin{equation*}
I=C \frac{d v}{d t} \tag{4}
\end{equation*}
$$

If the total stray capacitance on a gate output, the logic-level voltage excursion, and the associated rise or fall times are known, then the ideal-case instantaneous current during the transition can be calculated.


Broken arrow shows path of line-charging current
Figure 35. Ideal Transmission-Line Current Handling

From Eq. (4) it can be determined that the current transient for charging load capacitance will increase with higher speed TTL circuits. Therefore, the Series 54ALS/74ALS devices will have lower transient current than the Series 54AS/74AS devices. Another parameter that should be considered is the value of R7 (shown in Figures 12 and 13). Resistor R7 acts as a limit on the charging current.

The current required for charging load capacitance $C_{L}$ (Figure 36) is supplied by the supply voltage when the transition is from logic low to logic high at the output of gate $1(\mathrm{Gl})$. When the output of G1 goes from high to low,

$C_{L}$ includes all capacitance: stray, device, etc.
Figure 36. Circuit with Effective Capacitive Loading
the load capacitance is shorted to ground by transistor Q5 (shown in Figures 12 and 13) and has no effect on supply current.

A characteristic common to all TTL totem-pole output stages contributes an additional current transient when the output changes from a logic low to a logic high. This transient, or spike, is caused by the overlap in conduction of the output transistors Q7 and Q5 (shown in Figures 12 and 13). The situation arises because transistor Q7 can turn on faster than transistor Q5 can turn off. This places a direct circuit consisting of transistors Q7 and Q5 and resistor R4 between supply voltage and ground. For all series 'ALS TTL circuits, the maximum possible peak current can be determined by

$$
\mathrm{I}_{\mathrm{CC}} \max =\frac{\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{CEQ6}}-\mathrm{V}_{\mathrm{BEQ} 7}-\mathrm{V}_{\mathrm{CEQ} 5}}{\mathrm{R} 7}
$$

However, due to the active turnoff circuit (consisting of R5, R6, and Q4), Q5 will be only slightly in the linear region and the current spike will be less.

The total supply-current switching transient is then a combination of three major effects: the difference in highlevel and low-level supply current, the charging of load capacitance, and the conduction overlap. Tests were performed to demonstrate these effects. The results are shown in Figure 37. Six types of series TTL devices were tested with no load (i.e., the oscilloscope was connected to the output only when measuring $\mathrm{V}_{\mathrm{O}}$ and the photographs were double exposed). This was to approximate the effects of conduction overlap isolated from the transient caused by charging load capacitance. Different vertical scales were used on some of the photographs.

The results are almost as predicted. The low-power devices have the lower transients. Since it is the fastest circuit, the SN74AS00 device should be highest. However, a decrease is shown, and the reason for the decrease is explained (Figure 39). The additional circuits to reduce conduction overlap of the output transistors result in a smaller transient even though the typical switching time is 1.7 ns compared to 9 ns for the Series 54/74LS.

The second series of tests shown in Figure 37 cover a capacitive load of .50 pF . For this test, all of the supply current transient peaks increase in amplitude and width.

Because of the larger transient currents, voltage spikes on the supply voltage measured at the IC package are also increased.

From these tests, it can be concluded that the condition to be avoided (the only one that can be avoided) is unnecessary stray capacitance in circuit wiring. The charging of load capacitance, in most cases, overshadows the other two effects with respect to noise produced on the supply voltage line by switching current transients.

The flow paths of these currents have been investigated to determine the grounding and decoupling necessary to counteract their effects. Supply voltage decoupling may be accomplished by one of two methods. Maintaining low impedance from the individual circuit supply voltage to


Figure 37(a). Supply-Current Transient Comparisons


Figure 37(b). Supply-Current Transient Comparisons
ground is common to both methods. In the first method, the supply voltage line may be considered as a transmission line back to a low impedance supply. The positive bus can be laminated with a ground bus to form a strip transmission line of extremely low impedance. This line can be electrically approximated with lumped capacitances as shown in Figure 38. The inductances are usually a distributed component which must be minimized to lower the line impedance.


Figure 38. Transmission-Line Power Buses
The second method is to consider the supply voltage bus as a dc connecting element only and to provide a lowimpedance path near the devices for the transient currents to be grounded (Figure 39).


Figure 39. Capacitive Storage Supply Voltage System

For effective filtering and decoupling, the capacitors must be able to supply the change in current for a period of time greater than the pulse width of this current. Since the problem is essentially one of dc changes due to logic state coupled with high-frequency transients associated with the changes, two different values of time constant must be considered. Capacitors combining the high capacitance required for long periods with the low series reactance required for fast transients are prohibitive in cost and size. A good compromise is the arrangement shown in Figure 40.

The typical component values may be found for the RF capacitor Cl by assuming that the parameters have common values as follows:

$$
\begin{aligned}
\Delta \mathrm{l}_{\mathrm{CC}} & =50 \mathrm{~mA} \\
\Delta \mathrm{~V} & =0.1 \mathrm{~V} \\
\Delta \mathrm{~T} & =20 \mathrm{~ns}
\end{aligned}
$$

Then the equation is as follows:

$$
\begin{aligned}
\mathrm{C} 1 & =\frac{\Delta \mathrm{I}_{\mathrm{CC}}}{\Delta \mathrm{~V} / \Delta \mathrm{T}}=\frac{(50)(20) \times 10^{-12}}{0.1 /\left(20 \times 10^{-9}\right)} \\
& =\frac{50 \times 10^{-3}}{0.1}=10,000 \times 10^{-12} \\
& =0.01 \mu \mathrm{~F}
\end{aligned}
$$

The same method may be used for the low-frequency capacitor $C 2$. However, the factor $\Delta T$, which was a worstcase transient time for calculating C 2 , now becomes a bit ambiguous. An analysis of the current cycling on a statistical basis is the best method in all but the simplest systems. The recommended procedure is to decouple using $10 \mu \mathrm{~F}$ to $50 \mu \mathrm{~F}$ capacitors.


Figure 40. Commonly Used Power Distribution and Decoupling System

A discrete inductance of $2 \mu \mathrm{H}$ to $10 \mu \mathrm{H}$ is sometimes used for additional decoupling. However, its benefits are questionable and its usefulness should be evaluated for the individual system. The low-pass filter formed must be capable of keeping the transients confined and off the distribution bus. The possibility of resonance in the inductor or LC combination must be considered.

Noise spikes on the supply voltage line that do not force the gate output below the threshold level do not present a serious problem. Downward spikes as large as 3 V can be tolerated on the supply voltage line without propagating through the logic system. The system designer can be confident that supply voltage noise can be handled even with minimal consideration.

Ground noise, however, cannot be treated lightly. Pulses on a high-impedance ground line can easily exceed the noise threshold. Only if a good ground system is maintained can this problem be overcome. If proper attention is paid to the ground system, noise problems can be minimized.

The concept of a common-ground-plane structure as used in RF and high-speed digital systems is quite different from the concept of the common-ground point as used in lowfrequency circuits. The more closely the chassis and ground can approach to being an integral unit, the better the noise suppression characteristics of the system. Consequently, all
parts of the chassis and ground bus system must be bound tightly together both electrically and mechanically. Floating or poorly grounded sections not only break the integrity of the ground system, but may actually act as a noise distribution system.

For grounds and decoupling on printed circuit boards, the most desirable arrangement is a double-clad or multilayer board with a solid ground plane or a mesh. Where component density prohibits this, the ideal should be relaxed only as far as necessary. Cross talk and ground noise can be reduced on large boards with a ground plane. Some suggestions for board grounds where a plane is not practical are as follows:

1. Use as wide a ground strap as possible.
2. Form a complete loop around the board by bringing both sides of the board through separate pins to the system ground.
The supply voltage line can provide part of the ground mesh on the board, provided it is properly decoupled. For a TTL system, a good guideline is $0.01 \mu \mathrm{~F}$ per synchronously driven gate and at least $0.1 \mu \mathrm{~F}$ for each 20 gates, regardless of synchronization. This capacitance may be lumped, but is more effective if distributed over the board. A good rule is to permit no more than 5 inches of wire between any two package supply-voltage points. Radio-frequency-type capacitors must be used for decoupling. Disk ceramics are best. It is sometimes a good practice to decouple the board from the external supply-voltage line with a $2.2 \mu \mathrm{~F}$ capacitor. However, this is optional and the RF capacitors are still required. In addition, it is recommended that gates driving long lines have the supply voltage decoupled at the gate supply voltage terminal and that the capacitor ground, device ground, and transmission-line ground be connected to a common point.

## Cross Talk

When currents and voltages are impressed on a connecting line in a system, it is impossible for adjacent lines to remain unaffected. Static and magnetic fields interact and opposing ground currents flow, creating linking magnetic fields. These cross-coupling effects are lumped together and called cross talk.

## Back-Panel Interconnections

Interconnecting signal lines can be grouped into three broad categories: coaxial lines, twisted-pair lines, and straight wire lines. Because of the low impedance and shielding characteristics of coaxial cable, its cross talk is minimal and is not a problem with TTL.

Figure 41 illustrates a practical type of signal transmission line. The mutual reactances $L_{m}$ and $C_{m}$ which form the noise coupling paths and the line parameters $L_{s}$ and $\mathrm{C}_{\mathrm{g}}$ which govern the line impedance, will vary with the type of line used. Since cross talk is a function of the ratio of the mutual impedances to the line characteristic impedances, the selection of transmission-line type must be at least partially a factor in cross-talk considerations.


Figure 41. Equivalent Circuit for Sending Line
The use of direct-wired connections is the simplest and lowest cost method, but they are also the poorest for noise rejection. If the lead is not cabled tightly together with similar leads, direct leads up to 12 inches in length can be used.

When the length of the signal line is increased, the line impedance is seen by the driving and receiving gates. As shown in Figure 42, a pulse sent along the sending line G3 and G 4 will be coupled via the coupling impedance $\mathrm{Z}_{\mathrm{c}}$ onto the receiving line G1 and G2, which can be in either of the two logic states. The extent to which cross talk will occur depends on the type of lines used and their relationship to each other.


## $\left(Z_{C}\right)$ - COUPLING IMPEDANCE

Figure 42. Equivalent Circuit for Cross Talk
The voltage impressed on the sending line by gate G3 is determined by the equation:

$$
\begin{equation*}
V_{\mathrm{SL}}=\frac{\mathrm{V}_{\mathrm{G} 3} Z_{0}}{\mathrm{R}_{\mathrm{S} 3}+\mathrm{Z}_{0}} \tag{5}
\end{equation*}
$$

where
$\mathrm{V}_{\mathrm{G} 3}=$ open-circuit logic voltage swing generated by gate G3
$\mathrm{R}_{\mathrm{S} 3}=$ output impedance of gate G3 $\mathrm{Z}_{0}=$ line impedance
$\mathrm{V}_{\mathrm{SL}}=$ voltage impressed on the sending line.
The relationship for the equation is illustrated in Figures 43 and 44.

The coupling from the sending line to the receiving line can be represented by taking coupling impedance $\mathrm{Z}_{\mathrm{c}}$ into


Figure 43. Capacitive Cross Talk Between Two Signal Lines
account. An equivalent circuit to represent the coupling from the sending line to the receiving line is shown in Figure 44.

As the voltage impressed on the sending line propagates farther along the line, it can be represented as voltage source $\mathrm{V}_{\mathrm{SL}}$ with a source impedance of $\mathrm{Z}_{01}$ (Figure 45 ). $\mathrm{V}_{\mathrm{SL}}$ is then coupled to the receiving line via the coupling capacitance, where the impedance looking into the line is line impedance in both directions. Therefore the equation becomes

$$
V_{R L}=V_{S L} \frac{\frac{Z_{0}}{2}}{\left(1.5 Z_{0}+Z_{c}\right)}
$$

The voltage impressed on the receiving line $\left(\mathrm{V}_{\mathrm{RL}}\right)$ then propagates along the receiving line to gate G 2 which can be considered as an open circuit and voltage doubling occurs. Therefore:

$$
\mathrm{V}_{\mathrm{in}(2)}=2 \mathrm{~V}_{\mathrm{RL}}=\mathrm{V}_{\mathrm{G} 3}\left(\frac{1}{1.5+\frac{\mathrm{Z}_{\mathrm{c}}}{\mathrm{Z}_{0}}}\right)\left(\frac{\mathrm{Z}_{0}}{\mathrm{RS} 3+\mathrm{Z}_{0}}\right)
$$

In the switching period, the transistor has a very low output impedance. Then $\mathrm{R}_{\mathrm{S} 3} \ll \mathrm{Z}_{0}$ and $\mathrm{V}_{\mathrm{in}(2)}$ can be simplified to the following:

$$
\mathrm{V}_{\mathrm{in}(2)}=\mathrm{V}_{\mathrm{G} 3}\left(\frac{1}{1.5+\frac{\mathrm{Z}_{\mathrm{c}}}{\mathrm{Z}_{0}}}\right)
$$



Figure 44. Coupling Impedances Involved in Cross Talk

The term $\mathrm{V}_{\mathrm{in}(2) / \mathrm{V}_{\mathrm{G} 3}}$ can be defined as the cross-talk coupling constant.

The worst-case for signal line cross talk occurs when sending and receiving lines are close together but widely separated from a ground return path. The lines then have a high characteristic impedance and a low coupling impedance.

For example, if we assume a coupling impedance of 50 pF at 150 MHz with a line impedance of approximately $200 \Omega$ then:

$$
\frac{V_{\mathrm{in}(2)}}{\mathrm{V}_{\mathrm{G} 3}}=0.62
$$

This level is unsatisfactory because none of the very highspeed logic circuits has a guaranteed noise margin greater than one-third of the logic swing. Such potential cross talk can be avoided by not using the close spacing of conductors.


Figure 45. Equivalent Cross-Talk Network
Mutual coupling can be reduced by using coaxial cable or shielded twisted pairs. When mutual inductance and capacitance are decreased, line capacitance is increased and imposes restrictions on the driver. Coaxial cable combines very high mutual impedance with low characteristic impedance and shielding. It effectively eliminates cross talk, but is necessary in only the noisiest environments. Twisted pairs are adequate for most applications and are typically less expensive and easier to use.

## Printed Circuit Card Conductors

Signal interconnections on a two-sided or multilayer printed circuit card can be grouped into two general categories: microstrip lines and strip lines. The microstrip line (Figure 46) consists of a signal conductor separated from a ground plane by a dielectric insulating material. A strip line (Figure 47) consists of a signal conductor within a dielectric insulating material and the conductor being centered between two parallel conductor planes. The important features of these type of printed circuit conductors are that the impedances are highly predictable, can be closely controlled, and the process is relatively inexpensive because standard printed circuit board manufacturing techniques are used. Typical impedances of these types of conductors with respect to their physical size and relative spacings are shown in Tables 7 and 8.

Table 7. Typical Impedance of Microstrip Lines

| Dimensions |  | Line Impedance <br> $\mathbf{Z O}_{\mathbf{O}}(\mathbf{\Omega})$ | Capacitance <br> per Foot (pF) |
| :---: | :---: | :---: | :---: |
| $\mathbf{H}$ (mils) | $\mathbf{W}$ (mils) | 35 | 40 |
| 6 | 20 | 40 | 35 |
| 6 | 15 | 56 | 30 |
| 15 | 20 | 66 | 26 |
| 15 | 15 | 80 | 20 |
| 30 | 20 | 89 | 18 |
| 30 | 15 | 105 | 16 |
| 60 | 20 | 114 | 14 |
| 60 | 15 | 124 | 13 |
| 100 | 20 | 132 | 12 |
| 100 | 15 |  |  |

Table 8. Typical Impedance of Strip Lines

| Dimensions |  | Line Impedance <br> $\mathbf{Z O}_{\mathbf{O}}(\Omega)$ | Capacitance <br> per Foot $(\mathbf{p F})$ |
| :---: | :---: | :---: | :---: |
| $\mathbf{H}^{\prime} \mathbf{a}=\mathbf{H}^{\prime} \mathbf{b}=$ <br> (mils) | $\mathbf{W}$ (mils) | (m) |  |
| 6 | 20 | 27 | 80 |
| 6 | 15 | 32 | 70 |
| 10 | 20 | 34 | 67 |
| 10 | 15 | 40 | 56 |
| 12 | 20 | 37 | 57 |
| 12 | 15 | 43 | 48 |
| 20 | 20 | 44 | 48 |
| 20 | 15 | 51 | 42 |
| 30 | 20 | 55 | 39 |
| 30 | 15 | 61 | 35 |

Relative dielectric constant $\approx 5$, and $H^{\prime} a=H^{\prime} b$

Cross talk on a printed circuit board is also a function of the mutual reactances and the line parameters which govern the line impedance. A microstrip line and a strip line are, by definition, conductors placed relatively close to a ground plane. Therefore, they have at least one inherent property which tends to reduce cross talk. In addition, the thickness $(\mathrm{H})$ of the dielectric and the spacing ( S ) of the conductors can be implemented selectively to reduce the amount of possible cross talk. The effects of these two dimensions on cross talk have been evaluated and are shown graphically in Figure 48. The data shown can be used to estimate the maximum crosstalk which will be encountered under the most unfavorable conditions.

Relative dielectric constant $\approx 5$


Figure 46. Microstrip Line


Figure 47. Strip Line


Figure 48. Line Spacing Versus
Cross-Talk Constant

## Transmission-Line Driving Reflections

When the interconnections used to transfer digital information become long enough so that line propagation delay is equal to or greater than the pulse transition times, the effects of reflections must be considered. These reflections are created because most TTL interconnections are not terminated in their characteristic impedance. Reflections lead to reduced noise margins, excessive delays, ringing, and overshoot. Some method must be used to analyze these reflections. Because neither the gate input nor output impedance is linear, basic transmission-line equations are applicable but unwieldy. Transmission-line characteristics of TTL interconnections can be analyzed by using a simple graphic technique.

Figure 49 shows piecewise linear plots of a gate input and both (logic-high and logic-low) states of the output for a typical TTL device. The output curves are plotted with positive slopes. The input is inverted because it is at the receiving end of a transmission line. The logic-high and logiclow intersections are indicated on the plot. These points are the steady-state values which will be observed on a lossless transmission line (Figure 50).

Figure 50 shows a typical TTL interconnection using a twisted-pair cable which, in this example, has a characteristic impedance of approximately $30 \Omega$. To evaluate a logic-high to logic-low 'AS transition see Figures 51 and 52. The equation $-1 / Z_{0}\left(Z_{0}=30 \Omega\right)$, which represents the transmission line, is superimposed on the output characteristic curves in the Bergeron plot. Since evaluation of a logic-high to logic-low transition is desired, the $-1 / Z_{0}$ line starts at the point of intersection of the impedance curves of the input and output for a logic-high state. The slope $-1 / Z_{0}$ then proceeds toward the logic-low output curve. At time $t_{0}$, the driver output voltage is determined by the intersection of


Figure 49. TTL Bergeron Diagram


Figure 50. 'ALS/'AS Driving Twisted Pair
$-1 / \mathrm{Z}_{0}$ and the logic-low output curve ( 1.2 V ). The transmission-line slope now becomes $1 / Z_{0}$ and is drawn toward the input curve. At time $t_{1}\left[t_{(n+1)}-t_{n}=\right.$ time delay of line], the receiving gate sees -0.7 V . Now the line slope changes back to $-1 / \mathrm{Z}_{0}$ and the output curve for a logic low is approached. This action continues until the logic-low intersection is reached. Figure 52 plots driver and receiver voltages versus time for this example.

A logic-low to logic-high transition is treated in approximately the same manner (Figure 53). The Bergeron line $-1 / Z_{0}$ starts at the intersection for a logic low. At time $\mathrm{t}_{0}$, the driver output rises to 2.2 V and, at time $\mathrm{t}_{1}$, the receiving gate input goes to approximately 4.35 V . Both output and input voltages are plotted in Figure 54.

Figures 55 through 58 illustrate 'ALS transitions and are treated in the same manner as the 'AS.

The scope photographs in Figures 59 through 66 show the effectiveness of the graphic techniques. In most cases, the calculated and experimental values of voltage steps agree within reason. The ringing that appears for the open wire is not immediately obvious. This is because the input and output curves in this region lie practically along the positive horizontal axis. At the scale used for graphic analysis, it is difficult to go much beyond the first few reflections. The graphic analysis is idealized and stray capacitance and inductance are not considered.


Figure 51. 'AS - ve Transition Bergeron Diagram


Figure 52. 'AS - ve Voltage/Time Plot


Figure 53. 'AS + ve Transition Bergeron Diagram


Figure 54. 'AS + ve Voltage/Time Plot


Figure 55. 'ALS - ve Transition Bergeron Diagram


Figure 56. 'ALS - ve Voltage/Time Plot


Figure 57. 'ALS + ve Transition Bergeron Diagram


Figure 58. 'ALS + ve Voltage/Time Plot


TRANSITION $(1 \rightarrow 0)$
Figure 59. Oscilloscope Photograph of 'AS001 - ve Transition Using 50-Ohm Line


TRANSITION $(0 \rightarrow 1)$
Figure 60. Oscilloscope Photograph of 'AS00 + ve Transition Using $\mathbf{5 0 - O h m}$ Line


Figure 61. Oscilloscope Photograph of 'AS00 - ve Transition Using 25-Ohm Line


Figure 62. Oscilloscope Photograph of 'AS00 + ve Transition Using 25-Ohm Line


Figure 63. Oscilloscope Photograph of 'ALS00A - ve Transition Using 50-Ohm Line


Figure 64. Oscilloscope Photograph of 'ALS00A + ve Transition Using 50-Ohm Line


Figure 65. Oscilloscope Photograph of 'ALS00A - ve
Transition Using $\mathbf{2 5 - O h m}$ Line


Figure 66. Oscilloscope Photograph of 'ALS00A + ve Transition Using 25-Ohm Line

## References

1. W.C. Elmore and M. Sands, Electronics Experimental Techniques, McGraw-Hill Book Co., New York, 30ff. (1949).
2. M. Williams and S. Miller, Series 54ALS/74ALS Schottky TTL Applications B215, Texas Instruments Limited, Bedford, England, August 1982.

## Acknowledgment

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## Appendix A Normalized Load Factors

Normalizing output drive capability and input current requirements can be very useful to designers of systems using two or more of the TI TTL series of devices. It provides a set of load factors (input cuurent requirements in Table A-1), which can be summed and compared directly to the fanout capability (see Table A-2) of the output being considered. The load factor values shown are valid for any input rated at one unit load.

The loading of these type of outputs can be checked from any column. However, most designs use one of the series as the basic building block and, since the tables cover each series individually, the designer has the choice of working from the column containing the normalized fanout. As an example, the designers of a system using series 'AS as the basic circuit will probably find that the use of the 'AS00 and 'AS1000 columns will suit best because both fanout and load factors are expressed for these series of devices.

The use of these simple and easy-to-remember numbers was developed within each series to make the verification of output loading a matter of counting the number of inputs connected to a particular output. When mixtures of series are used, a common denominator (normalized factor) becomes useful.

## USE OF TABLES A-1 AND A-2

Every possible combination of the seven 54/74 TTL families is included in these tables. If, for example, the existing system used 74 S series logic and it is desired that some of it be replaced by series 74ALS logic, a quick check should be made on whether the 'ALS can be supplied with sufficient input current. By taking the 74S row and 'ALS, column figures of 2.5 and 20 are obtained for high- and low-level loads, respectively (see Table A-1). This indicates that, for high logic levels, two and one-half 'ALS gates can be driven for each 'S series gate removed. However, if more 74S series gates are being driven by this 'ALS device, the fanout between 'ALS and 'S series gate is required, you can now use Table A-2.

The 'ALS row and the 'S column are chosen. The figures are 8 for the high-logic level and 4 for the low-logic level. In this case the lowest figure is taken so that the interconnection is reliable for both logic states. So each 'ALS gate inserted will drive 4 ' S series gates.

Table A-1. Normalized Input Currents

| SERIES | 1/0 | $\begin{gathered} \text { INPUT } \\ \text { CURRENT } \\ \text { (mA) } \end{gathered}$ | INPUT CURRENT NORMALIZED |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\bigcirc 00$ | 'HOO | 'L00 | ${ }^{\prime}$ LSOO | 'S00 | 'ASOO | 'ALSOOA | 'AS1000 | 'ALS1000A |
| 54/7400 | HI | 0.04 | 1 | 0.8 | 4 | 2 | 0.8 | 2 | 2 | 2 | 2 |
| 54/7400 | LO | 1.6 | 1 | 0.8 | 8.89 | 4 | 0.8 | 3.2 | 16 | 3.2 | 16 |
| 54H/74H00 | HI | 0.05 | 1.25 | 1 | 5 | 2.5 | 1 | 2.5 | 2.5 | 2.5 | 2.5 |
| $54 \mathrm{H} / 74 \mathrm{HOO}$ | LO | 2 | 1.25 | 1 | 11.11 | 5 | 1 | 4 | 20 | 4 | 20 |
| 54/74L00 | HI | 0.01 | 0.25 | 0.2 | 1 | 0.5 | 0.2 | 0.5 | 0.5 | 0.5 | 0.5 |
| 54/74L00 | LO | 0.18 | 0.11 | 0.09 | 1 | 0.45 | 0.09 | 0.36 | 1.8 | 0.36 | 1.8 |
| 54LS/74LS00 | HI | 0.02 | 0.5 | 0.4 | 2 | 1 | 0.4 | 1 | 1 | 1 | 1 |
| 54LS/74LS00 | LO | 0.4 | 0.25 | 0.2 | 2.22 | 1 | 0.2 | 0.8 | 4 | 0.8 | 4 |
| 54S/74S00 | H! | 0.05 | 1.25 | 1 | 5 | 2.5 | 1 | 2.5 | 2.5 | 2.5 | 2.5 |
| 54S/74S00 | LO | 2 | 1.25 | 1 | 11.11 | 5 | 1 | 4 | 20 | 4 | 20 |
| 54AS/74AS00 | HI | 0.02 | 0.5 | 0.4 | 2 | 1 | 0.4 | 1 | 1 | 1 | 1 |
| 54AS/74AS00 | LO | 0.5 | 0.31 | 0.25 | 2.78 | 1.25 | 0.25 | 1 | 5 | 1 | 5 |
| 54ALS/74ALSO0A | HI | 0.02 | 0.5 | 0.4 | 2 | 1 | 0.4 | 1 | 1 | 1 | 1 |
| 54ALS/74ALSOOA | LO | 0.1 | 0.06 | 0.05 | 0.56 | 0.25 | 0.05 | 0.2 | 1 | 0.2 | 1 |
| 54AS1000 | HI | 0.02 | 0.5 | 0.4 | 2 | 1 | 0.4 | 1 | 1 | 1 | 1 |
| 54AS1000 | LO | 0.5 | 0.31 | 0.25 | 2.78 | 1.25 | 0.25 | 1 | 5 | 1 | 5 |
| 54ALS1000A | H! | 0.02 | 0.5 | 0.4 | 2 | 1 | 0.4 | 1 | 1 | 1 | 1 |
| 54ALS 1000 A | LO | 0.1 | 0.06 | 0.05 | 0.56 | 0.25 | 0.05 | 0.2 | 1 | 0.2 | 1 |

Table A-1 is normally used (in combination with Table A-2) when replacing one logic family with another in an existing system.

Table A-2 is normally used when originally designing a system which employs several TTL families to optimize performance.

Table A-2. Fanout Capability (Output Currents Normalized to Input Currents)

| SERIES | 1/0 | OUTPUT <br> CURRENT <br> (mA) | OUTPUT DRIVE NORMALIZED |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | '00 | 'H00 | 'L00 | ${ }^{\text {LSOO }}$ | 'S00 | 'ASOO | 'ALSOOA | 'AS1000 | ALS 1000A |
|  |  |  | *HI 0.04 | 0.05 | 0.01 | 0.02 | 0.05 | 0.02 | 0.02 | 0.02 | 0.02 |
|  |  |  | to 1.6 | 2 | 0.18 | 0.4 | 2 | 0.5 | 0.1 | 0.5 | 0.1 |
| 54/7400 | HI | 0.4 | 10 | 8 | 40 | 20 | 8 | 20 | 20 | 20 | 20 |
| 54/7400 | LO | 16 | 10 | 8 | 88.89 | 40 | 8 | 32 | 160 | 32 | 160 |
| 54H/74H00 | HI | 0.5 | 12.5 | 10 | 50 | 25 | 10 | 25 | 25 | 25 | 25 |
| 54H/74H00 | LO | 20 | 12.5 | 10 | 111.11 | 50 | 10 | 40 | 200 | 40 | 200 |
| 54LOO | HI | 0.1 | 2.5 | 2 | 10 | 5 | 2 | 5 | 5 | 5 | 5 |
| 54LOO | LO | 2 | 1.25 | 1 | 11.11 | 5 | 1 | 4 | 20 | 4 | 20 |
| 74L00 | HI | 0.2 | 5 | 4 | 20 | 10 | 4 | 10 | 10 | 10 | 10 |
| 74L00 | LO | 3.6 | 2.25 | 1.8 | 20 | 9 | 1.8 | 7.2 | 36 | 7.2 | 36 |
| 54LS/74LS00 | HI | 0.4 | 10 | 8 | 40 | 20 | 8 | 20 | 20 | 20 | 20 |
| 54LS00 | LO | 4 | 2.5 | 2 | 22.22 | 10 | 2 | 8 | 40 | 8 | 40 |
| 74LS00 | LO | 8 | 5 | 4 | 44.44 | 20 | 4 | 16 | 80 | 16 | 80 |
| 54S/74S00 | HI | 1 | 25 | 20 | 100 | 50 | 20 | 50 | 50 | 50 | 50 |
| 54S/74S00 | LO | 20 | 12.5 | 10 | 111.11 | 50 | 10 | 40 | 200 | 40 | 200 |
| 54AS/74AS00 | HI | 2 | 50 | 40 | 200 | 100 | 40 | 100 | 100 | 100 | 100 |
| 54AS/74AS00 | LO | 20 | 12.5 | 10 | 111.11 | 50 | 10 | 40 | 200 | 40 | 200 |
| 54ALS/74ALSOOA | HI | 0.4 | 10 | 8 | 40 | 20 | 8 | 20 | 20 | 20 | 20 |
| 54ALSOOA | LO | 4 | 2.5 | 2 | 22.22 | 10 | 2 | 8 | 40 | 8 | 40 |
| 74ALSOOA | LO | 8 | 5 | 4 | 44.44 | 20 | 4 | 16 | 80 | 16 | 80 |
| 54AS1000 | HI | 40 | 1000 | 800 | 4000 | 2000 | 800 | 2000 | 2000 | 2000 | 2000 |
| 54AS1000 | LO | 40 | 25 | 20 | 222.22 | 100 | 20 | 80 | 400 | 80 | 400 |
| 74AS1000 | HI | 48 | 1200 | 960 | 4800 | 2400 | 960 | 2400 | 2400 | 2400 | 2400 |
| 74AS1000 | LO | 48 | 30 | 24 | 266.67 | 120 | 24 | 96 | 480 | 96 | 480 |
| 54ALS1000A | HI | 1 | 25 | 20 | 100 | 50 | 20 | 50 | 50 | 50 | 50 |
| 54ALS1000A | LO | 12 | 7.5 | 6 | 66.67 | 30 | 6 | 24 | 120 | 24 | 120 |
| 74ALS1000A | HI | 2 | 65 | 52 | 260 | 130 | 52 | 130 | 130 | 130 | 130 |
| 74ALS1000A | LO | 24 | 15 | 12 | 133.33 | 60 | 12 | 48 | 240 | 48 | 240 |

*Input Current HI
${ }^{\dagger}$ Input Curent lo

## Appendix $B$

## Letter Symbols, Terms, and Definitions

These symbols, terms, and definitions are in accordance with those currently agreed upon by the JEDEC Council of the Electronics Industries Association (EIA) for use in the USA and by the International Electrotechnical Commission (IEC) for international use. The definitions are grouped into sections applying to voltages, currents, switching characteristics, and classification of circuit complexity.

## VOLTAGES

## VIH High-level input voltage

An input voltage level within the more positive (less negative) of the two ranges of values used to represent the binary variables. A minimum value is specified which is the least-positive (most-negative) value of high-level input voltage for which operation of the logic element within specification limits is guaranteed.

VIL Low-level input voltage
An input voltage level within the less positive (more negative) of the two ranges of values used to represent the binary variables. A maximum value is specified which is the most-positive (least-negative) value of low-level input voltage for which operation of the logic element within specification limits is guaranteed.
$\mathbf{V}_{\mathbf{T}}+\quad$ Positive-going threshold voltage
The voltage level at a transition-operated input that causes operation of the logic element according to specification as the input voltage rises from a level below the negative-going threshold voltage, $\mathrm{V}_{\mathrm{T}}-$.

VT- Negative-going threshold voltage
The voltage level at a transition-operated input that causes operation of the logic element according to specification as the input voltage falls from a level above the positive-going threshold voltage, $\mathrm{V}_{\mathrm{T}}+$.
VOH High-level output voltage
The voltage at an output terminal for a specified output current $I \mathrm{OH}$ with input conditions applied that according to the product specification will establish a high level at the output.

VOL Low-level output voltage
The voltage at an output terminal for a specified output current IOL with input conditions applied that according to the product specification will establish a low level at the output.

## $\mathbf{V}_{\mathbf{O}(o n)}$ On-state output voltage

The voltage at an output terminal for a specified output current with input conditions applied that according to the product specification will cause the output switching element to be in the on state.

Note: This characteristic is usually specified only for outputs not having internal pull-up elements.

## $\mathbf{V} \mathbf{O}$ (off) Off-state output voltage

The voltage at an output terminal for a specified output current with input conditions applied that according to the specification will cause the output switching element to be in the off state.
Note: This characteristic is usually specified only for outputs not having internal pull-up elements.

## CURRENT

IIH High-level input current
The current flowing into* an input when a specified high-level voltage is applied to that input.
IIL Low-level input current
The current flowing into* an input when a specified low-level voltage is applied to that input.

[^58]IOH High-level output current
The current flowing into* the output with a specified high-level output voltage $\mathrm{V}_{\mathrm{OH}}$ applied.
Note: This parameter is usually specified for open-collector outputs intended to drive other logic circuits.
IO(off) Off-state output current
The current flowing into* an output with a specified output voltage applied and input conditions applied that according to the product specification will cause the output switching element to be in the off state.
Note: This parameter is usually specified for open-collector outputs intended to drive devices other than logic circuits or for three-state outputs.

IOS Short-circuit output current
The current flowing into* an output when that output is short-circuited to ground (or other specified potential) with input conditions applied to establish the output logic level farthest from ground potential (or other specified potential).
ICCH Supply current, output(s) high
The current flowing into ${ }^{*}$ the $\mathrm{V}_{\mathrm{CC}}$ supply terminal of a circuit when the reference output(s) is (are) at a high-level voltage.

ICCL Supply current, output(s) low
The current flowing into ${ }^{*}$ the $\mathrm{V}_{\mathrm{CC}}$ supply terminal of a circuit when the reference output(s) is (are) at a low-level voltage.

## DYNAMIC CHARACTERISTICS

$\mathbf{f}_{\max } \quad$ Maximum clock frequency
The highest rate at which the clock input of a bistable circuit can be driven through its required sequence while maintaining stable transitions of logic level at the output with input conditions established that should cause a change of output state with each clock pulse.
thZ Output disable time (of a three-state output) from high level
The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined high level to a high-impedance (off) state.
$t_{\text {LZ }} \quad$ Output disable time (of a three-state output) from low level
The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined low level to a high-impedance (off) state.
tPLH . Propagation delay time, low-to-high-level output
The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined low level to the defined high level.
tPHL Propagation delay time, high-to-low-level output
The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined high level to the defined low level.
tTLH Transition time, low-to-high-level output
The time between a specified low-level voltage and a specified high-level voltage on a waveform that is changing from the defined low level to the defined high level.
tTHL Transition time, high-to-low-level output
The time between a specified high-level voltage and a specified low-level voltage on a waveform that is changing from the defined high level to the defined low level.
$\mathbf{t}_{\mathbf{w}} \quad$ Average pulse width
The time between $50 \%$ amplitude points (or other specified reference points) on the leading and trailing edges of a pulse.
*Current flowing out of a terminal is a negative value.

## Hold time

The time interval for which a signal or pulse is retained at a specified input terminal after an active transition occurs at another specified input terminal.

## trelease Release time

The time interval between the release from a specified input terminal of data intended to be recognized and the occurrence of an active transition at another specified input terminal.

Note: When specified, the interval designated "release time" falls within the setup interval and constitutes, in effect, a negative hold time.
$\mathbf{t}_{\text {su }} \quad$ Setup time
The time interval for which a signal is applied and maintained at a specified input terminal before an active transition occurs at another specified input terminal.
tZH Output enable time (of a three-state output) to high level
The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined high level.
tZL Output enable time (of a three-state output) to low level
The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined low level.

## CLASSIFICATION OF CIRCUIT COMPLEXITY

## Gate equivalent circuit

A basic unit-of-measure of relative digital-circuit complexity. The number of gate equivalent circuits is that number of individual logic gates that would have to be interconnected to perform the same function.

## LSI Large-scale integration

A concept whereby a complete major subsystem or system function is fabricated as a single microcircuit. In this context a major subsystem or system, whether logical or linear, is considered to be one that contains 100 or more equivalent gates or circuitry of similar complexity.

MSI Medium-scale integration
A concept whereby a complete subsystem or system function is fabricated as a single microcircuit. The subsystem or system is smaller than for LSI, but whether digital or linear, is considered to be one that contains 12 or more equivalent gates or circuitry of similar complexity.
SSI Small-scale integration
Integrated circuits of less complexity than medium-scale integration (MSI).
*Current flowing out of a terminal is a negative value.


# Error Detection and Correction Using SN54/74ALS632A, SN54/74ALS633 through SN54/74ALS635 

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## INTRODUCTION

## NEED FOR ERROR CORRECTION

With memory systems continuing to expand and the expectation of 256 K DRAMs in the near future, it has become increasingly important that system designers consider error detection and correction. Generally, the larger the chip density, the greater the probability for device errors. It is easy to recognize this probability when one considers that a 32 -bit $\times 64 \mathrm{~K}$ memory, using 64 K DRAMs, equates to approximately 2.1 million bits of information. This expands to 8.4 million bits of information when using 256 K DRAMs. For memory sizes larger than $1 / 2$ million bits, it is generally considered that error detection and correction is required to guarantee high reliability.

The SN54/74ALS632A, SN54/74ALS633 through SN54/74ALS635 provide a simple solution to these requirements in 32-bit machines. In addition, the 'ALS632A and ALS633 provide the necessary hardware to perform bytewrite operations which are typically used in the more advanced systems. To ensure the integrity of the error detection and correction circuit itself, diagnostic capabilities have been provided in all four devices.

The 'ALS632A series devices are not limited to only 32 -bit systems. They can easily be implemented in $16-$ or 24 -bit systems. In the case of 16 -bit systems, the additional memory needed for holding the check bits can be reduced when compared to conventional 16-bit EDAC's.

The pin function table and mechanical data for the 'ALS632A, ALS633 through 'ALS635 are shown respectively as Table 1 and Figure 1.

## OPERATIONAL DESCRIPTION

## WRITE MODE

During a memory write cycle, the EDAC is required to generate a 7 -bit check word to accompany the 32 -bit data word before being written into memory. To place the 'ALS632A, "ALS633 through 'ALS635 in the write mode, simply take S1 and S0 low. Output enable controls $\overline{\mathrm{OEB}} 0$ through $\overline{\mathrm{OEB}} 3$ for the 'ALS632A, 'ALS633, or $\overline{\mathrm{OEDB}}$ for the 'ALS634, 'ALS635, must be taken high before the data word can be applied. Output enable control $\overline{\mathrm{OECS}}$ must be taken low to pass the check word to the external bus.

The check word will be generated in not more than 48 ns * after the data word has been applied. The 'ALS632A series EDACs can be made to appear transparent to memory, during the write mode, because typical write times of most DRAMs are much larger than the propagation delay of data to check word.

## READ-FLAG-CORRECT OPERATION

During a memory read cycle, the function of the 'ALS632A series EDACs is to compare the 32 -bit data word against the 7 -bit check word previously stored in memory. It will then flag and correct any single-bit error which may have occurred. Single bit errors will be detected through the $\overline{\mathrm{ERR}}$ flag and double bit errors will be detected through the $\overline{M E R R}$ flag. Figure 2 shows a typical timing diagram of the read-flag-correct operation.

When $S 0$ is taken high, the EDAC will internally begin the correction process, although it should be noted that the error flags are enabled while in the read mode. For many applications, the simplest operation can be obtained by always executing the correction cycle, regardless if a single-bit error has occurred.

## IMPORTANT TIMING CONSIDERATIONS FOR READ-FLAG-CORRECT MODE

The most frequently asked question for an EDAC is how fast can a correction cycle be executed. Before S0 can be taken high, the data and check word must be set up at least $10 \mathrm{~ns} *$. In addition, the data and check word must be held for at least $15 \mathrm{~ns} *$ after S 0 goes high. This ensures the data and check word is saved in the EDAC's input latches. After the hold time has been satisfied, the source which is driving the data bus can be placed in high impedance and the EDAC's output drivers can be enabled. This is accomplished by taking $\overline{\mathrm{OEB}} 0$ through $\overline{\mathrm{OEB}} 3$ ('ALS632A, 'ALS633) or $\overline{\mathrm{OEDB}}$ ('ALS634, 'ALS635) low.

If the minimum data set up time is used as a reference, and the output drivers are enabled after the minimum data hold time, then correction will be accomplished in not more than 58 ns .

## READ MODIFY-WRITE OPERATIONS

The'ALS632A and 'ALS633 contain the necessary hardware to perform byte-write operations. The 'ALS634 and 'ALS635 are not capable of byte-write operations because they do not contain an output data latch or individual byte controls. When performing a read-modifywrite function, typically the user would first want to perform the read-flag-correct cycle as discussed before, and shown in Figure 2. This ensures that corrected data is used at the start of the modity-write operation.

The corrected data is then latched into the output data latch by taking LEDBO from low to high. Upon completing this, modifying any byte or bytes is easily accomplished by taking the appropriate byte control $\overline{\mathrm{OEB}} 0$ through $\overline{O E B} 3$ high. This allows the user to place the modified byte or bytes back onto the data bus while retaining the other byte or bytes. An example of a read-

[^59]
## ceramic packages－side－braze（JD suffix）

This is a hermetically sealed ceramic package with a metal cap and side－brazed tin－plated leads．
＇ALS632A，ALS633 ．．．JD PACKAGE
（TOP VIEW）

| LEDB0 | 1 | $\bigcirc_{52}$ | $\square^{\mathrm{V}} \mathrm{cc}$ |
| :---: | :---: | :---: | :---: |
| MERR | 2 | 51 | ¢ 51 |
| ERR［ | 3 | 50 | ¢ so |
| DBO | 4 | 49 | D DB31 |
| DB1 | 5 | 48 | －DB30 |
| DB2 ${ }^{\text {c }}$ | 6 | 47 | 万 DB29 |
| DB3 | 7 | 46 | D DB28 |
| DB4 ${ }^{\text {a }}$ | 8 | 45 | D DB27 |
| DB5 | 9 | 44 | $7 \mathrm{DB26}$ |
| OEB0 | 10 | 43 | DOEB3 |
| DB6 | 11 | 42 | 万DB25 |
| DB7 | 12 | 41 | 万D824 |
| GND | 13 | 40 | 万GND |
| DB8 | 14 | 39 | －DBi23 |
| DB9 | 15 | 38 | DB22 |
| $\overline{\mathrm{OEB}} 1$ | 16 | 37 | $\overline{O E B 2}$ |
| DB10 | 17 | 36 | 万DB21 |
| DB11 | 18 | 35 | 70820 |
| DB12 | 19 | 34 | П DB19 |
| D813 | 20 | 33 | PDB18 |
| D814 | 21 | 32 | 3 DB17 |
| DB15 | 22 | 31 | ］DB16 |
| CB6 | 23 | 30 | 7 CBO |
| CB5 | 24 | 29 | ］CB1 |
| CB4 | 25 | 28 | $\square \mathrm{CB2}$ |
| $\overline{\text { OECB }}$ | 26 | 27 | ［ CB3 |

＇ALS634，＇ALS635 ．．．．JD PACKAGE （TOP VIEW）





| DIM | 48 | 52 |
| :--- | :---: | :---: |
| $A \pm 0.25(0.010)$ | $15,24(0.600)$ | $15,24(0.600)$ |
| B MAX | $62,2(2.45)$ | $67.3(2.65)$ |
| C NOM | $15.0(0.590)$ | $15,0(0.590)$ |

ALL DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

NOTE：a．Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position．
Figure 1．Mechanical Data for＇ALS632A，＇ALS633 through＇ALS635

Table I. Pin Function for 'ALS632A, 'ALS633 through 'ALS635



Figure 2. Read-Flag-Correct Timing Diagram
modify-write for byte 0 is shown in Figure 3. Since the check word is no longer valid for the modified data word, a new one is easily generated by taking S0 and S1 low. After the appropriate propagation delay, the new check word will be available.

## IMPORTANT TIMING CONSIDERATIONS FOR READMODIFY WRITE OPERATIONS

$\overline{\text { LEDB0 }}$ should not be brought from low to high until 45 ns * after S 0 goes high. This will ensure that corrected data is latched into the data output latches. On the other hand, $\overline{\text { LEDB0 }}$ should be brought high no later than $0 \mathrm{~ns}^{*}$
before S0 and S1 goes low. Again, this is to ensure that the corrected data is stored into the data output latches. Also of importance is the new check word will be available no later than 48 ns* after S0 and S1 goes low.

## DIAGNOSTIC MODE OPERATION

The purpose of the diagnostic mode is to provide the user with the capability of easily detecting when the EDAC or memory is failing. There are several possibilities as to how a user might employ this feature, but Figure 4 shows a typical timing diagram of some diagnostics which can be performed with these devices. Generally, the user would first place the EDAC in the read mode ( $\mathrm{S} 0=\mathrm{L}, \mathrm{S} 1=\mathrm{H}$ ), then apply a valid check word and data word. A valid check word is one in which the user knows what the associated data word. The user would next place the EDAC into the diagnostic mode by taking S0 high, and S1 low. This latches the valid check word into its input latches but leaves the data input latches transparent. To verify that the valid check word was latched properly, $\overline{O E C S}$ can be taken low causing the valid check word to be placed back onto the bus. Since the data input latches remain transparent, this allows the user to apply various diagnostic data words
against the valid check word. A diagnostic data word is one in which either a single or double bit error exists. In either case, the error flags should respond. The output data latch can be verified by taking LEDBO high and confirming the stored diagnostic data word is the same. This is made possible because error correction is disabled while in the diagnostic mode ( $\mathrm{S} 0=\mathrm{H}, \mathrm{S} 1=\mathrm{L}$ ). Taking S 1 high and LEDBO low will verify that the EDAC will correct the data word. Also, the error syndrome code can be verified by taking OECS low. It should be noted that only the 'ALS632A and 'ALS633 are capable of this pass through verification of the diagnostic data word. The 'ALS634 and 'ALS635 do not have the output data latch required to perform this function.

## 16-BIT SYSTEMS USING THE ALS632A SERIES EDACs

The 'ALS632A series EDACs can reduce the memory size required in 16 -bit systems where conventional 16 -bit EDACs ( 6 check bits, 16 data bits) are presently used. Figure 5 shows the typical system architecture for the 16-bit EDAC. In this system, 88 devices would be required for the 22 -bit $\times 256 \mathrm{~K}$ memory array, assuming 64 K DRAMs are used. It is easy to see that $27.3 \%$, or 24 devices, are


Figure 3. Read-Modify-Write Operation
required for storing the check bits. When using the'ALS632A series EDACs, the memory required for the check bits can be reduced to $17.9 \%$, or only 14 devices. This reduces the total number of DRAMs required by 10 devices. Figure 6 shows the architecture when using the 32 -bit EDAC. The
four 'LS646s are used to group two 16 -bit data words into one 32 -bit data word. In addition, this type of system can be used in byte-write operations where the other system cannot.


Figure 4. Diagnostic Mode Timing Diagram



Figure 6. 16-Bit System using 32-Bit EDAC

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# MEMORY MAPPING USING SN54/74LS610 THRU SN54/74LS613 

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## INTRODUCTION

Microprocessors, due to the advent of high density semiconductor memories (i.e., 64 K or larger), are being used more and more in systems featuring memory structures larger than 64 K bytes. The majority of the microprocessors in use or available today have a 16 -bit address bus, with a maximum addressing capability of 64 K words. Due to this limitation, some sort of memory mapping is necessary to adapt these microprocessors to applications where large. memory structures are required.

The memory mappers (SN54/74LS610 through SN54/74LS613) from TI were designed to alleviate this addressing limitation. These devices employ a paged memory mapping technique in expanding the system memory address bus by 8 bits, thus effectively increasing the system addressing capability by a factor of $2^{8}$ or 256 . For microprocessors with a 16 -bit address bus (such as the Z-80, the 8085 and the 6800), this results in an increase in the maximum addressing capability from 64 K bytes to 16 M bytes and for the TMS 9900 (which has a 15 -bit address bus), the result is an increase from 32 K words to 8 M words (word = 2 bytes).

In the mapping operation, the four MSBs of the microprocessor address word are used to access one of the sixteen 12-bit registers of the memory mapper's $16 \times 12$-bit RAM array. Each mapper register is capable of holding a 12 -bit address which will be termed the page address and will be used as the 12 MSBs of the memory address bus. The remaining 12 bits ( 11 in the case of the TMS9900) of the microprocessor address bus will be transferred directly to memory from the microprocessor and will be used to address the memory locations within each page. (See Figure 1)

The memory will be organized into $2^{\mathrm{X}}$ pages (where x equals the number of bits of the page address) with $2^{n-4}$ words or bytes (where n is the bit length of the microprocessor address bus) per page. Once loaded, the mapper can access only 16 pages or 64 K bytes $(32 \mathrm{~K}$ words in the

TMS9900 case). In order to access more pages, the memory mapper RAM array must be reloaded with 16 new page addresses. This is done by the microprocessor via the data bus with the mapper in the WRITE mode. (A more detailed description of the modes of operation will be given later in this report.)

## FUNCTIONAL DESCRIPTION

A functional block diagram of the SN54/74LS610 memory mapper, which consists mainly of: a 4-bit 2 -to-1 multiplexer, a $16 \times 12$-bit RAM array, a 12 -bit 2 -to- 1 multiplexer, 243 -state buffers, control logic and in the case of 'LS610 and 'LS611, a 12-bit transparent latch, as shown in Figure 2. Table I lists the functional differences between the 'LS610, 'LS611, 'LS612, and 'LS613. Table II lists the function of each pin.

Depending on the state of the input control signals (i.e., $\overline{\mathrm{CS}}, \mathrm{R} / \overline{\mathrm{W}}, \overline{\mathrm{STROBE}}, \overline{\mathrm{MM}}$, and $\overline{\mathrm{ME}}$ ), the mapper can be operated in three basic modes of operation, I/O (READ or WRITE), MAP and PASS. An explanation of each mode and the control signals necessary to achieve that mode of operation is given below: (Refer to Table III)

## Input/Output Mode

In this mode a page address can be loaded either into a mapper register or can be read from a memory mapper register depending on the state of the R/W (READ/ WRITE) input. This input signal controls either the READ or WRITE function of the I/O Mode.

## WRITE Mode

One of the sixteen 12 -bit registers is loaded with a page address via the D0-D11 I/O ports from the microprocessor. The address of the selected register is inputted via the RSO-RS3 inputs and is usually the four LSBs of the microprocessor address word. The chip select (CS), the strobe ( $\overline{\mathrm{STROBE}}$ ) and R/W controls should all be low.


Figure 1. Mapping Operation


Figure 2. Logic Diagram of the Memory Mapper 'LS610

Table I. Device Comparison

| Device | Map Outputs <br> Latched | Map <br> Output Type |
| :---: | :---: | :---: |
| SN54/74LS610 | Yes | 3-State |
| SN54/74LS611 | Yes | Open-collector |
| SN54/74LS612 | No | 3-State |
| SN54/74LS613 | No | Open-collector |

## - READ Mode

The contents of one of the sixteen 12 -bit registers is read from the mapper via the D0-D11 I/O ports. As in the WRITE mode, the mapper register is selected by the address on the RSO-RS3 inputs. Again chip select ( $\overline{\mathrm{CS}}$ ) should be low, while the $\mathrm{R} / \overline{\mathrm{W}}$ should be kept high.

## MAP Mode

The contents of one of the sixteen 12 -bit memory mapper registers is outputted to the system address bus via the MO0-MO11 outputs. The address on MA0-MA3 selects the mapper register and is usually the four MSBs of the microprocessor address word. The chip select ( $\overline{\mathrm{CS}}$ ) must be inactive (high), the map mode ( $\overline{\mathrm{MM}}$ ) control and the map enable ( $\overline{\mathrm{ME}}$ ) must both be active (low). The n-4 LSBs, where $n$ equals the microprocessor address bit length, of the microprocessor address bus will be transferred directly to memory from the microprocessor, while the remaining 12 MSBs of the system address bus will be driven onto the bus by the memory mapper.

Table II. Pin Functions

| Pin | Pin Name | Functional Description |
| :---: | :---: | :---: |
| $\begin{gathered} 7-12 \\ 29-34 \end{gathered}$ | D0 thru D11 | I/O connections to data and control bus used for reading from and writing to the map register selected by RSO-RS3 when $\overline{\mathrm{CS}}$ is low. Mode controlled by R/ $\bar{W}$. (DO corresponds to MOO and is the most significant bit.) |
| 36, 38, 1, 3 | RSO thru RS3 | Register select inputs for I/O operations. (RS3 is the least significant bit.) |
| 6 | $\mathrm{R} \overline{\mathrm{W}}$ | Read or write control used in I/O operations to select the condition of the data bus. When high, the data bus outputs are active for reading the map register. When low, the data bus is used to write into the register. |
| 5 | STROBE | Strobe input used to enter data into the selected map register during I/O operations. |
| 4 | $\overline{\mathrm{CS}}$ | Chip select input. A low input level selects the memory mapper (assuming more than one used) for an I/O operation. |
| 35, 37, 39, 2 | MAO thru MA3 | Map address inputs to select one of 16 map registers when in map mode ( $\overline{\mathrm{MM}}$ low and $\overline{\mathrm{CS}}$ high). (MA3 is the least significant bit.) |
| $\begin{aligned} & 14-19 \\ & 22-27 \end{aligned}$ | MOO thru MO11 | Map outputs. Present the map register contents to the system memory address bus in the map mode. In the pass mode, these outputs provide the map address data on MO8-MO11 and low levels on MO0-MO7. (MO11 is the least significant bit.) |
| 13 | $\overline{M M}$ | Map mode input. When low, 12 bits of data are transferred from the selected map register to the map outputs. When high (pass mode), the four bits present on the map address inputs are passed to the map outputs. |
| 21 | $\overline{M E}$ | Map enable for the map outputs. A low level allows the outputs to be active while a high input level puts the outputs at high impedance. |
| 28 | C | Latch enable input for the 'LS610 and 'LS611 (no internal connection for 'LS612 and 'LS613). A high level will transparently pass data to the map outputs. A low level will latch the outputs. |
| 40,20 | $V_{\text {CC }}$, GND | Power supply ( 5 V ) and network ground (substrate) pins. |

Table III. Modes of Operation

| MAPPER INPUTS | 1/0 |  | MAP | PASS |
| :---: | :---: | :---: | :---: | :---: |
|  | WRITE (LOAD) | READ (VERIFY) |  |  |
| $\overline{\text { CS }}$ | Active (Low) | Active (Low) | Inactive (High) | Inactive (High) |
| STROBE | Active (Low) | Don't Care | Don't Care | Don't Care |
| $\mathrm{R} / \bar{W}$ | Low | High | Don't Care | Don't Care |
| $\overline{\mathrm{MM}}$ | Don't Care | Don't Care | Active (Low) | Inactive (High) |
| $\overline{M E}$ | Inactive (High) | Inactive (High) | Active | Active |
| RSO-RS3 | Address of Selected Register | Address of Selected Register | Don't Care | Don't Care |
| MAO-MA3 | Don't Care | Don't Care | Address of Selected Register | Address of Selected Register |
| MOO-MO11 | High Impedance | High Impedance | Valid Address | Valid Address |
| D0-D11 | Register contents to be loaded (input) | Register contents to be read (output) | Input Mode | Input Mode |

## PASS Mode

The four LSBs (MO8-MO11) of the memory mapper address bus (MO0-MO11) will be the same as the address on the MA0-MA3 input bus, while the remaining eight MSBs of the memory mapper address bus will all be low. The chip select ( $\overline{\mathrm{CS}}$ ) and the map mode ( $\overline{\mathrm{MM}}$ ) should both the inactive (high); map enable ( $\overline{\mathrm{ME}}$ ) should be active. In other words, the address on the system address bus will be the same as the address outputted by the microprocessor, and the memory mapper becomes transparent to the system.

## SYSTEMS INTEGRATION

The flexibility of the memory mapper is such that it can be used with microprocessors that have either an 8 -bit or a 16 -bit data bus. In order to use the memory mapper to its fullest potential (i.e., expand the address bus by eight bits) with an 8 -bit microprocessor, the 12 -bit page address must be multiplexed into the mapper via the 8 -bit data bus. This means that the time it normally takes to load or read the memory mapper will be at least doubled and extra external circuitry will be necessary. If the requirement of the system is such that the address bus needs to be increased by only four bits, then there is no need for multiplexing in the page address. Of course this means that the address bus is expanded to only 20 bits resulting in a 1 -megabyte addressing capability. Next in this report, we will look at two 8 -bit systems utilizing the 'LS612 memory mapper.

## TMS9995-Based System

Figure 3 shows a TMS9995-based system using the 'LS612 to expand the address bus by four bits. The TMS9995 is an 8 -bit microprocessor with a 16 -bit address bus. This system employs the Programmable System Interface (TMS9901) to control the operation of the mapper. The control of the mapper is software programmable via
the I/O ports of the TMS9901. Since the mapper registers are viewed as part of the logical memory space, an address decode (AD0) of the 12 MSBs is gated with a CRU bit to select the mapper for a READ or WRITE operation. The specific mapper register is then selected by the four LSBs of the microprocessor address bus (A15-A12) via the RS0-RS3 inputs of the mapper. Table IV shows the state of the three control signals P0, P1 and AD0 and the corresponding mode of operation of the mapper. When placed in the I/O mode, the READ or WRITE operation is then controlled by memory signals from the microprocessor (i.e., $\overline{W E} /$ $\overline{\text { CRUCLK }}, \overline{\text { MEMEN, }}$, and $\overline{\mathrm{DB} \mathrm{IN}}$ ). On POWER-UP and RESET, the I/O ports of the ' 9901 are put into the input mode. The pull-up resistors R1 and R2 will ensure the mapper is placed in the pass mode during POWER-UP and RESET. The resultant address bus is 20 bits wide, and SA19 is the LSB.

## Z-80-Based System

Figure 4 shows another 8 -bit (Z-80-based) system using the TI memory mapper. In this case, the control of the mapper is implemented by two flip-flops feeding $\overline{\mathrm{MM}}$ and $\overline{\mathrm{CS}}$. These flip-flops are programmed by the Z-80 and are addressed by the data bus, D0-D1. Table V shows the necessary states of D0 and D1 to set the mapper in its proper mode of operation. Again during POWER-UP or RESET, the flip-flops are both cleared by RST, which is supplied by the system and which puts the mapper in the pass mode.

Table IV. TMS9900/'LS610 Control Signals

| MEMORY MAPPER | CONTROL SIGNALS |  |  |
| :---: | :---: | :---: | :---: |
| MODE OF OPERATION | P1 | PO | ADO |
| MAP | L | H | L |
| PASS | H | H | L |
| I/O | H | L | L |



Figure 3. TMS9995 with Memory Mapper


Figure 4. Z-80 with Memory Mapper

Table V. Z-80/LS'610 Control Signals

| CONTROL SIGNALS |  |  | MEMORY MAPPER |  |
| :---: | :---: | :---: | :---: | :---: |
| DO | D1 | (ADO) $\overline{\text { IORQ }}$ | MODE OF OPERATION |  |
| L | L | $\uparrow$ | PASS |  |
| H | L | $\uparrow$ | MAP |  |
| L | H | $\uparrow$ | $1 / O$ |  |

## TMS9900-Based System

One of the limitations of using an 8 -bit microprocessor with the memory mapper, without multiplexing the page address, is that the address bus can only be expanded four bits. In a 16 -bit system, one based on a 16 -bit microprocessor like the TMS9900, no extra circuitry is necessary to load the mapper with the full 12 -bit address. Figure 5
shows a TMS9900 with an SN54/74LS612 for memory mapping. The control of the mapper is implemented in the same fashion as the system using the TMS9995 mentioned previously in the report. The resultant addressing capability is eight megawords. These TI microprocessors have set aside address space for RESET, XOP and INTERRUPT VECTORS, which are addressed when the microprocessor performs a context switch. During a context switch, the microprocessor must be able to address these locations which are part of the logical address (i.e., locations that are capable of being addressed by the microprocessor independently). One method, besides placing the mapper into the pass mode, is to load the memory mapper register whose 4-bit address is $\mathrm{O}_{\mathrm{H}}$ with the address of the first page of physical memory. This, like the pass mode, will effectively make the memory mapper appear to be transparent.


Figure 5. TMS9900 with Memory Mapper

Another point worth noting is that in all three of the previously mentioned systems, the $\overline{\mathrm{ME}}$ input was always connected to ground. This caused the mapper address buffers to be enabled during all modes of operation of the mapper. This is only a problem during the I/O mode where, when loading the mapper register, other memory locations are also being written into. The method used to avoid destroying data already in memory was to put the mapper into the pass mode during the I/O operation. This was accomplished simply by pulling $\overline{\mathrm{MM}}$ input high, thus making the system address equal to the microprocessor address.

## Multimapper Systems

In a system employing a single memory mapper, the maximum active addressing capability is only 16 pages, if increased addressing capabilities are needed, the mapper must be reloaded. To avoid this procedure, another mapper may be added to the system. This will not increase the overall addressing capability of the system, but it will double the amount of active pages and will also afford twice the active addressing capability. Even though the control of two mappers is a little more detailed than the control of one, the same basic methods employed in the systems with one mapper can be used here.

## TIMING

The subject of how the mapper affects the critical timing parameters of the memory READ/WRITE cycles and what changes, if any, are needed to accommodate the mapper, have not been discussed in this report. First, looking at the I/O mode of operation where the mapper registers are either loaded or read from, it is seen that the mapper registers can be regarded as standard common I/O, static RAMs, with maximum access times (RS to valid MO, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ ) of 75 ns . Once the $\mathrm{I} / \mathrm{O}$ mode is set ( $\overline{\mathrm{CS}}=$ low), the only two signals necessary to read or write into the mapper are STROBE and $\mathrm{R} / \overline{\mathrm{W}}$. As shown in the previously mentioned system, these signals were supplied directly from the microprocessor with no wait states necessary to perform either function. This will be the case with most microprocessors.

In the MAP and PASS mode, the main concern is the maximum access time (MA to MO). This access time is specified at a maximum of 70 ns , which, depending on the timing of the microprocessor and the memory used, may or may not cause any problems. In the Z-80-based system, no wait states were introduced by the mapper because the memory control signals become active 95 ns after the microprocessor address bus became valid. This gives the address bus sufficient time to settle down.

In conclusion, it can be said that for most microprocessors and memory available at the time of this writing, the operation of the mapper does not adversely affect the memory cycle timing and is flexible enough to be used with almost all microprocessors.

## SUMMARY

The possible uses of the memory mapper and the various techniques that can be employed to control its operation are numerous and only some examples were shown in this report. Some of the other possible applications of the mapper include: (1) achieving system addressing capability greater than 16 megabytes is accomplished by reducing the number of mapper registers used by a factor of 2 , thus increasing the size of each page by the same factor of 2 without affecting the total amount of pages; (2) being used in systems employing DMA; (3) memory protection which can be accomplished by sacrificing one or two bits of the page address, and gating these bits with the memory control signals.

Another technique that may be employed in controlling the modes of operation of the mapper is to use PROMs.

# Bit-Slice Processor Applications 8-Bit Family 

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VLSI Systems Engineering<br>214/995-4720

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## Contents

Title PageSection 1Introduction
INTRODU̇CTION ..... 3-73
Section 22910 Microprogram Controller Emulation Using the 'AS890 Microsequencer
2910 MICROPROGRAM CONTROLLER EMULATION USING THE 'AS890 MICROSEQUENCER ..... 3-75
Emulator Configuration ..... 3-75
Microinstruction Conversion ..... 3-75
2910 Emulation Differences . ..... 3-75
Loop Counts ..... 3-75
Register Loading ..... 3-76
Stack Full Indication ..... 3-76
Data Path Widths ..... 3-76
Section 3
Minimum Cycle Time Delay Calculations for a 16-Bit System
MINIMUM CYCLE TIME DELAY CALCULATIONS FOR A 16-BIT SYSTEM ..... 3-93
16-Bit Computer System Design ..... 3-93
Benchmark I: Comparison of Am2903A/2910A with 'AS888-1/'AS890-1 ..... 3-94
Benchmark II: Comparison of Am2901C/2910A with 'AS888-1/'AS890-1 ..... 3-94
Summary of Results ..... 3-94
Section 4
32-Bit CPU Design with the 'AS888/'AS890
32-BIT CPU DESIGN WITH THE 'AS888/'AS890 ..... 3-101
Designing a 32 -Bit System ..... 3-101
Construction of the ALU ..... 3-101
Construction of the CCU. ..... 3-103
Tracing Through a 32 -Bit Computer ..... 3-104
Defining the Macrocode Instruction Format ..... 3-107
Tracing a Macrocode Instruction ..... 3-107
System Enhancements ..... 3-109
Timing and System Throughput ..... 3-111
Fetch Analysis ..... 3-111
Multiplication Analysis ..... 3-111
Section 5
An Adaptive Clock Generator to Increase 'AS888 System Speed Section 5
An Adaptive Clock Generator to Increase 'AS888 System Speed an adaptive clock generator to increase 'as 888 System speed ..... 3-113
Circuit Description ..... 3-113
PROM Program ..... 3-113
3-113
Section 6Floating-Point System Design Using the 'AS888/'AS890
FLOATING-POINT SYSTEM DESIGN USING THE 'AS888/'AS890 ..... 3-125
Step 1: Choose a Floating-Point Number System ..... 3-125
Step 2: Choose an Algorithm for $\operatorname{Sin}(x)$ ..... 3-126
Step 3: Make 'AS888 Register Assignments ..... 3-126
Step 4: Substitute Registers for Variables in the Algorithm ..... 3-127
Step 5: Decompose Steps in the Algorithm into Simple Operations ..... 3-127
Step 6: Translate into 'AS888/890 Instructions; Identify Subroutines ..... 3-128
Step 7: Expand Subroutines into 'AS888/890 Operations ..... 3-129
Floating-Point Multiplication ..... 3-129
Floating-Point Addition ..... 3-131
Step 8: Evaluate Trade-Offs and Block Diagram the Hardware ..... 3-133
Step 9: Define Microinstruction Fields During Detailed Hardware Design ..... 3-134
Step 10: Assemble the Microprogram ..... 3-134
List of Illustrations
Figure Title Page
2-1 2910 Emulator Block Diagram ..... 3-76
3-1 16-Bit Computer System ..... 3-93
3-2 Am2903-Based 16-Bit Computer System ..... 3-97
3-3 'AS888-Based 16-Bit Computer System ..... 3-98
3-4 ALU Path for Multiplication and Division in the Am2903A System ..... 3-98
3-5 ALU Path for Multiplication and Division in the 'AS888 System ..... 3-99
3-6 Am2901C-Based 16-Bit Computer System ..... 3-99
3-7 Modified Design of Am2901C-Based System ..... 3-100
4-1 System Design Approach ..... 3-101
4-2 CCU Block Diagram ..... 3-102
4-3 ALU Block Diagram ..... 3-102
4-4 Cascaded 'AS888 Packages ..... 3-103
5-1 Adaptive Clock Generator Circuit ..... 3-114
5-2 Adaptive Clock Generator Timing Diagram ..... 3-115
5-3 Propagation Delay Without Carry and Without Shift ..... 3-118
5-4 Propagation Delay Without Carry and With Shift ..... 3-119
5-5 Propagation Delay With Carry and Without Shift ..... 3-120
5-6 Propagation Delay With Carry and With Shift ..... 3-121
5-7 PROM Data ..... 3-124
6-1 Block Diagram of Floating-Point Processor ..... 3-134

# List of Programs 

Program Title Page
2-1 Logic Equations Used to Generate Emulator PAL 1 ..... 3-78
2-2 Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 1 ..... 3-79
2-3 Simulation Results for Emulator PAL 1 ..... 3-82
2-4 JEDEC Printout for Emulator PAL 1 ..... 3-83
2-5 Logic Equations Used to Generate Emulator PAL 2 ..... 3-84
2-6 Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 2 ..... 3-85
2-7 Simulation Results for Emulator PAL 2 ..... 3-88
2-8 JEDEC Printout for Emulator PAL 2. ..... 3-91
5-1 BASIC Program to Generate PROM Data ..... 3-122

## List of Tables

Table Title Page
2-1 Typical Switching Characteristics ..... 3-75
2-2 'AS890 Encodings for Am2910 Instructions ..... 3-77
2-3 Effect of Table 2-2 Encodings on 'AS890 Control Signals ..... $3-77$
3-1 Am2903A/Am2910A Timings for Addition ..... 3-94
3-2 'AS888-1/'AS890-1 Timings for Addition ..... 3-94
3-3 Am2903A/Am2910A Timings for Addition with Shift ..... 3-95
3-4 'AS888-1/'AS890-1 Timings for Addition with Shift ..... 3-95
3-5 Am2903A/Am2910A Timings for Multiplication ..... 3-95
3-6 Am2903A/Am2910A Timings for Division ..... 3-95
3-7 'AS888-1/'AS890-1 Timings for Multiplication and Division ..... 3-96
3-8 Am2901C/Am2910A Timings for Addition ..... 3-96
3-9 Am2901C/Am2910A Timings for Addition with Shift ..... 3-96
3-10 Summary of Results ..... 3-96
4-1 Microcode Definition ..... 3-105
4-2 Functional Listing of Fetch ..... 3-106
4-3 Assembler Listing of Fetch ..... 3-106
4-4 Microcode Listing of Fetch ..... 3-107
4-5 Possible Instruction Formats ..... 3-107
4-6 Functional Listing of Multiply ..... 3-107
4-7 Assembler Code of Multiply ..... 3-108
4-8 Microcode Listing of Multiply ..... 3-109
4-9 Critical Delay Path Analysis ..... 3-110
4-10 Fetch Timing Comparison ..... 3-110
4-11 Multiply Timing Comparison ..... 3-110
5-1 'AS888-1 Timing Characteristics ..... 3-115
5-2 Shift and Carry as a Function of I7-I0 ..... 3-116
5-7 PROM Data ..... 3-123
6-1 Floating Point Sin(x) Microprogram ..... 3-135
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## Section 1

## Introduction

Bit-slice technology has gained widespread acceptance among CPU designers over the past several years as a means of increasing system speed and reducing the discrete logic needed for CPU construction. TI's recent entries on the market, the SN74AS888 8-bit processor slice and its companion microsequencer, the SN74AS890, increase processing throughput per unit area to an extent never before realized in bit-slice systems, making them well suited to the construction of high-speed systems with flexible instruction sets.

This is the first in a series of application books addressed to users of TI's bit-slice products. It discusses ways to take advantage of the 'AS888/'AS890's increased speed in the areas of CPU design and floating point processing, compares their performance with similar products, and presents a means of achieving optimum speed by adding an adaptive clock circuit to an 'AS888/'AS890 system. Also included is a 2910 emulator, which allows users to take advantage of the 'AS890's increased speed and greatly expanded addressing range, while still retaining existing 2910 software. Brief abstracts of the papers in this volume are given below.

Section 2, "2910 Microprogram Controller Emulation using the 'AS890 Microsequencer,'' converts the 16 instructions of the 2910 into 'AS890 commands, using programmable array logic (PALs) for fast emulation. By using the emulator, accessible microcode store can be quadrupled from 4,096 to 16,384 memory locations, and advantage can be taken of the 'AS890's deeper stack.

Section 3, "Minimum Cycle Time Delay Calculations for a 16-Bit System," examines some timings for systems using TI's 'AS888-1/'AS890-1, AMD's Am2901C/2910A,
and AMD's Am2903A/2910A. Four cases are considered: addition, addition followed by a shift of the result, unsigned integer multiplication and unsigned integer division.

Section 4, " 32 -Bit CPU Design with the 'AS888/'AS890,'' takes a look at constructing a central processing unit by cascading four 'AS888s to form a 32 -bit ALU and the 'AS890 sequencer to address a control store containing the system microcode. Microcode and assembly code are given for an instruction fetch routine and for unsigned multiplications.

Section 5, "An Adaptive Clock Generator to Increase 'AS888 System Speed,'" uses an adaptive circuit to generate clock pulses for an 'AS888-based system. The clock cycle length is optimally matched to the propagation delay of the 'AS888 for each individual instruction, further increasing the speed of the system. The circuit is linked to the 'AS888 with a PROM that decodes 888 instructions into cycle lengths. A BASIC program calculates instruction lengths and generates a file that can be transmitted to a Data I/O PROM programmer.

Section 6, "Floating Point Design using the 'AS888/'AS890,' provides a model for floating point system design, illustrating the step by step development of a utility to compute $\sin (\mathrm{x})$. By developing a $\sin (\mathrm{x})$ algorithm, a microprogram is generated and hardware requirements are identified in an interactive manner.

The application notes in this volume were prepared by the following members of VLSI Systems Engineering:

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## Section 2

## 2910 Microprogram Controller Emulation using the 'AS890 Microsequencer

The 'AS890 microsequencer, with its powerful instruction set, can be microprogrammed to emulate the popular 2910 microprogram controller. By converting the 16 instructions of the 2910 into the appropriate 'AS890 commands, 2910 users can both quadruple accessible microcode store from 4,096 to 16,384 memory locations and take advantage of the 'AS890's deeper stack, while retaining existing microprograms and preserving prior investments in software without loss of system performance. Programmable Read Only Memory (PROM) can be used to implement the system, or TI's Programmable Array Logic PAL ${ }^{\circledR}$ can be selected for faster emulation.

## EMULATOR CONFIGURATION

The DRB inputs of the 'AS890 are used as the 2910 emulator's D (direct data) inputs. JSRP and JRP (2910 instructions 5 and 7) conditionally select the counter/register, requiring the counter/register contents to be available through the Y-output multiplexer. The 'AS890 does not directly support this function, but it can be accomplished by enabling either the DRA or DRB ports as an output and selecting the appropriate path through the Y-multiplexer.

JSRP and JRP also require that direct data input and existing register/counter contents be available at the Y multiplexer concurrently. The emulator uses direct data port DRA and register/counter A for this purpose. Two '74AS244 buffers are used to isolate DRA from DRB so that register/counter A can be loaded from the Direct Data input and DRA can be used to send the register/counter's contents to the Y-multiplexer.

Figure 2-1 shows the configuration of the 2910 emulator. To provide fast propagation delays, two TIBPAL16L8-15s, with a maximum propagation delay of 15 ns , are used for the control PALs. Because the TIBPAL16L8-15 will only accommodate seven product
terms and eight were required for the condition code input to the 'AS890, it is driven by two outputs of the control PAL. These outputs are selectively enabled using the $\overline{\text { CCEN }}$ input (see Programs 2-1 and 2-5 for detailed PAL equations).

Typical switching delays for the 2910 emulator are summarized in Table 2-1.

## MICROINSTRUCTION CONVERSION

Table 2-2 lists Y-multiplexer, stack and register control encodings that can be used to convert the 2910 instruction set into 'AS890 microinstructions. The effect of these encodings on the Y-multiplexer, stack and register controls is shown in Table 2-3. Data from Table 2-2 was used as input to a universal program logic compiler to produce the emulator's two control PALs. Files generated for each PAL by the compiler include:

1. a logic description file
2. a listing of expanded product terms and fuse map
3. simulation results
4. a JEDEC file.

These are reproduced at the end of this application note. The CUPLTM software used to develop the PALs is available from Texas Instruments or from Assisted Technology, Inc., San Jose, CA.

## 2910 EMULATION DIFFERENCES

The architecture of the 'AS890 does not lend itself to a complete emulation of the 2910 controller. Differences are noted below.

## Loop Counts

The 2910 register/counter is tested for a zero value prior to decrementing and branching on conditional loops. The counter is usually loaded with a value that is one less

Table 2-1. Typical Switching Characteristics

| SET-UP AND HOLD TIMES |  |  | COMBINATIONAL DELAYS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT | Ts | Th | FROM | то |  |  |
|  |  |  |  | Y | $\begin{aligned} & \text { PL,MAP } \\ & \text { VECT } \end{aligned}$ | FULL |
| $\mathrm{D} \rightarrow \mathrm{R}$ ( Inst. $=5,7$ ) | 15 | 0 | D0-D13 (Inst. $=5,7$ ) | 15 |  |  |
| $\mathrm{D} \rightarrow \mathrm{R}$ (Inst. $=5,7$ ) | 8 | 0 | DO-D13 (Inst. $\neq 5,7)$ | 8 |  |  |
| $\mathrm{D} \rightarrow \mathrm{Pc}$ (Inst. $=5,7$ ) | 28 | 0 | $10-13$ (Inst. $=5,7,9$ ) | 27 | 10 |  |
| $\mathrm{D} \rightarrow \mathrm{Pc}$ (inst. $\neq 5,7)$ | 20 | 0 | 10-13 (Inst. $=5,7,9$ ) | 22 | 10 |  |
| 13-10 | 36 | 0 | $\overline{\text { CC }}$ | 22 |  |  |
| CC | 36 | 0 | CCEN | 22 |  |  |
| $\overline{\text { CCEN }}$ | 36 | 0 | CP | 18 |  | 25 |
| Cl | 12 | 0 | $\mathrm{CP}(1=8,9, \mathrm{~F}$ \& CNTR $=2)$ | 24 |  | 25 |
| RLD | 36 | 0 | OE | 8 |  |  |



Figure 2-1. 2910 Emulator Block Diagram
than the desired loop count. The 'AS890 tests for a one prior to decrementing. Therefore, the 2910 emulator requires that the actual loop count, rather than loop count minus one, be loaded into the register/counter.

Three of the 2910 instructions (RFCT, RPCT, and TWB) execute once and terminate the counter decrement when a zero is found in the register/counter. The emulator requires a one in the register/counter to execute these instructions and terminate the counter decrement. Loading a zero into the register/counter before decrementing will cause the emulator to loop 16,384 times.

## Register Loading

Using the 2910's register load (RLD) input during a JSRP or JRP instruction allows external data to be input to the register/counter while the current value in the register/counter is output on the Y-bus. This is not the case with the 'AS890, where an external value placed on DRA for input to the register/counter will also be sent to the $Y$ -
multiplexer outputs. A register load using the emulator must therefore be implemented independently of the JSRP or JRP instructions.

## Stack Full Indication

The 'AS890 stack is nine levels deep, compared to the 2910's five-level stack. The 2910 signals that all five levels of the stack are used by setting FULL low. The emulator's FULL signal is set to zero when its eighth stack location is used, indicating that only one location remains available. A low value will also appear at the FULL output when a stack POP is to be executed and the stack is empty.

## Data Path Widths

Because the 'AS890 supports 14-bit data paths instead of the 2910's 12 -bit paths, the number of address locations that can be accessed by the emulator can be expanded from 4,096 to 16,634 locations.

PAL is a registered trademark of Monolithic Memories Inc.

Table 2-2. 'AS890 Encodings for Am2910 Instructions

| 13-10 | MNEMONIC | NAME | $\overline{\mathrm{CCEN}}=$ LOW and $\overline{\mathrm{CC}}=\mathrm{HIGH}$ |  |  |  | $\overline{\text { CCEN }}=\mathrm{HIGH}$ or $\overline{\mathrm{CC}}=$ LOW |  |  |  | ENABLE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CCOUT | RC | S | MUX | CCOUT | RC | S | MUX |  |
| 0 | JZ | JUMP ZERO | H | LLL | LLL | HHH | H | LLL | LLL | HHH | PL |
| 1 | CJS | COND JSB PL | H | LLL | HLH | HHH | L | LLL | HLH | HHH | PL |
| 2 | JMAP | JUMP MAP | H | LLL | HHH | HLL | H | LLL | HHH | HLL | MAP |
| 3 | CJP | COND JUMP PL | H | LLL | HHH | HHH | L | LLL | HHH | HHH | PL |
| 4 | PUSH | PUSH/COND LD CNTR | H | LLLL | HHL | HHH | H | LHL | HHL | HHH | PL |
| 5 | JSRP | COND JSB R/PL | L | LLI | HHL | HLL | H | LLL | HHL | HLL | PL |
| 6 | CJV | COND JUMP VECTOR | H | LLL | HHH | HHH | L | LLLL | HHH | HHH | VECT |
| 7 | JRP | COND JUMP R/PL | L | LLL | HHH | HLL | H | LLL | HHH | HLL | PL |
| 8 | RFCT | RPT LOOP, CNTR $=0$ | L | LLL | LHL | LLH | L | LLLH | LHL | LLH | PL |
| 9 | RPCT | RPT LOOP, CNTR $\neq 0$ | L | LLH | HHH | HLL | L | LLH | HHH | HLL | PL |
| A | CRTN | COND RTN | H | LLL | LHH | LHH | L | LLL | LHH | LHH | PL |
| B | CJPP | COND JUMP PL \& POP | H | LLL | LHH | HHH | L | LLL | LHH | HHH | PL |
| C | LDCT | LD CNTR 7 CONTINUE | H | LHL | HHH | HHH | H | LHL | HHH | HHH | PL |
| D | LOOP | TEST END LOOP | L | LLL | LHL | LHH | H | LIL | LHL | LHH | PL |
| E | CONT | CONTINUE | H | LLL | HHH | HHH | H | LLL | HHH | HHH | PL |
| F | TWB | THREE-WAY BRANCH | L | LLLH | LHL | LHH | H | LLL | LHL | LHH | PL |

Table 2-3. Effect of Table 2-2 Encodings on 'AS890 Control Signals

| 13-10 | MNEMONIC | NAME | ZERO | $\overline{\text { CCEN }}=$ LOW and $\overline{\mathrm{CC}}=\mathrm{HIGH}$ |  |  |  | $\overline{\text { CCEN }}=\mathrm{HIGH}$ or $\overline{\mathrm{CC}}=$ LOW |  |  |  | ENABLE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CCOUT | RC | S | MUX | ccout | RC | S | MUX |  |
| 0 | JZ | JUMP ZERO |  | H | Hold | Reset | 0 | H | Hold | Reset | 0 | PL |
| 1 | CJS | COND JSB PL |  | H | Hold | Hold | MPC | L | Hold | Push | DRB | PL |
| 2 | JMAP | JUMP MAP |  | H | Hold | Hold | DRB | H | Hold | Hold | DRB | MAP |
| 3 | CJP | COND JUMP PL |  | H | Hold | Hold | MPC | L | Hold | Hold | DRB | PL |
| 4 | PUSH | PUSH/COND LD CNTR |  | H | Hold | Push | MPC | H | LoadA | Push | MPC | PL |
| 5 | JSRP | COND JSB R/PL |  | L | Hold | Push | DRA | H | Hold | Push | DRB | PL |
| 6 | CJV | COND JUMP VECTOR |  | H | Hold | Hold | MPC | L | Hold | Hold | DRB | VECT |
| 7 | JRP | COND JUMP R/PL |  | L | Hold | Hold | DRA | H | Hold | Hold | DRB | PL |
| 8 | RFCT | RPT LOOP, CNTR $=0$ | L | L | DecA | Hold | STK | L | DecA | Hold | STK | PL |
|  |  |  | H | L | Deca | Pop | MPC | L | DecA | Pop | MPC | PL |
| 9 | RPCT | RPT LOOP, CNTR $=0$ | L | L | Deca | Hold | DRA | L | DecA | Hold | DRA | PL |
|  |  |  | H | L | DecA | Hold | MPC | L | DecA | Hold | MPC | PL |
| A | CRTN | COND RTN |  | H | Hold | Hold | MPC | L | Hold | Pop | STK | PL |
| B | CJPP | COND JUMP PL \& POP |  | H | Hold | Hold | MPC | L | Hold | Pop | DRB | PL |
| C | LDCT | LD CNTR 7 CONTINUE |  | H | LoadA | Hold | MPC | H | LoadA | Hold | MPC | PL |
| D | LOOP | TEST END LOOP |  | L | Hold | Hold | STK | H | Hold | Pop | MPC | PL |
| E | CONT | CONTINUE |  | H | Hold | Hold | MPC | H | Hold | Hold | MPC | PL |
| F | TWB | THREE-WAY BRANCH | L | L | DecA | Hold | STK | H | DecA | Pop | MPC | PL |
|  |  |  | H | L | DecA | Pop | DRB | H | Hold | Pop | MPC | PL |

Program 2-1. Logic Equations Used to Generate Emulator PAL 1

```
CUPL Version 2.02a Copyright (c) 1983.84.85 Assisted Technology, Inc. -- LISTING
Source File: B:2910EM Device: pl6l8
                PARTNO 2910EM:
                    NAME '74AS890/2910 EMULATOR PAL 1 ;
                    DATE 04/04/85;
                    REV 01 :
                    DESIGNER RICHARD D. NAWROCKI ;
                    COMPANY TEXAS INSTRUMENTS ;
                    ASSEMBLY 00001 ;
                            LOCATION U100;
                    /***********************************************************************/
                    /* THIS dEVICE GENERATES CONTROL SIGNALS FOR THE '74AS890 */
            EMULATION OF THE 2910 MICROPROGRAM CONTROLLER. */
            * */
```




```
/** Inputs **/
```



```
/** Outputs **/
PIN 19 = RAOE ; 湆 74AS890 DRA OUTPUT ENABLE */
PIN [18..16]=[MUXO..2]; 庴 % 74AS8890 MUX Y CONTROL 
PIN 12** = EN_244 ; 7* 74AS244 OUTPUT ENABLESS */
/** Declarations and Intermediate Variable Definitions **/
    FIELD INSTRUCTION = [13..0]
    FIELD STACK 
    /** Logic Equations **/
    IRAOE = INSTRUCTION:[5,7] & RLD ;
    !EN_244 = INSTRUCTION:[0..4,6,8..F] # (INSTRUCTION:[5,7] & !RLD) ;
    STACK = INSTRUCTION:1 & 'H'5'
                            # INSTRUCTION:[2,3,6,7,9,C,E] & 'H'7
                                # INSTRUCTION:[4,5] & 'H'6
                                # INSTRUCTION:[8,D,F] & 'H'2
        # INSTRUCTION:[A,B] & 'H'3 ;
    Y_MUX = INSTRUCTION:[0,1,3,4,6,B,C,E] & 'H'7
        # INSTRUCTION:[2,5,7,9] & 'H'4
        # INSTRUCTION:8 & 'H'I
        # INSTRUCTION:[A.D.F] & 'H'3 ;
        JEDEC Fuse Checksum (7103)
    JEDEC Transmit Checksum (259E)
```

Program 2-2. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 1

CUPL Device Partno Name Revision Date
Designer COMPANY ASSEMBLY LOCATION
2.02A

P16L8 DLIB-C-18-5
2910 EM
294AS890/2910 EMULATOR PAL 1
01
04/04/85
RICHARD D. NAWROCKI TEXAS INSTRUMENTS 00001 U100

## Expanded Product Terms


RAOE ${ }_{i}$ OE $\rightarrow$
SO.OE ${ }_{1} \rightarrow$
Sl.OE ->
S2.OE $\underset{1}{ } \rightarrow$
MUXI ${ }^{->}$
MUXI ${ }^{->}$
MUXI ${ }^{->}$

| \# 10 | $\&$ | $I 2$ | $\&$ | $!I 3$ |
| :--- | :--- | :--- | :--- | :--- |
| $\#$ | $!11$ | $\&$ | $!I 2$ | $\&$ |
| $\#$ | $I 3$ | $\&$ | $I 1$ | $\&$ |


| \# 10 | $\&$ | $I 2$ | $\&$ | $!I 3$ |
| :--- | :--- | :--- | :--- | :--- |
| $\#$ | $!11$ | $\&$ | $!I 2$ | $\&$ |
| $\#$ | $I 3$ | $\&$ | $I 1$ | $\&$ |


| \# 10 | $\&$ | $I 2$ | $\&$ | $!I 3$ |
| :--- | :--- | :--- | :--- | :--- |
| $\#$ | $!11$ | $\&$ | $!I 2$ | $\&$ |
| $\#$ | $I 3$ | $\&$ | $I 1$ | $\&$ |

    \& 113
    \& 113
    \& 113
    MUX2 $\rightarrow$
MUX2 $\rightarrow$
MUX2 $\rightarrow$
\# $!_{10}^{10} \& \stackrel{!12}{12} \& \frac{\& 13}{13}$
\# $!_{10}^{10} \& \stackrel{!12}{12} \& \frac{\& 13}{13}$
\# $!_{10}^{10} \& \stackrel{!12}{12} \& \frac{\& 13}{13}$
RAOE $100^{->} \& 12 \& 1 I 3 \& R L D$
RAOE $100^{->} \& 12 \& 1 I 3 \& R L D$
RAOE $100^{->} \& 12 \& 1 I 3 \& R L D$



$\begin{array}{llllll}\text { Sl } & \text { II } & \& & I I 2 & \&!I 3\end{array}$
$\begin{array}{llllll}\text { Sl } & \text { II } & \& & I I 2 & \&!I 3\end{array}$
$\begin{array}{llllll}\text { Sl } & \text { II } & \& & I I 2 & \&!I 3\end{array}$



STACK
S2 , S1 , S0
STACK
S2 , S1 , S0
STACK
S2 , S1 , S0
$\underset{\text { MUX2 }}{\text { Y_MUX }} \rightarrow$ MUX1 , MUXO
$\underset{\text { MUX2 }}{\text { Y_MUX }} \rightarrow$ MUX1 , MUXO
$\underset{\text { MUX2 }}{\text { Y_MUX }} \rightarrow$ MUX1 , MUXO
$\underset{1}{E N-244 . O E ~} \rightarrow$
$\underset{1}{E N-244 . O E ~} \rightarrow$
$\underset{1}{E N-244 . O E ~} \rightarrow$
MUXO_OE ${ }^{->}$
MUXO_OE ${ }^{->}$
MUXO_OE ${ }^{->}$
MUXI ${ }^{1}$ oe $\rightarrow$
MUXI ${ }^{1}$ oe $\rightarrow$
MUXI ${ }^{1}$ oe $\rightarrow$
MUX2 $i^{->}$
MUX2 $i^{->}$
MUX2 $i^{->}$

Program 2-2. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 1 (Continued)

Symbol Table


## Fuse Plot



```
Pin #17
    0512
    0544 --x-x----x---------------------------
    0576 -x---x--x---------------------------
    0608 x--x-x---x-----------------------------
```



```
    0672 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    0704 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    0736 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    Pin #l6
    0768 ----------------------------------
    0800 ---x-x--x----------------------------
    0832 --x-x---x--------------------------
```




```
    0928 x x x x x x x x x x x x x x x x x x x x x x x x x x x x x x x x
    0960 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    0992 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
```

Program 2-2. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 1 (Continued)

```
Pin #15
    1024
    1056 -xx-x
    1088 -x-x-\cdots----x-------------------------
    1120--x-x---x--------------------------
    1152 -x-x-x
```



```
    1216 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
```



```
PIN #14
    1 2 8 0
    1312-x---x---x--------------------------
    1344 xxxxxxxxxxxxxxxyxyxxyxxyxxyxyxyxyx
    1376 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxyxxxx
    1408 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
```



```
    1472 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    1504 xXxXxXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
```

Pin \#13
1536 --------------------------------------

1600 -x-x-x

1664 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
1696 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
1728 xxxxxxxxxxyxxxXXXXXXXXXXXXXXXXXXX
1760 xXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
PIN \#12
1792
1824
1856
1888
1920

1984 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
2016 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX

LEGEND $x$ : FUSE NOT bLOWN - : FUSE BLOWN

Program 2-3. Simulation Results for Emulator PAL 1


Program 2-4. JEDEC Printout for Emulator PAL 1

*V0030 01110XXXXNXLHHHHHHHN *YOO 12 1111 $0 \times X X X N X L H L L H H H N$ *0757
*VOO26 $00110 \times X X X N X L H H H H H H H N$ *V0027 $10111 \times X X X X X L L H L L H H H N$
$* V 002810110 X X X X N X L L H L L H H H N$ *V0027 10111XXXXXXLLHLLHHHN *V0029 01111XXXXNXLHHHHHHHN

* 1000
* L0032
* L0256
- 0288
* 0352 100110110111111111111111111111111
* 20512 11111111111111111111111111111111
* 0544 110101111011111111111111111111111
*L0576 10111011011111111111111111111111

*L0800 11101011011111111111111111111111
* 083211010111011111111111111111111111
*L1024 111111111111111111111111111111111
*L1056 1001011111111111111111111111111
*L1088 1010111110111111111111111111111
*L1120 110101110111111111111111111111111
*L1152 10101011111111111111111111111111

* L1536 111111111111111111111111111111
*L1568 0111101101111111111111111111111
*L1600 1010101111111111111111111111111

*L1824 111111101111111111111111111111
*L1856 11111011101111111111111111111111
*L1888 11100111101111111111111111111111
*L1920 11010111101110111111111111111111
* 7103
*V0001 00001XXXXNXLLLLLHHHHN
VO002 $00000 \times X X X N X L L L L H A H H N$
*V0003 10001 XXXXNXLHLHHHHHN
*V0004 $10000 \times X X X N X L H L H H H H H N$
*V0005 $01001 \times X \times$ XNXLHHHHLLHN
*V0007 $11001 \times X X X N X L H H H H H H H N$
*V0008 $11000 \times X X X$ XNLHHHHHHHN
*VO009 $00101 \times x \times$ XNXLAHLHAHHN
*VOO11 $10101 \times X \times$ XNXHHHLHLLLN
*V0012 $10100 \times X X X$ NXLHHLHLLHN
*V0013 $01101 \times X \times X$ XXLHHHHHHHN
*V0014 01100XXXXNXLHHHHHHHN
*ソ0015 1110 XXXXXNX HHHHLL
*V0017 $00011 \times \times \times \times N \times L L H L L L H H N$
*V0018 $00010 \times X X X N X L L H L L L H H N$
*V0019 $10011 \times X X X N X L H H H H L L H N$
*V0020 $10010 \times X X X N X L H H H H L L H N ~$
*V0021 01011XXXXNXLLLHHLHHHN
* 0022 01010 $\times \times \times \times$ NXLLHHLHHN *OO23 11O1 *V0024 $11010 \times X X X N X L L H H H H H H N$ *V0025 00111 XXXXNXLHHHHHHHN

Program 2-5. Logic Equations Used to Generate Emulator PAL 2

```
CUPL Version 2.02a Copyright (c) 1983,84,85 Assisted Technology, Inc. -- LISTING
Source File: B:2910EMl
                            Device: pl6l8
```



Program 2-6. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 2

CUPL Device NAME Revision Date Designer Company ASSEMBLY Location
2.02A
2.02A
P16L8 DLIB-C-18-5
P16L8 DLIB-C-18-5
2910EM1
2910EM1
74AS890/2910 EMULATOR PAL 2
74AS890/2910 EMULATOR PAL 2
0 1
0 1
04/04/85
04/04/85
RICHARD D. NAWROCKI
RICHARD D. NAWROCKI
TEXAS INSTRUMENTS
TEXAS INSTRUMENTS
00001
00001
Ul01
Ul01

## Expanded Product Terms


CC_OUT1.OE $\rightarrow$
COUNTER ->
RC2 , RCl , RC0

MAP $\overrightarrow{10}$
\& I1 \& ! I2
\& 113
PL $\overrightarrow{\mathrm{I} 3}$
\#! I1 \& ! I3
\# 10 \& 11 \& ! 13
$\begin{array}{rlll}\text { RCO } & -> & & \\ & !10 & \& & I 1 \\ \# & \text { II } & 8 & I 2 \\ \# & \text { II } & \& & I \\ \# & \text { I2 } \\ \# & \text { In } & & \\ \# & \text { RLD } & \end{array}$
$\mathrm{RCl} \overrightarrow{10}$ \& RLD
\# ! I2 \& R RLD
\# Il \& RLD
\# !CCEN \& CC \& ! I 3 \& RLD
$\mathrm{RC2}_{1}^{->}$
VECT ->
110 \& I1 \& I2 \& !13
$\underset{1}{\text { MAP. OE }} \rightarrow$
PL.OE $->$

Program 2-6. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 2 (Continued)
Symbol Table


Fuse Plot



Program 2-6. Expanded Product Terms, Symbol Table and Fuse Plot for Emulator PAL 2 (Continued)

```
Pin #13
    1536
    1568 x--x-x---x---------------------
    1600 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    1632 xxxxxxxxxxxxxxxxxXXXXXXXXXXXXXXXXX
    1664 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    1696 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
    1728 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    1760 xxXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
PIN #12
1792
    1824
```



```
    1888 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    1920 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    1952 XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    1984 x XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
    2016 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx
```

```
LEGEND }x\mathrm{ : FUSE NOT BLOWN
        - : FUSE BlOWN
```

Program 2-7. Simulation Results for Emulator PAL 2


Simulation Results
słodəy uolŋeכ!!dd $\forall$ W


INSTRUCTION 0


Program 2-7. Simulation Results for Emulator PAL 2 (Continued)


Program 2-7. Simulation Results for Emulator PAL 2 (Continued)



Program 2-8. JEDEC Printout for Emulator PAL 2 (Continued)
*V0028 $1100000 \times X N X H H L L H L L Z N$
*V0029 1100111 XXNXHHLLLLZLN
*V0030 $1100011 \times X N X H H L L H L Z L N$
*V0031 $1100101 \times X N X H H L L L L Z L N$
*V0032 1100001 XXNXHHLLHLZLN
*V0033 $0010110 \times X N X H H L L L L H Z N ~$
*V0034 $0010010 \times X$ XXHHLLHLHZN
*V0035 $0010100 \times$ XNXHHLLHLHZN
*V0036 $0010000 \times$ XNXHHLLHLHZN
*V0037 0010111XXNXHHLLHLZHN
*V0038 $0010011 \times X N X H H L L H L Z H N$
*V0039 0010101 XXNXHHLLHLZHN
*V0040 0010001XXNXHHLLHLZHN
*V0041 1010110XXNXHHLLLLLZN
*V0042 $1010010 \times X N X H H L L H L L Z N ~$
*V0043 $1010100 \times \times N X H H L L L L H Z N$
*V0044 $1010000 \times \times N \times H H L L H L H Z N$
*V0045 $1010111 \times X N X H H L L L L Z H N$
*V0046 $1010011 \times X N X H H L L H L Z H N$
*V0047 1010101XXNXHHLLLLZHN
*V0048 $1010001 \times X N X H H L L H L Z H N$
*V0049 $0110110 \times X N X L H H L L L H Z N$
*V0050 0110010XXNXLHHLHLHZN
*V0051 0110100XXNXLHHLLLLZN
*V0052 0110000XXNXLHHLHLLZN
*V0053 0110111XXNXLHHLLLZLN
*V0054 0110011XXNXLHHLHLZLN
*V0055 0110101XXNXLHHLLLZLN
*V0056 0110001XXNXLHHLHLZLN
*V0057 $1110110 \times X N X H H L L L L L Z N ~$
*V0058 1110010XXNXHHLLHLLZN
*V0059 $1110100 \times$ XNXHHLLLLHZN
*V0060 1110000XXNXHHLLHLHZN
*V0061 1110111 XXNXHHLLLLZHN
*V0062 1110011XXNXHHLLHLZHN
*V0063 1110101XXNXHHLLLLZHN
*V0064 1110001 XXNXHHLLHLZHN
*V0065 $0001110 \times X N X H H L H L L L Z N ~$
*V0066 $0001010 \times X N X H H L L H L L Z N ~$
*V0067 $0001100 \times$ XNXHHLHLLLZN
*V0068 0001000XXNXHHLLHLLZN
*V0069 0001111XXNXHHLHLLZLN
*V0070 $0001011 \times X N X H H L L H L Z L N ~$
*V0071 $0001101 \times X N X H H L H L L Z L N$
*V0072 0001001 XXNXHHLLHLZLN
*V0073 $1001110 \times X N X H H L H L L L Z N$
*V0074 $1001010 \times \times N X H H L L H L L Z N$
*V0075 $1001100 \times$ XNXHHLHLLLZN
*V0076 $1001000 \times$ XNXHHLLHLLZN
*V0077 $1001111 \times X N X H H L H L L Z L N$
*V0078 $1001011 \times X N X H H L L H L Z L N$
*V0079 $1001101 \times X N X H H L H L L Z L N$
*V0080 1001001 XXNXHHLLHLZLN
*V0081 $0101110 \times \times N X H H L L L L H Z N$
*V0082 $0101010 \times X N X H H L L H L H Z N$
*V0083 0101100XXNXHHLLLLLZN
*V0084 0101000XXNXHHLLHLLZN
*V0085 $0101111 \times \times N \times H H L L L L Z L N$
*V0086 $0101011 \times X N X H H L L H L Z L N ~$
*V0087 0101101XXNXHHLLLLZLN
*V0088 0101001 XXNXHHLLHLZLN
*V0089 $1101110 \times X N X H H L L L L H Z N ~$
*V0090 1101010XXNXHHLLHLHZN
*V0091 1101100XXNXHHLLLLLZN
*V0092 $1101000 \times$ XNXHHLLHLLZN
*V0093 $1101111 \times X N X H H L L L L Z L N$
*V0094 $1101011 \times X N X H H L L H L Z L N$
*V0095 1101101XXNXHHLLLLZLN
*V0096 $1101001 \times X N X H H L L H L Z L N$
*V0097 $0011110 \times X N X H H L L H L H Z N$
*V0098 $0011010 \times X N X H H L L H L H Z N ~$
*V0099 $0011100 \times$ XNXHHLLHLHZN
*V0100 $0011000 \times X$ XXHHLLHLHZN
*V0101 $0011111 \times X N X H H L L H L Z H N$
*VO102 0011011XXNXHHLLHLZHN
*V0103 $0011101 \times \times N X H H L L H L Z H N$
*V0104 0011001XXNXHHLLHLZHN
*V0105 1011110XXNXHHLLLLLZN
*V0106 $1011010 \times \times N \times H H L L H L L Z N ~$
*V0107 $1011100 \times$ XNXHHLLLLHZN
*VO108 $1011000 \times \times N X H H L L H L H Z N$
*V0109 $1011111 \times X N X H H L L L L Z H N$
*V0110 $1011011 \times X N X H H L L H L Z H N$
*V0111 $1011101 \times X N X H H L L L L Z H N$
*V0112 1011001 XXNXHHLLHLZHN
*V0113 0111110XXNXHHLLLLLHZN
*VO114 0111010XXNXHHLLLHLHZN
*VO115 $0111100 \times \times N \times H H L L L L H Z N ~$
*VO116 O111000XXNXHHLLLHLHZN
*V0117 0111111XXNXHHLLLLZHN
*V0118 0111011XXNXHHLLLLZZHN
*V0119 0111101XXNXHHLLLLZHN
*V0120 0111001XXNXHHLLHLZHN
*V0121 1111110XXNXHHLHLLLZN
*V0122 $1111010 \times \times N \times H H L L H L L Z N$
*V0123 1111100XXNXHHLHLLHZN
*V0124 1111000XXNXHHLLHLHZN
*V0125 1111111XXNXHHLHLLZHN
*VO126 1111011XXNXHHLLHLZHN
*V0127 1111101XXNXHHLHLLZHN
*V0128 1111001XXNXHHLLHLZHN
*A128

## Section 3

## Minimum Cycle Time Delay Calculations for a 16-Bit System

This article examines some timings for a typical 16-bit computer system using a bit-slice processor and microsequencer. Comparative data for systems using TI's 'AS888-1/'AS890-1, AMD's Am2901C/2910A, and AMD's Am2903A/2910A are presented. Timing calculations are based on data from TI SN74AS888/890 family data sheets and from the AMD2900 Family Bipolar Microprocessor Logic and Interface 1985 Data Book.

## 16-BIT COMPUTER SYSTEM DESIGN

Figure 3-1 shows a basic design for a 16 -bit computer system. The computer control unit (CCU), shown on the left side of the dotted line, executes microcode from the microprogram memory (also known as the control store). A one-level pipeline design is used to speed data processing,
allowing the address and contents of the next instruction to be fetched while the current instruction is being executed. The arithmetic logic unit, consisting of the bit-slice processor chips and any other logic needed to process the data, is shown on the right side of the figure.

This section compares the time required to perform the following functions, using TI's SN74AS888-1/890-1, AMD's Am2901C/2910A and AMD's Am2903A/2910A bitslice products:

1. addition
2. addition with a shift
3. unsigned integer multiplication
4. unsigned integer division.

Cases 3 and 4 are not included in the Am2901C/Am2910A discussion, since the Am2901C does not incorporate internal multiplication or division algorithms.


Figure 3-1. 16-Bit Computer System

## Benchmark I: Comparison of Am2903A/2910A with 'AS888-1/'AS890-1

Design of a 16-bit system that is Am2903A-based is presented in Figure 3-2. The same system implemented with the 'AS888-1 and 'AS890-1 is shown in Figure 3-3. These systems are used to calculate timings for the four cases discussed in this section. Timings for the control path are given in the first test case and remain constant for the remaining three cases.

Tables 3-1 and 3-2 contain timing results for addition using the two chip sets; Tables 3-3 and 3-4 analyze the add with shift combination. It can be seen that the TI system runs $36 \%$ faster for addition and $32 \%$ faster for addition followed by a shift of the result.

Figures 3-4 and 3-5 show the ALU data paths used for multiplication and division by the two systems. Tables 3-5, 3-6 and 3-7 display timings for the critical path calculations for these operations. Increases in speed using the TI parts are even more significant here, where multiplication is faster by $42 \%$ and division faster by $37 \%$.

## Benchmark II: Comparison of Am2901C/2910A with 'AS888-1/'AS890-1

The same 16-bit system can be constructed with Am2901C slices. Since the Am2901C has a smaller instruction set than the Am2903A or the 'AS888-1, multiplication and division must be emulated using external add with shift hardware and bit testing. For this reason, the comparison for this benchmark is restricted to the cases of addition and addition with shift.

The basic system for these two cases using the Am2901C is shown in Figure 3-6; timing calculations for the control and data paths are listed in Table 3-8. These can be compared directly with the 'AS888 design and calculations shown previously in Figure 3-3 and Table 3-2. Addition is $13 \%$ faster using the AS888-1.

To implement the shift function, two multiplexers and an exclusive-OR gate are needed. A modified design is shown in Figure 3-7, along with timing calculations in Table 3-9. A comparison of these with Figure 3-3 and data in Table 3-4 shows that the TI system performs an addition with shift $25 \%$ faster than the Am2901C equivalent.

## SUMMARY OF RESULTS

Table 3-10 summarizes the timings of the various cases implemented with the TI and AMD parts. It can be seen that the TI 'AS888-1/'AS890-1 system runs faster than the others in all cases. Addition using the TI parts can be performed $26 \%$ faster than with the system using the Am2901C and $36 \%$ faster than that using the Am2903A. Addition with a
shift is $25 \%$ faster on the TI system than the Am2901C system and $32 \%$ faster than the Am2903C. An even wider variance occurs with the more complicated algorithms: multiplication is $42 \%$ faster using the TI chip; division is $37 \%$ faster.

Table 3-1. Am2903A/Am2910A Timings for Addition

| COMPONENT | DATA PATH | TIME <br> (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Pipeline register | Clock to output | 9 |
| Am2903A | A, B to $\bar{G}, \bar{P}$ | 52 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{\mathrm{n}+2}$ | 7 |
| Am2903A | $C_{n}$ to $C_{n+4}$, OVR, $Z, Y$ | 35 |
| Am2903A | Setup time | 5 |
|  | Total for data loop | 108 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for Am2903 addition |  | 108 |

Table 3-2. 'AS888-1/'AS890-1 Timings for Addition

| COMPONENT | DATA PATH | TIME <br> (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Pipeline register | Clock to output | 9 |
| 'AS888-1 | A, B to $\mathrm{C}_{\mathrm{n}+8}$ | 30 |
| 'AS888-1 | $C_{n}$ to $C_{n+8}$, OVR, $\mathrm{Z}, \mathrm{Y}$ | 27 |
| Register | Setup time | 2 |
|  | Total for data loop | 68 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| 'AS890-1 | $\overline{\mathrm{CC}}$ to output | 25 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total Control Loop | 69 |
| Critical path for 'AS888 addition |  | 69 |

Table 3-3. Am2903A/Am2910A Timings for Addition with Shift

| COMPONENT | DATA PATH | tIME (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Pipeline register | Clock to output | 9 |
| Am2903A | A, B to $\bar{G}, \bar{P}$ | 52 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{n+2}$ | 7 |
| Am2903A | $\mathrm{C}_{\mathrm{n}}$ to $\mathrm{C}_{\mathrm{n}+4}, \overline{\mathrm{S100}}$ | 23 |
| Am2903A | SIO(n) shift to $Y$ | 23 |
| Am2903A | RAM setup | 5 |
|  | Total for data loop | 119 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for AM with shift | 903 addition | 119 |

Table 3-4. 'AS888-1/'AS890-1 Timings for Addition with Shift

| COMPONENT | DATA PATH | TIME (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Pipeline register | Clock to output | 9 |
| 'AS888-1 | A, B to $\mathrm{C}_{\mathrm{n}+8}$ | 30 |
| 'AS888-1 | $\mathrm{C}_{\mathrm{n}}$ to $\mathrm{C}_{\mathrm{n}+8}, \overline{\text { SIOO }}$ | 25 |
| 'AS888-1 | $\overline{\text { SIO(n) }}$ shift to $Y$ | 14 |
| 'AS888-1 | Register file setup time | 2 |
|  | Total for data loop | 80 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| 'AS890-1 | $\overline{\mathrm{CC}}$ to output | 25 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 69 |
| Critical path for | S888 addition with shift | 80 |

Table 3-5. Am2903A/Am2910A Timings for Multiplication

| COMPONENT | DATA PATH | time (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Am2918 | Clock to output | 27 |
| Am2903A | $18-10$ to $\overline{\mathrm{G}}, \overline{\mathrm{P}}$ | 71 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{\mathrm{n}+\mathrm{z}}$ | 7 |
| Am2903A | $C_{n}$ to $C_{n+4}, \overline{\text { SIOOO}}$ | 23 |
| Am2903A | SIO(n) shift to $Y$ | 23 |
|  | Total for data loop | 151 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| mux | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for Am2903 multiplication |  | 151 |

Table 3-6. Am2903A/Am2910A Timings for Division

| COMPONENT | DATA PATH | TIME (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Am2918 | Clock to output | 27 |
| Am2903A | $18-10$ to $\bar{G}, \bar{P}$ | 50 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{\mathrm{n}+\mathrm{z}}$ | 7 |
| Am2903A | $\mathrm{C}_{\mathrm{n}}$ to. $\mathrm{C}_{\mathrm{n}+4}, \overline{\mathrm{SIOO}}$ | 32 |
| Am2903A | $\overline{\mathrm{SIO}(\mathrm{n})}$ shift to $Y$ | 23 |
|  | Total for data loop | 139 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for Am2903 division |  | 139 |

Table 3-7. 'AS888-1/'AS890-1 Timings for Multiplication and Division

| COMPONENT | DATA PATH | TIME (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| 'AS888-1 | Clock to $\mathrm{C}_{\mathrm{n}}+8$ | 46 |
| 'AS888-1 | $\mathrm{C}_{\mathrm{n}}$ to $\overline{\mathrm{SIO}}$ | 25 |
| 'AS888-1 | $\overline{\text { SIO }} \mathbf{( n )}$ shift to $Y$ | 14 |
| 'AS888-1 | Register file setup time | 2 |
|  | Total for data loop | 87 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| 'AS890-1 | $\overline{\mathrm{CC}}$ to output | 25 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total Control Loop | 69 |
| Critical path for 'AS888 multiplication or division |  | 87 |

Table 3-8. Am2901C/Am2910A Timings for Addition

| COMPONENT | DATA PATH | TIME (NS) |
| :---: | :---: | :---: |
| Data Loop | , |  |
| Pipeline register | Clock to output | 9 |
| Am2901C | $\mathrm{A}, \mathrm{B}$ to $\overline{\mathrm{G}}, \overline{\mathrm{P}}$ | 37 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{\mathrm{n}+\mathrm{z}}$ | 7 |
| Am2901C | $\begin{aligned} & C_{n} \text { to } C_{n+4}, \text { OVR, F3, } \\ & F=0, Y \end{aligned}$ | 25 |
| Register | Setup time | 2 |
|  | Total for data loop | 80 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for Am2901C addition |  | 80 |

Table 3-9. Am2901C/Am2910A Timings for Addition with Shift

| COMPONENT | DATA PATH | TIME (NS) |
| :---: | :---: | :---: |
| Data Loop |  |  |
| Pipeline register | Clock to output | 9 |
| Am2901C | A, B to $\bar{G}, \bar{P}$ | 37 |
| Am2902A | $\overline{\mathrm{GO}}, \overline{\mathrm{PO}}$ to $\mathrm{C}_{\mathrm{n}+\mathrm{z}}$ | 7 |
| Am2901C | $\mathrm{C}_{\mathrm{n}}$ to F3, OVR | 22 |
| XOR and MUX |  | 21 |
| Am2901C | RAM3 setup | 12 |
|  | Total for data loop | 108 |
| Control Loop |  |  |
| Pipeline register | Clock to output | 9 |
| MUX | Select to output | 13 |
| Am2910A | $\overline{\mathrm{CC}}$ to output | 30 |
| PROM | Access time | 20 |
| Pipeline register | Setup time | 2 |
|  | Total for control loop | 74 |
| Critical path for Am2903 addition |  |  |

Table 3-10. Summary of Results

| Operation | CALCULATED TIMINGS |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | DATA PATHS |  |  | CONTROL PATHS |  |  | SYSTEM CLOCK |  |  |
|  | Am2901C | Am2903A | 'AS888-1 | Am2901C | Am2903A | 'AS888-1 | Am2901C | Am2903A | 'AS888-1 |
| Addition | 80 | 108 | 68 | 74 | 74 | 69 | 80 | 108 | 69 |
| Addition with Shift | 108 | 119 | 80 | 74 | 74 | 69 | 108 | 119 | 80 |
| Multiplication | - | 151 | 87 | . - | 74 | 69 | - | 151 | 87 |
| Division | - | 139 | 87 | - | 74 | 69 | - | 139 | 87 |



Figure 3-2. Am2903-Based 16-Bit Computer System


Figure 3-3. 'AS888-Based 16-Bit Computer System


Figure 3-4. ALU Path for Multiplication and Division in the Am2903A System


Figure 3-5. ALU Path for Multiplication and Division in the 'AS888 System


Application Reports $\omega$


Figure 3-7. Modified Design of Am2901C-Based System

## Section 4

## 32-Bit CPU Design With the 'AS888/'AS890

Microprogramming and bit slice technology have made possible the development of powerful systems using flexible instructions sets and wide address/data buses to access more than one gigaword of physical main memory. This section discusses one design approach to such a system, using 'AS888 bit slice and 'AS890 microsequencer components.

A structured approach to system design, such as that illustrated in Figure 4-1, is recommended in developing custom bit-slice designs. The product specification gives a starting point or basis for the project. In this example, four 'AS888 bit slices are used to implement the 32-bit arithmetic portion of the CPU, and an 'AS890 microsequencer is used for ALU and system control. A group of PROMs stores the microinstructions; a writable control store could also be implemented using additional control logic and components to load and modify the microprogram memory. The system is designed to access more than one gigaword of memory.

Since speed is a concern, carry look-ahead rather than ripple-through logic is recommended. If ripple-through logic were used, the system clock would need to be slowed down to allow the propagation of the carry bits through the various 'AS888 stages. By using carry look-ahead, the amount of time needed for the data to stabilize is greatly reduced by anticipating the carry across the 'AS888 packages.

So that the scratchpad area can be used for address calculations and mathematical computations, the 'AS888's internal register file is dedicated for system functions. To provide the system user with a macrolevel equivalent of register locations, a 16 -word external register file is also included. Access to the external register file is under microprogram control, allowing address selection to come from the microcode itself or from one of the three operand fields of the instruction register.

PROMs eliminate the use of main memory as a source for constants used in initialization or table look-up functions. Accessing main memory for table values would require time and slow system throughput; by placing fixed values in fast PROMs, access time is kept to a minimum and system throughput is not altered.

Control, data and address buses shared by the system are accessed by three-state registers. The control register supplies the non-CPU part of a computer system with control signals. The data bus allows the ALU to supply data for the rest of the system and can also be a source of data for the ALU; this is accomplished by using three-state registers to drive the bidirectional data bus, along with registers to sample the bus. The address bus uses one of the external register file locations to maintain a program counter, thus allowing a 32-bit address bus capable of addressing about 4 gigawords


Figure 4-1. System Design Approach
of main memory. Using three-state drivers for this bus enables other subsystems to take control of the system buses.

A pipeline register supplies the microsequencer and the ALU with both data and instructions. To get macrocode into the system, an instruction register and a mapping PROM are used to convert the opcode to a microprogram routine address. The condition code signal, used for testing various conditions, is supplied by a register-input-based PAL. PAL inputs can be fixed values or combinations of the status signals coming from the ALU. The read address select pins for the 'AS888's internal B register can be sourced from the microword itself or from three nibbles of the macroword, to provide offsets for the N -way branches to various microcode routines.

## DESIGNING A 32-BIT SYSTEM

A typical 32-bit system block diagram using the 'AS888 Bit-Slice and 'AS890 Microsequencer is shown in Figures 4-2 and 4-3. It can be broken down into two sections, the ALU (arithmetic logic unit) and the CCU (computer control unit). The ALU section performs all manipulation of data both to and from main memory, such as arithmetic and logical operations. The CCU section controls instruction (macro-code) flow and any miscellaneous control operations, such as fetching instructions or supplying addresses for main memory access.

## Construction of the ALU

To cascade the four 'AS888s to obtain the 32-bit arithmetic unit shown in Figure 4-4, the shift multiplex SIO0


Figure 4-2. CCU Block Diagram


Figure 4-3. ALU Block Diagram


Figure 4-4. Cascaded 'AS888 Packages
and $\overline{\mathrm{QIO}}$ terminals are connected to the $\overline{\mathrm{SIO}}$ and $\overline{\mathrm{QIO} 7}$ terminals of adjacent packages, and the least significant package's signals are connected to the most-significant package's. Optionally, the SN74ALS240 inverting gates can be connected to the $\overline{\mathrm{SIO}}-\overline{\mathrm{SIO}}$ terminals and the byte inputs to implement byte and bit control. Another chip, the SN74AS182 look-ahead carry generator, provides a ripplecarry function, to help system throughput.

The design includes a 16 -word register file, the SN74AS870 (see Figure 4-3). This allows the user to access 16 working areas for temporary data storage or address calculations such as indexing. In this design example, the 'AS888's internal register file is not accessible directly by the user; it is reserved for microcode operations, such as address computation and temporary storage for arithmetic operations. Addressing the register files is permitted through the microprogram or from the macrocode instruction register under microcode control. The transfer register connected to the 'AS888's Y and DB buses allows for feedback into the 'AS888 under microprogram control. Since the constant PROMs and the external register file share the A bus, they cannot be accessed at the same time. The transfer register enables data from the external register file to be transmitted to the B bus, making possible the addition of operands from the constant PROMs and the external register file, for example.

Constant PROMs are also included to simplify the programming and operation of the ALU by supplying fixed data for various operations, such as:

1. Clearing the system register files for initialization. This brings the system up to a known state.
2. Supplying a correction value to the offset in a branch instruction,i.e., converting a 16 -bit offset to a true 32 -bit address.
3. Table look-up for fixed mathematical operations, such as computing sines and cosines.

## Construction of the CCU

Sequencing and branching operations at speeds compatible with the 'AS888 are supplied by the 'AS890, a microprogrammed controller working as a powerful microsequencer. Features of the 'AS890 include:

1. Stack capability. The 9 -word stack can be accessed by using a stack pointer or a read pointer; the latter is designed for nondestructive dumping of the stack contents.
2. Register/counter facility. Two registers, DRA and DRB, can be used for latching data from the external data buses or as counters for loops.

A ZERO signal is generated when the decremented counter reaches a zero value.
3. Interrupt control. A register for temporarily holding the return address is supplied; upon entering the interrupt routine, the contents of the return register must be pushed onto the stack for later use.
4. Next address generation. The $Y$ output multiplexer offers a selection of same or incremented address, address from DRA or DRB buses, address from stack, or a concatenation of DRA13-DRA4 and B3-B0.
A microprogram memory/pipeline register supplies the microsequencer and the rest of the system with instructions (see Figure 4-2). The memory might consist of ROMs, or it could be a writable-control store with support logic to allow loading or updating of the control store. For a general purpose machine with a fixed instruction set, ROMs would be more economic.

Some 'AS890 instructions are influenced by the $\overline{\mathrm{CC}}$ input. Many are variations of branch and jump instructions. To form and supply $\overline{\mathrm{CC}}$, a register can be used to latch the state of the 'AS888 and supply inputs to a PAL for decoding, based upon the microcode's needs. Combinatorial logic in the PAL allows multiple or single events to be selected or provides a fixed value of " 1 " or " 0 '" for forced conditions.

To supply the microsequencer with the proper address of the microcode-equivalent version of the macrocode instruction, an instruction register and mapping PROM are needed. Under microprogram control, the instruction register samples the data bus to get the macrocode instruction. The opcode portion is passed to the mapping PROM to form an address to the microcode routine. When the microcode is ready to jump to the routine, it turns off the Y bus output of the 'AS890 and enables the output of the mapping PROM. An optional means of altering the address uses B3-B0 inputs of the 'AS890 to implement an N-way branch routine. In this method, the ten most significant address bits of DRA or DRA are concatenated with the B3-B0 bits to supply an address.

Control information is supplied to the rest of the system via the control register and bus. By setting various bits within the control register, information can be passed to other subsystems, such as memory and I/O peripherals. Bit 0 could represent the read/write control line while bit 1 could select memory or I/O for the read/write. Bit 2 might function to enable interrupts and bit 3 to indicate when the system should enter a "wait"' state for slow memory. The remaining control bits can be programmed by the system designer to indicate additional condition states of the 'macrosystem'.

Addressing of the register files, both 'AS888 internal and 'AS870 external, is done through the use of two 1-of-2 selector banks. The first bank selects address source; this design offers a choice for operand processing of fixed values from the microcode or values from the macroinstruction latched in the instruction register. The second bank selects the first or second operand as an address source for port 0 of the external register file; port 1 uses the third operand
as an address source. It should be noted that the design presented in Figure 4-2 is a one-level pipeline that is instruction-data based. The address and contents of the next instruction are being fetched while the current instruction is being executed. Tracing through the data flow, the following can be observed:

1. The pipeline register contains the current instruction being executed
2. The ALU has just executed its instruction, and has the current status ready at its output pins
3. The status register that is attached to the ALU contains the previous instruction's resulting status
4. The contents of the next microprogram word are being fetched at the same time that the current instruction is being executed.

## TRACING THROUGH A 32-BIT COMPUTER

With the 'AS888 and 'AS890 as foundation chips, the typical 32 -bit supermini of Figures 4-2 and 4-3 can now be functionally traced. First, note that the data of the main program is handled separately from that of the microcodeeach on its own bus. The system is initialized by setting the "clear" signal high-this causes a forced jump to the beginning of the microcode memory. Instructions carried out by the microcode at this point might run system diagnostics, clear all registers throughout the 'AS888-based system, and set up the initial macrocode program address. In this design, the first program address to fetch an instruction from main memory comes from a fixed value in the microcode memory; it is possible to allow the address to be retrieved from a permanent location in main memory or from either a front panel or console, by modifying the microcode program slightly.

Table 4-1 illustrates the microcode format for this design. Note that it contains control signals for all chips involved in the design. Some of these, such as $\overline{\text { TRANSLATCH }}$ and MARLATCH, are used with the system clock to provide controlled loading of the various holding registers. Others supply necessary addressing information, directing input from either the main data bus or from the microcode word itself.

The FETCH routine is shown in functional, assembler and microcoded forms in Tables 4-2, 4-3 and 4-4. First, the program counter is read from the external register file and stored into the memory address register. After the program counter is placed on the address bus, the program counter is updated and stored while the data from memory is allowed to settle down to a stable condition. The data is then latched in both the instruction register and data-in register.

The opcode field of the instruction register is passed through the mapping PROM to convert the opcode to an equivalent microcode routine address. When $\overline{\mathrm{YOE}}$ is forced high by the microcode, the 'AS890 is three-stated from the Y bus and the mapping PROM's output is taken out of the three-state mode to supply an address to the control store (microprogram memory); a forced jump is made to the microcode routine to perform the instruction.

Table 4-1. Microcode Definition

| MICROCODE FIELD | PIN NAME | INPUT TO | FUNCTION |
| :---: | :---: | :---: | :---: |
| 0-13 | DRA13-DRA0 | 'AS890 | Used for next-address branches |
| 14-27 | DRB13-DRB0 | 'AS890 | Used for loading counter |
| 28-30 | RC2-RC0 | 'AS890 | Register/counter controls |
| 31-33 | S2-S0 | 'AS890 | Stack control |
| 34-36 | MUX2-MUXO | 'AS890 | MUX control of Y output bus |
| 37 | $\overline{\text { INT }}$ | 'AS890 | Interrupt control |
| 38 | $\widehat{\text { RAOE }}$ | 'AS890 | Enables DRA output |
| 39 | $\overline{\text { RBOE }}$ | 'AS890 | Enables DRB output |
| 40 | OSEL | 'AS890 | Mux control for DRA source |
| 41 | INC | 'AS890 | Incrementer control |
| 42 | $\overline{\text { YOE }}$ | 'AS890 | Enables $Y$ output bus |
| 43-50 | 17-10 | 'AS888 | Instruction inputs |
| 51 | OEA | 'AS888 | DA bus enable |
| 52 | $\overline{E A}$ | 'AS888 | ALU input operand select |
| 53 | $\overline{O E B}$ | 'AS888 | DB bus enable |
| 54 | OEY | 'AS888 | $Y$ bus output enable |
| 55 | SELY | 'AS888 | $Y$ bus select |
| 56-57 | EB1-EB0 | 'AS888 | ALU input operand selects |
| 58 | WE | 'AS888 | Register file write enable |
| 59 | $\overline{\text { MAP }}$ | PROM | Enables mapping PROM to 'AS890 Y bus |
| 60 | $\overline{\text { IR }}$ | Latch | Latches data bus to instruction register |
| 61 | $\overline{C R}$ | Latch | Latches control data to bus |
| 62-69 | CTRL7-CTRLO | Latch | Data for control latch |
| 70-71 | BSEL1-BSELO | Multiplexer | Selects data for 'AS890 |
| 72-75 | B3-B0 | Multiplexer | Microcode data to switch |
| 76 | CONDCD | Latch | Controls latch of 'AS888 status |
| 77-80 | SELC3-SELC0 | PAL | Selects combination of 'AS888 status |
| 81 | DTALATCHI | Latch | Controls latching of data-in |
| 82 | DTAIN | Latch | Enables data-in output to bus |
| 83 | DTALATCHO | Latch | Controls latching of data-out |
| 84 | DTAOUT | Latch | Enables data-out output to DB bus |
| 85 | $\overline{\text { MARLATCH }}$ | Latch | Controls latching of address |
| 86 | $\overline{\text { MAR }}$ | Latch | Enables MAR output to address bus |
| 87 | CONSTPROM | PROM | Enables PROM to DA bus |
| 88-99 | A11-A0 | PROM | Address of constant in PROM |
| 100 | SWITCH2 | Multiplexer | Selects microcode or Instruction Register data |
| 101 | SWITCH1 | Multiplexer | Selects microcode or Instruction Register data |
| 102-105 | A3-A0 | Multiplexer | Register file address ('AS888) |
| 106-109 | B3-80 | Multiplexer | Register file address ('AS888) |
| 110-113 | C3-C0 | Multiplexer | Register file address ('AS888) |
| 114 | REGUWR | Register File | Port 0 write enable |
| 115 | REGLWR | Register File | Port 1 write enable |
| 116 | REGU | Register File | Chip enable on port 0 |
| 117 | $\overline{\text { REGL }}$ | Register File | Chip enable on port 1 |
| 118 | TRANSLATCH | Latch | Controls latch between Y and DB bus |
| 119 | TRANS | Latch | Enables output to DB bus |
| 120 | SELCN2 | Multiplexer | Supplies carry input to 'AS888 |
| 121 | SELCN1 | Multiplexer | Supplies carry input to 'AS888 |
| 122 | REGUB | Multiplexer | Selects address for external register file |
| 123-126 | BYTE3 - $\overline{\text { BYTE0 }}$ | Three-state | Enables data for byte/bit operations |

Table 4-2. Functional Listing of Fetch

```
FETCH: MAR = PC, Enable MAR output
    PC = PC + 1
    IR = DIR = data bus, Disable 'AS890 Y bus,
        Enable mapping PROM to Y bus
```

Table 4-3. Assembler Listing of Fetch

| FETCH: OP890 .., 111,10; INC; | Set 'AS890 for continue |
| :---: | :---: |
| OP888 NOP,GROUP5,10,,1111; | Perform NOP and read external register 15 |
| OEY;SELY; | Enable $Y$ bus output |
| CR;CTRL 00000011; | Generate external control bus signals |
| SELC 01; | Select fixed CC value to 'AS890 |
| MARLATCH;MAR; | Latch value on $Y$ bus and enable output |
| SWITCH 00;REGL; | Select address source and enable port |
| TRANSLATCH | Latch Y bus for transfer to B bus |
| OP890 ..,111,10;INC; | Set 'AS890 for continue |
| OP888 PASS,INCS,00,.,1111; | Increment program counter |
| OEB;OEY; | Enable $Y$ bus output |
| SELC 01; | Select fixed CC value to 'AS890 |
| MAR | Output address to address bus |
| REGLWR;REGL; | Update program counter in register file |
| TRANS; | Enable transfer latch output to $B$ bus |
| SELCN 01 | Select carry input to LSP to be "1" |
| OP890 ,.,111,10; | Set 'AS890 for continue |
| OP888 NOP,GROUP5,10; | Perform NOP |
| MAP; | Enable mapping PROM to 'AS890 Y bus |
| IR; | Latch data bus to get macrolevel code |
| SELC 01 | Select fixed CC value to 'AS890 |
| DTALATCHI; | Put data bus also in data register |
| MAR | Output address to address bus |

Key to Table 4-3

OP888 a,b,c,d,e,f

## where:

$\mathbf{a}=$ upper bits of instruction, 17-14 $\quad \mathbf{d}=A$ address of register files
$b=$ lower bits of instruction, 13-10 $\quad e=B$ address of register files
$c=$ value of EB1-EB0 $\quad f=C$ address of register files

OP890 v,w, x,y,z
where:
$v=$ DRA value, 14-bits $y=S 2-S 0$
$w=$ DRB value, 14-bits $z=$ MUX2-MUX0
$x=R C 2-R C 0$

After the routine is complete, a jump is made back to the FETCH routine by using the next-address supplied by the microprogram. It is up to the system designer/ programmer to make sure that all system housekeeping is performed, so that nothing causes a fatal endless loop.

## DEFINING THE MACROCODE INSTRUCTION FORMAT

Since this is a 32 -bit design, a variety of instruction formats are available. The size of the opcode along with the types of addressing used, will affect both system size and performance. The formats shown in Table 4-5 will be used for discussion.

All Table 4-5 formats have an opcode field of 11 bits and source/destination fields of 7 bits; the first three bits of the latter designate the address type, and the remaining four
bits are used for register access. The opcode length allows 2,048 macrocoded instructions to be mapped to equivalent microcoded routines. The address fields can specify any of the following modes: register, relative, autoincrement/ autodecrement, indexed, absolute, and deferred. The offset used in the Type 0 instruction can be used for branch-based instructions, for an offset range of $\pm 32727$.

## TRACING A MACROCODE INSTRUCTION

Microcode for a Type 3 multiplication instruction is shown in Table 4-6, using the following assumptions:

1. Code for retrieving the operands will not be shown. Jumps will be made to routines that will place the temporary operands into internal register locations 2 and 3 of the 'AS888, after being fetched from main memory.

Table 4-4. Microcode Listing of Fetch

| DRA13DRAO | DRB13DRB0 | ¢ | $\begin{aligned} & \text { ஷi } \\ & \text { ベ } \end{aligned}$ |  |  | 17-10 |  | $\left\lvert\, \frac{a}{i} \times \underset{0}{\infty}\right.$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00000000000000 | 00000000000000 | 000 | 111 | 010 | 111010 | 11111111 | 11101101 | 110 |
| 00000000000000 | 00000000000000 | 000 | 111 | 010 | 111010 | 11110100 | 11000001 | 111 |
| 00000000000000 | 00000000000000 | 000 | 111 | 10 | 111001 | 11111111 | 01111101 |  |

Table 4-4. Microcode Listing of Fetch (Continued)


Table 4-5. Possible Instruction Formats
TYPE 0 - OPCODE + 16-BIT OFFSET

| $0-10$ | $11-15$ | $16-31$ |
| :---: | :---: | :---: |
| Opcode | Not Used |  |$\quad$ Offset |  |
| :---: |

TYPE 1 - OPCODE + DESTINATION

| $0-10$ | $11-24$ |  |
| :---: | :---: | :---: |
| Opcode | Not used | $25-31$ <br> Destination |

TYPE 2 - OPCODE + SOURCE + DESTINATION

| $0-10$ | $11-17$ | $18-24$ | $25-31$ |
| :---: | :---: | :---: | :---: |
| Opcode | Not used | Source | Destination |

TYPE 3 - OPCODE + SOURCE1 + SOURCE2 + DESTINATION

| $0-10$ | $11-17$ | $18-24$ | $25-31$ |
| :---: | :---: | :---: | :---: |
| Opcode | Source | Source | Destination |

Table 4-6. Functional Listing of Multiply
UMULIS:
JUMPSUB SOURCE1
Get first operand
JUMPSUB SOURCE2,
Get second operand
BCOUNT $=32$ Load DB counter register
REG $9=0$
Clear temporary accumulator
$M Q=R E G 2$
LOOP:
UMULI WITH REG 3 DECREMENT BCOUNT, BRANCH TO LOOP IF NOT ZERO,
LATCH 'AS888 STATUS,
REG $9=A L U$
${ }^{1}$ REG $8=$ MQ
JUMPSUB STORPSW JUMPSUB MDEST
JUMP FETCH
Load multiplier
Issue the multiply
Decrement the DB counter
Loop back until done
Store 'AS888 flags
Store intermediate result
Store intermediate result
Update macro program status
Store result at destination
Get next instruction

Table 4-7. Assembler Code of Multiply

| UMULI3: |  |
| :---: | :---: |
| OP890 SOURCE1,.,110,110; | Perform a subroutine branch |
| INC; YOE; | Increment address and enable Y bus |
| OP888 NOP;GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to " 1 ". to set up 'AS890 continue |
| MAR | Maintain address on main address buss |
| OP890 SOURCE2,00000000100000,110,110,110; | Perform subroutine branch and load B counter |
| INC; YOE; | Increment microaddress and enable $Y$ bus |
| OP888 NOP,GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to " 1 " to set up 'AS890 continue |
| MAR | Maintain address on main address bus |
| OP890 ,.,111,110; | Perform a continue instruction |
| INC;YOE; | Increment microaddress and enable Y bus |
| OP888 CLEAR,GROUP5,...1001; | Zero out register file accumulator |
| WE; | Enable writing to register file |
| SELC 0001; | Set CC to "1" to set up 'AS890 continue |
| MAR | Maintain address on main address buss |
| OP890 LOOP.,.111,110; | Perform a continue instruction |
| INC;YOE; | Increment microaddress and enable Y bus |
| OP888 LOADMQ,INCS,,,0010; | Load MQ register with $S+C n$, from external register file |
| MAR | Maintain address on main address bus |
| LOOP: |  |
| OP890 LOOP,,101,111,100; | Decrement B and loop til ZERO $=1$ |
| INC;YOE; | Increment microaddress and enable $Y$ bus |
| OP888 UMULI,GROUP4,01,0011,,1001; | Perform unsigned multiply on accumulator |
| WE; | Update register file accumulator |
| MAR | Maintain address on main address bus |
| OP890 ,..111,110; | Perform a continue instruction |
| INC; YOE; | Increment microaddress and enable Y bus |
| OP888 PASS,INCS,,.,1000; | Put $\mathrm{S}+\mathrm{Cn}$ in temporary register file |
| WE; | Allow updating of register file |
| MAR | Maintain address on main address bus |
| OP890 STORPSW,.,110,110; | Perform a subroutine branch |
| INC;YOE; | Increment microaddress and enable $Y$ bus |
| OP888 NOP,GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to " 1 " for set up 'AS890 continue |
| MAR | Maintain address on main address bus |
| OP890 FETCH,.,111; | Perform a branch to FETCH routine |
| INC; YOE; | Increment microaddress and enable Y bus |
| OP888 NOP,GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001 | Set CC to " 1 " for 'AS890 continue |

Key to Table 4-7.

## OP888 a,b,c,d,e,f

## where:

a $=$ upper bits of instruction, 17-14
$\mathrm{b}=$ lower bits of instruction, 13-10
c $=$ value of EB1-EB0
$d=A$ address of register files
$e=B$ address of register files
$f=C$ address of register files

OP890 v,w,x,y,z
where:

```
v = DRA value, 14-bits
w = DRB value, 14-bits
x = RC2.RC0
y = S2-S0
z = MUX2-MUX0
```

Table 4-8. Microcode Listing of Multiply

| DRA13DRAO | DRB13. DRBO |  | $\begin{aligned} & \dot{\sim} \\ & \underset{\sim}{\sim} \\ & \text { N } \end{aligned}$ |  |  | 17-10 |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00000000001100 | 00000000000000 | 000 | 110 | 110 | 111010 | 11111111 | 11110001 | 111 |
| 00000000010000 | 00000000100000 | 110 | 110 | 110 | 111010 | 111111111 | 11110001 | 111 |
| 00000000000000 | 00000000000000 | 000 | 111 | 110 | $1 \begin{array}{llllll}1 & 1 & 0 & 1 & 0\end{array}$ | 11110000 | 11100000 | 1111 |
| 00001000001000 | 00000000000000 | 000 | 111 | 110 | 1110010 | 11100100 | 11100001 | 1111 |
| 00001000001000 | 00000000000000 | 101 | 111 | 100 | 111010 | 11010000 | 11100010 | 111 |
| 00000000000000 | 10000000000000 | 000 | 111 | 101 | 111010 | 1111111111 | 11100010 | $1 \begin{array}{lll}1 & 1\end{array}$ |
| 00000000010100 | 00000000000000 | 000 | 110 | 110 | 111010 | 111111111 | 11110001 | $1 \begin{array}{lll}1 & 1\end{array}$ |
| 00000000011000 | 0000000000000 | 000 | 110 | 110 | 1111010 | 11111111111 | 11110001 | 1111 |
| 00000000000011 | 00000000000000 | 000 | 111 | 000 | 111010 | 11711111 | 11110001 | 111 |

Table 4-8. Microcode Listing of Multiply (Continued)

| CTRL7- <br> CTRLO |  | $\begin{aligned} & \text { O} \\ & \dot{m} \\ & \text { M } \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \\ & 0 \\ & 2 \\ & 0 \\ & 0 \end{aligned}$ |  |  | A11-A0 |  | ¢ | $\begin{aligned} & \text { O! } \\ & \stackrel{\omega}{\infty} \end{aligned}$ | $\begin{aligned} & \dot{U} \\ & \dot{U} \end{aligned}$ |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00000000 | 00 | 0000 | 1 | 0001 | 1111101 | 00000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | 1111 |
| 00000000 | 00 | 0000 | 1 | 0001 | 1111101 | 00000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | 11111 |
| 00000000 | 00 | 0000 | 1 | 0001 | 11111101 | 000000000000 | 00 | 0000 | 0000 | 1001 | 111111000 | 11111 |
| 00000000 | 00 | 0000 | 0 | 0001 | 11111101 | 000000000000 | 00 | 0000 | 0010 | 0000 | 110111000 | 11111 |
| 00000000 | 00 | 0000 | 0 | 0001 | 11111101 | 000000000000 | 00 | 0011 | 0000 | 1001 | 101011000 | 1111 |
| 00000000 | 00 | 0000 | 0 | 0001 | 11111101 | 00000000000 | 00 | 0000 | 0000 | 1000 | 101011000 | 11111 |
| 00000000 | 00 | 0000 | 0 | 0001 | 1111101 | 000000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | 1111 |
| 00000000 | 00 | 0000 | 1 | 0001 | 1111101 | 000000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ |
| 00000000 | 00 | 0000 | 1 | 0001 | 1111111 | 00000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | 1111 |

2. A jump to a routine to store the product in the destination will be handled similarly.
3. Multiplication will be unsigned; the result will be placed in two temporary locations of the 'AS888.
4. An update to the program status word, which the user can access at the macrocode level, must also be performed but is not shown.
Assembler code is shown in Table 4-7; a microcode listing is given in Table 4-8. The first two lines of microcode are subroutine jumps to opcode fetching routines, which store the operands in register files 2 and 3 in the 'AS888. The next two instructions load up the 'AS890 with a counter constant for the multiply loop, load the MQ register of the 'AS888 with the multiplier and clear the register that is temporarily used for the accumulator.

A loop is then entered to perform the multiply instruction 32 times to form the product, with the multiplicand coming from the internal register file of the 'AS888. Upon exiting the loop, the MQ register is stored
in a temporary register location in the 'AS888. The MQ register now contains the least significant bits of the result and the temporary accumulator the most significant bits. A subroutine jump is made to the program status word update routine; this will take the status flags of the last multiplication iteration and change the macrolevel status word. The next subroutine jump is to a destination routine, which is followed by a branch to the FETCH routine to get the next macroinstruction to be executed.

## SYSTEM ENHANCEMENTS

The above example provides a broad overview of 32-bit system design using the 'AS888 and 'AS890. Certain additional options may enhance system performance. These include:

1. Status latching. The design does not take into account changes that need to be examined at the microlevel while retaining macrolevel status information. One solution would be to include another register in parallel to the status latch
and provide control to choose between the two to form the condition code value.
2. Interrupts. To efficiently use a computer system, interrupts are used to alter program flow in the case of I/O programming and realtime applications (involving hardware timers). To include this capability, external hardware must be included and the microcode modified accordingly.
3. Control store. One way of implementing microprogram memory is to use a ROM-based design. It is becoming more common to design a writable control store, a completely RAMbased or part RAM, part ROM storage system, that can be altered by system operation, such as initialization from a floppy disk subsystem, or by the user to optimize or implement new macrolevel instructions. The cost of implementation must be weighed with the risks involved in changing instructions which may not be supported by other sites.
4. Instruction word definitions. Changing the instruction word definitions will have an effect on both system design and performance. Removing Type 3 instructions from the design, for example, will have an effect on both
hardware and software: the external register file addressing must be changed and the 1-of-2 selector removed. Likewise, changing the opcode length may restrict the instruction address capability and also cause either an increase or decrease in the microcode size.
5. Dynamic memory access (DMA). The above system does not support dynamic memory access. To include this function requires a change in the address output control, along with support circuitry for the type of DMA selected. Some error detection and correction logic for main memory might also be included.
6. Computer control unit. The design presented here shows a one-level pipeline architecture that is instruction-data based. System throughput may be increased by converting to a pipeline of greater depth, or using another variety of one-level pipeline, such as instruction-address based or address-data based. Care must be taken when increasing the size of the pipeline, especially when handling branch/jump situations. The reader is advised to carefully research this area before implementing any design.

Table 4-9. Critical Delay Path Analysis

| CONTROL LOOP |  |  | DATA LOOP |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| COMPONENT | DATA PATH | TIME (NS) | COMPONENT | DATA PATH | TIME <br> (NS) |
| Pipeline register MUX 'AS890-1 PROM <br> Pipeline register | Clock to output Select to output $\overline{\mathrm{CC}}$ to output Access time Setup time | $\begin{array}{r} 9 \\ 13 \\ 25 \\ 20 \\ 2 \\ \hline 69 \end{array}$ | $\begin{aligned} & \text { 'AS888-1 } \\ & \text { 'AS182 } \\ & \text { 'AS888-1 } \\ & \text { 'AS888-1 } \end{aligned}$ | Clock to $\mathrm{C}_{\mathrm{n}}$ $C_{n}$ to $C_{n+z}$ $C_{n}$ to $\overline{\mathrm{SiO}}$ $\overline{\mathrm{SIO}}$ to Y | $\begin{array}{r} 46 \\ 5 \\ 25 \\ 14 \\ \hline 90 \end{array}$ |

Table 4-10. Fetch Timing Comparison

| FETCH | 'AS888 |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Data width | 32 | 16 | 16 | 16 | 16 |
| No. of cycles | 4 | 3 | 4 | 4 | 4 |
| Clock rate | 11.11 MHz | 4 MHz | 10 MHz | 10 MHz | 8 MHz |
| Total time | 360 ns | 750 ns | 400 ns | 400 ns | 600 ns |

Table 4-11. Multiply Timing Comparison

|  | 'AS888 | 'AS888 |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| MULTIPLY | $32-$ BIT | $16-$ BIT | $\mathbf{Z 8 0 0 1}$ | $8086-1$ | 80286 | 68000 L |
| Size | $32 \times 32$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ |
| No. of cycles | 35 | 19 | 70 | 128 | 21 | $\leq 74$ |
| Clock rate | 11.11 MHz | 10.98 MHz | 4 MHz | 10 MHz | 10 MHz | 8 MHz |
| Total time | $3.150 \mu \mathrm{~s}$ | $1.729 \mu \mathrm{~s}$ | $17.5 \mu \mathrm{~s}$ | $12.8 \mu \mathrm{~s}$ | $2.1 \mu \mathrm{~s}$ | $\leq 9.25 \mu \mathrm{~s}$ |

## TIMING AND SYSTEM THROUGHPUT

A critical path analysis was undertaken to determine the maximum clock rate for the proposed system. The longest delay path is the multiplication data path, which involves the internal register file and the shift function of the 'AS888. Table 4-9 contains the critical delay calculations for both the ALU and CCU. Since both portions of the system must be satisfied, a clock rate of 90 ns was selected for the following comparisons.

## FETCH ANALYSIS

Most microprocessors perform an instruction fetch in a pipeline mode; the next instruction is fetched while the current instruction is executing. The fetch code shown earlier requires a minimum of four cycles: three to issue the code and one to break the pipeline for processing the batch. This results in a total time of 360 ns , based on a 90 ns cycle time. Fetch times for the representative microprocessors have been estimated from data books and are shown in Table 4-10; wait states for slow memory are not included. As can be seen from the table, the 'AS888 design example is estimated to run from 1.1 to 2.1 times faster than the 16 -bit microprocessors.

## MULTIPLICATION ANALYSIS

This analysis assumes that multiplication is unsigned integer and register to register based. No account is taken of time needed for instruction fetch or operand fetch or store.

The basic loop for the multiply takes 35 cycles: 2 for accumulator and multiplier setup, 32 for actual multiply loop and 1 to store the least significant bits in an internal register file. Given a cycle time of 90 ns , a 32 by 32 bit multiplication can be implemented in 2.275 microseconds. A 16 -bit multiply requires 16 iterations of the inner loop; both timings are included in Table 4-11 for comparison. Values for the 16-bit multiplies of the representative microprocessors have been estimated from data books.

As shown in Table 4-11, the 16 by 16 multiply can be performed with the 'AS888 at a faster rate than the 16 -bit microprocessors. Even comparing the 32 by 32 multiply of the application design, one can see that the 'AS888 based system has a better macroinstruction execution speed. Using the 'AS888 and 'AS890 in a system design will allow high throughput and a flexible architecture.
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## Section 5

# An Adaptive Clock Generator To Increase 'AS888 System Speed 

'AS888-1 instructions execute within 50 to 90 ns ; over half execute in less than 60 ns . It is therefore possible to enhance the speed of an 'AS888 system using an adaptive clock generator that spaces clock pulses according to the time required to complete each operation. The advantage of using this circuit is that the system can process each instruction in almost exactly the time it takes the desired results to reach steady-state. The alternative is to use a periodic 90 ns clock and waste use of 'AS888 "idle time." Just how fast the system will run with the adaptive clock is a function of the statistical distribution of microinstructions within any given microprogram.

The time required for an 'AS888 instruction depends on whether shift, carry, register file read, ZERO status test and/or N status test are used. These operations require varying lengths of time to execute, depending on the number of 'AS888 internal delays involved. Whether shift and/or carry are used is determined by the 'AS888 instruction field. ALU source operands can originate from the register file or the DA and DB buses; this is determined by the state of the $\overline{E A}$ and EB1-EB0 inputs. Whether or not ZERO or N status are tested depends on other system signals, such as a status select field in the microinstruction to select ALU status during conditional branching. Depending on the system architecture, the pipelining scheme used and the flexibility of the microprogram, the designer may wish to ensure that test ZERO and test N signals be made available during the cycle in which ZERO or N are generated in order to better match clock pulse spacing to processing delay. By also providing a register file read signal, the clock spacing will be optimally matched to the processing delay.

## CIRCUIT DESCRIPTION

A diagram of the adaptive clock circuit is given in Figure 5-1. The circuit consists of a PROM decoder and a programmable oscillator. The PROM contains a table of cycle length codes as a function of the 'AS888 instruction field, register file read (RFRD), ZERO test (ZTST) and N test (NTST). These signals are connected to the PROM address inputs from the control store outputs as shown. If the RFRD, ZTST and NTST signals are not available, these inputs can be tied high, or a smaller PROM can be used.

The cycle length codes residing in PROM are used to select one of nine delays in the programmable delay line oscillator. The selected delay provides the phase shift required for oscillation. Two progammable delay lines (Data Delay Devices PDU-1613-5) are needed; they must be alternately switched into the feedback loop so that each has
time to empty. The programmable delay lines establish the timing from leading edge to leading edge of the clock for an overall error of only $\pm 3.5 \mathrm{~ns}$. The delays for various fixed-length delay lines are indicated by the numbers in the numbered boxes in Figure 5-1.

Timing for this circuit is shown in Figure 5-2. RST initializes the circuit. When RST releases, the open collector output of U4a provides an initial rising edge from which all successive rising edges are regenerated. Toggle flip-flop U3a switches between the two halves of the oscillator. Latches U6a and U6b are alternately enabled by the $Q$ and $\bar{Q}$ outputs of U3b. In this manner only one delay line at a time is selected to receive a pulse. U3a generates $\overline{\mathrm{OE} 1}$ and $\overline{\mathrm{OE} 2}$ which select the available delay line for output. The pulse width regulation is also initiated by U3a. TQ and TQ serve as references for edge detectors U5a-U5d. The fixed delay lines shape $\overline{\mathrm{OC} 1}$, CLR1, $\overline{\mathrm{OC} 2}$, and CLR2. The output control $\overline{\mathrm{OC} 1}$ (or $\overline{\mathrm{OC} 2}$ ) on U6a (or U6b) turns off several nanoseconds after a rising transition in TQ (or $\overline{\mathrm{TQ}}$ ) has occurred thereby holding Q1 (or Q2) high. This stretches the on-time of the pulse to nearly 50 ns . U6a (or U6b) is cleared 10 ns later. After another 10 ns the output control turns on again, allowing the $Q$ which was just cleared to establish the falling edge of the stretched pulse. This stretched pulse then enters the selected delay line, U7 (or U8), exiting at a time established by the cycle length code. The delay line output enable, $\overline{\mathrm{OE} 1}$ (or $\overline{\mathrm{OE} 2}$ ) switches in the delay line before its pulse is ready to exit. In this manner, the width of the previous pulse is regulated to within 20 to 30 ns .

## PROM PROGRAM

The cycle lengths are defined by analyzing the propagation delays from the 'AS888 data sheet given in Table 5-1. Variations in cycle lengths depend on whether shift, carry, register file read, ZERO test or N test are used. The algorithm for determining cycle length is flowcharted in Figures $5-3-5-6$. Total cycle length is found by adding up all the contributing delays for each possible case. Sums less than 50 ns must be adjusted to 50 ns since this is the minimum clock cycle length specified in the data sheet. Seven nanoseconds is used as the propagation time for $\overline{\mathrm{G}} / \mathrm{P}$ to Cn ; this assumes an 'AS182 lookahead carry generator is used with the 'AS888. Each total delay is rounded up to the nearest integer multiple of 5 ns , which gives nine possible outcomes.

Use of the shifters or carry is inherent in each instruction as shown in Table 5-2. Cycle length codes can be generated by looking up Table 5-2 for each instruction, performing the algorithm in Figures 5-3-5-6, and encoding


Figure 5-1. Adaptive Clock Generator Circuit


Figure 5-2. Adaptive Clock Generator Timing Diagram

Table 5-1. 'AS888-1 Timing Characteristics

| PARAMETER | FROM (INPUT) | TO (OUTPUT) |  |  |  |  |  |  |  |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Y | $C_{n}+8$ | $\overline{\mathrm{G}, \overline{\mathrm{P}}}$ | 2* | N | OVR | DA | DB | $\overline{\text { ào }}$ | S'0 |  |
| ${ }^{\text {tpd }}$ | $\begin{aligned} & \text { A3-AO, } \\ & \text { B3-BO } \end{aligned}$ | 44 | 30 | 36 | 50 | 44 | 44 | 17 | 17 | 48 | 48 | ns |
|  | DA7-DAO, DB7-DBO | 36 | 24 | 24 | 46 | 41 | 32 | - | - | 40 | 40 |  |
|  | $\mathrm{C}_{\mathrm{n}}$ | 22 | 8 | - | 27 | 21 | 16 | - | - | 25 | 25 |  |
|  | EA | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | EB | 40 | 25 | 25 | 49 | 41 | 41 | - | - | 44 | 44 |  |
|  | 17-10 | 46 | 27 | 27 | 50 | 42 | 35 | - | - | 45 | 45 |  |
|  | $\overline{\text { OEB }}$ | - | - | - | - | - | - | - | 12 | - | - |  |
|  | $\overline{\mathrm{OEY}}$ | 12 | - | - | - | - | - | - | - | - | - |  |
|  | $\overline{\overline{010}(\mathrm{n})}$ Shift | 14 | - | - | 20 | - | - | - | - | - | - |  |
|  | $\begin{aligned} & \hline \overline{\mathrm{SO}(\mathrm{n})} \\ & \text { Shift } \end{aligned}$ | 14 | - | - | 20 | 18 | - | - | - | - | - |  |
|  | CK | 50 | 46 | 46 | 50 | 50 | 50 | 30 | 30 | 50 | 50 |  |
|  | $\overline{\text { OEA }}$ | - | - | - | - | - | - | 12 | - | - | - |  |
|  | SSF** | - | - | - | - | - | 9 | - | - | - | - |  |

[^60]**For byte instructions only.
NOTE 1: For load circuit and voltage waveforms, see page 1-12 of The TTL Data Book, Volume 3, 1984.
each of the nine possible time delays with a number from 0 to 8. A BASIC program which follows this procedure and generates the PROM data in Data I/O hex-ASCII format is shown in Program 5-1. Program lines 147-149 look up carry and shift for each instruction. Once carry and shift are known, the program solves the total delay algorithm in Figures

5-3-5-6 for all cases of ZTST, NTST, and RFRD as shown in program lines 163-184. At this point the actual time to process the microinstruction for the given conditions is solved. The time values are then encoded from 0 to 8 in program lines 188-195. The output is listed in Figure 5-7.

Table 5-2. Shift and Carry as a Function of 17-10

| GROUP 1 INSTRUCTIONS |  |  |  |
| :---: | :---: | :---: | :---: |
| INSTRUCTION BITS (I3-IO) HEX CODE | MNEMONIC | CARRY | SHIFT |
|  | ADD <br> SUBR <br> SUBS <br> INCS <br> INCNS <br> iNCR <br> INCNR <br> XOR <br> AND <br> OR <br> NAND <br> NOR <br> ANDNR | $\begin{aligned} & r \\ & 2 \\ & 2 \\ & 2 \\ & 2 \\ & 2 \end{aligned}$ |  |
| GROUP 2 INSTRUCTIONS |  |  |  |
| INSTRUCTION BITS (17-14) hex CODE | MNEMONIC | CARRY | SHIFT |
| 0 1 2 3 4 4 5 6 7 8 9 A B C D D E | SRA <br> SRAD <br> SRL <br> SRLD <br> SLA <br> SLAD <br> SLC <br> SLCD <br> SRC <br> SRCD <br> MOSRA <br> MOSRL <br> MOSLL <br> MOSLC <br> LOADMQ <br> PASS |  |  |

Table 5-2. Shift and Carry as a Function of 17-10 (Continued)

| GROUP 3 Instructions |  |  |  |
| :---: | :---: | :---: | :---: |
| INSTRUCTION BITS (17-10) hex code | MNEMONIC | CARRY | SHIFT |
| 08 | SET1 | - |  |
| 18 | SETO |  |  |
| 28 | TB1 | . |  |
| 38 | тво |  |  |
| 48 | ABS | $\cdots$ |  |
| 58 | Smic | - |  |
| 68 | ADDI | - |  |
| 78 | SUBI | - |  |
| 88 | BADD | $\checkmark$ |  |
| 98 | bSUBS | - |  |
| A8 | BSUBR | - |  |
| B8 | BINCS | - |  |
| C8 | BINCNS | $\checkmark$ |  |
| D8 | BXOR |  |  |
| E8 | BAND |  |  |
| F8 | BOR |  |  |
| GROUP 4 Instructions |  |  |  |
| 00 | CRC |  | $\checkmark$ |
| 10 | SEL | - |  |
| 20 | SNORM | $\checkmark$ | - |
| 30 | DNORM |  | - |
| 40 | DIVRF | $\stackrel{\square}{ }$ |  |
| 50 | sdivaf | - | . |
| 60 | Smuli | - | r |
| 70 | smult | r | - |
| 80 | Soivin |  | $\stackrel{\square}{\sim}$ |
| 90 | SDIVIS | - | - |
| AO | sdivi | - | - |
| Bо | udivis | - | $\stackrel{\sim}{\sim}$ |
| co | udivi | r | $\stackrel{ }{ }$ |
| Do | umuli | - | $\checkmark$ |
| EO | SDIVIT | - | $\checkmark$ |
| Fo | UDIVIT | $\checkmark$ | - |
| GROUP 5 INSTRUCTIONS |  |  |  |
| OF | CLR |  |  |
| 1F | CLR |  |  |
| 2 F | CLR |  |  |
| 3 F | CLR |  |  |
| 4 F | CLR |  |  |
| 5 F | CLR |  |  |
| 6 F | CLR |  |  |
| 7 F | bcdbin | 「 | $\checkmark$ |
| 8 F | Ex3bC | - |  |
| 9 F | Ex3c | - |  |
| AF | sdivo | $\checkmark$ |  |
| BF | CLR |  |  |
| CF | CLR |  |  |
| DF | BINEX3 | $\checkmark$ | 「 |
| EF | CLR |  |  |
| FF | NOP |  |  |



Figure 5-3. Propagation Delay Without Carry and Without Shift


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Figure 5-4. Propagation Delay Without Carry and With Shift
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Figure 5-5. Propagation Delay With Carry and Without Shift


3

Figure 5-6. Propagation Delay With Carry and With Shift

```
CLS
    PRINT "
    PRINT
    PRINT "
'
DEFINT A-Z
DIM TABLE(4096)
DEFINE TRANSMISSION CONTROL CHARACTERS
STX$=CHR$ (2)
ETX$=CHR$(3)
CR$=CHR$(13)+CHR$(10)
TX$=STX$
BS$=CHR$(8)
    Input usER's PROM data file name and open the file
PRINT:INPUT "PROM data output FILE NAme";OF$ : PRINT
OPEN "O",#1,OF$ : PRINT "WRITING CYCLE LENGTH CODES TO ";OF$;"...": PRINT
    SET UP DATA I/O PROGRAMMER FOR HEX-ASCII (COMMA) FORMAT
PRINT #1,"53A"
    FOR EACH 'AS888 InSTRUCTION (bITS I7-[0), DETERMINE IF
    SHIFT AND/OR CARRY ARE USED
FOR ITI4=0 TO 15
    FOR I3IO = 0 TO 15
    DEFINE THE 8-BIT INSTRUCTION FIELD AND IDENTIFY WHICH GROUP(S)
    THE INSTRUCTION BELONGS TO
    I7IO = 1714 * 16 + I3I0
    GROUP1 = (I3I0<>0) AND (I3I0<>8) AND (I3I0<>15)
    GROUP2 = GROUP1
    GROUP3 = (1310 = 8)
    GROUP4 = (I3IO = 0)
    GROUP5 = (I3I0 = 15)
    DETERMINE WHETHER THE INSTRUCTION USES SHIFT AND/OR CARRY
    CARRY = (GROUPI AND (I7I4<8))
    OR (GROUP3 AND (I7I4>3) AND (I7I4<13))
    OR (GROUP4 AND (I7I4<>0) AND (I7I4<>3) AND (I7I4<>8))
    OR (GROUP5 AND ( (I7I4>7) AND (I7I4<l1) OR (I7I4 = 13)))
    SHIFT = (GROUP2 AND (I7I4<<14))
                        OR (GROUP4 AND (I7I4<>1) AND (I7I4<>4) AND (I7I4<>5))
                        OR (GROUP5 AND ((I7I4=7) OR (I7I4 = 13)))
F
    GIVEN WHETHER SHIFT AND/OR CARRY ARE USED, FIND THE WORST CASE DELAY
    (IN INCREMENTS OF 5 NS) IF REGISTER FILE READ, ZERO TEST AND/OR N TEST
        ALSO OCCUR
FOR RF = 0 TO -1 STEP -1
FOR Z = 0 TO -1 STEP -1
    SOLVE PROPAGATION dELAY USING 'AS888 dATA SHEET; ROUND UP TO NEAREST
    5 NS INCREMENT
IF NOT CARRY AND NOT SHIFT THEN TIME = 50
IF NOT CARRY AND SHIFT AND NOT RF AND }
```



148
149

Program 5-1. BASIC Program to Generate PROM Data


Program 5-1. BASIC Program to Generate PROM Data (Continued)
\$A0000.01,02,02,02,03,04,04,04,07,08,08.08,04,05,06,06 $\$ A 0010.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0020.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ 40030.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0040.00,00,00,00,00,00,00,00,07,08,08,08,04,05,06,06$ $\$ A 0050.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0060.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ 40070.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00$ $\$ A 0080.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06$ $\$ 40090.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ \$A00A0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 $\$ A 00 \mathrm{~B} 0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 00 C 0.00,00,00,00,00,00,00,00,07,08,08,08,04,05,06,06$ \$AOODO.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$AOOE $0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 00 F 0.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00$ $\$ A 0100.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0110.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0120.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0130.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0140.00,00,00,00,00,00,00,00,07,08,08,08,04,05,06,06$ $\$ A 0150.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0160.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ 40170.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00$ \$A0180.01,02,02,02,03,04,04,04,07,08,08,08,04,05,06,06 \$A0190.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 $\$ A 01 A 0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 01 B 0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ \$AOIC0.00.00,00,00,00.00,00.00,07.08,08.08,04,05.06,06 \$A01D0.07,08,08.08,04,05,06,06,07,08,08.08,04,05,06.06 \$A01E0.07,08,08,08,04,05,06,06.07,08,08,08,04,05,06,06 \$AOIF0.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00 $\$ A 0200.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06$ $\$ A 0210.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ \$A0220.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 $\$ A 0230.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0240.03,03,04.04,01,01,02,02,07,08,08,08,04,05,06,06$ $\$ 40250.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ 40260.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ 40270.07,08,08,08,04,05,06,06,00,00,00,00,00,00.00,00$ $\$ A 0280.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06$ $\$ 40290.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ \$A02AO.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$A02B0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$A02C0.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06 \$A02D0.07,08,08.08,04,05,06,06,07,08,08,08,04,05,06,06 \$A02E0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$A02F0.07,08,08,08,04,05,06,06,00,00,00,00,00,00.00,00 \$A0300.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 $\$ A 0310.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0320.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ \$A0330.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 $\$ A 0340.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06$ $\$ A 0350.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0360.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0370.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00$ \$A0 $380.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06$ $\$ A 0390.07,08,08,08,04,05,06,06,07,08,08.08,04,05,06,06$ \$A03A0.07,08,08,08,04,05,06,06,07,08,08,08.04,05,06,06 \$A03B0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$A03C0.03,03,04,04,01,01,02,02,07,08,08,08,04,05,06,06 \$A03D0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$A03E0.07,08,08,08,04,05,06,06,07,08,08,08,04,05,06,06 \$AOSF0.07,08,08,08,04,05,06,06,01,02,02,02,03,04,04,04
\$A0400.01,02,02,02,03.04,04,04,01,02,02,02,03,04,04.04 \$A0410.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0420.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0430.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0440.03,03,04,04,01,01,02,02,01,02,02,02,03,04,04,04 AO450.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0460.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0470.01,02,02,02,03,04,04,04,03,03,04,04,01,01,02,02 $\$ A 0480.07,08,08,08,04,05,06,06.01,02,02,02,03,04,04,04$ $\$ A 0490.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ \$AO4AO.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 $\$$ AO4B0.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 SAO4C0.03,03,04,04,01,01,02,02,01,02,02,02,03,04,04,04 \$A04D0.01,02.02,02,03,04,04,04,01,02,02,02,03,04,04.04 AO4EO.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A04F0.01,02,02,02,03,04,04,04,03,03,04,04,01,01,02,02 \$A0500.07,08,08,08,04,05,06,06,01,02,02,02,03,04,04,04 $\$ 40510.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ \$A0520.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0530.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A0540.03,03,04,04,01,01,02,02,01,02,02,02,03,04,04,04 $\$ A 0550.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ $\$ A 0560.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ \$A0570.01,02.02,02,03,04,04,04,03,03,04,04,01,01,02,02 \$A0580.07,08,08,08,04,05,06,06,01,02,02,02,03.04,04.04 \$A0590.01,02,02,02,03,04;04,04,01,02,02,02,03,04,04,04 \$A05AO.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A05B0.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 $\$ A 05 C 0.03,03,04,04,01,01,02,02,01,02,02,02,03,04,04,04$ \$A05D0.01.02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A05E0.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A05F0.01, 02, 02,02,03,04,04,04,00,00,00,00,00,00,00,00 $\$ A 0600.07,08,08,08,04,05,06,06,01,02,02,02,03,04,04,04$ $\$ 40610.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ SAO620.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 $\$ A 0630.01,02.02,02,03,04,04,04,01,02,02,02.03,04,04,04$ \$A0640.03,03,04,04,01,01,02,02,01,02,02.02.03,04,04,04 $\$ A 0650.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ $\$ A 0660.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ $\$ A 0670.01 .02,02,02,03,04,04,04,00,00,00,00,00,00,00,00$ $\$ A 0680.07,08,08,08,04,05,06,06,01,02,02,02,03,04,04,04$ \$A0690.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A06AO.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 $\$ A 06 B 0.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04$ \$A05C0.00,00,00,00,00,00,00,00,01,02,02,02,03,04,04,04 \$A06E0.01,02,02,02,03,04,04,04,01,02,02,02,03,04,04,04 \$A06F $0.01,02,02,02,03,04,04,04,07,08,08,08,04,05,06,06$ $\$ A 0700.07,08,08,08,04,05,06,06,00,00,00,00,00,00,00,00$ $\$ A 0710.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 0720.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 0730.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 0740.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 0750.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 0760.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ 40770.00,00.00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ 40780.07,08,08,08,04,05,06,06,00,00.00 .00,00,00,00,00$ $\$ 20790.00,00,00.00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ A 07 A 0.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$$ AO7BO. $00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ \$A07C0.00,00,00,00, 00,00,00,00,00,00,00,00,00,00,00,00 \$A07D0. $00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ 407 E 0.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$ $\$ 407 F 0.00,00,00,00,00,00,00,00,00,00,00,00,00,00,00,00$

Figure 5-7. PROM Data

## Section 6

## Floating-Point System Design Using the 'AS888/'AS890

Bit-slice processor architecture addresses the problem of optimizing system performance while allowing the user to balance hardware complexity against software flexibility. Bit-slice systems usually operate at or near the speed of the most primitive of programmable processors, the PROM state sequencer. Of course, bit-slice architecture incorporates circuitry dedicated not only to sequencing, but also data processing (ALU) operations. In keeping with the trend of these programmable devices to track the speed of fast discrete hardware, the 'AS888 8-bit slice ALU and 'AS890 microsequencer have been produced in Advanced Schottky bipolar technology. In addition to sheer speed, the components feature greater density ( 2 micron geometry) for greater functionality (more special purpose circuitry on board). The impact will be faster, more powerful systems in applications which previously pushed the limits of bit-slice processors.

Consider an application in which bit-slice architecture has dominated for years: CPU design. The microprogrammed CPU itself spans a spectrum of uses ranging from general purpose minicomputers to compact airborne computers. A specific example which illustrates various facets of design using the 'AS888 and 'AS890 is a CPU with a floating-point utility to compute $\sin (x)$.

The design process can be subject to many influences, including personal preference, available development tools, peculiarities of the application, and constraints from the user, customer or manufacturing environment. No hard and fast design rules could be applied universally, but most designers will start with a specific plan in mind.

The goal of this example is to produce the hardware and microprogram which will implement the $\sin (x)$ function in floating-point arithmetic. Before the microprogram can be assembled, the hardware must be defined since the fields of
the microinstruction are dedicated to specific hardware once the microinstruction register is hardwired to the devices it controls. Since the final architecture chosen depends on tradeoffs between implementing certain operations in hardware or software, critical applications will require that a cursory analysis of the software be made before the hardware is cast in concrete. Attempting to develop microcode for a tentative architecture will force the issue on which operations are better suited for hardware. Before the architecture or the microprogram requirements can be known, the algorithms which describe the application processes must be defined. Once an algorithm is formulated it can be broken down into operations involving variable and constant quantities. The variables can be assigned to registers and then the algorithm can be translated into a microprogram. The following steps illustrate the plan for this CPU design example incorporating a floating-point $\sin (x)$ utility:

Step 1: Choose a floating-point number system
Step 2: Choose an algorithm for approximating $\sin (x)$
Step 3: Make 'AS888 register assignments
Step 4: Substitute registers for variables in the algorithm
Step 5: Decompose steps of the algorithm into simple operations
Step 6: Translate into 'AS888/890 operations; identify subroutines
Step 7: Expand subroutines into 'AS888/890 operations
Step 8: Evaluate trade-offs and block diagram the hardware
Step 9: Define microinstruction fields during detailed hardware design
Step 10: Assemble the microprogram

## STEP 1: CHOOSE A FLOATING-POINT NUMBER SYSTEM

An IEEE floating-point format will be chosen for this example for portability of data and software. It is important to note that the IEEE defines many standards in arithmetic processing, but for simplicity this example will encompass only number format. Furthermore, while several formats are IEEE compatible, only the basic single-precision format will be considered.

The IEEE basic single-precision format is defined as a 32 -bit representation in which the component fields are a 1-bit $\operatorname{sign} s$, an 8-bit biased exponent $e$ and a 23-bit fraction $f$ which are assembled in the following order:


The quantity is evaluated as $(-1)^{s} 2^{e}-127(1 . f)$. Not-a-number, zero and infinity have special representations. The one preceding the binary point is implied and is called the implicit one or implicit bit. It coincides with the fact that the digits are normalized (left justified).

## STEP 2: CHOOSE AN ALGORITHM FOR $\operatorname{Sin}(x)$

Many algorithms are discussed in the literature for approximating useful quantities like $\sin (x)$. Literature research is a good place to start to familiarize oneself with various algorithms and trade-offs for a particular application. Computer simulation is also useful to compare algorithms for speed and accuracy. R.F. Ruckdeschel in BASIC Scientific Subroutines, Vol. 1 (BYTE, McGraw-Hill Publications Co., New York, N.Y., 1981, pp. 159-191) discusses trade-offs and provides a simulation in BASIC for a $\sin (x)$ algorithm. An adaptation of this material has been chosen for this example:
A) Reduce angle range to first quadrant. $(0 \leq x \leq \pi / 2)$
B) Compute $\sin (\mathrm{x}) \simeq \sum_{\mathrm{n}=0}^{6} \mathrm{~A}_{\mathrm{n}} \mathrm{x}^{2 \mathrm{n}-1}$. The coefficients are:

| Coefficient | Decimal | IEEE hex |
| :---: | :---: | :--- |
| $\mathrm{A}_{0}$ | 1.000000 | 3F80 0000 |
| $\mathrm{A}_{1}$ | -0.1666667 | BE2A AAAD |
| $\mathrm{A}_{2}$ | 0.008333333 | 3C08 8888 |
| $\mathrm{A}_{3}$ | -0.0001984127 | B950 0D01 |
| $\mathrm{A}_{4}$ | 0.000002755760 | 3638 EF99 |
| $\mathrm{A}_{5}$ | -0.00000002507060 | B2D7 5AD5 |
| $\mathrm{A}_{6}$ | 0.0000000001641060 | 2F34 6FBC |

The algorithm can be implemented in the following steps:
A) Reduce angle range to first quadrant. ( $0 \leq \mathrm{x} \leq \pi / 2$ )

1) $\operatorname{SIGN}=\operatorname{SGN}(x)$
2) $\operatorname{ABSX}=\|x\|$
3) $\mathrm{XNEW}=\mathrm{ABSX}-2 \pi \times \operatorname{INT}(\mathrm{ABSX} / 2 \pi)$
4) If XNEW $>\pi$ then SIGN $=-$ SIGN and XNEW $=$ XNEW $-\pi$
5) If XNEW $>\pi / 2$ then XNEW $=\pi-$ XNEW
where

$$
\operatorname{SGN}(x)=\left\{\begin{array}{l}
+1 \text { if } x \geq 0 \\
-1 \text { if } x<0
\end{array}\right.
$$

$\operatorname{INT}(x)=$ integer function
B) Compute $\sin (\mathrm{x}) \simeq \sum_{\mathrm{n}=0}^{6} \mathrm{~A}_{\mathrm{n}} \mathrm{x}^{2 \mathrm{n}-1}$.

1) Let $\mathrm{XSQR}=\mathrm{XNEW} 2$; INITIALIZE $\operatorname{SINX}=0$
2) Do $i=6$ to 1 step -1
$\operatorname{SINX}=\mathrm{XSQR} \times \operatorname{SINX}+\mathrm{A}(\mathrm{i})$
Enddo
3) $\operatorname{SINX}=$ SIGN $\times$ XNEW $\times$ SINX

Step B-2 computes the summation in a geometric series for economy. The major difference between steps A and B is that A requires more diverse ALU operations while B uses only multiplication and addition recursively.

## STEP 3: MAKE 'AS888 REGISTER ASSIGNMENTS

Just as in assembly language programming, registers must be allocated for variables. Using Rn to denote the 'AS888 register whose address is n , where $0 \leq \mathrm{n} \leq \mathrm{F}$ (hex), the following register assignments can be made:

$$
\begin{aligned}
& \mathrm{R} 0=\mathrm{X} \\
& \mathrm{R} 1=\mathrm{SIGN} \\
& \mathrm{R} 2=\mathrm{ABSX} \\
& \mathrm{R} 3=\mathrm{XNEW} \\
& \mathrm{R} 4=\mathrm{XSQR} \\
& \mathrm{R} 5=\mathrm{SINX}
\end{aligned}
$$

The following constants can also be defined:

| $\quad$ Constant | Decimal | IEEE hex |
| :--- | ---: | :--- |
| PI $=\pi$ | 3.141593 | 4059 OFDB |
| PIOVR2 $=\pi / 2$ | 1.570797 | 3FC9 OFDB |
| 2PI $=2 \pi$ | 6.283185 | 40C9 0FDB |
| 1OVR2PI $=1 / 2 \pi$ | 0.159155 | 3E22 F981 |

## STEP 4: SUBSTITUTE REGISTERS FOR VARIABLES IN THE ALGORITHM

Now the algorithm can be rewritten with registers replacing variables:
A) Reduce angle range to first quadrant $(0 \leq \mathrm{x} \leq \pi / 2)$.

1) $\mathrm{R} 1=\operatorname{SGN}(\mathrm{RO})$
2) $R 2=\|R 0\|$
3) $\mathrm{R} 3=\mathrm{R} 2-2 \pi \times \operatorname{INT}(\mathrm{R} 2 / 2 \pi)$
4) If R3> $\pi$ then R1 $=-\mathrm{R} 1$; R3 $=\mathrm{R} 3-\pi$
5) If R3 $>\pi / 2$ then $\mathrm{R} 3=\pi-\mathrm{R} 3$
B) Compute $\sin (x)=\sum_{n=0}^{6} A_{n} x^{2 n-1}$.
6) Let $\mathrm{R} 4=\mathrm{R} 0^{2}$; INITIALIZE R5 $=0$
7) Do $i=6$ to 1 step -1 $\mathrm{R} 5=\mathrm{R} 4 \times \mathrm{R} 5+\mathrm{A}(\mathrm{i})$
Enddo
8) $\mathrm{R} 5=\mathrm{R} 1 \times \mathrm{R} 0 \times \mathrm{R} 5$

Since various references to constants are made, it is probably best to load constants as needed rather than attempt to allocate registers for them. Constants can be loaded from a constant field in the microinstruction or from ROM. The trade-off is 32 bits by 16 K of micromemory versus 32 bits by the number of constants (typically less than 16 K ). For this example, it will be assumed that a constant field in the microinstruction is acceptable.

## STEP 5: DECOMPOSE STEPS IN THE ALGORITHM INTO SIMPLE OPERATIONS

The $\sin (x)$ function can be microprogrammed as a subroutine; let FSIN be its entry address. R0 would be loaded with $x$ before FSIN was called. Upon return, R5 would contain $\sin (x)$. Now decompose the steps in the algorithm into simple arithmetic and logical operations. Other operations can be left as functions to be defined later.

FSIN: SUBROUTINE
; A) Reduce angle range to first quadrant. ( $0 \leq x \leq \pi / 2$ )

| $\mathrm{R} 1=\mathrm{SGN}(\mathrm{R} 0)$ | ; 1) Let R1 = Sign of R0 |
| :---: | :---: |
| $\mathrm{R} 2=\mathrm{ABS}(\mathrm{R} 0)$ | 2) $\mathrm{R} 2=\\|\mathrm{R} 0\\|$ |
| $\mathrm{R} 3=\mathrm{R} 2 * 10 \mathrm{VR} 2 \mathrm{PI}$ | ; 3) $\mathrm{R} 3=\mathrm{R} 2-2 \pi * \operatorname{INT}(\mathrm{R} 2 / 2 \pi)$ |
| $\mathrm{R} 3=\mathrm{INT}(\mathrm{R} 3)$ | ; |
| $\mathrm{R} 3=\mathrm{R} 3 * 2 \mathrm{PI}$ | ; |
| $\mathrm{R} 3=\mathrm{R} 2-\mathrm{R} 3$ | ; |
| $\mathrm{Y}=\mathrm{R} 3-\mathrm{PI}$ | 4) If R3 $>\pi$, |
| Jump if Negative to Step A-5 | ; |
| $\mathrm{R1}=-\mathrm{Rl}$ | ; then $\mathrm{R} 1=-\mathrm{RI}$; |
| $\mathrm{R} 3=\mathrm{R} 3-\mathrm{PI}$ | ; $\mathrm{R} 3=\mathrm{R} 3-\pi$ |
| $\mathrm{Y}=\mathrm{PIOVR2}-\mathrm{R} 3$ | ; |
| Jump if Negative to Step B-1 | ; 5) If R3 $>\pi / 2$ |
| $\mathrm{R} 3=\mathrm{PI}-\mathrm{R} 3$ | ; then $\mathrm{R} 3=\pi-\mathrm{R} 3$ |

; B) Compute $\sin (x)=\sum_{n=0}^{6} A_{n} x^{2 n-1}$

```
R4 = R0 * R0 ; 1) Let R4 = R02. Let R5 = 0
R5 = 0
R5 = R4*R5 ; 2) Do i=6 to 1 step -1
R5 = R5 + A6
    R5 = R4 × R5 + A(i)
R5 = R4 * R5
    Enddo
R5 = R5 + A5
R5 = R4 * R5
R5 = R5 + A4
R5 = R4*R5
R5 = R5 + A3
R5 = R4*R5
R5 = R5 + A2
R5 = R4 * R5
R5 = R5 + Al
R5 = R4 * R5
R5 = R5 + A0
R5 = R0 * R5 ; 3) R5 = R1 }\times\textrm{R}0\times\textrm{R}
R5 = R5 * R1:RETURN ;
```


## END SUBROUTINE

## STEP 6: TRANSLATE INTO 'AS888/890 INSTRUCTIONS; IDENTIFY SUBROUTINES

The simplified steps of the algorithm can be represented fairly easily as 'AS888/890 instructions. Necessary functions (and suggested names) can be identified by inspection as:

1) FMUL - Floating-point multiplication
2) FADD - Floating-point addition
3) FINT - Floating-point integer conversion
4) FINV - Floating-point additive inverse (to subtract using FADD)
5) FABS - Floating-point absolute value
6) FSGN - Floating-point sign test
7) FCHS - Floating-point change of sign (to multiply by SIGN)
"Function" in this context refers to a special operation regardless of how it is coded. In fact, FMUL and FADD are fairly complex and require detailed explanation. FINV, FABS, FSGN and FCHS are single instruction operations that mask or mask and test. FINT requires several inline instructions or a subroutine and will be left to the interested reader as an exercise. Now the steps of the algorithm can be translated into 'AS888/890 operations which include references to these functions.

FSIN: SUBROUTINE

```
; A) Reduce angle range to first quadrant. (0\leqx\leqm/2)
    R1 = FSGN(R0) ; Get sign bit (MSB)
    R2 = FABS(R0) ; Take absolute value (clear MSB)
    R3 = FMUL(R2.1OVR2PI) ; Multiply register and constant
    R3 = FINT(R3) ; Floating-point integer conversion
    R3 = FMUL(R3,2PI) ; Multiply register and constant
    R3 = FADD(R2,INV(R3)) ; Subtract registers by adding inverse
    Y = FADD(R3,NEGPI) : TEST NEG ; Subtract by adding negative constant
    JT SIN1 ; Jump if true (jump if negative)
    R1 = FINV(R1) ; Complement sign of R1
    R3 = FADD(R3,NEGPI) ; Subtract by adding negative constant
SIN1:Y = PIOVR2 - R3 : TEST NEG ; Subtract to compare (don't store)
JT SIN2 ; Jump if true (jump if negative)
R3 = FADD(PI,FINV(R3)) ; Subtract by adding negative register
```

$$
\begin{aligned}
& \text {; B) Compute } \sin (x) \simeq \sum_{n=0}^{6} A_{n} X^{2 n-1} \\
& \text { SIN2: R4 }=\text { FMUL(R0,R0) ; Square by multiplying } \\
& \text { R5 }=\mathrm{A} 6 \\
& \mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5) \\
& \text {; Initialize series } \\
& \mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 5) \\
& \text {; Multiply registers } \\
& \mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5) \\
& \text {; Add coefficient } \\
& \mathrm{R} 5=\mathrm{FÁDD}(\mathrm{R} 5, \mathrm{~A} 4) \\
& \text {; Multiply registers } \\
& \text {; Add coefficient } \\
& \mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5) \\
& \text {; Multiply registers } \\
& \mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 3) \\
& \text {; Add coefficient } \\
& \mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5) \\
& \text {; Multiply registers } \\
& \mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 2) \\
& \text {; Add coefficient } \\
& \mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5) \\
& \text {; Multiply registers } \\
& \mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 1) \\
& \text {; Add coefficient } \\
& \text { R5 }=\text { FMUL(R4,R5) } \\
& \text {; Multiply registers } \\
& \mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 0) \\
& \text {; Add coefficient } \\
& \text { R5 }=\text { FMUL(R0,R5) } \\
& \text {; Multiply registers } \\
& \text { R5 }=\mathrm{FCHS}(\mathrm{R} 5, \mathrm{R} 1): \text { RETURN } \\
& \text {; Change MSB of R5 to MSB of R1 }
\end{aligned}
$$

## END SUBROUTINE

This contrived language has a syntax which may be suitable for a source program. For the sake of illustration, it can be assumed that the microassembler recognizes this particular syntax. The series was computed inline instead of using a loop since it is relatively short. If a loop were used, a means of indexing the constants would be required.

## STEP 7: EXPAND SUBROUTINES INTO 'AS888/890 OPERATIONS

FMUL and FADD algorithms can now be expanded. Since they are called extensively from FSIN, they are more critical to the efficiency of the final design. Wherever possible, it is desirable to reduce the execution time of both in order to maintain efficiency.

## Floating-Point Multiplication

Let M1 be the multiplier and M2 be the multiplicand whose product is P. Let the sign, exponent and fraction fields of their IEEE representation be:

```
M1: |S1|E1|F1|
M2 : |S2|E2|F2|
    P : |S3|E3|F3|
```

$P$ is found by multiplying mantissas (fraction plus implicit one) and adding exponents. Since M1 and M2 are normalized, the range of $1 . F 1 \times 1 . F 2$ is

$$
1.00 \ldots 0 \leq 1 . \mathrm{F} 1 \times 1 . \mathrm{F} 2 \leq 11.1 \ldots 10
$$

The implicit bit may "overflow" into bit position 24. This type of overflow must be detected so that the result can be normalized. Normalization requires right shifting the result of 1.F1 $\times 1 . \mathrm{F} 2$ and incrementing E3. The implicit bit is then cleared when S3, E3 and M3 are packed to form P. The floating-point multiplication algorithm may then be defined as follows:

1) Unpack M1 into signed fraction (SF1) and exponent (E1)
2) Set the implicit bit in SFl
3) Unpack M2 into signed fraction (SF2) and exponent (E2)
4) Set the implicit bit in SF2
5) Perform $\mathrm{SF} 3=\mathrm{SF} 1 \times \mathrm{SF} 2$ using signed integer multiplication
6) Perform $\mathrm{E} 3=\mathrm{E} 1+\mathrm{E} 2$
7) Test SF3 for overflow into bit 24
8) If true, then increment E3 and right shift SF3
9) Clear the implicit bit in SF3
10) Pack E3 and SF3 to get $P$

As before, the steps of this algorithm can be broken down into simpler operations:

1) Unpack M1 into signed fraction (SFl) and exponent (El)
$\mathrm{E} 1=\mathrm{FEXP}(\mathrm{M} 1)$
$\mathrm{SF} 1=\mathrm{FRAC}(\mathrm{M} 1)$
2) Set the implicit bit in SF1
$\mathrm{SF} 1=\mathrm{SF} 1$ OR BIT23
3) Unpack M2 into signed fraction (SF2) and exponent (E2)
$\mathrm{E} 2=\mathrm{FEXP}(\mathrm{M} 2)$
$\mathrm{SF} 2=\mathrm{FRAC}(\mathrm{M} 2)$
4) Set the implicit bit in SF2
$\mathrm{SF} 2=\mathrm{SF} 2$ OR BIT23
5) Perform SF3 $=\mathrm{SF} 1 \times \mathrm{SF} 2$ using signed integer multiplication $\mathrm{SF} 3=\mathrm{IMUL}(\mathrm{SF} 1, \mathrm{SF} 2)$
6) Perform E3 = E1 + E2 $\mathrm{E} 3=\mathrm{E} 1+\mathrm{E} 2$
7) Test SF3 for overflow into bit 24

TEST (SF3 AND BIT24)
JUMP IF FALSE to step 9
8) If true, then increment E3 and right shift SF3

INC E3
SF3 $=$ RSHFT (SF3)
9) Clear the implicit bit in SF3. SF3 $=$ SF3 AND NOT_BIT23
10) Pack E3 and SF3 to get $P$ P = SF3 OR E3

FEXP, FRAC, testing bit 24 and setting/clearing bit 23 are all mask operations that translate into single 'AS888 instructions. The integer multiplication (IMUL) is simply the multiplication algorithm supported by the 'AS888 instruction set. No significant hardware features are required to do floating-point multiplication, nor are any subroutines required to support it.

Register assignments can now be made as before. Since FSIN uses registers in the lower half of the register file, it might be preferable to restrict FMUL to the upper registers. For example:

$$
\begin{aligned}
& \mathrm{RF}=\mathrm{P} \\
& \mathrm{RE}=\mathrm{M} 1, \mathrm{~F} 1, \mathrm{SF} 1 \\
& \mathrm{RD}=\mathrm{M} 2, \mathrm{~F} 2, \mathrm{SF} 2 \\
& \mathrm{RC}=\mathrm{E} 1 \\
& \mathrm{RB}=\mathrm{E} 2
\end{aligned}
$$

RE and RD can share variables that need not be preserved. Using this assignment, FMUL computes RF = FMUL(RE,RD). RE and RD must be loaded prior to calling FMUL and RF must be stored upon return. By substituting registers for variables and reorganizing operations in the FMUL algorithm to better fit 'AS888/890 operations the following source program may be created:

FMUL: SUBROUTINE

$$
\begin{array}{ll}
\mathrm{RC}=\mathrm{FEXP}(\mathrm{RE}) & \text {; Unpack M1 into exponent } \\
\mathrm{RE}=\mathrm{FRAC}(\mathrm{RE}) & \text {; and fraction } \\
\mathrm{RE}=\mathrm{RE} O R \text { BIT23 } & \text {; Set implicit bit } \\
M Q=\operatorname{SMTC}(\mathrm{RE}) & \text {; Prepare to multiply } \\
\mathrm{RB}=\mathrm{FEXP}(\mathrm{RD}) & \text {; Unpack M2 into exponent } \\
\mathrm{RD}=\text { FMAG(RD) } & \text {; and fraction } \\
\mathrm{RD}=\mathrm{RD} \text { OR BIT23 } & \text {; Set implicit bit } \\
\mathrm{RD}=\text { SMTC(RD) } & \text {;Prepare to multiply }
\end{array}
$$

```
    RE = 0: RCA = #22d ; Initialize to multiply
    RE = SMULI RD : LOOP RCA ; Integer multiplication iteration
    RE = SMULT RD ; Final step in signed multiply
    Y= TB0(RE,BIT1):BYTE = #0100b:TEST Z ; Test 'overflow'
    JF FMULI ; Jump if false (exponent ok)
    INEX(RC) ; Increment exponent: add 00800000
    RE = SRA(RE) ; Shift fraction to normalize
FMULI:RC = RC + RB : TEST CARRY ; Add exponents and test carry
JT ERROR ; Jump if carry true to handler
RE = SMTC(RE) ; Get sign magnitude fraction
RE = RE AND # 807F_FFFFh ; Clear implicit bit
RF = RE OR RC : RETURN ; Pack fraction and exponent
```


## Floating-Point Addition

The floating-point addition algorithm (FADD) is slightly more complex than FMUL, since the two addends will usually not have the same exponent. Therefore the smaller (absolute value) addend must first be chosen by comparing exponents. Then it must be denormalized to align its digits with the digits of the larger addend. In other words, the two addends must have the same exponent before their fractions can be added. This process can be described by the following algorithm:

1) Unpack A1 to get SF 1 and El
2) Set implicit bit in SF 1
3) Unpack A2 to get SF2 and E2
4) Set implicit bit in SF2
5) If $\mathrm{E} 2>\mathrm{E} 1$ then go to step 9 $(\|\mathrm{A} 1\| \leq\|\mathrm{A} 2\|)$
6) Let DIFF $=\mathrm{E} 1-\mathrm{E} 2$
7) Do i $=1$ to DIFF SF2 $=$ RSHFT(SF2) (Arithmetic right shift) Enddo
8) Let E3 = E1, go to step 12
$(\|A 2\|>\|A 1\|)$
9) Let DIFF = E2 - E1
10) Do $\mathrm{i}=1$ to DIFF
$\mathrm{SFl}=\mathrm{RSHFT}(\mathrm{SF} 1)$ (Arithmetic right shift)
Enddo
11) Let E3 $=\mathrm{E} 2$
12) $\mathrm{SF} 3=\mathrm{SF} 1+\mathrm{SF} 2$
13) Test "overflow'" into bit 24
14) Jump if false to step 17
15) Increment exponent E3
16) Normalize signed fraction with right arithmetic shift
17) Clear implicit bit
18) Pack: SUM $=$ SF3 or E3
19) Return

Register assignments for variables must now be made. Since FSIN uses registers in the lower half of the 'AS888 register file, it is necessary to use the upper registers:

```
RF=SUM
RE = A1, F1,SF1
RD = A2, F2,SF2
RC=El
RB = E2
```

By slightly reorganizing the sequence to better fit 'AS888/890 operations, the following microprogram to perform FADD can be created:

FADD: SUBROUTINE
; 1) Unpack A1 to get SF1 and E1
RC $=$ FEXP(RE)
$\mathrm{RC}=\mathrm{FEXP}(\mathrm{RE}) \quad$; Get exponent (E1)
$\mathrm{RE}=\mathrm{FRAC}(\mathrm{RE}) \quad$; Get signed fraction (SF1)
; 2) Set implicit bit in SF1
$\mathrm{MQ}=$ RE OR BIT23 ; Set implicit bit
$R E=\operatorname{SMTC}(\mathrm{RE}) \quad$; Convert to two's complement
; 3) Unpack A2 to get SF2 and A2
$\mathrm{RB}=\mathrm{FEXP}(\mathrm{RD}) \quad$; Get exponent $(\mathrm{E} 2)$
$R D=\operatorname{FRAC}(R D) \quad$; Get signed fraction (SF2)
; 4) Set implicit bit in SF2
RD $=$ RD OR BIT23 ; Set implicit bit
RD $=$ SMTC $($ RD $) \quad$; Convert to two's complement
; 5) If E2 $>$ E1 then go to step 9
RF $=\mathrm{RC}-\mathrm{RB}:$ TEST NEGATIVE ; Compare A2 from A1
JT FADD1 : RCA $=\# 8$; Jump if E2 $>$ E1; set up loop count
; 6) Let DIFF = E1 - E2.
$\mathrm{Y} / \mathrm{RF}=\mathrm{SLC}(\mathrm{RF}):$ LOOP RCA ; Rotate 8 times to get difference
$\mathrm{RCA}=\mathrm{Y} / \mathrm{RF} \quad$; Load difference in loop counter
: 7) Do $\mathrm{i}=1$ to DIFF
; ${ }^{\prime} \quad \mathrm{SF} 2=\operatorname{RSHFT}(\mathrm{SF} 2)$
; Enddo
RD $=\operatorname{SRA}(R D):$ LOOP RCA ; Orient digits of smaller addend
; 8) Let $\mathrm{E} 3=\mathrm{E} 1$, go to step 12
RB $=$ RC : JUMP FADD2 ; Swap registers and branch
; 9) Let DIFF = E2 - E1
FADD1: RF $=\operatorname{NOT}(\mathrm{RF}) \quad$ : Complement result of E1 - E2
$\mathrm{Y} / \mathrm{RF}=\operatorname{SLC}(\mathrm{RF}):$ LOOP RCA ; Shift 8 times to get DIFF
RCA $=\mathrm{Y} / \mathrm{RF}$; Load DIFF in loop counter
;10) Do i $=1$ TO DIFF
; $\quad \mathrm{SFl}=\operatorname{RSHFT}(\mathrm{SFl})$
; Enddo
RE $=\operatorname{SRA}($ RE $):$ LOOP RCA ; Align SF1 with SF2
;11) Let $\mathrm{E} 3=\mathrm{E} 2$ (no instruction required -RB already has E 2 in it)
;12) $\mathrm{SF} 3=\mathrm{SF} 1+\mathrm{SF} 2$
FADD2: RF $=$ RD + RE ; Add
RF $=\operatorname{SMTC}(\mathrm{RF})$. ; Convert to sign-magnitude
;13) Test "overflow" into bit 24
$\mathrm{RF}=\mathrm{TB} 0(\mathrm{RF}$, BIT24) ; Check for normalization
;14) Jump if false to step 17
JF FADD3 ; If so, finish and exit
;15) Else increment exponent
INC RB : TEST NEG ; Test for exponent overflow
;16) Normalize signed fraction
$R F=\operatorname{SRA}(R F):$ JT ERROR ; Jump to error handler if overflow
;17) Clear implicit bit
FADD3: RF $=$ SET0 (RF, BIT23)
; Reset bit 23 of RF
;18) Pack: SUM = SF3 OR E3

$$
R F=R F \text { OR RB }: \text { RETURN } \quad \text {; OR signed fraction and exponent } .
$$

There is an important consequence of FADD which impacts the hardware. Since the number of shifts required to denormalize the small addend is data dependent (computed in the ALU), it is necessary to provide a path between the ALU Y bus and the 'AS890 DRA bus. All the other operations are simple 'AS888/890 instructions, including the FRAC and FEXP mask operations discussed during the development of FMUL. ERROR is a floating-point overflow error handler.

## STEP 8: EVALUATE TRADE-OFFS AND BLOCK DIAGRAM THE HARDWARE

A rough estimate of the FSIN worst case execution time can be arrived at by making the following observations about FSIN, FMUL and FADD:

FMUL
integer recursion $=22$ cycles
other instructions $\simeq 18$ cycles
total $\simeq 40$ cycles
FADD
denormalization $\simeq 23$ cycles
other instructions $\simeq 25$ cycles
total $=50$ cycles
FSIN
number of calls to $\mathrm{FMUL}=12$
number of calls to FADD $=11$
number of other cycles $\simeq 10$
Approximate worst case total $=10+(12 \times 40)+(11 \times 50)=1040$ cycles. At 50 nanoseconds per cycle, this requires approximately 52 microseconds. There are few improvements that could be made in hardware to speed this time, except perhaps the addition of a flash multiplier which would reduce the integer computation by about 20 cycles (an overall reduction of about two percent). A barrel shifter could have the same benefit during floating-point addition for a total reduction of about 4 percent. For the sake of simplicity, it will be assumed that 52 microseconds is acceptable for the $\sin (x)$ computation.

Another issue which must be considered is the problem of loading the 'AS888 and 'AS890 with constants. A slight materials cost reduction might be realized by storing constants in table PROMs rather than in control store memory. An interesting use of the DRA and DRB ports on the 'AS890 would be to use the output of RCA or RCB to index data in the constant PROM. This would allow long series to be implemented in loop form rather than the inline method used in FSIN. Once again, the constant PROM will not be implemented for the sake of simplicity.

Now the architecture can be designed to meet the requirements identified throughout this analysis:

1) A path between the 'AS888 Y bus and the 'AS890 DRA bus.
2) A path between the microinstruction register and the 'AS890 DRA bus for loading loop counts and branch addresses.
3) A path between the microinstruction register and the 'AS888 Y bus for loading constants.
4) Independent control of $\overline{\text { SIOO }}$ in each 'AS888 slice to allow bit/byte instructions.
5) A status register to store 'AS888 status for testing.
6) A status mux to test the 'AS888 status, bit 23 of the 'AS888 Y bus, bit 24 of the 'AS888 Y bus and hardwired 0 and 1.

A system having these features is illustrated in Figure 6-1.

## STEP 9: DEFINE MICROINSTRUCTION FIELDS DURING DETAILED HARDWARE DESIGN

The detailed hardware design will produce a wiring diagram that fixes the position within the microinstruction of each of the various control signals that are connected from the microinstruction register to the 'AS888, 'AS890, status mux and any other special hardware. Once this design is complete it is possible for the assembler to sort the control bits of each instruction properly so that they will be properly oriented when the microprogram is installed in the target system.

## STEP 10: ASSEMBLE THE MICROPROGRAM

TI is currently developing an 'AS888/890 microassembler. Several microassemblers are commercially available, and many users prefer to write their own. The microprogram shown in Table 6-1 was hand-assembled, but has a syntax that is suitable for interpretation by a user-written assembler.


Figure 6-1. Block Diagram of Floating-Point Processor

Table 6.1. Floating Point $\operatorname{Sin}(x)$ Microprogram

| 0000 SIN : | $\begin{aligned} * & \text { R1 } \end{aligned}=\text { FSGN(RO) }$ |
| :---: | :---: |
|  | * R2 $=$ FABS(R0) |
| 0001 | $\mathrm{R} 2=\mathrm{R} 0$ |
| 0002 | R2 = R0 SET0 \#80h : BYTE = \#1000b |
|  | * R3 = FMUL(R2,10VR2PI) |
| 0003 | $\mathrm{RE}=\mathrm{R} 2$ |
| 0004 | RD $=$ \#3EA2 F984h |
| 0005 | JSR FMUL |
| 0006 | R3 $=$ RF |
|  | * R3 $=$ FINT(R3) |
| 0007 | RF $=$ R3 |
| 0008 | JSR FINT [EXERCISE FOR READER] |
| 0009 | R3 $=$ RF |
|  | * R3 = FMUL(R3,2PI) |
| 000A | $\mathrm{RE}=\mathrm{R} 3$ |
| 000B | RD $=$ \#40C9 OFDBh |
| 000C | JSR FMUL |
| 000D | $\mathrm{R} 3=\mathrm{RF}$ |
|  | * R3 = FADD(R2, $\mathrm{INV}(\mathrm{R} 3)$ ) |
| 000E | $\mathrm{RE}=\mathrm{R} 2$ |
| 000F | RD = R5 XOR \#8000 0000h |
| 0010 | JSR FADD |
| 0011 | $\mathrm{R} 3=\mathrm{RF}$ |
|  | * Y = FADD(R2,NEGPI) |
| 0012 | RE $=$ R2 |
| 0013 | RD = \#C059 OFDBh |
| 0014 | JSR FADD |
| 0015 | $\mathrm{Y}=$ RF: TEST NEG |
| 0016 | JT SIN1. |
|  | - R1 = FINV(R1) |
| 0017 | R1 = R1 XOR \#8000 0000h |
|  | * R3 $=$ FADD(R3,NEGPI) |
| 0018 | $\mathrm{RE}=\mathrm{R} 3$ |
| 0019 | RD $=$ \#C059 OFDBh |
| 001A | JSR FADD |
| 001B | R3 $=$ RF |
| * SIN1: | Y = FADD (PIOVR2,INV(R3) ) : TEST NEG |
| 001C SIN1: | RE = \#3FC9 OFDBh |
| 0010 | $\mathrm{RD}=\mathrm{R} 3 \times \mathrm{XOR} \# 80000000 \mathrm{~h}$ |
| 001 E | JSR FADD |
| 001 F | $Y=$ RF : TEST NEG |
| 0020 | JT SIN2 |
|  | - R3 = FADD(P),FINV(R3)) |
| 0021 | RE $=$ \#4059 0FDBh |
| 0022 | RD $=$ R3 XOR \#8000 0000h |
| 0023 | JSR FADD |
| 0024 | R3 $=$ RF |
| - SIN2: | R4 $=$ FMUL RO, RO) |
| 0025 SIN2: | $\mathrm{RE}=\mathrm{RO}$ |
| 0026 | $\mathrm{RD}=\mathrm{RO}$ |
| 0027 | JSR FMUL |
| 0028 | R4 $=$ RF |


|  | $\begin{gathered} \text { 32-bit } \\ \text { Constant } \end{gathered}$ |  |  | 岗 |
| :---: | :---: | :---: | :---: | :---: |
| $00 \times 10211100 \mathrm{FA}$ | 8000000 | 1111 | $027 \times \times \times 111$ | 7 |
| $00 \times 20 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \mathrm{X}$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| 0028001110018 | $\mathrm{X} \times \times \times \times \times \times \mathrm{X}$ | 11110 | $027 \times \times \times \times 111$ | 7 |
| $02 \times \mathrm{O} \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{CX} 1111 \times \mathrm{F}$ | 3 EA 2 F 984 | 1111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 0 1 4 4000600111 | 7 |
| $0 \mathrm{FX} 30 \times 11100 \mathrm{~F} 6$ | $\mathrm{X} \times \times \times \times \times \times \mathrm{X}$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $03 \times \mathrm{FOX11100F6}$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\mathrm{X} \times \times \times \times \times \times \mathrm{x}$ | 1 111111 | 014. | 7 |
| $0 \mathrm{FX} 30 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| $03 \times E 0 \times 11100 F 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{CXX1110} \mathrm{\times FF}$ | 40 C 90 FDB | 1111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | 11111 |  | 7 |
| $0 \mathrm{FX} 30 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $02 \times \mathrm{COX} 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $05 \times \mathrm{O} 211100 \mathrm{~F} 9$ | 80000000 | 11111 | $027 \times \times \times \times 1111$ | 7 |
| $1 \times \times \times \times 1111 \times \times F$ | $\times \times \times \times \times \times \times$ | 11111 | 014400741111 | 7 |
| $0 \mathrm{FX} 30 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $02 \times \mathrm{EX} 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 111 | $027 \times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{CXX11} 10 \times \mathrm{F}$ | C0590FDB | 11111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | 11111 |  | 7 |
| 1 FXXOX 11000 F | $\times \times \times \times \times \times \times x$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 2 |
| $1 \times \times \times \times \times 111 \times \times F F$ | $\mid x \times \times \times \times \times \times \times$ | 1111 | 0170000111 | 7 |
| $01 \times 10211100 \mathrm{~F}$ | 8000000 | 1111 | $027 \times \times \times 111$ | 7 |
| $03 \times \mathrm{OX11100F6}$ | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| $03 \times \mathrm{DXX1111} \mathrm{\times FF}$ | C0590FDB | 1111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 0144006741111 | 7 |
| OFX30X11100F6 | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{EXX11110F6}$ | 35 C 90 FDB | 11111 | $027 \times \times \times \times 111$ | 7 |
| $03 \times 00211100 \mathrm{~F} 9$ | 80000000 | 11111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times 111 \times \times F$ | X $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 01400741111 | 7 |
| $1 \mathrm{~F} \times \times 0 \times 11000 \mathrm{~F}$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 2 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\mathrm{X} \times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | 0170000111 | 7 |
| $0 \times \times E \times \times 11110 \mathrm{~F}$ | 40590 FDB | 1111 | $027 \times \times \times 111$ | 7 |
| $03 \times 00211100 \mathrm{~F} 9$ | 80000000 | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times$ | 11111 | 0140074111 | 7 |
| $0 \mathrm{FX} 30 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| $00 \times E 0 \times 11100 F 6$ | $\mathrm{x} \times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times 111$ | 7 |
| $00 \times 00 \times 11100 F 6$ | $\mathrm{x} \times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | 111111 | 0140060111 | 7 |
| $0 \mathrm{FX40X11100F6}$ | $\mathrm{X} \times \times \times \times \times \times \mathrm{x}$ | 111 | $027 \times \times \times 11$ |  |

Table 6.1. Floating Point Sin(x) Microprogram (Continued)

* $\mathrm{R} 5=\mathrm{A} 6$

R5 = \#2F34 6FBCh

* R5 $=$ FMUL(R4,R5)
$R E=R 4$
$R D=R 5$
JSR FMUL
R5 $=$ RF
* R5 = $\operatorname{FADD}(\mathrm{R} 5, \mathrm{~A} 5)$
$R E=R 5$
RD $=$ \#B2D7 5AD5h
JSR FADD
$R 5=R F$
* R5 $=$ FMUL (R4,R5)
$\mathrm{RE}=\mathrm{R} 4$
$R D=R 5$
JSR FMUL
$\mathrm{R} 5=\mathrm{RF}$
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 4)$
$R E=R 5$
RD $=$ \#3638 EF99h
JSR FADD
R5 = RF
* $\cdot R 5=F M U L(R 4, R 5)$
$R E=R 4$
$R D=R 5$
JSR FMUL
$R 5=R F$
* $\mathrm{R} 5=\operatorname{FADD}(\mathrm{R} 5, \mathrm{~A} 3)$
$R E=R 5$
RD = \#B950 0001h
JSR FADD
$R 5=R F$
* $\mathrm{R} 5=\mathrm{FM} \operatorname{L}(\mathrm{R} 4, R 5)$
$R E=R 4$
$R D=R 5$
JSR FMUL
$\mathrm{R} 5=\mathrm{RF}$
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 2)$ $R E=R 5$ RD $=$ \#3C08 8888h JSR FADD R5 $=$ RF
* $\mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, R 5)$
$R E=R 4$
RD = R5
JSR FMUL
R5 = RF
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 1)$
$R E=R 5$
$R D=\# B E 2 A$ AAADh
JSR FADD
$R 5=R F$
* R5 $=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5)$
$R E=R 4$
$R D=R 5$
JSR FMUL
$R 5=R F$

|  | $\begin{gathered} \text { 32-bit } \\ \text { Constant } \end{gathered}$ |  |  | DRB13DRB0 | n |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $0 \times \times 50 \times 11110 \mathrm{~F} 6$ | 2 F 346 FBC | 1111 | 027 | $\times \times \times 111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | 027 | $\times \times \times 11$ | 7 |
| $05 \times \mathrm{D} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | 11111 | 0140 | 0060111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | - $\times \times \times 111$ | 7 |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | 027 | X $\times$ X 1111 | 7 |
| $0 \times \mathrm{COXX1111} \mathrm{\times FF}$ | B 2 D 75 AD5 | 11111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | 1111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\mathrm{X} \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \times$ | 1111 | 027 | X X X X 111 | 7 |
| $05 \times 00 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | X $\times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | 11111 | 0140 | 0060191 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $05 \times \mathrm{E}$ O 11100 F 6 | $\times \times \times \times \times \times \times \times$ | 1111 | 027 | X $\times \times \times 111$ | 7 |
| $0 \times \times \mathrm{D} \times 11111 \times \mathrm{F}$ | 3638 EF 99 | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times$ | X $\times \times \times \times 111$ | 7 |
|  | X $\times \times \times \times \times \times \times$ | 1111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\mathrm{X} \times \times \times \times \times \times \times$ | 1111 | 027 | X $\times \times \times 111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | x $\times \times \times \times \times \times \times$ | 1111 | 027 | $\times \times 111$ | 7 |
| $05 \mathrm{XD} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times$ | - $\times \times \times \times 1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 7 |
| $1 \times \times \times \times \times 111 \times \mathrm{F}$ ¢ F | $\times \times \times \times \times \times \times \times$ | 1111 | 0140 | 0060111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | 027 | 人 $\times \times 1111$ | 7 |
| $0 \times \times \mathrm{D} \times 1111 \times \mathrm{F}$ ¢ 1 | B 9500001 | 11111 | 027 | $\times \times \times \times 1111$ | 7 |
| $1 \times \times \times \times \times 111 \times \mathrm{F}$ ¢ F | $\times \times \times \times \times \times \times \times$ | 1111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | X $\times \times \times 1111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | 027 | 11 |  |
| $05 \times \mathrm{D} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times$ | ¢ $\times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | 11111 | 014 | 0006001111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\mathrm{x} \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | X $\times \times \times 1111$ | 7 |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | 027 | x $\times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{D} \times 1111 \times \mathrm{F}$ ¢ | 3 C 088888 | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \mathrm{F}$ ¢ F | $\times \times \times \times \times \times \times \times$ | 1111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1.111 | $027 \times$ | X $\times \times \times 1111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | 027 | X $\times \times \times \times 1111$ | 7 |
| $05 \times \mathrm{D} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | - $\times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 0140 | 0060111 | 7 |
| $0 \mathrm{FX} 50 \times 1,1100 \mathrm{~F} 6$ | $\mathrm{X} \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $05 \mathrm{XE} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | 027 | - $\times \times \times \times 111$ | 7 |
| $0 \times \times \mathrm{OX} 1 \mathrm{~T}_{1} 111 \mathrm{FF}$ | BE 2 AAAAD | 11111 | 027 | X $\times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | 11111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $04 \times E 0 \times 11100 \mathrm{~F} 6$ | X $\times$ X X X X ${ }^{\text {x }}$ | 1111 | $027 \times$ | X $\times \times \times \times 111$ | 7 |
| $05 \times \mathrm{D} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | 027 | $x \times \times \times 11$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times$ | 1111 | 0140 | 0060111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | 027 | $\times \times \times \times 111$ |  |

Table 6.1. Floating Point $\operatorname{Sin}(x)$ Microprogram (Continued)

|  | * R5 = FADD $(\mathrm{R} 5, \mathrm{~A} 0)$ |
| :---: | :---: |
| 0056 | $R E=R 5$ |
| 0057 | RD $=$ \#3F80 0000h |
| 0058 | JSR FADD |
| 0059 | R5 = RF |
|  | * R5 = FMUL(R0,R5) |
| 005A | $R E=R 0$ |
| 005B | $\mathrm{RD}=\mathrm{R} 5$ |
| 005C | JSR FMUL |
| 005D | R5 = RF |
|  | * R5 = FCHS (R5,R1) : RETURN |
| 005E | R1 = R1 OR \#7FFF FFFFh |
| 005F | R5 = R5 XOR R1: RETURN |
|  | * RC $=$ FEXP(RE) |
| 0060 FMUL: | RC $=$ RE AND \#7F80 0000h |
|  | * RE $=$ FRAC(RE) |
| 0061 | RE $=$ RE AND \#807F FFFFh |
|  | * RE $=$ RE OR bit23 |
| 0062 | RE = RE OR \#0080 0000h |
|  | * MQ $=$ SMTC(RE) |
| 0063 | RE $=$ SMTC(RE) |
| 0064 | LOADMQ : PASS |
|  | * RB $=\mathrm{FEXP}(\mathrm{RD})$ |
| 0065 | RB $=$ RD AND \#7F80 0000h |
|  | * RD $=$ FRAC(RD) |
| 0066 | RD $=$ = RD AND \#807F FFFFh |
| 0067 | $R D=R D$ OR bit 23 |
| 0068 | RD $=$ SMTC(RD) |
| 0069 | $\mathrm{RE}=0: \mathrm{RCB}=\# 22 \mathrm{D}$ |
| 006A | RE = SMULI RD : LOOP RCB |
| 006B | RE $=$ SMULT RD |
| 006C | TB0(RE,bit1) : BYTE = \#0100b : TEST Z |
| 006D | JT FMUL1 |
|  | * INEX RC |
| 006E | $R C=R C A D D \# 00800000 \mathrm{~h}$ |
| 006F | $R E=S R A(R E)$ |
| $\begin{aligned} & 0070 \text { FMUL1: } \\ & 0071 \end{aligned}$ | $R C=R C A D D^{\circ} R B: T E S T$ CARRY JT ERROR |
| 0072 | $R E=S M T C(R E)$ |
| 0073 | RE = RE AND \#807F FFFFh |
| * FADD: | $\mathrm{RC}=\mathrm{FEXP}(\mathrm{RE})$ |
| 0074 FADD: | RC $=$ RC AND \#7F80 0000 |
|  | * RE = FRAC(RE) |
| 0075 | RE = RE AND \#807F FFFFh |
| 0076 | $M \mathrm{M}=$ RE OR bit 23 |
| 0077 | $R E=S M T C(R E)$ |
|  | * RB $=$ FEXP(RD) |
| 0078 | RB = RD AND \#7F80 0000 |


|  | $\begin{gathered} \text { 32-bit } \\ \text { Constant } \end{gathered}$ |  |  | 岗 |
| :---: | :---: | :---: | :---: | :---: |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $0 \times \mathrm{XDXX1111} \mathbf{1}$ ¢ F F | 3 F 800000 | 11111 | $027 \times \mathrm{XXX} 1111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 0140074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| $00 \times \mathrm{E}$ O 11100 F 6 | $\times \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| $05 \times \mathrm{D} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \mathrm{F}$ ¢ F | $\times \times \times \times \times \times \times \times$ | 11 1 | 014400601111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \mathrm{x}$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| $01 \times 10211100 \mathrm{FB}$ | B 7 FFFFFF | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| 05150011100 F | $\times \times \times \times \times \times \times$ | 1111 | $022 \times \mathrm{XXX} 111$ | 7 |
| OEXCO211100FA | 7 F 800000 | 1111 | $027 \times \times \times \times 111$ | 7 |
| OEXEO211100 FA | 807 FFFFF | 1111 | $027 \times \times \times \times 11$ | 7 |
| OEXFO211100FB | 00800000 | 1111 | $027 \times \times \times \times 111$ | 7 |
| OXEEX 01111058 | $\times \times \times \times \times \times \mathrm{X}$ | 1111 | $027 \times \times \times \times 11$ | 7 |
| $1 \mathrm{EXX} 0 \times 11110 \mathrm{E} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| ODXB 0211100 FA | 7 F 800000 | 1111 | $027 \times \times \times \times 111$ | 7 |
| ODXD0211100FA | 807 FFFFF | 1111 | $027 \times \times \times \times 111$ | 7 |
| ODXD 0211100 FB | 00800000 | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 1111$ | 7 |
| $0 \times \mathrm{D} \times 01111 \mathrm{D} 58$ | $\times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| OEEEOO11110F9 | 00000016 | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $617 \times \times \times 1111$ | 4 |
| O DEE 000111111060 | $\times \times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $567006 \mathrm{Cl}_{1} 11$ | 4 |
| ODEE 000111100070 | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $067 \times \times \times \times 111$ | 7 |
| O O F O O 0 1 1 1 1 0 3 | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 0 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 4 |
| $1 \times \mathrm{XXXXX111} \times \mathrm{FF}$ | $\mathrm{X} \times \times \times \times \times \times \mathrm{X}$ | 11111 | $017 \times \times \times \times 111$ | 7 |
| 0 CXCO 2111000 F 1 | 00800000 | 11111 | $027 \times \times \times \times 111$ | 7 |
| 0 EXE $0 \times 11100006$ | x $\times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| OCBC 0011100 F 1 | X $\times \times \times \times \times \times \mathrm{X}$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times \times \times \times 1111$ | 0 |
|  | X $\times \times \times \times \times \times \mathrm{x}$ | $1 \begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $017 \times \times \times \times 1111$ | 7 |
| OXEEX 0111111058 | X X X X X X X | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 FFFFF | 1111 | $027 \times \times \times \times 111$ | 7 |
| OCXCO211100FA | 7 F 800000 | 1111 | $027 \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 FFFFF | 1119 | $027 \times \times \times \times 111$ | 7 |
| $1 \mathrm{E} \times \times 0111100 \mathrm{E}$ ( | 00800000 | 111111 | $027 \times \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 F F F F F | 11111 | $027 \times \times \times \times 111$ | 7 |
| 0 DXBO 211100 FA | 7 F 800000 | 1111 | $027 \times \times \times \times 111$ | 7 |

Table 6.1. Floating Point $\operatorname{Sin}(x)$ Microprogram (Continued)

|  | RD $=$ FRAC(RD) |
| :---: | :---: |
| 0079 | RE = RE AND \#807F FFFFh |
| 007A | $R D=R D$ OR bit23 |
| 007B | RD $=$ SMTC(RD) |
| 007C | $R F=R C-R B: C O=0: T E S T$ NEG |
| 007D | JT FADD1 : RCB $=$ \#8 |
| 007E | Y/RF $=$ SLC(RF) : LOOP RCB |
| 007F | $Y=R F: R C A=Y$ |
| 0080 | RD $=$ SRA(RD) : LOOP RCA |
| 0081 | RB $=$ RC: JUMP FADD2 |
| 0082 FADD1: | RF $=$ NOT RF |
| 0083 | Y/RF $=$ SLC(RF) : LOOP RCB |
| 0084 | $Y=R F: R C A=Y$ |
| 0085 | RE $=$ SRA(RE) : LOOP RCA |
| 0086 FADD2: | $R F=R D+R E$ |
| 0087 | RF $=$ SMTC(RF) |
| 0088 | $\mathrm{RF}=\mathrm{TBO}(\mathrm{RF}, \mathrm{bit24}):$ TEST Z |
| 0089 | JF FADD3 |
| 008A | INC RB: TEST NEG |
| 008B | RF = SRA(RF) : JT ERROR |
| 008C FADD3: | RF $=$ SETO (RF, bit23) |
| 008D | RF $=$ RF OR RB : RETURN |


|  | $\begin{gathered} \text { 32-bit } \\ \text { Constant } \end{gathered}$ |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OEXEO211100FA | 807 FFFFF | 1111 | 027 | $\begin{aligned} & \mathrm{X}\end{aligned} \mathrm{X} \times \mathrm{X} 1111$ | 7 |
| 0 DXD0211100FB | 00800000 | 1111 | $027 \times$ | x | 7 |
| $0 \times \mathrm{D} \times 01111058$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| 0 CBFO011100F3 | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | ¢ $\times \times \times \times 111$ | 2 |
| $1 \times \times \times \times 111 \times \mathrm{CFF}$ | X $\times \times \times \times \times \times 8$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $617 \times$ | X $\times$ X $\times 1111$ | 4 |
| $0 \mathrm{FXFO} \mathrm{O} 110 \times 066$ | $\times \times \times \times \times \times \times \times$ | 1111 | 5670 | 007 E1 11 | 4 |
| $1 \times \mathrm{X} \times \mathrm{X} 1100 \times \mathrm{F}$ | X $\times$ X $\times \times \times \times \mathrm{x}$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 2770 | 000801111 | 7 |
| 0 D X 0 X 1110006 | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | 167 | 007 E 111 | 4 |
| $0 \mathrm{CXB} 0 \times 1110 \times \mathrm{F}$ | $x \times \times \times \times \times \times$ | 111 | $027 x$ | X $\times \times \times 1 \begin{array}{llll}1 & 1\end{array}$ | 7 |
| 0 FXFOX 11100 F 7 | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times$ | X $\times \times \times 111$ | 7 |
| OFXF0X1100066 | $\times \times \times \times \times \times \times \times$ | 11111 | $617 \times$ | X $\times \times \times \times 1111$ | 4 |
| $1 \mathrm{XXXXX1100XFF}$ | $\times \times \times \times \times \times \times$ | 1111 | 567 | 00841 | 4 |
| OEXEOX1110006 | XXXXXXXX | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 2770 | 0086111 | 7 |
| ODEFOO11100F1 | $\times \times \times \times \times \times \times \times$ | 1111 | $027 x$ | x $\times \times \times 111$ | 7 |
| OXFFX 011111058 | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times$ | 人 $\times \times \times \times 111$ | 7 |
|  | X X X X X X X | 01111 | $027 x$ | x $\times \times \times 1111$ | 4 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | 1 11111 | $047 \times$ | X $\times \times \times \times 1111$ | 7 |
| O B X B OX 111111 F 6 | X $\times$ X $\times$ X $\times$ X | 11111 | $027 \times$ | 人 $\times \times \times \times 111$ | 3 |
| OF7F $0 \times 111100006$ | X $\times \times \times \times \times \times \mathrm{X}$ | 111 | $017 \times$ | x $\times \times \times 11$ | 7 |
| 07 F | $\times \times \times \times \times \times \times$ | 101 | $027 x$ | X $\times \times \times 11$ | 7 |
| 0 FBFO011100FB | $\times \times \times \times \times \times \times$ | 1111 | $022 x$ | XXXX1111 |  |

# Excerpt from SN74AS888, SN74AS890 Bit-Slice Processor User's Guide 

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## 4. 32-Bit CPU Design Methodology

Microprogramming and bit-slice technology have made possible the development of powerful systems using flexible instructions sets and wide address/data buses to access more than one Gigaword of physical main memory. This section discusses one design approach to such a system, using 'AS888 bit-slice and 'AS890 microsequencer components.
A structured approach to system design, such as that illustrated in Figure 4-1, is recommended in developing custom bit-slice designs. The product specification gives a starting point or basis for the project. In this example, four 'AS888 bit slices are used to implement the 32-bit arithmetic portion of the CPU, and an 'AS890 microsequencer is used for ALU and system control. A group of PROMs stores the microinstructions; a writable control store could also be implemented using additional control logic and components to load and modify the microprogram memory. The system is designed to access more than one Gigaword of memory.


Figure 4-1. System Design Approach

Since speed is a concern, carry look-ahead rather than ripple-through logic is recommended. If ripple-through logic were used, the system clock would need to be slowed down to allow the propagation of the carry bits through the various 'AS888 stages. By using carry look-ahead, the amount of time needed for the data to stabilize is greatly reduced by anticipating the carry across the 'AS888 packages.
So that the scratchpad area can be used for address calculations and mathematical computations, the 'AS888's internal register file is dedicated for system functions. To provide the system user with a macrolevel equivalent of register locations, a 16 -word external register file is also included. Access to the external register file will be under microprogram control, allowing address selection to come from the microcode itself or from one of the three operand fields of the instruction register.

PROMs eliminate the use of main memory as a source for constants used in initialization or table look-up functions. Accessing main memory for table values would require time and slow system throughput; by placing fixed values in fast PROMs, access time is kept to a minimum and system throughput is not altered.

Control, data and address buses shared by the system are accessed by three-state registers. The control register, as explained in section 4.1.2, supplies the non-CPU part of a computer system with control signals. The data bus allows the ALU to supply data for the rest of the system and can also be a source of data for the ALU; this is accomplished by using three-state registers to drive the bi-directional data bus, along with registers to sample the bus. The address bus uses one of the external register file locations to maintain a program counter, thus allowing a 32-bit address bus capable of addressing about four Gigawords of main memory. Using three-state drivers for this bus enables other subsystems to take control of the system buses.

A pipeline register supplies the microsequencer and the ALU with both data and instructions. To get macrocode into the system, an instruction register and a mapping PROM are used to convert the opcode to a microprogram routine address. The condition code signal, used for testing various conditions, is supplied by a registerinput based PAL. PAL inputs can be fixed values or combinations of the status signals coming from the ALU. The read address select pins for the 'AS888's internal B register can be sourced from the microword itself or from three nibbles of the macroword, to provide offsets for the N -way branches to various microcode routines.

### 4.1 Designing a 32-Bit System

A typical 32-bit system block diagram using the 'AS888 bit-slice and 'AS890 microsequencer is shown in Figures 4-2 and 4-3. It can be broken down into two sections, the ALU (arithmetic logic unit) and the CCU (computer control unit). The ALU section performs all manipulation of data both to and from main memory, such as arithmetic and logical operations. The CCU section controls instruction (macrocode) flow and any miscellaneous control operations, such as fetching instructions or supplying addresses for main memory access.

### 4.1.1 Construction of the ALU

To cascade the four 'AS888s to obtain the 32-bit arithmetic unit shown in Figure 4-4, the shift multiplex $\overline{\mathrm{SIOO}}$ and $\overline{\mathrm{QIOO}}$ terminals are connected to the $\overline{\mathrm{SIO7}}$ and $\overline{\mathrm{QIO7}}$ terminals of adjacent packages, and the least significant package's signals are connected to the most-significant package's. Optionally, SN74ALS240 inverting gates can be connected to the $\overline{\mathrm{SIOO}} \overline{\mathrm{SIO7}}$ terminals and the byte inputs to implement byte and bit control. Another chip, the SN74AS182 look-ahead carry generator, provides a ripple-carry function, to help system throughput.
The design includes a 16 -word register file, the SN74AS870 (see Figure 4-3). This allows the user to access 16 working areas for temporary data storage or address calculations such as indexing. In this design example, the 'AS888's internal register file is not accessible directly by the user; it is reserved for microcode operations, such as address computation and temporary storage for arithmetic operations. Addressing the register files is permitted through the microprogram or from the macrocode instruction register under microcode control.

The transfer register connected to the 'AS888's $Y$ and DB buses allows for feedback into the 'AS888 under microprogram control. Since the constant PROMs and the external register file share the $A$ bus, they cannot be accessed at the same time. The transfer register enables data from the external register file to be transmitted to the $B$ bus, making possible the addition of operands from the constant PROMs and the external register file, for example.

Constant PROMs are also included to simplify the programming and operation of the ALU by supplying fixed data for various operations, such as:

1) Clearing the system register files for initialization. This will bring the system up to a known state.
2) Supplying a correction value to the offset in a branch instruction, i.e., converting a 16 -bit offset to a true 32 -bit address.
3) Table look-up for fixed mathematical operations, such as computing sines and cosines.

### 4.1.2 Construction of the CCU

Sequencing and branching operations at speeds compatible with the 'AS888 are supplied by the 'AS890, a microprogrammed controller working as a powerful microsequencer (see Figure 3-1). Features of the 'AS890 include:

1) Stack capability. The 9 -word stack can be accessed by using a stack pointer or a read pointer; the latter is designed for non-destructive dumping of the stack contents.
2) Register/counter facility. Two registers, DRA and DRB, can be used for latching data from the external data buses or as counters for loops. A ZERO signal is generated when the decremented counter reaches a zero value.
3) Interrupt control. A register for temporarily holding the return address is supplied; upon entering the interrupt routine, the contents of the return register must be pushed onto the stack for later use.
4) Next address generation. The $Y$ output multiplexer offers a selection of same or incremented address, address from DRA or DRB buses, address from stack, or a concatenation of DRA13-DRA4 and B3-BO.

A microprogram memory/pipeline register supplies the microsequencer and the rest of the system with instructions (see Figure 4-2). The memory might consist of ROMs, or it could be a writable-control store with support logic to allow loading or updating of the control store. For a general purpose machine with a fixed instruction set, ROMs would be more economic.

Some 'AS890 instructions are influenced by the $\overline{\mathrm{CC}}$ input. Many are variations of branch and jump instructions. To form and supply $\overline{\mathrm{CC}}$, a register can be used to latch the state of the 'AS888 and supply inputs to a PAL for decoding, based upon the microcode's needs. Combinatorial logic in the PAL allows multiple or single events to be selected or provides a fixed value of " 1 " or " 0 " for forced conditions.

To supply the microsequencer with the proper address of the microcode-equivalent version of the macrocode instruction, an instruction register and mapping PROM are needed. Under microprogram control, the instruction register samples the data bus to get the macrocode instruction. The opcode portion is passed to the mapping PROM to form an address to the microcode routine. When the microcode is ready to jump to the routine, it turns off the $Y$ bus output of the 'AS890 and enables the output of the mapping PROM. An optional means of altering the address uses B3-BO inputs of the 'AS890 to implement a N -way branch routine. In this method, the ten most significant address bits of DRA or DRA are concatenated with the B3-BO bits to supply an address.

Control information is supplied to the rest of the system via the control register and bus. By setting various bits within the control register, information can be passed to other subsystems, such as memory and $1 / O$ peripherals. Bit 0 could represent the read/write control line while bit 1 could select memory or I/O for the read/write. Bit 2 might function to enable interrupts and bit 3 to indicate when the system should enter a "wait" state for slow memory. The remaining control bits can be programmed by the system designer to indicate additional condition states of the "macrosystem".


Figure 4－2．CCU Block Diagram


Figure 4-3. ALU Block Diagram

Addressing of the register files, both the 'AS888 internal and the 'AS870 external, is done through the use of two 1 -of- 2 selector banks. The first bank selects address source; this design offers a choice for operand processing of fixed values from the microcode or values from the macroinstruction latched in the instruction register. The second bank selects the first or second operand as an address source for port 0 of the external register file; port 1 uses the third operand as an address source.
It should be noted that the design presented in Figure 4-2 for the computer control unit is a one-level pipeline that is instruction-data based. The address and contents of the next instruction are being fetched while the current instruction is being executed. Tracing through the data flow, the following can be observed:

1) The pipeline register contains the current instruction being executed;
2) The ALU has just executed its instruction, and has the current status ready at its output pins;
3) The status register that is attached to the ALU contains the previous instruction's resulting status;
4) The contents of the next microprogram word are being fetched at the same time that the current instruction is being executed.

### 4.2 Tracing through a 32-Bit Computer

With the 'AS888 and 'AS890 as foundation chips, the typical 32-bit supermini of Figures $4-2$ and $4-3$ can now be functionally traced. First, note that the data of the main program is handled separately from that of the microcode - each on its own bus. The system is initialized by setting the "clear" signal high - this causes a forced jump to the beginning of the microcode memory. Instructions carried out by the microcode at this point might run system diagnostics, clear all registers throughout the 'AS888-based system, and set up the initial macrocode program address. In this design, the first program address to fetch an instruction from main memory comes from a fixed value in the microcode memory; it is possible to allow the address to be retrieved from a permanent location in main memory or from either a front panel or console, by modifying the microcode program slightly.

Table 4-1 itlustrates the microcode format for this design. Note that it contains control signals for all chips involved in the design. Some of these, such as TRANSLATCH and MARLATCH, are used with the system clock to provide controlled loading of the various holding registers. Others supply necessary addressing information, directing input from either the main data bus or from the microcode word itself.

The FETCH routine is shown in functional, assembler and microcoded forms in Tables $4-2,4-3$ and 4-4. First, the program counter is read from the external register file and stored into the memory address register. After the program counter is placed on the address bus, the program counter is updated and stored while the data from memory is allowed to settle down to a stable condition. The data is then latched in both the instruction register and data-in register.

The opcode field of the instruction register is passed through the mapping PROM to convert the opcode to an equivalent microcode routine address. When YOE is forced high by the microcode, the 'AS890 is tri-stated from the $Y$ bus, and the mapping PROM's output is taken out of the tri-state mode to supply an address to the control store (microprogram memory); a forced jump is made to the microcode routine to perform the instruction.

After the routine is complete, a jump is made back to the FETCH routine using the next-address supplied by the microprogram. It is up to the system designer/programmer to make sure that all system housekeeping is performed so that nothing causes a fatal endless loop.


Figure 4-4. Cascaded 'AS888 Packages

Table 4-1. Microcode Definition

| MICROCODE FIELD | PIN NAME | INPUT TO | FUNCTION |
| :---: | :---: | :---: | :---: |
| 0-13 | DRA13-DRA0 | 'AS890 | Used for next-address branches |
| 14-27 | DRB13-DRB0 | 'AS890 | Used for loading counter |
| 28-30 | RC2-RC0 | 'AS890 | Register/counter controls |
| 31-33 | S2-S0 | 'AS890 ${ }^{\prime}$ | Stack control |
| 34-36 | MUX2-MUX0 | 'AS890 | MUX control of Y output bus |
| 37 | $\overline{\text { NT }}$ | 'AS890 | Interrupt control |
| 38 | $\overline{\text { RAOE }}$ | 'AS890 | Enables DRA output |
| 39 | $\overline{\text { RBOE }}$ | 'AS890 | Enables DRB output |
| 40 | OSEL | 'AS890 | Mux control for DRA source |
| 41 | INC | 'AS890 | Incrementer control |
| 42 | $\overline{\text { YOE }}$ | 'AS890 | Enables Y output bus |
| 43-50 | 17-10 | 'AS888 | Instruction inputs |
| 51 | $\overline{\text { OEA }}$ | 'AS888 | DA bus enable |
| 52 | EA | 'AS888 | ALU input operand select |
| 53 | $\overline{\text { OEB }}$ | 'AS888 | DB bus enable |
| 54 | OEY | 'AS888 | Y bus output enable |
| 55 | SELY | 'AS888 | $Y$ bus select |
| 56-57 | EB1-EB0 | 'AS888 | ALU input operand selects |
| 58 | $\overline{W E}$ | 'AS888 | Register file write enable |
| 59 | $\overline{\text { MAP }}$ | PROM | Enables mapping PROM to 'AS890 Y bus |
| 60 | $\overline{\mathrm{R}}$ | Latch | Latches data bus to instruction register |
| 61 | $\overline{C R}$ | Latch | Latches control data to bus |
| 62-69 | CTRL7-CTRLO | Latch | Data for control latch |
| 70-71 | BSEL1-BSELO | Multiplexer | Selects data for 'AS890 |
| 72-75 | B3-B0 | Multiplexer | Microcode data to switch |
| 76 | CONDCD | Latch | Controls latch of 'AS888 status |
| 77-80 | SELC3-SELC0 | PAL | Selects combination of 'AS888 status |
| 81 | DTALATCHI | Latch | Controls latching of data-in |
| 82 | $\overline{\text { DTAIN }}$ | Latch | Enables data-in output to bus |
| 83 | DTALATCHO | Latch | Controls latching of data-out |
| 84 | DTAOUT | Latch | Enables data-out output to DB bus |
| 85 | $\overline{\text { MARLATCH }}$ | Latch | Controls latching of address |
| 86 | $\overline{\mathrm{MAR}}$ | Latch | Enables MAR output to address bus |
| 87 | CONSTPROM | PROM | Enables PROM to DA bus |
| 88-99 | A11-A0 | PROM | Address of constant in PROM |
| 100 | SWITCH2 | Multiplexer | Selects microcode or Instruction Register data |
| 101 | SWITCH1 | Multiplexer | Selects microcode or Instruction Register data |
| 102-105 | A3-A0 | Multiplexer | Register file address ('AS888) |
| 106-109 | B3-B0 | Multiplexer | Register file address ('AS888) |
| 110-113 | C3-C0 | Multiplexer | Register file address ('AS888) |
| 114 | REGUWR | Register File | Port 0 write enable |
| 115 | REGLWR | Register File | Port 1 write enable |
| 116 | $\overline{\text { REGU }}$ | Register File | Chip enable on port 0 |
| 117 | $\overline{\text { REGL }}$ | Register File | Chip enable on port 1 |
| 118 | TRANSLATCH | Latch | Controls latch between Y and DB bus |
| 119 | TRANS | Latch | Enables output to DB bus |
| 120 | SELCN2 | Multiplexer | Supplies carry input to 'AS888 |
| 121 | SELCN1 | Multiplexer | Supplies carry input to 'AS888 |
| 122 | REGUB | Multiplexer | Selects address for external register file |
| 123-126 | BYTE3 - $\overline{\text { BYTEO }}$ | Three-state | Enables data for byte/bit operations |

Table 4-2. Functional Listing of Fetch

```
FETCH: }\quad\mathrm{ MAR = PC, Enable MAR output
PC = PC + 1
IR = DIR = data bus, Disable 'AS890 Y bus,
    Enable mapping PROM to Y bus
```

Table 4-3. Assembler Listing of Fetch

| FETCH: OP890 ,.,111,10;INC; | Set 'AS890 for continue |
| :---: | :--- |
| OP888 NOP,GROUP5,10,.,1111; | Perform NOP and read external register 15 |
| OEY;SELY; | Enable Y bus output |
| CR;CTRL 00000011; | Generate external control bus signals |
| SELC 01; | Select fixed CC value to 'AS890 |
| MARLATCH;MAR; | Latch value on Y bus and enable output |
| SWITCH 00;REGL; | Select address source and enable port |
| TRANSLATCH | Latch Y bus for transfer to B bus |
| OP890 ,,111,10;INC; | Set 'AS890 for continue |
| OP888 PASS,INCS,00,,,1111; | Increment program counter |
| OEB;OEY; | Enable Y bus output |
| SELC 01; | Select fixed CC value to 'AS890 |
| MAR; | Output address to address bus |
| REGLWR;REGL; | Update program counter in register file |
| TRANS; | Enable transfer latch output to B bus |
| SELCN 01 | Select, carry input to LSP to be "1" |
| OP890 ,,,111,10; | Set 'AS890 for continue |
| OP888 NOP,GROUP5,10; | Perform NOP |
| MAP; | Enable mapping PROM to 'AS890 Y bus |
| IR; | Latch data bus to get macrolevel code |
| SELC 01 | Select fixed CC value to 'AS890 |
| DTALATCHI; | Put data bus also in data register |
| MAR | Output address to address bus |

## Key to Table 4-3

OP888 a,b,c,d,e,f
where:
a $=$ upper bits of instruction, 17-14
b $=$ lower bits of instruction, 13-10
c = value of EB1-EB0
$\mathrm{d}=\mathrm{A}$ address of register files
$\mathrm{e}=\mathrm{B}$ address of register files
OP890 $\mathrm{v}, \mathrm{w}, \mathrm{x}, \mathrm{y}, \mathrm{z}$
where:
$v=$ DRA value, 14 -bits
$w=$ DRB value, 14 -bits
$x=$ RC2-RC0
$y=S 2-S 0$
$f=C$ address of register files

Table 4-4. Microcode Listing of Fetch

| DRA13DRAO | DRB13DRBO |  | $\begin{aligned} & \stackrel{\circ}{\dot{\sim}} \\ & \stackrel{y}{2} \end{aligned}$ |  |  | 17-10 |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0000000000000 | 0000000000000 | 000 | 111 | 010 | 111010 | 11111111 | 11101101 | 110 |
| 0000000000000 | 0000000000000 | 000 | 111 | 010 | 111010 | 11110100 | 11000001 | 111 |
| 00000000000000 | 0000000000000 | 000 | 111 | 010 | 111001 | 11111111 | 01111101 | 001 |

Table 4-4. Microcode Listing of Fetch (continued)

| CTRLTCTRLO |  | $\begin{aligned} & \text { \%. } \\ & \text { M } \end{aligned}$ | $0$ |  |  | A11-A0 |  | $\begin{aligned} & \stackrel{̣}{\dot{¢}} \\ & \hline \end{aligned}$ | $\begin{aligned} & \circ \stackrel{\mathscr{H}}{\text { M }} \end{aligned}$ | $\begin{aligned} & \text { O} \\ & \dot{\dddot{y}} \end{aligned}$ |  | 喭 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00000011 | 00 | 0000 | 1 | 0001 | 1111001 | 000000000000 | 00 | 0000 | 0000 | 1111 | 111001000 | 1111 |
| 00000000 | 00 | 0000 | 1 | 0001 | 1111101 | 000000000000 | 00 | 0000 | 0000 | 1111 | 101010010 | 1111 |
| 00000000 | 00 | 0000 | 1 | 0001 | 0111101 | 00000000000 | 00 | 0000 | 0000 | 0000 | 111111000 | 1111 |

### 4.3 Defining the Macrocode Instruction Format

Since this is a 32-bit design, a variety of instruction formats are available. The size of the opcode, along with the types of addressing used, will affect both system size and performance. The formats shown in Table 4-5 will be used for discussion.
All Table 4-5 formats have an opcode field of 11 bits and source/destination fields of 7 bits; the first three bits of the latter designate the address type, and the remaining four bits are used for register access. The opcode length allows 2,048 macrocoded instructions to be mapped to equivalent microcoded routines. The address fields can specify any of the following modes: register, relative, autoincrement/autodecrement, indexed, absolute, and deferred. The offset used in the Type 0 instruction can be used for branch-based instructions, for an offset range of $\pm 32727$.

Table 4-5. Possible Instruction Formats

TYPE 0 - OPCODE + 16-BIT OFFSET

| $0-10$ | $11-15$ <br> Not Used | $16-31$ <br> Opfodset |
| :---: | :---: | :---: |

TYPE 1 - OPCODE + DESTINATION

| $0-10$ | $11-24$ | $25-31$ |
| :---: | :---: | :---: |
| Opcode | Not used | $25-3$ <br> Destination |

TYPE 2 - OPCODE + SOURCE + DESTINATION

| $0-10$ | $11-17$ | $18-24$ | $25-31$ |
| :---: | :---: | :---: | :---: |
| Opcode | Not used | Source | Destination |

TYPE 3 - OPCODE + SOURCE1 + SOURCE2 + DESTINATION

| $0-10$ | $11-17$ | $18-24$ | $25-31$ |
| :---: | :---: | :---: | :---: |
| Opcode | Source | Source | 25 Destination |

### 4.4 Tracing a Macrocode Instruction

Microcode for a Type 3 multiplication instruction is shown in Table 4-6, using the following assumptions:

1) Code for retrieving the operands will not be shown. Jumps will be made to routines that will place the temporary operands into internal register locations 2 and 3 of the 'AS888, after being fetched from main memory.
2) A jump to a routine to store the product in the destination will be handled similarly.
3) Multiplication will be unsigned; the result will be placed in two temporary locations of the 'AS888.
4) An update to the program status word, which the user can access at the macrocode level must also be performed, but is not shown.

Assembler code is shown in Table 4-7; a microcode listing is given in Table 4-8. The first two lines of microcode are subroutine jumps to opcode fetching routines, which store the operands in register files 2 and 3 in the 'AS888. The next two instructions load up the 'AS890 with a counter constant for performing the multiply loop, load the MQ register of the 'AS888 with the multiplier and clear the register that is temporarily used for the accumulator.

# Table 4-6. Functional Listing of Multiply 

```
UMULI3:
    JUMPSUB SOURCE1
    JUMPSUB SOURCE2,
        BCOUNT = 32
    REG 9=0
    MQ = REG 2
LOOP:
    UMULI WITH REG 3
        DECREMENT BCOUNT,
        BRANCH TO LOOP IF NOT ZERO,
        LATCH 'AS888 STATUS,
        REG 9=ALU
    REG 8=MQ
    JUMPSUB STORPSW
    JUMPSUB MDEST
    JUMP FETCH
```

Get first operand
Get second operand Load DB counter register Clear temporary accumulator Load multiplier

ssue the multiply Decrement the DB counter Loop back until done Store 'AS888 flags Store intermediate result Store intermediate result Update macro program status Store result at destination Get next instruction

A loop is then entered to perform the multiply instruction 32 times to form the product, with the multiplicand coming from the internal register file of the 'AS888. Upon exiting the loop, the MQ register is stored in a temporary register location in the 'AS888. The MQ register now contains the least-significant bits of the result and the temporary accumulator the most significant bits. A subroutine jump is made to the program status word update routine; this will take the status flags of the last multiplication iteration and change the macrolevel status word. The next subroutine jump is to a destination routine, which is followed by a branch to the FETCH routine to get the next macro instruction to be executed.

### 4.5 System Enhancements

The above example provides a broad overview of 32-bit system design using the 'AS888 and 'AS890. Certain additional options may enhance system performance. These include:

1) Status latching. The design does not take into account changes that need to be examined at the microlevel while retaining macrolevel status information. One solution would be to include another register in parallel to the status latch and provide control to choose between the two to form the condition code value.
2) Interrupts. To efficiently use a computer system, interrupts are used to alter program flow in the case of I/O programming and real-time applications (involving hardware timers). To include this capability, external hardware must be included and the microcode modified accordingly. Information on interrupt implementation is given in section 3.
3) Control store. One way of implementing microprogram memory is to use a ROMbased design. It is becoming more common to design a writable control store, a completely RAM-based or part RAM, part ROM storage system, that can be altered by system operation, such as initialization from a floppy disk subsystem, or by the user to optimize or implement new macrolevel instructions. The cost of implementation must be weighed with the risks involved in changing instructions which may not be supported by other sites.
4) Instruction word definitions. Changing the instruction word definitions will have an effect on both system design and performance. Removing Type 3 instructions from the design, for example, will have an effect on both hardware and software: the external register file addressing must be changed and the 1-of-2 selector

Table 4-7. Assembler Code of Multiply

| UMULI3: |  |
| :---: | :---: |
| OP890 SOURCE1,..110,110; | Perform a subroutine branch |
| INC; YOE; | Increment address and enable Y bus |
| OP888 NOP;GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to " 1 " to set up 'AS890 continue |
| MAR | Maintain address on main address buss |
| OP890 SOURCE2,00000000100000,110,110,110; | Perform subroutine branch and load B counter |
| INC;YOE; | Increment microaddress and enable Y bus |
| OP888 NOP,GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to "1" to set up 'AS890 continue |
| MAR | Maintain address on main address bus |
| OP890 ,.,111,110; | Perform a continue instruction |
| INC;YOE; | Increment microaddress and enable $Y$ bus |
| OP888 CLEAR,GROUP5,.,.1001; | Zero out register file accumulator |
| WE; | Enable writing to register file |
| SELC 0001; | Set CC to "1" to set up 'AS890 continue |
| MAR | Maintain address on main address buss |
| OP890 LOOP,,,111,110; | Perform a continue instruction |
| INC;YOE: | Increment microaddress and enable Y bus |
| OP888 LOADMQ,INCS ,,,0010; | Load MO register with $S+C n$, from external register file |
| MAR | Maintain address on main address bus |
| LOOP: |  |
| OP890 LOOP,101,111,100; | Decrement B and loop til ZERO $=1$ |
| INC;YOE; | Increment microaddress and enable $Y$ bus |
| OP888 UMULI,GROUP4,01,0011,,1001; | Perform unsigned multiply on accumulator |
| WE; | Update register file accumulator |
| MAR | Maintain address on main address bus |
| OP890 ...111,110; | Perform a continue instruction |
| INC; YOE; | Increment microaddress and enable $Y$ bus |
| OP888 PASS,INCS,,,,1000; | Put $\mathrm{S}+\mathrm{Cn}$ in temporary register file |
| WE; | Allow updating of register file |
| MAR | Maintain address on main address bus |
| OP890 STORPSW.,.,10,110; | Perform a subroutine branch |
| INC; YOE; | Increment microaddress and enable Y bus |
| OP888 NOPGROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001; | Set CC to "1" for set up 'AS890 continue |
| MAR | Maintain address on main address bus |
| OP890 FETCH, ,, 111; | Perform a branch to FETCH routine |
| INC;YOE; | Increment microaddress and enable Y bus |
| OP888 NOP,GROUP5; | Tell 'AS888 to do nothing during jump |
| SELC 0001 | Set CC to "1" for 'AS890 continue |

## Key to Table 4-7.

## OP888 a,b,c,d,e,f

where:
$a=$ upper bits of instruction, 17-14
$b=$ lower bits of instruction, 13-10
$c=$ value of EB1-EB0
$\mathbf{d}=A$ address of register files
$\mathrm{e}=\mathrm{B}$ address of register files
$f=C$ address of register files

OP890 v,w,x,y,z
where:
$v=$ DRA value, 14 -bits
$w=$ DRB value, 14 -bits
$x=R C 2-R C 0$
$y=S 2-S 0$
$z=$ MUX2-MUX0
removed. Likewise, changing the opcode length may restrict the instruction address capability and also cause either an increase or decrease in the microcode size.
5) Dynamic memory access (DMA). The above system does not support dynamic memory access. To include this function requires a change in the address output control, along with support circuitry for the type of DMA selected. Some error detection and correction logic for main memory might also be included.
6) Computer control unit. The design presented here shows a one-level pipeline architecture that is instruction-data based. System throughput may be increased by converting to a pipeline of greater depth, or using another variety of onelevel pipeline, such as instruction-address based or address-data based. Care must be taken when increasing the size of the pipeline, especially when handling branch/jump situations. The reader is advised to carefully research this area before implementing any design.

### 4.6 Timing and System Throughput

A critical path analysis was undertaken to determine the maximum clock rate for the proposed system. The longest delay path is the multiplication data path, which involves the internal register file and the shift function of the 'AS888. Table 4-9 contains the critical delay calculations for both the ALU and CCU. Since both portions of the system must be satisfied, a clock rate of 90 ns was selected for the following comparisons.

### 4.6.1 Fetch Analysis

Most microprocessors perform an instruction fetch in a pipeline mode; the next instruction is fetched while the current instruction is executing. The fetch code shown earlier requires a minimum of four cycles: three to issue the code and one to break the pipeline for processing the branch. This results in a total time of 360 ns , based on a 90 ns cycle time. Fetch times for the representative microprocessors have been estimated from data books and are shown in Table 4-10; wait states for slow memory are not included. As can be seen from the table, the 'AS888 design example is estimated to run from 1.1 to 2.1 times faster than the 16 -bit microprocessors.

### 4.6.2 Multiplication Analysis

This analysis assumes that multiplication is unsigned integer and register to register based. No account is taken of time needed for instruction fetch or operand fetch or store.

The basic loop for the multiply takes 35 cycles: 2 for accumulator and multiplier set up, 32 for actual multiply loop and 1 to store the least-significant bits in an internal register file. Given a cycle time of 90 ns , a 32 by 32 bit multiplication can be implemented in 2.275 microseconds. A 16-bit multiply requires 16 iterations of the inner loop; both timings are included in Table 4-11 for comparison. Values for the 16 -bit multiplies of the representative microprocessors have been estimated from data books.

As shown in Table 4-11, the 16 by 16 multiply can be performed with the 'AS888 at a faster rate than the 16 -bit microprocessors. Even comparing the 32 by 32 multiply of the application design, one can see that the 'AS888 based system has a better macroinstruction execution speed. Using the 'AS888 and 'AS890 in a system design will allow high throughput and permit a flexible architecture.
Table 4－8．Microcode Listing of Multiply

| DRA13－ DRAO | DRB13－ DRB0 | \％ | $\begin{aligned} & \text { 户̀ } \\ & \text { ベ } \end{aligned}$ |  |  | 17－10 |  <br>  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00000000001100 | 0000000000000 | 000 | 110 | 110 | 111010 | 11111111 | 11110001 | 111 |
| 00000000010000 | 0000000100000 | 110 | 110 | 110 | 111010 | 11111111 | 11110001 | 111 |
| 0000000000000 | 000000000000 | 000 | 111 | 110 | 111010 | 11110000 | 11100000 | 111 |
| 00001000001000 | 000000000000 | 000 | 111 | 110 | 111010 | 11100100 | 11100001 | 111 |
| 00001000001000 | 0000000000000 | 101 | 111 | 100 | 111010 | 11010000 | 11100010 | 111 |
| 00000000000000 | 0000000000000 | 000 | 111 | 101 | 111010 | 11111111 | 11100010 | 111 |
| 00000000010100 | 000000000000 | 000 | 110 | 110 | 111010 | 11111111 | 11110001 | 111 |
| 00000000011000 | 0000000000000 | 000 | 110 | 110 | 111010 | 111111111 | 11110001 | 111 |
| 0000000000011 | 0000000000000 | 000 | 111 | 000 | 111010 | 11111111 | 11110001 | 11 |

Table 4-9. Critical Delay Path Analysis

| CONTROL PATH |  |  | DATA PATH |  |  |
| :--- | :--- | :---: | :--- | :--- | ---: |
| Pipeline Reg. | Clock to Output | 9 | 'AS888-1 | Clock to $C_{n}$ | 46 |
| MUX | Select to Output | 13 | 'AS182 | C $_{n}$ to $C_{n+z}$ | 5 |
| 'AS890-1 | CC to Output | 25 | 'AS888-1 | C $_{n}$ to SIO | 25 |
| PROM | Access Time | 20 | 'AS888-1 | SIO to $Y$ | $\underline{14}$ |
| Pipeline Reg. | Setup Time | $\frac{2}{90}$ |  |  | 90 ns |

Table 4-10. Fetch Timing Comparison

| FETCH | 'AS888 <br> 32-BIT | Z8001 | $8086-1$ | 80286 | 68000 L |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Data width | 32 | 16 | 16 | 16 | 16 |
| No. of cycles | 4 | 3 | 4 | 4 | 4 |
| Clock rate | 11.11 MHz | 4 MHz | 10 MHz | 10 MHz | 8 MHz |
| Total time | 360 ns | 750 ns | 400 ns | 400 ns | 600 ns |

Table 4-11. Multiply Timing Comparison

| MULTIPLY | 'AS888 | 'AS888 |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| S2-BIT | 16-BIT | Z8001 | $8086-1$ | 80286 | $\mathbf{6 8 0 0 0 L}$ |  |
| Size | $32 \times 32$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ | $16 \times 16$ |
| No. of cycles | 35 | 19 | 70 | 128 | 21 | $\leqslant 74$ |
| Clock rate | 11.11 MHz | 10.98 MHz | 4 MHz | 10 MHz | 10 MHz | 8 MHz |
| Total time | $3.150 \mu \mathrm{~s}$ | $1.729 \mu \mathrm{~s}$ | $17.5 \mu \mathrm{~S}$ | $12.8 \mu \mathrm{~s}$ | $2.1 \mu \mathrm{~s}$ | $\leqslant 9.25 \mu \mathrm{~s}$ |

## 5. Floating-Point System Design

Bit-slice processor architecture addresses the problem of optimizing system performance while allowing the user to balance hardware complexity against software flexibility. Bit-slice systems usually operate at or near the speed of the most primitive of programmable processors, the PROM state sequencer. Of course, bit-slice architecture incorporates circuitry dedicated not only to sequencing, but also data processing (ALU) operations. In keeping with the trend of these programmable devices to track the speed of fast discrete hardware, the 'AS888 8-bit slice ALU and 'AS890 microsequencer have been produced in Advanced Schottky bipolar technology. In addition to sheer speed, the components feature greater density ( 2 micron geometry) for greater functionality (more special purpose circuitry on board). The impact will be faster, more powerful systems in applications which previously pushed the limits of bit-slice processors.

Consider an application in which bit-slice architecture has dominated for years: CPU design. The microprogrammed CPU itself spans a spectrum of uses ranging from general purpose minicomputers to compact airborne computers. A specific example which illustrates various facets of design using the 'AS888 and 'AS890 is a CPU with a floating-point utility to compute $\sin (x)$.

The design process can be subject to many influences, including personal preference, available development tools, peculiarities of the application, and constraints from the user, customer or manufacturing environment. No hard and fast design rules could be applied universally, but most designers will start with a specific plan in mind.

The goal of this example is to produce the hardware and microprogram which will implement the $\sin (x)$ function in floating-point arithmetic. Before the microprogram can be assembled, the hardware must be defined since the fields of the microinstruction are dedicated to specific hardware once the microinstruction register is hardwired to the devices it controls. Since the final architecture chosen depends on tradeoffs between implementing certain operations in hardware or software, critical applications will require that a cursory analysis of the software be made before the hardware is cast in concrete. Attempting to develop microcode for a tentative architecture will force the issue on which operations are better suited for hardware. Before the architecture or the microprogram requirements can be known, the algorithms which describe the application processes must be defined. Once an algorithm is formulated it can be broken down into operations involving variable and constant quantities. The variables can be assigned to registers and then the algorithm can be translated into a microprogram. The following steps illustrate the plan for this CPU design example incorporating a floating-point $\sin (x)$ utility:

| Step | 1: Choose a floating-point number system |
| :---: | :---: |
| Step | 2: Choose an algorithm for approximating $\sin (x)$ |
| Step | 3: Make 'AS888 register assignments |
| Step | 4: Substitute registers for variables in the algorithm |
| Step | 5: Decompose steps of the algorithm into simple operations |
| Step | 6: Translate into 'AS888/890 operations; identify subroutines |
| Step | 7: Translate subroutines into 'AS888/890 operations |
| Step | 8: Evaluate tradeoffs and block diagram the hardware |
| Step | 9: Define microinstruction fields during detailed hardware design |
| Step 10 | 0: Assemble the microprogram |

### 5.1 Choose a Floating-Point Number System

An IEEE floating-point format will be chosen for this example for portability of data and software. It is important to note that the IEEE defines many standards in arithmetic processing, but for simplicity this example will encompass only number format. Furthermore, while several formats are IEEE compatible, only the basic single-precision format will be considered.

The IEEE basic single-precision format is defined as a 32-bit representation in which the component fields are a 1-bit sign $s$, an 8-bit biased exponent $e$ and a 23-bit fraction $f$ which are assembled in the following order:

| $s$ | $e$ | $f$ |
| :--- | :--- | :--- |
| 31 |  | 0 |

The quantity is evaluated as $(-1)^{s} 2 e-127$ (1.f). Not-a-number, zero and infinity have special representations. The one preceding the binary point is implied and is called the implicit one or implicit bit. It coincides with the fact that the digits are normalized (left justified).

### 5.2 Choose an Algorithm for $\operatorname{Sin}(x)$

Many algorithms are discussed in the literature for approximating useful quantities like $\sin (x)$. Literature research is a good place to start to familiarize oneself with various algorithms and tradeoffs for a particlar application. Computer simulation is also useful to compare algorithms for speed and accuracy. R.F. Ruckdeschel in BASIC Scientific Subroutines, Vol. 1 (BYTE, McGraw-Hill Publications Co. New York, N.Y., 1981, pp. 159-191 discusses tradeoffs and provides a simulation in BASIC for a $\sin (x)$ algorithm. An adaptation of this material has been chosen for this example:
A) Reduce angle range to first quadrant. ( $0 \leq x \leq \pi / 2$ )
B) Compute $\sin (x)=\sum_{n=0}^{6} A_{n} x^{2 n-1}$. The coefficients are:

| Coefficient | Decimal | IEEE hex |
| :---: | :---: | :--- |
| $\mathrm{A}_{0}$ | 1.000000 | 3F80 0000 |
| $\mathrm{A}_{1}$ | -0.1666667 | BE2A AAAD |
| $\mathrm{A}_{2}$ | 0.008333333 | 3 C08 8888 |
| $\mathrm{A}_{3}$ | -0.0001984127 | B950 0D01 |
| $\mathrm{A}_{4}$ | 0.000002755760 | 3638 EF99 |
| $\mathrm{A}_{5}$ | -0.00000002507060 | B2D7 5AD5 |
| $\mathrm{A}_{6}$ | 0.0000000001641060 | $2 F 346 \mathrm{FBC}$ |

The algorithm can be implemented in the following steps:
A) Reduce angle range to first quadrant. ( $0 \leq \mathrm{x} \leq \pi / 2$ )

1) $\operatorname{SIGN}=\operatorname{SGN}(x)$
2) $A B S X=\|x\|$
3) $\mathrm{XNEW}=\mathrm{ABSX}-2 \pi \times \operatorname{INT}(\mathrm{ABSX} / 2 \pi)$
4) If XNEW $>\pi$ then SIGN $=-$ SIGN and XNEW $=$ XNEW $-\pi$
5) If XNEW $>\pi / 2$ then XNEW $=\pi-$ XNEW
where

$$
\begin{aligned}
& \operatorname{SGN}(x)=\left\{\begin{array}{l}
+1 \text { if } x \geq 0 \\
-1 \text { if } x<0
\end{array}\right. \\
& \operatorname{INT}(x)=\text { integer function }
\end{aligned}
$$

B) Compute $\sin (x)=\sum_{n=0}^{6} A_{n} x^{2 n-1}$.

1) Let $X S Q R=X N E W 2$; INITIALIZE SINX $=0$
2) Do $i=6$ to 1 step -1
$\operatorname{SINX}=X S Q R \times \operatorname{SINX}+A(i)$
Enddo
3) $\operatorname{SINX}=$ SIGN $\times X N E W \times$ SINX

Step B-2 computes the summation in a geometric series for economy. The major difference between steps $A$ and $B$ is that $A$ requires more diverse ALU operations while $B$ uses only multiplication and addition recursively.

### 5.3 Make 'AS888 Register Assignments

Just as in assembly language programming, registers must be allocated for variables. Using Rn to denote the 'AS888 register whose address is $n$, where $0 \leq n \leq F$ (hex), the following register assignments can be made:

$$
\begin{aligned}
& \text { RO }=\mathrm{X} \\
& \text { R1 }=\text { SIGN } \\
& \text { R2 }=\text { ABSX } \\
& \text { R3 }=\text { XNEW } \\
& \text { R4 }=\text { XSQR } \\
& \text { R5 }=\text { SINX }
\end{aligned}
$$

### 5.4 Substitute Registers for Variables in the Algorithm

Now the algorithm can be rewritten with registers replacing variables:
A) Reduce angle range to first quadrant ( $0 \leq \mathrm{x} \leq \pi / 2$ ).

1) $\mathrm{R} 1=\operatorname{SGN}(\mathrm{RO})$
2) $R 2=\|R O\|$
3) $\mathrm{R} 3=\mathrm{R} 2-2 \pi \times \operatorname{INT}(\mathrm{R} 2 / 2 \pi)$
4) If R3> $\pi$ then R1 $=-\mathrm{R} 1$; R3 $=\mathrm{R} 3-\pi$
5) If R3 $>\pi / 2$ then R3 $=\pi-$ R3
B) Compute $\sin (x) \simeq \sum_{n=0}^{6} A_{n} x^{2 n-1}$.
6) Let R4 $=$ RO2; INITIALIZE R5 $=0$
7) Do $i=6$ to 1 step -1
$R 5=R 4 \times R 5+A(i)$
Enddo
8) $\mathrm{R} 5=\mathrm{R} 1 \times \mathrm{RO} \times \mathrm{R} 5$

Since various references to constants are made, it is probably best to load constants as needed rather than attempt to allocate registers for them. Constants can be loaded from a constant field in the microinstruction or from ROM. The tradeoff is 32 bits by 16 K of micromemory versus 32 bits by the number of constants (typically less than 16 K$)$. For this example, it will be assumed that a constant field in the microinstruction is acceptable.

### 5.5 Decompose Steps in the Algorithm into Simple Operations

The $\sin (x)$ function can be microprogrammed as a subroutine; let FSIN be its entry address. RO would be loaded with $x$ before FSIN were called. Upon return, R5 would contain $\sin (x)$. Now decompose the steps in the algorithm into simple arithmetic and logical operations. Other operations can be left as functions to be defined later.

FSIN: SUBROUTINE
; A) Reduce angle range to first quadrant. ( $0 \leq x \leq \pi / 2$ )

| $\mathrm{R} 1=\operatorname{SGN}(\mathrm{RO})$ | 1) Let R1 = Sign of RO |
| :---: | :---: |
| $\mathrm{R} 2=\mathrm{ABS}(\mathrm{RO})$ | 2) $\mathrm{R} 2=\\|\mathrm{RO}\\|$ |
| $\mathrm{R} 3=\mathrm{R} 2 * 10 \mathrm{VR} 2 \mathrm{PI}$ | 3) R3 $=\mathrm{R} 2-2 \pi * \operatorname{INT}(\mathrm{R} 2 / 2 \pi)$ |
| $\mathrm{R} 3=\mathrm{INT}(\mathrm{R} 3$ ) |  |
| $\mathrm{R} 3=\mathrm{R} 3 * 2 \mathrm{PI}$ |  |
| $\mathrm{R} 3=\mathrm{R} 2-\mathrm{R} 3$ |  |
| $\mathrm{Y}=\mathrm{R} 3-\mathrm{PI}$ | 4) If R3 $>\pi$, |
| Jump if Negative to Step A-5 |  |
| $\mathrm{R} 1=-\mathrm{R} 1$ | then R1 $=-\mathrm{R} 1$; |
| $\mathrm{R} 3=\mathrm{R} 3-\mathrm{Pl}$ | $\mathrm{R} 3=\mathrm{R} 3-\pi$ |
| $\mathrm{Y}=$ PIOVR2 -R 3 |  |
| Jump if Negative to Step B-1 | 5) If R3 > $\pi / 2$ |
| $\mathrm{R} 3=\mathrm{Pl}-\mathrm{R} 3$ | then R3 $=\pi-\mathrm{R} 3$ |

```
; B) Compute \(\sin (x) \simeq \sum_{n=0}^{6} A_{n} x^{2 n-1}\)
```



```
\(R 5=R 4 * R 5\)
\(R 5=R 5+A 2\)
\(R 5=R 4\) * R5
\(R 5=R 5+\mathrm{A} 1\)
\(\mathrm{R} 5=\mathrm{R} 4\) * R5
\(R 5=R 5+A 0\)
\(\mathrm{R} 5=\mathrm{RO}\) * R5
R5 = R5 * R1 : RETURN ;
```


## END SUBROUTINE

### 5.6 Translate into 'AS888/890 Instructions; Identify Subroutines

The simplified steps of the algorithm can be represented fairly easily as 'AS888/890 instructions. Necessary functions (and suggested names) can be identified by inspection as:

1) FMUL - Floating-point multiplication
2) FADD - Floating-point addition
3) FINT - Floating-point integer conversion
4) FINV - Floating-point additive inverse (to subtract using FADD)
5) FABS - Floating-point absolute value
6) FSGN - Floating-point sign test
7) FCHS - Floating-point change of sign (to multiply by SIGN)
"Function" in this context refers to a special operation regardless of how it is coded. In fact, FMUL and FADD are fairly complex and require detailed explanation. FINV, FABS, FSGN and FCHS are single instruction operations that mask or mask and test. FINT requires several inline instructions or a subroutine and will be left to the interested reader as an exercise. Now the steps of the algorithm can be translated into 'AS888/890 operations which include references to these functions.

FSIN: SUBROUTINE
; A) Reduce angle range to first quadrant. ( $0 \leq x \leq \pi / 2$ )

```
    R1 = FSGN(RO) ;Get sign bit (MSB)
    R2 = FABS(RO) ; Take absolute value (clear MSB)
    R3 = FMUL(R2,1OVR2PI) ; Multiply register and constant
    R3 = FINT(R3) ; Floating-point integer conversion
    R3 = FMUL(R3,2PI) ; Multiply register and constant
    R3 = FADD(R2,INV(R3)) ; Subtract registers by adding inverse
    Y = FADD(R3,NEGPI) : TEST NEG; Subtract by adding negative constant
    JT SIN1 ; Jump if true (jump if negative)
    R1 = FINV(R1) ; Complement sign of R1
    R3 = FADD(R3,NEGPI) ; Subtract by adding negative constant
SIN1:Y = PIOVR2 - R3 : TEST NEG ; Subtract to compare (don't store)
    JT SIN2 ; Jump if true (jump if negative)
    R3 = FADD(PI,FINV(R3)) ; Subtract by adding negative register
```

; B) Compute $\sin (x)=\sum_{n=0}^{6} A_{n} \times 2 n-1$
SIN2: R4 = FMUL(RO,RO) ; Square by multiplying
R5 = A6 ; Initialize series
R5 $=$ FMUL (R4,R5) ; Multiply registers
R5 $=$ FADD (R5,A5) ; Add coefficient
R5 $=$ FMUL(R4,R5) ; ; Multiply registers
R5 $=$ FADD (R5,A4) ; Add coefficient
R5 $=$ FMUL(R4,R5) ; Multiply registers
R5 $=$ FADD (R5,A3) ; Add coefficient
R5 = FMUL(R4,R5) ; Multiply registers
R5 = FADD(R5,A2) ; Add coefficient
R5 $=$ FMUL(R4,R5) ; Multiply registers
R5 $=$ FADD (R5,A1) ; Add coefficient
R5 $=$ FMUL(R4,R5) ; Multiply registers
R5 $=$ FADD $($ R5,AO $) \quad$; Add coefficient
R5 $=$ FMUL(RO,R5) ; Multiply registers
R5 $=\mathrm{FCHS}(\mathrm{R} 5, \mathrm{R} 1):$ RETURN ; Change MSB of R5 to MSB of R1

END SUBROUTINE

This contrived language has a syntax which may be suitable for a source program. For the sake of illustration, it can be assumed that the microassembler recognizes this particular syntax. The series was computed inline instead of using a loop since it is relatively short. If a loop were used, a means of indexing the constants would be required.

### 5.7 Expand Subroutines into 'AS888/890 Operations

FMUL and FADD algorithms can now be expanded. Since they are called extensively from FSIN, they are more critical to the efficiency of the final design. Wherever possible, it is desirable to reduce the execution time of both in order to maintain efficiency.

### 5.7.1 Floating-Point Multiplication

Let M 1 be the multiplier and M 2 be the multiplicand whose product is P . Let the sign, exponent and fraction fields of their IEEE representation be:

```
M1: |S1|E1|F1|
M2 : |S2|E2|F2|
    P : |S3|E3|F3|
```

$P$ is found by multiplying mantissas (fraction plus implicit one) and adding exponents. Since M1 and M2 are normalized, the range of $1 . \mathrm{F} 1 \times 1 . \mathrm{F} 2$ is

$$
1.00 \ldots 0 \leq 1 . \mathrm{F} 1 \times 1 . \mathrm{F} 2 \leq 11.1 \ldots 10
$$

The implicit bit may "overflow" into bit position 24. This type of overflow must be detected so that the result can be normalized. Normalization requires right shifting the result of 1.F1 $\times 1 . \mathrm{F} 2$ and incrementing E3. The implicit bit is then cleared when S3, E3 and M3 are packed to form P. The floating-point multiplication algorithm may then be defined as follows:

1) Unpack M1 into signed fraction (SF1) and exponent (E1)
2) Set the implicit bit in SF1
3) Unpack M2 into signed fraction (SF2) and exponent (E2)
4) Set the implicit bit in SF2
5) Perform SF3 $=$ SF1 $\times$ SF2 using signed integer multiplication
6) Perform E3 = E1 + E2
7) Test SF3 for overflow into bit 24
8) If true, then increment E3 and right shift SF3
9) Clear the implicit bit in SF3
10) Pack E3 and SF3 to get $P$

As before, the steps of this algorithm can be broken down into simpler operations:

1) Unpack M1 into signed fraction (SF1) and exponent (E1)
$\mathrm{E} 1=\operatorname{FEXP}(\mathrm{M} 1)$
SF1 $=\operatorname{FRAC}(\mathrm{M} 1)$
2) Set the implicit bit in SF1 SF1 = SF1 OR BIT23
3) Unpack M2 into signed fraction (SF2) and exponent (E2) $\mathrm{E} 2=\mathrm{FEXP}(\mathrm{M} 2)$ SF2 $=$ FRAC (M2)
4) Set the implicit bit in SF2 SF2 = SF2 OR BIT23
5) Perform SF3 $=$ SF1 $\times$ SF2 using signed integer multiplication SF3 = IMUL (SF1, SF2)
6) Perform E3 $=\mathrm{E} 1+\mathrm{E} 2$ $\mathrm{E} 3=\mathrm{E} 1+\mathrm{E} 2$
7) Test SF3 for overflow into bit 24

TEST (SF3 AND BIT24) JUMP IF FALSE to step 9
8) If true, then increment E3 and right shift SF3 INC E3
SF3 $=$ RSHFT (SF3)
9) Clear the implicit bit in SF3.

SF3 = SF3 AND NOT_BIT23
10) Pack E3 and SF3 to get $P$ $P=S F 3$ OR E3

FEXP, FRAC, testing bit 24 and setting/clearing bit 23 are all mask operations that translate into single 'AS888 instructions. The integer multiplication (IMUL) is simply the multiplication algorithm supported by the 'AS888 instruction set. No significant hardware features are required to do floating-point multiplication, nor are any subroutines required to support it.

Register assignments can now be made as before. Since FSIN uses registers in the lower half of the register file, it might be preferable to restrict FMUL to the upper registers. For example:

```
RF=P
RE = M1, F1, SF1
RD = M2, F2, SF2
RC = E1
RB = E2
```

RE and RD can share variables that need not be preserved. Using this assignment, FMUL computes RF = FMUL(RE,RD). RE and RD must be loaded prior to calling FMUL and RF must be stored upon return. By substituting registers for variables and reorganizing operations in the FMUL algorithm to better fit 'AS888/890 operations the following source program may be created:

FMUL: SUBROUTINE

| $\mathrm{RC}=\mathrm{FEXP}(\mathrm{RE})$ | ; Unpack M1 into exponent |
| :---: | :---: |
| $R E=F R A C(R E)$ | ; and fraction |
| RE $=$ RE OR BIT23 | ; Set implicit bit |
| $\mathrm{MQ}=\mathrm{SMTC}(\mathrm{RE})$ | ; Prepare to multiply |
| $R B=F E X P(R D)$ | ; Unpack M2 into exponent |
| $\mathrm{RD}=\mathrm{FMAG}(\mathrm{RD})$ | ; and fraction |
| $\mathrm{RD}=\mathrm{RD}$ OR BIT23 | ; Set implicit bit |
| RD $=$ SMTC(RD) | ; Prepare to multiply |
| $R E=0: R C A=\# 22 d$ | ; Initialize to multiply |
| RE $=$ SMULI RD : LOOP RCA | ; Integer multiplication iteration |
| RE $=$ SMULT RD | ; Final step in signed multiply |
| $Y=$ TBO(RE, BIT 1 ) $: B Y T E=\# 0100$ | TEST Z ; Test "overflow' |
| JF FMUL1 | ; Jump if false (exponent ok) |
| INEX(RC) | ; Increment exponent: add 00800000 |
| $R E=S R A(R E)$ | Shift fraction to normalize |
| FMUL1:RC = RC + RB: TEST CARRY JT ERROR | ; Add exponents and test carry <br> ; Jump if carry true to handler |
| $\mathrm{RE}=\mathrm{SMTC}(\mathrm{RE})$ | ; Get sign magnitude fraction |
| $R E=R E$ AND \# 807F_FFFFh | ; Clear implicit bit |
| RF = RE OR RC : RETURN | ; Pack fraction and exponent |

### 5.7.2 Floating-Point Addition

The floating-point addition algorithm (FADD) is slightly more complex than FMUL, since the two addends will usually not have the same exponent. Therefore the smaller (absolute value) addend must first be chosen by comparing exponents. Then it must be denormalized to align its digits with the digits of the larger addend. In other words, the two addends must have the same exponent before their fractions can be added. This process can be described by the following algorithm:

1) Unpack A1 to get SF1 and E1
2) Set implicit bit in SF1
3) Unpack A2 to get SF2 and E2
4) Set implicit bit in SF2
5) If $\mathrm{E} 2>\mathrm{E} 1$ then go to step 9 ( $\|\mathrm{A} 1\| \leq\|\mathrm{A} 2\|$ )
6) Let DIFF = E1 - E2
7) Do i $=1$ to DIFF

SF2 $=$ RSHFT(SF2) (Arithmetic right shift)
Enddo
8) Let E3 = E1, go to step 12 $(\|A 2\|>\|A 1\|)$
9) Let DIFF = E2 - E1
10) Do $i=1$ to DIFF SF1 $=$ RSHFT(SF1) (Arithmetic right shift) Enddo
11) Let E3 = E2
12) $\mathrm{SF} 3=\mathrm{SF} 1+\mathrm{SF} 2$
13) Test "overflow" into bit 24
14) Jump if false to step 17
15) Increment exponent E3
16) Normalize signed fraction with right arithmetic shift
17) Clear implicit bit
18) Pack: SUM $=$ SF3 or E3
19) Return

Register assignments for variables must now be made. Since FSIN uses registers in the lower half of the 'AS888 register file, it is necessary to use the upper registers:

$$
\begin{aligned}
& \mathrm{RF}=\mathrm{SUM} \\
& \mathrm{RE}=\mathrm{A} 1, \mathrm{~F} 1, \mathrm{SF} 1 \\
& \mathrm{RD}=\mathrm{A} 2, \mathrm{~F} 2, \mathrm{SF} 2 \\
& \mathrm{RC}=\mathrm{E} 1 \\
& \mathrm{RB}=\mathrm{E} 2
\end{aligned}
$$

By slightly reorganizing the sequence to better fit 'AS888/890 operations, the following microprogram to perform FADD can be created:

## FADD: SUBROUTINE

; 1) Unpack A1 to get SF1 and E1

$$
\begin{array}{ll}
R C=\operatorname{FEXP}(R E) & \text {; Get exponent (E1) } \\
R E=F R A C(R E) & \text {; Get signed fraction (SF1) }
\end{array}
$$

; 2) Set implicit bit in SF1
$M Q=$ RE OR BIT23 ; Set implicit bit
RE $=$ SMTC(RE) ; Convert to two's complement
; 3) Unpack A2 to get SF2 and A2

| RB $=$ FEXP(RD) | ; Get exponent (E2) |
| :--- | :--- |
| RD $=$ FRAC(RD) | ;Get signed fraction (SF2) |

; 4) Set implicit bit in SF2

| RD $=$ RD OR BIT23 | ; Set implicit bit |
| :--- | :--- |
| RD $=$ SMTC(RD) | ; Convert to two's complement |

; 5) If E2 > E1 then go to step 9
RF = RC - RB: TEST NEGATIVE ; Compare A2 from A1
JT FADD1 : RCA = \#8 ; Jump if E2 > E1; set up loop count
; 6) Let DIFF = E1 - E2.
Y/RF $=$ SLC(RF) : LOOP RCA ; Rotate 8 times to get difference
RCA $=$ Y/RF ; Load difference in loop counter
; 7) Do $\mathbf{i}=1$ to DIFF
SF2 $=$ RSHFT(SF2)
Enddo
RD $=$ SRA(RD) : LOOP RCA ; Orient digits of smaller addend
; 8) Let E3 = E1, go to step 12
RB = RC : JUMP FADD2 ; Swap registers and branch
; 9) Let DIFF = E2 - E1
FADD1: RF $=$ NOT(RF) ; Complement result of E1 - E2
Y/RF $=\operatorname{SLC}($ RF ) : LOOP RCA ; Shift 8 times to get DIFF
RCA $=$ Y/RF ; Load DIFF in loop counter
;10) Do $i=1$ TO DIFF
SF1 = RSHFT(SF1)
Enddo RE $=$ SRA(RE) : LOOP RCA ; Align SF1 with SF2
;11) Let E3 = E2 (no instruction required - RB already has E2 in it)
;12) $\mathrm{SF} 3=\mathrm{SF} 1+\mathrm{SF} 2$
FADD2: $R F=R D+R E$; Add
RF $=$ SMTC(RF) ; Convert to sign-magnitude
;13) Test '"overflow' into bit 24
RF $=$ TBO (RF, BIT24) ; Check for normalization
;14) Jump if false to step 17
JF FADD3 ; If so, finish and exit
;15) Else increment exponent INC RB : TEST NEG ; Test for exponent overflow
;16) Normalize signed fraction RF $=$ SRA(RF) : JT ERROR ; Jump to error handler if overflow
;17) Clear implicit bit
FADD3: RF $=$ SETO (RF, BIT23) ; Reset bit 23 of RF
;18) Pack: SUM $=$ SF3 OR E3
RF = RF OR RB: RETURN ; Or signed fraction and exponent

There is an important consequence of FADD which impacts the hardware. Since the number of shifts required to denormalize the small addend is data dependent (computed in the ALU) it is necessary to provide a path between the ALU $Y$ bus and the 'AS890 DRA bus. All the other operations are simple 'AS888/890 instructions, including the FRAC and FEXP mask operations discussed during the development of FMUL. ERROR is a floating-point overflow error handler.

### 5.8 Evaluate Tradeoffs and Block Diagram the Hardware

A rough estimate of the FSIN worst case execution time can be arrived at by making the following observations about FSIN, FMUL and FADD:

```
FMUL
    integer recursion \simeq 22 cycles
    other instructions }\simeq18\mathrm{ cycles
    total }=40\mathrm{ cycles
FADD
    denormalization }\simeq23\mathrm{ cycles
    other instructions =25 cycles
    total \simeq 50 cycles
FSIN
    number of calls to FMUL = 12
    number of calls to FADD = 11
    number of other cycles }=1
```

Approximate worst case total $=10+(12 \times 40)+(11 \times 50)=1040$ cycles. At 50 nanoseconds per cycle, this requires approximately 52 microseconds. There are few improvements that could be made in hardware to speed this time, except perhaps the addition of a flash multiplier which would reduce the integer computation by about 20 cycles (an overall reduction of about two percent). A barrel shifter could have the same benefit during floating-point addition for a total reduction of about 4 percent. For the sake of simplicity, it will be assumed that 52 microseconds is acceptable for the $\sin (x)$ computation.

Another issue which must be considered is the problem of loading the 'AS888 and 'AS890 with constants. A slight materials cost reduction might be realized by storing constants in table PROMs rather than in control store memory. An interesting use of the DRA and DRB ports on the 'AS890 would be to use the output of RCA or RCB to index data in the constant PROM. This would allow long series to be implemented in loop form rather than the inline method used in FSIN. Once again, the constant PROM will not be implemented for the sake of simplicity.
Now the architecture can be designed to meet the requirements identified throughout this analysis:

1) A path between the 'AS888 Y bus and the 'AS890 DRA bus.
2) A path between the microinstruction register and the 'AS890 DRA bus for loading loop counts and branch addresses.
3) A path between the microinstruction register and the 'AS888 $Y$ bus for loading constants.
4) Independent control of $\overline{S I O O}$ in each 'AS888 slice to allow bit/byte instructions.
5) A status register to store 'AS888 status for testing.
6) A status mux to test the 'AS888 status, bit 23 of the 'AS888 Y bus, bit 24 of the 'AS888 Y bus and hardwired 0 and 1.

A system having these features is illustrated in Figure 5.1.


Figure 5-1. Block Diagram of Floating-Point Processor

### 5.9 Define Microinstruction Fields During Detailed Hardware Design

The detailed hardware design will produce a wiring diagram that fixes the position within the microinstruction of each of the various control signals that are connected from the microinstruction register to the 'AS888, 'AS890, status mux and any other special hardware. Once this design is complete it is possible for the assembler to sort the control bits of each instruction so that they will be properly oriented when the microprogram is installed in the target system.

### 5.10 Assemble the Microprogram

TI is currently developing an 'AS888/890 microassembler. Several microassemblers are commercially available, and many users prefer to write their own. The microprogram shown in Table 5-1 was hand-assembled, but has a syntax that is suitable for interpretation by a user-written assembler.

* R1 = FSGN(R0)
$0000 \mathrm{SIN}:$

0001
0002

0003
0004
0005
0006

0007
R1 = R0 AND \#8000 0000

* $\mathrm{R} 2=\mathrm{FABS}(\mathrm{RO})$

R2 $=$ R0

* $\mathrm{R} 3=\mathrm{FMUL}(\mathrm{R} 2,10 \mathrm{VR} 2 \mathrm{PI})$
$R E=R 2$
RD $=$ \#3EA2 F984h JSR FMUL $\mathrm{R} 3=\mathrm{RF}$
* R3 $=$ FINT(R3)
$\mathrm{RF}=\mathrm{R} 3$ R3 = RF
* R3 $=$ FMUL(R3,2PI)

RE $=$ R3
RD $=$ \#40C9 0FDBh
JSR FMUL
R3 $=$ RF

* R3 $=$ FADD(R2,INV(R3))
$R E=R 2$ JSR FADD
$R 3=R F$

R2 $=$ R0 SET0 \#80h : BYTE $=\# 1000 \mathrm{~b}$

JSR FINT [EXERCISE FOR READER]

RE $=$ R2
RD $=$ R5 XOR $\# 80000000 \mathrm{~h}$

Table 5.1. Floating Point $\operatorname{Sin}(x)$ Microprogram


Table 5.1. Floating Point $\operatorname{Sin}(x)$ Microprogram (continued)
$Y=\operatorname{FADD}($ R2,NEGPI)
$R E=R 2$
RD $=$ \#C059 0FDBh JSR FADD Y = RF : TEST NEG JT SIN1

* $\mathrm{R} 1=\mathrm{FINV}(\mathrm{R} 1)$ R1 = R1 XOR \#8000 0000h
* $\mathrm{R} 3=$ FADD(R3,NEGPI)

RE $=$ R3
RD = \#C059 0FDBh JSR FADD $R 3=R F$

* SIN1: $\quad$ Y = FADD (PIOVR2,INV(R3)) : TEST NEG RE $=\# 3 F C 9$ OFDBh RD = R3 XOR \#8000 0000h JSR FADD Y = RF: TEST NEG JT SIN2
* R3 $=$ FADD(PI,FINV(R3) RE $=\# 4059$ OFDBh RD $=$ R3 XOR \#8000 0000h JSR FADD $\mathrm{R} 3=\mathrm{RF}$
* SIN2: R4 $=$ FMUL(RO,RO)

SIN2: $\quad R E=R O$
$R D=R 0$ JSR FMUL R4 $=$ RF

Table 5.1. Floating Point $\operatorname{Sin}(x)$ Microprogram (continued)

* $\mathrm{R} 5=\mathrm{A} 6$ R5 = \#2F34 6FBCh
* R5 = FMUL(R4,R5) $R E=R 4$ $R D=R 5$ JSR FMUL
$R 5=R F$
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 5)$
$R E=R 5$
RD $=$ \#B2D7 5AD5h
JSR FADD
$R 5=R F$
* $\mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5)$
$\mathrm{RE}=\mathrm{R} 4$
$\mathrm{RD}=\mathrm{R} 5$
JSR FMUL
R5 = RF
* R5 = FADD(R5,A4) $R E=R 5$
RD = \#3638 EF99h JSR FADD $\mathrm{R} 5=\mathrm{RF}$
* R5 $=$ FMUL(R4,R5)
$\mathrm{RE}=\mathrm{R} 4$
$\mathrm{RD}=\mathrm{R} 5$
003A
003B
003C 003D JSR FMUL $R 5=R F$

Table 5.1. Floating Point Sin(x) Microprogram (continued)

* R5 = FADD(R5,A3)
$R E=R 5$
$\mathrm{RD}=$ \#B950 0D01h
JSR FADD
$\mathrm{R} 5=\mathrm{RF}$
* R5 $=$ FMUL(R4,R5)
$R E=R 4$
RD $=$ R5
JSR FMUL
R5 = RF
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 2)$
$R E=R 5$
$\mathrm{RD}=\# 3 \mathrm{C} 088888 \mathrm{~h}$
JSR FADD
R5 = RF
* $\mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5)$
$\mathrm{RE}=\mathrm{R} 4$
$\mathrm{RD}=\mathrm{R} 5$
JSR FMUL
R5 = RF
* $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 1)$
$R E=R 5$
RD $=$ \#BE2A AAADh
JSR FADD
R5 = RF
* $\mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 4, \mathrm{R} 5)$
$R E=R 4$
$R D=R 5$ JSR FMUL
$R 5=R F$

|  | 32-bit <br> Constant |  |  | DRB13DRBO | 岕 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times$ | X $\times \times \times 1$1 | 7 |
| $0 \times \mathrm{CDXX} 1111 \times \mathrm{F}$ ¢ | B 9500 D 01 | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | X $\times \times \times 1111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times$ | 11111 | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times$ | X $\times \times \times 1111$ | 7 |
| $05 \times \mathrm{O} 0 \times 1.1100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 1 \begin{array}{llll}1\end{array}$ | 7 |
| $1 \times \mathrm{XXXX} 111 \times \mathrm{C}$ ¢ F | X $\times \times \times \times \times \times \mathrm{X}$ | 11111 | 0140 | $\begin{array}{lllllll}0 & 0 & 6 & 0 & 1 & 1\end{array}$ | 7 |
| $0 \mathrm{FX50X11} 100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 11111 | $027 \times$ | X $\times \times \times 1$1 | 7 |
| $0 \times \mathrm{CDXX1111}$ 1 1 F F | 3 C 08888888 | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 111$ | 7 |
|  | X X X X X X X | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 0140 | 00741111 | 7 |
| $0 \mathrm{FX50X11} 100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | X $\times \times \times 1 \begin{array}{llll}1 & 1\end{array}$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \times$ | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $05 \times \mathrm{O}$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 1 \begin{array}{llll}1 & 1\end{array}$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 0140 | 006601111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | $027 \times$ | X $\times \times \times 111$ | 7 |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times$ | - $\times \times \times \times 1 \begin{array}{llll}1\end{array}$ | 7 |
| $0 \times \mathrm{CDXX} 111111 \mathrm{~F}$ | BE 2 AAAAD | $1 \begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | - $\times \times \times \times 1111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F \mathrm{~F}$ | X $\times \times \times \times \times \times \mathrm{X}$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 0140 | 0074111 | 7 |
| $0 \mathrm{FX} 50 \times 11100 \mathrm{~F} 6$ | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | $027 \times$ | $\times \times \times \times 1111$ | 7 |
| $04 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 1111$ | 7 |
| $05 \times \mathrm{O}$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 \times$ | $\times \times \times \times 1 \begin{array}{llll} \\ \times\end{array}$ | 7 |
| $1 \times \times \mathrm{X} \times 111 \times \mathrm{P}$ ¢ F | $\times \times \times \times \times \times \times$ | 1 1 1 1 | 0140 | 0060111 | 7 |
| $0 \mathrm{~F} \times 50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | 111 | $027 \times$ | $\times \times \times \times 111$ | 7 |

Table 5．1．Floating Point $\operatorname{Sin}(x)$ Microprogram（continued）
＊ $\mathrm{R} 5=\mathrm{FADD}(\mathrm{R} 5, \mathrm{~A} 0)$

## 0056

0057
0058
0059

005A
005B
005C
005D

005E
005F

0060 FMUL： RD $=$ \＃3F80 0000h JSR FADD $R 5=R F$
＊ $\mathrm{R} 5=\mathrm{FMUL}(\mathrm{R} 0, \mathrm{R} 5)$
$R E=R O$
$R D=R 5$ JSR FMUL R5 $=$ RF
＊R5 $=$ FCHS（R5，R1）：RETURN R1＝R1 OR \＃7FFF FFFFh R5＝R5 XOR R1 ：RETURN
＊ $\mathrm{RC}=\mathrm{FEXP}(\mathrm{RE})$ RC $=$ RE AND \＃7F80．0000h
＊ $\mathrm{RE}=\mathrm{FRAC}(\mathrm{RE})$ RE＝RE AND \＃807F FFFFh
＊RE＝RE OR bit23 RE $=$ RE OR \＃0080 0000h
＊MQ＝SMTC（RE） $R E=S M T C(R E)$ LOADMO ：PASS
＊ $\mathrm{RB}=\mathrm{FEXP}(\mathrm{RD})$ $R B=R D A N D$ \＃7F80 0000h

|  | 32-bit <br> Constant |  |  |  | 岃 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $05 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | 1111 | 027 | 人 $\times \times \times \times 111$ | 7 |
| $0 \times \mathrm{CDXX1111} \mathrm{\times FF}$ | 3 F 800000 | 11111 | 027 | X $\times \times \times 1111$ | 7 |
| $1 \times \mathrm{X} \times \times \mathrm{X} 111 \times \mathrm{FF}$ | $\times \times \times \times \times \times \times$ | 11111 | 014 | 0074111 | 7 |
| 0 FX 50 X 11100 F 6 | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | 027 | X X X $\times 111$ | 7 |
| $00 \times \mathrm{E} 0 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | 027 | x $\times \times \times \times 1111$ | 7 |
| $05 \times \mathrm{O} \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 027 | X $\times \times \times 111$ | 7 |
| $1 \times \times \times \times \times 111 \times \times F$ | $\times \times \times \times \times \times \times \times$ | 11111 | 014 | 0060111 | 7 |
| OFX $50 \times 11100 \mathrm{~F} 6$ | $\times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 027 | X $\times \times \times 111$ | 7 |
| $01 \times 10211100 \mathrm{FB}$ | B 7 FFFFFF | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 027 | 人XXX111 | 7 |
| 051500111100 F | $\times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 022 | $\times \times \times \times 111$ | 7 |
| OEXC0211100FA | 7 F 800000 | 1111 | 027 | $\times \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 FFFFF | 1111 | 027 | $\times \times \times 111$ | 7 |
| OEXF0211100FB | 00800000 | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| OXEEX 011111058 | $\times \times \times \times \times \times \times \times$ | 11111 | 027 | X $\times \times \times 1 \begin{array}{lll}1\end{array}$ | 7 |
| $1 \mathrm{EXX} 0 \times 11110 \mathrm{E} 6$ | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 027 | X $\times \times \times 111$ | 7 |
| ODXB0211100FA | 7 F 800000 | 111 | 027 | X $\times \times \times 111$ | 7 |

Table 5.1. Floating Point $\operatorname{Sin}(x)$ Microprogram (continued)
0070 FMUL1: $\quad$ RC $=$ RC ADD ${ }^{\circ}$ RB : TEST CARRY
0071
0072
0073

* FADD:

0074 FADD:

* RE $=$ FRAC(RE) RE $=$ RE AND \#807F FFFFh $M O=$ RE OR bit 23 RE $=$ SMTC(RE)
* $\mathrm{RB}=\mathrm{FEXP}(\mathrm{RD})$ $R B=$ RD AND \#7F80 0000

|  | $\begin{gathered} \text { 32-bit } \\ \text { Constant } \end{gathered}$ |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| ODXD0211100FA | 807 FFFFF | 1111 | $027 \times \times \times \times 111$ | 7 |
| $0 \mathrm{D} \times \mathrm{D} 02111100 \mathrm{~F}$ ¢ | 00800000 | 11111 | $027 \times \times \times \times 119$ | 7 |
| $0 \times \mathrm{D} \times 011111 \mathrm{D} 58$ | $\times \times \times \times \times \times \times$ | 1111 | $027 \times \times \times \times 111$ | 7 |
| OEEE 000111110 F 9 | 00000016 | 11111 | $617 \times \times \times \times 111$ | 4 |
| ODEE 000111110060 | $\times \times \times \times \times \times \times$ | 1111 | 567006 A 111 | 4 |
| ODEE 000111100070 | X $\times \times \times \times \times \times \times$ | 1111 | $067 \times \times \times \times 111$ | 7 |
| 00 F 0000111110038 | $\times \times \times \times \times \times \times$ | 1011 | $027 \times \times \times \times 111$ | 4 |
| $1 \times \times \times \times \times \times 111 \times \mathrm{F}$ | $\times \times \times \times \times \times \times \times$ | 1111 | $017 \times \times \times \times 111$ | 7 |
| 0 CXC 02111100 F 1 | 00800000 | 1111 | $027 \times \times \times \times 111$ | 7 |
| OEXEOX1110006 | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| 0 C BCO O 1111000 F 1 | $\times \times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 0 $277 \times \times \times \times 1111$ | 0 |
| $1 \times \times \times \times \times 111 \times \times F$ | X $\times \times \times \times \times \times \times$ | 11111 | $017 \times \times \times \times 111$ | 7 |
| $0 \times E E X 01111058$ | $X \times \times \times \times \times \times$ | 11111 | $027 \times \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 FFFFF | 11111 | $027 \times \times \times \times 111$ | 7 |
| 0 CXCO 211100 FA | 7 F 800000 | 1111 | $027 \times \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 FFFFF | 1111 | $027 \times \times \times \times 111$ | 7 |
| 1 EXX 0111100 E ¢ | 00800000 | 111111 | $027 \times \times \times 111$ | 7 |
| OEXEO211100FA | 807 F F F F F | 1111 | $027 \times \times \times \times 111$ | 7 |
| ODXB0211100FA | 7 F 800000 | 1111 | $027 \times \times \times 11$ | 7 |

Table 5.1. Floating Point Sin(x) Microprogram (continued)

|  | 32-bit <br> Constant | Oion |  | DRB13DRB0 | 岕 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OEXEO211100FA | 807 FFFFF | 11111 | 027 | $\times \times \times \times 1 \begin{array}{lll}1 & 1\end{array}$ | 7 |
| 0 DXD 0211100 FB | 00800000 | 1111 | $027 \times$ | $\times \times \times \times 111$ | 7 |
| $0 \times \mathrm{D} \times 011111058$ | $\times \times \times \times \times \times \times$ | 11111 | $027 x$ | $\times \times \times \times 111$ | 7 |
| 0 C B F 00111100 F 3 | $\times \times \times \times \times \times \times \times$ | 11111 | $027 \times$ | 人 $\times \times \times \times 1 \begin{array}{llll}1\end{array}$ | 2 |
| $1 \times \mathrm{X} \times \times \mathrm{X} 1111 \times \mathrm{CFF}$ | X $\times \times \times \times \times \times 8$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | $617 \times$ | XXXX111 | 4 |
| $0 \mathrm{FXF} 0 \times 110 \times 066$ | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | 5670 | 007 E 111 | 4 |
| $1 \times \mathrm{XXXX1100} \mathrm{\times FF}$ | $\times \times \times \times \times \times \times \times$ | $\begin{array}{lllll}1 & 1 & 1 & 1\end{array}$ | 277 | 0080111 | 7 |
| 0 DXD0X1110006 | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | 167 | 007 E 111 | 4 |
| 0 CXB0X1110 10 FF | X $\times \times \times \times \times \times \times$ | $1 \begin{array}{lllll}1 & 1 & 1\end{array}$ | 027 | $\times \times \times \times 111$ | 7 |
| 0 F X F 0 X 11100 F 1 | $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | 027 | X X X X 111 | 7 |
| 0 F X F 0 X 1100066 | X $\times$ X $\times$ X $\times$ X X | 11111 | 617 | X X X X 1111 | 4 |
| $1 \times \mathrm{XXXX} 1100 \times \mathrm{F}$ | X $\times \times \times \times \times \times \mathrm{X}$ | 11111 | 567 | 0084111 | 4 |
| OEXEOX1110006 | X $\times$ X $\times$ X $\times$ X | 11111 | 277 | 0086111 | 7 |
| ODEFOO11100F1 | $\times \times \times \times \times \times \times \times$ | 11111 | 027 | X $\times \times \times \times 111$ | 7 |
| O X F F X 011111110058 | X X X X X X X X | 1111 | 027 | X $\times$ X $\times 1 \begin{array}{llll}1 & 1\end{array}$ | 7 |
| O 0 F F 00000111111038 | $\times \times \times \times \times \times \times \times$ | 01111 | 027 | X $\times \times \times \times 1$1 | 4 |
| $1 \times \mathrm{XXXX} 111 \mathrm{l} \times \mathrm{F}$ F | X $\times \times \times \times \times \times \mathrm{X}$ | 1111 | 047 | XXXX 1111 | 7 |
| 0 BX B $0 \times 111111 \mathrm{~F}$ ¢ | X $\times \times \times \times \times \times \times$ | $1 \begin{array}{llll}1 & 1 & 1 & 1\end{array}$ | $027 x$ | X $\times \times \times 1$1 | 3 |
| OF7 F 0 X 11110006 | X $\times$ X $\times$ X $\times$ X | 11111 | $017 \times$ | XXXX11119 | 7 |
|  | X $\times \times \times \times \times \times \mathrm{X}$ | $1 \begin{array}{llll}1 & 1 & 1\end{array}$ | $027 \times$ | X $\times \times \times 11$ | 7 |
| 0 FBFOO11100FB | $\mathrm{X} \times \times \times \times \times \times \mathrm{X}$ | 111 | $022 x$ | XXXX111 |  |

## General Information

1

Numerical Index
Glossary
Explanation of Function Tables Parameter Measurement Information Functional Index

LSI Devices
2

## Application Reports

Advanced Schottky Family Error Detection and Correction Memory Mapping<br>Bit-Slice Processor 8-Bit Family Excerpt - SN74AS888, SN74AS890<br>Bit-Slice Processor User's Guide

Mechanical Data

## ORDERING INSTRUCTIONS

Electrical characteristics presented in this data book, unless otherwise noted, apply for circuit type(s) listed in the page heading regardless of package. The availability of a circuit function in a particular package is denoted by an alphabetical reference above the pin-connection diagram(s). These alphabetical references refer to mechanical outline drawings shown in this section.

Factory orders for circuits described in this catalog should include a four-part type number as explained in the following example.


MUST CONTAIN TWO TO FOUR LETTERS

| SN | Standard Prefix |
| :--- | :--- |
| SNJ | JEDEC PUBLICATION 101, Class B |
| JANB | MIL-M- $\mathbf{3 8 5 1 0}$ Qualified |

2. Unique Circuit Description

MUST CONTAIN SIX TO TEN CHARACTERS
(From Individual Data Sheet)
Examples:
74S225
54LS610
74ALS232
74ALS632A
74ALS29864
3. Package

## MUST CONTAIN ONE OR TWO LETTERS

D, DW ('Small Outline" Packages)
J, JD, JG, JT, N, NT, NW, P, W (Dual-in-Line Packages)
FH or FN (Chip Carriers)
(From pin-connection diagram on individual data sheet)
4. Instructions (Dash No.)

3 PEP processing, level 3 ( N or NT packages only)
${ }^{\dagger}$ These circuits in dual-in-line and "small outline" packages are shipped in one of the carriers shown below. Unless a specific method of shipment is specified by the customer (with possible additional costs), circuits will be shipped in the most practical carrier. Please contact your TI sales representative for the method that will best suit your particular needs.

[^61]Dual-in-Line (J, JD, JG, JT, N, NT, NW, P, W)

## D plastic "small outline" packages

Each of these "small outline" packages consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high-humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.


## D plastic "small outline" packages

Each of these "small outline" packages consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high-humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.


NOTES: A. Body dimensions do not include mold flash or protrusion.
B. Mold flash or protrusion shall not exceed 0,15 (0.006).
C. Leads are within $0,25(0.010)$ radius of true position at maximum material dimension.
D. Lead tips to be planar within $\pm 0,051(0.002)$ exclusive of solder.

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

## MECHANICAL DATA

## DW plastic "small outline" packages

Each of these "small outline" packages consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high-humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

## 20-PIN DW PACKAGE




NOTES: A. Body dimensions do not include mold flash or protrusion.
B. Mold flash or protrusion shall not exceed $0,15(0.006)$.
C. Leads are within $0.25(0.010)$ radius of true position at maximum material dimension.
D. Lead tips to be planar within $\pm 0,051(0.002)$ exclusive of solder.

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

## DW plastic "small outline" packages

Each of these "small outline" packages consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high-humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

## 24-PIN DW PACKAGE



NOTES: A. Body dimensions do not include mold flash or protrusion.
B. Mold flash or protrusion shall not exceed 0,15 \{0.006).
C. Leads are within $0,25(0.010)$ radius of true position at maximum material dimension.
D. Lead tips to be planar within $\pm 0,051(0.002)$ exclusive of solder.

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

## FK ceramic chip carrier packages

Each of these hermetically sealed chip carrier packages has a three-layer ceramic base with a metal lid and braze seal. The packages are intended for surface mounting on solder lands on 1,27 (0.050-inch) centers. terminals require no additional cleaning or processing when used in soldered assembly.
FK package terminal assignments conform to JEDEC Standards 1 and 2.

## FK CERAMIC CHIP CARRIER PACKAGES (28-terminal package shown)


*All dimensions and notes for the specified JEDEC outline apply.

all linear dimensions are in millimeters and parenthetically in inches

FN plastic chip carrier package
Each of these chip carrier packages consists of a circuit mounted on a lead frame and encapsulated within an electrically nonconductive plastic compound. The compound withstands soldering temperatures with no deformation, and circuit performance characteristics remain stable when the devices are operated in high-humidity conditions. The packages are intended for surface mounting on solder lands on 1,27(0.050) centers. Leads require no additional cleaning or processing when used in soldered assembly.

FN PLASTIC CHIP CARRIER PACKAGE
(28-terminal package used for illustration)


| JEDEC | NO. OF | A |  | B |  | C |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OUTLINE | TERMINALS | MIN | MAX | MIN | MAX | MIN | MAX |
| MO 047AA | 20 | 9.78 | 10.03 | 8.89 | 9.04 | 7.87 | 8.38 |
|  |  | 10.3851 | 10.3951 | 10.3501 | 10.3561 | 10.3101 | 10.3301 |
| MO 047AB | 28 | 12.32 | 12.57 | 11.43 | 11.58 | 10.41 | 10.92 |
|  |  | 10.4851 | 10.4951 | 10.4501 | $(0.4561$ | 10.4101 | 10.4301 |
| MO 047AC | 44 | 17.40 | 17.65 | 16.51 | 16.66 | 15.49 | 16.00 |
|  |  | 10.6851 | 10.6951 | $10.650)$ | 10.6561 | 10.6101 | 10.6301 |
| MO 047AE | 68 | 25.02 | 25.27 | 24.13 | 24.33 | 23.11 | 23.62 |
|  |  | 10.9851 | 10.9951 | 10.9501 | 10.9561 | 10.9101 | 10.9301 |



Ali dimensions and notes for the specified JEDEC outline apply.
NOTES: A. Centerline of center pin each side is within $0,10(0.004)$ of package centerline as determined by dimension B . B. Location of each pin is within $0,127(0.005)$ of true position with respect to center pin on each side.
C. The lead contact points are planar within $0,10(0.004)$.
alL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

## MECHANICAL DATA

## 68-pin GB pin grid array ceramic package

This is a hermetically sealed ceramic package with metal cap and gold-plated pins.


J ceramic packages (including JD, JT, and JW dual-in-line packages)
Each of these hermetically sealed dual-in-line packages consists of a ceramic base, ceramic cap, and a lead frame. Hermetic sealing is accomplished with glass. The packages are intended for insertion in mounting-hole rows on $7,62(0.300)$ or $15,24(0.600)$ centers. Once the leads are compressed and inserted sufficient tension is provided to secure the package in the board during soldering. Tin-plated ("brightdipped') leads require no additional cleaning or processing when used in soldered assembly.
NOTE: For the 14-, 16-, and 20-pin packages, the letter $J$ is used by itself since these packages are available only in the 7,62 ( 0.300 ) row spacing. For the 24 -pin packages, if no second letter or row spacing is specified, the package is assumed to have $15,24(0.600$ ) row spacing.

14-PIN J CERAMIC


ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

16-PIN J CERAMIC


- For memories of 64 bits and up and a few MSI/LSI products in Series 54/74 and Series 54S/74S that are derived from memory circuit bars, this maximum is 7,62 (0.300). All other dimensions apply without modification.

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES
NOTE A: Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position.

## MECHANICAL DATA

## J ceramic dual-in-line packages (continued)



24-PIN JT CERAMIC, 0.300 -INCH ROW SPACING


ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES
NOTE A: Each pin centerline is located within $0.25(0.010)$ of its true longitudinal position.

## J ceramic dual-in-line packages (continued)



NOTE A: Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position.

## MECHANICAL DATA

## J ceramic dual-in-line packages (continued)

This is a hermetically sealed ceramic package with a metal cap and side-brazed tin-plated leads.

## JD CERAMIC-SIDE BRAZE



| DIM | PINS (N) | 16 | 18 | 20 | 22 |
| :--- | :---: | :---: | :---: | :---: | :---: |
| 24 |  |  |  |  |  |
| $\mathrm{~A}+0.51(+0.020)$ | 7.62 | 7.62 | 7.62 | 7.62 | 7.62 |
| $-0.25(-0.010)$ | $(0.300)$ | $(0.300)$ | $(0.300)$ | $(0.300)$ | $(0.300)$ |
| $\mathrm{B}(\mathrm{MAX})$ | 20,57 | 23,11 | 25,65 | 27,94 | 30.86 |
|  | $(0.810)$ | $10.910)$ | $(1.010)$ | $11.100)$ | $(1.215)$ |
| $\mathrm{C}(\mathrm{NOM})$ | 7.37 | 7.37 | 7.37 | 9,91 | 7.37 |
|  | $(0.290)$ | $(0.290)$ | $(0.290)$ | $(0.390)$ | $(0.290)$ |


| DIM | 24 | 28 | 40 | 48 | 52 | 64 |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| $A+0,51(+0.020)$ | 15,24 | 15,24 | 15,24 | 15,24 | 15,24 | 22,86 |
| $-0,25(-0.010)$ | $(0,600)$ | $(0.600)$ | $(0.600)$ | $10.600)$ | $(0.600)$ | $(0.900)$ |
| B (MAX) | 31,8 | 36,8 | 52,1 | 62,2 | 67,3 | 82,6 |
|  | $(1.250)$ | $(1,450)$ | $(2.050)$ | $(2.450)$ | $(2.650)$ | $(3.250)$ |
| C (NOM) | 15,0 | 15,0 | 15,0 | 15,0 | 15,0 | 22.6 |
|  | $(0.590)$ | $(0.590)$ | $(0.590)$ | $(0.590)$ | $(0.590)$ | $(0.890)$ |

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

NOTE A: Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position.

## N plastic packages (including NT and NW dual-in-line packages)

Each of these dual-in-line packages consists of a circuit mounted on a lead frame and encapsulated within an electrically nonconductive plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high-humidity conditions. The packages are intended for insertion in mounting-hole rows on 7,62(0.300), 15,24 (0.600), or $22,86(0.900)$ centers. Once the leads are compressed and inserted, sufficient tension is provided to secure the package in the board during soldering. Leads require no additional cleaning or processing when used in soldered assembly.

NOTE: For all except 24-pin packages, the letter $N$ is used by itself since only the 24-pin package is available in more than one row-spacing. For the 24-pin package, the $7,62(0.300)$ version is designated NT; the $15,24(0.600)$ version is designated NW. If no second letter or row-spacing is specified, the package is assumed to have $15,24(0.600)$ row-spacing.


Falls Within JEDEC TO-116 and EIA MO-001AA Dimensions
ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES


## MECHANICAL DATA

N plastic dual-in-line packages (continued)

20-PIN N PACKAGE


Parts may be supplied in accordance
Parts may be supplied in accordanco
with the alternate side view at the
with the alternate side view at the
option of TI. European-manufactured parts may have pin 1 as shown in view $A$. Alternato-side view parts
manufactured outside of the USA
may have a maximum package length
of 26,7 (1.050).

NOTES: A. Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position. B. For solder-dipped leads, this dimension applies from the lead tip to the standoff. C. Parts may be supplied with a draft angle of $7^{\circ}$ typical at the option of TI .

N plastic dual-in-line packages (continued)


NOTES: A. Each pin centerline is located within $0.25(0.010)$ of its true longitudinal position.
B. For solder-dipped leads, this dimension applies from the lead tip to the standoff.

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

## MECHANICAL DATA

N plastic dual-in-line packages (continued)


NOTES: A. Each pin centerline is located within $0.25(0.010)$ of its true longitudinal position.
B. For solder-dipped leads, this dimension applies from the lead tip to the standoff.

## N plastic dual-in-line packages (continued)



48-PIN, 52-PIN, AND 64-PIN N PLASTIC


PIN SPACING IS 2.54 (0.100) T.P.
(See Note A)

| PIM | 48 | 52 | 64 |
| :--- | :---: | :---: | :---: |
| A $\pm 0,25(0.010)$ | $15,24(0.600)$ | $15,24(0.600)$ | $22,86(0.900)$ |
| B MAX | $62,2(2.45)$ | $67,3(2.65)$ | $81,3(3.20)$ |

ALL LINEAR DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES
NOTES: A. Each pin centerline is located within $0,25(0.010)$ of its true longitudinal position.

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[^0]:    * Current out of a terminal is given as a negative value.

[^1]:    - Denotes available technology.

[^2]:    - Denotes available technology.

    A Denotes planned new products.
    A Denotes " $A$ " suffix version available in the technology indicated.
    $B$ Denotes " $B$ " suffix version available in the technology indicated.

[^3]:    - Denotes available technology.

[^4]:    SN54LS224, SN54LS228 . . . J PACKAGE

[^5]:    ${ }^{10 \mathrm{nH}}$
    $\equiv$ Noninverting delay $\geq 10 \mathrm{~ns}$ (e.g., 2 stages of 'LSO4), 2 places.

[^6]:    ${ }^{\dagger}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

[^7]:    ${ }^{\dagger}$ This symbol is in accordance with ANSII/EEE Std 91-1984 and IEC Publication 617-12.
    Pin numbers shown are for $\mathrm{D}, \mathrm{J}$, and N packages.

[^8]:    *'LS610 and 'LS612 have 3-state ( $\nabla$ ) map outputs.
    'LS611 and 'LS613 have open-collector ( $\Omega$ ) map outputs.

[^9]:    *'ALS616 has 3 -state ( $\nabla$ ) check-bit and data outputs.
    'ALS617 has open-collector( $\Omega$ ) check-bit and data outputs.

[^10]:    ${ }^{\dagger}$ Diagnostic data is a data word with an error in one bit location except when testing the $\overline{M E R R}$ error flag. In this case, the diagnostic data word will contain errors in two bit locations.

[^11]:    These times ensure that corrected data is saved in the output data latch.
    ${ }^{\ddagger}$ These times ensure that the diagnostic data word is saved in the output data latch.

[^12]:    ${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    SFor $1 / O$ ports, the parameters $I_{I_{H}}$ and $I_{I L}$ include the off-state output current.

[^13]:    ${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    $\S_{\text {For }} I / O$ ports, the parameters $I_{I H}$ and $I_{\mid L}$ include the off-state output current.

[^14]:    ${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    SFor $1 / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
    IThe output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, loS.

[^15]:    ${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    ${ }^{5}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.

[^16]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    ${ }^{\ddagger}$ For $I / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state output current.
    \$The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

[^17]:    ${ }^{\ddagger}$ All typical values are at $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

[^18]:    1 These parameters are measured with the internal output state of the storage register opposite to that of the bus input.
    NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

[^19]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{\mathrm{IL}}$ include the off-state output current.
    §The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS

[^20]:    $\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

[^21]:    PRonuction DATA decuments contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments

[^22]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    $\ddagger$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

[^23]:    The positive transition of the MODE control will cause low-level data at the $A$ output Bus or stored in Q to be invalid for 12 ns . NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

[^24]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state output current.
    §The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit current, tos.

[^25]:    $\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
    Pin numbers shown are for DW, JT, and NT packages.

[^26]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\ddagger}$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the off-state current.
    §The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, IOS.

[^27]:    § DB (during select instruction) through Y port.

[^28]:    $\dagger$ This parameter limits normal system performance.

[^29]:    $\dagger$ This parameter limits normal system performance.

[^30]:    $\dagger$ This parameter limits normal system performance.

[^31]:    $\dagger$ For the SLA and SLAD instructions, OVR is set if signed arithmetic overflow or if the ALU result MSB XOR MSB-1 equals one.

[^32]:    ${ }^{\dagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$.
    ${ }^{\ddagger}$ For $1 / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state current.
    SThe output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, los.

[^33]:    $\dagger$ This parameter limits normal system performance.

[^34]:    $\dagger$ This parameter limits normal system performance.

[^35]:    $\dagger$ This parameter limits normal system performance.

[^36]:    $H=$ high level, $L=$ low level, $X=$ irrelevant.
    *Reset command is implemented by setting S2-SO = LLL.

[^37]:    $\mathrm{H}=$ high level, $\mathrm{L}=$ low level, $\mathrm{X}=$ irrelevant, $\mathrm{V}=$ varies (condition code value is dependent upon machine and data status and will vary accordingly).

[^38]:    ${ }^{\dagger}$ Decrementing Register/Counter $A$ or $B$ and sensing a zero.
    NOTE 3: The total clock period of clock high and clock low must not be less than clock cycle time. The minimum pulse durations specified are only for clock high or clock low, but not for both simultaneously.

[^39]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\ddagger}$ For $1 / O$ ports, the parameters $\mathrm{I}_{I \mathrm{H}}$ and $\mathrm{I}_{\mathrm{IL}}$ include the off-state current.
    §The output conditions have been chosen to produce a current that closely approximates one-half the true short-circuit current, IOS.

[^40]:    ${ }^{\dagger}$ Load resistor R1 $=100 \Omega$.

[^41]:    ${ }^{\dagger}$ This parameter limits normal system performance.

[^42]:    ${ }^{\dagger}$ This parameter limits normal system performance.

[^43]:    ${ }^{\dagger}$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
    $\ddagger$ For $I / O$ ports, the parameters $I_{I H}$ and $I_{I L}$ include the offstate output current
    § The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS. and CLK high; and $\mathrm{Y} 15-\mathrm{YO}, \mathrm{ZL}$, and $\mathrm{ZN4}$ open.

[^44]:    ${ }^{\dagger}$ This parameter applies only to the circular mode with S high and OP high.
    $\ddagger$ These parameters apply only to the normalization mode.
    ${ }^{\S}$ These parameters apply only to the 32 -bit mode $(16 \mathrm{~B} / \overline{32 \mathrm{~B}}=\mathrm{L})$.

[^45]:    $t_{\text {en }}=$ tpZL or tPZH
    $t_{\text {dis }}=t^{\text {PLZ }}$ or $\mathrm{t}_{\mathrm{PHZ}}$

[^46]:    NC-No internal connection

[^47]:    $t_{\text {en }}=t_{\text {PZH }}$ or tPZL
    $\mathrm{t}_{\mathrm{dis}}=\mathrm{t}_{\mathrm{PH}} \mathrm{Z}$ or $\mathrm{t}_{\mathrm{pLZ}}$

[^48]:    $\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984.

[^49]:    ${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[^50]:    ${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
    $\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\S}$ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

[^51]:    $\dagger$ For conditions shown as MIN or MAX, use appropriate value specificed under recommended operating conditions.
    $\ddagger$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\S}$ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

[^52]:    ${ }^{\dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
    ${ }^{\ddagger}$ All typical values are at $V_{C C}=5 \mathrm{~V}, \mathrm{~T}_{A}=25^{\circ} \mathrm{C}$.
    ${ }^{\S}$ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.
    Additional information on these products can be obtained from the factory as it becomes available.

[^53]:    ${ }^{\dagger}$ For conditions shown as MIN or MAX, use appropriate value specified under recommended operating conditions.
    $\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{C}} \mathrm{C}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\S}$ For $I / O$ ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{LL}}$ include the off-state output current.
    INot more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

[^54]:    ${ }^{\dagger}$ For conditions shown as MIN or MAX, use appropriate value specified under recommended operating conditions.
    $\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
    ${ }^{\S}$ For I/O ports, the parameters $\mathrm{I}_{\mathrm{IH}}$ and $\mathrm{I}_{\mathrm{I}} \mathrm{include}$ the off-state output current.
    I Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

[^55]:    ${ }^{\dagger}$ These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

[^56]:    ${ }^{\dagger}$ No load dynamic power dissipation, $P_{d}=C_{p d} V_{C C}{ }^{2} f+I C C V_{C C}$ NOTE 2: For load circuit and voltage waveforms, see page 1-14 of the High-Speed CMOS Logic Data Book, 1984.

[^57]:    *Integrated Schottky-Barrier-diode-clamped transistor is patented by Texas Instruments Incorporated, U.S. Patent Number 3,463,975.

[^58]:    *Current flowing out of a terminal is a negative value.

[^59]:    *These times are based on SN74ALS632A data.

[^60]:    *Load resistor R1 = 100

[^61]:    "Small Outline" (D, DW)

    - A-Channel Plastic Tubing
    - Tape and Reel
    - Barnes Carrier (W only)

